

## A New Approach To Data Service . . . 1975 RCA Solid State DATABOOKS

Seven textbook-size volumes covering all current commercial
RCA solid-state devices (through January 1,1975 ) RCA solid-state devices (through January 1, 1975)
Linear Integrated Circuits and DMOS Devices (Data only) ..... SSD-201C
Linear Integrated Circuits and DMOS Devices (Application Notes only) ..... SSD-202C
COS/MOS Digital Integrated Circuits ..... SSD-203C
Power Transistors ..... SSD-204C
RF/Microwave Devices ..... SSD-205C
Thyristors, Rectifiers, and Diacs ..... SSD-206C
High-Reliability Devices ..... SSD-207CAnnouncement Newsletter: "What's New in Solid State"Availabe FREE to all DATABOOK users."Bingo-type Response-Card Service" included with News-letter Available FREE to all DATABOOK users.Update Mailing Service available by subscription.Indexed Binder available for Update Filing.NOTE: See pages 3 and 4 for additional information on thistotal data service. To qualify for Newsletter mailing,use the form on page 4 (unless you received yourDATABOOK directly from RCA). You must qualifyannually since a new mailing list is started for eachedition of the DATABOOKS.

# nen COS/MOS integrated Circuits 

This DATABOOK contains complete data and related application notes on COS/MOS digital integrated circuits presently available from RCA Solid State Division as standard products. For ease of type selection, functional diagrams are shown on pages 8-18. Data sheets are then included in type-number sequence, followed by output-drivecurrent test-circuit connections, terminalassignment diagrams, and dimensional outlines for all types, by application notes in numerical order, and finally by a comprehensive subject index.

To simplify data reference, data sheets are arranged as nearly as possible in numerical sequence of device type numbers. Because some data sheets include more than one type number, however, some types may be out of sequence. If you don't find the type you're looking for where you expect it to be, please consult the Index to Devices on page 7.

Trade Mark(s) Registered ${ }^{\circledR}$
Marca(s) Registrada(s)

Copyright 1974 by RCA Corporation
(All rights reserved under Pan-American Copyright Convention)

Printed in USA/11-74

Information furnished by RCA is believed to be accurate and reliable. However, no responsibility is assumed by RCA for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of RCA.

RCA Solid State | Box 3200 | Somerville, N.J., U.S.A. 08876
RCA Limited | Sunbury-on-Thames | Middlesex TW16 7HW, England
RCA s.a. | 4400 Herstal | Liege, Belgium

## RCA Solid State Total Data Service System

The RCA Solid State DATABOOKS are supplemented throughout the year by a comprehensive data service system that keeps you aware of all new device announcements and lets you obtain as much or as little product information as you need - when you need it.

New solid-state devices and related publications announced during the year are described in a newsletter entitled "What's New in Solid State". If you obtained your DATABOOK(s) directly from RCA, your name is already on the mailing list for this newsletter. If you obtained your book(s) from a source other than RCA and wish to receive the newsletter, please fill out the form on page 4; detach it, and mail it to RCA.

Each newsletter issue contains a "bingo"-type fast-response form for your use in requesting information on new devices of interest to you. If you wish to receive all new product information published throughout the year, without having to use the newsletter response form, you may subscribe to a mailing service which will bring you all new data sheets and application notes in a package every other month. You can also obtain a binder for easy filing of all your supplementary material. Provisions for obtaining information on the update mailing service and the binder are included in the order form on page 4.

Because we are interested in your reaction to this approach to data service, we invite you to add your comments to the form when you return it, or to send your remarks to one of the addresses listed at the top of the form. We solicit your constructive criticism to help us improve our service to you.

## Order Form for＂What＇s New in Solid State＂ and for further information on Update Mailings and Binders

Please fill out just one copy of this form，and mail it to：
（a）from U．S．A．and Canada：
RCA Solid State Division
Box 3200
Somerville，N．J．，U．S．A． 08876
（b）from Latin America and Far East：
RCA Solid State
International Sales
Somerville，N．J．，U．S．A． 08876
（c）from United Kingdom，Europe，Middle East，and Africa：

| RCA Limited | RCA s．a． |  |
| :--- | :--- | :--- |
| Sunbury－on－Thames | or | 4400 Herstal |
| Middlesex TW16 7HW，England |  | Liege，Belgium |

Please add my name to the mailing list for＂What＇s New in Solid State＂
$\square$ Please send me details on obtaining update mailings for my DATABOOKS and a binder for filing of supplementary material．


Function：（Check One）

## A $口$ Executive／Administration

B ㅁ Purchasing／Procurement
C－Research／Development
Do Design Engineer
E व Application／Components Engineer
F ロ Production／Manufacturing
Gロ Documentation／Library
Hロ Reliability／QA
I $\square$ Education／Training
J ロ Program／Project Management
$K 口$ Marketing

Activity：（Check One）
A Broadcast
B－Communication
C I Instrumentation／Control
D－Computer／Data Processing
E $\square$ Computer，Peripheral
$F \square$ Automotive
G a Industrial
Ho Medical
1 ㅁ Research
J ロ Transportation
$K$ C Consumer，Electronic
L $\square$ Consumer，Appliance
Mロ Space
N O Ordnance
$O$ Avionics
P Electronic Warfare

## Table of Contents

Page
Index :o Application Notes ..... 6
Index to Devices ..... 7
Functional Diagrams:
Gates ..... 8
Multivibrators ..... 10
Flip-Flops ..... 11
Latches ..... 11
Shift Registers ..... 12
Counters ..... 13
Display Counters/Decoders/Drivers/Encoders ..... 15
Multiplexers ..... 16
Arithmetic Circuits ..... 17
Phase-Locked Loop ..... 17
Schmitt Trigger ..... 17
Memories ..... 18
Rate Multipliers ..... 18
New Products Program ..... 19
Design and Operating Considerations ..... 21
COS/MOS Family Characteristics ..... 25
Ordering Information ..... 30
IC Packages and Lead Forms ..... 30
Technical Data ..... 31
Appendix:
Output-Drive-Current Test-Circuit Connections ..... 426
Terminal-Assignment Diagrams ..... 428
Dimensional Outlines ..... 435
Application Notes ..... 441
Subject Index ..... 461

## Index to Application Notes

Number Title Page
1CE-402 . . . . . . . . . . "Operating Considerations for RCA Solid State Devices" ..... 442
ICAN-6000 . . . . . . . . . "Handling Considerations for MOS Integrated Circuits" ..... 447
ICAN-6080 . . . . . . . . . Digital-to-Analog Conversion Using the RCA-CD4007A COS/MOS IC' ..... 453
ICAN-6086 . . . . . . . . . "Timekeeping Advances Through COS/MOS Technology" ..... 459
ICAN-6101 . . . . . . . . "The RCA COS/MOS Phase-Locked Loop - A Versatile Building Block for Micro-Power Digital and Analog Applications" ..... 471
ICAN-6166 . . . . . . . . . "COS/MOS MSI Counter and Register Design and Applications" ..... 479
ICAN-6176 . . . . . . . . . "Noise Immunity of COS/MOS Integrated-Circuit Logic Gates" ..... 495
ICAN-6210 . . . . . . . . . "A Typical Data-Gathering and Processing System Using CD4000A-Series COS/MOS Parts" ..... 503
ICAN-6218 . . . . . . . . . "Gate-Oxide Protection Circuit in RCA COS/MOS Digital Integrated Circuits" ..... 514
ICAN-6224 . . . . . . . . "Radiation Resistance of the COS/MOS CD4000A Series" ..... 516
ICAN-6230 . . . . . . . . . 'Using the CD4047A in COS/MOS Timing Applications" ..... 518
ICAN-6267 . . . . . . . . "Astable and Monostable Oscillators Using RCA COS/MOS Digital Integrated Circuits" ..... 531
ICAN-6289 . . . . . . . . ."A COS/MOS PCM Telemetry and Remote Data Acquisition Design" ..... 539
ICAN-6304 . . . . . . . . . "Power Supplies for COS/MOS Systems" ..... 551
ICAN-6498 . . . . . . . . ."Design of Fixed and Programmable Counters Using the RCA-CD4018A COS/MOS Presettable Divide-by-"N" Counter" ..... 556
ICAN-6576 . . . . . . . . ."Power-Supply Considerations for COS/MOS Devices" ..... 562
ICAN-6600 . . . . . . . . ."Arithmetic Arrays Using Standard COS/MOS Building Blocks ..... 568
ICAN-6601 . . . . . . . . "Transmission and Multiplexing of Analog or Digital Signals Utilizing the CD4016A Quad Bilateral Switch" ..... 574
ICAN-6602 . . . . . . . . 'IInterfacing COS/MOS With Other Logic Families" ..... 586
ICAN-6716 . . . . . . . . ."Low-Power Digital Frequency Synthesizers Utilizing COS/MOS IC's" ..... 598
ICAN-6733 . . . . . . . . ."Battery-Powered Digital-Display Clock/Timer and Metering Applications Utilizing the RCA-CD4026A and CD4033A Decade Counters - 7-Segment Output Types" ..... 613
ICAN-6739 . . . . . . . . ."COS/MOS Rate Multipliers - Versatile Circuits for Synthesizing Digital Functions" ..... 629

## Index to COS/MOS Integrated Circuits

(Circuits marked with an asterisk (*) are also available in chip form. A data sheet on COS/MOS IC chips, File No. 517, is available on request.)

Type No.

* CD4000A
* CD4001A
- CD4002A
- CD4004A
- CD4006A
* CD4007A
- CD4008A
* CD4009A
- CD4010A
* CD4011A
- CD4012A
* CD4013A
* CD4014A
* CD4015A
- CD4016A
* CD4017A
* CD4018A
* CD4019A
* CD4020A
- CD4021A
* CD4022A
* CD4023A
* CD4024A
* CD4025A
* CD4026A
* CD4027A
* CD4028A
* CD4029A
* CD4030A
* CD4031A
* CD4032A
* CD4033A
* CD4034A
* CD4035A
* CD4036A
* CD4037A
* CD4038A
* CD4039A
* CD4040A
* CD4041A
* CD4042A
* CD4043A
* CD4044A
* CD4045A
* CD4046A
* CD4047A
* CD4048A
* CD4049A
* CD4050A CD4051A CD4052A CD4053A

Description
Dual 3-input NOR gate plus inverter
Quad 2-input NOR gate
Dual 4-input NOR gate
Replaced by CD4024A Series
18-stage static shift register
Dual complementary pair plus inverter
4-bit full adder with parallel carry
Hex buffer/converter (inverting)
Hex buffer/converter (non-inverting)
Quad 2-input NAND gate
Dual 4-input NAND gate
Dual "D" flip-flop with set/reset
8 -stage static shift register
Dual 4-stage static shift register
Quad bilateral switch
Decade counter/divider
Presettable divide-by" $N$ " counter
Quad AND-OR select gate
14-stage binary/ripple counter
8 -stage static shift register
Divide-by-8 counter/divider
Triple 3-input NAND gate
7 -stage binary counter
Triple 3-input NOR gate
Decade counter/divider
Dual J-K master-slave flip-flop
BCD-to-decimal decoder
Presettable up/down counter
Quad exclusive-OR gate
64-stage static shift register
Triple serial adder (positive logic)
Decade counter/divider
MSI 8-stage static shift register
4 -stage parallel in/out shift register
4-word x 8-bit RAM (binary addressing)
Triple AND-OR bi-phase pairs
Triple serial adder (negative logic)
4-word $\times 8$-bit RAM (word-line addressing)
12-stage binary/ripple counter
Quad true/complement buffer
Quad clocked "D" latch
Quad 3-state NOR R/S latch
Quad 3-state NAND R/S latch
21-stage counter
Micropower phase-locked loop
Monostable/astable multivibrator
Expandable 8-input gate
Hex buffer/converter (inverting)
Hex buffer/converter (non-inverting)
Single 8-channel multiplexer
Differential 4-channel multiplexer
Triple 2-channel multiplexer

Page No.

Type No.

* CD4054A
* CD4055A
- CD4056A
* CD4057A CD4059A
* CD4060A
* CD4061A
- CD4062A
* CD4063B
* CD4066A CD4067B
* CD4068B
* CD4069B CD4070B
- CD4071B
* CD4072B
* CD4073B
* CD4075B CD4076B CD4077B
* CD4078B
* CD4081B
* CD4082B
* CD4085B
* CD4086B

CD4089B

* CD4093B CD4094B CD4095B

CD4096B

CD4097B

CD4098B CD4099B CD4502B CD4511B

* CD4514B

4-line liquid-crystal display driver
BCD-7-segment decoder/driver
BCD-7-segment decoder/driver
LSI 4-bit arithmetic logic unit
Programmable divide-by-N counter
Programmable divide-by-N counter 285
14-stage ripple-carry binary counter/divider and oscillator
256-word x 1-bit static RAM 298
200-stage dynamic shift register 305
4-bit magnitude comparator 313
Quad bilateral switch 319
16-channel multiplexer/demultiplexer 326
8 -input NAND gate 329
Hex Inverter 334
Quad exclusive-OR gate 340
Quad 2-input OR gate 342
Dual 4-input OR gate 342
Triple 3-input AND gate 348
Triple 3-input OR gate 342
4-bit D-Type register with 3 state outputs 354
Quad exclusive NOR gate 340
8 -input NOR gate 357
Quad 2-input AND gate 348
Dual 4-input AND gate 348
Dual 2-wide 2-input AND-OR-INVERT gate 362
Expandable 4-wide 2-input
AND-OR-INVERT gate
Binary rate multiplier 374
Quad 2-input NAND Schmitt Triggers 378
8-stage shift-and-store bus register 384
Gated J-K M-S Flip-Flop
(non-inverting J\&K inputs)
386
Gated J-K M-S Flip-Flop
(inverting \& non-inverting $J \& K$ inputs)
386
Differential 8-channel multiplexer/
demultiplexer
326
Dual monostable multivibrator 388
8-bit addressable latch . 392
Strobed hex inverter/buffer
BCD to 7 -segment latch decoder driver
4-bit latch/4-to-16 line decoder (high on select)

401

* CD4515B 4-bit latch/4-to-16 line decoder 401
(low on select)
407
* CD4518B Dual BCD up counter 407
* CD4520B Dual binary up counter 407

CD4527B
CD4532B

* CD4555B

BCD rate multiplier
417
8 -input priorty encoder
Dual binary to 1 of 4 decoder/
demultiplexer (high on select)
419

* CD4556B Dual binary to 1 -of-4 decoder/ demultiplexer (low on select)

GATES
NOR/NAND, OR/AND


CD4072B
Dual 4-Input OR Gate File No. 807


CD4082B
Dual 4-Input AND Gate File No. 806


CD4081B
Quad 2-Input AND Gate File No. 806

$V_{D D}=14$
$V_{S S}=7$


CD 92cs-23874
CD4068B
8-Input
NAND Gate
File No. 809


CD4002A
Dual 4-Input
NOR Gate
File No. 479


CD4012A
Dual 4-Input NAND Gate
File No. 479


CD4000A
Dual 3-Input NOR Gate
Plus Invarter
File No. 479

## GATES NOR/NAND (Cont'd)



MULTI- LEVEL/FUNCTIONAL


GATES
Buffers \& Inverters



92CS-23737R1
CD4069B
Hex
Inverter
File No. 804
A $3 \sim-2$ - $G=\bar{A}$
B $5 \sim-4 \mathrm{H}=\overline{\mathrm{B}}$
c $7>-6$
0 9
$E 11 \sim-12$
F

(a)
$A \sim$ G=A
$B \xrightarrow{4}$
$\mathrm{C} \xrightarrow{7}=\mathrm{C}$
0 N=0
(12
F 14


92Cs-25158 (b)

CD4010A, CD4050A
File No. $479 \quad$ File No. 599
Hex Buffer/Converter Inverting Type

CD4009A, CD4049A
File No. 479 File No. 599 Hex Buffer/Converter Non-Inverting Type

## MULTIVIBRATORS



CD4047A
Monostable/Astable
Multivibrator
File No. 623


CD4098B
Dual Monostable Multivibrator Preliminary


CD4041A
Quad True/Complement
Buffer
File No. 572


CD4502B
Strobed
Hex Inverter/Buffer
Preliminary

FLIP. FLOPS


92Cs-25046
CD4013A
Dual " $D$ " with
Set/Reset Capability
File No. 479

CD4076B
4-Bit "D"-Type with
3-State Outputs Preliminary



92CS-17187R1
CD4027A
Dual "J-K" with
Set Reset Capability File No. 503

LATCHES


CD4042A
Quad Clocked "D" Latch
File No. 589


CD4095B
Gated J-K M-S Type Non-Inverting Inputs Preliminary


Quad NOR R/S Latch
(3 Output States)
File No. 590


CD4096B
Gated J-K M-S Type Inverting and
Non-Inverting Inputs
Preliminary

## SHIFT REGISTERS



## COUNTERS

Binary/Ripple

$V_{S S}=8$
$V_{D D}=16$
92Cs-20522
CD4040A
12.Stage

File No. 624

Synchronous


CD4017A
Decade Counter/Divider Plus 10 Decoded Decimal Outputs File No. 479


CD4022A
Divide-by-8 Counter/Divider with 8 Decimal Outputs File No. 479


CD4018A
Presettable Divide-by-"N" Counter Fixed or Programmable File No. 479


92cs-25075
CD4029A
Presettalbe Up/Down Counter Binary or BCD-Decade File No. 503

COUNTERS
Synchronous (Cont'd)



File No. 808

Clock-Timer


## DISPLAY COUNTERS/DECODERS/DRIVERS/ENCODERS



CD4026A
Decade Counter/Divider with 7-Segment Display Outputs and Display Enable File No. 503


CD4033A
Decode Counter/Divider with 7-Segment Display Outputs and Ripple Blanking File No. 503

4-Bit Latch/4-to-16 Line Decoders
(High on Select) (Low on Select)
File No. 814


CD4511B
BCD-to-7-Segment Latch Decoder Driver Preliminary





Liquid Crystal BCD to 7-Segment Decoder/Driver with "Display-Frequency" Output File No. 634


Liquid Crystal BCD to 7-Segment Decoder/Driver with Strobed-Latch Function File No. 634

## MULTIPLEXERS



CD4016A
CD4066A
Quad Bilatoral Switch
File No. 479

File No. 769


CD4067B
16-Channal
Multiplexer/Demultiplexer
Preliminary


CD4097B
Differential 8-Channel Multiplexer/Demultiplexer Preliminary


CD4051A
Single 8-Channel
Preliminary


CD4052A
Differential 4-Channel Preliminary



CD4555B
Dual 1-of-4 Decoder/Demultiplexers Output High


CD4556B

Output Low

TRUTH TABLE

| INPUTS |  |  | OUTPUTS CD4555B |  |  |  | OUTPUTS CD4556B |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ENABLE | SELECT |  |  |  |  |  |  |  |  |  |
| E | B | A | Q3 | Q2 | Q1 | 00 | $\overline{\text { Q3 }}$ | $\overline{\mathrm{Q} 2}$ | Q1 | $\overline{\mathrm{QO}}$ |
| 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 |
| 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 |
| 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 |
| 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 |
| 1 | X | X | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |

X = DON'T CARE

## ARITHMETIC CIRCUITS



PHASE-LOCKED LOOP


SCHMITT TRIGGER


CD4093B
Quad 2-Input NAND Type
File No. 836

MEMORIES
Word-Organized


CD4036A
4-Word $\times 8$-Bit (Binary Addressing)
File No. 613


CD4039A
4-Word $\times$ 8-Bit (Direct Word-Line Addressing) File No. 613

Bit-Organized


CD4061A
256-Word by 1-Bit Static Random Access
File No. 768
RATE MULTIPLIERS


## NEW PRODUCTS PROGRAM

The CD Preliminary COS/MOS types listed below are some of the devices scheduled for introduction during 1975. Logic diagrams and terminal assignment diagrams are shown following the listing.

Additional types will also be announced throughout the year. For information concerning announcement dates and product availability*, contact your RCA representative or supplier, or watch for announcement in the RCA Solid State Announcement Newsletter "What's New In Solid State" referred to on the inside front cover of this DATABOOK.

| Preliminary <br> CD Type | Circuit Description | Similar <br> Industry <br> Type |
| :--- | :--- | :---: |
| CD4508B | Dual 4-Bit Latch | MC14508 |
| CD4510B | 4-Bit BCD Up/Down Counter | MC14510 |
| CD4516B | 4-Bit Binary Up/Down Counter | MC14516 |
| CD40100B | 32-Bit Left/Right Shift Register | - |
| CD40101B | 9-Bit Parity Generator \& Checker | - |
| CD40102B | Presettable 8-Bit BCD Down Counter | - |
| CD40103B | Presettable 8-Bit Binary Down Counter | - |
| CD40104B | Three State 4-Bit Left/Right Shift Register | - |
| CD40105B | 4-Word X 4-Bit FIFO Buffer | - |
| CD40106B | Hex Schmitt Trigger Inverter | - |
| CD40107B | Dual 2-Input NAND Buffer/Driver | - |
| CD40108B | 4 X4 Multiport Register | - |
| CD40181B | 4-Bit Arithmetic Logic Unit | - |
| CD40182B | Look-Ahead Carry Block | - |
| CD40192B | Synchronous 4-Bit BCD Up/Down Counter (Dual Clock) | - |
| CD40193B | Synchronous 4-Bit Binary Up/Down Counter (Dual Clock) | - |
| CD40194B | 4-Bit Left/Right Shift Register | - |

*Because of the wide interest in COS/MOS parts, RCA reserves the right to limit sample quantities.


## COUNTERS



## COS/MOS Design and Operating Considerations

The information on the following pages serves as a brief introduction to COS/MOS specifications, ratings, and performance characteristics. This information is included to help the user avoid problems in connection with over-all systems design. COS/MOS operation, design, and layout fundamentals are discussed in detail in the RCA COS/MOS Integrated Circuits Manual, CMS-271.

## Maximum Ratings

The maximum ratings for all the COS/MOS devices included in this book are as follows:


## Operating Supply-Voltage Range

COS/MOS integrated circuits are specified in one of two supply-voltage ranges: "A"-series devices operate from 3 to 15 volts, and " B "-series devices from 3 to 18 volts. Logic systems occasionally experience transient conditions on the powersupply line which, when added to the nominal power-bus voltage, could exceed the safe limits of circuits connected to the power bus. Recommended supply-voltage ranges which realistically assess these conditions are 4 to 12 volts for " $A$ "-series devices, and 4 to 15 volts for " $B$ "-series devices.

The recommended maximum power-supply limit is substantially below the minimum primary breakdown limit for the devices to allow for limited power-supply transient and regulation limits. The minimum recommended supply voltage of 4 volts also takes into account transient and regulation
limits. In addition, circuits that operate in a linear mode over a portion of the voltage range, such as RC or crystal oscillators, often require a supply voltage of at least 4 volts.

## Power Dissipation

Power dissipation in a COS/MOS device is composed of two terms, quiescent (dc) dissipation and dynamic (ac) dissipation, $P_{Q}$ and $P_{a c}$ respectively. Quiescent dissipation, generally varying from a few nanowatts for small devices to tens of microwatts for large devices, is due to a combination of leakage effects comprising parasitic junction diodes (normally reverse-biased) and surface effects. Dynamic dissipation is comprised of two elements: (1) "through"-current that exists during the transition from one logic level to the other, when both N-MOS and P-MOS devices are momentarily conducting simultaneously, and (2) power-supply current required to charge the node and output capacitance during switching.

The first component (internal switching) of dynamic dissipation is usually negligible compared to the component associated with charging capacitance, particularly for systems with fast rise and fall times. As transition times increase, however, through-current increases appreciably and the total current is a complex function of the transition times and capacitance.

In most circuits, the ac dissipation ( $\mathrm{P}_{\mathrm{ac}}$ ) in watts is equal to $\mathrm{C}_{\mathrm{O}} \mathrm{V}_{\mathrm{DD}^{2}} \mathrm{f}$, where $\mathrm{C}_{\mathrm{O}}$ is the effective output capacitance (including load capacitance) in farads, $\mathrm{V}_{\mathrm{DD}}$ is the supply voltage in volts, and f is the frequency in Hz . Because the output capacitance must be charged from $\mathrm{V}_{\mathrm{SS}}$ to $\mathrm{V}_{\mathrm{DD}}$ once each period, dynamic dissipation increases linearly with frequency and load capacitance, and as the square of the supply voltage $\mathrm{V}_{\mathrm{DD}}$. Each COS/MOS data sheet includes a curve showing dynamic power dissipation as a function of frequency. Fig. 1 shows switching current and voltage waveforms for different values of load capacitance and input rise and fall times.

## System Noise Considerations

In general, COS/MOS devices are much less sensitive to noise on power and ground lines than bipolar logic families (such as TTL or DTL). However, this sensitivity varies as a function of the power-supply voltage, and more importantly as a function of synchronism between noise spikes and input transitions. Good power distribution in digital systems requires that the power bus have a low dynamic impedance; for this purpose, discrete decoupling capacitors should be distributed across the power bus.

## Power-Source Rules

The safe operating procedures listed below can easily be understood by reference to the basic COS/MOS inverter and its gate-oxide protection network plus inherent diodes, as shown in Fig. 2.

1. When separate power supplies are used for the COS/MOS

## COS/MOS Design and Operating Considerations



Fig. 1-Switching-current waveforms.
device and for the device inputs, the device power supply should always be turned on before the independent input signal sources, and the input signals should be turned off before the power supply is turned off $\left(\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{\mathrm{I}} \leqslant \mathrm{V}_{\mathrm{DD}}\right.$ as a maximum limit). This rule will prevent over-dissipation and possible damage of the D2 input-protection diode when the device power supply is grounded. When the device power supply is an open circuit, violation of this rule can result in undesired circuit operation although device damage should not result; ac inputs can be rectified by diode D2 to act as a power supply.
2. The power-supply operating voltage should be kept safely below the absolute maximum supply rating, as indicated previously.
3. The power-supply polarity for COS/MOS circuits should not be reversed. The data sheets state that the positive ( $\mathrm{V}_{\mathrm{DD}}$ ) terminal should never be more than 0.5 volt negative with respect to the negative $\left(\mathrm{V}_{\mathrm{SS}}\right)$ terminal $\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}>-0.5 \mathrm{~V}\right)$.


Fig. 2-COS/MOS inverter.

This absolute maximum rating means that reversal of polarity will forward-bias and short the structural and protection diodes between $V_{D D}$ and $V_{S S}$.
4. $V_{D D}$ should be equal to or greater than $V_{C C}$ for COS/MOS buffers which have two power supplies (in particular, for CD4009A and CD4010A COS/MOS-to-TTL "down"-conversion devices).
5. Power-source current capability should be limited to as low a value as reasonable to assure good logic operation.
6. Large values of resistors in series with $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$ should be avoided; transient turn-on of input protection diodes can result from drops across such resistors during switching.

## Gate-Oxide Protection Networks

A problem occasionally encountered in handling and testing low-power semiconductor devices, including MOS and smallgeometry bipolar devices, has been damage to gate oxide and/or p-n junctions. Fig. 3 shows the gate-oxide protection circuits used to protect COS/MOS circuits from static electricity damage. ICAN-6218 gives further information on protection circuits. Although these circuits are included in all COS/MOS devices, the handling precautions discussed in ICAN-6218 and in ICAN-6000 should be observed.

## Input Signals and Ratings

1. Input signals should be maintained within the powersupply voltage range, $\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{\mathrm{I}} \leqslant \mathrm{V}_{\mathrm{DD}}$. In applications such as astable and monostable multivibrators, input current can flow and should be limited to the microampere level by use of a resistor in series with the input terminal affected.
2. All COS/MOS inputs should be terminated. When COS/MOS inputs are wired to edge card connectors with COS/MOS drive coming from another PC board, a shunt resistor should be connected to $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$ in case the inputs become unterminated with the power supply on.

(b)

(c) 92CS-22883


Fig. 3-Protection circuits used in COS/MOS devices: (a) normal gate input protection; (b) CD4059A and CD4050A gate input protection; (c) transmission-gate input-output protection; (d) active (inverter) output protection.
3. When $\operatorname{COS} / \mathrm{MOS}$ circuits are driven by TTL logic, a "pull-up" resistor should be connected from the COS/MOS input to 5 volts (further information is given in ICAN6602).
4. Input signals should be maintained within the recommended input-signal-swing range.

## Output Rules

1. The power dissipation in a COS/MOS package should not exceed 200 milliwatts. The actual dissipation should be calculated when (a) shorting outputs directly to $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$, (b) driving low-impedance loads, or (c) directly driving the base of a p-n-p or n-p-n bipolar transistor.
2. Output short circuits often result from testing errors or improper board assembly. Shorts on buffer outputs or across power supplies greater than 5 volts can damage COS/MOS devices.
3. COS/MOS, like active pull-up TTL, cannot be connected in the "wire-OR" configuration because an "on" P-MOS and an "on" N-MOS transistor could be directly shorted across the power-supply rails.
4. Paralleling inputs and outputs of gates is recommended only when the gates are within the same IC package.
5. Output loads should return to a voltage within the supply-voltage range ( $\mathrm{V}_{\mathrm{DD}}$ to $\mathrm{V}_{\mathrm{SS}}$ ).
6. Large capacitive loads (greater than 5000 pF ) on COS/MOS buffers or high-current drivers act like short circuits and may over-dissipate output transistors.
7. Output transistors may be over-dissipated by operating buffers as linear amplifiers or using these types as one-shot or astable multivibrators.

## Noise Immunity

The complementary structure of the inverter, common to all COS/MOS logic devices, results in a near-ideal input-output transfer characteristic, with switching point midway ( $45 \%$ to $55 \%$ ) between the 0 and 1 output logic levels. The result is high dc noise immunity.

Fig. 4 illustrates minimum and maximum transfer characteristics useful for defining noise immunity for an inverter and a.
non-inverter. The noise-immunity voltage $\left(\mathrm{V}_{\mathrm{NL}}, \mathrm{V}_{\mathrm{NH}}\right)$ is that noise voltage at any one input which will not propagate through the system. Minimum noise immunity is $30 \%$ of the supply voltage ( $20 \%$ for some buffer types). Some noiseimmunity definitions are given below:
$\mathrm{V}_{\mathrm{IL}} \max =$ the maximum input voltage at low-level input for which the output logic level does not change state.
$\mathrm{V}_{\mathrm{IH}} \min =$ the minimum input voltage at high-level input for which the output logic level does not change state.

$\mathrm{v}_{\mathrm{NH}}=\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{IH}}$
$\mathrm{V}_{\mathrm{OH}} \min =$ minimum high-level output voltage (logic 1 level) for rated $\mathrm{V}_{\mathrm{NL}}$ (for an inverting logic function) or $\mathrm{V}_{\mathrm{NH}}$ (for a non-inverting logic function).
$\mathrm{V}_{\mathrm{OL}} \max =$ maximum low-level output voltage for rated $\mathrm{V}_{\mathrm{NH}}$ (for an inverting logic function) or $\mathrm{V}_{\mathrm{NL}}$ (for a non-inverting logic function).

Noise immunity.increases as the input noise pulse width becomes less than the propagation delay of the circuit. This condition is often described as ac noise immunity. (Further information on noise immunity is given in ICAN-6176.)


Fig. 4-Minimum and maximum transfer characteristics for (a) inverting logic function, and (b) non-inverting logic function.

## COS/MOS Design and Operating Considerations

## Clock Rise- and Fall-Time Requirements

All COS/MOS clocked devices have maximum clock riseand fall-time ratings (normally 5 to 15 microseconds). With longer rise or fall times, a device may not function properly because of data ripple-through, false triggering problems, etc. Long rise and fall times on COS/MOS buffer-type inputs cause increased power dissipation which may exceed device capability for power supplies above 5 volts.

## Parallel Clocking

Process variations leading to differences in input threshold voltage among random device samples can cause loss of data between certain synchronously clocked sequential circuits, as
shown in Fig. 5. This problem can be avoided if the clock rise time $\left(t_{r} C L\right)$ is made less than the total of the fixed propagation delay plus the output transition time of the first stage, as determined from the device data for the specific loading condition in effect. Schmitt Trigger circuits such as the CD4093B are an ideal solution to applications requiring wave-shaping.

## Three-State Logic

Three-state logic can be easily implemented by use of a transmission gate in the output circuit; this technique provides a solution to the wire-OR problem in many cases.


Fig. 5-Error effect that results from a slow clock in cascaded circuits.

## COS/MOS Family Characteristics

## Overview

CD4000A Series - RCA COS/MOS types designed for 3-to-15-volt operation; all package styles

CD4000B Series - RCA COS/MOS types designed for 3-to-18-volt operation; all package styles

CD4500B Series - RCA COS/MOS types similar to industry 4500-series types designed for 3-to-18-volt operation; all package styles

## Packages

Dual-in-line Plastic - suffix AE or $\mathrm{BE}\left(-40^{\circ} \mathrm{C}\right.$ to $+85^{\circ} \mathrm{C}$ operation)

Dual-in-line Ceramic - suffix AF or $\mathrm{BF}\left(-55^{\circ} \mathrm{C}\right.$ to $+125^{\circ} \mathrm{C}$ operation)

Dual-in-line Welded-Seal Ceramic - suffix AD or BD $\left(-55^{\circ} \mathrm{C}\right.$ to $+125^{\circ} \mathrm{C}$ operation)

Flat-Pack Ceramic - suffix AK or $\mathrm{BK}\left(-55^{\circ} \mathrm{C}\right.$ to $+125^{\circ} \mathrm{C}$ operation)

Chip Form - suffix AH or $\mathrm{BH}\left(-55^{\circ} \mathrm{C}\right.$ to $+125^{\circ} \mathrm{C}$ operation $)$

## Features

Ultra-Low Quiescent Power:
0.005 to $0.05 \mu \mathrm{~W}$ typical for SSI at $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$
0.1 to $0.5 \mu \mathrm{~W}$ typical for MSI at $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$

Wide Output-Voltage Swing when Driving COS/MOS:
High-level output - typically $\mathrm{V}_{\mathrm{DD}}$
Low-level output - typically $\mathrm{V}_{\mathrm{SS}}$
High Noise Immunity:
$45 \%$ of $V_{D D}$ typical
$30 \%$ of $V_{\text {DD }}$ guaranteed on most devices
High Fan-Out Driving COS/MOS: greater than 50
Input Current: $\pm 10 \mathrm{pA}$ typical
Standard Input-Protection Circuit: double diode clamps plus series resistor

Low Input Capacitance: 5 pF typical

## Static Electrical Characteristics

Quiescent Device Current ( $I_{L}$ ). The quiescent current is the device current drawn by an IC in the steady-state condition with no load on the output. The IC inputs are tied either to the positive $\left(\mathrm{V}_{\mathrm{DD}}\right)$ terminal or the negative $\left(\mathrm{V}_{\mathrm{SS}}\right)$ terminal when quiescent current is measured.
Most devices exhibiting typical or "low" leakage currents at oom temperature $\left(25^{\circ} \mathrm{C}\right)$ are dominated by p-n junction eakage. For these devices, $\mathrm{I}_{\mathrm{L}}$ doubles approximately every $11^{\circ} \mathrm{C}$. Devices exhibiting leakage currents close to the maximum rating are dominated by surface leakage and will not generally follow an exponential characteristic, i.e., surface eakage current will usually increase at a considerably slower ate than junction leakage as the temperature is increased.
Typical and minimum values for $\mathrm{I}_{\mathrm{L}}$ are given on individual COS/MOS data sheets. For "B"-series devices, these values are tandardized for SSI types and for MSI types. Quiescent-
device-current test circuits are also shown on the individual data sheets.

Output Voltage Levels $\left(\mathrm{V}_{\mathrm{OL}}\right.$ and $\left.\mathrm{V}_{\mathrm{OH}}\right) . \mathrm{V}_{\mathrm{OL}}$ is the logic-"0" or low-level output voltage. $\mathrm{V}_{\mathrm{OH}}$ is the logic-" 1 " or high-level output voltage. $\mathrm{V}_{\mathrm{OL}}$ and $\mathrm{V}_{\mathrm{OH}}$ are specified under no load with inputs set at $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$ (i.e., noise-free input conditions). Values for both " A "-series and " B "-series devices are as follows:

Low-Level Output ( $\mathrm{V}_{\mathrm{OL}}$ ):
Typical value at $+25^{\circ} \mathrm{C} \ldots \ldots \ldots . .$. Ground $\left(\mathrm{V}_{\mathrm{SS}}\right)$
Maximum value at $-40^{\circ} \mathrm{C} /-55^{\circ} \mathrm{C} \ldots . . . . . . . . . . .0 .01 \mathrm{~V}$
Maximum value at $+85^{\circ} \mathrm{C} /+125^{\circ} \mathrm{C} \ldots \ldots . \ldots . .0 .05 \mathrm{~V}$
High-Level Output ( $\mathrm{V}_{\mathrm{OH}}$ ):
Typical value at $25^{\circ} \mathrm{C} \ldots \ldots \ldots \ldots . . . . . . . . . . V_{\text {DD }}$
Minimum value at $-40^{\circ} \mathrm{C} /-55^{\circ} \mathrm{C} \ldots \ldots .\left(\mathrm{V}_{\mathrm{DD}}-0.01 \mathrm{~V}\right)$
Minimum value at $+85^{\circ} \mathrm{C} /+125^{\circ} \mathrm{C} \ldots .\left(\mathrm{V}_{\mathrm{DD}}-0.05 \mathrm{~V}\right)$
Voltage and Current Transfer Characteristics. Curves of voltage and current input/output characteristics are given in the individual data sheets for inverter, gate, and buffer devices.

DC Noise Immunity $\left(\mathbf{V}_{\mathbf{N L}}\right.$ and $\left.\mathbf{V}_{\mathbf{N H}}\right)$. Noise-immunity definitions were covered previously. Values for both " $A$ "-series and " $B$ "-series devices are given below:

| ${ }^{\mathrm{V}_{\mathrm{NL}}}{ }_{\mathrm{V}_{\mathrm{DD}}}$ | $\left.\mathrm{V}_{\mathrm{OH}}{ }^{(m i n}.\right)$ | $\mathrm{V}_{\mathrm{NL}}\left(\right.$ at $\left.25^{\circ} \mathrm{C}\right)$ |
| :---: | :---: | :---: |
|  | Inverting Inverting <br> SSI Devices MSI Devices | Typ. Max. |
| 5 | 3.6 | $2.25 \quad 1.5$ |
| 10 | 7.29 .0 | $4.5 \quad 3.0$ |
| 15* | $10.8 \quad 13.5$ | 6.75 - |
| $\mathrm{V}_{\mathrm{NH}} \mathrm{V}_{\mathrm{DD}}$ | $\mathrm{V}_{\mathrm{OL}}{ }^{\text {(max. }}$ ) | $\mathrm{V}_{\mathrm{NH}}\left(\right.$ at $\left.25^{\circ} \mathrm{C}\right)$ |
|  | Inverting Inverting <br> SSI Devices MSI Devices | Typ. Max. |
|  | "A" Series "B" Series |  |
| 5 | $\begin{array}{lll}0.95 & 1.4 & 0.8\end{array}$ | $2.25 \quad 1.5$ |
| 10 | $\begin{array}{lll}2.9 & 2.8 & 1.0\end{array}$ | 4.53 .0 |
| 15* | $4.2 \quad 1.5$ | 6.75 - |

*Specified for " B " series only.

Noise-immunity test circuits are shown on individual device data sheets.

Output Drive Current ( $I_{D} N$ and $I_{D} P$ ). $I_{D} N$ is the output sink current (existing in the N-MOS device) when the P-MOS device is "off" and the N-MOS device is "on", i.e., logic " 0 " state. $\mathrm{I}_{\mathrm{D}} \mathrm{P}$ is the output source current (existing in the P-MOS device) when the N-MOS device is "off" and the P-MOS device is "on", i.e., logic " 1 " state. Output-drive-current values are given in the individual data sheets. For CD4000B- series devices, these values are standardized as follows:

## COS/MOS Family Characteristics

| CHARACTERISTIC | SYMBOL | $\begin{gathered} \mathrm{V}_{\mathrm{O}} \\ \text { Volts } \end{gathered}$ | $\begin{aligned} & V_{D D} \\ & \text { Volts } \end{aligned}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| Output Drive Current: |  |  |  |  |  |  |  |  |  |  |  |  |  |
| N -Channel (Sink) | $I^{\prime} N$ | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - | mA |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |
| P-Channel (Source) | $I^{\prime} P$ | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.15 | - | - | mA |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  | mA |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| $\begin{aligned} & \text { N.Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ | $I^{\prime} N$ | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |
| P-Channel (Source) | ${ }_{10}{ }^{\text {P }}$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA |
|  |  | 4.6 | 5 | -0.45 | - | -- | -0.4 | -0.8 | - | -0.36 | - | - |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |

These charts show that at $+25^{\circ} \mathrm{C}$ drive-current limits are the same for all package styles, i.e., they are standardized for all packages. "B"-series drive-current characteristics curves are also standardized. CD4500B-series devices have the same $I_{D} N$ characteristics, but in some devices the $I_{D} P$ capability differs from standard CD4000B-series standards, although it is identical with similar 4500-series industry types. Figs. 6 and 7 show the normalized variation of output currents (source and sink currents) with respect to temperature and voltage for typical " B "-series devices.

Fig. 8 shows a typical test setup for output drive current. The input switches $\mathrm{S} 1, \mathrm{~S} 2, \mathrm{~S} 3 . \mathrm{S}_{\mathrm{N}}$ are set to positions (or, in sequential logic, sequenced to positions) which will cause the output terminal under test to be at the desired logic level (" 0 " for $I_{D} N$, " 1 " for $I_{D} P$ ). Output switch $S 4$ is positioned to connect an ammeter from the output terminal under test to a separate power source which is to be set to the $\mathrm{V}_{\mathrm{O}}$ value specified in the applicable data sheet. Drive current is measured by means of meter M1. Test-circuit connections for individual COS/MOS devices are given in the Appendix.


Fig. 6-Variation of normalized sink current ( $I_{D} N$ ) and source current
( $D^{P}$ ) with temperature.

## COS/MOS Family Characteristics



92CS-25115


Fig. 7-Variations of normalized sink current ( ${ }_{D} D N$ ) and source current ( $I^{P}$ ) with supply voltage.


Fig. 8-Output-drive-current test circuit.

Input Current ( $\mathbf{I}_{\mathbf{I}}$ ). Input current $\mathrm{I}_{\mathrm{I}}$ is the current measured in an input pin with the input voltage at $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$; it consists only of leakage current existing primarily in protection-circuit diodes.
$\mathrm{I}_{\mathrm{I}}$ (typ.) $= \pm 10$ p A for " A " and " B " series COS/MOS
$I_{I}(\max )=. \pm 1 \mu \mathrm{~A}$ for " $B$ " series COS/MOS at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}$
Fig. 9 shows a typical test setup for input current. Switches S1, S2, S3. . $\mathrm{S}_{\mathrm{N}}$ are set to positions which connect the input


Fig. 9-Input-current test circuit.
terminal under test through current meter M1 to either $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$ (determined by position of S4). Input terminals not under test are connected to $\mathrm{V}_{\mathrm{SS}}$. Output terminals are open. Input current is indicated by meter M1.

Threshold Voltage. Threshold voltages of n - and p -channel devices generally range from 0.7 to 2.8 volts, centered around 1.5 volts. Noise-immunity specifications, which are shown on all COS/MOS data sheets, provide the necessary controls on device thresholds and are generally useful for commercial applications purposes. Values of threshold voltage are specified for high-reliability COS/MOS devices, and are shown in the High-Reliability Devices DATABOOK, SSD-207. Detailed circuits and connections for threshold-voltage tests are also shown in SSD-207.

## Dynamic Electrical Characteristics

For "A"-series COS/MOS devices, dynamic electrical characteristics are measured at $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ and $10 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}$ $=15 \mathrm{pF}$ and input $\mathrm{t}_{\mathrm{r}}$ and $\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$. Typical temperature coefficient for dynamic characteristics is $\left|0.3 \% /{ }^{\circ} \mathrm{C}\right|$ (negative for maximum clock frequency, positive for other time parameters). " $B$ "-series devices are measured at $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}, 10$ V , and $15 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, and input $\mathrm{t}_{\mathrm{r}}$ and $\mathrm{t}_{\mathrm{f}}=20$ ns. Figs. 10-12 show the normalized variation of transition time $\left({ }^{\mathrm{T}} \mathrm{TLH}\right.$ and $\left.{ }^{\mathrm{t}} \mathrm{THL}\right)$ and propagation delay time ( ${ }^{\mathrm{t}} \mathrm{PHL}$ and $\mathrm{t}_{\mathrm{PLH}}$ ) with respect to temperature and voltage for " B "-series devices.

## COS/MOS Family Characteristics



Fig. 10-Variation of normalized transition time (tTLH and tTHL) and propagation delay time (tPHL and tPLH) with temperature.


Fig. 11-Variation of normalized transition time ( ${ }^{\text {TLH }}$ and $\mathrm{t}_{\mathrm{THL}}$ ) with supply voltage.

# COS/MOS Family Characteristics 



Fig. 12-Variation of normalized propagation delay time $\mathbf{~}^{\mathbf{t}} \mathbf{P H L}{ }^{\text {and }}$ ${ }^{t_{P L H}}{ }^{\prime}$ with supply voltage.

Waveforms for measurement of dynamic characteristics are shown at right. Typical curves of dynamic characteristics are given in the individual data sheets. For CD4000B-series devices, values for transition time $\left(\mathrm{t}_{\mathrm{THL}}\right.$ and $\left.\mathrm{t}_{\mathrm{TLH}}\right)$ are standardized, as shown below:

| V DD | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: |
| 5 | 100 | 200 | ns |
| 10 | 50 | 100 | ns |
| 15 | 40 | 80 | ns |

Curves of transition time as a function of $\mathrm{V}_{\mathrm{DD}}$ are also standardized for these devices, as shown in Fig. 13.


Fig. 13-Variation of transition time ( $t_{T H L}$ and $t_{T L H}$ ) with load capacitances at three levels of supply voltage.


Clock pulse rise and fall times


92Cs-20070

Transition Times and Propagation Delay Times for Combinational Logic Circuits


Set-Up Times, Transition Times, and Propagation Delay Times for Positive-Edge-Triggered Sequential Logic Circuits


Set-Up Times, Transition Times, and Propagation Delay Times for Negative-Edge-Triggered Sequential Logic Circuits

## ORDERING INFORMATION

COS/MOS IC's are available in a wide variety of package designs. These packages are identified by Suffix Letters indicated in the chart shown at right. When ordering COS/MOS devices, it is important that the appropriate suffix letter be affixed to the type number of the device required.

CD4000A and CD4000B Series

| PACKAGE | Suffix Letters |
| :--- | :---: |
| Welded-Seal Ceramic Dual-In-Line | D |
| Plastic Dual-In-Line | E |
| Ceramic Dual-In-Line | F |
| Ceramic Flat Pack | K |
| Chip | H |
| TO-5 Style | T |

## COS/MOS PACKAGES AND LEAD FORMS



H-1383R 1

14-Lead
Flat Pack "K'"


14-Lead Welded-Seal
Dual-in-Line
Ceramic "D"


H-1703

16-Lead
Flat Pack "K"


16-Lead Welded-Seal
Dual-in-Line
Ceramic "D"


H-1757
24-Lead
Flat Pack "K"


16-Lead Welded-Seal Dual-in-Line
Ceramic "D"

14-Lead
Dual-in-Line Ceramic "F"
14-Lead
Dual-in-Line Ceramic "F"



H-1803

28-Lead Flat Pack "K"


24-Lead Welded-Seal
Dual-in-Line
Ceramic "D"


28-Lead Welded-Seal
Dual-in-Line
Ceramic " $D$ "


16-Lead Welded-Seal Dual-in-Line SideBrazed Ceramic "D"


16-Lead
Dual-in-Line Ceramic " $F$ "


14-Lead Dual-inLine Plastic "E"


16-Lead Dual-in-
Line Plastic " $E$ "


12-Lead
TO-5 "T"

## Technical Data

## Digital Integrated Circuits

Monolithic Silicon
CD4000A,CD4001A CD4002A,CD4025A


## COS/MOS NOR Gates (Positive Logic)

## Special Features

- Medium speed operation. . . . . . tPHL $=$ tPLH $=25$ ns (typ.) at $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$
- Low "high"- and "low"-level output impedance. . . . . . $500 \Omega$ and $200 \Omega$ (typ), respectively at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$

Dual 3 Input
plus Inverter CD4000AD, CD 4000AE, CD4000AF, CD 4000AK Quad 2 Input CD4001AD, CD4001AE, CD4001AF, CD4001AK
Dual 4 Input CD4002AD, CD4002AE, CD4002AF, CD4002AK
Triple 3 Input CD4025AD, CD4025AE, CD4025AF, CD4025AK

The combination of these devices and the RCA NAND positive logic gate types CD4011A, CD4012A, and CD4023A
can account for appreciable package-count savings in various logic function configurations.



CD4002A


CD4025A


Fig.1.1-Schematic diagram for type CD4000A.


Fig.1.2-Schematic diagram for type CD4001A.


Fig.1.3-Schematic diagram for type CD4002A.


STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathbf{V}_{\mathbf{D D}}-\mathbf{V}_{\mathbf{S S}}$ )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC <br> TERISTIC <br> curves <br> \& TEST <br> CIRCUITS <br> Fig. No |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4000AD,CD4001AD,CD4002AD,CD4025AD, CD4000AK,CD4001AK,CD4002AK,CD4025AK, CD4000AF,CD4001AF,CD4002AF,CD4025AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 0.05 | - | 0.001 | 0.05 | - | - | 3 | $\mu \mathrm{A}$ |  |
|  |  |  | 10 | - | - | 0.1 | - | 0.001 | 0.1 | - | - | 6 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 0.25 | - | 0.005 | 0.25 | - | - | 15 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {O }}$ | $\begin{aligned} & V_{1}=V_{D D} \\ & I_{0}=O A \end{aligned}$ | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | $\begin{aligned} & 15 \\ & 1.6 \end{aligned}$ |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH | $\begin{aligned} & V_{1}=V_{S S} \\ & I_{O}=O A \end{aligned}$ | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v | 1.7 |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 3.6 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | - |
|  |  | $10=0$ | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | v | - |
|  |  |  | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: <br> N -Channel | IDN | $V_{1}=V_{\text {DD }}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | 0.5 | - | - | 0.40 | 1 | - | 0.28 | - | - | mA | $\begin{aligned} & 1.8 \\ & 1.10 \end{aligned}$ |
|  |  |  |  | 1.1 | - | - | 0.9 | 2.5 | - | 0.65 | - | - |  |  |
| P.Channel | ${ }^{1}{ }^{P}$ | $\mathrm{V}_{1}=\mathrm{V}_{\text {SS }}$ | 5 | -0.62 | - | - | 0.5 | -2 | $=$ | -0.35 | - | - | mA | $\begin{aligned} & 1.9 \\ & 1.11 \end{aligned}$ |
|  |  |  | 10 | -0.62 | - | - | 0.5 | -1 | - | -0.35 | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

4 Maximum noise-free low-level Bipolar output voltage.
$\neq$ Minimum noise-free high-level Bipolar output voltage.


Fig.1.5-Min. \& max. voltage transfer characteristics.


Fig. 1.6-Typ. voltage transfer characteristics
as a function of temp.

File No. 479

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage (VD $\mathrm{V}_{\mathrm{DS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4000AE, CD4001AE, CD4002AE, CD4025AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $V_{0}$ | VDD | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volt: | Min. | Typ. | Max. | Min. | Typ. | Max: | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $\mathrm{I}_{\mathrm{L}}$ |  | 5 | - | - | 0.5 | - | 0.005 | 0.5 | - | - | 15 | $\mu \mathrm{A}$ |  |
|  |  |  | 10 | - | - | 5 | - | 0.005 | 5 | - | - | 30 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 2.5 | - | 0.025 | 2.5 | - | - | 75 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 50 | - | 0.05 | 50 | - | - | 300 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ | $\begin{aligned} & V_{1}=V_{D D} \\ & I_{O}=O A \end{aligned}$ | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | $\begin{aligned} & 1.5 \\ & 1.6 \end{aligned}$ |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ | $\begin{aligned} & V_{1}=V_{S S} \\ & I_{O}=O A \end{aligned}$ | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | 1.7 |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - |  |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition. <br> See Appendix | $V_{N L}$ | $10=0$ | 5 | 1.5 |  | - | 1.5 | 2.25 |  | 1.4 |  |  | V | - |
|  |  |  | 10 | 3 |  |  | 3 | 4.5 |  | 2.9 |  |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 5 | 1.4 | - |  | 1.5 | 2.25 |  | 1.5 |  |  | v | - |
|  |  |  | 10 | 2.9 | - |  | 3 | 4.5 |  | 3 |  |  |  |  |
| Output Drive Current: N-Channel | IDN | $V_{1}=V_{D D}$ | 5 | 0.35 | - | - | 0.3 | 1 | - | 0.24 | - | - | mA | $\begin{aligned} & 1.8 \\ & 1.10 \end{aligned}$ |
|  |  |  |  | 0.72 | - | - | 0.6 | 2.5 | - | 0.48 | - | - |  |  |
| P-Channel | ${ }^{1} \mathrm{D} P$ | $\mathrm{V}_{1}=\mathrm{V}_{\mathrm{SS}} \left\lvert\, \begin{aligned} & 2.5 \neq \\ & 9.5\end{aligned}\right.$ | 5 | -0.35 | - | - | -0.3 | -2 | - | -0.24 | - | - | $m A$ | $\begin{aligned} & 1.9 \\ & 1.11 \end{aligned}$ |
|  |  |  |  | -0.3 | - | - | -0.25 | -1 | - | -0.2 | - | - |  |  |
| Input Current | 1 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

A Maximum noise-free low-level Bipolar output voltage.
$\neq$ Minimum noise-free high-level Bipolar output voltage.

- See Appendix.


Fig.1.7-Typ. current \& voltage transfer characteristics.


Fig. 1.8-Typ. n-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=\mathbf{2 0} \mathrm{ns}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3 \%} /{ }^{\circ} \mathbf{C}$. (See Appendix for Waveforms)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4000AD, AF, AK CD4001AD, AF, AK CD4002AD, AF, AK CD4025AD, AF, AK |  |  | CD4000AE, CD4001AE CD4002AE,CD4025AE |  |  |  |  |
|  |  | VDD (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: High to-Low Level | tPHL | 5 | - | 35 | 50 | - | 35 | 80 | ns | 1.13 |
|  |  | 10 | - | 25 | 40 | - | 25 | 55 |  |  |
| Low-to-High Level | tPLH | 5 | - | 35 | 95 | - | 35 | 120 | ns | 1.13 |
|  |  | 10 | - | 25 | 45 | - | 25 | 65 |  |  |
| Transition Time: High-to-Low Level | tTHL | 5 | - | 65 | 125 | - | 65 | 200 | ns | 1.14 |
|  |  | 10 | - | 35 | 70 | - | 35 | 115 |  |  |
| Low-to-High Level | tTLH | 5 | - | 65 | 175 | - | 65 | 300 | ns | 1.14 |
|  |  | 10 | - | 35 | 75 | - | 35 | 125 |  |  |
| Input Capacitance | $C_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF | - |

DYNAMIC ELECTRICAL CHARACTERISTICS (Driving TTL,DTL) AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{D D}{ }^{-V_{S S}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | TYPICAL CHARAC. TERISTICS CURVES Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{array}{\|l\|} \text { Driving } \\ \text { TTL,DTL } \end{array}$ | CD4000AD, AF, AK CD4001AD, AF, AK CD4002AD, AF, AK CD4025AD, AF, AK |  |  | CD4000AE,CD4001AE CD4002AE,CD4025AE |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: High-To-Low Level | ${ }^{\text {tPHL}}$ | $R_{L}=2 k \Omega 2$ | Med. Power | - | 35 | - | - | 35 | - | ns | 1.15 |
|  |  | $R_{L}=20 \mathrm{ks} 2$ | Low Power | - | 35 | - | - | 35 | - |  |  |
| Low.To.High Level | ${ }^{\text {P PLH }}$ | $R_{L}=2 k \Omega 2$ | Med. Power | - | 15 | - | - | 15 | - | ns | 1.16 |
|  |  | $\mathrm{R}_{\mathrm{L}}=20 \mathrm{k} \Omega$ | Low Power | - | 20 | - | - | 20 | - |  |  |
| Transition Time | ${ }^{\text {t }}$ THL | $R_{L}-2 k \Omega$ | Med. Power | -- | 40 | - | - | 40 | - | ns |  |
|  |  | $\mathrm{R}_{\mathrm{L}}=20 \mathrm{kS2}$ | Low Power | - | 40 | - | - | 40 | - |  |  |

DRAIN-TO-SOURCE VOLTS ( $V_{D S}$ )

$92 \mathrm{CS}-17776$
Fig. 1.9-Typ. p-channel drain characteristics.



92CS-17844
Fig.1.11-Min. p-channel drain characteristics.


Fig.1.13-Typ. propagation delay time vs. $C_{L}$.


Fig. 1.15-Typ.low-level propagation delay time vs. $C_{L}-$ driving TTL \& DTL.


Fig. 1.12-Typ. propagation delay time vs. VDD.


Fig.1.14-Typ. transition time vs. $C_{L}$.

Fig.1.16-Typ. high-level propagation delay time vs. $C_{L}-$ driving $T T L$ \& DTL.


Fig. 1.17 - Typ. dissipation characteristics.


Fig. 1.18 - Quiescent device current test circuit for CD4000A.


Fig. 1.19 - Quiescent device current test circuit for CD4001A.


Fig. 1.20 - Quiescent device current test circuit for CD4002A.


Fig.1.21 - Quiescent device current test circuit for CD4025A.


Fig. 1.22 - Noise immuntty test circuit for CD4000A.


Fig.1.23-Noise immunity test circuit for CD4001A.


Fig. 1.24 - Noise immunity test circuit for CD4002A.


92CS - 20736RI
Fig. 1.25 - Noise immunity test circuit for CD4025A.

# Digital Integrated Circuits <br> Monolithic Silicon <br> CD4006AD, CD4006AF CD4006AE, CD4006AK 



# COS/MOS 18-Stage Static Shift Register 

Special Features

- Fully static operation
- Up to 5 MHz shifting rates
- Permanent register storage with clock line "high" or "low" - - - no information recirculation required


## Applications

- Serial shift registers
- Time delay circuits
- ${ }^{6}$ Frequency division

CD4006A types are comprised of 4 separate "shift register" sections; two sections of four stages and two sections of five stages with an output tap at the fourth stage. Each section has an independent "single rail" data path.
A common clock signal is used for all stages. Data is shifted to the next stage on negative-going transitions of the clock.


TRUTH TABLE FOR SHIFT REGISTER STAGE

| $D$ | $C L^{\Delta}$ | $D+1$ |
| :---: | :---: | :---: |
| 0 | $\square$ | 0 |
| 1 | $\square$ | 1 |
| $x$ | $\Gamma$ | $N C$ |

NC $=$ NO CHANGE
$X=$ DON'T CARE
$\Delta=$ LEVEL CHANGE

92Cs-17887
Fig.3.1-Logic diagram and truth table (one register stage) for type CD4006A.

Through appropriate connections of inputs and outputs, multiple register sections of $4,5,8$, and 9 stages or single register sections of $10,12,13,14,16,17$ and 18 can be implemented using one CD4006A package. Longer shift register sections can be assembled by using more than one CD4006A.


NOTE: ALL " $p$ "-UNIT SUBSTRATES ARE CONNECTED TO VDD
ALL "N" -UNIT SUBSTRATES ARE CONNECTED TO $V_{S S}$

92CS-17894
Fig.3.2-Schematic diagram (one register stage) for type CD4006A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs . . . . . . . . . . . . . . . . . . . . . . . . . . V VSS $\leq V_{1} \leq V_{D D}$ )
(Recommended DC Supply Voltage (VDD $\mathbf{V}_{\text {SS }}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | test CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC teristic CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4006AD, CD4006AK, CD4006AF |  |  |  |  |  |  |  |  |  |  |
|  |  | - $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max, |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 3.11 |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 2.5 | - | 0.05 | 2.5 | - | - | 150 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 10 | - | 0.1 | 10 | - | - | 600 |  |  |
| Output Voltage: <br> Low Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{VOH}_{\mathrm{O}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $v$ | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) <br> For Definition, See Appendix | $\mathrm{v}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 3.12 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | $\checkmark$ |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N -Channel | $I_{0} \mathrm{~N}$ | 0.5 | 5 | 0.155 | - | - | 0.125 | 0.25 | - | 0.085 | - | - | mA | $\begin{aligned} & 3.3 \\ & 3.5^{\circ} \end{aligned}$ |
|  |  | 0.5 | 10 | 0.31 | - | - | 0.25 | 0.5 | - | 0.175 | - | - |  |  |
| P.Channel | ${ }_{10}{ }^{P}$ | 4.5 | 5 | -0.125 | - | - | -0.1 | -0.15 | - | -0.07 | - | $-$ | mA | $\begin{aligned} & 3.4 \\ & 3.6^{\star} \end{aligned}$ |
|  |  | 9.5 | 10 | -0.25 | - | - | -0.2 | -0.3 | - | -0.14 | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

- See Appendix.


Fig.3.3-Typ. n-channel drain characteristics.


Fig.3.4-Typ. p-channel drain characteristics.

STATIC ELECTRICAL CHARACTERISTICS (AII inputs . . . . . . . . . . . . . . . . . . . . . . . . . . $\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. <br> TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4006AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | VDD | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.03 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 3.11 |
|  |  |  | 10 | - | - | 10 | - | 0.05 | 10 | - | - | 140 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 25 | - | 0.15 | 25 | - | - | 350 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 100 | - | 0.5 | 100 | - | - | 1400 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) <br> For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 3.12 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\text {NH }}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N-Channel | ${ }^{1} \mathrm{ON}$ | 0.5 | 5 | 0.072 | - | - | 0.06 | 0.25 | - | 0.048 | - | - | mA | $\begin{aligned} & 3.3 \\ & 3.5 \end{aligned}$ |
|  |  | 0.5 | 10 | 0.15 | - | - | 0.125 | 0.5 | - | 0.10 | - | - |  |  |
| P-Channel | ${ }_{10}{ }^{P}$ | 4.5 | 5 | -0.06 | - | - | -0.05 | -0.15 | - | -0.04 | - | - | mA | $\begin{aligned} & 3.4 \\ & 3.6^{\circ} \end{aligned}$ |
|  |  | 9.5 | 10 | -0.12 | - | - | -0.1 | -0.3 | - | -0.08 | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

- See Appendix.


Fig.3.5-Min. n-channel drain characteristics.


Fig.3.6-Min. p-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$ except $\mathrm{t}_{\mathbf{r}} C L, \mathrm{t}_{\mathbf{f}} \mathrm{CL}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3} \%{ }^{\circ} \mathrm{C}$ (See Appendix for Waveforms)


* If more than one unit is cascaded $\mathrm{t}_{\mathrm{f}} \mathrm{CL}$ should be made less than or equal to the sum of the fixed propagation delay at 15 pF and the transition time of the output driving stage for the estimated capacitive load.


Fig.3.7-Typ. propagation delay time vs. $C_{L}$.


Fig.3.8-Typ. transition time vs. $C_{L}$.


Fig.3.9-Typ. dissipation characteristics.


Fig.3.10-Typ. input clock frequency vs. VDD.



Fig.3.12-Noise immunity test circuit.



Terminal No. $14=V_{D D}$
Terminal No. $7=V_{S S}$

## COS/MOS Dual Complementary Pair Plus Inverter

Special Features

- Medium speed operation. . . tPHL $=$ tpLH $=20 \mathrm{~ns}$ (typ.) at $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$
- Low "high"- and "low"-output impedance. . . . . $500 \Omega$ (typ.) at $V_{D D}-V_{S S}=10 \mathrm{~V}$


## Applications

- Extremely high-input impedance amplifiers; inverters, shapers, linear amplifiers, threshold detector

CD4007A types are comprised of three N-Channel and three P-Channel enhancement-type MOS transistors. The transistor elements are accessible through the package terminals to provide a convenient means for constructing the various typical circuits shown in Fig.4.1.

More complex functions are possible using multiple packages. Numbers shown in parentheses indicate terminals that are connected together to form the various configurations listed. For proper operation $\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ must be satisfied.


Fig.4.1-Sample COS/MOS logic circuit arrangements using type CD4007A.

File No. 479

STATIC ELECTRICAL CHARACTERISTICS (AII inputs $\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\left.\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}\right) \ldots . . . . . .3$ to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4007AD, CD4007AK, CD4007AF |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  | VDD | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  |  | 5 | - | - | 0.05 | - | 0.001 | 0.05 | - | - | 3 | $\mu \mathrm{A}$ | 4.15 |
|  |  |  |  | 10 | - | - | 0.1 | - | 0.001 | 0.1 | - | - | 6 |  |  |
| Quiescent Device Dissipation/Package | $P^{\text {D }}$ |  |  | 5 | - | - | 0.25 | - | 0.005 | 0.25 | - | - | 15 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | $\begin{aligned} & 4.2 \\ & 4.3 \\ & 4.4 \\ & 1.5 \\ & 4.6 \end{aligned}$ |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition, See Appendix | $V_{\text {NL }}$ |  | 3.6 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 4.16 |
|  |  |  | 7.2 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $V_{\text {NH }}$ |  | 0.95 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  |  | 2.9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N -Channel | 1 DN | $V_{1}=V_{\text {DD }}$ | $0.4{ }^{4}$ | 5 | 0.75 | - | - | 0.6 | 1 | - | 0.4 | - | - | mA | $\begin{aligned} & 4.7 \\ & 4.9 \end{aligned}$ |
|  |  |  | 0.5 | 10 | 1.6 | - | - | 1.3 | 2.5 | - | 0.95 | - | - |  |  |
| P-Channel | $I_{\text {I }}$ P | $\mathrm{V}_{1}=\mathrm{V}_{\text {SS }}$ | 2.57 | 5 | -1.75 | - | - | -1.4 | -4 | - | -1 | - | - |  | $\begin{aligned} & 4.8 \\ & 4.10 \end{aligned}$ |
|  |  |  | 9.5 | 10 | -1.35 | - | - | -1.1 | -2.5 | - | -0.75 | - | - |  |  |
| Input Current | $1 /$ |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

4 Maximum noise-free low-level Bipolar output voltage.
${ }^{\prime}$ Minimum noise-free high-level Bipolar output voltage.
g) High Sink- and Source-Current Driver

h) Dual Bi-Directional Transmission Gating
(1,5,12); $(2,9)$;
(11,4); $(8,13,10) ;(6,3)$
(2) $\begin{aligned} & \text { OUT, } \\ & \left(\mathrm{IN}_{1}\right)\end{aligned}$


92CS-15347

Fig.4.1-Sample COS/MOS logic circuit arrangements using type CD4007A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voitage (VDD $\mathbf{V}_{\mathbf{S S}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4007AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $V_{0}$ Volts | $V_{\text {DO }}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device |  |  | 5 | - | - | 0.5 | - | 0.005 | 0.5 | - | - | 15 | $\mu \mathrm{A}$ | 4.15 |
|  | IL |  | 10 | - | - | 1 | - | 0.005 | 1 | - | - | 30 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 2.5 | - | 0.025 | 2.5 | - | - | 75 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 10 | - | 0.05 | 10 | - | - | 300 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | $\begin{aligned} & 4.2 \\ & 4.3 \\ & 4.4 \\ & 1.5 \\ & 4.6 \end{aligned}$ |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | , | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition, <br> See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 3.6 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 4.16 |
|  |  | 7.2 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | VNH | 0.95 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 2.9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N-Channel | 10 N | $V_{1}=V_{\text {DD }}$ | 5 | 0.35 | - | - | 0.3 | 1 | - | 0.24 | - | - | mA | $\begin{aligned} & 4.7 \\ & 4.9 \end{aligned}$ |
|  |  |  | 10 | 1.2 | - | - | 1 | 2.5 | - | 0.8 | - - | - |  |  |
| P-Channel | $I^{\prime} P$ | $\mathrm{V}_{1}=\mathrm{V}_{\text {SS }}$ | 5 | -1.3 | - | - | -1.1 | -4 | - | -0.9 | - | - |  | $\begin{aligned} & 4.8 \\ & 4.10 \end{aligned}$ |
|  |  |  | 10 | -0.65 | - | - | -0.55 | -2.5 | - | -0.45 | - | - |  |  |
| Input Current | $1 /$ |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

[^0]

Detailed schematic diagram showing input, output, and parasitic diodes.

File No. 479

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ and input rise and fall times $=20 \mathrm{~ns}$
Typical Temperature Coefficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$ (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4007AD,CD4007AK CD4007AF |  |  | CD4007AE |  |  |  |  |
|  |  | $\begin{array}{\|l\|} \hline \text { VDD } \\ \text { (Volts) } \\ \hline \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: High-to-Low Level | tPHL | 5 | - | 35 | 60 | - | 35 | 75 | ns | $\begin{aligned} & 4.11 \\ & 4.13 \end{aligned}$ |
|  |  | 10 | - | 20 | 40 | - | 20 | 50 |  |  |
| Low-to-High Level | tPLH | 5 | - | 35 | 60 | - | 35 | 75 | ns |  |
|  |  | 10 | - | 20 | 40. | - | 20 | 50 |  |  |
| Transition Time: High-to-Low Level | tTHL | 5 | - | 50 | 75 | - | 50 | 100 | ns | 4.12 |
|  |  | 10 | - | 30 | 40 | - | 30 | 50 |  |  |
| Low-to-High Level | tTLH | 5 | - | 50 | 75 | - | 50 | 100 | ns |  |
|  |  | 10 | - | 30 | 40. | - | 30 | 50 |  |  |
| Input Capacitance | CI | Any Input | - | 5 | - | - | 5 | - | pF | - |



Fig.4.2-Min. \& max. voltage transfer characteristics for inverter.


Fig.4.4-Typ. voiràje transier characteristics for NAND gate.


Fig.4.3-Typ. voltage transfer characteristics for NOR gate.


Fig.4.5-Typ. voltage transfer characteristics as a function of temp.


Fig.4.6-Typ. current and voltage transfer characteristics for inverter.


92CS-17788
Fig.4.8-Typ. p-channel drain characteristics.


Fig.4.7-Typ. n-channel drain characteristics.


Fig.4.9-Min. n-channel drain characteristics.

File No. 479


Fig.4.12-Typ. transition time vs. $C_{L}$.


Fig.4.14-Typ. dissipation characteristics.


Fig.4.13-Max. propagation delay time vs. $v_{D D}$.


Fig.4.15-Quiescent device current test circuit.


Fig.4.16-Noise immunity test circuit.

# Digital Integrated Circuits 

Monolithic Silicon
CD4008AD, CD4008AF CD4008AE, CD4008AK


## COS/MOS Four-Bit Full Adder

With Parallel Carry Out

## Special Features

- MSI complexity on a single chip. ..... 4 Sum Outputs plus parallel Carry-Output
- High speed operation. . . . . . Carry-In to Carry-Out delay, tPHL. tpLH $=45$ ns at $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$


## Applications

- Binary addition/arithmetic units

CD4008A types consist of four full-adder stages with fast look-ahead carry provision from stage to stage. Circuitry is included to provide a fast "parallel-carry-out" bit to permit high-speed operation in arithmetic sections using several CD4008A's. CD4008A inputs include the four sets of bits to be added, $A_{1}$ to $A_{4}$ and $B_{1}$ to $B_{4}$, in addition to the "Carry In" bit from a previous section. CD4008A outputs include the four sum bits, $\mathrm{S}_{1}$ and $\mathrm{S}_{4}$, in addition to the high-speed "parallel-cary-out" which may be utilized at a succeeding CD4008A section.


TERMINAL NO. $16=V_{\text {OD }}$. TERMINAL NO. $8=V_{S S}$

Fig.5.1-Logic diagram for type CD4008A.
TRUTH TAGLE

| $A_{i}$ | $B_{i}$ | $C_{i}$ | $C_{0}$ | SUM |
| :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 1 |
| 0 | 1 | 0 | 0 | 1 |
| 1 | 1 | 0 | 1 | 0 |
| 0 | 0 | 1 | 0 | 1 |
| 1 | 0 | 1 | 1 | 0 |
| 0 | 1 | 1 | 1 | 0 |
| 1 | 1 | 1 | 1 | 1 |



NOTES
ALL "A" $\mathbf{B}^{\text {" } B \text { " INPUT BITS OCCUR AT } 1=0}$ ALL SUMS SETTLED AT $t=530 \mathrm{~ns}$ $C_{L}=15 \mathrm{pF}, \mathrm{T}_{A}=+25^{\circ} \mathrm{C}, V_{D D}-V_{S S}=+10 \mathrm{~V}$

Fig.5.2-Typical speed characteristics of a 16-bit adder.

File No. 479

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage (VDD $-\mathrm{V}_{\mathrm{SS}}$ )

| CHARACTERISTIC | SYMBOL | $\begin{gathered} \text { TEST } \\ \text { CONDITIONS } \end{gathered}$ |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES 8. TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4008AD, CD4003AK, CD4008AF |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $v_{0}$ | $V_{\text {DO }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Trp. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Cursent | ${ }^{\prime}$ |  |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 5.8 |
|  |  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Pack age | $P_{D}$ |  |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | $v$ | - |
|  |  |  |  | 10 | - | - | 0.01 | . | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{VOH}^{\text {O }}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | . | 995 | . | $\cdots$ |  |  |
| Noise Immunity (Any Input) For Definition. Soe Appendix | $V_{\text {NL }}$ |  | 0.95 | 5 | 1.5 | - |  | 1.5 | 2.25 | . | 14 | - | . | $v$ | $5.9 *$ |
|  |  |  | 2.9 | 10 | 3 | - | - | 3 | 4.5 | - | 29 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 36 | 5 | 1.4 | - | . | 1.5 | 225 | . | 15 | - | - | v |  |
|  |  |  | 7.2 | 10 | 2.9 | - | - | 3 | 4.5 | . | 3 | - | - |  |  |
| Output Drive Current N -Channel | ${ }_{1}{ }^{N}$ | $\begin{array}{\|c\|} \hline \text { Carry } \\ \text { Output } \\ \hline \end{array}$ | 0.5 | 5 | 0.31 | - | - | 0.25 | 0.5 | - | 0.175 | - | - | mA | - |
|  |  |  | 0.5 | 10 | 0.93 | - | - | 0.75 | 1.5 | - | 0.53 | - | - |  |  |
|  |  | $\begin{gathered} \text { Sum } \\ \text { Output } \end{gathered}$ | 3 | 5 | 0.012 | - | - | 0.01 | 0.2 | - | 0.007 | - | - |  |  |
|  |  |  | 3 | 10 | 0.31 | - | - | 0.25 | 0.5 | - | 0.175 | - | - |  |  |
| P.Channel | ${ }_{1}{ }^{P}$ | $\begin{array}{\|c\|} \hline \text { Carry } \\ \text { Output } \end{array}$ | 4.5 | 5 | -0.31 | - | - | -0.25 | -0.5 | - | -0.175 | - | - | mA |  |
|  |  |  | 9.5 | 10 | 0.93 | - | - | 0.75 | -1.5 | - | -0.53 | - | - |  |  |
|  |  | $\begin{array}{\|c\|} \hline \text { Sum } \\ \text { Output } \end{array}$ | 2 | 5 | 0.012 | - | - | -0.01 | -0.2 | - | 0.007 | - | - |  |  |
|  |  |  | 7 | 10 | 0.185 | - | - | -0.15 | -0.3 | - | -0.105 | - | - |  |  |
| Input Current | 1 |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

${ }^{\star}$ See Appendix


92Cs-17822
Fig.5.3-Sum-in to carry out propagation delay time vs. $C_{L}$.


Fig.5.4-Sum-in or carry-in to sum-out propagation delay time vs. $C_{L}$.

STATIC ELECTRICAL CHARACTERISTICS (All inputs $\mathbf{v}_{\mathbf{S s}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}} \mathbf{l}$
(Recommended DC Supply Voltage $\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}\right) \ldots \ldots . . .3$ to 15 V )

| CHARACTERISTIC | SYMBOL | $\begin{gathered} \text { TEST } \\ \text { CONDITIONS } \end{gathered}$ |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES 8 TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  |  | 4008A |  |  |  | - |  |  |
|  |  | $V_{0}$ Volts |  | VDD <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime}$ |  |  |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 5.8 |
|  |  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |  |
|  |  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  |  | 5 | - | - | 0.01 |  | 0 | 0.01 | - | - | 0.05 | $v$ | - |  |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |  |
| High Level | VOH |  |  | 5 | 4.99 | - | . - | 499 | 5 | - | 4.95 | - | - | V | - |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 0.95 | - | - |  |  |  |
| Noise Immunity (Any Input) For Definition, See Appendix | VNL |  | 0.95 | 5 | 1.5 | . | - | 15 | 2.25 | . | 1.4 | - | - | V | $5.9 *$ |  |
|  |  |  | 2.9 | 10 | 3 | - |  | 3 | 4.5 | - | 29 | - | - |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 36 | 5 | 1.4 | .. | - | 1.5 | 2.25 | - | 1.5 | - | - | $v$ |  |  |
|  |  |  | 7.2 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |  |
| Output Drive Current N-Channel | ${ }_{1}{ }^{N}$ | Carry Output | 0.5 | 5 | 0.155 | - | - | 0.13 | 0.5 | - | 0.105 | - | - | mA | - |  |
|  |  |  | 0.5 | 10 | 0.6 | - | - | 0.5 | 1.5 | - | 0.4 | - | - |  |  |  |
|  |  | $\begin{array}{\|c\|} \hline \text { Sum } \\ \text { Output } \end{array}$ | 3 | 5 | 0.009 | - | - | 0.007 | 0.2 | - | 0.005 | - | - |  |  |  |
|  |  |  | 3 | 10 | 0.24 | - | - | 0.2 | 0.5 | - | 0.16 | - | - |  |  |  |
| P.Channel | ${ }_{1} D^{P}$ | $\begin{array}{\|c\|} \hline \text { Carry } \\ \text { Output } \end{array}$ | 4.5 | 5 | -0.155 | - | - | -0.13 | -0.5 | - | -0.105 | - | - | mA |  |  |
|  |  |  | 9.5 | 10 | -0.6 | - | - | -0.5 | -1.5 | - | -0.4 | - | - |  |  |  |
|  |  | $\begin{array}{\|c\|} \hline \text { Sum } \\ \text { Output } \end{array}$ | 2 | 5 | -0.008 | - | - | -0 007 | -0.2 | - | -0.005 | - | - |  |  |  |
|  |  |  | 7 | 10 | 0.12 | - | - | -0.1 | -0.3 | - | -0.08 | - | - |  |  |  |
| Input Current | $1 /$ |  |  |  | - | - | - | - | 10 | - | - | - | - | OA | - |  |

See Appendix


Fig.5.5-Carry-in to carry-out propagation delay time vs. $C_{L}$.


Fig.5.6-Max. propagation delay time vs. $V_{D D}$ for carry-in to carry-out.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$ and input rise and fall times $=\mathbf{2 0} \mathbf{n s}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  |  | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4008AD,CD4008AK CD4008AF |  |  | CD4008AE |  |  | UNITS |  |
|  |  | \|(Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: At Sum Outputs; From Sum Input | ${ }^{t}$ PHL. <br> tPLH | 5 | - | 900 | 1300 | - | 900 | 2000 | ns | 5.4 |
|  |  | 10 | - | 325 | 500 | - | 325 | 650 |  |  |
| From Carry Input |  | 5 | - | 900 | 1300 | - | 900 | 2000 | ns |  |
|  |  | 10 | - | 325 | 500 | - | 325 | 650 |  |  |
| At Carry Output; From Sum Input |  | 5 | - | 320 | 600 | - | 320 | 800 | ns | 5.3 |
|  |  | 10 | - | 120 | 200 | - | 120 | 240 |  |  |
| From Carry Input |  | 5 | - | 100 | 175 | - | 100 | 200 | ns | 5.5 |
|  |  | 10 | - | 45 | 75 | - | 45 | 90 |  |  |
| Transition Time: At Sum Outputs | ${ }^{\mathrm{t}}$ THL. <br> tTLH | 5 | - | 1250 | 2200 | - | 1250 | 2900 |  |  |
|  |  | 10 | - | 550 | 900 | - | 550 | 1100 |  | - |
| At Carry Output |  | 5 | - | 125 | 225 | - | 125 | 290 | ns | - |
|  |  | 10 | - | 45 | 75 | - | 45 | 90 |  |  |
| Input Capacitance | $C_{1}$ | Any Input | - | 10 | - | - | 10 | - | pF | - |



92CS-17825R1
Fig.5.7-Typ. dissipation characteristics.


Fig.5.8-Quiescent device current test circuit.


Fig.5.9-Noise immunity test circuit.


Fig.5.10-Schematic diagram.


Fig.5.10 - Schematic diagram.

# Digital Integrated Circuits 

Aonolithic Silicon

# COS/MOS Hex Buffers/Converters 

Inverting Type: CD4009AD, CD4009AE, CD4009AK
Non-Inverting Type: CD4010AD, CD4010AE, CD4010AK
Special Features (Each Buffer)

- High current sinking capability. . . . . 8 mA (min.) at $\mathrm{V}_{\mathrm{OL}}=0.5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{DD}}=+10 \mathrm{~V}$
Applications
- COS/MOS to DTL/TTL hex converter - COS/MOS logic-level converter
- COS/MOS current "sink" or "source" driver Multiplexer-1 to 6 or 6 to 1


## CAUTION:

VCC VOLTAGE LEVEL MUST BE EQUAL TO OR LESS THAN VDD. FOR 10.5- TO 15-VOLT SUPPLIES, CLOAD MUST BE EQUAL TO OR LESS THAN 5000 pF .

CD4009A types may be used as a hex COS/MOS inverter, a COS/MOS to DTL or TTL logic-level converter, or a COS/MOS current driver.

The CD4049A and CD4050A are preferred Hex Buffer replacements for the CD4009A and CD4010A, respectively, in all applications except multiplexers.

CD4010A types may be used as a COS/MOS to DTL or TTL hex converter or a COS/MOS current driver.

Conversion ranges are from COS/MOS logic operating at +3 V to +15 V supply levels to DTL or TTL logic operating at +3 V to +6 V supply levels. Conversion to logic output levels greater than +6 V is permitted providing $\mathrm{V}_{\mathrm{CC}}(\mathrm{DTL} / \mathrm{TTL}) \leq$ $V_{D D}(C O S / M O S)$.




$\mathrm{NCO}-13$
$v_{c c} \mathrm{O}^{-1}$
GND - 8
$\mathrm{v}_{\mathrm{DD}} \mathrm{O}^{-16}$



Fig.6.1-Logic diagram for types CD4009A.






Fig.6.2-Logic diagram for types CD4010A.


Fig.6.3-Schematic diagram tor types CD4009A. 1 of 6 identical stages.


Fig.6.5-Min. \& max. voltage transfer characteristics - CD4009A.


Fig.6.7-Min. \& max. voltage transfer characteristics $\left(V_{D D}=5\right)-C D 4010 A$.


Fig.6.4-Schematic diagram for types CD4010A. 1 of 6 identical stages.


Fig.6.6-Typ. voltage transfer characteristics as function of temp. - CD4009A.


Fig.6.8-Min. \& max. voltage transfer charac-
teristics $\left(V_{D}=10\right)-$ CD4010A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathbf{S S}}$ ) 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4009AD, CD4009AK, CD4010AD, CD4010AK |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathbf{O}}$ | VDD | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current: | IL |  | 5 | - | - | 0.3 | - | 0.01 | 0.3 | - | - | 20 | $\mu \mathrm{A}$ | 6.22 |
|  |  |  | 10 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 1.5 | - | 0.05 | 1.5 | - | - | 100 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 5 | - | 0.1 | 5 | - | - | 300 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | 6.5through$6.0^{2}$ 6 |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| (Any Input) | $V_{N L}$ |  | 5 | 1 | - | - | 1 | 2.25 | - | 0.9 | - | - | $v$ | 6.23 |
| CD4010A |  |  | 10 | 2 | - | - | 2 | 4.5 | $=$ | 1.9 | - | - |  |  |
|  |  | 0.95 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - |  |  |
|  |  |  | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
| CD4009A | $\mathrm{V}_{\mathrm{NH}}$ | 0.95 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | $v$ |  |
|  |  |  | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 3.6 | 5 | 1.4 | - | - | 1.5 | 2.25 | $=$ | 1.5 | - | - |  |  |
|  |  | 7.2 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N -Channel | IDN | 0.4 | 5 | 3.75 | - | - | 3 | 4 | - | 2.1 | - | - | mA | $\begin{aligned} & 6.12 \\ & 6.13 \end{aligned} \text {. }$ |
|  |  | 0.5 | 10 | 10 | - | - | 8 | 10 | - | 5.6 | - | - |  |  |
| P-Channel | $I_{D} P$ | 2.5 | 5 | -1.85 | - | - | -1.25 | -1.75 | - | -0.9 | - | - | mA | - |
|  |  | 9.5 | 10 | -0.9 | - | - | -0.6 | -0.8 | - | -0.4. | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

See Appendix.


Fig.6.9-Min. \& max. voltage transfer characteristics $\left(V_{D D}=15\right)-$ CD4010A.


Fig.6.10-Typ. voltage transfer characteristics as a function of temperature CD4010A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs<br>$\mathrm{v}_{\mathrm{Ss}} \leq \mathrm{V}_{\mathrm{I}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$<br>(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4009AE, CD4010AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}}$ | $\mathrm{V}_{\text {DD }}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current: | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 3 | - | 0.03 | 3 | - | - | 42 | $\mu \mathrm{A}$ | 6.22 |
|  |  |  | 10 | - | - | 5 | - | 0.05 | 5 | - | - | 70 |  |  |
| Quiascent Device Dissipation/Package | $P_{D}$ |  | 5 | - | - | 15 | - | 0.15 | 15 | - | - | 210 | $\mu W$ | - |
|  |  |  | 10 |  |  | 50 | - | 0.5 | 50 | - | - | 700 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 |  |  | 0.01 |  | 0 | 0.01 | - | - | 0.05 | V | 6.5through 6.10 |
|  |  |  | 10 | - |  | 0.01 |  | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 |  |  | 4.99 | 5 | - | 4.95 | - | - | v |  |
|  |  |  | 10 | 9.99 | . |  | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) CD4009A | $v_{\text {NL }}$ | 3.6 | 5 | 1 |  |  | 1 | 2.25 | - | 0.9 | - | - | $v$ | 6.23 |
|  |  | 7.2 | 10 | 2 |  |  | 2 | 4.5 | - | 1.9 | - | - |  |  |
| CD4010A |  | 0.95 | 5 | 15 |  |  | 1.5 | 2.25 |  | 1.4 | - | - |  |  |
|  |  | 2.9 | 10 | 3 |  |  | 3 | 4.5 |  | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.95 | 5 | 1.4 |  |  | 3 | 2.25 | - | 1.5 | - | - | $v$ |  |
| CD4010A |  | 2 | 10 | 2.9 |  |  | 3 | 4.5 | . | 1.5 | - | - |  |  |
|  |  | 3.6 | 5 | 1.4 |  |  | 3 | 2.25 | . | 1.5 | - | - |  |  |
|  |  | 7.2 | 10 | 2.9 |  |  | 3 | 4.5 | - | 1.5 | - | - |  |  |
| Output Drive Current: N -Channel | ${ }^{1} \mathrm{ON}$ | 0.4 | 5 | 3.6 | - | - | 3 | 4 | - | 2.4 | - | - | mA | $\begin{aligned} & 6.12 \\ & 6.13 \end{aligned}$ |
|  |  | 0.5 | 10 | 9.6 | - | - | 8 | 10 | - | 6.4 | - | - |  |  |
| P.Channel | ${ }_{10} P$ | 2.5 | 5 | -1.5 | - | - | -1.25 | -175 | - | -1 | - | - | mA | - |
|  |  | 9.5 | 10 | -0.72 | - | - | -0.6 | $-0.8$ | - | -0.48 | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

- See Appendix.


Fig.6.11-Max. propagation delay time vs. VDD - CD4010A.


Fig.6.12-Typ. n-channel drain characteristics - CD4009A, CD4010A.

DYNAMIC ELECTRICAL CHARACTERISTICS at $\mathbf{T}_{\mathbf{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4009AD, CD4009AK CD4010AD, CD4010AK |  |  | CD4009AE CD4010AE |  |  |  |  |
|  |  |  | $\begin{array}{\|l\|} \hline V_{D D} \\ \text { (Volts) } \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: High-to-Low Level | tPHL | $V_{C C}=V_{D D}$ | 5 | - | 15 | 55 | - | 15 | 70 | ns | 6.14 |
|  |  |  | 10 | - | 10 | 30 | - | 10 | 40 |  |  |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V} \end{aligned}$ |  | - | 10 | 25 | - | 10 | 35 |  |  |
| Low-to-High Level | tPLH | $\mathrm{V}_{\text {CC }}=\mathrm{V}_{\text {DD }}$ | 5 | - | 50 | 80 | - | 50 | 100 | ns | 6.15 |
|  |  |  | 10 | - | 25 | 55 | - | 25 | 70 |  |  |
|  |  | $\begin{aligned} & V_{D D}=10 \mathrm{~V} \\ & V_{C C}=5 \mathrm{~V} \end{aligned}$ |  | - | 15 | 30 | - | 15 | 40 |  |  |
| Transition Time: High-to-Low Level | tTHL | $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{DD}}$ | 5 | - | 20 | 45 | - | 20 | 60 | ns | 6.18 |
|  |  |  | 10 | - | 16 | 40 | - | 16 | 50 |  |  |
| Low-to-High Level | ${ }^{\text {t }}$ LH | $V_{C C}=V_{D D}$ | 5 | - | 80 | 125 | - | 80 | 160 | ns | 6.19 |
|  |  |  | 10 | - | 50 | 100. | - | 50 | 120 |  |  |
| Input Capacitance (Any Input) | $\mathrm{Cl}_{1}$ | CD 4009A |  | - | 15 | - | - | 15 | - | pF | - |
|  |  | CD4010A | . | - | 5 | - | - | 5 | - |  |  |



Fig.6.13-Min. n-channel drain characteristics.


Fig.6.14-Typ. high-to-low level propagation delay time vs. $C_{L}-C D 4009 A$, CD4010A.


Fig.6.15-Typ. low-to-high level propagation delay time vs. $C_{L}-$ CD4009A,
CD4010A.


Fig.6.17-Typ. low-to-high level propagation
delay time vs. $C_{L}$ (driving TTL,
DTLI - CD4009A, CD4010A.


Fig.6.19-Typ. low-to-high level transition time vs. $C_{L}-$ CD4009A, CD4010A.


Fig.6.16-Typ. high-to-low level propagation delay time vs. $C_{L}$ (driving TTL,
DTL) - CD4009A, CD4010A.


Fig.6.18-Typ. high-to-low level transition time vs. $C_{L}-$ CD4009A, CD4010A.


Fig.6.20-Max. propagation delay time vs.
$V_{D D}-C D 4009 A$.


Fig.6.21-Typ. dissipation characteristics CD4009A, CD4010A.


92cs-19806
Fig.6.22 - Quiescent dissipation test circuit.


Fig.6.23 - Noise immunity test circuit for CD4009A.


Fig.6.24 - Noise immunity test circuit for CD4010A.

# Digital Integrated Circuits <br> Monolithic Silicon 

CD4011A,CD4012A,CD4023A


CD4011A

## COS/MOS NAND Gates (Positive Logic)

Quad 2 Input •••CD4011AD, CD4011AE, CD4011AF, CD4011AK
Dual 4 Input • . CD CD012AD, CD4012AE, CD4012AF, CD4012AK
Triple 3 Input • • CD4023AD, CD4023AE, CD4023AF, CD4023AK

## Special Features

- Medium speed operation. . . . . tPHL $=$ tPLH $=25$ ns (typ.) at $C_{L}=15 \mathrm{pF}$
- Low "high"- and "low"-level output impedance. . . . . . 400 and $800 \Omega$ (typ.) respectively at $V_{D D}-V_{S S}=10 \mathrm{~V}$

The combination of these devices and the RCA NOR sositive logic gate types CD4000A, CD4001A, CD4002A, ind CD4025A can account for appreciable package-count iavings in various logic function configurations.


Fig.7. 1 - Schematic diagram for type CD4012A.


CD4012A


CD4023A


Fig.7.2 - Schematic diagram for type CD4011A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs

| CHARACTERISTIC | SYPABOL | $\begin{gathered} \text { TEST } \\ \text { CONDITIONS } \end{gathered}$ |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES 8. TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4011AD, CD4011AK, CD4011AF, CD4012AD, CD4012AK, CD4012AF, CD4023AD, CD4023AK, CD4023AF |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\begin{array}{\|l\|} V_{0} \\ \text { Volts } \end{array}$ | VDD <br> Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device |  |  |  | 5 | - | - | 0.05 | - | 0.001 | 0.05 | - | - | 3 | $\mu \mathrm{A}$ | - |
| Current | L |  |  | 10 | - | - | 0.1 | - | 0.001 | 0.1 | - | - | 6 |  |  |
| Quiescent Device Dissipation/Package | PD |  |  | 5 | - | - | 0.25 | - | 0.005 | 0.25 | - | - | 15 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
| Output Voltage: Low Leve! | $\mathrm{V}_{\text {OL }}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | 7.47.5 |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | $\begin{aligned} & 7.6 \\ & 7.7 \end{aligned}$ |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition. <br> See Appendix | $\mathrm{V}_{\mathrm{NL}}$ |  | 3.6 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | - |
|  |  |  | 7.2 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | VNH |  | 0.95 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V | - |
|  |  |  | 2.9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current <br> N.Channel | ${ }^{\prime} D^{N}$ | CD4011A | $\begin{array}{c\|c} A & 0.5 \\ A & \\ \hline & 0.5 \\ 0.5 \\ 0.5 \end{array}$ | 5 | 0.31 | - | - | 0.25 | 0.5 | - | 0.175 | - | - | mA | - |
|  |  | Series |  | 10 | 0.62 | - | - | 0.5 | 0.6 | - | 0.35 | - | - |  |  |
|  |  | CD4012A <br> Series |  | 5 | 0.15 | - | - | 0.12 | 0.25 | - | 0.085 | - | - |  |  |
|  |  |  |  | 10 | 0.31 | - | - | 0.25 | 0.6 | - | 0.175 | - | - |  |  |
| P-Channel | $I_{0} P$ |  | 4.5 | 5 | 0.31 | - | - | -0.25 | $-0.5$ | - | 0.175 | - | - | mA |  |
|  |  |  | 9.5 | 10 | -0.75 | - | - | -0.6 | -1.2 | - | 0.4 | - | - |  |  |
| Input Current | $1 /$ |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

- See Appendix.


Fig.7.3 - Schematic diagram for type CD4023A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\left.\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}\right)$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) 3 to 15 V )

| CHARACTERISTIC | SYMBOL | $\begin{gathered} \text { TEST } \\ \text { CONDITIONS } \\ \hline \end{gathered}$ |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4011AE, CD4012AE, CD4023AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\begin{array}{\|c\|} \hline V_{0} \\ \text { Volts } \\ \hline \end{array}$ |  | VDD <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  |  |  | 5 | - | - | 0.5 | - | 0.005 | 0.5 | - | - | 15 | $\mu \mathrm{A}$ | - |
|  |  |  |  | 10 | - | - | 5 | - | 0.005 | 5 | - | - | 30 |  |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 2.5 | - | 0.025 | 2.5 | - | - | 75 | $\mu \mathrm{W}$ | - |  |
|  |  |  |  | 10 | - | - | 50. | - | 0.05 | 50 | - | - | 300 |  |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | $\begin{aligned} & 7.4 \\ & 7.5 \end{aligned}$ |  |
|  |  |  |  | 10 | - | - | 0.01 | - | - 0 | 0.01 | - | - | 0.05 |  |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | $\begin{aligned} & 7.6 \\ & 7.7 \end{aligned}$ |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition, <br> See Appendix | $\mathrm{V}_{\text {NL }}$ |  | 3.6 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | $v$ | - |  |
|  |  |  | 7.2 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 0.95 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | $v$ | - |  |
|  |  |  | 2.9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |  |
| Output Drive Current <br> N-Channel | ${ }^{1} D^{N}$ | $\begin{aligned} & \text { CD4011A } \\ & \text { CD4023A } \\ & \text { Series } \\ & \hline \end{aligned}$ | 0.5 | 5 | 0.145 | - | - | 0.12 | 0.5 | - | 0.095 | -. | - | mA | - |  |
|  |  |  | 0.5 | 10 | 0.3 | - | - | 0.25 | 0.6 | - | 0.2 | - | - |  |  |  |
|  |  | CD4012A <br> Series | 0.5 | 5 | 0.072 | - | - | 0.06 | 0.25 | - | 0.05 | - | - |  |  |  |
|  |  |  | 0.5 | 10 | 0.155 | - | - | 0.13 | 0.6 | - | 0.105 | - | - |  |  |  |
| P-Channel | IDP |  | 4.5 | 5 | 0.145 | - | - | -0.12 | -0.5 | - | -0.095 | - | - | mA |  |  |
|  |  |  | 9.5 | 10 | -0.35 | - | - | -0.3 | -1.2 | - | -0.24 | - | - |  |  |  |
| Input Current | $1 /$ |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |  |

See Appendix


Fig. 7.4-Min. \& max. voltage transfer characteristics.


Fig.7.5-Typ. voltage transfer characteristics as a function of temperature.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$, and input rise and fall times $=\mathbf{2 0} \mathrm{ns}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \%{ }^{\circ} \mathrm{C} \quad$ (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  |  | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4011AD, AF, AK CD4012AD, AF, AK CD4023AD, AF, AK |  |  | CD4011AE CD4012AE CD4023AE |  |  | UNITS |  |
|  |  | $\begin{aligned} & \begin{array}{l} \mathrm{V}_{\text {DD }} \\ \text { (Volts) } \end{array} \end{aligned}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: Low-to-High Level | tPLH | 5 | - | 50 | 75 | - | 50 | 100 | ns | 7.13 |
|  |  | 10 | - | 25 | 40 | - | 25 | 50 |  | $7.19$ |
| High-to-Low Level CD4011A and CD4023A Series | tPHL | 5 | - | 50 | 75 | - | 50 | 100 |  | 7.14 |
|  |  | 10 | - | 25 | 40 | - | 25 | 50 | ns | 7.19 |
| CD4012A Series |  | 5 | - | 100 | 150 | - | 100 | 200 | ns | 7.15 |
|  |  | 10 | - | 50 | 75. | - | 50 | 100 |  | 7.19 |
| Transition Time: Low-to-High Level | ${ }^{\text {t }}$ L H | 5 | - | 75 | 100 | - | 75 | 125 | ns | 7.16 |
|  |  | 10 | - | 40 | 60 | - | 40 | 75 |  |  |
| High-to-Low Level CD4011A and CD4023A Series | tTHL | 5 | - | 75 | 125 | - | 75 | 150 | ns | 7.17 |
|  |  | 10 | - | 50 | 75. | - | 50 | 100 |  |  |
| CD4012A Series |  | 5 | - | 250 | 375 | - | 250 | 500 | ns | 7.18 |
|  |  | 10 | - | 125 | 200 | - | 125 | 250 |  |  |
| Input Capacitance | $C_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF | - |



Fig.7.6 - Typ. multiple input switching


Fig.7.7 - Typ. current \& voltage transfer characteristics.


Fig.7.8-Typ. n-channel drain characteristics.

Fig.7.10-Min. n-channel drain characteristics

- CD4011A \& CD4023A.


92Cs-17849


Fig.7.13-Typ. low-to-high level propagation delay time vs. $C_{L}$.


Fig.7.14-Typ high-to-low level propagation
delay time vs. $C_{L}-$ CD4011A,
\& CD4023A.


Fig.7.16-Typ. low-to-high transition time vs. $C_{L}$.


Fig.7.18-Typ. high-to-low level transition time vs. $C_{L}-C D 4012 A$.


Fig.7.15-Typ. high-to-fow level propagation delay time vs. $C_{L}-C D 4012 A$.


Fig.7.17-Typ. high-to-low level transition time vs. $C_{L}-$ CD4011A \& CD4023A.


Fig.7.19-Typ. propagation delay time vs. $V_{D D}$


Fig.7.20-Typ. dissipation characteristics.


Fig.7.21-Quiescent device current test circuit for CA4011A.


Fig.7.22-Noise-immunity test circuit for CD4011A.


Fig.7.25-Quiescent device current test circuit for CD4023A.


Fig.7.26-Noise-immunity test circuit for CD4023A.

## Digital Integrated Circuits

Monolithic Silicon
CD4013AD, CD4013AF CD4013AE, CD4013AK


## Dual 'D'-Type Flip-Flop

## With Set-Reset Capability

## Special Features

- Static flip-flop operation. . . . . . retains state indefinitely with clock level either "high" or "low"
- Medium speed operation. 10 MHz (typ.) clock toggle rate at

$$
V_{D D}-V_{S S}=10 V
$$

■ Low "high"- and "low" output impedance. . . . . . 400 4 and 200S2, respectively at $V_{D D}-V_{S S}=10 \mathrm{~V}$

## Applications

- Registers, counters, control circuits

CD4013A types consist of two identical, independent data-type flip-flops. Each flip-flop has independent data, set, reset, and clock inputs and " Q " and " $\overline{\mathrm{Q}}$ " outputs. These devices can be used for shift register applications, and, by connecting " $\overline{\mathrm{Q}}$ " output to the data input, for counter and
toggle applications. The logic level present at the " $D$ " input is transferred to the $\mathbf{Q}$ output during the positive-going transition of the clock pulse. Setting or resetting is independent of the clock and is accomplished by a high level on the set or reset line, respectively.


| CLA | D | R | 5 | Q | $\overline{\mathbf{Q}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\Gamma$ | 0 | 0 | 0 | 0 | 1 |
|  | 1 | 0 | 0 | 1 | 0 |
| , | X | 0 | 0 | Q | $\bar{Q}$ |
| $\times$ | $\times$ | 1 | 0 | 0 | 1 |
| X | $\times$ | 0 | 1 | 1 | 0 |
| X | $\times$ | 1 | 1 | 1 | 1 |

$$
\begin{aligned}
\star & =\text { LEVEL CHANGE } \\
\text { X } & =\text { DON'T CARE CASE } \\
* * & =\text { FFI/FF2 TERMINAL ASSIGNMENTS }
\end{aligned}
$$

Fig.8.1-Logic diagram and truth table (one of two identical flip-flops).


Fig.8.2-Schematic diagram (1 of two identical flip-
flops).


Fig.8.3-Typ. n-channel drain characteristics.
Fig.8.4-Typ. p-channel drain characteristics.
(Recommended DC Supply Voltage (VDD $\mathbf{V}_{\text {SS }}$ ) . . . . . . . . 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS <br> Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4013AD, CD4013AK, CD4013AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $V_{\text {DD }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 1 | - | 0.005 | 1 | - | - | 60 | $\mu \mathrm{A}$ | 8.9 |
|  |  |  | 10 | - | - | 2 | - | 0.005 | 2 | - | - | 120 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {P }}$ |  | 5 | - | - | 5 | - | 0.025 | 5 | - | - | 300 | $\mu \mathrm{W}$ | $\begin{aligned} & 8.7 \\ & 8.9 \end{aligned}$ |
|  |  |  | 10 | - | - | 20 | - | 0.05 | 20 | - | - | 1200 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition, See Appendix | VNL | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 8.10 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | VNH | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V | 8.10 |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N-Channel | IDN | 0.5 | 5 | 0.65 | - | - | 0.5 | 1 | - | 0.35 | - | - | mA | - |
|  |  | 0.5 | 10 | 1.25 | - | - | 1 | 2.5 | - | 0.75 | - | - |  |  |
| P.Channel | $I^{\prime} P$ | 4.5 | 5 | -0.31 | - | - | -0.25 | -0.5 | - | -0.175 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.8 | - | - | -0.65 | -1.3 | - | -0.45 | - | - |  |  |
| Input Current | $1 /$ |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

See Appendix


Fig.8.5-Min. n-channel drain characteristics.


92CS-17856

Fig.8.6-Min. p-channel drain characteristics.

STATIC ELECTRICAL CHARACTERISTICS (All inputs . . . . . . . . . . . . . . . . . . . . . . . . . . $\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage (VDD $-\mathrm{V}_{S S}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. teristic curves \& TEST circuits Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4013AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{\text {L }}$ |  | 5 | - | - | 10 | - | 0.01 | 10 | - | - | 140 | $\mu \mathrm{A}$ | 8.9 |
|  |  |  | 10 | - | - | 20 | - | 0.02 | 20 | - | - | 280 |  |  |
| Quiascent Device Dissipation/Package | PD |  | 5 | - | - | 50 | - | 0.05 | 50 | - | - | 700 | $\mu \mathrm{W}$ | 8.7 |
|  |  |  | 10 | - | - | 200 | - | 0.2 | 200 | - | - | 2800 |  | 8.9 |
| Output Voltage: Low.Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $v$ | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$. | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 8.10 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V | 8.10 |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | -- |  |  |
| Output Drive Current: N -Channel | 10 N | 0.5 | 5 | 0.35 | - | - | 0.3 | 1 | - | 0.24 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.72 | - | - | 0.6 | 2.5 | - | 0.5 | - | - |  |  |
| P.Channel | $I^{\prime} P$ | 4.5 | 5 | -0.17 | - | - | -0.14 | -0.5 | - | -0.12 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.4 | - | - | -0.33 | -1.3 | - | -0.27 | - | - |  |  |
| Input Current | 1 |  |  | - | - | - | - | 10 | - |  | - | - | pA | - |

See Appendix


Fig.8.7-Typ. dissipation characteristics.


Fig.8.8-Typ. clock frequency vs. VDD.

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$ except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathbf{f}} \mathrm{CL}$ (See Appendix for Waveforms)

Typical Temperature Coefficient for all values of $\mathbf{V}_{\mathbf{D D}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4013AD, CD4013AK |  |  | CD4013AE |  |  |  |  |
|  |  | $\begin{array}{\|l\|} \hline V_{\text {DD }} \\ \text { (Volts) } \\ \hline \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| CLOCKED OPERATION |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: | tPHL $=$ | 5 | - | 150 | 300 | - | 150 | 350 | ns | - |
|  | tPLH | 10 | - | 75 | 110 | - | 75 | 125 |  |  |
| Transition Time | $\begin{aligned} & \text { tTHL }= \\ & \text { tTLH } \end{aligned}$ | 5 | - | 75 | 125 | - | 75 | 150 | ns | - |
|  |  | 10 | - | 50 | 70 | - | 50 | 75 |  |  |
| Minimum Clock Pulse Width | $\begin{aligned} & \mathrm{t} W \mathrm{~L}= \\ & \mathrm{tWH} \end{aligned}$ | 5 | - | 125 | 200 | - | 125 | 500 | ns | - |
|  |  | 10 | - | 50 | 80 | -- | 50 | 100 |  |  |
| Clock Rise \& Fall Time | $\begin{aligned} & { }^{{ }^{\mathrm{trCLL}_{\mathrm{CL}}}=} \\ & \mathrm{t}_{\mathrm{fCL}} \end{aligned}$ | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  | 10 | - | - | 5 | - | - | 5 |  |  |
| Set-Up Time |  | 5 | - | 20 | 40 | - | 20 | 50 | ns | - |
|  |  | 10 | - | 10 | 20 | - | 10 | 25 |  |  |
| Maximum Clock Frequency | ${ }^{\mathrm{f}} \mathrm{CL}$ | 5 | 2.5 | 4 | - | 1 | 4 | - | MHz | 8.8 |
|  |  | 10 | 7 | 10 | - | 5 | 10 | - |  |  |
| Input Capacitance | $\mathrm{Cl}_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF |  |
| SET \& RESET OPERATION |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: | $\begin{aligned} & \operatorname{tPHL}(R)= \\ & \operatorname{tpLH}(R) \end{aligned}$ | 5 |  | 175 | 300 |  | 175 | 350 | ns | - |
|  |  | 10 |  | 75 | 110 |  | 75 | 125 |  |  |
| Minimum Set and Reset Pulse Widths | $\begin{aligned} & \mathrm{t} W H(\mathrm{~S}), \\ & \mathrm{t}^{W} \mathrm{FH}(\mathrm{R}) \end{aligned}$ | 5 |  | 125 | 250 |  | 125 | 500 | ns | - |
|  |  | 10 |  | 50 | 100 |  | 50 | 125 |  |  |

* If more than one unit is cascaded in a parallel clocked operation, $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ should be made less than or equal to the sum of the fixed propagation delay time at 15 pF and the transition time of the output driving stage for the estimated capacitive load.


Fig. 8.9-Quiescent device current test circuit.


Fig.8.10-Noise immunity test circuit.


Fig8.11-Typ. propagation delay time vs. $C_{L}$.


Fig.8.12-Typ. transition time vs. $C_{L}$.


# COS/MOS 8-Stage <br> Static Shift Register 

SYNCHRONOUS PARALLEL OR SERIAL INPUT/SERIAL OUTPUT
Special Features

- Medium speed operation. . . . . . 5 MHz (typ.) clock rate at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
- Fully static operation
- MSI complexity on a single chip. .

8 master-slave flip-flops plus output buffering and control gating

## Applications

- Synchronous parallel input/serial output data queueing
- Parallel to serial data conversion - General purpose register

CD4014A types are 8-stage parallel-input/serial output registers having common Clock and Parallel/Serial Control inputs, a single Serial Data input, and individual parallel "Jam" inputs to each register stage. Each register stage is a D-type, master-slave flip-flop. In addition to an output from stage 8, " $Q$ " outputs are also available from stages 6 and 7 .
Parallel as well as serial entry is made into the register synchronous with the positive clock line transition and under control of the Parallel/Serial Control input. When the

Parallel/Serial Control input is "low", data is serially shifted into the 8 -stage register synchronously with the positive transition of the clock line. When the Parallel/Serial Control input is "high", data is jammed into the 8 -stage register via the parallel input lines and synchronous with the positive transition of the clock line. Register expansion using multiple CD4014A packages is permitted.


Fig.9.1-Logic block diagram.

TRUTH TABLE

| CL ${ }^{\text {4 }}$ | $\left\lvert\, \begin{aligned} & \operatorname{SER} \\ & \text { IN } \end{aligned}\right.$ | PAR SER CONTROL | P1.1 | PI-n | $\begin{aligned} & \hline Q_{1} \\ & \text { (INTER- } \\ & \text { NAL) } \end{aligned}$ | $\mathrm{Q}_{\mathrm{n}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\cdots$ | 1 | 0 | 0 | 0 | 0 |
|  | x | 1 | 1 | 0 | 1 | 0 |
| $\square$ | $x$ | 1 | 0 | 1 | 0 | 1 |
| 7 | x | 1 | 1 | 1 | 1 | 1 |
| $5$ | 0 | 0 | $x$ | $x$ | 0 | $e_{n}-1$ |
| $\square$ | 1 | 0 | X | X | 1 | $Q_{n}-1$ |
|  | x | x | x | x | Q1 | $Q_{n}$ |


9.2-Schematic diagram - CD4014A.

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES $\&$ TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4014AD, CD4014AK, CD4014AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ |  | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\text {L }}$ |  | 5 | - | - | 5 | - | 0.5 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 9.7 |
|  |  |  | 10 | - | - | 10 | - | 1 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 25 | - | 2.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 100 | - | 10 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 9.8 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: <br> N-Channel | $I_{\text {I }} \mathrm{N}$ | 0.5 | 5 | 0.15 | - | - | 0.12 | 0.3 | - | 0.085 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.31 | - | - | 0.25 | 0.5 | - | 0.175 | - | - |  |  |
| P-Channel | $I^{\prime} P$ | 4.5 | 5 | -0.1 | - | - | -0.08 | -0.16 | - | -0.055 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.25 | - | - | -0.20 | -0.44 | - | -0.14 | - | - |  |  |
| Input Current | $I_{1}$ |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

- See Appendix

9.3 - Typ. dissipation characteristics.

9.4 - Max. input clock frequency vs. $V_{D D}$.
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4014AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DO}}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 9.7 |
|  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition. <br> See Appendix | $V_{N L}$ | 0.8 | 5 | 1.5 |  | - | 1.5 | 2.25 | - | 1.4 | $\checkmark$ | $\cdots$ | V | 9.8 |
|  |  | 1.0 | 10 | 3 |  |  | 3 | 4.5 | $\cdots$ | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N.Channel | ${ }_{1} \mathrm{DN}$ | 0.5 | 5 | 0.072 | - | - | 0.06 | 0.3 | - | 0.05 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.12 | - | - | 0.1 | 0.5 | - | 0.08 | - | - |  |  |
| P.Channel | ${ }_{10}{ }^{\text {P }}$ | 4.5 | 5 | -0.06 | - | - | -0.05 | -0.16 | - | -0.04 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.12 | - | - | -0.1 | -0.44 | - | -0.08 | - | - |  |  |
| Input Current | $1 /$ |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

See Appendix

9.5 - Typ. propagation delay time vs. $C_{L}$.

9.6 - Typ. transition time vs. $C_{L}$.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$ except $\mathrm{t}_{\mathbf{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3} \% /{ }^{\circ} \mathbf{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4014AD CD4014AK CD4014AF |  |  | CD4014AE |  |  |  |  |
|  |  | $\begin{array}{\|l\|} \hline V_{D D} \\ \text { (Volts) } \\ \hline \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: | tPHL $=$ | 5 | - | 300 | 750 | - | 300 | 1000 | ns | 9.5 |
|  | tPLH | 10 | - | 100. | 225 | - | 100 | 300 |  |  |
| Transition Time | tTHL= | 5 | - | 150 | 300 | - | 150 | 400 | ns | 9.6 |
|  | t $T$ LH | 10 | - | 75 | 125 | - | 75 | 150 |  |  |
| Minimum Clock Pulse Width | tWL $=$ | 5 | - | 200 | 500 | - | 200 | 830 | ns | - |
|  | tWH | 10 | - | 100 | 175 | - | 100 | 200 |  |  |
| Clock Rise \& Fall Time | $\begin{aligned} & \mathrm{trCL}^{*}= \\ & \mathrm{tfCL}^{2} \end{aligned}$ | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  | 10 | - | - | 15 | - | - | 15 |  |  |
| Set-Up Time |  | 5 | - | 100 | 350 | - | 100 | 500 | ns | - |
|  |  | 10 | - | 50 | 80 | - | 50 | 100 |  |  |
| Maximum Clock Frequency | ${ }^{\mathrm{f}} \mathrm{CL}$ | 5 | 1 | 2.5 | - | 0.6 | 2.5 | - | MHz | - |
|  |  | 10 | 3. | 5 | - | 2.5 | 5 | - |  |  |
| Input Capacitance | $\mathrm{C}_{1}$ | ANY INPUT | - | 5 | - | - | 5 | - | pF | - |

- If more than one unit is cascaded in a paraliel clocked operation, $t_{r} C L$ should be made less than or equal to the sum of the fixed propagation delay time at 15 pF and the transition time of the output driving stage for the estimated capacitive load.


Test performed with the following sequence of " 1 ' $s$ " and " 0 's"

|  | $S_{1}$ | $S_{2}$ | $S_{3}$ | $S_{4}$ | $S_{5}$ |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Don't | 0 | 1 | 1 | 0 | 0 |
| Test | 0 |  | 1 | 0 |  |
| Test | 0 | 1 | 1 | 1 | 0 |
| Test | 1 | 0 | 0 | 0 | 0 |
| Test | 1 | 0 | 1 | 1 | 1 |
| Test | 1 | 0 | 0 | 0 | 1 |



92cs-17908
9.8-Noise immunity test circuit.


# COS/MOS Dual 4-Stage Static Shift Register 

With Serial Input/Parallel Output
Special Features

- Medium speed operation. . . . . 5 MHz (typ.) clock rate at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
- Fully static operation
- MSI complexity on a single chip.

8 master-slave flip-flops plus output buffering

Applications<br>- Serial-input/parallel-output data queueing

- Serial to parallel data conversion
- General purpose register

RCA CD4015A types consist of two identical, independent, 4 -stage serial-input/parallel-output registers. Each register has independent "Clock" and "Reset" inputs as well as a single serial "Data" input. " $Q$ " outputs are available from each of the four stages on both registers. All register stages are D-type, master- slave flip-fleps. The logic level present at the
data input is transferred into the first register stage and shifted over one stage at each positive-going clock transition. Resetting of all stages is accomplished by a high level on the reset line. Register expansion to 8 stages using one CD4015A package, or to more than 8 stages using additional CD4015A $s$ is possible.


Fig.10.1-Logic diagram and truth table.

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4015AD, CD4015AK, CD4015AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | VDD | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.5 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 10.6 |
|  |  |  | 10 | - | - | 10 | - | 1 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 25 | - | 2.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 100 | - | 10 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $v$ | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition, <br> See Appendix | $V_{\text {NL }}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 10.7 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: | ${ }^{1} \mathrm{DN}$ | 0.5 | 5 | 0.15 | - | - | 0.12 | 0.3 | - | 0.085 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.31 | - | - | 0.25 | 0.5 | - | 0.175 | - | - |  |  |
| P.Channel | ${ }_{1}{ }^{P}$ | 4.5 | 5 | -0.1 | - | - | -0.08 | -0.16 | - | -0.055 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.25 | - | - | -0.20 | -0.44 | - | -0.14 | - | - |  |  |
| Input Current | 1 |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

- See Appendix.


Fig. 10.2-Typ. clock frequency vs. $V_{D D}$ -


Fig. 10.3-Typ. propagation delay time vs. $C_{L}$.

(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | test CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC curves \& TEST circuits Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4015AE |  |  |  |  |  |  |  |  |  |  |
|  |  | Vo | $\mathrm{V}_{\mathrm{DD}}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Vots | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 10.6 |
|  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 10.7 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | $\checkmark$ |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: | 10 N | 0.5 | 5 | 0.072 | - | - | 0.06 | 0.3 | - | 0.05 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.12 | - | - | 0.1 | 0.5 | - | 0.08 | - | - |  |  |
| P.Channel | ${ }_{1}{ }^{\text {P }}$ | 4.5 | 5 | -0.06 | - | - | -0.05 | -0.16 | - | -0.04 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.12 | - | - | -0.1 | -0.44 | - | -0.08 | - | - |  |  |
| Input Current | 1 |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

- See Appendix.


Fig. 10.4-Typ. transition time vs. $C_{L}$.


Fig. 10.5-Typ. dissipation characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$
Typical Temperature Coefficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4015AD CD4015AK CD4015AF |  |  | CD4015AE |  |  |  |  |
|  |  | $\begin{array}{\|l\|} \hline \text { VDD } \\ \text { (Volts) } \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |

## CLOCKED OPERATION



- If more than one unit is cascaded in a parallel clocked operation,
$t_{r} C L$ should be made less than or equal to the sum of the fixed propagation delay time at 15 pF and the transition time of the output driving stage for the estimated capacitive load.


Test performed with the following sequence of " 1 ' $s$ " and " 0 ' $s$ " $\mathrm{S}_{1} \mathrm{~S}_{2} \quad \mathrm{~S}_{3}$
$\begin{array}{llll}\text { Test } & 0 & 1 & 0\end{array}$
Don't Test 0001
Don't Test 1001
Don't Test 000
Don't Test 1000
Don't Test 0001
$\begin{array}{llll}\text { Test } & 1 & 0 & 1\end{array}$
Don't Test 0000
Test 1000

Fig. 10.6 - Quiescent device current test circuit.


Fig. 10.7 - Noise immunity test circuit.


Fig. 10.8 - Schematic diagram.

# Digital Integrated Circuits <br> Monolithic Silicon <br> CD4016AD, CD4016AF CD4016AE, CD4016AK 



## Applications

- Analog signal switching/multiplexing Signal gating Squelch control Chopper
- Digital signal switching/Multiplexing
- COS/MOS logic implementation
- Analog-to-digital \& digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain


## Special Features

## COS/MOS Quad Bilateral Switch

## For Transmission or Multiplexing of Analog or Digital Signals

- Wide range of digital and analog signal levels Digital or analog signal to 15 V peak Analog signal $\pm 7.5 \mathrm{~V}$ peak
- Low "ON" resistance$300 \Omega$ typ. over $15 \mathrm{~V}_{\text {p-p }}$ signal input range, for $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=15 \mathrm{~V}$
- Matched switch characteristics $40 \Omega$ typ. difference between RON values at a fixed bias point over $15 \mathrm{~V}_{\mathrm{p} \text {-p }}$ signal input range $V_{D D}-V_{S S}=15 \mathrm{~V}$
- High "On/Off" output voltage ratio -65 dB typ. @ $f_{\text {is }}=10 \mathrm{kHz}, R_{\mathrm{L}}=10 \mathrm{k} \Omega$
- High degree of linearity $-<\mathbf{0 . 5 \%}$ distortion typ. @ $\mathrm{f}_{\mathrm{is}}=\mathbf{1 k H z}$,
$\mathrm{V}_{\text {is }}=5 \mathrm{~V}_{\mathrm{p}-\mathrm{p}}, \mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}} \geq 10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$.
- Extremely low "OFF" switch leakage resulting in very low offset current and high effective "OFF" resistance 10 pA typ. @ $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$
- Extremely high control input impedance (control circuit isolated from signal circuit) - $10^{12} \Omega$ typ.
- Low crosstalk between switches --50 dB typ. @ $\mathrm{f}_{\mathrm{is}}=0.9 \mathrm{MHz}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$
- Matched control-input to signal-output capacitances Reduces output signal transients
- Transmits frequencies up to $10 \mathbf{M H z}$


NOTE: All switch P-channel sebstrates are internally connected to terminal No. 14.

$$
\text { All switch N-channel substrates are internally connected to terminal No. } 7 .
$$

NORMAL OPERATION:
Control-Line Biasing
Switch "ON": $V_{C} " 1 "=V_{D D}$
Switch "OFF": $V_{C} " 0^{\prime \prime}=V_{S S}$

SIGNAL-LEVEL RANGE:
$V_{S S} \leq V_{\text {is }} \leqslant V_{D D}$

Fig.11.1-Schematic diagram.


Fig.11.2-Typ. "ON" characteristics for 1 of 4 switches with $V_{D D}=+15 \mathrm{~V}$, $V_{S S}=O V$.


Fig.11.4-Typ. "ON" characteristics for 1 of 4 switches with $V_{D D}=+5 \mathrm{~V}$, $V_{S S}=O V$.


Fig.11.6-Typ. "ON" characteristics for 1 of 4 switches with $V_{D D}=+5 V$. $V_{S S}=-5 V$.


Fig.11.3-Typ. "ON" characteristics for 1 of 4 switches with $V_{D D}=+10 \mathrm{~V}$, $V_{S S}=O V$.


Fig.11.5-Typ. "ON" characteristics for 1 of 4 switches with $V_{D D}=+7.5 \mathrm{~V}$,
$V_{S S}=-7.5 V$.


Fig.11.7-Typ. "ON" characteristics for 1 of 4 switches with $V_{D D^{*}}=+2.5 \mathrm{~V}$,
$V_{S S}=-2.5 \mathrm{~V}$.

ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $V_{D D}-V_{S S}$ ) 3 to 15 V)

\begin{tabular}{|c|c|c|c|c|c|c|c|c|c|c|c|c|}
\hline \multirow{4}{*}{CHARACTERISTIC} \& \multirow{4}{*}{SYMBOL} \& \multicolumn{4}{|c|}{\multirow{4}{*}{TEST CONDITIONS}} \& \multicolumn{6}{|c|}{LIMITS} \& \multirow{4}{*}{Units} \\
\hline \& \& \& \& \& \& \multicolumn{2}{|l|}{\multirow[t]{2}{*}{\[
\begin{array}{|c|}
\hline \text { CD4016AD } \\
\hline-55^{\circ} \mathrm{C} \\
\hline
\end{array}
\]}} \& \multicolumn{2}{|l|}{\multirow[t]{2}{*}{CD4016AK,}} \& \multicolumn{2}{|l|}{\multirow[t]{2}{*}{CDA016AF}} \& \\
\hline \& \& \& \& \& \& \& \& \& \& \& \& \\
\hline \& \& \& \& \& \& Typ. \& Max. \& Typ. \& Max. \& Typ. \& Max. \& \\
\hline \begin{tabular}{l}
Quiescent Dissipation per Package \\
All Switches "OFF"
\end{tabular} \& \multirow[t]{2}{*}{\(\mathrm{P}_{\mathrm{T}}\)} \& \begin{tabular}{ll} 
\& \(\frac{T}{1}\) \\
\(v_{\text {DD }}\) \& 1 \\
\(v_{\text {SS }}\) \& 7 \\
\(v_{C}\) \& 5 \\
\(v_{\text {is }}\) \& 1 \\
\(v_{\text {OS }}\) \& 2
\end{tabular} \& \[
\begin{aligned}
\& \text { TERMINAL } \\
\& \hline 14 \\
\& 7 \\
\& 5,6,12,13 \\
\& 1,4,8,11 \\
\& 2,3,9,10 \\
\& \hline
\end{aligned}
\] \&  \& TS \& - \& 5 \& 0.1 \& 5 \& - \& 300 \& \(\mu \mathrm{W}\) \\
\hline All Switches "ON" \& \&  \& \[
\begin{aligned}
\& \text { TERMINAL } \\
\& \hline 14 \\
\& 7 \\
\& 5.6 .12 .13 \\
\& 1.4 .8 .11 \\
\& \hline
\end{aligned}
\] \&  \& TS
IED

10 \& - \& 5 \& 0.1 \& 5 \& - \& 300 \& $\mu \mathrm{W}$ <br>
\hline \multicolumn{13}{|l|}{SIGNAL INPUTS $\mathrm{V}_{\text {is }}$ ) AND OUTPUTS ( $\mathrm{V}_{\text {os }}$ )} <br>
\hline \multirow{13}{*}{'"ON" Resistance} \& \multirow{13}{*}{${ }^{\mathrm{R}} \mathrm{ON}$} \& \multirow{15}{*}{$R_{L}=10 \mathrm{k}!2$} \& $\mathrm{v}_{\mathrm{C}}-\mathrm{v}_{\text {DD }}$ \& $\mathrm{v}_{\text {SS }}$ \& $v_{\text {is }}$ \& \multirow[b]{2}{*}{120} \& \multirow[b]{2}{*}{360} \& \multirow[b]{2}{*}{200} \& \multirow[b]{2}{*}{400} \& \multirow[b]{2}{*}{300} \& \multirow[b]{2}{*}{600} \& \multirow{4}{*}{$\Omega$} <br>
\hline \& \& \& \multirow{3}{*}{+7.5V} \& \multirow{3}{*}{-7.5V} \& +7.5V \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& -7.5V \& 120 \& 360 \& 200 \& 400 \& 300 \& 600 \& <br>
\hline \& \& \& \& \& -0.25V \& 130 \& 775 \& 280 \& 850 \& 470 \& 1230 \& <br>
\hline \& \& \& \multirow{3}{*}{+5V} \& \multirow{3}{*}{-5V} \& +5V \& 130 \& 600 \& 250 \& 660 \& 400 \& 960 \& \multirow{3}{*}{$\Omega$} <br>
\hline \& \& \& \& \& -5V \& 130 \& 600 \& 250 \& 660 \& 400 \& 960 \& <br>
\hline \& \& \& \& \& =0.25V \& 325 \& 1870 \& 580 \& 2000 \& 900 \& 2600 \& <br>
\hline \& \& \& \multirow{3}{*}{$+15 \mathrm{~V}$} \& \multirow{3}{*}{OV} \& +15V \& 120 \& 360 \& 200 \& 400 \& 300 \& 600 \& \multirow{3}{*}{$\Omega$} <br>
\hline \& \& \& \& \& +0.25V \& 120 \& 360 \& 200 \& 400 \& 300 \& 600 \& <br>
\hline \& \& \& \& \& 9.3 V \& 150 \& 775 \& 300 \& 850 \& 490 \& 1230 \& <br>
\hline \& \& \& \multirow{3}{*}{+10v} \& \multirow{3}{*}{OV} \& +10V \& 130 \& 600 \& 250 \& 660 \& 400 \& 960 \& \multirow{3}{*}{$\Omega$} <br>
\hline \& \& \& \& \& +025V \& 130 \& 600 \& 250 \& 660 \& 400 \& 960 \& <br>
\hline \& \& \& \& \& 56 V \& 300 \& 1870 \& 560 \& 2000 \& 880 \& 2600 \& <br>
\hline $\triangle$ "ON" Resistance \& \multirow[b]{2}{*}{$\triangle R_{\text {ON }}$} \& \& +7.5V \& $-7.5 \mathrm{~V}$ \& $\pm 75 \mathrm{~V}$ \& - \& - \& 10 \& - \& - \& - \& \multirow[b]{2}{*}{$\Omega$} <br>
\hline Between Any 2 of 4 Switches \& \& \& +5. V \& -5v \& $\pm 5 \mathrm{~V}$ \& - \& - \& 15 \& - \& - \& - \& <br>
\hline Sine-Wave Response (Distortion) \& \& ( $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \text { I2 } \\ & \mathrm{i}_{15}=1 \mathrm{kH2}\end{aligned}$ \& \& -5v \& 5V(pp) ${ }^{\text {a }}$ \& - \& - \& 0.4 \& - \& - \& - \& \% <br>

\hline Input or Output Leakage-Switch "OFF" \& \& $\frac{\mathrm{V}_{\mathrm{DD}}}{+75 \mathrm{~S}}$ \& $$
\frac{V_{C}=v}{5 V} \quad \frac{v_{C}}{-75 V}
$$ \& vSS \& \& - \& - \& $\pm 100$ \& - \& - \& - \& pA <br>

\hline (Effective "OFF" Resistance) \& \& +5V \& V -5V \& \& 5 V \& - \& - \& . \& $$
\begin{array}{|r|}
* \\
\hline 125 \\
\hline
\end{array}
$$ \& - \& - \& nA <br>

\hline Frequency-ResponseSwitch "ON" (Sine Wave Input) \& \& \multirow[b]{2}{*}{$$
\left\{\begin{array}{l}
R_{L}=1 \mathrm{k}!! \\
V_{15} 5 \mathrm{~V}(\rho \mathrm{p})
\end{array}\right.
$$} \& \multicolumn{3}{|l|}{\[

$$
\begin{aligned}
& V_{C}=V_{D O}=-5 \mathrm{~V}, V_{S S}=-5 \mathrm{~V} \\
& 20 \log _{10} \frac{v_{\mathrm{OS}}}{v_{15}}=-3.1 \mathrm{~B}
\end{aligned}
$$
\]} \& - \& - \& 40 \& - \& - \& - \& MH2 <br>

\hline Feedthrough Switch "OFF" \& \& \& \multicolumn{3}{|l|}{(1) $\begin{aligned} & V_{\mathrm{DD}}=75 \mathrm{~V}_{\mathrm{C}}=V_{\mathrm{SS}}=-5 \mathrm{~V} \\ & 20 \log { }_{10} \frac{v_{05}}{v_{\text {IS }}}=-50.18\end{aligned}$} \& - \& - \& 1.25 \& - \& - \& - \& M $\mathrm{Hz}_{2}$ <br>

\hline Crosstalk Between Any 2 of the 4 Switches (Frequency at $\mathbf{- 5 0 ~ d B}$ ) \& \& \[
\left\{$$
\begin{array}{l}
R_{L}=1 k!! \\
V_{\text {is }}(A)= \\
5 V(p \rho)
\end{array}
$$\right.

\] \& \[

$$
\begin{aligned}
& V_{C^{\prime}(A)} \\
& 20 \log
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& \mathrm{v}_{\mathrm{DD}}=\cdot \\
& v_{\mathrm{C}^{(B)}}= \\
& 10 \frac{v_{\text {of }}(\mathrm{B}}{v_{\text {( }}(\mathrm{A})}
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& v_{S S}=-5 v \\
& =-50 \times 1 B
\end{aligned}
$$
\] \& - \& - \& 0.9 \& - \& - \& - \& MHz <br>

\hline \multirow[t]{3}{*}{$$
\text { Capacitance } \frac{\text { Input }}{\frac{\text { Output }}{\text { Feedthrough }}}
$$} \& $\mathrm{C}_{15}$ \& \multicolumn{4}{|l|}{\multirow[t]{3}{*}{$\mathrm{V}_{\mathrm{DO}}=+5 \mathrm{~V} \cdot \mathrm{~V}_{\mathrm{C}}=\mathrm{V}_{\mathrm{SS}}=-5 \mathrm{~V}$}} \& \multirow[t]{3}{*}{} \& \multirow[t]{3}{*}{} \& \multirow[b]{3}{*}{0.2} \& \multirow[t]{3}{*}{} \& \multirow[t]{3}{*}{-} \& \multirow[t]{3}{*}{} \& \multirow{3}{*}{pF} <br>

\hline \& $\mathrm{C}_{\mathrm{OS}}$ \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& $\mathrm{C}_{\text {IOS }}$ \& \& \& \& \& \& \& \& \& \& \& <br>

\hline Propagation Delay Signal Input to Signal Output \& ${ }^{\text {P }} \mathrm{pd}$ \& \multicolumn{4}{|l|}{$$
\begin{aligned}
& V_{C}=V_{D D}=+10 \mathrm{~V}, V_{S S}=G N D . C_{L}=15 \mathrm{pF} . \\
& V_{\text {is }}=10 \mathrm{~V} \text { (şquare wave) } . \\
& t_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns} \text { (input signal) }
\end{aligned}
$$} \& - \& - \& 10 \& - \& - \& - \& ns <br>

\hline
\end{tabular}

- $\pm 10 \times 10^{-3}$
© Symmetrical about 0 volts
* Limit determined by minimum feasible leakage measurement for automatic testing.


## ELECTRICAL CHARACTERISTICS (All inputs $\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\mathbf{\prime}}$ <br> (Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) 3 to 15 V)

\begin{tabular}{|c|c|c|c|c|c|c|c|c|c|c|c|c|}
\hline \multirow{4}{*}{CHARACTERISTIC} \& \multirow{4}{*}{SYMBOL} \& \multicolumn{4}{|c|}{\multirow{4}{*}{TEST CONDITIONS}} \& \multicolumn{6}{|c|}{LIMITS} \& \multirow{4}{*}{UNITS} \\
\hline \& \& \& \& \& \& \& \& \multicolumn{2}{|l|}{\multirow[t]{2}{*}{CD4016AE}} \& \& \& \\
\hline \& \& \& \& \& \& \multicolumn{2}{|l|}{\(-40^{\circ} \mathrm{C}\)} \& \& \& \multicolumn{2}{|r|}{\(85^{\circ} \mathrm{C}\)} \& \\
\hline \& \& \& \& \& \& Typ. \& Max. \& Typ. \& Max. \& Typ. \& Max. \& \\
\hline \begin{tabular}{l}
Quiescent Dissipation per Package \\
All Switches "OFF"
\end{tabular} \& \multirow{2}{*}{\({ }^{\text {P }}\) T} \& \begin{tabular}{ll} 
\& \(\frac{T}{1}\) \\
\(v_{\text {DD }}\) \& 1 \\
\(v_{\text {SS }}\) \& 7 \\
\(v_{C}\) \& 5 \\
\(v_{\text {is }}\) \& 1 \\
\(v_{\text {OS }}\) \& 2 \\
\hline
\end{tabular} \& \multicolumn{3}{|l|}{} \& - \& 5 \& 0.1 \& 5 \& - \& 80 \& \(\mu \mathrm{W}\) \\
\hline All Switches "ON" \& \&  \& \[
\begin{aligned}
\& \text { TERMINAL } \\
\& \hline 14 \\
\& 7 \\
\& 5.6 .12 .13 \\
\& 1.4 .8 .11 \\
\& \hline
\end{aligned}
\] \& \begin{tabular}{l}
LS \\
V
+1
G
+1
\(\leq\)
\end{tabular} \& TS
IED

0 \& - \& 5 \& 01 \& 5 \& - \& 80 \& $\mu \mathrm{W}$ <br>
\hline \multicolumn{13}{|l|}{SIGNAL INPUTS ( $\mathrm{V}_{\text {is }}$ ) AND OUTPUTS ${ }^{\text {a }}$ ( os $^{\prime}$ )} <br>

\hline \multirow{13}{*}{'"ON" Resistance} \& \multirow{13}{*}{${ }^{\mathrm{R}} \mathrm{ON}$} \& \multirow{15}{*}{$R_{L}=10 \mathrm{k}!2$} \& $\mathrm{v}_{\mathrm{C}}-\mathrm{v}_{\mathrm{DD}}$ \& $\mathrm{v}_{\text {SS }}$ \& $V_{15}$ \& \multirow[b]{2}{*}{130} \& \multirow[b]{2}{*}{370} \& \multirow[b]{2}{*}{200} \& \multirow[b]{2}{*}{400} \& \multirow[b]{2}{*}{260} \& \multirow[b]{4}{*}{| 520 |  |
| ---: | ---: |
| 520 |  |
| 1080 |  |
| 80 |  |} \& \multirow{4}{*}{$\Omega$} <br>

\hline \& \& \& \multirow{3}{*}{+7.5V} \& \multirow{3}{*}{-7.5V} \& +7.5V \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& -7.5V \& 130 \& 370 \& 200 \& 400 \& 260 \& \& <br>
\hline \& \& \& \& \& $\underline{0.25 V}$ \& 160 \& 790 \& 280 \& 850 \& 400 \& \& <br>
\hline \& \& \& \multirow[b]{2}{*}{+5V} \& \multirow{3}{*}{-5V} \& +5V \& 150 \& 610 \& 250 \& 660 \& 340 \& 840 \& \multirow{3}{*}{$\Omega$} <br>
\hline \& \& \& \& \& -5V \& 150 \& 610 \& 250 \& 660 \& 340 \& 840 \& <br>
\hline \& \& \& \& \& $=0.25 \mathrm{~V}$ \& 370 \& 1900 \& 580 \& 2000 \& 770 \& 2380 \& <br>
\hline \& \& \& \multirow{3}{*}{$+15 \mathrm{~V}$} \& \multirow{3}{*}{OV} \& +15V \& 130 \& 370 \& 200 \& 400 \& 260 \& 520 \& \multirow{3}{*}{$\Omega$} <br>
\hline \& \& \& \& \& $\underline{+0.25 v}$ \& 130 \& 370 \& 200 \& 400 \& 260 \& 520 \& <br>
\hline \& \& \& \& \& 9.3 V \& 180 \& 790 \& 300 \& 850 \& 400 \& 1080 \& <br>
\hline \& \& \& \multirow{3}{*}{+10V} \& \multirow{3}{*}{OV} \& +10V \& 150 \& 610 \& 250 \& 660 \& 340 \& 840 \& \multirow{3}{*}{$\Omega$} <br>
\hline \& \& \& \& \& +025V \& 150 \& 610 \& 250 \& 660 \& 340 \& 840 \& <br>
\hline \& \& \& \& \& 56 V \& 350 \& 1900 \& 560 \& 2000 \& 750 \& 2380 \& <br>
\hline $\triangle$ "ON" Resistance \& \multirow[b]{2}{*}{$\triangle \mathrm{R}_{\mathrm{ON}}$} \& \& +7.5V \& -7.5V \& $\pm 75 \mathrm{~V}$ \& - \& - \& 10 \& - \& - \& - \& \multirow[b]{2}{*}{$\Omega$} <br>
\hline Between Any 2 of 4 Switches \& \& \& +5V \& -5V \& $\pm 5 \mathrm{~V}$ \& - \& - \& 15 \& - \& - \& - \& <br>

\hline Sine-Wave Response (Distortion) \& \& $$
\begin{aligned}
& \mathrm{A}_{\mathrm{L}}=10 \mathrm{k} \Omega 2 \\
& \mathrm{H}_{15}=1 \mathrm{kH} \mathrm{H}_{2} \\
& \hline
\end{aligned}
$$ \& +5V \& -5V \& $5 \mathrm{~V}(\mathrm{pp})^{\wedge}$ \& - \& - \& 0.4 \& - \& - \& - \& \% <br>

\hline \multirow[t]{2}{*}{Input or Output Leakage-Switch "OFF" (Effective "OFF" Resistance)} \& \& \multicolumn{4}{|c|}{$$
\frac{v_{D D}}{.75 \mathrm{~V}} \frac{v_{C}=v_{S S}}{-75 \mathrm{~V}} \frac{v_{15}}{ \pm 7.5 \mathrm{~V}}
$$} \& - \& - \& $\pm 100$ \& - \& - \& - \& pA <br>

\hline \& \& \multicolumn{4}{|c|}{-5V -5V $\quad \pm 5 \mathrm{~V}$} \& - \& - \& - \& $\pm{ }^{*}$ \& - \& - \& nA <br>

\hline Frequency-ResponseSwitch "ON" (Sine Wave Input) \& \& \multirow[b]{2}{*}{$$
\left\{\begin{array}{l}
R_{L}=1 k! \\
v_{15} 5 V(p p)
\end{array}\right.
$$} \& \multicolumn{3}{|l|}{\[

$$
\begin{aligned}
& V_{\mathrm{C}}=V_{D D}=-5 \mathrm{~V} . \mathrm{V}_{\mathrm{SS}}=-5 \mathrm{~V} \\
& 20 \mathrm{Log}_{10} \frac{v_{\mathrm{OS}}}{V_{\text {is }}}=-3.1 \mathrm{~B}
\end{aligned}
$$
\]} \& - \& - \& 40 \& - \& - \& - \& $\mathrm{MH}_{2}$ <br>

\hline Feedthrough Switch "OFF" \& \& \& \multicolumn{3}{|l|}{$$
\begin{aligned}
& \mathrm{V}_{\mathrm{DD}}=.5 \mathrm{~V} \mathrm{~V}_{\mathrm{C}}=\mathrm{v}_{\mathrm{SS}}=-5 \mathrm{~V} \\
& 20 \mathrm{Log} 10 \frac{v_{\mathrm{Gs}}}{v_{15}}=-50 \mathrm{~A} 18
\end{aligned}
$$} \& - \& - \& 1.25 \& - \& - \& - \& MHz <br>

\hline Crosstalk Between Any 2 of the 4 Switches (Frequency at $\mathbf{- 5 0} \mathrm{dB}$ ) \& $\cdots$ \& \[
\left\{$$
\begin{array}{l}
R_{L}=1 k!! \\
\dot{v}_{\text {I }}(A)= \\
5 V(p) p)
\end{array}
$$\right.

\] \& \[

$$
\begin{aligned}
& \mathrm{V}_{\mathrm{C}^{(A \mid}} \\
& 20 \log _{1}
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& \mathrm{v}_{\mathrm{DD}}= \\
& \mathrm{v}_{\mathrm{C}^{(\mathrm{BI}}}= \\
& 10 \frac{\mathrm{v}_{\mathrm{of}{ }^{\prime \prime}}^{\mathrm{v}_{15^{\prime}}}}{}
\end{aligned}
$$

\] \& \[

$$
\begin{aligned}
& \hline v . \\
& v_{S S}=-5 \mathrm{v} \\
& -504 B
\end{aligned}
$$
\] \& - \& - \& 0.9 \& - \& - \& - \& MHz <br>

\hline $$
\text { Capacitance } \frac{\text { Input }}{\frac{\text { Output }}{\text { Feedthrough }}}
$$ \&  \& \multicolumn{4}{|l|}{$\mathrm{V}_{\mathrm{DO}}=+5 \mathrm{~V} \cdot \mathrm{~V}_{\mathrm{C}}=\mathrm{v}_{\mathrm{SS}}=-5 \mathrm{~V}$} \&  \&  \& \[

$$
\begin{array}{r}
4 \\
4 \\
0.2
\end{array}
$$
\] \& - \& - \& - \& pF <br>

\hline Propagation Delay Signal Input to Signal Output \& ${ }^{\text {tpd }}$ \& \multicolumn{4}{|l|}{$$
\begin{aligned}
& V_{C^{\prime}}=V_{D D^{2}}+10 \mathrm{~V} . V_{S S}{ }^{2} \text { GND. } C_{L}=15 p F \\
& v_{\text {is }}=10 \mathrm{~V} \text { (square wave) } \\
& t_{\mathrm{r}}=t_{t}=20 \text { ns (input signal) }
\end{aligned}
$$} \& - \& - \& 10 \& - \& - \& - \& ns <br>

\hline
\end{tabular}

- $\pm 10 \times 10^{-3}$

A Symmetrical about 0 volts

[^1]ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | ${ }^{-55^{\circ} \mathrm{C} 4016 \mathrm{~A}}$ |  |  | - CD4016AK, CD |  |  | ${ }^{0164 F}{ }^{125}{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max |  |
| CONTROL (V) ${ }_{\text {C }}$ ) |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Switch Threshold Voltage* | $\mathrm{V}_{T H} \mathrm{~N}$ | $v_{15} \leq v_{\text {DD }}$ | $\begin{aligned} & V_{D D}-V_{S S}=15 \mathrm{~V}, 10 \mathrm{~V} \\ & 5 \mathrm{~V} ; \mathrm{I}_{\mathrm{IS}}=10 \mu \mathrm{~A} \end{aligned}$ | 0.7 | - | 2.9 | 0.5 | 1.5 | 2.7 | 0.2 | - | 2.4 | V |
| Input Current | ${ }^{\prime} \mathrm{C}$ |  | $\begin{aligned} & v_{D D}-v_{S S}=10 \mathrm{v} \\ & v_{C} \leq v_{D D}-v_{S S} \end{aligned}$ | - | - | - | - | $\pm 10$ | - | - | - | - | pA |
| Average Input Capacitance | ${ }^{\text {c }}$ C | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V} . \\ & \mathrm{v}_{\mathrm{C}}=10 \mathrm{~V} \\ & \text { (square wave): } \\ & \mathrm{t}_{\mathrm{rc}}=\mathrm{t}_{\mathrm{fc}}=20 \mathrm{~ns} \end{aligned}$ |  | - | - | - | - | 5 | - | - | - | - | pF |
| Crosstalk (Control Input to Signal Output) |  |  | $R_{L}=10 \mathrm{kS}$ | - | - | - | - | 50 | - | - | - | - | mV |
| Turn "ON" <br> Propagation Delay | ${ }^{\text {tod }}{ }^{\text {C }}$ |  | $\mathrm{v}_{15} \leq 10 \mathrm{~V} . \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | - | - | - | - | 20 | - | - | - | - | ns |
| Maximum Allowable Control Input Repetition Rate |  | $\begin{aligned} & V_{D D}=10 \mathrm{~V}, V_{S S}=G N D . R_{L}=1 \mathrm{kS} 2 \\ & C_{L}=15 \mathrm{pF} \\ & V_{C}=10 \mathrm{~V} \text { (square wave) } \\ & t_{r}=t_{\mathrm{f}}=20 \mathrm{~ns} \end{aligned}$ |  | - | - | - | - | 10 | - | - | - | - | MHz |

TYPICAL "ON" RESISTANCE CHARACTERISTICS

| CHARAC. teristic* | SUPPLY <br> CONDITIONS |  | LOADCONDITIONS |  |  |  |  |  | TYPICAL CHARACTERISTIC CURVE Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ |  | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ |  | $\mathrm{R}_{\mathrm{L}}=100 \mathrm{k} \Omega$ |  |  |
|  | $\begin{aligned} & V_{D D} \\ & \text { (V) } \end{aligned}$ | $\begin{aligned} & \mathrm{v}_{\mathrm{ss}} \\ & \text { (V) } \end{aligned}$ | $\begin{gathered} \text { VALUEE } \\ (\Omega) \end{gathered}$ | $\begin{aligned} & v_{\text {is }} \\ & \text { (V) } \end{aligned}$ | $\begin{gathered} \hline \text { VALUE } \\ (\Omega) \end{gathered}$ | $\begin{aligned} & v_{\text {is }} \\ & \text { (v) } \end{aligned}$ | $\begin{gathered} \hline \text { VALUE } \\ (\Omega) \\ \hline \end{gathered}$ | $\begin{aligned} & \mathrm{V}_{\text {is }} \\ & \text { (V) } \end{aligned}$ |  |
| $\mathrm{R}_{\mathrm{ON}}$ | +15 | 0 | 200 | +15 | 200 | +15 | 180 | +15 | 11.2 |
|  |  |  | 200 | 0 | 200 | 0 | 200 | 0 |  |
| $\mathrm{R}_{\mathrm{ON}}{ }^{\text {max. }}$ ) | +15 | 0 | 300 | +11 | 300 | +9.3 | 320 | +9.2 |  |
| $\mathrm{R}_{\mathrm{ON}}$ | +10 | 0 | 290 | +10 | 250 | +10 | 240 | +10 | 11.3 |
|  |  |  | 290 | 0 | 250 | 0 | 300 | 0 |  |
| $\mathrm{R}_{\text {ON }}($ max. $)$ | +10 | 0 | 500 | +7.4 | 560 | +5.6 | 610 | +5.5 |  |
| $\mathrm{R}_{\mathrm{ON}}$ | + 5 | 0 | 860 | + 5 | 470 | + 5 | 450 | + 5 | 11.4 |
|  |  |  | 600 | 0 | 580 | 0 | 800 | 0 |  |
| $\mathrm{R}_{\text {ON }}$ (max.) | + 5 | 0 | 1.7 k | +4.2 | 7k | +2.9 | 33k | +2.7 |  |
| $\mathrm{R}_{\text {ON }}$ | +7.5 | -7.5 | 200 | +7.5 | 200 | +7.5 | 180 | +7.5 | 11.5 |
|  |  |  | 200 | -7.5 | 200 | -7.5 | 180 | -7.5 |  |
| $\mathrm{R}_{\text {ON }}{ }^{\text {(max. }}$ ) | +7.5 | -7.5 | 290 | $\pm 0.25$ | 280 | $\pm 25$ | 400 | $\pm 0.25$ |  |
| $\mathrm{R}_{\mathrm{ON}}$ | + 5 | - 5 | 260 | + 5 | 250 | + 5 | 240 | + 5 | 11.6 |
|  |  |  | 310 | -5 | 250 | -5 | 240 | -5 |  |
| $\mathrm{R}_{\text {ON }}{ }^{\text {(max. })}$ | + 5 | - 5 | 600 | $\pm 0.25$ | 580 | $\pm 0.25$ | 760 | $\pm 0.25$ |  |
| $\mathrm{R}_{\mathrm{ON}}$ | +2.5 | -2.5 | 590 | +2.5 | 450 | +2.5 | 490 | +2.5 | 11.7 |
|  |  |  | 720 | -2.5 | 520 | -2.5 | 520 | -2.5 |  |
| $\mathrm{R}_{\text {ON }}{ }^{\text {(max.) }}$ | +2.5 | -2.5 | 232k | $\pm 0.25$ | 300k | $\pm 0.25$ | 870k | $\pm 0.25$ |  |

- Variation from a perfect switch; $\mathrm{RON}=0 \Omega$.


## ELECTRICAL CHARACTERISTICS (All inputs <br> $\mathbf{V}_{\mathbf{S S}} \leq \mathbf{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$ <br> (Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) <br> .... 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | Limits |  |  |  |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  | 4016 A |  |  |  |  |  |
|  |  |  |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $8^{\circ}{ }^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  | Min. | Tryp. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| CONTROL ( $\mathrm{V}_{\mathrm{C}}$ ' |  |  |  |  |  |  |  |  |  |  |  |  |  |
| Switch Threshold Voltage* | $\mathrm{V}_{\mathrm{TH}} \mathrm{N}$ | $v_{1 s} \leq v_{D O}$ | $\begin{aligned} & V_{D D^{-}} V_{S S}=15 \mathrm{~V} .10 \mathrm{~V}, \\ & 5 V_{;}{ }^{\prime} I_{S}=10 \mu \mathrm{~A} \end{aligned}$ | - | - | - | 0.5 | 1.5 | 2.7 | - | - | - | $\checkmark$ |
| Input Current | 'c |  | $\begin{aligned} & v_{D D}-v_{S S}=10 v . \\ & v_{C} \leq v_{D D}-v_{S S} \end{aligned}$ | - | - | - | - | $\pm 10$ | - | - | - | - | pA |
| Average Input Capacitance | ${ }^{\text {c }}$ C | $\begin{aligned} & v_{D D^{-}} V_{S S}=10 \mathrm{~V} . \\ & v_{\mathrm{C}}=10 \mathrm{~V} \\ & \text { (square wave). } \\ & \text { 'rc }^{2}=\mathrm{t}_{\mathrm{fc}}=20 \mathrm{~ns} \end{aligned}$ |  | - | - | - | - | 5 | - | - | - | - | pF |
| Crosstalk (Control Input to Signal Output) |  |  | $R_{L}=10 \mathrm{k} 32$ | - | - | - | - | 50 | - | - | - | - | mV |
| Turn "ON" Propagation Delay | ${ }^{\text {bpd }}$ C |  | $v_{15} \leq 10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | - | - | - | - | 20 | - | - | - | - | ns |
| Maximum Allowable Control Input Repetition Rate |  | $\begin{aligned} & v_{D D}=10 \mathrm{~V} . V_{S S}=G N D . R_{L}=1 \mathrm{k} \Omega! \\ & C_{L}=15 \mathrm{pF} \\ & v_{C}=10 \mathrm{~V} \text { (square wave) } \\ & t_{r}=t_{f}=20 \mathrm{~ns} \end{aligned}$ |  | - | - | - | - | 10 | - | - | - | - | MHz |



Fig.11.8-Typ. "ON" characteristics as a function of temp. for 1 of 4 switches with $V_{D D^{=}}+5 \mathrm{~V}$,
$V_{S S}=-5 V$.


Fig.11.9-Typ. feedthru vs. freq. - switch "OFF".


Fig. 11.10-Typ. crosstalk between switch circuits in the same package.


ALL UNUSED TERMINALS ARE CONNECTED TO VSS

Fig.11.12-Test circuit for square wave response.


Fig.11.11-Typ. switch frequency response - switch "ON".

ALL UNUSED TERMINALS ARE CONNECTED TO $V_{S S}$

92cs-16071


Fig.11.13-"OFF" switch input or output leakage test circuit.


SCALE: $X=0.2 \mathrm{~ms} / \mathrm{DIV} \quad Y=2.0 \mathrm{~V} / \mathrm{DIV}$ $V_{D D}=V_{C}=+7.5 \mathrm{~V}, V_{S S}=-7.5 \mathrm{~V}, R_{L}=10 \mathrm{~K} \Omega$ $C_{L}=15 \mathrm{pF}$
$\mathrm{f}_{1 S}=1 \mathrm{KHz} \quad \mathrm{V}_{1 \mathrm{~S}}=5 \mathrm{~V} \mathrm{p}-\mathrm{p}$
DISTORTION $=0.2 \%$
Fig.11.14-Typ. sine wave response of $V_{D D}=$ $+7.5 \mathrm{~V}, V_{S S}=-7.5 \mathrm{~V}$.


SCALE: $X=100 \mathrm{~ns} / D I V$
$\mathrm{Y}=5.0 \mathrm{~V} / \mathrm{DIV}$
Fig.11.17-Typ. square wave response at $V_{D D}=V_{C}=+15 V, V_{S S}=$ Gnd.


SCALE: $X=0.2 \mathrm{~ms} /$ DIV $Y=2.0 \mathrm{~V} / \mathrm{DIV}$
$\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\mathrm{C}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{~K} \Omega$
$C_{L}=15 \mathrm{p}^{\mathrm{F}}$
$f_{I S}=1 \mathrm{KHz} \quad V_{I S}=5 \mathrm{Vp}-\mathrm{p}$
DISTORTION $=0.4 \%$

Fig. 11.15-Typ. sine wave response of $V_{D D}=$ $+5 V, V_{S S}=-5 V$.


SCALE: $X=100 \mathrm{~ns} /$ DIV
$\mathrm{Y}=5.0 \mathrm{~V} / \mathrm{DIV}$
Fig.11.18-Typ. square wave response at $V_{D D}=V_{C}=+10 V, V_{S S}=$ Gnd.


SCALE: $X=0.2 \mathrm{~ms} /$ DIV $Y=2.0 \mathrm{~V} /$ DIV
$\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\mathrm{C}}=+2.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=-2.5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{~K} \Omega$
$C_{L}=15 p^{F}$
$\mathrm{f}_{\mathrm{IS}}=1 \mathrm{KHz} \quad \mathrm{V}_{\mathrm{IS}}=5 \mathrm{~V} \mathrm{p}-\mathrm{p}$
DISTORTION $=3 \%$
Fig.11.16-Typ. sine wave response of $V_{D D}=$ $+2.5 \mathrm{~V}, V_{S S}=-2.5 \mathrm{~V}$.


SCALE: $X=100 \mathrm{~ns} /$ DIV $Y=2 \mathrm{~V} /$ DIV

Fig.11.19-Typ. square wave response at $V_{D D}=V_{C}=+5 V, V_{S S}=$ Gnd.


Fig.11.20-Crosstalk-contral input to signal output.


ALL UNUSED TERMINALS
ARE CONNECTEO TO $V$ SS
92Cs-16085
Fig.11.21-Propagation delay time signal input (V/S) to signal output (VOS).
$10 \mathrm{~V} \square$ tr $=\mathrm{ff}=20 \mathrm{~ns}$


Fig.11.23-Max. allowable control-input repetition rate.


ALL UNUSED TERMINALS ARE CONNECTED TO $V_{\text {SS }}$

92Cs-16088
Fig.11.22-Turn-on propagation delay-control input.


ALL UNUSED TERMINALS
ARE CONNECTED TO $V_{S S}$
92CS-16081
Fig.11.24-Capacitance CIOS and COS.


Fig.11-25-Switch thresholf voltage - N-channel test circuit.

# Digital Integrated Circuits 

Monolithic Silicon
CD4017AD, CD4017AF
CD4017AE, CD4017AK


# COS/MOS Decade Counter/Divider 

## Plus 10 Decoded Decimal Outputs

## Special Features

- Medium speed operation. . . . . . 5 MHz (typ.) at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
- Fully static operation
- MSI complexity on a single chip. . . . . . decade counter plus 10 decoded outputs


## Applications

- Decade counter/decimal decode display applications
- Frequency division

CD4017A types consist of a 5 -stage Johnson decade counter and an output decoder which converts the Johnson binary code to a decimal number. Inputs include a "Clock", a "Reset", and a "Clock Enable" signal.

The decade counter is advanced one count at the positive clock signal transition if the clock enable signal is "low". Counter advancement via the clock line is inhibited when the clock enable signal is "high". A "high" reset signal clears the decade counter to its zero count. Use of the Johnson decade counter configuration permits high speed operation, 2 -input decimal decode gating, and spike-free decoded outputs. Anti-lock gating is provided, thus assuring proper counting sequence. The 10 decoded outputs are normally "low" and go "high" only at their respective decimal time slot. Each

- Counter control/timers
- Divide by $N$ counting
$\mathrm{N}=2$ - 10 with one CD4017A and one CD4001A
$\mathrm{N}>10$ with multiple CD4017A's
- For further application information, see ST4166
"COS/MOS MSI Counter and Register Design \&
Applications"
decoded output remains "high" for one full clock cycle. A carry-out (COUT) signal completes one cycle every 10 clock input cycles and is used to directly clock the succeeding decade in a multi-decade counting chain.


Fig. 12.1 - Logic diagram.


Fig. 12.2 - Timing diagram.

Fig.12.4-Typ. propagation delay time vs. $C_{L}$ for carry output.


Fig.12.6-Typ. transition time vs. $C_{L}$ for carry output.


Fig. 12.3-Typ. propagation delay time vs. $C_{L}$ for decoded outputs.


Fig. 12.5 - Typ. transition time vs. $C_{L}$ for decoded outputs.


Fig. 12.7 - Typ. clock frequency vs. $V_{D D}$.

STATIC ELECTRICAL CHARACTERISTICS (All inputs $\mathrm{v}_{\mathrm{SS}} \leq \mathrm{v}_{\mathbf{1}} \leq \mathrm{v}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4017AD, CD4017AK, CD4017AF |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{0}$ | $V_{\text {DD }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 12.9 |
|  |  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | PD |  |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) <br> For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 12.10 |
|  |  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: <br> N.Channel | ${ }^{1} \mathrm{D}^{N}$ | Decoded Outputs | 0.5 | 5 | 0.06 | - | - | 0.05 | 0.1 | - | 0.035 | - | - | mA | - |
|  |  |  | 0.5 | 10 | 0.12 | - | - | 0.1 | 0.4 | - | 0.07 | - | - |  |  |
|  |  | Carry Output | 0.5 | 5 | 0.185 | - | - | 0.15 | 0.4 | - | 0.105 | - | - |  |  |
|  |  |  | 0.5 | 10 | 0.45 | - | - | 0.35 | 1 | - | 0.25 | - | - |  |  |
| P-Channel | ${ }_{1}{ }^{P}$ | Decoded | 4.5 | 5 | -0.0375 | - | - | -0.03 | -0.075 | - | -0.021 | - | - | mA |  |
|  |  | Outputs | 9.5 | 10 | -0.12 | - | - | -0.1 | -0.2 | - | -0.07 | - | - |  |  |
|  |  | Carry Output | 4.5 | 5 | -0.185 | - | - | -0.15 | -0.4 | - | -0.105 | - | - |  |  |
|  |  |  | 9.5 | 10 | -0.45 | - | - | -0.35 | - 1 | - | -0.25 | - | - |  |  |
| Input Current | 11 |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

- See Appendix.


Fig. 12.8-Typ. dissipation characteristics.

File No. 479
STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage (VD $\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | test CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4017AE |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $v_{0}$ | $\mathrm{V}_{\text {DD }}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $\mathrm{I}_{\mathrm{L}}$ |  |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 12.9 |
|  |  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device <br> Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14,000 |  |  |
| Output Voltage: Low.Level | $\mathrm{V}_{\mathrm{OL}}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High. Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition. See Appendix | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 12.10 |
|  |  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 14 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | v |  |
|  |  |  | 9.0 | 10 | 29 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }^{1}{ }^{N}$ | DecodedOutputs | 0.5 | 5 | 0.03 | - | - | 0.025 | 0.1 | - | 0.02 | - | - | mA | - |
|  |  |  | 0.5 | 10 | 0.085 | - | - | 0.07 | 0.4 | - | 0.055 | - | - |  |  |
|  |  | Carry Output | 0.5 | 5 | 0.095 | - | - | 0.08 | 0.4 | - | 0.065 | - | - |  |  |
|  |  |  | 0.5 | 10 | 0.3 | - | - | 0.25 | 1 | - | 0.2 | - | - |  |  |
| P.Channel | ${ }^{1} D^{P}$ | Decoded | 4.5 | 5 | -0.018 | - | - | -0.015 | -0.075 | - | -0.012 | - | - | mA |  |
|  |  | Outputs | 9.5 | 10 | -0.085 | - | - | -0.07 | -0.2 | - | -0.055 | - | - |  |  |
|  |  | Carry Output | 4.5 | 5 | -0.095 | - | - | -0.08 | -0.4 | - | -0.065 | - | - |  |  |
|  |  |  | 9.5 | 10 | -0.3 | - | - | -0.24 | - 1 | - | -0.20 | - | - |  |  |
| Input Current | 1 |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

- See Appendix.


Fig. 12.9-Quiescent device current test circuit.


Fig.12.10-Noise immunity test circuit.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$, and input rise and fall times $=\mathbf{2 0}$ ns except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathbf{f}} \mathbf{C L}$ Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \%{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)


* Measured with respect to carry output line


Fig. 12.11-Divide by $N$ counter $(N \leq 10)$ with $N$ decoded outputs.

When the $N^{\text {th }}$ decoded output is reached ( $N^{\text {th }}$ clock pulse) the S-R flip flop (constructed from two NOR gates of the CD4001A) generates a reset pulse which clears the CD4017A to its zero count. At this time, if the $\mathrm{N}^{\text {th }}$ decoded output is greater than or equal to 6 , the COUT line goes "high" to clock the next CD4017A counter section. The " 0 " decoded output also goes high at this time. Coincidence of the clock "low" and decoded " 0 " output "low" resets the S-R flip flop to enable the CD4017A. If the $N^{\text {th }}$ decoded output is less than 6, the $\mathrm{C}_{\text {OUT }}$ line will not go "high" and, therefore, cannot be used. In this case " 0 " decoded output may be used to perform the clocking function for the next count-: er.

# Digital Integrated Circuits 

Monolithic Silicon
CD4018AD, CD4018AF
CD4018AE, CD4018AK


## COS/MOS

## Presettable Divide-Byo'則' Counter

## Special Features

- Medium speed operation.

5 MHz (typ.) at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$

- Fully static operation
- MSI complexity on a single chip


## Applications

- Fixed and programmable divide-by-10, 9, 8, 7, 6, 5, 4, 3, 2 counters
- Fixed and programmable counters greater than 10
- Programmable decade counters
- Frequency division
- Divide-by-"N" counters/frequency synthesizers
- Counter control/timers

CD4018A types consist of 5 Johnson-Counter stages, buffered $\overline{\mathrm{Q}}$ outputs from each stage, and counter preset control gating. "Clock", "Reset", "Data", "Preset Enable", and 5 individual "Jam" inputs are provided. Divide by 10,8 , 6,4 , or 2 counter configurations can be implemented by feeding the $\overline{\mathrm{Q}} 5, \overline{\mathrm{Q}} 4, \overline{\mathrm{Q}} 3, \overline{\mathrm{Q}} 2, \overline{\mathrm{Q}} 1$ signals, respectively, back to the Data input. Divide-by-9, 7,5, or 3 counter configurations can be implemented by the use of a CD4011A gate package
to properly gate the feedback connection to the Data input. Divide-by functions greater than 10 can be achieved by use of multiple CD4018A units. The counter is advanced one count at the positive clock-signal transition. A "high" Reset signal clears the counter to an "all-zero" condition. A "high" Preset-Enable signal allows information on the Jam inputs to preset the counter. Anti-lock gating is provided to assure the proper counting sequence.


Fig. 13.1 - Logic diagram.

STATIC ELECTRICAL CHARACTERISTICS (All inputs $\mathrm{V}_{\mathbf{S S}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4018AD, CD4018AK, CD4018AF |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $v_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\text {IL }}$ |  |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 13.9 |
|  |  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | $\mathrm{PD}_{\mathrm{D}}$ |  |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $v$ | - |
|  |  |  |  | 10 | . 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition, <br> See Appendix | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 15 | - | - | 15 | 225 | - | 1.4 | - | - | V | 13.10 |
|  |  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V | - |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current :N.Channel | ${ }_{1}{ }^{N}$ | $\overline{\mathrm{a}}_{5}$ | 0.5 | 5 | 0.18 | - | - | 0.15 | 0.4 | - | 0.105 | - | - | mA | $\bullet$ |
|  |  |  | 0.5 | 10 | 0.45 | - | - | 0.35 | 1 | - | 0.25 | - | - |  |  |
|  |  | $\begin{aligned} & \overline{\mathrm{o}}_{1}, \overline{\mathrm{o}}_{2} \\ & \overline{\mathrm{o}}_{3}, \overline{\mathrm{o}}_{4} \end{aligned}$ | 0.5 | 5 | 0.06 | - | - | 0.05 | 0.1 | - | 0.035 | - | - |  |  |
|  |  |  | 0.5 | 10 | 0.25 | - | - | 0.2 | 0.4 | - | 0.14 | - | - |  |  |
| P.Channel | ${ }_{1} D^{P}$ | $\overline{\mathrm{a}}_{5}$ | 4.5 | 5 | -0.185 | - | - | 0.15 | 0.4 | - | -0.105 | - | - | mA | - |
|  |  |  | 9.5 | 10 | 0.45 | - | - | -0.35 | -1 | - | 0.25 | - | - |  |  |
|  |  | $\overline{\mathrm{o}}_{1} \overline{\mathrm{O}}_{2}$ | 4.5 | 5 | -0.075 | - | - | -0.06 | -0.15 | - | -0.04 | - | - |  |  |
|  |  | $\overline{\mathrm{O}}_{3} \overline{\mathrm{O}}_{4}$ | 9.5 | 10 | 0.25 | - | - | -0.2 | -0.4 | - | -0.14 | - | - |  |  |
| Input Current | 11 |  |  |  |  |  |  | - | 10 | - | - | - | - | pA | - |

-See Appendix.


Fig. 13.2 - Timing diagram.

STATIC ELECTRICAL CHARACTERISTICS (All inputs $\mathrm{v}_{\mathrm{SS}} \leq \mathrm{v}_{1} \leq \mathrm{v}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $V_{D D}-V_{S S}$ ).

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | L.IMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4018AE |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{0}$ | $V_{\text {DD }}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 13.9 |
|  |  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | ${ }^{\text {PD }}$ |  |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition. See Appendix | $V_{N L}$ |  | 0.8 | 5 | 15 | - | - | 15 | 2.25 | - | 1.4 | - | - | V | 13.10 |
|  |  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{VNH}^{\text {N }}$ |  | 4.2 | 5 | 14 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | $v$ | - |
|  |  |  | 9.0 | 10 | 29 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current <br> N.Channel | ${ }^{1} \mathrm{D}^{N}$ | $\overline{0}_{5}$ | 0.5 | 5 | 0.095 | - | - | 0.08 | 0.4 | - | 0.065 | - | - | mA | * |
|  |  |  | 0.5 | 10 | 0.3 | - | - | 0.25 | 1 | - | 0.2 | - | - |  |  |
|  |  | $\overline{\mathrm{a}}_{1} \overline{\mathrm{O}}_{2}$. | 0.5 | 5 | 0.03 | - | - | 0.025 | 0.1 | - | 0.02 | - | - |  |  |
|  |  | $\mathrm{O}_{3} \mathrm{O}_{4}$ | 0.5 | 10 | 0.18 | - | - | 0.15 | 0.4 | - | 0.12 | - | - |  |  |
| P.Channel | ${ }_{1}{ }^{P}$ | $\overline{\mathrm{O}}_{5}$ | 4.5 | 5 | -0.095 | - | - | -0.08 | -0.4 | - | -0.065 | - | - | mA | - |
|  |  |  | 9.5 | 10 | -0.3 | - | - | -0.25 | -1 | - | -0.2 | - | - |  |  |
|  |  | $\overline{\mathrm{a}}_{1}, \overline{\mathrm{O}}_{2}$ | 4.5 | 5 | -0.035 | - | - | -0.03 | -0.15 | - | -0.024 | - | - |  |  |
|  |  | $\overline{\mathrm{a}}_{3}, \overline{\mathrm{a}}_{4}$ | 9.5 | 10 | -0.18 | - | - | -0.15 | -0.4 | - | -0.12 | - | - |  |  |
| Input Curreṇt | 11 |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

## See Appendix



Fig. 13.3-Typ. propagation delay time vs. $C_{L}$ for decoded outputs.


Fig. 13.4-Typ. propagation delay time vs. $c_{L}$ for $\bar{Q}_{5}$ output.


Fig. 13.5-Typ. transition time vs. $C_{L}$ for decoded outputs.


Fig.13.7- Typical clock frequency
vs. VDD.


Fig. 13.9 - Quiescent device current test circuit.


Fig.13.6-Typ. transition time vs. $C_{L}$ for $\bar{Q}_{5}$ output.


Fig.13.8-Typ. dissipation characteristics


92CS-17914RI

Fig. 13.10 - Noise immunity test circuit.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$ except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ Typical Temperature Coerficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$
(See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{aligned} & \text { CD4018AD } \\ & \text { CD4018AK } \\ & \text { CD4018AF } \end{aligned}$ |  |  | CD4018AE |  |  |  |  |
|  |  | $\begin{array}{\|l} \hline \mathrm{V}_{\mathrm{DD}} \\ \text { (Volts) } \\ \hline \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |

## CLOCKED OPERATION

| Propagation Delay Time: To $\overline{\mathrm{Q}}_{5}$ Output | $\begin{aligned} & \mathrm{t}_{\mathrm{PHL}}= \\ & \mathrm{t}_{\mathrm{PLH}} \end{aligned}$ |  | $\begin{array}{r} 5 \\ 10 \end{array}$ | - | $\begin{aligned} & 350 \\ & 125 \end{aligned}$ | $\begin{array}{r} 1000 \\ 250 \end{array}$ |  | $\begin{aligned} & 350 \\ & 125 \end{aligned}$ | $\begin{array}{\|r\|} \hline 1300 \\ \hline 300 \\ \hline \end{array}$ | ns | 13.4 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| To Other Outputs |  |  |  | - | $\begin{aligned} & 500 \\ & 200 \end{aligned}$ | $\begin{array}{r} 1200 \\ 400 \end{array}$ |  | $\begin{aligned} & 500 \\ & 200 \end{aligned}$ | $\begin{array}{r} 1600 \\ 500 \end{array}$ | ns | 13.3 |
| Transition Time: <br> To $\overline{\mathrm{Q}}_{5}$ Output | $\begin{aligned} & { }^{{ }^{\prime} \mathrm{THL}}= \\ & { }^{\mathrm{t}} \mathrm{TLH} \end{aligned}$ |  | 5 | - | $\begin{array}{r} 100 \\ 50 \end{array}$ | $\begin{aligned} & 300 \\ & 150 \end{aligned}$ |  | $\begin{array}{r} 100 \\ 50 \end{array}$ | $-\frac{350}{200}$ | ns | 13.6 |
| To Other Outputs |  |  | 5 | - | 300 | 900 | - | 300 | 1200 | ns | 13.5 |
|  |  |  | 10 | - | 125 | 350 | - | 125 | 450 |  |  |
| Minimum Clock Pulse Width | $\begin{aligned} & { }^{{ }^{W} W L}= \\ & { }^{t_{W H}} \end{aligned}$ |  | 5 | - | 200 | 500 | - | 200 | 830 | ns | - |
|  |  |  | 10 | - | 100 | 170 | - | 100 | 250 |  |  |
| Clock <br> Rise \& Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{rCL}}= \\ & \mathrm{t}_{\mathrm{fCL}} \end{aligned}$ |  | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  |  | 10 | - | - | 15 | - | - | 15 |  |  |
| Data Input Set-Up Time |  |  | 5 | - | 175 | 500 | - | 175 | 700 | ns | - |
|  |  |  | 10 | - | 75 | 200 | - | 75 | 300 |  |  |
| Maximum Clock Frequency | ${ }^{\text {f }} \mathrm{CL}$ |  | 5 | 1 | 2.5 | - | 0.6 | 2.5 | - | MHz | - |
|  |  |  | 10 | 3. | 5 | - | 2 | 5 | - |  |  |
| Input Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |
| PRESET* OR RESET OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: | $\begin{aligned} & \mathrm{t}_{\mathrm{PLH}}(\mathrm{R}) \\ & \\ & \mathrm{t}_{\mathrm{PHL}}(\mathrm{PR})= \\ & \mathrm{t}_{\mathrm{PLH}}(\mathrm{PR}) \end{aligned}$ |  | 5 | - | 350 | 1000 | - | 350 | 1300 | ns |  |
| To $\overline{\mathrm{O}}_{5}$ Output |  |  | 10 | - | 125 | 250 | - | 125 | 300 |  |  |
| To Other Outputs |  |  | 5 | - | 500 | 1200 | - | 500 | 1600 | ns | - |
|  |  |  | 10 | - | 200 | 400 | - | 200 | 500 |  |  |
| Preset or Reset Pulse Width | ${ }^{t}$ WH(R). <br> tWH(PR) |  | 5 | - | 200 | 500 | - | 200 | 830 | ns | - |
|  |  |  | 10 | - | 100 | 165 | - | 100 | 250 |  |  |
| Preset or Reset Removal Time |  |  | 5 | - | 300 | 750 | - | 300 | 1000 | ns | - |
|  |  |  | 10 | - | 100 | 225 | - | 100 | 275 |  |  |

*At Preset Enable or Jam Inputs.


divide by 5


DIVIDE BY 3


CONNECTED BACK TO "DATA" (SKIPS "ALL-l's" STATE)

## Digital Integrated Circuits Monolithic Silicon <br> CD4019AD, CD4019AF <br> CD4019AE, CD4019AK



## COS/MOS Quad <br> AND-OR Select Gate

## Special Features

- Medium-speed operation. . . . . . tPHL $=$ tPLH $=50$ ns (typ.) at $C_{L}=15 \mathrm{pF}$


## Applications

- AND-OR select gating
- Shift-right/shift-left registers
- True/complement selection
- AND/OR/Exclusive-OR selection

CD4019A types are comprised of four "AND-OR Select" gate configurations, each consisting of two 2-input AND gates driving a single 2 -input OR gate. Selection is accomplished by control bits $\mathrm{K}_{\mathrm{a}}$ and $\mathrm{K}_{\mathrm{b}}$. In addition to
selection of either channel A or channel B information, the control bits can be applied simultaneously to accomplish the logical $A+B$ function.


Fig.14.1-Schematic diagram for 1 of 4 identical stages.

TYPICAL CD4019A APPLICATIONS


Fig.14.2-AND/OR select gating.


Fig.14.3-‘Shift left/shift right" register.


Fig. 14.4 - "True" complement" selector.

STATIC ELECTRICAL CHARACTERISTICS (All inputs

$$
\left.\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}\right)
$$

(Recommended DC Supply Voltage (VDD $\mathrm{V}_{\text {SS }}$ ) . . . . . . . . . 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4019AD, CD4019AK, CD4019AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.03 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 14.10 |
|  |  |  | 10 | - | -- | 10 | - | 0.05 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 25 | - | 0.15 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 100 | - | 0.5 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition. See Appendix | VNL | 0.95 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14.11 |
|  |  | 2.9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 3.6 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 7.2 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current N-Channel | ${ }^{1} \mathrm{DN}$ | 0.5 | 5 | 0.6 | - | - | 0.45 | 0.9 | - | 0.30 | - | - | mA | $\checkmark$ |
|  |  | 0.5 | 10 | 0.9 | - | - | 0.75 | 1.5 | - | 0.55 | - | - |  |  |
| P.Channel | ${ }_{1} D^{P}$ | 4.5 | 5 | -0.31 | - | - | -0.25 | -0.5 | - | -0.175 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.95 | - | - | -0.7 | -1.5 | - | -0.5 | - | - |  |  |
| Input Current | $1 /$ |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

- See Appendix.


Fig. 14.5 - AND/OR Exclusive-OR selector.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $V_{D D}-V_{S S}$ )
. . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4019AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\text {DD }}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Voits | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 50 | - | 0.1 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 14, 10 |
|  |  |  | 10 | - | - | 100 | - | 0.2 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | ${ }^{\text {P }}$ |  | 5 | - | - | 250 | - | 0.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 1000 | - | 2 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition, See Appendix | $V_{\text {NL }}$ | 0.95 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14, 11 |
|  |  | 2.9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 3.6 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | $v$ |  |
|  |  | 7.2 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current N.Channel | ${ }^{1} \mathrm{DN}$ | 0.5 | 5 | 0.37 | - | - | 0.30 | 1.0 | - | 0.23 | - | - | mA | $\dagger$ |
|  |  | 0.5 | 10 | 0.8 | - | - | 0.65 | 1.5 | - | 0.5 | - | - |  |  |
| P.Channel | ${ }_{10}{ }^{P}$ | 4.5 | 5 | -0.145 | - | - | -0.12 | -0.5 | - | -0.095 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.6 | - | - | -0.5 | -1.5 | - | -0.4 | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

*See Appendix.


Fig.14.6-Typ. propagation delay time vs $C_{L}$.


Fig.14.7-Typ. transition time vs. $C_{L}$.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$, and input rise and fall times $=\mathbf{2 0} \mathrm{ns}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \%{ }^{\circ} \mathrm{C}$ (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4019AD, CD4019AK, CD4019AF |  |  | CD4019AE |  |  |  |  |
|  |  | $\begin{array}{\|l} \hline V_{\mathrm{DD}} \\ \text { (Volts) } \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: | ${ }^{\mathrm{t}} \mathrm{PHL}$, <br> tPLH | 5 | - | 100 | 225 | - | 100 | 300 | ns | 14.6 |
|  |  | 10 | - | 50 | 100 | - | 50 | 125 |  |  |
| Transition Time | ${ }^{\mathrm{t}}$ THL. <br> tTLH | 5 | - | 100 | 200 | - | 100 | 275 | ns | 14.7 |
|  |  | 10 | - | 40 | 65 | - | 40 | 80 |  |  |
| Input Capacitance | $C_{1}$ | All $A$ and $B$ Inputs | - | 5 | - | - | 5 | - | pF | - |
|  |  |  | - | 12 | - | - | 12 | - |  |  |



Fig. 14.8-Max. propagation delay time vs VDD.


92CS-17915


Fig.14.9-Typ. dissipation characteristıcs per output.


Fig.14.11-Noise immunity test circuit.

Digital Integrated Circuits
Monolithic Silicon
CD4020AD, CD4020AF CD4020AE, CD4020AK


## COS/MOS <br> 14-Stage Ripple-Carry <br> Binary Counter/Divider

## Special Features

- Medium speed operation. . . . . . 7 MHz (typ.) at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathbf{S S}}=10 \mathrm{~V}$
- Low "high"- and "low"-level output impedance. . . . . . 1000 $\Omega$ (typ.) at $V_{D D}-V_{S S}=10 \mathrm{~V}$
- MSI complexity on a single chip. . . . . . 14 fully static, master-slave stages
- COS/MOS gate-input loading at both Reset and Input-pulse lines

CD4020A types consist of a pulse input shaping circuit, reset line driver circuitry, and 14 ripple-carry binary counter stages. Buffered outputs are externally available from stages 1, and 4 through 14. The counter is reset to its "all zeroes" state by a high level on the reset inverter input line. Each counter stage is a static master-slave flip-flop. The counter is advanced one count on the negative-going transition of each input pulse.

## Applications

a Frequency-dividing circuits

- Time-delay circuits
- Counter control
- Counting functions


Fig. 15.1 - Logic diagram for 1 of 14 binary stages.

STATIC ELECTRICAL CHARACTERISTICS (All inputs

$$
\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}
$$

(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4020AD, CD4020AK, CD4020AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\text {DD }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 15 | - | 0.5 | 15 | - | - | 900 | $\mu \mathrm{A}$ | 15.11 |
|  |  |  | 10 | - | - | 25 | - | 1 | 25 | - | - | 1500 |  |  |
| Quiescent Device Dissipatıon 'Package | $P_{\text {D }}$ |  | 5 | - | - | 75 | - | 2.5 | 75 | - | - | 4500 | $\mu \mathrm{W}$ | 15.10 |
|  |  |  | 10 | - | - | 250 | - | 10 | 250 | - | - | 15000 |  |  |
| Output Voltage. Low Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) <br> For Definition, See Appendix | VNL | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 15.12 |
|  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V | 15.13 |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current N.Channel | N0 | 0.5 | 5 | 0.09 | - | - | 0.075 | 0.2 | - | 0.05 | - | - | $m A$ | $\bullet$ |
|  |  | 0.5 | 10 | 0.185 | - | - | 0.15 | 0.4 | - | 0.105 | - | - |  |  |
| P.Channel | $I^{\prime} P$ | 4.5 | 5 | -0.11 | - | - | -0.09 | -0.25 | - | -0.065 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.25 | - | - | -0.20 | -0.5 | - | -0.14 | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

See Appendix.


Fig.15.2 - Schematic diagram of pulse shapers and 1 of 14 binary stages.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4020AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{O}}$ | $V_{\text {DD }}$ |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{1} \mathrm{~L}$ |  | 5 |  |  | 50 |  | 1 | 50 |  |  | 700 | $\mu \mathrm{A}$ | 15.11 |
|  |  |  | 10 |  |  | 100 |  | 2 | 100 | - | $\cdots$ | 1400 |  |  |
| Quiescent Device Dissipation 'Package | ${ }^{P}$ |  | 5 |  |  | 250 |  | 5 | 250 | . | - | 3500 | $\mu \mathrm{W}$ | 15.10 |
|  |  |  | 10 |  |  | 1000 |  | 20 | 1000 | - | - | 14000 |  |  |
| Output Voltage Low Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 |  |  | 001 |  | 0 | 0.01 |  |  | 0.05 | V | - |
|  |  |  | 10 |  |  | 001 |  | 0 | 0.01 |  |  | 0.05 |  |  |
| High-Level | VOH |  | 5 | 499 |  |  | 499 | 5 |  | 4.95 | - | - | V | - |
|  |  |  | 10 | 999 |  |  | 9.99 | 10 |  | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any input) <br> For Definition, <br> See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 15 |  |  | 15 | 225 |  | 1.4 |  |  | V | 15.12 |
|  |  | 1.0 | 10 | 30 |  |  | 3 | 4.5 |  | 2.9 |  | . |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 14 |  |  | 15 | 225 |  | 1.5 | . |  | V | 15.13 |
|  |  | 9.0 | 10 | 29 |  |  | 3 | 4.5 |  | 3.0 |  | - |  |  |
| Output Drive Current N.Channel | ${ }^{1} \mathrm{D} N$ | 0.5 | 5 | 0.09 |  |  | 0.08 | 0.33 |  | 0.065 | - | - | $m A$ | $\bullet$ |
|  |  | 0.5 | 10 | 0.16 |  |  | 0.10 | 0.5 |  | 0.10 | - | - |  |  |
| P.Channel | $1_{1}{ }^{P}$ | 4.5 | 5 | -0 09 |  |  | -0.06 | -0.25 |  | -0.05 | - | - | mA |  |
|  |  | 9.5 | 10 | -0 18 |  |  | -0.15 | -0.5 |  | -0.12 | - | . |  |  |
| Input Current | 11 |  |  |  |  |  |  | 10 |  |  |  | - | pA | - |

See Appendix.


Fig. 15-3-Typ. n-channel drain characteristics.


92CS-17814

Fig.15.4-Typ. p-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20$ ns except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3 \%} /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{aligned} & \text { CD4020AD } \\ & \text { CD4020AK } \\ & \text { CD4020AF } \end{aligned}$ |  |  | CD4020AE |  |  |  |  |
|  |  |  | $\begin{array}{\|l\|} \hline \text { VDD } \\ \text { (Volts) } \\ \hline \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| CLOCKED OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: | ${ }^{\text {t }} \mathrm{PHL}=$ |  | 5 | - | 450 | 600 | - | 450 | 650 | ns | 15.7 |
|  | ${ }^{\text {tPLH }}$ |  | 10 | - | 150 | 225 | - | 150 | 250 |  |  |
| Transition Time | $\begin{aligned} & \mathrm{t}_{\mathrm{THL}}= \\ & \mathrm{t}_{\mathrm{TLH}} \end{aligned}$ |  | 5 | - | 450 | 600 | - | 450 | 650 | ns | 15.8 |
|  |  |  | 10 | - | 200 | 300 | - | 200 | 350 |  |  |
| Minimum Clock Pulse Width | $\begin{aligned} & t_{W L}= \\ & t_{W H} \end{aligned}$ |  | 5 | - | 200 | 335 | - | 200 | 500 | ns | - |
|  |  |  | 10 | - | 70 | 125 | - | 70 | 165 |  |  |
| Clock <br> Rise \& Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{rCL}}= \\ & \mathrm{t}_{\mathrm{fCL}} \end{aligned}$ |  | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  |  | 10 | - | - | 15 | - | - | 15 |  |  |
| Maximum Clock Frequency | ${ }^{f} \mathrm{CL}$ |  | 5 | 1.5 | 2.5 | - | 1 | 2.5 | - | MHz | 15.9 |
|  |  |  | 10 | 4 | 7 | - | 3 | 7 | - |  |  |
| Input Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |
| RESET OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: | ${ }^{\text {tPHL }}$ (R) |  | 5 | - | 2000 | 3000 | - | 2000 | 3500 | ns | 15.7 |
|  |  |  | 10 | - | 500 | 775 | - | 500 | 900 |  |  |
| Minimum Resct Pulse Width | ${ }^{\text {t }} \mathrm{WH}(\mathrm{R})$ |  | 5 | - | 1800 | 2500 | - | 1800 | 3000 | ns | - |
|  |  |  | 10 | - | 300 | 475 | - | 300 | 550 |  |  |

*Propagation Delay is from clock input to $\mathrm{Q}_{1}$ output.


Fig. 15.5-Min. n-channel drain characteristics.


92CS-17863

Fig.15.6-Min. p-channel drain characteristics.


Fig. 15.7-Typ. propagation delay time vs. $C_{L}$.

Fig. 15.9-Typ. clock frequency vs. $V_{D D}$.


Fig.15.8-Tvp. transition time vs. $C_{L}$.


Fig.15.10-Typ. dissipation characteristics.


# Digital Integrated Circuits 

Monolithic Silicon

## CD4021AD, CD4021AF CD4021AE, CD4021AK



# COS/MOS 8-Stage <br> Static Shift Register 

Asynchronous Parallel Input/Serial Output, Synchronous Serial Input/Serial Output

## Special Features

- Asynchronous parallel or synchronous serial operation under control of parallel/serial control-input
- Individual "jam" inputs to each register stage
- Master-slave flip-flop register stages
- Fully static operation. . . . . . DC to 5 MHz

CD4021A types are 8 -stage parallel or serial-input/serialoutput shift registers having common Clock and Parallel/ Serial Control inputs, a single Serial Data input, and individual parallel "Jam" inputs to each register stage. Each register stage is a D-type, master-slave flip-flop. "Q" outputs are available from the sixth, seventh, and eighth stages.

When the parallel/Serial Control input is "low", data is serially shifted into the 8 -stage register synchronously with the positive-going transition of the Clock pulse.

## Applications

- Asynchronous parallel input/serial output data queueing
- Parallel to serial data conversion ■ General purpose register

[^2]

| CL ${ }^{\text { }}$ | Serral Input | Paratlet/ Serial Control | Pl. 1 | Pİn | $\mathbf{a}_{1}$ <br> (Internal) | $\mathrm{O}_{\mathrm{n}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| X | x | 1 | 0 | 0 | 0 | 0 |
| $x$ | $X$ | 1 | 0 | 1 | 0 | 1 |
| x | x | 1 | 1 | 0 | 1 | 0 |
| $\times$ | x | 1 | 1 | 1 | 1 | 1 |
|  | $\begin{aligned} & 0 \\ & 1 \end{aligned}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & x \\ & x \end{aligned}$ | $\begin{aligned} & x \\ & x \end{aligned}$ | $\begin{aligned} & 0 \\ & 1 \end{aligned}$ | $\begin{aligned} & O_{n \cdot 1} \\ & O_{n} \cdot 1 \end{aligned}$ |
| - | X | 0 | $x$ | X | $\mathrm{O}_{1}$ | $\mathrm{a}_{\mathrm{n}}$ |



Fig. 16.3-Schematic diagram - CD4021A.

(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | $\begin{gathered} \text { TEST } \\ \text { CONDITIONS } \\ \hline \end{gathered}$ |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4021AD, CD4021AK, CD4021AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\text {DD }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $\mathrm{I}_{\mathrm{L}}$ |  | 5 | - | - | 5 | - | 0.5 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 16.8 |
|  |  |  | 10 | - | - | 10 | - | 1 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 25 | - | 2.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 100 | - | 10 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | $v$ | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $v$ | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) <br> For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 16.9 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | VNH | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | .- | 1.5 | - | - | V |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N-Channel | IDN | 0.5 | 5 | 0.15 | - | - | 0.12 | 0.3 | - | 0.085 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.31 | - | - | 0.25. | 0.5 | - | 0.175 | - | - |  |  |
| P.Channel | ${ }_{1}{ }^{\prime} P$ | 4.5 | 5 | -0.1 | - | - | -0.08 | -0.16 | - | -0.055 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.25 | - | - | -0.20 | -0.44 | - | -0.14 | - | - |  |  |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

©See Appendix.


Fig. 16.4-Typ. clock frequencv vs. $V_{D D}$.


Fig. 16.5-Typ. propagation delay time vs. $C_{L}$.

STATIC ELECTRICAL CHARACTERISTICS (All inputs . . . . . . . . . . . . . . . . . . . . . . . . . $\mathrm{V}_{\text {SS }} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\text {DD }}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | $\begin{gathered} \text { TEST } \\ \text { CONDITIONS } \end{gathered}$ |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC curves $\&$ TEST circuits Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4021AE |  |  |  |  |  |  |  |  |  |  |
|  |  | Vo | $V_{\text {DD }}$ |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Vots | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 16.8 |
|  |  |  | 10 | - | - | 100 | $-$ | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition, <br> See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 16.9 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | v |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }_{1}{ }^{\text {N }}$ | 0.5 | 5 | 0.072 | - | - | 0.06 | 0.3 | - | 0.05 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.12 | - | - | 0.1 | 0.5 | - | 0.08 | - | - |  |  |
| P.Channel | ${ }_{10}{ }^{\text {P }}$ | 4.5 | 5 | -0.06 | - | - | -0.05 | -0.16 | - | -0.04 | - | - | mA |  |
|  |  | 9.5 | 10 | -0.12 | - | - | -0.1 | -0.44, | - | -0.08 | - | - |  |  |
| Input Current | 1 |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

*See Appendix.


Fig. 16.6-Typ. transiition time vs. $C_{L}{ }^{*}$


Fig. 16.7-Typ. dissipation characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$ and input rise and fall times $=20 \mathrm{~ns}$ except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4021AD CD4021AK CD4021AF |  |  | CD4021AE |  |  |  |  |
|  |  |  | VDD (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time ${ }^{* *}$ | tPHL $=$ |  | 5 | - | 300 | 750 | - | 300 | 1000 | ns | 16.5 |
|  | tPLH |  | 10 | - | 100 | 225. | - | 100 | 300 |  |  |
| Transition Time | $\begin{aligned} & \mathrm{t} T \mathrm{HL}= \\ & \mathrm{t} T \mathrm{LLH} \end{aligned}$ |  | 5 | - | 150 | 300 | - | 150 | 400 | ns | 16.6 |
|  |  |  | 10 | - | 75 | 125 | - | 75 | 150 |  |  |
| Minimum Clock Pulse Width | $\begin{aligned} & \text { tWL }= \\ & \text { tWH } \end{aligned}$ |  | 5 | - | 200 | 500 | - | 200 | 830 | ns | - |
|  |  |  | 10 | - | 100 | 175 | - | 100 | 200 |  |  |
| Minimum High-Level Parallel/Serial Control Pulse Width | tWH(P/S) |  | 5 | - | 200 | 500 | - | 200 | 830 |  | - |
|  |  |  | 10 | - | 100 | 175 | - | 100 | 200 |  |  |
| Clock Rise \& Fall Time | $\begin{aligned} & * \operatorname{trCL}= \\ & \operatorname{tfCL} \end{aligned}$ |  | 5 | - | - | $\overline{15}$ | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  |  | 10 | $\because$ | - | 15 | - | - | 15 |  |  |
| Set-Up Time |  |  | 5 | - | 100 | 350 | - | 100 | 500 | ns | - |
|  |  |  | 10 | - | 50 | 80 | - | 50 | 100 |  |  |
| Maximum Clock Frequency | ${ }^{\mathrm{f}} \mathrm{CL}$ |  | 5 | 1 | 2.5 | - | 0.6 | 2.5 | - | MHz | - |
|  |  |  | 10 | 3 | 5 | - | 2.5 | 5 | - |  |  |
| Input Capacitance | $\mathrm{Cl}_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |

** From Clock or Parallel/Serial Control Input
$S_{1} S_{2} S_{3} S_{4} S_{5}$
$\begin{array}{lllll}0 & 0 & 1 & 0 & 0 \\ 1 & 0 & 1 & 1 & 1 \\ 1 & 0 & 1 & 0 & 1 \\ 0 & 1 & 1 & 1 & 1 \\ 0 & 1 & 0 & 0 & 0\end{array}$
Fig. 16.8-Quiescent device current test circuit.

Test performed with the following sequence of "One's" and "Zero's".


- If mure than one unit is cascaded in a parallel clocked operation, ${ }_{r} \mathrm{CL}$ should be made less than or equal to the sum of the fixed propagation delay time at 15 pF and the transition time of the output driving stagge for the estimated capacitive load.


Fig. 16.9-Noise immunity test circuit.

# Digital Integrated Circuits <br> Monolithic Silicon <br> CD4022AD, CD4022AF CD4022AE, CD4022AK 



## COS/MOS Divide - By - 8 Corares/Digider with 8 Decoded Outputs

## Special Features

- Medium speed operation. . . . . 5 MHz (typ.) at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{S S}=10 \mathrm{~V}$
- MSI complexity on a single chip
- Divide by $N$ counting; $N=2$ to 8 with one CD4022A plus one CD4001A, package
Applications
- Binary counting/decoding E Binary counter control/timers

CD4022A types consist of a 4 -stage divide-by- 8 Johnson counter, associated decode output gating and a carry-out bit. The counter is cleared to its zero count by a "high" reset signal. The counter is advanced on the positive clock-signal transition provided the clock enable sianal is "low".

Use of the Johnson divide-by-8 counter configuration permits high-speed operation, 2 -input decode gating, and
spike-free decoder outputs. Anti-lock gating is provided, thus assuring proper counting sequence. The 8 decode gating outputs are normally "low" and go "high" only at their respective decoded time slot. Each decode gate output remains "high" for one full clock cycle. The carry-out signal completes one cycle every 8 clock-input cycles and is used as a ripple-carry signal to directly clock a succeeding counter package in a multi-package counting system.


Fig.17.1-Logic diagram.


Fig.17.2-Timing diagram.

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4022AD, CD4022AK, CD4022AF |  |  |  |  |  |  |  |  |  |  |
|  |  |  | Vo | VDD | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ |  |
|  |  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  | 17.9 |
| Quiescent Device Dissipation/Package | PD |  |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (Any Input) <br> For Definition. <br> See Appendix | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | $v$ | 17.10 |
|  |  |  | 1.0 | 10 | 3 | - | -. | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current N.Channel | ${ }^{1} \mathrm{D} N$ | Decoded Outputs | 0.5 | 5 | 0.062 | - | - | 0.05 | 0.15 | - | 0.035 | - | - | mA | - |
|  |  |  | 0.5 | 10 | 0.12 | - | - | 0.1 | 0.3 | - | 0.07 | - | - |  |  |
|  |  | Carry Output | 0.5 | 5 | 0.185 | - | - | 0.15 | 0.5 | - | 0.105 | - | - |  |  |
|  |  |  | 0.5 | 10 | 0.375 | - | - | 0.3 | 1 | - | 0.21 | - | - |  |  |
| P.Channel | ${ }^{1} D^{P}$ | Decoded Outputs | 4.5 | 5 | -0.038 | - | - | -0.03 | -0.075 | - | -0.021 | - | - | mA |  |
|  |  |  | 9.5 | 10 | -0.12 | - | - | $-0.11$ | -0.15 | - | -0.07 | - | - |  |  |
|  |  | $\begin{aligned} & \text { Carry } \\ & \text { Output } \end{aligned}$ | 4.5 | 5 | -0.185 | - | - | -0.15 | -0.4 | - | -0.105 | - | - |  |  |
|  |  |  | 9.5 | 10 | -0.375 | - | - | -0.3 | -0.8 | - | -0.21 | - | - |  |  |
| Input Current | $1 /$ |  |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

- See Appendix


LOAD CAPACITANCE ( $C_{L}$ ) -pF 92C5-17818

Fig. 17.3-Typ. propagation delay time vs. $C_{L}$ for decoded outputs.


Fig.17.4-Typ. propagation delay time vs. $C_{L}$ for carry output.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\left.\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}\right)$
(Recommended DC Supply Voltage ( $\left.V_{D D}-V_{S S}\right)$ 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4022AE |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{0}$ | $V_{\text {DO }}$ |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Volt: | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 17.9 |
|  |  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) For Definition, See Appendix | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 17.10 |
|  |  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | -- |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current N.Channel | ${ }^{1}{ }^{N}$ | Decoded Outputs | 0.5 | 5 | 0.03 | - | - | 0.025 | 0.15 | - | 0.02 | - | - | mA | - |
|  |  |  | 0.5 | 10 | 0.06 | - | - | 0.05 | 0.3 | - | 0.04 | - | - |  |  |
|  |  | $\begin{aligned} & \text { Carry } \\ & \text { Output } \end{aligned}$ | 0.5 | 5 | 0.095 | - | - | 0.08 | 0.5 | - | 0.065 | - | - |  |  |
|  |  |  | 0.5 | 10 | 0.155 | - | - | 0.13 | 1 | - | 0.105 | - | - |  |  |
| P.Channel | ${ }_{1}{ }^{P}$ | Decoded Outputs | 4.5 | 5 | -0.018 | - | - | -0.015 | -0.075 | - | -0.012 | - | - | mA |  |
|  |  |  | 9.5 | 10 | -0.06 | - | - | -0.05 | -0.15 | - | -0.04 | - | - |  |  |
|  |  | CarryOutput | 4.5 | 5 | -0.095 | - | - | -0.08 | -0.4 | - | -0.065 | - | - |  |  |
|  |  |  | 9.5 | 10 | -0.155 | - | - | -0.13 | -0.8 | - | -0.105 | - | - |  |  |
| Input Current | 11 |  |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

- See Appendix


Fig.17.5-Typ. transition time vs. $C_{L}$ for decoded outputs.


Fig.17.6-Typ. transition time vs. $C_{L}$ for carry output.


Fig.17.7- Typical clock frequency
vs. $V_{D D}$.


Measure the leakage current of the device for all switch combinations.

Fig.17.9-Quiescent device current test circuit.


Fig.17.11-Clock line test set-up.


Fig.17.8-Typical dissipation characteristics.


Fig.17.10-Noise immunity test circuit.


Fig.17.12-Clock enable and set-up time test circuit.


Fig. 17.13-Reset propagation delay time and minimum reset pulse duration.

File No. 479

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20$ ns except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \%{ }^{\circ} \mathrm{C}$ (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4022AD,CD4022AKCD4022AF |  |  | CD4022AE |  |  |  |  |
|  |  |  | $\begin{array}{\|l\|} \hline V_{\text {DD }} \\ \text { (Volts) } \\ \hline \end{array}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| CLOCKED OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: Carry-Out Line | ${ }^{\mathrm{t}} \mathrm{PH} \mathrm{L}$. <br> ${ }^{t}$ PLH |  | 5 | - | 325 | 1000 | - | 325 | 1300 | ns | 17.4 |
|  |  |  | 10 | - | 125 | 250 | - | 125 | 500 |  |  |
| Decode Out Lines |  |  | 5 | - | 400 | 1200 | - | 400 | 1600 | ns | 17.3 |
|  |  |  | 10 | - | 200 | 400 | - | 200 | 800 |  |  |
| Transition Time: Carry-Out Line | ${ }^{\mathrm{t}}$ THL, <br> ${ }^{t}$ TLH |  | 5 | - | 85 | 300 | - | 85 | 340 | ns | 17.6 |
|  |  |  | 10 | - | 50 | 100 | - | 50 | 200 |  |  |
| Decode Out Lines |  |  | 5 | - | 300 | 900 | - | 300 | 1200 | ns | 17.5 |
|  |  |  | 10 | - | 125 | 250 | - | 125 | 500 |  |  |
| Minimum Clock Pulse Width | ${ }^{t}$ WL. <br> ${ }^{t}$ WH |  | 5 | - | 250 | 500 | - | 250 | 830 | ns | 17.11 |
|  |  |  | 10 | - | 85 | 170 | - | 85 | 250 |  |  |
| Clock <br> Rise \& Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{r} C L} \\ & \mathrm{t}_{\mathrm{f} C L} \end{aligned}$ |  | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | 17.11 |
|  |  |  | 10 | - | - | 15 | - | - | 15 |  |  |
| Clock Enable Set-Up Time |  |  | 5 | 350 | 175 | - | 700 | 175 | - | ns | 17.12 |
|  |  |  | 10 | 150 | 75 | - | 300 | 75 | - |  |  |
| Maximum Clock Frequency | ${ }^{\mathrm{f}} \mathrm{CL}$ |  | 5 | 1 | 2.5 | - | 0.6 | 2.5 | - | MHz | 17.7 |
|  |  |  | 10 | 3 | 5 | - | 2 | 5 | - |  |  |
| Input Capacitance | $\mathrm{C}_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |
| RESET OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: Carry-Out Line | $\begin{aligned} & \text { tPHL, } \\ & \text { tpLH } \end{aligned}$ |  | 5 | - | 300 | 900 | - | 300 | 1200 | ns | - |
|  |  |  | 10 | - | 125 | 250 | - | 125 | 500 |  |  |
| Decode-Out Line |  |  | 5 | - | 500 | 1250 | - | 500 | 2500 | ns | - |
|  |  |  | 10 | - | 200 | 400 | - | 200 | 800 |  |  |
| Minimum Reset Pulse Width | ${ }^{\text {t }}$ WL. |  | 5 | - | 150 | 300 | - | 150 | 600 | ns | 17.13 |
|  | ${ }^{\text {t Wh }}$ |  | 10 | - | 75 | 150 | - | 75 | 300 |  |  |



## Digital Integrated Circuits

Monolithic Silicon
Solid State Division


## COS/MOS 7-Stage Binary Counter

With Buffered Reset
Special Features:

- Medium speed operation. . . . 7 MHz (typ.) input pulse rate at

$$
V_{D D}-V_{S S}=10 \mathrm{~V}
$$

- Low "high" and "low" level output impedance. . . . . $700 \Omega$ and $500 \Omega$ (typ.), respectively at $V_{D D}-V_{S S}=10 \mathrm{~V}$
- Logic block complexity on a single chip. . . . . . .each output accessible and resettable
- Static counter operation - counter retains state indefinitely with input pulse level "low" or "high"
- COS/MOS gate input loading on both reset and input-pulse lines

The CD4024A types consist of an input pulse shaping circuit, reset line driver circuitry, and seven binary counter stages. The counter is reset to "zero" by a high level on the reset input. Each counter stage is a static master-slave flip-flop. The counter state is advanced one count on the negative-going transition of each input pulse.

## Applications:

- Frequency-dividing circuits
- Time-delay circuits
- Counter control
- D/A counter and switch on one chip

[^3]

Fig. 1-1 - Functional diagram for CD4024AD, AK, AE, AF.


Fig.1-2 - Functional diagram for CD4024AT.


Fig. 1-3 - Schematic diagram (pulse shapel and 1 binary stage).


Fig. 1-4 - Logic block diagram (pulse shaper and 1 binary stage).

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathbf{S S}}$ ) 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC curves \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4024AD, CD4024AK, CD4024AT, CD4024AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min: | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device | ${ }^{\text {L }}$ |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 1-13 |
|  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 25 | - | 1.5. | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage: <br> Low-Level | $\mathrm{VOL}_{\mathrm{O}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{VOH}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $v$ | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | $\checkmark$ | 1-14 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | $-$ | 1.5 | 2.25 | - | 1.5 | - | - | v | 1-15 |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: <br> N -Channel | $\mathrm{I}^{\mathrm{N}}$ | 0.5 | 5 | 0.31 | - | - | 0.25 | 0.5 | - | 0.175 | - | - | mA | $\begin{aligned} & 1-5 \\ & 1-7 \end{aligned}$ |
|  |  | 0.5 | 10 | 0.62 | - | - | 0.5 | 1 | - | 0.35 | - | - |  |  |
| P.Channel | ${ }_{10}{ }^{P}$ | 4.5 | 5 | 0.19 | - | - | -0.15 | -0.3 | - | 0.105 | - | - | mA | $\begin{aligned} & 1-6 \\ & 1-8 \end{aligned}$ |
|  |  | 9.5 | 10 | -0.45 | - | - | -0.35 | -0.7 | - | -0.25 | - | - |  |  |
| Input Current | 1 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig. 1-5 Typ. $N$-channel drain characteristics.


Fig. 1-6 Typ. P-channel drain characteristics.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4024AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $V_{\text {DD }}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 1-13 |
|  |  |  | 10 | - | - | 100 | - | 1 | 100 | - |  | 1400 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 250 | -. | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | . |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) | VNL | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 |  | 1.4 |  |  | V | 1-14 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - |  | V | 1-15 |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N -Channel | IDN | 0.5 | 5 | 0.15 | - | - | 0.12 | 0.5 | - | 0.095 | - | - | mA | $\begin{aligned} & 1-5 \\ & 1-7 \end{aligned}$ |
|  |  | 0.5 | 10 | 0.31 | - | - | 0.25 | 1 | - | 0.2 | - | -- |  |  |
| P-Channel | $I^{\prime}{ }^{P}$ | 4.5 | 5 | -0.145 | - | - | -0.12 | -0.3 | - | -0.095 | - | - | mA | $\begin{aligned} & 1-6 \\ & 1-8 \end{aligned}$ |
|  |  | 9.5 | 10 | -0.31 | - | - | -0.25 | -0.7 | - | -0.2 | - | - |  |  |
| Input Current | $I_{1}$ |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig.1-7 Min. N-channel drain characteristics.


92Cs-19079

Fig. 1,-8-Min. P-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} C, V_{S S}=O V, C_{L}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$, except $t_{r} \phi$ and $t_{f} \phi$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3 \%}{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4024AD, CD4024AK CD4024AT, CD4024AF |  |  | CD4024AE |  |  |  |  |
|  |  | (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| $\phi$ INPUT OPERATION |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time* | ${ }^{\text {P }}{ }^{\text {PHL }}$, | 5 | - | 175 | 350 | - | 175 | 400 | ns | 1-9 |
|  | ${ }^{\text {P }}$ PLH | 10 | - | 80 | 150 | - | 80 | 150 |  |  |
| Transition Time | ${ }^{\text {t }}$ THL. | 5 | - | 175 | 225 | - | 175 | 250 | ns | 1-10 |
|  | ${ }^{\text {t }}$ tLH | 10 | - | 80 | 150 | - | 80 | 150 |  |  |
| Minimum InputPulse Width | ${ }^{\text {t }}$ WL. | 5 | - | 200 | 330 | - | 200 | 500 | ns | - |
|  | ${ }^{\text {t WH }}$ | 10 | - | 140 | 125 | - | 140 | 165 |  |  |
| Input Pulse Rise \& Fall Time | $\mathrm{tr}^{\text {¢ }}$ | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  | ${ }_{t f}{ }^{\phi}$ | 10 | - | - | 10. | - | - | 10 |  |  |
| Maximum Input Pulse Frequency | ${ }_{\dagger} \phi$ | 5 | 1.5 | 2.5 | - | 1 | 2.5 | - | MHz | 1-12 |
|  |  | 10 | 4 | 7 | - | 3 | 7 | - |  |  |
| Input Capacitance | $C_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF | - |
| RESET OPERATION |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time | ${ }^{\text {P PHL }}$ (R) | 5 | - | 500 | 700 | - | 500 | 800 | ns | - |
|  |  | 10 | - | 250 | 350 | - | 250 | 400 |  |  |
| Minimum Reset Pulse Width | ${ }^{\text {t }}$ WH(R) | 5 | - | 375 | 500 | - | 375 | 600 | ns | - |
|  |  | 10 | - | 200 | 300 | - | 200 | 350 |  |  |

*Propagation delay time is from clock input to $\mathrm{Q}_{1}$ output.


Fig. 1-9 Typ. propagation delay time vs. $C_{L}$.


Fig. 1-10 Typ. transition time vs. $C_{L}$.


Fig. 1-11 Typ. dissipation characteristics.


Fig. 1-12 Typ. input pulse frequency vs. VDD.


Fig.1-13 Quiescent device current test circuit.


92CS-17897
Fig.1-14 Noise Immunity test circuit.


Fig. 1-15 Reset noise immunity test circuit.


# COS/MOS Decade Counters/Dividers 

With Decoded 7-Segment Display Outputs and: Display Enable - CD 4026AD, AE, AF, AK Ripple Blanking - CD4033AD, AE, AF, AK

## Special Features:

- Counter and 7 -segment decoding in one package
- Ideal for low-power displays
- Easily interfaced with 7 -segment display types
- Fully static counter operation: DC to 2.5 MHz (typ.)
- Display Enable Output (CD4026A)
- "Ripple Blanking" and Lamp Test (CD4033A)

RCA CD4026A and CD4033A ${ }^{4}$ each consists of a 5 -stage Johnson decade counter and an output decoder which converts the Johnson code to a 7 -segment decoded output for driving each stage in a numerical display.
These devices are particularly advantageous in display applications where low power dissipation and/or low package count are important.
Inputs common to both types are Clock, Reset, \& Clock Enable; common outputs are Carry Out and the seven decoded outputs (a, b, c, d, e, f, g). Additional inputs and outputs for the CD4026A include Display Enable input and Display Enable and Ungated "C-segment" outputs. Signals peculiar to the CD4033 are Ripple-Blanking and Lamp Test inputs and a Ripple-Blanking Output.
A 'high" Reset signal clears the decade counter to its zero count. The counter is advanced one count at the positive clock signal transistion if the Clock Enable signal is "low". Counter advancement via the clock line is inhibited when the Clock Enable signal is "high". Antilock gating is provided on the Johnson counter, thus assuring proper counting sequence. The Carry-Out ( $\mathrm{C}_{\text {out }}$ ) signal completes one cycle every ten clock input cycles and is used to directly clock the succeeding decade in a multi-decade counting chain.
The seven decoded outputs ( $a, b, c, d, e, f, g$ ) illuminate the proper segments in a seven segment display device used for representing the decimal number 0 to 9 . The 7 -segment outputs go "high" on selection in the CD4033A; in the CD4026A these outputs go "high" only when the Display Enable IN is "high".

[^4]
## Applications:



■ Decade counting/7-segment decimal display

- Frequency division/7-segment decimal displays
- Clock/watches/timers (e.g. $\div \mathbf{6 0}, \div \mathbf{6 0}, \div \mathbf{1 2}$ counter/display)
- Counter/display driver for meter applications


## CD4026A

When the Display Enable IN is'"low"the seven decoded outputs are forced "low" regardless of the state of the counter. Activation of the display only when required results in significant power savings. This system also facilitates implementation of display-character multiplexing.

The Carry Out and ungated "C-segment" signals are not gated by the Display Enable and therefore are available continuously. This feature is a requirement in implementation of certain divider functions such as divide-by-60 and divide-by-12.

## CD4033A

The CD4033A has provisions for automatic blanking of the non-significant zeros in a multi-digit decimal number which results in an easily readable display. consistent with normal writing practice. For example, the number 0050.07000 in an eight digit display would be displayed as 50.07 . Zero suppression on the integer side is obtained by connecting the RBI terminal of the CD4033A associated with the most significant digit in the display to a "low-level" voltage and connecting the RBO terminal of that stage to the RBI terminal of the CD4033A in the next-lower significant


Fig.2-1 CD4026A logic diagram.
position in the display. This procedure is continued for each succeeding CD4033A on the integer side of the displav
'On the fraction side of the display the RBI of the CD4033A associated with the least significent bit is connected to a "low level" voltage and the RBO of that CD4033A is connected to the RBI terminal of the CD4033A in the next more-significant-bit position. Again, this procedure is continued for all CD4033A's on the fraction side of the display.

In a purely fractional number the zero immediately preceding the decimal point can be displayed by connecting the RBI of that stage to a "high level" voltage (instead of to the RBO of the next more-significant-stage). For Example: optional zero $\rightarrow 0.7346$.

Likewise, the zero in a number such as 763.0 can be displayed by connecting the RBI of the CD4033A associated with it to a "high-level" voltage.
Ripple blanking of non-significant zeros provides an appreciable savings in display power.

The CD4033A has a "Lamp Test" input which, when connected to a "high-level" voltage, overrides normal decoder operation and enables a check to be made on possible display malfunctions by putting the seven outputs in the "high" state.


Fig.2-2 - CD4026A timing diagram.

For maximum ratings, see page 22.


Fig.2-3 CD4033A logic diagram.


Fig.2-4 CD4033A timing diagram.


Fig.2-5 Min. \& typ. P-channel segment drain characteristics @ $V_{D D}=3.5 \& 5 \mathrm{~V}$.


Fig.2-7 Typ. P-channel drain characteristics as a function of temp.


Fig.2-9 Typ. propagation delay time vs. $c_{L}$ for carry outputs.


Fig.2-6 Min. \& typ. P-channel segment drain characteristics @ $V_{D D}=10 \& 15 \mathrm{~V}$.


Fig.2-8 Typ. propagation delay time vs. $c_{L}$ for decoded outputs.


Fig.2-10 Typ. transition time vs. $C_{L}$ for decoded outputs.

STATIC ELECTRICAL CHARACTERISTICS (All inputs $\mathrm{V}_{\mathrm{Ss}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathbf{V}_{\mathrm{DD}}-\mathbf{V}_{\mathbf{S S}}$ ) 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC- <br> TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4026AD, CD4026AK ,CD4026AF CD4033AD, CD4033AK, CD4033AF |  |  |  |  |  |  |  |  |  |  |
|  |  | Vo Volts |  | VDD <br> Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{\text {IL }}$ |  |  |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 2-14 |
|  |  |  |  | 10 | - | - | 10 | - | 0.5 | 10. | - | - | 600 |  |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ |  |  |
|  |  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |  |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |  |
| Noise Immunity (All Inputs) | $V_{\text {NL }}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | $2 \cdot 15$ |  |
|  |  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |  |
| Output Drive Current: <br> N-Channel | ${ }^{1} \mathrm{D}^{N}$ | Decoded Outputs | 0.5 | 5 | 0.15 | - | - | 0.12 | 0.24 | - | 0.09 | - | - | mA |  |  |
|  |  |  | 0.5 | 10 | 0.32 | - | - | 0.25 | 0.5 | - | 0.18 | - | - |  |  |  |
|  |  | Carry Output | 0.5 | 5 | 0.12 | - | - | 0.15 | 0.4 | - | 0.1 | - | - |  |  |  |
|  |  |  | 0.5 | 10 | 0.45 | - | - | 0.35 | 1 | - | 0.25 | - | - |  |  |  |
| P-Channel | ${ }_{1}{ }^{P}$ | Decoded Outputs | 4.5 | 5 | -0.21 | - | - | -0.14 | -0.28 | - | -0.1 | - | - | mA | $\begin{aligned} & 2-5, \\ & 2-6,2-7 \end{aligned}$ |  |
|  |  |  | 9.5 | - 10 | -0.45. | - | - | -0.3 | -0.6 | - | -0.22 | - | - |  |  |  |
|  |  | Carry Output | 4.5 | 5 | -0.12 | - | - | -0.15 | -0.4 | - | -0.1 | - | - |  | - |  |
|  |  |  | 9.5 | 10 | -0.45 | - | - | -0.35 | -1 | - | -0.25 | - | - |  |  |  |
| Input Current | $1 /$ | Any Input |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |  |

For Output Drive Current test connections see Appendix.


Fig.2-11 Typ. transition time vs. $C_{L}$ for carry output.


Fig.2-12 Max. input clock frequency vs. VDD.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage (VDD $-\mathrm{V}_{\mathrm{SS}}$ ). . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. <br> TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4026AE, CD4033AE |  |  |  |  |  |  |  |  |  |  |
|  |  |  | Vo | $\mathrm{V}_{\mathrm{DD}}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | $2 \cdot 14$ |
|  |  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | PD |  |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ |  |
|  |  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 2.15 |
|  |  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }^{1} \mathrm{D}^{N}$ | Decoded Outputs | 0.5 | 5 | 0.08 | - | - | 0.06 | 0.24 | - | 0.05 | - | - | mA |  |
|  |  |  | 0.5 | 10 | 0.15 | - | - | 0.12 | 0.5 | - | 0.1 | - | - |  |  |
|  |  | Carry Output | 0.5 | 5 | 0.095 | - | - | 0.08 | 0.4 | - | 0.06 | - | - |  |  |
|  |  |  | 0.5 | 10 | 0.3 | - | - | 0.25 | 1 | - | 0.2 | - | - |  |  |
| P.Channel | ${ }_{1}{ }^{P}$ | Decoded Outputs | 4.5 | 5 | -0.09 | - | - | -0.07 | -0.28 | - | -0.06 | - | - | mA | $\begin{aligned} & 2 \cdot 5, \\ & 2 \cdot 6,2 \cdot 7 \end{aligned}$ |
|  |  |  | 9.5 | 10 | -0.2 | - | - | -0.15 | -0.6 | - | -0.13 | - | - |  |  |
|  |  | Carry Output | 4.5 | 5 | -0.095 | - | - | -0.08 | -0.4 | - | -0.06 | - | - |  | - |
|  |  |  | 9.5 | 10 | -0.3 | - | - | -0.24 | -1 | - | -0.2 | - | - |  |  |
| Input Current | $I_{1}$ | Any Input |  |  | - | - | - | - | 10 | - | - | - | - | pA |  |

For Output Drive Current test connections see Appendix.


DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathbf{S S}}=\mathbf{O V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input riea and fall times $=20 \mathrm{~ns}$, except $\boldsymbol{t}_{\mathbf{r}} C L$ and $\mathbf{t}_{\mathbf{f}} C L$
Typical Temperature Coefficient for all values of $V_{D D}=0.3 \%{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4026AD, AF, AK CD4033AD, AF, AK |  |  | $\begin{aligned} & \text { CD4026AE } \\ & \text { CD4033AE } \end{aligned}$ |  |  |  |  |
|  |  |  | (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| CLOCKED OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: Carry Out Line | ${ }^{t} \mathrm{PHL}$. <br> ${ }^{\text {t }}$ PLH |  | 5 | - | 350 | 1000 | - | 350 | 1300 | ns | 2.9 |
|  |  |  | 10 | - | 125 | 250 | - | 125 | 300 |  |  |
| Decode Out Lines |  | - | 5 | - | 600 | 1700 | - | 600 | 2200 | ns | 2.8 |
|  |  |  | 10 | - | 250 | 500 | - | 250 | 700 |  |  |
| Transition Time: | ${ }^{t}$ THL' <br> ${ }^{t}$ TLH |  | 5 | - | 100 | 300 | - | 100 | 350 | ns | $2 \cdot 11$ |
| Carry Out Line |  |  | 10 | - | 50 | 150 | - | 50 | 200 |  |  |
| Decode Out Lines |  |  | 5 | - | 300 | 900 | - | 300 | 1200 | ns | $2-10$ |
|  |  |  | 10 | - | 125 | 350 | - | 125 | 450 |  |  |
| Minimum Clock Pulse Width | ${ }^{t}$ WL. <br> ${ }^{t}$ WH |  | 5 | - | 200 | 330 | - | 200 | 500 | ns | - |
|  |  |  | 10 | - | 100 | 170 | - | 100 | 250 |  |  |
| Clock Rise \& Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{rCL}}{ }^{*} \\ & \mathrm{t}_{\mathrm{fCL}} \end{aligned}$ |  | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  |  | 10 | - | - | 15 | - | - | 15 |  |  |
| Clock Enable Set-Up Time |  |  | 5 | - | 175 | 500 | - | 175 | 700 | ns | - |
|  |  |  | 10 | - | 75 | 200 | - | 75 | 300 |  |  |
| Maximum Clock Frequency | ${ }^{\mathrm{f}} \mathrm{CL}$ | Measured with Respect to Carry Out Line | 5 | 1.5 | 2.5 | - | 1 | 2.5 | - | MHz | 2-12 |
|  |  |  | 10 | 3 | 5 | - | 2 | 5 | - |  |  |
| Input Capacitance | C | Any Input |  | - | 5 | - | - | 5 | - | pF | - |
| RESET OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: To Carry Out Line | ${ }^{\text {t PHL }}$ (R) |  | 5 | - | 350 | 1000 | - | 350 | 1300 | ns | - |
|  |  |  | 10 | - | 125 | 250 | - | 125 | 300 |  |  |
| To Decode Out Lines |  |  | 5 | - | 550 | 1400 | - | 550 | 1900 | ns | - |
|  |  |  | 10 | - | 240 | 500 | - | 240 | 600 |  |  |
| Reset Pulse Width | ${ }^{t}$ WH(R) |  | 5 | - | 200 | 330 | - | 200 | 500 | ns | - |
|  |  |  | 10 | - | 100 | 165 | - | 100 | 250 |  |  |
| Reset Removal Time |  |  | 5 | - | 300 | 750 | - | 300 | 1000 | ns | - |
|  |  |  | 10 | - | 100 | 225 | - | 100 | 275 |  |  |



Fig.2-15 - Noise immunity test circuits.

## INTERFACING THE CD4026A AND CD4033A WITH COMMERCIALLY AVAILABLE 7-SEGMENT DISPLAY DEVICES <br> (Refer to Application Note ICAN-6733 for detailed interfacing information)



LOW-POWER INCANDESCENT READOUTS
PINLITES INC- Series 0 and $R$
TUBE REQUIREMENTS: $\quad \mathrm{V}_{\mathrm{T}}(\mathrm{V}) \quad \mathrm{mA} /$ Segment

| $0-03-15$ | 1.5 | 8 |
| :--- | :--- | :--- |
| $0-04-30$ | 3.0 | 8 |
| $0-06-30$ | 3.0 | 8 |
| R-R3-20 | 2.0 | 4.3 |
| R-R4-30 | 3.0 | 4.3 |

ASSUMED
TRANSISTOR CHARACTERISTICS
Bdc (min.) $\geq 30$
$\mathrm{V}_{\mathrm{CE}}($ sat. $) \leq 0.50 \mathrm{~V}$
$\begin{aligned} & @ V_{D D} \geq 3.5 \mathrm{~V}(\mathrm{~min} .) \\ & I_{B} \geq 0.25 \mathrm{~mA}(\mathrm{~min} .) \\ & I_{T} \leq 7.5 \mathrm{~mA}(\mathrm{~min} .)\end{aligned}$

CD4009A
$@ V_{D D}=10 V(\mathrm{~min}).$.
$V_{0}{ }^{\prime \prime} O^{\prime \prime} \leq 0.6 \mathrm{~V}$
$\mathrm{I}_{\mathrm{T}}=8 \mathrm{~mA}(\mathrm{~min}$.
$e^{2} V_{D D}=6 V($ min. $)$ $V_{0}{ }^{\prime \prime} 0^{\prime \prime} \leq 1.0 \mathrm{~V}$
$I_{T}=5 \mathrm{~mA}(\mathrm{~min}$.
$V_{\top} \approx 1.5 \mathrm{~V}$ TO 3.5 V

INCANDESCENT READOUTS
RCA Numitron- DR2000 Series
TUBE REQUIREMENTS:

$$
\begin{aligned}
& \mathrm{V}_{\mathrm{T}}=3.5-5.0 \mathrm{~V} \\
& \mathrm{I}_{\mathrm{T}}=24 \mathrm{~mA}^{\prime} \text { Segment }
\end{aligned}
$$

ASSUMED TRANSISTOR CHARACTERISTICS
$\beta \mathrm{dc}($ min. $) \geq 25$
$\mathrm{V}_{\mathrm{CE}}$ (sat.) $\leq 0.50 \mathrm{~V}$
${ }^{(2} V_{D D}=8 V($ min. $)$
$I_{B}=1.0 \mathrm{~mA}(\mathrm{~min}$.
$I_{\top}=24 \mathrm{~mA}$ (min.)
CD4009A
$@ V_{D D}=10 V(\min$.
$V_{0}{ }^{\prime} \mathrm{O}^{\prime \prime} \leq 2 \mathrm{~V}$
$I_{T}=20 \mathrm{~mA}(\mathrm{~min}$.
$V_{T} \approx 3.5$ V TO 6 V

92CS-19133R2

## NEON READOUTS (NIXIE TUBEA)

1. Alco Electronics- MG19
2. Burroughs- B5971, B7971, B8971

TUBE REQUIREMENTS $\mathrm{V}_{\mathrm{T}}(\mathrm{Vdc}) \mathrm{mA} /$ Segment
Alco MG19 . . . . . . . . . . . 180 . . . . . . 0.5
Burroughs B5971 . . . . . . 170 . . . . . . 3
" B7971, B8971. . . . $170 \ldots . . . .6$


TRANSISTOR CHARACTERISTICS
Leakage with transistor cutoff $\leq 0.05 \mathrm{~mA}$
$V_{(\mathrm{BR})}$ CER $\cdots>\mathrm{V}_{\mathrm{T}}$
$\beta_{\mathrm{dc}}{ }^{(\min )} \geq 30$
$\Delta$ (Trademark) Burroughs Corp.

LOW-VOLTAGE VACUUM FLUORESCENT READOUTS


1. Tung-Sol DIGIVAC S/ ${ }^{\ddagger}$-Type DT1704A or DT1705C
2. Nippon Electric (NEC)-Type DG12E or LD915

TUBE REQUREMENTS: 100 to $300 \mu \mathrm{~A} /$ segment at tube voltages of 12 V to 25 V depending on required brightness. Filament requirement 45 mA at $1.6 \mathrm{~V}, \mathrm{AC}$ or DC .

INTERFACING THE CD4026A AND CD4033A WITH COMMERCIALLY AVAILABLE 7-SEGMENT DISPLAY DEVICES

## LIGHT EMITTING DIODE DISPLAYS




Solid State Division

## Digital Integrated Circuits

Monolithic Silicon

## CD4027AD, CD4027AE, CD4027AK



## COS/MOS Dual J-K <br> 

With Set/Reset Capability

## Special Features:

- Static flip-flop operation. . . . . . .retains state indefinitely with clock level either "high" or "low"
- Medium speed operation.
.8 MHz (typ.) clock toggle rate at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
- Low "high"-and "low" output impedance. . . . . . $700 \Omega$ and $300 \Omega$,

Applications:
respectively, at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{S S}=10 \mathrm{~V}$

- Registers, counters, control circuits

RCA CD4027A $\triangle$ is a single monolithic chip integrated circuit containing two identical complementary-symmetry "J-K" master-slave flip-flops. Each flip-flop has provisions for individual "J", "K", "Set", "Reset", and "Clock" input signals. Buffered " Q " and " $\overline{\mathrm{Q}}$ " signals are provided as outputs. This input-output arrangement provides for compatible operation with the RCA CD4013A dual "D"-type flip-flop.

The CD4027A is useful in performing control, register, and toggle functions. Logic levels present at the " $J$ " and " $K$ " inputs along with internal self-steering control the state of each flip-flop; changes in the flip-flop state are synchronous with the positive-going transition of the "clock" pulse. Set and reset functions are independent of the clock and are initiated when a "high" level signal is present at either the "Set" or "Reset" input.

A Formerly developmental type TA5872.


STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathrm{I}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4027AD, CD4027AK |  |  |  |  |  |  |  |  |  |
|  |  | $v_{0}$ | $V_{\text {DD }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| Quiescent Device Current | ${ }^{1} \mathrm{~L}$ |  | 5 | - | - | 1 | - | 0.005 | 1 | - | - | 60 | $\mu \mathrm{A}$ |
|  |  |  | 10 | - | - | 2 | - | 0.005 | 2 | - | - | 120 |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 5 | - | 0.025 | 5 | - | - | 300 | $\mu \mathrm{W}$ |
|  |  |  | 10 | - | - | 20 | - | 0.05 | 20 | - | - | 1200 |  |
| Output Voltage: Low. Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |
| Noise Immunity (Any Input) | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 |  | 1.4 | - | -- | V |
|  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |
|  | $\mathrm{VNH}^{\text {N }}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | v |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |
| Output Drive Current: <br> N.Channel | ${ }^{1} \mathrm{D} N$ | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 5 | 0.63 | - | - | 0.5 | 1 | - | 0.33 | - | - | mA |
|  |  | $V_{0}=0.5 \mathrm{~V}$ | 10 | 1.25 | - | - | 1 | 2.5 | - | 0.7 | - | - |  |
| P-Channel | ${ }_{1} D^{P}$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | $-0.31$ | - | - | -0.25 | -0.5 | - | -0.175 | - | - | mA |
|  |  | $\mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 10 | -0.8 | - | - | -0.65 | -1.3 | - | -0.45 | - | - |  |
| Input Current | $I_{1}$ | Any Input |  | - | - | - | - | 10 | - | - | - | - | pA |

For Output Drive Current test connections see Appendix


Fig.3-2 Typ. N-channel drain characteristics.


92CS-17801

Fig.3-3 Typ. P-channel drain characteristics.

File No. 503
STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\left.\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}\right)$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES $\&$ TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4027AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | VDD |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 10 | - | 0.01 | 10 | - | - | 140 | $\mu \mathrm{A}$ | $3 \cdot 12$ |
|  |  |  | 10 | - | - | 20 | - | 0.05 | 20 | - | - | 280 |  |  |
| Quiescent Device Dissipat:on/Package | $P_{\text {D }}$ |  | 5 | - | - | 50 | - | 0.05 | 50 | - | - | 700 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | -- | - | 200 | - | 0.5 | 200 | - | - | 2800 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH | . | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | $3 \cdot 13$ |
|  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }^{1} \mathrm{D} N$ | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 5 | 0.3 | - | - | 0.3 | 1 | - | 0.24 | - | - | mA | $\begin{aligned} & 3-2, \\ & 3-4 \end{aligned}$ |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 0.72 | - | - | 0.6 | 2.5 | - | 0.5 | - | - |  |  |
| P-Channel | ${ }^{1} \mathrm{D} P$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.17 | - | - | -0.14 | -0.5 | - | -0.063 | - | - | mA | $\begin{aligned} & 3-3 \\ & 3-5 \end{aligned}$ |
|  |  | $\mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 10 | -0.4 | - | - | -0.33 | -1.3 | - | -0.27 | - | - |  |  |
| Input Current | 11 | Any Input |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig.3-4 Min. N-channel drain characteristics.


92CS-19092

Fig.3-5 Min. P-channal drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$, exceptt $\mathrm{C}_{\mathrm{r}} \mathrm{CL}$ and $\mathrm{t}_{\mathrm{f}} \mathrm{CL}$.
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3} \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4027AD, CD4027AK |  |  | CD4027AE |  |  |  |  |
|  |  | $V_{D D}$ \|(Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time | ${ }^{1}$ PHL. <br> $t_{\mathrm{pLH}}$ | 5 | - | 150 | 300 | - | 150 | 400 | ns | 3-7 |
|  |  | 10 | - | 75 | 110 | - | 75 | 150 |  |  |
| Transition Time | ${ }^{\mathrm{t}} \mathrm{THL}$ ' <br> ${ }^{t}$ TLH | 5 | - | 75 | 125 | - | 75 | 250 | ns | $3-8$ |
|  |  | 10 | - | 50 | 70 | - | 50 | 140 |  |  |
| Minimum Clock Pulse Width | ${ }^{t}$ WL. <br> ${ }^{t}$ WH | 5 | - | 165 | 330 | - | 165 | 500 | ns | - |
|  |  | 10 | - | 65 | 110 | - | 65 | 165 |  |  |
| Clock Rise \& Fall Time | $\begin{aligned} & { }^{*} \mathrm{t}_{\mathrm{rCL}} \text { ' } \\ & \mathrm{t}_{\mathrm{fCL}} \end{aligned}$ | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  | 10 | - | - | 5 | - | - | 5 |  |  |
| Set-Up Time |  | 5 | - | 70 | 150 | - | 70 | 200 | ns | - |
|  |  | 10 | - | 25 | 50 | - | 25 | 75 |  |  |
| Maximum Clock Frequency (toggle mode) | fCL | 5 | 1.5 | 3 | - | 1 | 3 | - | MHz | $3-9$ |
|  |  | 10 | 4.5 | 8 | - | 3 | 8 | - |  |  |
| Input Capacitance | $C_{1}$ | - | - | 5 | - | - | 5 | - | pF | - |
| SET \& RESET OPERATION |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time | $\begin{aligned} & { }^{\mathrm{t}} \mathrm{PHL}(\mathrm{R}) \\ & { }^{\mathrm{t}} \mathrm{PLH}(\mathrm{~S}) \end{aligned}$ | 5 | - | 175 | 225 | $-$ | 175 | 350 | ns | - |
|  |  | 10 | - | 75 | 110 | - | 75 | 150 |  |  |
| Minimum Set and Reset Pulse Widths | $\begin{aligned} & t_{W H(S)} \\ & t_{W L(R)} \end{aligned}$ | 5 | - | 125 | 200 | - | 125 | 300 | ns | - |
|  |  | 10 | - | 50 | 80 | - | 50 | 120 |  |  |

* If more than one unit is cascaded in a parallel clocked operation, $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ should be made less than or equal to the sum of the fixed propagation delay time at 15 pF and the transition time of the output driving stage for the estimated capacitive load.


Fig.3-6 Typ. propagation delay time vs. $C_{L}$.


Fig.3-7 Typ. transition time vs. $C_{L}$.


Fig.3-8 Schematic diagram for one of two identical J-K flip flops.


Fig.3-9 Max. clock frequency vs. supply voltage.


Fig.3-10 Typ. dissipation characteristics.


Fig.3-11 - Dissipation test circuit.


TEST PERFORMED WITH THE FOLLOWING LOGIC LEVELS PRESENT

| CL | $J$ | $K$ | $\mathbf{S}$ | $\mathbf{R}$ |
| :---: | :---: | :---: | :---: | :---: |
| 0 | 1 | 1 | 0 | 1 |
| 0 | 0 | 0 | 1 | 1 |
| 0 | 0 | 0 | 1 | 0 |
| 1 | 0 | 0 | 1 | 0 |

Fig.3-12 - Quiescent device current test circuit.


Fig.3-13 - Noise-immunity test circuit.
$\qquad$


Solid State Division

Digital Integrated Circuits
Monolithic Silicon
CD4028AD, CD4028AF CD4028AE, CD4028AK


## COS/MOS <br> BGD-tarDecimal Decoder

## Special Features:

- BCD to decimal decoding or binary to octal decoding
- High decoded output drive capability. . . . . 8 mA (typ.) sink or source
- "Positive logic" inputs and outputs. . . . . .decoded outputs go "high" on selection
- Medium speed operation. . . . . . . . tTHL, tTLH = 30 ns (typ.) @
$V_{D D}=10 \mathrm{~V}$
Applications:
- Code conversion
- Indicator-tube decoder
- Address decoding-memory selection control

RCA CD4028AA types are BCD to decimal or binary to octal decoders consisting of pulse shaping circuits on all 4 inputs, decoding-logic gates, and 10 output buffers. A BCD code applied to the four inputs, A to D results in a "high" level at the selected one of 10 decimal decoded outputs. Similarly, a 3 -bit binary code applied to inputs $A$ through $C$ is decoded in

[^5]TABLE I - TRUTH TABLE

| $D$ | $C$ |
| :--- | :--- |
| 0 | 0 |
| 0 | 0 |
| 0 | 0 |
| 0 | 0 |
| 0 | 1 |
| 0 | 1 |
| 0 | 1 |
| 0 | 1 |
| 1 | 0 |
| 1 | 0 |

octal code at output 0 to 7. A "high"-level signal at the D input inhibits octal decoding and causes inputs 0 through 7 to go "low". If unused, the D input must be connected to $V_{\text {SS }}$. High drive capability is provided at all outputs to enhance dc and dynamic performance in high fan-out applications.

All inputs and outputs are protected against electrostatic effects.


Fig.4-1 Logic diagram.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\overline{\mathrm{v}}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{v}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD 4028AD, CD4028AK, CD4028AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\text {DD }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{1} \mathrm{~L}$ |  | 5. | - | - | 5 | - | 0.5 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 4.8 |
|  |  |  | 10 | - | - | 10 | - | 1 | 10 | - | - | 600. |  |  |
| Quiescent Device Dissipation/Package | ${ }^{\text {PD }}$ |  | 5 | - | - | 25 | - | 2.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 100 | - | 10 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low Leve! | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | . | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | . | 9.95 | . | - |  |  |
| Noise Immunity (Any Input) | $V_{N L}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 |  | 1.4 | - | - | V | 4.9 |
|  |  | 1 | 10 | 3.0 | - | - | 3 | 4.5 |  | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 |  | 1.5 | - | - | V |  |
|  |  | 9 | 10 | 2.9 | - | . | 3 | 4.5 |  | 3.0 | - | - |  |  |
| Output Drive Current: <br> N.Channel | ${ }^{1} \mathrm{D} N$ | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 5 | 0.75 | - | - | 0.6 | 1.2 | - | 0.45 | - | - | mA | 4.2 |
|  |  | $\mathrm{v}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 1.5 | - | - | 1.2 | 2.4 | - | 0.9 | - | - |  |  |
| P.Channel | ${ }_{1} D^{P}$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.7 | - | -- | -0.45 | -0.9 | - | -0.32 | - | - | mA | 4.3 |
|  |  | $\mathrm{v}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 10 | -1.4 | - | - | -0.95 | -1.9 | - | -0.65 | - | - |  |  |
| Input Current | 11 | Any Input |  | - | - | - | - | 10 | - | - | - | - | pA |  |

For Output Drive Current test connections see Appendix


Fig.4-2 Typ. N-channel drain characteristics.


Fig.4-3 Typ. P-channel drain characteristics.
(Recommended DC Supply Voitage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES $\&$ TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4028AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $V_{0}$ | $\mathrm{V}_{\text {DD }}$ |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 50 | - | 5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 4.8 |
|  |  |  | 10 | - | - | 100 | - | 10 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $\mathrm{P}_{\mathrm{D}}$ |  | 5 | - | - | 250 | - | 25 | 250 | - | - | 3500 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 1000 | - | 100 | 1000 | -- | - | 14,000 |  |  |
| Output Voltage: Low Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) | $V_{\text {NL }}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 4.9 |
|  |  | 1 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | -- |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | v |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 45 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N.Channel | ${ }_{1}{ }^{N}$ | $\mathrm{v}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 5 | 0.35 | - | - | 0.3 | 1.2 | - | 0.25 | - | - | mA | 4.2 |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 0.7 | - | - | 0.6 | 2.4 | - | 0.5 | - | - |  |  |
| P. Channel | ${ }^{1}{ }^{P}$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.32 | - | - | -0.22 | -0.9 | - | -0.18 | - | - | mA | 4.3 |
|  |  | $\mathrm{v}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 10 | -0.65 | - | - | -0.48 | -1.9 | - | -0.4 | - | - |  |  |
| Input Current | 11 | Any Input |  | - | - | - | - | -10 | - | - | - | - | pA |  |

For Output Drive Current test connections see Appendix.


Fig.4-4 Typ. propagation delay time vs. $C_{L}$.
Fig.4-5 Typ. transition time vs. $C_{L}$.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{S S}=O \mathrm{O}, \mathrm{C}_{\mathbf{1}}=15 \mathrm{pF}$, and all input rise and fall times $=20 \mathrm{~ns}$
Typical Temperature Coefficient for all values of $V_{D D}=0.3 \%{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{aligned} & \text { CD4028AD. } \\ & \text { CD4028 } A F \end{aligned}$ |  |  | CD4028AE |  |  |  |  |
|  |  | (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time | ${ }^{\text {P }}$ PHL . | 5 | - | 250 | 480 | 7. | 250 | 700 | ns | 4-6 |
|  | ${ }^{\text {PLHH }}$ | 10 | - | 100 | 180 | - | 100 | 290 |  |  |
| Transition Time | ${ }^{\text {t }}$ THL, | 5 | - | 60 | 150 | - | 60 | 300 | ns | 4.5 |
|  | ${ }^{\text {t }}$ TH | 10 | - | 30 | 75 | - | 30 | 150 |  |  |
| Input Capacitance | $C_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF | - |



Fig.4-6 Max. propagation delay time vs. VDD.


Fig.4-7 Dissipation vs. input frequency.


Fig.4-9 Noise-immunity test circuit.

## TYPICAL APPLICATIONS



16 OUTPUTS
92CS-17293RI
Fig.4-10 Code conversion circuit.

The circuit shown in Fig.4-10 converts any 4-bit code to a decimal or hexadecimal code. Table 2 shows a number of codes and the decimal or hexadecimal number in these codes which must be applied to the input terminals of the CD4028A to select a particular output. For example: in order to get a "high" on output No. 8 the input must be either an 8 expressed in 4 -Bit Binary code, a 15 expressed in 4-Bit Gray code, or a 5 expressed in Excess-3 code.

TABLE 2 - CODE CONVERSION CHART.

| INPUTS |  |  |  | InPUT CODES |  |  |  |  |  | OUTPUT NUMBER |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | xcimal |  | Deci |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| 0 | C | 8 |  |  |  |  | 0 |  |  | 1 | 2 | 3 | 4 |  | 5 | 6 | 8 | 910 |  | 11 | 12 | 1314 |  | 15 |
| 0 | 0 | 0 | 0 | 0 | 0 |  |  |  | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | - | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 0 | 1 | 1 | 1 |  |  | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 0 | 2 | 3 |  | 0 | 2 | 2 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 1 | 3 | 2 | 0 | 3 | 3 |  | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 0 | 0 | 4 | 7 | 1 | 4 | 4 |  | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 0 | 1 | 5 | 6 | 2 |  |  | 3 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 1 | 0 | 6 | 4 | 3 | 1 |  | 4 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 1 | 1 | 7 | [ 5 | 4 | 2 |  |  | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 8 | 15 | 5 |  |  |  | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 1 | 9 | 14 | 6 |  |  | 5 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | - | , | 0 | 0 | 0 |
| 1 | 0 | 1 | 0 | 10 | 12 | 7 | 9 |  | 6 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 1 | 1 | 11 | 13 | 8 |  | 5 |  | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 |
| 1 | 1 | 0 | 0 | 12 | 8 | 9 | 5 | 6 |  | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 |
| 1 | 1 | 0 | 1 | 13 | 9 |  | 6 | 7 | 7 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 |
| 1 | 1 | 1 | 0 | 14 | 11 |  | 8 | 8 | 8 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | - | 0 | 0 | 0 | 1 | 0 |
| 1 | 1 | 1 | 1 | 15 | 10 |  | 7 | 9 | 9 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |



Fig.4-11 6-bit binary to 1 of 64 address decoder.


TRANSISTOR CHARACTERISTICS:
Leakage with transistor cutoff $\leq 0.05 \mathrm{~mA}$
$V_{\text {(BR)CEO }} \ldots 270 \mathrm{~V}$
$\Delta$ (Trademark) Burrough Corp.
92CS-17295R1


# COS/MOS Presettable Up/Down Counter <br> Binary or BCD-Decade 

Special Features:

- Medium speed operation. .. 5 MHz (typ.) @ $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ and $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
- Multi-package parallel clocking for synchronous high speed output response or ripple clocking for slow clock input rise and fall times
- "Preset Enable" and individual "Jam" inputs provided
- Binary or decade up/down counting
- BCD outputs in decade mode

Applications:
E Programmable binary and decade counting/frequency synthesizers-BCD output

- Analog to digital and digital to analog conversion
- Up/Down binary counting
- Up/Down decade counting
- Magnitude and sign generation
- Difference counting

RCA CD4029A4 types consist of a four-stage binary or BCD-decade up/down counter with provisions for "lookahead" carry in both counting modes. The inputs consist of a single Clock, Carry-in (Clock Enable), Binary/Decade, Up/ Down, Preset Enable, and four individual Jam signals. Four separate buffered Q signals and a Carry Out signal are provided as outputs.
A "high" preset Enable signal allows information on the Jam inputs to preset the counter to any state asynchronously with the clock. A "low" on each Jam line, when the Preset-Enable signal is "high", resets the counter to its zero count. The counter is advanced one count at the positive transition of the clock when the Carry-In and Preset Enable signals are "low". Advancement is inhibited when the Carry-In or Preset Enable signals are "high". The carry-out signal is normally "high" and goes "low" when the counter
reaches its maximum count in the " $U$ " " mode or the minimum count in the "Down" mode provided the Carry-In signal is "low". The Carry-In signal in the "low" state can thus be considered a "Clock Enable". The carry-in terminal must be connected to $V_{\text {SS }}$ when not in use.
Binary counting is accomplished when the Binary/Decade input is "high"; the counter counts in the Decade mode when the Binary/Decade input is "low". The counter counts "Up" when the Up/Down input is "high", and "Down" when the Up/Down input is "low". Multiple packages can be connected in either a parallel-clocking or a ripple-clocking arrangement as shown in Fig. 5-12. Parallel clocking provides synchronous control and hence faster reponse from all counting outputs. Ripple-clocking allows for longer clock input rise and fall times.
^Formerly developmental type TA5925.


## Truth Tables

TRUTH TABLE FOR F-F No.I

NC-NO CHANGE TE-TOGGLE ENABLE $X$-DON'T CARE

| CONTROL <br> INPUT | LOGIC <br> LEVEL | ACTION |
| :---: | :---: | :--- |
| BIN/DEC. <br> (B/D) | 1 | BINARY COUNT <br> DECADE COUNT |
| UP/DOWN <br> (U/D) | 1 | UP COUNT <br> DOWN COUNT |
| PRESET ENABLE |  |  |
| (PE) |  |  |



Fig.5-2 - Timing diagram-binary mode.
$92 \mathrm{CM}-17192$


Fig.5-3 - Timing diagram-decade mode.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4029AD, CD4029AK |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ |  | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | $5 \cdot 10$ |
|  |  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\text {OL }}$ |  |  | 5 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 |  |  |
| High-Level | V OH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | $5-11$ |
|  |  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N -Channel | ${ }_{1}{ }^{N}$ | Outputs | 0.5 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.28 | - | - | mA | - |
|  |  |  | 0.5 | 10 | 0.74 | - | - | 0.6 | 1.2 | - | 0.42 | - | - |  |  |
|  |  | Carry Output | 0.5 | 5 | 0.1 | - | - | 0.08 | 0.16 | - | 0.06 | - | - |  | - |
|  |  |  | 0.5 | 10 | 0.4 | - | - | 0.32 | 0.64 | - | 0.22 | - | - |  |  |
| P.Channel | ${ }^{1} \mathrm{D}$ P | Q Outputs | 4.5 | 5 | -0.18 | - | - | -0.12 | -0.24 | - | -0.08 | - | - | mA | - |
|  |  |  | 9.5 | 10 | -0.3 | - | - | -0.2 | -0.4 | - | -0.14 | - | - |  |  |
|  |  | Carry Output | 4.5 | 5 | -0.09 | - | - | -0.06 | -0.12 | - | -0.04 | - | - |  | - |
|  |  |  | 9.5 | 10 | -0.15 | - | - | -0.1 | -0.2 | - | -0.07 | - | - |  |  |
| Input Current | $I_{1}$ | Any Input |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig.5-4 Typ. propagation delay time vs. $C_{L}$ for Q outputs.


Fig.5-5 Typ. propagation delay time vs. $C_{L}$ for carry output.

File No. 503
STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4029AE |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $v_{0}$ | VDD |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 5-10 |
|  |  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (Any Input) | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 5.11 |
|  |  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }_{1}{ }^{N}$ | Q <br> Outputs | 0.5 | 5 | 0.24 | - | - | 0.2 | 0.8 | - | 0.16 | - | - | mA | - |
|  |  |  | 0.5 | 10 | C. 36 | - | - | 0.3 | 1.2 | - | 0.24 | - | - |  |  |
|  |  | Carry Output | 0.5 | 5 | 0.05 | - | - | 0.04 | 0.16 | - | 0.03 | - | - |  | - |
|  |  |  | 0.5 | 10 | 0.19 | - | -- | 0.16 | 0.64 | - | 0.13 | - | - |  |  |
| P-Channel | ${ }^{1} D^{P}$ | Q Outputs | 4.5 | 5 | -0.07 | - | - | -0.06 | -0.24 | - | -0.05 | - | - | mA | - |
|  |  |  | 9.5 | 10 | -0.14 | - | - | -0.1 | -0.4 | - | -0.08 | - | - |  |  |
|  |  | Carry Output | 4.5 | 5 | -0.04 | - | - | -0.03 | -0.12 | - | -0.02 | - | - |  | - |
|  |  |  | 9.5 | 10 | -0.07 | - | - | -0.05 | -0.2 | - | -0.04 | - | - |  |  |
| Input Current | $1_{1}$ | Any Input |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig.5-6 Typ. transition time vs. $C_{L}$ for Q outputs.


Fig.5-7 Typ. transition time vs. $C_{L}$ for carry output.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, V_{S S}=O V, C_{L}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$, except $\mathrm{t}_{\mathbf{r}} \mathrm{CL}$ and $\mathrm{t}_{\mathbf{f}} \mathrm{CL}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3} \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4029AD, CD4029AK |  |  | CD4029AE |  |  |  |  |
|  |  |  | VDD (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| CLOCKED OPERATION |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: Q Outputs | ${ }^{t}{ }^{\text {PHL }}$. <br> ${ }^{\mathrm{t}} \mathrm{PLH}$ |  | 5 | - | 325 | 650 | - | 325 | 1300 |  |  |
|  |  |  | 10 | - | 115 | 230 | - | 115 | 460 | ns | 5.4 |
| Carry Output |  |  | 5 | - | 425 | 850 | - | 425 | 1700 | ns | 5.5 |
|  |  |  | 10 | - | 150 | 300 | - | 150 | 600 |  |  |
| Transition Time: Q Outputs | ${ }^{\mathrm{t}} \mathrm{THL}$. <br> ${ }^{t}$ TLH |  | 5 | - | 100 | 200 | - | 100 | 400 |  | 5.6 |
|  |  |  | 10 | - | 50 | 100 | - | 50 | 200 |  |  |
| Carry Output |  |  | 5 | - | 200 | 400 | - | 200 | 800 | ns | 5.7 |
|  |  |  | 10 | - | 100 | 200 | - | 100 | 400 |  |  |
| Minimum Clock Pulse Width | ${ }^{t}$ WL. <br> ${ }^{t}$ WH |  | 5 | - | 200 | 340 | - | 200 | 500 | ns | - |
|  |  |  | 10 | - | 100 | 170 | - | 100 | 250 |  |  |
| Clock Rise \& Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{r}} \mathrm{CL}, * * * \\ & \mathrm{t}_{\mathrm{f}} \mathrm{CL} \end{aligned}$ |  | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  |  | 10 | - | - | 15 | - | - | 15 |  |  |
| Set-Up Times* | $\begin{array}{\|l} \mathrm{t}_{\mathrm{t}} \mathrm{SH}, \\ \mathrm{t}^{\mathrm{SLLH}} \end{array}$ |  | 5 | - | 325 | 650 | - | 325 | 1300 | ns | - |
|  |  |  | 10 | - | 115 | 230 | - | 115 | 460 |  |  |
| Maximum Clock Frequency | ${ }^{\text {f }} \mathrm{CL}$ |  | 5 | 1.5 | 2.5 | - | 1 | 2.5 | - | MHz | $5-8$ |
|  |  |  | 10 | 3 | 5 | - | 2 | 5 | - |  |  |
| Input Capacitance | $\mathrm{C}_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |
| PRESET ENABLE |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: O Outputs | ${ }^{\mathrm{t}}{ }^{\mathrm{PHL}}$. <br> ${ }^{\text {t PLH }}$ |  | 5 | - | 325 | 650 | - | 325 | 1300 | ns | - |
|  |  |  | 10 | - | 115 | 230 | - | 115 | 460 |  |  |
| Carry Output |  |  | 5 | - | 425 | 850 | - | 425 | 1700 | ns | - |
|  |  |  | 10 | - | 150 | 300 | - | 150 | 600 |  |  |
| Minimum Preset Enable Pulse Width | ${ }^{\text {t }}$ WH |  | 5 | - | 115 | 330 | - | 115 | 660 | ns | - |
|  |  |  | 10 | - | 80 | 160 | - | 80 | 320 |  |  |
| Minimum Preset Enable Removal Time | ${ }^{\text {t }}$ removal |  | 5 | - | 325 | 650 | - | 325 | 1300 | ns | - |
|  |  |  | 10 | - | 115 | 230 | - | 115 | 460 |  |  |
| CARRY INPUT |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: Carry Output | ${ }^{\text {t }}$ PHL. |  | 5 | - | 175 | 350 | - | 175 | 700 | ns | - |
|  |  |  | 10 | - | 50 | 100 | - | 50 | 200 |  |  |

*From Up/Down, Binary/Decade or Carry Input Control Inputs to Clock Input.
** If more than one unit is cascaded in the parallel clocked application, $\mathrm{t}_{\mathbf{r}} \mathrm{CL}$ should be made less than or equal to the sum of the fixed propagation delay at 15 pF and the transition time of the carry output driving stage for the estimated capacitive load.

File No. 503


Fig.5-8 Max. clock frequency vs. $V_{D D}$.


Fig.5-10 Quiescent device current test circuit.


Fig.5-9 Typ. dissipation characteristics.


Fig.5-11 Noise-immunity test circuit.


Fig.5-12 Cascading counter packages.

The CD4029A "Clock" and "Up/Down" inputs are used directly in most applications. In applications where "Clock Up" and "Clock Down" inputs are provided, conversion to the CD4029A "Clock" and "Up/Down" inputs can easily be realized by use of the circuit shown below.

CD4029A changes count on positive transitions of "Clock Up" or "Clock Down" inputs. For the gate configuration shown below, when counting "up" the "Clock Down' input must be maintained "high" and conversely when counting "down" the "Clock Up" input must be maintained "high".


Fig.5-13 Conversion of "clock up", "clock down" input signals to "clock" and "up/down" input signals.


Solid State Division

Digital Integrated Circuits
Monolithic Silicon
CD4030AD, CD4030AF CD4030AE, CD4030AK


## COS/MOS Quad Exclusive-OR Gate

## (Positive Logic)

## Special Features:

■ Medium speed operation. . . . . . .tPHL $=$ tPLH $=40 \mathrm{~ns}$ (typ.) @ $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ and $V_{D D}-V_{S S}=10 \mathrm{~V}$
. Low output impedance. . . . . . . $500 \Omega$ (typ.) @ $V_{D D}-V_{S S}=10 \mathrm{~V}$

## Applications:

- Even and odd-parity generators and checkers
- Logical comparators
- Adders/subtractors
- General logic functions

RCA CD4030A 4 types each contains four independent Exclusive-OR gates integrated on a single monolithic silicon chip. Each Exclusive-OR gate consists of four N -channel and four P-channel enhancement-type transistors.
All inputs and outputs are protected against electrostatic effects.

4 Formerly developmental type TA5940.
TRUTH TABLE FOR ONE OF FOUR IDENTICAL GATES

| $A$ | $B$ | $J$ |
| :---: | :---: | :---: |
| 0 | 0 | 0 |
| 1 | 0 | 1 |
| 0 | 1 | 1 |
| 1 | 1 | 0 |


" 0 " = LOW LEVEL
Fig.6-1 Schematic diagram for 1 of 4 identical exclusive-OR gates.
TYPICAL APPLICATIONS

$92 \mathrm{CS}-17413$
Fig.6-2a Even-parity-bit generator (1-3/4 x CD4030A).


Fig.6-2b Even-parity checker ( $2 \times$ CD4030A).

STATIC ELECTRICAL CHARACTẸRISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) ... 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4030AD, CD4030AK, CD4030AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $V_{0}$ <br> Volts | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{\mathrm{L}} \mathrm{L}$ |  | 5 | - | - | 0.5 | - | 0.005 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | $6-11$ |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 2.5 | - | 0.025 | 2.5 | - | - | 150 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 10 | - | 0.1 | 10 | - | - | 600 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (All Inputs) | $\mathrm{V}_{\text {NL }}$ | 0.95 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 6 -12 |
|  |  | 2.9 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 3.6 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 7.2 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }^{1} \mathrm{D}^{N}$ | 0.5 | 5 | 0.75 | - | - | 0.6 . | 1.2 | - | 0.45 | - | - | mA | 6-3 |
|  |  | 0.5 | 10 | 1.5 | - | - | 1.2 | 2.4 | - | 0.9 | - | - |  |  |
| P.Channel | ${ }^{1} D^{P}$ | 4.5 | 5 | -0.45 | - | - | -0.3 | -0.6 | - | -0.21 | - | - | mA | 6-4 |
|  |  | 9.5 | 10 | -0.95 | - | - | -0.65 | -1.3 | - | -0.45 | - | - |  |  |
| Input Current | $1_{1}$ | $V_{1}=O V$ or $V_{1}=V_{D D}$ |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.

## TYPICAL APPLICATIONS (Cont'd)



Fig.6-2c Odd-parity-bit generator (2 $\times$ CD4030A).


Fig.6-2d Odd-parity checker ( $\times$ CD4030A).

STATIC ELECTRICAL CHARACTERISTICS
All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ )
3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4030AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $V_{0}$ | $V_{\text {DD }}$ |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | 'L |  | 5 | - | - | 5 | - | 0.05 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 6-11 |
|  |  |  | 10 | - | - | 10 | - | 0.1 | 10 | - | - | 140 |  |  |
| Quiescent Device Dissipation/Package | ${ }^{\text {P }}$ |  | 5 | - | - | 25 | - | 0.25 | 25 | - | - | 350 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {L }}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (All Inputs) | $\mathrm{V}_{\mathrm{NL}}$ | 0.95 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 6-12 |
|  |  | 2.9 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | VNH | 3.6 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 7.2 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: | ${ }_{1}{ }^{N}$ | 0.5 | 5 | 0.35 | - | - | 0.3 | 1.2 | - | 0.25 | - | - | mA | 6-3 |
| N-Channel |  | 0.5 | 10 | 0.7 | - | - | 0.6 | 2.4 | - | 0.5 | - | - |  |  |
| P-Channel | ${ }^{1} D^{P}$ | 4.5 | 5 | -0.21 | - | - | -0.15 | -0.6 | - | -0.12 | - | - | mA | 6-4 |
|  |  | 9.5 | 10 | -0.45 | - | - | -0.32 | -1.3 | - | -0.25 | - | - |  |  |
| Input Current | $I_{1}$ | $V_{1}=O V$ or $V_{1}=V_{D D}$ |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig.6-3 Typ. N-channel drain characteristics.


Fig.6-4 Typ. P-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} C, V_{S S}=O V, C_{L}=15 p F$, and all input rise and fall times $=20 \mathrm{~ns}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \%{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4030AD, AK, AF |  |  | CD4030AE |  |  |  |  |
|  |  | (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time | ${ }^{\text {P PHL, }}$ | 5 |  | 100 | 200 |  | 100 | 300 | ns | $\begin{aligned} & 6.7 \\ & 6.9 \end{aligned}$ |
|  | ${ }^{\text {t PLH }}$ | 10 |  | 40 | 100 |  | 40 | 150 |  |  |
| Transition Time: High-to-Low Level | ${ }^{\text {t }}$ THL | 5 |  | 70 | 150 |  | 70 | 300 | ns | 68 |
|  |  | 10 |  | 25 | 75 |  | 25 | 150 |  |  |
| Low-to-High Level | ${ }^{\text {t }}$ TLH | 5 |  | 80 | 150 |  | 80 | 300 | ns |  |
|  |  | 10 |  | 30 | 75 |  | 30 | 150 |  |  |
| Input Capacitance | $c_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF | - |



Fig.6-5 8-bit comparator.

TABLE I - TWO'S COMPLEMENT NUMBERS AND THEIR EQUIVALENT DECIMAL VALUES.

Fig.6-6 8-bit two's complement adder-substractor.


The Two's complement adder - subtractor can add or subtract any two of the numbers in Table I. For example:



Fig.6-7 Typ. propagation delay time vs. $C_{L}$.


Fig.6-9 Max. propagation delay time vs. $V_{D D}$.


Fig.6-11 Quiescent device current test circuit.


Fig.6-8 Typ. transition time vs. $C_{L}$.


Fig.6-10 Dissipation vs. input frequency.


Fig.6-12 Noise-immunity test circuit.


# COS／MOS 64－Stage Static Shift Register 

## Applications：

For use in digital equipment where low－power dissipation， low package count，and／or high noise immunity are primary design requirements．
－Serial shift registers
－Time delay circuits

RCA CD4031A＊is a 64 －stage static shift register in which each stage is a D－type，master－slave flip－flop．
The logic level present at the data input is transferred into the first stage and shifted one stage at each positive－going clock transition．Maximum clock frequencies up to 2 Mega－ hertz can be obtained．Because fully static operation is al－ lowed，information can be permanently stored with the clock line in either the＂low＂or＂high＂state．The CD4031A has a mode control input that，when in the＂high＂state，allows operation in the recirculating mode．Register packages can be cascaded and the clock lines driven directly for high speed operation．Alternatively，a delayed clock output（CLD）is provided that enables cascading register packages while allow－ ing reduced clock drive fan－out and transition－time require－ ments．
Data（ Q ）and $\overline{\text { Data }}(\overline{\mathrm{Q}})$ outputs are provided from the 64th register stage．The Data（ O ）output is capable of driving one TTL or DTL load．
＊Formerly Dev．No．TA5989．

MAXIMUM RATINGS，Absolute Maximum Values：

| Storage－Temperature Range ． Operating－Temperature Range | $-6!$ |
| :---: | :---: |
| Ceramic packages． | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Plastic package | $-40^{\circ} \mathrm{C}$ to＋850${ }^{\circ} \mathrm{C}$ |
| DC Supply Voltage Range（ $\mathrm{V}_{\text {DD }}-\mathrm{V}_{S S}$ ） | -0.5 to +15 V |
| Device Dissipation（per package） | 200 mW |
| All Inputs | $\mathrm{V}_{S S} \leqslant \mathrm{~V}_{1} \leqslant \mathrm{~V}_{\text {DD }}$ |
| Recommended DC Supply |  |
| Voltage Range（ $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathbf{S S}}$ ） | 3 to 15 V |
| Recommended Input Voltage Swing | $\mathrm{V}_{\text {DD }}$ to $\mathrm{V}_{S S}$ |

## Features：

－Fully static operation：DC to $4 \mathrm{MHz} @ \mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
－Operation from a single 3 to 15 V positive or negative power supply
－High noise immunity
－Microwatt quiescent power dissipation： $10 \mu \mathrm{~W}$（typ．）for ceramic packages； $100 \mu \mathrm{~W}$（typ．）for plastic packages
－Full military operating temperature range：$-\mathbf{5 5}{ }^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$（Ceramic Pkg．）
－Single phase clocking requirements
－Protection against electrostatic effects on all inputs
－Data compatible with TTL－DTL
－Recirculation capability
－Two cascading modes：
Direct clocking for high－speed operation
Delayed clocking for reduced clock drive requirements


Fig．1－Functional diagram．


Fig. 2-CD4031A logic diagram and truth tables.


Fig. 3-Cascading using direct clocking for high speed operation (see clock rise \& fall time requirement).


Fig. 4-Cascading using delayed clocking for reduced clock drive requirements.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | CD4031AD, CD4031AK |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\left\|\begin{array}{c} v_{0} \\ V_{o l t} \end{array}\right\|$ |  | $V_{D D}$ <br> Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{L}$ |  |  |  | 5 | - | - | 10 | - | 0.5 | 10 | - | - | 600 | $\mu \mathrm{A}$ | 13 |
|  |  |  |  | 10 | - | - | 25 | - | 1 | 25 | - | - | 1500 |  |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 50 | - | 2.5 | 50 | - | - | 3000 | $\mu \mathrm{N}$ | -- |  |
|  |  |  |  | 10 | - | - | 250 | - | 10 | 250 | - | - | 15000 |  |  |  |
| Output Voltage: Low-Level | $V_{\text {OL }}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | $\cdot$ | - | 0.05 | V | -. |  |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |  |
| Noise Immunity (All Inputs) For Definition See Appendix * | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |  |
|  |  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | v |  |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |  |
| Output Drive Current: <br> N-Channel | $I_{D} \mathrm{~N}$ | 0 | 0.4 | 4.5 | 1.6 | - | - | 1.3 | 2.6 | $\cdots$ | 0.91 | - | - | mA | 5 |  |
|  |  |  | 0.5 | 10 | 5 | 9.6 | - | 4 | 8 | - | 3.2 | 5.6 | - |  |  |  |
|  |  | $\overline{0}$ | 0.5 | 5 | 0.11 | - | . | 0.09 | 0.18 | - | 0.06 | - | - |  |  |  |
|  |  |  | 0.5 | 10 | 0.24 | - | - | 0.2 | 0.4 | - | 0.14 | - | - |  |  |  |
|  |  | $C L_{0}$ | 0.5 | 5 | 0.48 | - | - | 0.4 | 0.8 | - | 0.28 | - | - |  |  |  |
|  |  |  | 0.5 | 10 | 1.5 | - | - | 1.2 | 2.4 | - | 0.84 | - | .- |  |  |  |
| P.Channel | $1 D^{P}$ | 0 | 4.5 | 5 | -0.4 | - | - | -0.32 | -0.64 | - | -0.22 | - | - | mA | 6 |  |
|  |  |  | 9.5 | 10 | -0.85 | - | - | -0.70 | -1.4 | -. | -0.49 | - | - |  |  |  |
|  |  | $\bar{\square}$ | 4.5 | 5 | -0.11 | - | - | -0.09 | -0.18 | - | -0.06 | - | - |  |  |  |
|  |  |  | 9.5 | 10 | -0.24 | - | - | -0.20 | -0.4 | - | -0.14 | - | - |  |  |  |
|  |  |  | 4.5 | 5 | -0.48 | -- | - | -0.40 | -0.8 | - | -0.28 | - | - |  |  |  |
|  |  |  | 9.5 | 10 | -1.0 | - | - | -0.80 | -1.6 | - | -0.56 | - | - |  |  |  |
| Input Current | 1 | Any Input |  |  |  | - | - | - | 10 | - | - | - | - | pA | - |  |

* For " Q " and " $\overline{\mathrm{Q}}$ " outputs use MSI Outputs Limits; for $C L_{D}$ output use Gate Output Limits.


DRAIN-TO-SOURCE VOLTS (V ${ }_{\text {DS }}$ )
Fig. 5-Typical \& minimum N-channel drain characteristics for 0 output.


Fig. 6-Typical P-channel drain characteristics for $Q$ output.

File No. 569

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}$
(Recommended DC Supply Voltage ( $V_{D D}-V_{S S}$ ) . . . . . 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | CD4031AE |  |  |  |  |  |  |  |  | UNITS | CHARACTER ISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{gathered} V_{0} \\ \text { Volts } \end{gathered}$ | $V_{D D}$ <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device <br> Current | $I_{L}$ |  |  | 5 | - | - | 50 | - | 1 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 13 |
|  |  |  |  | 10 | - | - | 100 | $\cdots$ | 2 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $P_{D}$ |  |  | 5 | - | - | 250 | - | 5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | . | - | 1000 | - | 20 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low•Level | $\mathrm{V}_{0 \mathrm{~L}}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | -- | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | -- | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | . |  |  |
| Noise Immunity <br> (All Inputs) <br> For Definition See Appendix | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |
|  |  |  | 1.0 | 10 | 3 | . | . | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $V_{\text {NH }}$ |  | 4.2 | 5 | 1.4 |  |  | 1.5 | 2.25 | - | 1.5 | $\cdots$ | - | V |  |
|  |  |  | 9.0 | 10 | 2.9 | . | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N -Channel | ${ }_{1} \mathrm{~N}$ | 0 | 0.4 | 4.5 | 1.6 | - | - | 1.3 | 2.6 |  | 1.05 | - | - | mA | 5 |
|  |  |  | 0.5 | 10 | 5 | 9.6 | - | 4 | 8 |  | 3.2 | 6.4 | - |  |  |
|  |  | $\overline{0}$ | 0.5 | 5 | 0.05 | - | - | 0.045 | 0.18 |  | 0.037 | - | -- |  |  |
|  |  |  | 0.5 | 10 | 0.12 | - | - | 0.1 | 0.4 |  | 0.08 | - | - |  |  |
|  |  | $\mathrm{CL}_{\mathrm{D}}$ | 0.5 | 5 | 0.24 | - | - | 0.2 | 0.8 |  | 0.16 | - | - |  |  |
|  |  |  | 0.5 | 10 | 0.75 | - | * | 0.6 | 2.4 | . | 0.5 | - | - |  |  |
| P-Channel | ${ }_{10}{ }^{P}$ | 0 | 4.5 | 5 | -0.20 | . | - | -0.16 | -0.64 |  | -0.13 | - | - | mA | 6 |
|  |  |  | 9.5 | 10 | -0.42 | - | - | -0.35 | -1.4 |  | -0.29 | - | - |  |  |
|  |  | - | 4.5 | 5 | -0.05 | - | - | -0.045 | -0.18 |  | -0.037 | - | - |  |  |
|  |  |  | 9.5 | 10 | -0.12 | - | - | -0.10 | -0.4 |  | -0.08 | - | - |  |  |
|  |  | $\mathrm{CL}_{\square}$ | 4.5 | 5 | -0.24 | - | - | -0.20 | -0.8 |  | -0.16 | - | - |  |  |
|  |  |  | 9.5 | 10 | -0.5 | . | - | -0.40 | -1.6 |  | -0.32 | - | - |  |  |
| Input Current | 11 | Any Input |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

* For " Q " and " $\overline{\mathrm{Q}}$ " outputs use MSI Outputs Limits; for $\mathrm{CL}_{\mathrm{D}}$ output use Gate Output Limits.

* LOAD CAPACITANCE OF $\mathrm{Q} \geq 15 \mathrm{pF}$

Fig. 7-Typical propagation delay time vs. $C_{L}$ for data outputs.


Fig. 8-Typical propagation delay vs. $C_{L}$ for delayed clock output.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{S S}=O V, C_{L}=15 \mathrm{pF}$ (unless otherwise specified), and input rise and fall times $=20$ ns, except $t_{r} C L$ and $t_{f} C L$.
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3} \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

"Capacitive loading on $\overline{\mathrm{Q}}$ output affects propagation delay of Q output. These limits apply for $\overline{\mathbf{Q}}$ load $\mathrm{C}_{\mathrm{L}} \leqslant 15 \mathrm{pF}$.

* "If more than one unit is cascaded in the parallel clocked application, $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ should be made less than or equal to the sum of the propagation delay at 15 pF and the transition time of the output driving stage.
***Maximum Clock Frequency for Cascaded Units;
a) Using Delayed Clock Feature $-f_{\max }=\frac{1}{(n-1) C L_{D} \text { prop. delay }+Q \text { prop. delay }+ \text { set-up time }}$ where $n=$ number of packages
b) Not Using Delayed Clock $-\quad f_{\text {max }}=\frac{1}{\text { propagation delay }+ \text { set-up time }}$


NOTE: ${ }^{\text {tTHL }}$ FOR $Q$ OUTPUT IS SIGNIFICANTLY LESS THAN itLH

Fig. 9-Typical transition time vs. $C_{L}$ for data outputs.


Fig. 10-Typical transition time vs. $C_{L}$ for delayed clock output.


Fig. 11-Maximum clock frequency vs. $V_{D D}$.


Fig. 12-Typical power dissipation vs. frequency.

TEST CIRCUITS


WITH S AT GROUND, CLOCK UNIT 64 TIMES BY CONNECTING $S_{2}$ TO PULSE GENERATOR. RETURN $S_{2}$ TO GND AND MEASURE LEAKAGE. CURRENT. REPEAT WITH $S_{1}$ AT $V_{D D}$.

Fig. 13-Quiescent device current.


Fig. 14-Noise immunity.


# COS／MOS Triple Serial Adder 

Positive Logic Adder－CD4032AD，CD4032AE，CD4032AK Negative Logic Adder－CD4038AD，CD4038AE，CD4038AK

## Special Features：

－Invert inputs on all adders for sum complementing applications
－Fully static operation．．．．．．．dc to 5 MHz （typ．）
－Buffered outputs
－Single－phase clocking
－Microwatt quiescent power dissipation．．．．． $5 \mu \mathrm{~W}$（typ．）

RCA CD4032A $\triangle$ and CD4038A types consist of three serial adder circuits with common clock and carry－reset inputs． Each adder has provisions for two serial data input signals and an invert command signal which，when a logical＂ 1 ＂ complements the sum．Data words enter the adder with the least significant bit first；the sign bit trails．The output is the MOD 2 sum of the input bits plus the carry from the previous bit position．The carry is only added at the positive－going clock transition for the CD4032A or at the negative going clock for the CD4038A，thus，for spike free operation the input data transitions should occur as soon as possible after the triggering edge．

The carry is reset to a logical＂ 0 ＇＂at the end of each word by applying a logical＇ 1 ＇signal to a carry－reset input one

Applications：<br>－Serial arithmetic units<br>－Digital correlators<br>－Digital datalink computers<br>－Flight control computers<br>－Digital servo control systems

bit－position before the application of the first bit of the next word Fig．7－2 and $7-4$ shows definitive waveforms for all input and output signals．
－Formerly developmental type TA5963．

For maximum ratings，see page 22.


Fig．7－2 CD4032A timing diagram．

File No. 503
STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathrm{I}} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. <br> TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4032AD, CD4032AK CD4038AD, CD4038AK |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\mathrm{DD}}$ |  | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | $\begin{aligned} & 7-8, \\ & 7-10 \end{aligned}$ |
|  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | $P_{D}$ |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (All Inputs) | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | $\begin{aligned} & 7-9, \\ & 7-11 \end{aligned}$ |
|  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }_{1} \mathrm{~N}$ | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 5 | 0.6 | - | - | 0.5 | 0.9 | - | 0.3 | - | - | mA | - |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 0.75 | - | - | 0.7 | 2.4 | - | 0.6 | - | - |  | - |
| P-Channel | ${ }_{1}{ }^{P}$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.21 | - | - | -0.15 | -0.4 | - | -0.075 | - | - | mA | - |
|  |  | $\mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 10 | -0.7 | - | - | -0.55 | $-1.2$ | - | -0.35 | - | - |  | - |
| Input Current | 11 |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig.7-3 CD4038A logic diagram of one of three serial adders.


Fig.7-4 CD4038A timing diagram.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathbf{S S}}$ )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{aligned} & \text { CD4032AE } \\ & \text { CD4038AE } \end{aligned}$ |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | VDD |  | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | $\begin{aligned} & \hline 7.8, \\ & 7.10 \end{aligned}$ |
|  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | PD |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) | $V_{\text {NL }}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | $\begin{aligned} & 7.9 \\ & 7.11 \end{aligned}$ |
|  |  | 1.0 | 10 | 3.0 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }^{1} \mathrm{D}$ | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 5 | 0.25 | - | - | 0.2 | 0.9 | - | 0.14 | - | - | mA | - |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 0.6 | - | - | 0.5 | 2.4 | - | 0.4 | - | - |  | - |
| P.Channel | ${ }_{1}{ }^{P}$ | $\mathrm{v}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.14 | - | - | -0.1 | -0.4 | - | -0.095 | - | - | mA | - |
|  |  | $\mathrm{v}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 10 | -0.3 | - | - | -0.27 | $-1.2$ | - | -0.22 | - | - |  | - |
| Input Current | $1 /$ |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

For Output Drive Current test connections see Appendix.


Fig.7-5 Typ. propagation delay time vs. $C_{L}$
for $A, B$, or invert inputs to sum outputs.


Fig.7-6 Typ. transition time vs. $C_{L}$ for sum outputs.

File No. 503
DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{SS}}=\mathrm{OV}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$, except
Typical Temperature Coefficient for all values of $V_{D D}=0.3 \%{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms) $\mathbf{t}_{\mathbf{r}} \mathrm{CL}$ and $\mathbf{t}_{\mathbf{f}} \mathrm{CL}$.

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4032AD, CD4032AK CD4038AD, CD4038AK |  |  | $\begin{aligned} & \text { CD4032AE } \\ & \text { CD4038AE } \end{aligned}$ |  |  |  |  |
|  |  | (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: <br> A, B, or Invert Inputs to Sum Outputs | ${ }^{\mathrm{t}} \mathrm{PHL}$, <br> ${ }^{t}$ PLH | 5 | - | 400 | 1100 | - | 400 | 1400 |  |  |
|  |  | 10 | - | 125 | 250 | - | 125 | 300 | ns | 7.5 |
| Clock Input to Sum Outputs |  | 5 | - | 800 | 2200 | - | 800 | 2400 | ns | - |
|  |  | 10 | - | 250 | 500 | - | 250 | 600 |  |  |
| Transition Time (Sum Outputs) | ${ }^{t}$ THL, <br> ${ }^{t}$ TLH | 5 | - | 125 | 375 | - | 125 | 425 | ns | 7-6 |
|  |  | 10 | - | 50 | 150 | - | 50 | 200 |  |  |
| Clock <br> Rise \& Fall Time | $\begin{gathered} *{ }^{*} \mathrm{t}_{\mathrm{r}} \mathrm{CL}, \\ \mathrm{t}_{\mathrm{f}} \mathrm{CL} \end{gathered}$ | 5 | - | - | 15. | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  | 10 | - | - | 15 | - | - | 15 |  |  |
| Input Set-Up Times* |  | 5 | $t_{r} \mathrm{CL}$ | - | - | $\mathrm{tr}_{\mathrm{r}} \mathrm{CL}$ | - | - | - | - |
|  |  | 10 |  |  |  |  |  |  |  |  |
| Maximum Clock Frequency | ${ }^{f} \mathrm{CL}$ | 5 | 1.5 | 2.5 | - | 1 | 2.5 | - | MHz | - |
|  |  | 10 | 3 | 5 | - | 2 | 5 | - |  |  |
| Input Capacitance | $\mathrm{C}_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF | - |

*This characteristic refers to the minimum time required for the A, B, or Reset Inputs to change state following a positive clock transition (CD4032A) or negative transition (CD4038A).

* If more than one unit is cascaded $t_{r} C L$ should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.


Fig.7-7 Typ. dissipation characteristics.


Fig.7-8 Quiescent device current test circuit CD4032A.


Fig.7-9 Noise-immunity test circuit-CD4032A.


Fig.7-10 Quiescent device current test circuit-CD4038A.


Fig.7-11 Noise-immunity test circuit-CD4038A.


# COS／MOS MSI 8－Stage Static Bidirectional Paralle！／Serial Input／Output Bus Register 

## Special Features：

－Bidirectional parallel data input
－Paraliel or serial inputs／parallel outputs
－Asynchronous or synchronous parallel data loading
－Parallel data－input enable on＂$A$＂data lines
－Data recirculation for register storage
－Multipackage register expansion
－Fully static operation DC－to－5 MHz（typ．） at $V_{D D}-V_{S S}=10 \mathrm{~V}$

RCA CD4034A is a static eight－stage parallel－or serial－input parallel－output register．It can be used to：
1）bidirectionally transfer parallel information between two buses，2）convert serial data to parallel form and direct the parallel data to either of two buses，3）store（recirculate） parallel data，or 4）accept parallel data from either of two buses and convert that data to serial form．Inputs that control the operations include a single phase clock（CL）， ＂$A$＂－data enable（AE），Asynchronous／synchronous（A／S）， ＂$A$＂bus to＂$B$＂bus／＂$B$＂bus to＂$A$＂bus（ $A / B$ ），and parallel／serial（P／S）．
Data inputs include 16 bidirectional parallel data lines of which the eight＂$A$＂data lines are inputs（outputs）and the ＂$B$＂data lines are outputs（inputs）depending on the signal level on the $A / B$ input．In addition，an input for serial data is also provided．
All register stages are D－type master－slave flip－flops with separate master and slave clock inputs generated internally to allow synchronous or asynchronous data transfer from master to slave．Isolation from external noise and the effects of loading is provided by output buffering．

## PARALLEL OPERATION

A＂high＂P／S input signal allows data transfer into the register via the parallel data lines synchronously with the positive transition of the clock provided the A／S input is ＂low＂．If the A／S input is＂high＂this transfer is independent of the clock．The direction of data flow is controlled by the $A / B$ input．When this signal is＂high＂the $A$ data lines are inputs（and B data lines are outputs）；a＂low＂A／B signal reverses the direction of data flow．

## Applications：

－Parallel Input／Parallel Output， Parallel Input／Serial Output， Serial Input／Parallel Output， Serial Input／Serial Output Register
－Shift right／shift left register
－Shift right／shift left with parallel loading
－Address register
－Buffer register
－Bus system register with enable parallel lines at bus side
－Double bus register system
－Up－Down Johnson or ring counter
－Pseudo－random code generators
－Sample and hold register（storage，counting，display）
－Frequency and phase comparator


Fig．1－Functional diagram．

The $A E$ input is an additional feature which allows many registers to feed data to a common bus. The " $A$ " Data lines are enabled only when this signal is "high".
Data storage through recirculation of data in each register stage is accomplished by making the $A / B$ signal "high" and the AE signal "low".

## SERIAL OPERATION

A "low" P/S signal allows serial data to transfer into the register synchronously with the positive transition of the clock. The A/S input is internally disabled when the register is in the serial mode (asynchronous serial operation is not allowed).
The serial data appears as output data on either the $B$ lines (when $A / B$ is "high") or the $A$ lines (when $A / B$ is "low" and the $A E$ signal is "high").

Register expansion can be accomplished by simply cascading CD4034A packages.

The CD4034A is supplied in two different packages; the CD4034AK in a 24 -lead flat pack, and the CD4034AD in a 24-lead ceramic dual-in-line package.

MAXIMUM RATINGS, Absolute-Maximum Values:

| Storage Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: |
| Operating Temperature Range | -55 to +125 |  |
| DC Supply Voltage Range ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) ...... | $0.5 \vee$ to +15 | $\checkmark$ |
| Device Dissipation (Per Pkg.) | 200 | mW |
| All Inputs ............ | $\mathrm{V}_{\text {SS }} \leq \mathrm{V}_{\mathrm{I}} \leq \mathrm{V}_{\mathrm{DD}}$ |  |
| Recommended DC Supply Voltage $\left(v_{D D}-v_{S S}\right) \ldots \ldots \ldots \ldots .$ | 3 to 15 |  |

## STATIC ELECTRICAL CHARACTERISTICS (All inputs

 $\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ).
3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4034AD, CD4034AK |  |  |  |  |  |  |  |  |  |  |
|  |  | Vo | VDD | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 9 |
|  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600 |  |  |
| Quiescent Device$\qquad$ | PD |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | 8 |
|  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{VOH}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  | 10 | $9.99^{\circ}$ | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) <br> For Definition <br> See Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 10 |
|  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3.0 | - | - |  |  |
| Output Drive Current: N-Channel | IDN | 0.5 | 5 | 0.124 | - | - | 0.1 | 0.20 | - | 0.07 | - | - | mA | - |
|  |  | 0.5 | 10 | 0.31 | - | - | 0.25 | 0.50 | - | 0.175 | - | - |  |  |
| P-Channel | ${ }^{1} \mathrm{D} P$ | 4.5 | 5 | -0.075 | - | - | -0.05 | -0.10 | - | -0.035 | - | - | mA | - |
|  |  | 9.5 | 10 | -0.188 | - | - | -0.125 | -0.25 | - | -0.088 | - | - |  |  |
| Input Current | 11 | - | - | - | - | - | - | 10 | - | - | - | - | pA | - |

File No. 575

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | CD4034AD, CD4034AK |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $V_{D D}$ <br> Volts | Min. | Typ. | Max. |  |  |
| Propagation Delay Time | ${ }^{\text {t }}$ PHL. <br> ${ }^{\text {tpLH}}$ |  | 5 | - | 600 | 1200 | ns | - |
|  |  |  | 10 | - | 240 | 480 |  |  |
| Jransition Time | ${ }^{\text {tTHL }}$. <br> ${ }^{t}$ TLH |  | 5 | - | 250 | 750 | ns | - |
|  |  |  | 10 | - | 100 | 300 |  |  |
| Minimum Clock Pulse Width | $\begin{aligned} & \mathrm{t} W \mathrm{~L} \\ & \mathrm{t} W \mathrm{WH} \\ & \hline \end{aligned}$ |  | 5 | - | 200 | 400 | ns | - |
|  |  |  | 10 | - | 100 | 175 |  |  |
| Minimum High-Level $A E, P / S, A / S$ <br> Pulse Width | tWH | . | 5 | - | 240 | 480 | ns | - |
|  |  |  | 10 | - | 85 | 195 |  |  |
| Clock Rise and Fall Time | $\begin{aligned} & { }^{*} \mathrm{t}_{\mathrm{r}} \mathrm{CL}, \\ & \mathrm{t}_{\mathrm{f}} \mathrm{CL} \end{aligned}$ |  | 5 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  |  | 10 | - | - | 15 |  |  |
| Set-Up Time | - |  | 5 | - | 250 | 500 | ns | - |
|  |  |  | 10 | - | 100 | 200 |  |  |
| Maximum Clock Frequency | ${ }^{\text {f }} \mathrm{CL}$ |  | 5 | 1.5 | 2.5 | - | MHz | 7 |
|  |  |  | 10 | 3.0 | 5 | - |  |  |
| Input Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | pF | - |

[^6]

32C5-19201
Fig.2-Functional and terminal assignment diagram for CD4034AK and CD4034AD.


Fig.3-Logic diagram.

Table I Truth Table for Register Input-Levels and the Resulting Register Operation (L = Low Level, H = High Level, X = Don't Care)

| "A" Enable | P/S | A/B | A/S | Operation" |
| :--- | :---: | :---: | :---: | :--- |
| L | L | L | X | Serial Mode; Synch. Serial Data Input, "A" Parallel Data Outputs Disabled |
| L | L | H | X | Serial Mode; Synch. Serial Data Input, "B" Parallel Data Output |
| L | H | L | L | Parallel Mode; "B" Synch. Parallel Data Inputs, "A" Parallel Data Outputs Disabled |
| L | H | L | H | Parallel Mode; "B" Asynch. Parallel Data Inputs, "A" Parallel Data Outputs Disabled |
| L | H | H | L | Parallel Mode; " $A " P a r a l l e l ~ D a t a ~ I n p u t s ~ D i s a b l e d, " ~$ <br> R" Parallel Data Outputs, Synch Data <br> Recirculation |
| L | H | H | H | Parallel Mode; " $A "$ Parallel Data Inputs Disabled, "B" Parallel Data Outputs, Asynch <br> Data Recirculation |
| H | L | L | X | Serial Mode; Synch. Serial Data Input, "A" Parallel Data Output |
| H | L | H | X | Serial Mode; Synch. Serial Data Input, "B" Parallel Data Output |
| H | H | L | L | Parallel Mode; "B" Synch. Parallel Data Input, "A" Parallel Data Output |
| H | H | L | H | Parallel Mode; "B" Asynch. Parallel Data Input, "A" Parallel Data Output |
| H | H | H | L | Parallel Mode; "A" Synch. Parallel Data Input, "B" Parallel Data Output |
| H | H | H | H | Parallel Mode; "A" Asynch. Parallel Data Input, "B" Parallel Data Output |

[^7]File No. 575



92CM-19198

Fig.4-Timing diagram.


Fig.5-Typ. propagation delay time vs. $C_{L}$.


Fig.6-Typ. transition time vs. $C_{L}$.


Fig.7-Typ. input frequency vs. VDD.


Fig.8-Typ. dissipation characteristics.


Fig.9_Quiescent device current test circuit.


Fig. 10- Noise immunity test circuit.


Fig.11- 16.Bit parallel in/parallel out, parallel in/serial out, serial in/parallel out, serial in/serial out register.


Fig.12-16-Bit serial in/gated parallel out register.


Fig. 13-Frequency and phase comparator.


A "'High" ("Low") on the shift Left/Shift Right input allows serial data on the Shift Left Input (Shift Right Input) to enter the register on the positive transition of the clock signal. A "high" on the " $A$ " Enable Input disables the " $A$ " parallel data lines on Reg. 1 and 2 and enables the " $A$ " data lines on registers 3 and 4 and allows parallel data
into registers 1 and 2. Other logic schemes may be used in place of registers 3 and 4 for parallel loading.
When paraliel inputs are not used Reg. 3 and 4 and associated logic are not required.
*Shift left input must be disabled during parallel entry.

Fig. 14 - Shift right/shift left with parallel inputs.


The " $A$ " enable ( $A E$ ) and $A / B$ signals control all combinations of transfer between the registers and bus systems.

Fig. 15 - Single- and double-bus systems.


Fig.16-N-stage shift register with fixed serial output line.


Fig.17-: Sample and hold register-serial/parallel in-parallel out.



# COS/MOS 4-Stage Parallel In/ Paralle! Out Shift Register 

with J-K Serial Inputs and True/ Complement Outputs

## APPLICATIONS:

- Sequence generation, control circuits, code conversion
- Counters, Registers, Arithmetic-Unit Registers, Shift Left - Shift Right Registers, Serial-to-Parallel/Parallel-toSerial conversions.

RCA-CD4035A* is a four-stage clocked serial register having provisions for synchronous parallel inputs to each stage and serial inputs to the first stage via $\mathrm{J} \overline{\mathrm{K}}$ logic. Register stages 2, 3 , and 4 are coupled in a serial "D" flip-flop configuration when the register is in the serial mode (Parallel/Serial control low).
Parallel entry via the " $D$ " line of each register stage is permitted only when the Parallel/Serial control is "high".

In the parallel or serial mode information is transferred on positive clock transitions.
When the True/Complement control is "high", the True contents of the register are available at the output terminals. When the True/Complement control is "low", the outputs are the complements of the data in the register. The True/ Complement control functions asynchronously with respect to the clock signal.
$J R$ input logic is provided on the first stage serial input to minimize logic requirements particularly in counting and sequence-generation applications. With $J \overline{\mathrm{~K}}$ inputs connected together, the first stage becomes a " $D$ " flip-flop. All asynchronous common reset is also provided.
CD4035A types are supplied in the 16 -lead flat pack, and in both the 16 -lead ceramic and plastic dual-in-line packages.

## FEATURES:

- 4-Stage clocked shift operation
- Synchronous parallel entry on all 4 stages
- $\quad \mathrm{J} \overline{\mathrm{K}}$ inputs on first stage
- Asynchronous True/Complement control on all outputs
- Reset control
- Static flip-flop operation; Master-slave configuration
- Buffered outputs
- Low-Power Dissipation - $5 \mu \mathrm{~W}$ typ. (ceramic)
- High speed - to 5 MHz

MAXIMUM RATINGS, Absolute-Maximum Values:

| Storage-Temperature Range | $-65^{\circ} \mathrm{C}$ to +150 | ${ }^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: |
| Operating Temperature Range: |  |  |
| Ceramic Package Types | $-55^{\circ} \mathrm{C}$ to +125 | ${ }^{\circ} \mathrm{C}$ |
| Plastic Package Types | $-40^{\circ} \mathrm{C}$ to +85 | ${ }^{\circ} \mathrm{C}$ |
| DC Supply-Voltage Range |  |  |
| ( $V_{\text {DD }}-V_{S S}$ ) | -0.5 V to +15 | $v$ |
| Device Dissipation (Per Pkg.) | 200 | mW |
| All Inputs. | $\mathrm{v}_{S S} \leq \mathrm{v}_{1} \leq \mathrm{v}_{\mathrm{DD}}$ |  |
| Recommended |  |  |
| DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{S S}$ ). | 3 to 15 | v |
| Recommended |  |  |
| Input Voltage Swing | $V_{D D}$ to $V_{S S}$ |  |

[^8]STATIC ELECTRICAL CHARACTERISTICS (All inputs . . . . . . . . . . . . . . . . . . . . . . . . . . $\mathrm{V}_{\mathbf{S S}} \leq \mathrm{V}_{\mathbf{I}} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ). . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4035AD, CD4035AK |  |  |  |  |  |  |  |  |  |  |
|  |  | Vo | $\mathrm{v}_{\mathrm{DD}}$ | .$^{55}{ }^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\text {L }}$ |  | 5 | - | - | 5 | - | 0.3 | 5 | - | - | 300 |  |  |
|  |  |  | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 600. | $\mu \mathrm{A}$ | 11 |
| Quiescent Device Dissipation Package | PD |  | 5 | - | - | 25 | - | 1.5 | 25 | - | - | 1500 |  |  |
|  |  |  | 10 | - | - | 100 | - | 5 | 100 | - | - | 6000 | $\mu \mathrm{N}$ | 4 |
| Output Voltage Low Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | $v$ | - |
| High Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - | v | - |
| Noise Immunity <br> (All Inputs) <br> For definition, see Appendix |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - |  | 12 |
|  | $\mathrm{V}_{\mathrm{NL}}$ | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - | v |  |
|  |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - | v |  |
| Output Drive Current: N Channe | IDN | 0.5 | 5 | 0.62 | - | - | 0.50 | 1 | - | 0.35 | - | - | mA | - |
|  |  | 0.5 | 10 | 1.55 | - | - | 1.25 | 2.5 | - | 0.87 | - | - |  |  |
| P Channel | ${ }_{10}{ }^{\text {P }}$ | 4.5 | 5 | -0.31 | - | - | -0.25 | -0.5 | - | -0.17 | - | - | mA | - |
|  |  | 9.5 | 10 | -0.81 | - | - | -0.65 | -1.3 | - | -0.45 | - | - |  |  |
| Input Current | 1 |  |  | - | - | - | - | 10 | - | - | - | - | PA | - |



Fig. 1-Typical Propagation Delay Time vs. Load Capacitance.


Fig. 2-Typical Transition Time vs. Load Capacitance.

(Recommended DC Supply Voltage (VDD $-V_{S S}$ ) . . . . . . . . . 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4035AE |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{0}$ | VDD | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  |  | 5 | - | - | 50 | - | 0.5 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 11 |
|  |  |  |  | 10 | - | - | 100 | - | 1 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation Package | $P_{D}$ |  |  | 5 | - | - | 250 | - | 2.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | 4 |
|  |  |  |  | 10 | - | - | 1000 | - | 10 | 1000 | - | - | 14000 |  |  |
| Output Voltage Low Level | $\mathrm{V}_{\mathrm{OL}}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | $\mathrm{VOH}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - . | - | V | - |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) <br> For Definition <br> See Appendix |  |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 12 |
|  | $\mathrm{V}_{\mathrm{NL}}$ |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: |  |  | 0.5 | 5 | 0.43 | - | - | 0.35 | 1 | - | 0.24 | - | - | mA | - |
| N Channel | ${ }^{1} \mathrm{DN}$ |  | 0.5 | 10 | 1.05 | - | - | 0.85 | 2.5 | - | 0.59 | - | - |  |  |
| P Channel | $I_{D} P$ |  | 4.5 | 5 | -0.2 | - | - | -0.18 | -0.5 | - | -0.12 | - | - | $m A$ | - |
|  |  |  | 9.5 | 10 | -0.56 | - | - | -0.45 | -0.31 | - | -0.31 | - | - |  |  |
| Input Current | 11 |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |



Fig. 3-Typical clock input frequency vs. $V_{D D}$.


Fig. 4-Typical dissipation characteristics.


Fig. 5-Logic Block Diagram.


Fig. 6-Binary-to-BCD Converter.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$ and $C_{L}=15 \mathrm{pF}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=\mathbf{0 . 3 \%}{ }^{\circ} \mathrm{C}$ (See Appendix for Waveforms)

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4035AD, CD4035AK |  |  | CD4035AE |  |  |  |  |
|  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| CLOCKED OPERATION |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: | tPLH, | 5 | - | 250 | 500 | - | 250 | 700 | ns | 1 |
|  | tPHL | 10 | - | 100 | 200 | - | 100 | 300 |  |  |
| Transition Time: | ${ }^{\mathrm{t}}$ THL, <br> tTLH | 5 | - | 100 | 200 | - | 100 | 300 | $n \mathrm{~s}$. | 2 |
|  |  | 10 | - | 50 | 100 | - | 50 | 150 |  |  |
| Minimum Clock Pulse Duration | tWL. tWH | 5 | - | 200 | 335 | - | 200 | 500 | ns | - |
|  |  | 10 | - | 100 | 165 | - | 100 | 250 |  |  |
| $\begin{aligned} & \text { Clock } \\ & \text { Rise \& Fall Time } \end{aligned}$ | $\begin{aligned} & \mathrm{t}_{\mathrm{r} C L}^{*} \\ & \mathrm{t}_{\mathrm{fCL}} \end{aligned}$ | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  | 10 | - | - | 5 | - | - | 5 |  |  |
| Setup Time: J/K Lines |  | 5 | - | 250 | 500 | - | 250 | 750 | ns | - |
|  |  | 10 | - | 100 | 200 | - | 100 | 250 |  |  |
| Parallel-In Lines |  | 5 | - | 100 | 350 | - | 100 | 500 |  |  |
|  |  | 10 | - | 50 | 80 | - | 50 | 100 |  |  |
| Maximum Clock Frequency | ${ }^{\mathrm{f}} \mathrm{CL}$ | 5 | 1.5 | 2.5 | - | 1 | 2.5 | - | MHz | 3 |
|  |  | 10 | 3 | 5 | - | 2 | 5 | - |  |  |
| Input Capacitance | $C_{1}$ | Any Input | - | 5 | - | - | 5 | - | pF | - |
| RESET OPERATION |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time: | tPHL, tPLH | 5 | - | 250 | 500 | - | 250 | 700 | ns | - |
|  |  | 10 | - | 100 | 200 | - | 100 | 300 |  |  |
| Minimum Reset Pulse Duration | tWL, <br> tWH | 5 | - | 200 | 400 | - | 200 | 500 | ns | - |
|  |  | 10 | - | 100 | 175 | - | 100 | 200 |  |  |

* If more than one unit is cascaded $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ should be made less than or equal to the sum of the fixed propagation delay time at 15 pF and the transition time of the output driving stage for the estimated capacitive load.


Fig. 7-BIDEC Logic.


92CS-19974
Fig. 8-Shirit Left/Shift Right Register.


Using a control line ( $E$ ) two different state sequences can be generated. For example, suppose the following two sequences are desired on command (control line E)

| Control $=\mathbf{E}=$ |  | 0 |  |  | 1 |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mathrm{Q}_{1}$ | $\mathrm{O}_{2}$ | $\mathrm{O}_{3}$ | $\mathbf{Q}_{4}$ |  | $\mathbf{Q}_{1}$ | $\mathrm{Q}_{2}$ | $\mathrm{Q}_{3}$ | $\mathrm{Q}_{4}$ |
|  | A | B | C | D |  | A | B | C | D |
| 0 | 0 | 0 | 0 | 0 | 15 | 1 | 1 | 1 | 1 |
| 1 | 1 | 0 | 0 | 0 | 14 | 0 | 1 | 1 | 1 |
| 2 | 0 | 1 | 0 | 0 | 13 | 1 | 0 | 1 | 1 |
| 5 | 1 | 0 | 1 | 0 | 10 | 0 | 1 | 0 | 1 |
| 10 | 0 | 1 | 0 | 1 | 5 | 1 | 0 | 1 | 0 |
| 4 | 0 | 0 | 1 | 0 | 11 | 1 | 1 | 0 | 1 |
| 9 | 1 | 0 | 0 | 1 | 6 | 0 | 1 | 1 | 0 |
| 3 | 1 | 1 | 0 | 0 | 12 | 0 | 0 | 1 | 1 |
| 6 | 0 | 1 | 1 | 0 | 9 | 1 | 0 | 0 | 1 |
| 13 | 1 | 0 | 1 | 1 | 2 | 0 | 1 | 0 | 0 |
| 11 | 1 | 1 | 0 | 1 | 4 | 0 | 0 | 1 | 0 |
| 7 | 1 | 1 | 1 | 0 | 8 | 0 | 0 | 0 | 1 |
| 14 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 |
| 12 | 0 | 0 | 1 | 1 | 3 | 1 | 1 | 0 | 0 |
| 8 | 0 | 0 | 0 | 1 | 7 | 1 | 1 | 1 | 0 |

Fig. 9(b)-State Sequences.

Fig. 9(a)-Double Sequence Generator.



Fig. 10-Example of Binary-to-BCD Conversion.

Using Couleur's Technique (BIDEC) ${ }^{\boldsymbol{A}}$, a binary number (most significant bit, MSB) first is shifted and processed, such that the BCD equivalent is obtained when the lastbinary bit is clocked into the register. The CD4035A, with the correct conversion logic, can also be used as a BCD-to-binary converter.
$\Delta$ The basic rule is: If a 4 or less is in a decade, shift with the next clock pulse; if a 5 or greater is in a decade, add 3 and then shift at the next clock pulse. For more information refer to "IRE TRANSACTIONS ON ELECTRONIC COMPUTERS', Dec. 1958, Pages 313-316.

## TEST CIRCUITS



Fig. 11-Quiescent device current.


Fig. 12-Noise immunity.


# COS/MOS 4-Word by 8-Bit Random-Access NDRO Memory 

Binary Addressing Direct Word-Line Addressing

CD4036AD, CD4036AK
CD4039AD, CD4039AK
Special Features:

- COS/MOS logic compatibility at all input and output terminals
- Memory bit expansion
- Memory word expansion via Wire-OR capability at the 8 INPUT-BIT and 8 OUTPUT-BIT lines
- Memory bypass capability for all bits
- Buffering on all outputs
- CD4036A- on-chip binary address decoding, separate READ INHIBIT and WRITE controls access Time-200 ns(Typ) at $V_{D D}=10 \mathrm{~V}$
- CD4039A-Direct word-line addressing

RCA type CD4036A is a single monolithic integrated circuit containing a 4 -word $\times 8$-bit Random Access NDRO Memory. Inputs include 8 INPUT-BIT lines, CHIP INHIBIT, WRITE, READ INHIBIT, MEMORY BYPASS, and 2 ADDRESS inputs. 8 OUTPUT-BIT lines are provided.
All input and output lines utilize standard COS/MOS inverter configurations and hence can be directly interfaced with COS/MOS logic devices.

CHIP INHIBIT allows memory word expansion by WIREORing of multiple CD4036A packages at either the 8-bit input and/or output lines (See Fig.15). With CHIP INHIBIT "high", both READ and WRITE operations are inhibited on the CD4036A. With CHIP INHIBIT "low", information can be written into and/or read continuously from one of the four words selected by the binary code on the two address lines. With CHIP INHIBIT "low", a "high" WRITE signal and a "low" READ INHIBIT signal activate WRITE and READ operations, respectively, at the addressed word location (See Fig.4).

The MEMORY BYPASS signal, when "high", allows shunting of information from the 8 INPUT-BIT lines directly to the 8 OUTPUT-BIT lines without disturbing the state of the 4 words. During the bypass operation input information may also be written into a selected word location, provided the CHIP INHIBIT is "low" and the WRITE is "high". The READ operation is deactivated during the BYPASS operation because information is fed directly from the 8 INPUT-BIT lines to the 8 OUTPUT-BIT lines.
RCA type CD4039A is identical to the CD4036A with the exception that individual address-line inputs have been provided for each memory word in place of the binary

## Applications:

Digital equipment where low power dissipation and/or high noise immunity are primary design requirements.

- Channel Preset Memory in digital frequency-synthesizer circuits
- General-purpose and scratch-pad memory in COS/MOS and other low-power systems.


Fig. 1 - CD4036A - Logic block diagram.

ADDRESS, CHIP INHIBIT, and READ INHIBIT inputs. When Wire-Oring multiple CD4039A packages for memory word expansion, an individual CD4039A is selected by addressing one of its word locations. The READ operation is activated whenever a word location is addressed (via a "high" signal-see Fig.5).

These devices will be supplied in two different 24 -lead ceramic packages; the CD4036AK and CD4039AK in the flat-pack, and the CD4036AD and CD4039AD in the dual-in-line package.

MAXIMUM RATINGS, Absolute-Maximum Values:

| Storage Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: |
| Operating Temperature Range | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| DC Supply Voltage Range $\left(V_{D D}-V_{S S}\right) \ldots \ldots \ldots \ldots$ | -0.5 to +15 | V |
| Device Dissipation (Per Pkg.) | 200 | mW |
| All Inputs | $\mathrm{V}_{\text {SS }} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\text {DD }}$ |  |
| Recommended DC Supply Voltage $\text { (VDD } \left.-V_{S S}\right) . \ldots . . .$ | 3 to 15 | V |
| Lead Temperature (During soldering) |  |  |
| At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$ from case for 10 seconds max | 265 | ${ }^{\circ} \mathrm{C}$ |

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4036AD, CD4036AK CD4039AD, CD4039AK |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{\mathrm{O}}$ | VDD | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime}$ |  |  | 5 | - | - | 5 | - | 0.5 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 11,12 |
|  |  |  |  | 10 | - | - | 10 | - | 1 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 25 | - | 2.5 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 100 | - | 10 | 100 | - | - | 6000 |  |  |
| Output Voltage: Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | VOH |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V | - |
|  |  |  |  | 10 | $9.99^{\circ}$ | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunitv <br> (All inputs except bit inputs when in memory bypass mode.) | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 13 |
|  |  |  | 1.0 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  |  | 9.0 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N -Channel | $I_{0} \mathrm{~N}$ | Nor-malReadModes | 0.5 | 5 | 0.12 | - | - | 0.10 | 0.20 | - | 0.07 | - | - | mA | 6 |
|  |  |  | 0.5 | 10 | 0.30 | - | - | 0.25 | 0.50 | - | 0.17 | - | - |  |  |
| P.Channel | ${ }_{10}{ }^{\text {P }}$ |  | 4.5 | 5 | -0.12 | - | - | -0.10 | -0.20 | - | -0.07 | - | - | mA | 7 |
|  |  |  | 9.5 | 10 | -0.30 | - | - | -0.25 | -0.50 | - | -0.17 | - | - |  |  |
| Output Drive Current: N -Channel | $I^{1} \mathrm{~N}$ | Mem- <br> ory <br> By- <br> pass <br> Mode <br> + <br> + <br>  <br>  | 0.5 | 5 | 0.04 | - | - | 0.03 | 0.06 | - | 0.02 | - | - | mA | - |
|  |  |  | 0.5 | 10 | 0.09 | - | - | 0.075 | 0.15 | - | 0.05 | - | - |  |  |
| P.Channel | $1^{\text {P }}$ |  | 4.5 | 5 | -0.04 | - | - | -0.03 | -0.06 | - | -0.02. | - | - | mA | - |
|  |  |  | 9.5 | 10 | -0.09 | - | - | -0.075 | -0.15 | - | -0.05 | - | - |  |  |
| Input Current | 11 |  | - | - | - | - | - | - | 10 | - | - | - | - | pA | - |

[^9]DYNAMIC ELECTRICAL CHARACTERISTICS at $\mathrm{T}_{\mathrm{A}}=\mathbf{2 5} \mathbf{5}^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | CD4036AD, CD4036AK CD4039AD, CD4039AK |  |  | UNITS | CHARAC- <br> TERISTIC <br> CURVES <br> \& TEST <br> CIRCUITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | VDD Volts | Min. | Typ. | Max. |  |  |
| Read Delay Time: (Access time) Read Inhibit (RI) | trd | OUTPUT TIED THROUGH $100 \mathrm{k} \Omega$ TO $V_{S S}$ FOR DATA OUTPUT "HIGH" AND TO VDD FOR DATA OUTPUT "LOW" | 5 | - | 375 | 750 | ns |  |
|  |  |  | 10 | - | 150 | 300 | Note 4 | 4,5 |
| Chip Inhibit (CI) |  |  | 5 | - | 500 | 1000 | Note 4 | 4,5 |
|  |  |  | 10 | - | 200 | 400 |  |  |
| Memory Bypass(MB) |  |  | 5 | - | 375 | 750 | ns | 4.5 |
|  |  |  | 10 | - | 150 | 300 |  |  |
| Address ${ }^{1}$ (ADD) |  |  | 5 | - | 500 | 1000 |  |  |
|  | tws |  | 10 | - | 200 | 400 |  |  |
| Write Set-up Time ${ }^{2}$ |  |  | 5 | 250 | 125 | - |  |  |
|  |  |  | 10 | 100 | 50 | - | ns | 4,5 |
| Write Removal Time ${ }^{3}$ | tWR |  | 5 | 0 | 0 | - | ns | 4,5 |
|  |  |  | 10 | 0 | 0 | - |  |  |
| Write Pulse Duration | tw |  | 5 | 150 | 75 | - | ns | 4,5 |
|  |  |  | 10 | 60 | 30 | - |  |  |
| Data Set-up Time ${ }^{5}$ | tDS |  | 5 | - | 0 | 0* | ns | 4,5 |
|  |  |  | 10 | - | 0 | 0 * |  |  |
| Data Overlap Time ${ }^{6}$ | tDO |  | 5 | $10{ }^{\circ}$ | 50 | - | ns | 4,5 |
| Output Transition Time |  |  | 10 | $40^{\circ}$ | 20 | - |  |  |
|  | tTHL, tTLH |  | 5 | - | 200 | 400 | ns | 9 |
|  |  |  | 10 | - | 100 | 200 |  |  |
| Input Capacitance | $\mathrm{C}_{1}$ | Any Input |  | - | 5 | - | pF | - |

1. For CD4036A only, remove $100-\mathrm{k} \Omega$ test condition and write all 1 's in word one, and all 0 's in word two, or vice-versa.
2. Delay from change of ADDRESS or CHIP-INHIBIT signals to application of WRITE pulse.
3. Delay from removal of WRITE pulse to change of ADDRESS or CHIP-INHIBIT signals.
4. Values for CD4036AD \& 4036AK only.
5. The time that DATA signal must be present before the WRITE pulse removal.

* Max. indicates satisfactory operation if tDS equals or exceeds this value.

6. The time that DATA signal must remain present after the WHITE pulse removal.

- Min. indicates satisfactory operation if $\mathrm{t} D \mathrm{O}$ equals or exceeds this value.

| Write <br> (Pin 2) | Read <br> Inhibit <br> (Pin 21) | Memory <br> Bypass <br> (Pin 11) | Chip <br> Inhibit <br> (Pin 22) | Operating Mode |
| :---: | :---: | :---: | :---: | :--- |
| X | X | L | H | Chip Inhibited (Outputs float) |
| X | X | H | H | Input/Output Shunted to output; <br> No Reading from Memory; <br> Information in Memory <br> Undisturbed |
| L | X | H | L | L |
| K | H | L | Input/Output Shunted to output; <br> No Reading from Memory; <br> Write Data into Addressed Word |  |
| L | L | L | L | Read Data from Addressed Word <br> Write Deactivated |
| H | L | L | L | Read/Write Deactivated <br> (Outputs float) |
| H | H | L | L | Read from Memory while <br> Writing Data into <br> Addressed Word |
| Write Data into Addressed Word <br> Read Deactivated (outputs float) |  |  |  |  |


| A1 | A0 | Addressed <br> Word |
| :--- | :--- | :--- |
| L 1 | Pin 23 | L |
| W Word 1 |  |  |
| H | H | Word 2 |
| H | H | Word 3 |
| Word 4 |  |  |

L = Low-Level Voltage,
$H=$ High-Level Voltage

Fig. 2 - Operating-mode truth table.


Fig.4-CD4036A Timing Diagram.


Fig.6-Typical n-channel drain characteristics.


Fig.8-Typical read delay time vs. $C_{L}$.


Fig.5-CD4039A Timing Diagram.


92CS-20677
Fig.7-Typical p-channel drain characteristics.


Fig.9-Typical transition time vs. $C_{L}$.


Fig.10-Typical power dissipation vs. frequency .

## TEST CIRCUITS



Fig. 11-Quiescent current (CD4036A).


Fig.12-Quiescent current (CD4039A).


Fig.13-Noise immunity.


+ The CD4036A CAN BE UTILIZED IN A SIMILAR FASHION.
SEE APP. NOTE ICAN-6498 - "DESIGN OF FIXED AND PROGRAMMABLE COUNTERS USING THE RCA CD4018A COS/MOS PRESETTABLE DIVIDE-BY-'N' COUNTER" AND ICAN-6716, "LOW POWER DIGITAL FREQUỄNCY SYNTHESIZERS UTILIZING COS/MOS IC'S'.

Fig. $14-$ Three-decade programmable $\div N$ counter with 4 -channel preset memory settings for frequency synthesizers.

The divide-by-N counter system shown in Fig. 14 is programmable from 2 to 999 . Four counter-preset words, selected by means of the rotary switches, can be stored in the CD4039A devices and can be read into each CD4018A by
simply addressing the proper word. Note that the CD4029A (see Bulletin File No. 503) Presettable Up/Down Counter with BCD decade counting can also be used to perform the basic counting function.


Fig.15-General-purpose memory storage -8 words $\times 16$ bits (RAM or ROM).

# COS/MOS Triple AND-OR Bi-Phase Pairs 

## Applications:

For use in digital equipment where low-power dissipation, low package count, and/or high noise immunity are primary design requirements.
a Split-Phase (Bi-Phase) Communication Systems.

- Disc, Drum, and Tape Digital Recording Systems.
- Plated Wire and Core Memory Systems.
- High-to-low logic level converter.

RCA CD4037A consists of three AND-OR pairs driven by common control signals A and B .
Each circuit has a data input (C), and two output terminals ( $D$ and $E$ ) that provide outputs in accordance with the truth table shown in Fig. 2. The circuit is useful for coding or decoding signals for split-phase (Bi-phase) communication systems, magnetic recording, and plated wire and core memory systems. A separate $V_{C C}$ terminal is provided to allow level conversion to any voltage from 3 volts to $V_{D D}$.
CD4037AD is supplied in a 14 -lead ceramic dual-in-line package, CD4037AE in a 14 -lead plastic dual-in-line package, CD4037AF in a 16 -lead dual-in-line ceramic frit-seal package, and CD4037AK in a 14 -lead ceramic flat package.

## Features:

- Outputs compatible with low-power TTL systems.
a High current sink and source ( 1.6 mA typ.) capability at $V_{D D}=V_{C C}=10 \mathrm{~V}$ and $V_{D S}=0.5 \mathrm{~V}$.
$\triangle$ Input protection against electrostatic effects.
$\boxminus$ Microwatt quiescent power dissipation: $\mathrm{PD}_{\mathrm{D}}=0.5 \mu \mathrm{~W} /$ ceramic pkg. (typ.), $\mathrm{PD}_{\mathrm{D}}=2 \mu \mathrm{~W} /$ plastic pkg. (typ.) at $V_{D D}=10 \mathrm{~V}$


## MAXIMUM RATINGS, Absolute-Maximum Values:



## CAUTION: VCC VOLTAGE LEVEL MUST BE EQUAL TO OR LESS POSITIVE THAN VDD



Fig.1-Schematic diagram of one AND-OR-Bi-Phase fair.

File No. 576
CD4037A

STATIC ELECTRICAL CHARACTERISTICS (AII inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage (VDD $\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4037AD, CD4037AF, CD4037AK |  |  |  |  |  |  |  |  |  |  |
|  |  | ${ }^{\prime}{ }_{0}$ | $\mathrm{V}_{\mathrm{cc}}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device | ${ }^{\prime} \mathrm{L}$ |  | 5 | 5 | - | - | 5 | - | 0.03 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 9 |
| Current |  |  |  | 10 | - | - | 10 | - | 0.05 | 10 | - | - | 600 |  |  |
| Quiescent Device | $\mathrm{P}_{\mathrm{D}}$ |  | 5 | 5 | - | - | 25 | - | 0.15 | 25 | - | - | 1500 | $\mu \mathrm{W}$ | - |
| Dissipation/Package |  |  |  | 10 | - | - | 100 | - | 0.5 | 100 | - | - | 6000 |  |  |
| Output Voltage: | $v_{\text {OL }}$ |  | 5 | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
| Low Level |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $\checkmark$ | - |
|  |  |  | 10 | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (All Inputs) For Definition, See Appendix | $v_{\text {NIL }}$ <br> $\mathrm{V}_{\mathrm{NIH}}$ | 0.8 | 5 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 10 |
|  |  | 1.0 | 10 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 4.2 | 5 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9.0 | 10 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: | ${ }^{1} \mathrm{~N}$ | 0.5 | 5 | 5 | 0.85 | - | - | 0.7 | 1.2 | - | 0.45 | - | - | mA | - |
| N-Channel |  | 0.5 | 10 | 10 | 1.3 | - | - | 1.1 | 2 | - | 0.7 | - | - |  |  |
| P.Channel | ${ }^{1} D^{P}$ | 4.5 | 5 | 5 | -0.65 | - | - | -0.55 | -1 | - | -0.35 | - | - | mA | - |
|  |  | 9.5 | 10 | 10 | -0.9 | - | - | -0.75 | -1.6 | - | -0.45 | - | - |  |  |
| Input Current | 1 |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |


| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4037AE |  |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{\text {cc }}$ | $\mathrm{V}_{\mathrm{DD}}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\text {L }}$ |  | 5 | 5 | - | - | 50 | - | 0.1 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 9 |
|  |  |  |  | 10 | - | - | 100 | - | 0.2 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | 5 | - | - | 250 | - | 0.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |
|  |  |  |  | 10 | - | - | 1000 | - | 2 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | - | $v$ | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | $v$ | - |
|  |  |  | 10 | 10 | 9.99 | $\cdots$ | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (All Inputs) For Definition, See Appendix | $v_{\text {NIL }}$ <br> $V_{\text {NIH }}$ | 0.8 | 5 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 10 |
|  |  | 1.0 | 10 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 4.2 | 5 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9.0 | 10 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N.Channel | ${ }^{1} \mathrm{D}$ N | 0.5 | 5 | 5 | 0.4 | - | - | 0.35 | 0.7 | - | c. 3 | - | - | mA | - |
|  |  | 0.5 | 10 | 10 | 0.65 | - | - | 0.55 | 1.1 | - | 0.45 | - | - |  |  |
| P. Channel | ${ }_{1}{ }^{P}$ | 4.5 | 5 | 5 | -0.35 | - | - | -0.3 | -0.55 | - | -0.2 | - | - | mA | - |
|  |  | 9.5 | 10 | 10 | -0.5 | - | - | -0.4 | -0.75 | - | -0.3 | - | - |  |  |
| Input Current | $1 /$ |  |  |  | - | - | - | - | 10 | - | - | - | - | pA | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and $\mathrm{V}_{\mathrm{C}}=5 \mathrm{~V}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARAC- <br> TERISTIC <br> CURVES <br> \& TEST <br> CIRCUITS <br> Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4037AD, CD4037AK, CD4037AF |  |  | CD4037AE |  |  |  |  |
|  |  | - | VDD <br> (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: | ${ }^{\text {tPHL }}$ |  | 5 | - | 225 | 450 | - | 325 | 650 | ns | 6, 8 |
| A and B Inputs | ${ }_{\text {tPLH }}$ |  | 10 | - | 75 | 150 | - | 100 | 200 |  |  |
| $C$ Inputs | ${ }^{\text {tPHL }}$ |  | 5 | - | 250 | 500 | - | 350 | 700 | ns |  |
|  |  |  | 10 | - | 75 | 150 | - | 100 | 200 |  |  |
|  | ${ }^{\text {tPLH }}$ |  | 5 | - | 225 | 450 | - | 325 | 650 |  |  |
|  |  |  | 10 | - | 90 | 180 | - | 125 | 250 |  |  |
| Transition Time: | ${ }^{\text {t }}$ THL |  | 5 | - | 40 | 80 | - | 60 | 120 | ns | 4,8 |
| High-to-Low Level |  |  | 10 | - | 15 | 30 | - | 20 | 40 |  |  |
| Low-to-High Level | t TLH |  | 5 | - | 75 | 150 | - | 100 | 200 | ns | 5,8 |
|  |  |  | 10 | - | 60 | 120 | - | 90 | 180 |  |  |
| Input Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |



92cs-19221

Fig.2-Logic diagram and truth table.


Fig.3-Coding and decoding waveforms.


Fig.4-Typical transition time vs $C_{L}$.


92CS-19225
Fig.5-Typical transition time vs $C_{L}$.


Fig.6-Typical propagation delay time vs $C_{L}$.


Fig.7-Typical dissipation characteristics.


Fig.8-Waveforms for measurement of dynamic characteristics.


Fig.9-Quiescent device current.

TEST CIRCUITS


Fig. $10-$ Noise immunity (at $T_{A}=25^{\circ} \mathrm{C}$ ).


# COS/MOS 12-Stage Ripple-Carry Binary Counter/Divider 

## Features:

- Medium-speed operation . . . . 5-MHz (typ.) input pulse rate at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
- Low "high"• and 'low"' level output impedance . . . . . . $750 \Omega$ (typ.) at $V_{D D}-V_{S S}=10 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{DS}}=0.5 \mathrm{~V}$
- Common reset
- Fully static operation
- All 12 buffered outputs available
- Low-power TTL compatible

RCA-CD4040A consists of an input-pulse-shaping circuit and 12 ripple-carry binary counter stages. Resetting the counter to the all-O's state is accomplished by a high-level on the reset line. A master-slave flip-flop configuration is utilized for each counter stage. The state of the counter is advanced one step in binary order on the negative-going transition of the input pulse. All inputs and outputs are fully buffered.
The CD4040A is supplied in a 16 -lead dual-in-line ceramic welded-seal package (CD4040AD), a 16 -lead dual-in-line plastic package (CD4040AE), a 16 -lead dual-in-line ceramic frit-seal package (CD4040AF), or a 16 -lead flat pack (CD4040AK).

## MAXIMUM RATINGS, Absolute-Maximum Values:

| Storage-Temperature Range | -65 to +150 | C |
| :---: | :---: | :---: |
| Operating-Temperature Range: |  |  |
| Ceramic-Package Types | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Plastic-Package Types | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| DC Supply-Voltage Range: $\left(V_{D D}-V_{S S}\right) \ldots .$ | -0.5 to +15 | V |
| Device Dissipation (Per Package) | 200 | mW |
| All Inputs | $\mathrm{V}_{\text {SS }} \leq \mathrm{V}_{\mathrm{I}} \leq \mathrm{V}_{\mathrm{DD}}$ |  |
| Recommended |  |  |
| DC Supply-Voltage ( $\mathrm{V}_{\mathrm{DD}}$ - $\mathrm{V}_{\text {SS }}$ ). . | 3 to 15 | V |
| Recommended |  |  |
| Input-Voltage Swing | $V_{\text {DD }}$ to $V_{S S}$ |  |
| Lead Temperature (During Soldering) |  |  |
| At distance $1 / 16^{\prime \prime} \pm 1 / 32^{\prime \prime}$ (1.59 $\pm 0.7$ from case for 10 s max. |  | $5^{\circ} \mathrm{C}$ |

## Applications:

- Frequency-dividing circuits
- Time-delay circuits
- Control counters

- R=HIGH DOMINATES (RESETS ALL STAGES)
- ACTION OCCURS ON NEGATIVE GOING

TRANSITION OF INPUT PULSE.COUNTER
ADVANCES ONE BINARY COUNT ON EACH NEGATIVE $\phi$ TRANSITION ( 4096 TOTAL BINARY COUNTS).

92CM-20748RI

Fig. 1 - Logic diagram of CD4040A input pulse shaper and 1 of 12 stages.

File No. 624

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}}-\mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) $\qquad$ . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4040AD, CD4040AK, CD4040AF |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $V_{\text {DD }}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 15 | - | 0.5 | 15 | - | - | 900 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 25 | - | 1 | 25 | - | - | 1500 |  |  |
| Quiescent Device Dissipation Package | $P_{D}$ |  | 5 | - | - | 75 | - | 2.5 | 75 | - | - | 4500 | $\mu N$ | 13 |
|  |  | Fanout of 50 COS/MOS Inputs | 10 | - | - | 250 | - | 10 | 250 | - | - | 15000 |  |  |
| Output Voltage: Low Level | VOL | Fanout of 50 COS/MOS Inputs | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) | $\begin{aligned} & V_{N L} \\ & V_{N H} \end{aligned}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 11,12 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: n-Channel | ${ }_{10} \mathrm{~N}$ | 0.5 | 5 | 0.22 | - | - | 0.145 | 0.36 | - | 0.102 | - | - | mA | 2,4 |
|  |  | 0.5 | 10 | 0.44 | - | - | 0.4 | 0.75 | - | 0.250 | - | - |  |  |
| p-Channel | $I_{D} P$ | 4.5 | 5 | -0.15 | - | - | -0.1 | -0.25 | - | -0.07 | - | - | mA | 3,5 |
|  |  | 9.5 | 10 | -0.3 | - | - | -0.25 | -0.5 | - | $\overline{0} .175$ | - | - |  |  |
| Input Current | 11 | Any Input |  | - | - | - | - | 10 | - | - | - | - | pA |  |

STATIC ELECTRICAL"CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage (VD V $_{\text {SS }}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4040AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | VDD | $-40{ }^{\circ} \mathrm{C}$ |  |  | 250 C |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | - | 50 | - | 1 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 100 | - | 2 | 100 | - | - | 1400 |  |  |
| Quiescent Device Dissipation Package | $P_{\text {D }}$ |  | 5 | - | - | 250 | - | 5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | 13 |
|  |  |  | 10 | - | - | 1000 | - | 20 | 1000 | - | - | 14000 |  |  |
| Output Voltage: Low Level | VOL | Fanout of 50 COS/MOS Inputs | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 11,12 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current <br> ( $\mathrm{Q}, \overline{\mathrm{a}}$ Outputs): <br> n-Channel | IDN | 0.5 | 5 | 0.21 | - | - | 0.08 | 0.36 | - | 0.056 | - | - | mA | 2,4 |
|  |  | 0.5 | 10 | 0.42 | - | - | 0.2 | 0.75 | - | 0.14 | - | - |  |  |
| p-Channel | $I_{1} P$ | 4.5 | 5 | -0.145 | - | - | -0.06 | -0.25 | - | -0.4 | - | - | mA | 3,5 |
|  |  | 9.5 | 10 | -0.29 | - | - | -0.15 | -0.5 | - | -0.1 | - | - |  |  |
| Input Current | 11 | Any Input |  | - | - | - | - | 10 | - | - | - | - | pA |  |

DYNAMIC ELECTRICAL CHARACTERISTICS, At $T_{A}=25^{\circ} \mathrm{C}, V_{S S}=O V, C_{L}=15 \mathrm{pF}$ (unless otherwise specified),
and input rise and fall times $=20 \mathrm{~ns}$, except $t_{r} C L$ and $t_{f} C L$. Typical Temperature Coefficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} C$.

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4040AK, AD, AF |  |  | CD4040AE |  |  | UNITS | NOTE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | VDD | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |  |  |
| Input-Pulse Operation |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time | tPHL. <br> tPLH |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | - | $\begin{aligned} & 450 \\ & 225 \end{aligned}$ | $\begin{aligned} & 900 \\ & 450 \end{aligned}$ | - | $\begin{aligned} & 450 \\ & 225 \end{aligned}$ | $\begin{aligned} & 950 \\ & 475 \end{aligned}$ | ns | 1 |
| Transition Time | $\begin{aligned} & \text { tTHL, } \\ & \text { tTLH } \\ & \hline \end{aligned}$ |  | $\begin{gathered} \hline 5 \\ 10 \\ \hline \end{gathered}$ | - | $\begin{array}{r} 150 \\ 75 \\ \hline \end{array}$ | $\begin{array}{\|l\|} \hline 300 \\ 150 \\ \hline \end{array}$ | - | $\begin{gathered} 150 \\ 75 \\ \hline \end{gathered}$ | $\begin{aligned} & 350 \\ & 175 \\ & \hline \end{aligned}$ | ns |  |
| Min. Input-Pulse Width | tWL. <br> tWH | $f=100 \mathrm{KHz}$ | $\begin{gathered} 5 \\ 10 \end{gathered}$ | - | $\begin{gathered} 200 \\ 75 \end{gathered}$ | $\begin{aligned} & 400 \\ & 110 \end{aligned}$ | - | $\begin{aligned} & 200 \\ & 75 \end{aligned}$ | $\begin{aligned} & 500 \\ & 125 \end{aligned}$ | ns |  |
| Input-Pulse <br> Rise \& Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{r} \phi} \\ & \mathrm{t}_{\mathrm{t} \phi} \end{aligned}$ |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | - | - | $\begin{aligned} & 15 \\ & 7.5 \end{aligned}$ | - | - | $\begin{aligned} & 15 \\ & 7.5 \end{aligned}$ | $\mu s$ | 2 |
| Max. Input-Pulse Frequency | ${ }^{\prime}{ }_{\phi}$ |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{gathered} 1 \\ 3.5 \end{gathered}$ | $\begin{gathered} \hline 1.75 \\ 5 \\ \hline \end{gathered}$ | - | $\begin{gathered} \hline 0.9 \\ 3.25 \\ \hline \end{gathered}$ | $\begin{array}{\|c} \hline 1.75 \\ 5 \\ \hline \end{array}$ | - | MHz |  |
| Input Capacitance | $C_{1}$ | Any input |  | - | 5 | - | - | 5 | - | pF |  |
| Reset Operation |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time | tPHL |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | - | $\begin{aligned} & \hline 500 \\ & 250 \\ & \hline \end{aligned}$ | $\begin{array}{\|c\|} \hline 1000 \\ 500 \\ \hline \end{array}$ | - | $\begin{array}{\|l\|} \hline 500 \\ 250 \\ \hline \end{array}$ | $\begin{array}{\|r\|} \hline 1250 \\ 600 \\ \hline \end{array}$ | ns | 3 |
| Minimum Reset Pulse Width | tWH |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | - | $\begin{aligned} & 500 \\ & 250 \end{aligned}$ | $\begin{array}{\|c} 1000 \\ 500 \\ \hline \end{array}$ | - | $\begin{array}{\|l\|} \hline 500 \\ 250 \\ \hline \end{array}$ | $\begin{aligned} & 1250 \\ & 600 \\ & \hline \end{aligned}$ | ns |  |

## NOTES:

1. Measured from the $50 \%$ level of the negative clock edge to the $50 \%$ level of either the positive or negative edge of the Q1 output ( pin 9); or measured from the negative edge of Q1 through Q11 outputs to the positive or negative edge of the next higher output.


Fig. 2 - Typical n-channel drain characteristics.
2. Maximum input rise or fall time for functional operation.
3. Measured from the positive edge of the reset pulse to the negative edge of any output (Q1 to Q12.).


92cs-21511
Fig. 3 - Typical p-channel drain characteristics.


Fig. 4 - Minimum n-channel drain characteristics.

DRAIN-TO-SOURCE VOLTAGE (VDS)-V


92cs-21513
Fig. 5 - Minimum p-channel drain characteristics.

INPUT PULSE SHAPER


NOTE: SUBSTRATES FOR ALL " $p$ " UNITS ARE CONNECTED TO VDD


Fig. 7 - Typical propagation delay time vs. Ioad capacitance (per stage.)


Fig. 9 - Typical dissipation characteristics.


92C5-20754

Fig. 8 - Typical transition time vs. load capacitance.


Fig. 10 - Maximum input-pulse frequency vs. supply voltage.

TEST CIRCUITS


Fig. 11 - Reset-noise-immunity test circuit.


92CS-17918
Fig. 12 - Input-pulse noise-immunity test circuit.


92CS-17918RI
Fig. 13 - Quiescent-device-dissipation test circuit.


## Solid State

 Division
## CD4041AD, CD4041AE,CD4041AK



## COS/MOS Quad True/Complement Buffer

## APPLICATIONS

- High Current Source/Sink Driver
- COS/MOS-to-DTL/TTL Converter
- Display Driver
- MOS Clock Driver
- Resistor Network Driver (Ladder or Weighted R)
- Buffer
- Transmission Line Driver

RCA COS/MOS type CD4041A* is a Quad True/ Complement Buffer consisting of $n$ - and $p$ - channel units having low-channel resistance and high-current (sourcing and sinking) capability. The CD4041A is intended for use as a buffer, line driver, or COS/MOS-to-TTL driver. It can be used as an ultra-low power resistor-network driver for A/D and D/A conversion, as a transmission-line driver, and in other applications where high noise immunity and low-power dissipation are primary design requirements.
The CD4041A is supplied in a 14 -lead dual-in-line ceramic package (CD4041AD), a 14 -lead dual-in-line plastic package (CD4041AE), or a 14 -lead flat pack (CD4041AK).
*Formerly Dev. No. TA6031

MAXIMUM RATINGS, Absolute-Maximum Values:

| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to +150 | ${ }^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: |
| Operating Temperature Range:' |  |  |
| Ceramic Package Types | $-55^{\circ} \mathrm{C}$ to +125 | ${ }^{\circ} \mathrm{C}$ |
| Plastic Package Types | $-40^{\circ} \mathrm{C}$ to +85 | ${ }^{\circ} \mathrm{C}$ |
| DC Supply Voltage Range |  |  |
| ( $\mathrm{V}_{\text {DD }}$ - $\mathrm{V}_{\text {SS }}$ ) | -0.5 V to +15 | $V$ |
| Device Dissipation (Per Pkg.) | 200 | mW |
| Average Dissipation Per Output | 100 | mW |
| Allowable Input Rise and Fall Time |  |  |
| All Inputs | $V_{S S} \leqslant V_{1} \leqslant V_{\text {DD }}$ |  |
| Recommended |  |  |
| DC Supply Voltage $4 \mathbf{V}_{\text {DD }}-\mathbf{V}_{\text {SS }}$ ) . | 3 to'15 | v |
| Recommended |  |  |
| Input Voltage Swing | $V_{\text {DD }}$ to $V_{S S}$ |  |

## Special Features

True Output

- High Current Source and Sink Capability
$8 \mathrm{~mA}(t y p). @ V_{D S}=0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$ 3.2 mA (typ.) @ $\mathrm{V}_{\mathrm{DS}}=0.4 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$ (two TTL loads)


## Complement Output

- Medium Current Source and Sink Capability
3.6 mA (typ.) @ $V_{D S}=0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$
1.6 mA (typ.) @ $V_{D S}=0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$


Fig. 1-CD4041A schematic diagram.

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4041AD, CD4041AK |  |  |  |  |  |  |  |  |
|  |  |  | $v_{0}$ Volts | VDD Volts | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device |  | Inputs <br> to <br> Ground <br> or <br> $V_{D D}$ |  | 5 | - | 1 | - | 0.005 | 1 | - | - 60 | $\mu \mathrm{A}$ | 19 |
|  |  |  |  | 10 | - | 2 | - | 0.005 | 2 | - | 120 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | 5 | - | 0.025 | 5 | - | 300 | $\mu \mathrm{W}$ |  |
|  |  |  |  | 10 | - | 20 | - | 0.05 | 20 | - | 1200 |  |  |
| Output Voltage: Low-Level | $\mathrm{v}_{\mathrm{OL}}$ | Fan-out of 50 cos/mOS Inputs |  | 5 | - | 0.01 | - | 0 | 0.01 | - | 0.05 | V | 10, 11 |
|  |  |  |  | 10 | - | 0.01 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | 4.99 | 5 | - | 4.95 | - | $\checkmark$ |  |
|  |  |  |  | 10 | 9.99 | - | 9.99 | 10 | - | 9.95 | - |  |  |
| Noise Immunity (All Inputs) For definition, see Appendix | $V_{\text {NL }}$ |  | 0.95 | 5 | 1.5 | - | 1.5 | 2.25 | - | 1.4 | - | V | 20 |
|  |  |  | 2.9 | 10 | 3 | - | 3 | 4.5 | - | 2.9 | - |  |  |
|  | $\mathrm{V}_{\text {NH }}$ |  | 3.6 | 5 | 1.4 | - | 1.5 | 2.25 | - | 1.5 | - | V |  |
|  |  |  | 7.2 | 10 | 2.9 | - | 3 | 4.5 | - | 3 | - |  |  |
| Output Drive Current: | ${ }_{1}{ }^{N}$ | True Output | 0.4 | 5 | 2.1 | - | 1.6 | 3.2 | - | 1.2 | - | mA | 2.6. |
|  |  |  | 0.5 | 10 | 6.25 | - | 5 | 10 | - | 3.5 | - |  |  |
|  |  | Comple. ment Output | 0.5 | 5 | 1 | - | 0.8 | 1.6 | - | 0.55 | - |  | 4.8. |
|  |  |  | 0.5 | 10 | 2.5 | - | 2 | 4 | - | 1.4 | - |  |  |
| P.Channel | ${ }_{1} D^{P}$ | True Output | 4.5 | 5 | -1.75 | - | -1.4 | -2.8 | - | -1 | - | mA | 3.7. |
|  |  |  | 9.5 | 10 | -5 | - | -4 | -8 | - | -2.8 | - |  |  |
|  |  | Comple. <br> ment <br> Output | 4.5 | 5 | -0.75 | - | -0.6 | -1.2 | - | -0.4 | - |  | 5.9. |
|  |  |  | 9.5 | 10 | -2.25 | - | -1.8 | -3.6 | - | -1.25 | - |  |  |
| Input Current | $1 /$ | Any Input |  |  | - | - | . | 10 | - | - | - | pA |  |

- Values shown are for true output.

*SEE FIG. 17 FOR TRANSition time limitations

Fig. 2-Typical n-channel drain charac-teristics-true output.


Fig. 3-Typical p-channel drain charac-teristics-true output.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |  | 4041 |  |  |  |  |  |
|  |  |  | $V_{0}$ Volts | VOD Volts | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device Current | ${ }^{1}$ | Inputs <br> to Ground or $V_{D D}$ |  | 5 | - | 10 | -- | 0.01 | 10 | - | 140 | $\mu \mathrm{A}$ | 19 |
|  |  |  |  | 10 | - | 20 | - | 0.02 | 20 | - | 280 |  |  |
| Quiescent Device Dissipation/Package | ${ }^{P}$ D |  |  | 5 | - | 50 | .. | 0.05 | 50 | - | 700 | $\mu \mathrm{W}$ |  |
|  |  |  |  | 10 | - | 200 | - | 0.2 | 200 | . | 2800 |  |  |
| Output Voltage: Low-Level | ${ }^{\text {OL }}$ | Fan-out of 50 cos/mOS Inputs |  | 5 |  | 0.01 | - | 0 | 0.01 | - | 0.05 | V | 10. 11 |
|  |  |  |  | 10 | - | 0.01 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | $\cdots$ | 4.99 | 5 | -- | 4.95 | - | $v$ |  |
|  |  |  |  | 10 | 9.99 | - | 9.99 | 10 | - | 9.95 | - |  |  |
| Noise Immunity (All Inputs) For definition, see Appendix | $\mathrm{V}_{\text {NL }}$ |  | 0.95 | 5 | 1.5 | - | 1.5 | 2.25 | - | 1.4 | - | V | 20 |
|  |  |  | 2.9 | 10 | 3 | - | 3 | 4.5 | - | 2.9 | - |  |  |
|  | $\mathrm{V}_{\text {NH }}$ |  | 3.6 | 5 | 1.4 | - | 1.5 | 2.25 | . | 1.5 | . | V |  |
|  |  |  | 7.2 | 10 | 2.9 | - | 3 | 4.5 | - | 3 | - |  |  |
| Output Drive Current: <br> N-Channel | ${ }_{1}{ }^{N}$ | True Output | 0.4 | 5 | 1 | - | 0.8 | 3.2 | $\cdots$ | 0.7 | - | mA | 2, 6. |
|  |  |  | 0.5 | 10 | 3 | - | 2.5 | 10 | - | 2.2 | - |  |  |
|  |  | Comple. ment Output | 0.5 | 5 | 0.5 | - | 0.4 | 1.6 | - | 0.35 | - |  | 4.8. |
|  |  |  | 0.5 | 10 | 1.2 | - | 1 | 4 | - | 0.9 | - |  |  |
| P.Channel | ${ }_{10}{ }^{P}$ | True Output | 4.5 | 5 | -0.85 | - | -0.7 | -2.8 | -- | -0.6 | - | mA | 3.7. |
|  |  |  | 9.5 | 10 | -2.4 | - | -2 | -8 | - | -1.8 | - |  |  |
|  |  | Comple. ment Output | 4.5 | 5 | -0.35 | . | -0.3 | -1.2 | - | -0.27 | - |  | 5.9. |
|  |  |  | 9.5 | 10 | -1.1 | - | -0.9 | -3.6 | - | -0.8 | - |  |  |
| Input Current | $1 /$ | Any Input |  |  | - | - | - | 10 | - | -- | . | PA | , |

- Values shown are for true output.


Fig. 4-Typical n-channel drain charac-teristics-complement output.


Fig. 5-Typical p-channel drain charac-teristics-complement output.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \%{ }^{\circ} \mathrm{C}$
(See Appendix for Waveforms)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4041AD, CD4041AK |  |  | CD4041AE |  |  |  |  |
|  |  |  | VDD (Volts) | Viln. | TYP. | MAX. | MIN. | TYP. | MAX. |  |  |
| Propagation Delay Time: High-to-Low Level | ${ }^{\text {tPHL }}$ | True | 5 | - | 65 | 115 | - | 65 | 140 | ns | - |
|  |  | Output | 10 | - | 40 | 75 | - | 40 | 100 |  |  |
|  |  | Complement Output | 5 |  | 55 | 100 |  | 55 | 125 | ns | - |
|  |  |  | 10 |  | 30 | 45 |  | 30 | 65 |  |  |
| Low-to-High Level | ${ }^{\text {tPLH }}$ | True | 5 | - | 75 | 125 | - | 75 | 150 | ns | 14 |
|  |  | Output | 10 | - | 45 | 75 | - | 45 | 100 |  |  |
|  |  | Complement | 5 | - | 45 | 100 | - | 45 | 125 | ns | 15 |
|  |  | Output | 10 | - | 25 | 40 | - | 25 | 60 |  |  |
| Transition Time: High-to-Low Level | ${ }^{\text {t }}$ THL | True | 5 | - | 20 | 40 | - | 20 | 60 | ns | 12 |
|  |  | Output | 10 | - | 13 | 25 | - | 13 | 40 |  |  |
|  |  | Complement | 5 | - | 40 | 60 | - | 40 | 80 | ns | 13 |
|  |  | Output | 10 | - | 25 | 40 | - | 25 | 50 |  |  |
| Low-to-High Level | ${ }^{\text {T }}$ LLH | True | 5 | - | 20 | 40 | - | 20 | 60 | ns | 12 |
|  |  | Output | 10 | - | 13 | 25 | - | 13 | 40 |  |  |
|  |  | Complement | 5 | - | 35 | 55 | - | 35 | 75 | ns | - |
|  |  | Output | 10 | - | 25 | 40 | - | 25 | 50 |  |  |
| Tnput Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |

DYNAMIC ELECTRICAL CHARACTERISTICS (Driving TTL,DTL) AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}-\mathbf{V}_{\mathbf{S S}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ (True Output)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | TYPICAL CHARACTERISTICS CURVES Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{array}{\|l\|} \text { Driving } \\ \text { TTL,DTL } \end{array}$ | $\begin{aligned} & \text { CD4041AD } \\ & \text { CD4041AK } \end{aligned}$ |  |  | CD4041AE |  |  |  |  |
|  |  |  |  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |  |  |
| Propagation Delay Time: <br> High-To-Low Level | ${ }^{\text {tPHL }}$ | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | Med. <br> Power | - | 75 | 150 | - | 75 | 175 | ns | - |
|  |  | $R_{L}=20 k \Omega$ | Low <br> Power | - | 75 | 150 | - | 75 | 175 |  |  |
| Low-To-High Level | ${ }^{\text {PPLH}}$ | $R_{L}=2 \mathrm{k} \Omega$ | Med. <br> Power | - | 85 | 175 | - | 85 | 200 | ns | - |
|  |  | $R_{L}=20 \mathrm{k} \Omega$ | Low Power | - | 85 | 175 | - | 85 | 200 |  |  |
| Transition Time | $\begin{aligned} & { }^{{ }^{2} \text { THL }=} \\ & { }^{t^{T} L H} \end{aligned}$ | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ | Med. <br> Power | - | 20 | 50 | - | 20 | 75 | ns | - |
|  |  | $R_{L}=20 \mathrm{k} \Omega$ | Low Power | - | 20 | 50 | - | 20 | 75 |  |  |



Fig. 6-Minimum n-channel drain char-acteristics-true output.


Fig. 8-Minimum n-channel drain char-acteristics-complement output.

Fig. 10-Minimum and maximum transfer characteristics-true output.


Fig. 7-Minimum p-channel drain char-acteristics-true output.


Fig. 9-Minimum p-channel drain char-acteristics-complement output.


Fig. 11-Minimum and maximum transfer characteristicscomplement output.


Fig. 12-Typical transition time vs. $C_{L}$-true output.


Fig. 14-Typical low-to-high level propagation delay time vs. $C_{L}$-true output.


Fig. 13-Typical high-to-low level transition time vs. $C_{L^{-}}$ complement output.


Fig. 15-Typical low-to-high level propagation delay time vs. $C_{L}$-complement output.


Fig. 16-Typical power dissipation vs. frequency per output pair.


Fig. 17-Typical power dissipation vs. input rise and fall time per output pair.

## TYPICAL APPLICATIONS

A. Ultra-Low Power D/A Converter


Fig. 18-D/A converter block diagram.

For resolution and accuracy of $\pm 1 / 2$ least significant bit (LSB) choose the values for $R$ (shown in Table I) where $R$ equals the value of the external ladder resistor plus the switch source impedance.

These values have been tabulated for $V_{D D}=5 \mathrm{~V}$ and $\mathrm{V}_{S S}=0 \mathrm{~V}$. For different supply (reference) voltages, the switch source impedance must be computed and added to the value of $R$ shown in Table $I$.

TABLE I. RESISTANCE VALUES AT $V_{D D}-V_{S S}=5 \mathrm{~V}$,
$\mathrm{T}_{\mathrm{A}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$

| RESOLUTION | ACCURACY OF 1/2 LSB | $R_{\text {min }}$ <br> $(\Omega)$ |
| :---: | :--- | ---: |
| 4 bit | $\pm 3.25 \%$ of full scale | 3.5 k |
| 6 bit | $\pm 0.8 \%$ of full scale | 14 k |
| 8 bit | $\pm 0.2 \%$ of full scale | 56 k |
| 10 bit | $\pm 0.05 \%$ of full scale | 224 k |
| 12 bit | $\pm 0.0125 \%$ of full scale | 896 k |

## B. Transmission Line Driver

Drive 100 pF load at 75 ns delay (typ.) $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$

TABLE II. ON RESISTANCE VALUES

$$
A T V_{D S}=0.1 \mathrm{~V}, T_{A}=25^{\circ} \mathrm{C}
$$

| $V_{\text {DD }}-V_{S S}$ <br> $\left(V_{\text {olts }}\right)$ | $R_{N}$ <br> $(\Omega)$ | $R_{P}$ <br> $(\Omega)$ |
| :---: | :---: | :---: |
| 5 | $175 \pm 50$ | $200 \pm 75$ |
| 10 | $75 \pm 25$ | $90 \pm 30$ |

C. CD4031A (64-Stage Static Shift Register) Clock Driver (80pF Load)

$$
t_{r}=t_{f}=40 \mathrm{~ns} \text { (typ.) }, V_{D D}-V_{S S}=10 \mathrm{~V}
$$



Fig. 19-Quiescent device cutrent.


Fig. 20-Noise immunity.

Solid State Division


## COS/MOS Quad Clocked "D" Latch

## Special Features:

- Medium Speed Operation . . . tpHL $=\mathbf{t P L H}=50 \mathrm{~ns}$ (typ) at
$V_{D D}=10 \mathrm{~V}$ and $C_{L}=15 \mathrm{pF}$
- Clock Polarity Control
- $\mathbf{Q}$ and $\overline{\mathbf{Q}}$ Outputs
- Common Clock
- Low Power TTL Compatible

Applications:

- Buffer Storage
- Holding Register
- General Digital Logic

RCA-CD4042A types contain four latch circuits, each strobed by a common clock. Complementary buffered outputs are available from each circuit. The impedance of the N and P-channel output devices is balanced and all outputs are electrically identical.

Information present at the data input is transferred to outputs $\mathbf{Q}$ and $\overline{\mathrm{Q}}$ during the CLOCK level which is programmed by the POLARITY input. For POLARITY $=0$ the transfer occurs during the O CLOCK level and for POLARITY = 1 the transfer occurs during the 1 CLOCK level. The outputs follow the data input providing the CLOCK and POLARITY levels defined above are present. When a CLOCK transition occurs (positive for POLARITY $=0$ and negative for POLARITY $=1$ ) the information present at the input during the CLOCK transition is retained at the outputs until an opposite CLOCK transition occurs.
CD4042A types are supplied in 16-lead ceramic flat-packs, plastic dual-in-line packages, and both welded-seal and fritseal ceramic dual-in-line packages.

MAXIMUM RATINGS, Absolute-Maximum Values:


File No. 589
STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\left.\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}\right)$
(Recommended DC Supply Voltage (VDD $-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD40 | AD, | 4042 | , CD | 42A |  |  |  |
|  |  |  | $V_{D D}$ Volts | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device |  | Inputs <br> to <br> Ground <br> or <br> $V_{D D}$ | 5 | - | 1 | - | 0.005 | 1 | - | 60 | $\mu \mathrm{A}$ | 8 |
|  |  |  | 10 | - | 2 | - | 0.005 | 2 | - | 120 |  |  |
| Quiescent Device Dissipation/Package | ${ }^{\text {P }}$ |  | 5 | - | 5 | - | 0.025 | 5 | - | 300 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | 20 | - | 0.05 | 20 | - | 1200 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ | Fan-out of 50 COS/MOS Inputs | 5 | - | 0.01 | - | 0 | 0.01 | - | 0.05 | V | - |
|  |  |  | 10 | - | 0.01 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | 4.99 | 5 | . | 4.95 |  | V |  |
|  |  |  | 10 | 9.99 | - | 9.99 | 10 | - | 9.95 | - |  |  |
| Noise Immunity (All Inputs) <br> For Definition, See Application | $\mathrm{V}_{\mathrm{NL}}$ | $\mathrm{V}_{\mathrm{O}}=0.95 \mathrm{~V}$ | 5 | 1.5 | - | 1.5 | 2.25 | - | 1.4 | - | V | 9 |
|  |  | $\mathrm{V}_{\mathrm{O}}=2.9 \mathrm{~V}$ | 10 | 3 | - | 3 | 4.5 | - | 2.9 | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | $\mathrm{V}_{\mathrm{O}}=3.6 \mathrm{~V}$ | 5 | 1.4 | - | 1.5 | 2.25 | - | 15 | - | V |  |
|  |  | $\mathrm{V}_{\mathrm{O}}=7.2 \mathrm{~V}$ | 10 | 2.9 | - | 3 | 4.5 | - | 3 | . |  |  |
| Output Drive Current: <br> N-Channel | ${ }^{1} \mathrm{D}^{N}$ | $V_{O}=0.5 \mathrm{~V}$ | 5 | 0.5 | - | 0.4 | 1 | - | 0.27 | - | mA | 2.4 |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 1.25 | - | 1 | 2 | - | 07 | - |  |  |
| P.Channel | ${ }_{1} D^{P}$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.45 | - | -0.35 | 1 | - | -0.25 | - | mA | 3.5 |
|  |  | $V_{O}=9.5 \mathrm{~V}$ | 10 | -1.15 | - | -0.9 | 2 | - | -0.6 | - |  |  |
| Input Current | $1 /$ | Any Input |  | - | - | - | 10 | - | - | -- | pA | - |

- For inverter output only.


Fig.2-Typ. n-channel drain characteristics.

DRAIN-TO-SOURCE VOLTAGE $\left(V_{D S}\right)-V$


92CS-20187
Fig.3-Typ. p-channel drain characteristics.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYmbol | test CONDITIONS |  | LIMITS |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | 4042 |  |  |  |  |  |
|  |  |  | $\begin{aligned} & \text { VDD } \\ & \text { Vols } \end{aligned}$ | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device | 1 | Inputs <br> to <br> Ground <br> or <br> $V_{D D}$ | 5 | - | 10 | - | 0.01 | 10 | - | 140 | $\mu \mathrm{A}$ | 8 |
|  |  |  | 10 | - | 20 | - | 0.02 | 20 | - | 280 |  |  |
| Quiescent Device Dissipation/Package | ${ }^{P}$ D |  | 5 | - | 50 | - | 0.05 | 50 | - | 700 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | 200 | - | 0.2 | 200 | -- | 2800 |  |  |
| Output Voltage: |  | Fan-out of 50 cos/mos Inputs | 5 | -- | 0.01 | - | 0 | 0.01 | - | 0.05 | v | - |
|  |  |  | 10 | - | 0.01 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | 4.99 | 5 | - | 4.95 | - | v |  |
|  |  |  | 10 | 9.99 | - | 9.99 | 10 | - | 9.95 | - |  |  |
| Noise Immunity (All Inputs) | $v_{N L}$ | $\mathrm{v}_{\mathrm{O}}=0.95 \mathrm{~V}$ | 5 | 1.5 | - | 1.5 | 2.25 | - | 1.4 | - | $v$ | 9 |
|  |  | $\mathrm{V}_{\mathrm{O}}=2.9 \mathrm{~V}$ | 10 | 3 | - | 3 | 4.5 | - | 2.9 | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | $\mathrm{V}_{\mathrm{O}}=3.6 \mathrm{~V}$ | 5 | 1.4 | - | 1.5 | 2.25 | - | 1.5 | - | $\checkmark$ |  |
|  |  | $\mathrm{V}_{0}=7.2 \mathrm{~V}$ | 10 | 2.9 | - | 3 | 4.5 | - | 3 | - |  |  |
| Output Drive Current: | ${ }^{1}{ }^{N}$ | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 5 | 0.24 | - | 0.2 | 1 | - | 0.18 | - | mA | 2.4 |
| N -Channel |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 0.6 | - | 0.5 | 2 | - | 0.45 | - |  |  |
| P.Channel | ${ }^{1} D^{P}$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.2 | - | -0.175 | -1 | - | -0.15 | - | mA | 3.5 |
|  |  | $\mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | 10 | -0.34 | - | -0.45 | -2 | - | -0.4 | - |  |  |
| Input Current | 1 | Any Input |  | - | - | - | 10 | - | - | - | pA | - |

- For inverter output only.


Fig.4-Min. n-channel drain characteristics.


Fig.5-Min. p-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{S S}=O V, C_{L}=15 \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$, Typical Temperature Coefficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} C$. (See Appendix for Waveforms) except $t_{r} C L$ and $t_{f} C L$.

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{gathered} \text { CD4042AD,CD4042AK } \\ \text { CD4042AF } \\ \hline \end{gathered}$ |  |  | CD4042AE |  |  |  |  |
|  |  | $\begin{aligned} & \text { VDD } \\ & \text { (Volts) } \end{aligned}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time | tPHL, | 5 | - | 150 | 300 | - | 150 | 400 | ns |  |
|  | ${ }_{\text {tPLH }}$ | 10 | - | 75 | 125 | - | 75 | 200 |  |  |
| Transition Time | 'THL, | 5 | - | 100 | 200 | - | 100 | 300 | ns |  |
|  | t TLH | 10 | - | 50 | 100 | - | 50 | 150 |  |  |
| Minimum Clock Pule Width | ${ }^{\text {t }}$ WL , | 5 | - | 175 | 250 | - | 175 | 350 | ns | - |
|  | tWH | 10 | - | 50 | 75 | - | 50 | 175 |  |  |
| Clock | ${ }^{\text {tr CL, }}$ | 5 | - | - | 15 | - | - | 15 | $\mu s$ | - |
| Rise \& Fall Time | $t_{\mathrm{fCL}}$ | 10 | - | - | 5 | - | - | 5 |  |  |
| Set-Up Time |  | 5 | - | 50 | 100 | - | 50 | 125 | ns | - |
|  |  | 10 | - | 25 | 50 | - | 25 | 60 |  |  |
| Input Capacitance | $\mathrm{C}_{1}$ | - | - | 5 | - | - | 5 | - | pF | - |



Fig.6-Typical propagation delay time vs. VDD.


92CS-20198

Fig. 8 - Quiescent device current.


Fig.7-Typical dissipation characteristics.


92Cs-20199

Fig. 9 - Noise Immunity


Solid State Division

Digital Integrated Circuits
Monolithic Silicon CD4043AD, CD4043AE,CD4043AK, CD4044AD,CD4044AE,CD4044AK


## COS/MOS Quad 3-State R/S Latches

Quad NOR R/S Latch - CD4043A
Quad NAND R/S Latch - CD4044A

## Special Features:

- Medium Speed Operation
- 3-Level Outputs with Common Output Enable
- Separate Set and Reset Inputs for Each Latch
- Low Power TTL Compatible
- NOR and NAND Configurations


## Applications:

- Holding Register in Multi-

Register System

- Four Bits of Independent Storage with Output Enable
- Strobed Register
- General Digital Logic

RCA.CD4043A types are quad cross-coupled 3 -state COS/MOS NOR latches and the CD4044A types are quad cross-coupled 3-state COS/MOS NAND latches. Each latch has a separate $\mathbf{Q}$ output and individual SET and RESET inputs. The $\mathbf{Q}$ outputs are gated through transmission gates controlled by a common ENABLE input. A logic " 1 " or "high" on the ENABLE input connects the latch states to the Q outputs. A logic " O " or "low" on the ENABLE input disconnects the
latch states from the Q outputs, resulting in an open circuit condition on the Qoutputs. The open circuit feature allows common bussing of the outputs. The logic operation of the latches is summarized in the truth table below shown in Fig. 1.
The CD4043A and CD4044A are supplied in 16-lead dual-inline ceramic packages (CD4043AD and CD4044AD), 16-lead ceramic flat packs (CD4043AK and CD4044AK), and 16-lead dual-in-line plastic packages (CD4043AE, CD4044AE).

## MAXIMUM RATINGS, Absolute-Maximum Values:



CD4044A TERMINAL DIAGRAM


92CS-20222



| $S$ | $R$ | $E$ | $Q$ |
| :--- | :--- | :--- | :--- |
| $x$ | $x$ | 0 | $O C^{*}$ |
| 0 | 0 | 1 | $N C+$ |
| 1 | 0 | 1 | 1 |
| 0 | 1 | 1 | 0 |
| 1 | 1 | 1 | $\Delta$ |

* OPEN CIRCUIT
+ NO CHANGE
$\triangle$ DOMINATED BY S = I INPUT

CD 4044 A-NAND


| $S$ | $R$ | $E$ | $Q$ |
| :--- | :--- | :--- | :--- |
| $x$ | $x$ | 0 | $O C^{*}$ |
| 1 | 1 | 1 | $N C+$ |
| 0 | 1 | 1 | 1 |
| 1 | 0 | 1 | 0 |
| 0 | 0 | 1 | $\Delta \Delta$ |

* open circuit
+ NO CHANGE
$\triangle \Delta$ DOMINATED BY R=O INPUT
92CS-20211
92cs-20212

Fig. 1 - Logic diagrams \& truth tables.


Fig.2-Schematic diagram-CD4043A.
Fig.3-Schematic diagram-CD4044A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs $\mathrm{v}_{\mathrm{SS}} \leq \mathrm{v}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage (VDD $-V_{S S}$ ) . . . . . . . . . 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | VDD Volts | LIMITS |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig. No |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4043AD, CD4043AK, CD4044AD, CD4044AK |  |  |  |  |  |  |  |  |
|  |  |  |  | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  | Min. | Max. | Min. | TYp. | Max. | Min. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ | Inputs to Ground or $V_{D D}$ | 5 | - | 1 | - | 0.005 | 1 | - | 60 | A | 11 |
|  |  |  | 10 | - | 2 | - | 0.005 | 2 | - | 120 |  |  |
| Quiescent Device Dissipation/Package | ${ }^{\text {P }}$ |  | 5 | - | 5 | - | 0.025 | 5 | - | 300 |  |  |
|  |  |  | 10 | - | 20 | - | 0.05 | 20 | - | 1200 | $\mu \mathrm{W}$ | - |
| Output Voltage: Low-Level | $v_{\text {OL }}$ | Fan-out of 50 COS/MOS Inputs | 5 | - | 0.01 | - | 0 | 001 | - | 0.05 | V | - |
|  |  |  | 10 | - | 0.01 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | 4.99 | 5 | - | 495 | - | V |  |
|  |  |  | 10 | 9.99 | - | 999 | 10 | - | 995 | - |  |  |
| Noise Immunity (All Inputs) | $V_{\text {NL }}$ | $\mathrm{V}_{0}=0.95 \mathrm{~V}$ | 5 | 1.5 | - | 15 | 225 | - | 14 | - | V | 12 |
|  |  | $v_{0}=2.9 \mathrm{~V}$ | 10 | 3 | - | 3 | 4.5 | - | 29 | - |  |  |
| For definition, see Appendix | $\mathrm{V}_{\text {NH }}$ | $\mathrm{v}_{0}=3.6 \mathrm{~V}$ | 5 | 1.4 | - | 15 | 2.25 | - | 15 | - | V |  |
|  |  | $\mathrm{V}_{\mathrm{O}}=7.2 \mathrm{~V}$ | 10 | 2.9 | - | 3 | 4.5 | - | 3 | - |  |  |
| N-Channel | ${ }^{1} \mathrm{D}^{N}$ | $v_{0}=0.5 \mathrm{~V}$ | 5 | 0.25 | - | 0.2 | 0.5 | - | 0.14 | - | mA | 4,6 |
|  |  | $v_{0}=0.5 v$ | 10 | 0.61 | - | 0.5 . | 1 | - | 0.35 | - |  |  |
| P. Channel | ${ }^{1} D^{P}$ | $v_{0}=4.5 \mathrm{~V}$ | 5 | -0.22 | - | -0.175 | -0.5 | - | -0.12 | - | $m A$ | 5,7 |
|  |  | $v_{O}=9.5 \mathrm{~V}$ | 10 | -0.5 | - | -0.4 | -1 | - | -0.28 | - |  |  |
| Input Current | 1 | Any Input | - | - | - | - | 10 | - | - | - | DA | - |



92cs-20215


Fig.5-Typ. p-channel drain characteristics.

File No. 590
STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $V_{D D}-V_{S S}$ ) . . . . . . . . 3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | VDD Volts | LIMITS |  |  |  |  |  |  | UNITS | CHARAC TERISTIC CURVES \& TEST CIRCUITS Fig No |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4043AE, CD4044AE |  |  |  |  |  |  |  |  |
|  |  |  |  | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  | Mın. | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device | 1 | Inputs <br> to <br> Ground <br> or $v_{\mathrm{DD}}$ | 5 | - | 10 | - | 0.01 | 10 | - | 140 | $\mu \mathrm{A}$ | 11 |
|  |  |  | 10 | - | 20 | - | 0.02 | 20 | - | 280 |  |  |
| Quiescent Dence Dissipotion/Package | ${ }^{P}$ D |  | 5 | - | 50 | - | 0.05 | 50 | - | 700 | $\mu \mathrm{W}$ | - - |
|  |  |  | 10 | - | 200 | - | 0.2 | 200 | - | 2800 |  |  |
| Output Voltage: | VOL | Far out of 50 cos/mOS Inputs | 5 | - | 0.01 | - | 0 | 0.01 | - | 0.05 | V | - |
|  | OL |  | 10 | - | 001 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | ${ }^{\mathrm{V}} \mathrm{OH}$ |  | 5 | 4.99 | - | 499 | 5 | - | 4.95 | - | V |  |
|  |  |  | 10 | 9.99 | - | 999 | 10 | - | 9.95 | - |  |  |
| Noise Immunity (All Inputs) For Definition See Appendix | $V_{\text {NL }}$ | $\mathrm{V}_{\mathrm{O}}=0.95 \mathrm{~V}$ | 5 | 15 | - | 15 | 225 | - | 14 | - | $\checkmark$ | 12 |
|  |  | $\mathrm{V}_{\mathrm{O}}=2.9 \mathrm{~V}$ | 10 | 3 | - | 3 | 4.5 | - | 2.9 | - |  |  |
|  | $\mathrm{V}_{\text {NH }}$ | $\mathrm{V}_{\mathrm{O}}=3.6 \mathrm{~V}$ | 5 | 14 | - | 15 | 2.25 | - | 15 | - | $\checkmark$ |  |
|  |  | $\mathrm{V}_{\mathrm{O}}=7.2 \mathrm{~V}$ | 10 | 2.9 | - | 3 | 4.5 | - | 3 | - |  |  |
| N-Channel | ${ }_{1}{ }^{N}$ | $V_{O}=0.5 \mathrm{~V}$ | 5 | 0.12 | - | 0.1 | 0.5 | - | 0.09 | - | mA | 4.6. |
|  |  | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ | 10 | 0.3 | - | 0.25 | 1 | - | 0.22 | - |  |  |
| P.Channel | ${ }^{1} D^{P}$ | $\mathrm{V}_{\mathrm{O}}=4.5 \mathrm{~V}$ | 5 | -0.11 | - | -0.09 | -0.5 | - | -0.08 | - | $m A$ | 5.7. |
|  |  | $V_{O}=9.5 \mathrm{~V}$ | 10 | -0.24 | - | -0.2 | -1 | $-$ | -0.18 | - |  |  |
| Input Current | $1 /$ | Any Input | - | - | - | - | 10 | - | - | - | nA | - |




92CS-20218

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=250 \mathrm{C}, \mathrm{V}_{\mathrm{SS}}=\mathrm{OV}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5 p F}$, and input rise and fall times $=\mathbf{2 0} \mathbf{n s}$, except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ and $\mathrm{t}_{\mathrm{f}} \mathrm{CL}$.

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | LIMITS |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | CD4043AD,CD4043AKCD4044AD,CD4044AK |  |  | CD4043AE, CD4044AE |  |  |  |  |
|  |  | (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  | Fig. No. |
| Propagation Delay Time | ${ }^{\text {tPHL, }}$ | 5 | - | 175 | 350 | - | 175 | 400 | ns | 8 |
|  | ${ }_{\text {tPLH }}$ | 10 | - | 75 | 175 | - | 75 | 200 |  |  |
| Transition Time | ${ }^{\text {t }}$ (HL, | 5 | - | 100 | 200 | - | 100 | 250 | ns | 9 |
|  | t TLH | 10 | - | 50 | 100 | - | 50 | 125 |  |  |
| Minimum Set and Reset Pulse Width | ${ }^{\text {t WH }}$ (S). | 5 | - | 80 | 200 | - | 80 | 225 | ns | - |
|  | tWH(R) | 10 | - | 40 | 100 | - | 40 | 110 |  |  |
| Input Capacitance | $\mathrm{C}_{1}$ | - | - | 5 | - | - | 5 | - | pF | - |



Fig.8-Typ. propagation delay time vs. $C_{L}$.


Fig.9-Typ. transition time vs. $C_{L}$.


Fig. 10-Typ. dissipation characteristics.

TEST CIRCUITS


Fig.11-Quiescent current.


Fig.12-Noise immunity.

TYPICAL APPLICATIONS


Fig. 13 - Switch bounce eliminator.


Fig.14-Multiple bus storage.


## COS／MOS 21－Stage Counter

## Applications：

－Digital equipment in which ultra－low dissipation and／or operation using a battery source are primary design requirements．
－Accurate timing from a crystal oscillator for timing applications such as wall clocks，table clocks，automobile clocks，and digital timing references in any circuit requiring accurately timed outputs at various intervals in the counting sequence．
－Driving miniature synchronous motors，stepping motors，or external bipolar transistors in push－pull fashion．

RCA－CD4045A is a timing circuit consisting of 21 counter stages，two output－shaping flip flops，two inverter output drivers，three 5.5 V zener diodes（providing transient pro－ tection at 16.5 V ），and input inverters for use in a crystal oscillator．This device may be operated over a 3 to 15 V supply voltage range．The CD4045A configuration provides 21 flip－flop counting stages，and two flip－flops for shaping the output waveform for a $3.125 \%$ duty cycle．Push－pull operation is provided by the inverter output drivers．
The first inverter is intended for use as a crystal oscillator／ amplifier．However，it may be used as a normal logic inverter if desired．
A crystal oscillator circuit can be made less sensitive to voltage supply variations by the use of source resistors．In this device，the sources of the $p$ and $n$ transistors have been brought out to package terminals．If external resistors are not required，the sources must be shorted to their respective

## Features：

－Operation from 3 to 15 volts
－Microwatt quiescent dissipation．
$2.5 \mu \mathrm{~W}$（typ．）＠ $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V} ; 10 \mu \mathrm{~W}($ typ．$) @ V_{D D}=10 \mathrm{~V}$
－Very－low operating dissipation．
1 mW （typ．）；＠VDD $=5 \mathrm{~V}, \mathrm{f} \phi=1 \mathrm{MHz}$
－Output drivers with sink or source capability． 7 mA （typ．）＠ $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$（sink） 5 mA （typ．）$@ \mathrm{~V}_{\mathrm{O}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=5 \mathrm{~V}$（source）
－Medium speed（typ．）．．．． $\mathbf{f} \phi=5 \mathrm{MHz} @ V_{D D}=5 \mathrm{~V}$ $\mathrm{f} \phi=10 \mathrm{MHz} @ \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$
－ 16.5 V zener diode transient protection on chip for automotive use
substrates $\left(S_{p}\right.$ to $V_{D D} S_{N}$ to $\left.V_{S S}\right)$ ．See Fig． 1.
CD4045A types are supplied in a 16 －lead flat pack，and in both 16 －lead ceramic and plastic dual－in－line packages．

Maximum Ratings，Absolute－Maximum Values：

| Storage－Temperature Range ．．．．$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |  |
| :---: | :---: |
| Operating－Temperature Range： |  |
| Ceramic packages | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Plastic package | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| DC Supply Voltage Range（ $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\text {SS }}$ ） | -0.5 to +15 V |
| Device Dissipation： <br> （per package，including zener diodes） | mW |
| All Inputs． | $\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ |
| Recommended DC Supply Voltage Range（ $V_{D D}-V_{S S}$ ） | 3 to 15 V |
| Recommended Input Voltage Swing | $\mathrm{V}_{\text {DD }}$ to $\mathrm{V}_{\text {SS }}$ |
| Peak Zener Diode Current （decay $\tau=80 \mathrm{~ms}$ ） | 150 mA |

```
Lead Temperature (During soldering):
    At distance 1/16 \pm1/32 inch (1.59 \pm0.79 mm)
        from case for }10\mathrm{ seconds max.
        265 %}\textrm{C
```

NOTE 1：To minimize power dissipation in the zener diodes， and to ensure device dissipation less than 200 mW ， a $150 \Omega$ current－limiting resistor must be placed in series with the power supply for $V_{D D}>13 \mathrm{~V}$ ．
NOTE 2：Observe power supply terminal connections．VDD is terminal No． 3 and $V_{\text {SS }}$ is terminal No． 14 （not 16 and 8 respectively，as in all other CD4000A Series 16－lead devices）．


92CM-20895
Fig. 1 -CD4045A and outboard components in a typical 21 -stage counter application.


Fig. 2-Typical dissipation vs input frequency (21 counting stages).


Fig. 3-Typical n-channel drain characteristics.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\left.\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}\right)$
(Recommended DC Supply Voltage (VDD $-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No . |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4045AD, CD4045AK |  |  |  |  |  |  |  |  |
|  |  |  | VDD |  | ${ }^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | ${ }^{\circ} \mathrm{C}$ |  |  |
|  |  |  | Volts | Min . | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device Current | IL |  | 5 | - | 15 | - | 0.5 | 15 | - | 900 | $\mu \mathrm{A}$ | 11 |
|  |  |  | 10 | - | 25 | - | 1 | 25 | - | 1500 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | 0.075 | - | 0.0025 | 0.075 | - | 4.5 | mW |  |
|  |  |  | 10 | - | 0.25 | - | 0.01 | 0.25 | - | 15 |  |  |
| Output Voltage: Low-Level | $\mathrm{v}_{\mathrm{OL}}$ | Driving COS/MOS | 5 | . | 0.01 | - | 0 | 0.01 | : | 0.05 | V |  |
|  |  |  | 10 | - | 0.01 | - | 0 | 0.01 | $\cdots$ | 0.05 |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | 4.99 | 5 | - | 4.95 | . |  |  |
|  |  |  | 10 | 9.99 | - | 9.99 | 10 | - | 9.95 |  |  |  |
| Noise Immunity (All Inputs) | $\mathrm{V}_{\mathrm{NL}}$ | $\begin{array}{r} \mathrm{V}_{\mathrm{O}} \\ \text { Volts } \end{array}$ | 5 | 1.5 |  | 1.5 | 2.25 |  | 1.4 |  | V |  |
|  |  |  | 10 | 3 |  | 3 | 4.5 |  | 2.9 |  |  |  |
|  | $\mathrm{V}_{\text {NH }}$ |  | 5 | 1.4 | . | 1.5 | 2.25 | - | 1.5 |  |  | 12 |
|  |  |  | 10 | 2.9 | . | 3 | 4.5 |  | . 3 |  |  |  |
| Output Drive Current N-Channel | ${ }^{1} \mathrm{D} N$ | 0.5 | 5 | 4.4 |  | 3.5 | 7 |  | 2.5 |  | mA |  |
|  |  | 0.5 | 10 | 6.9 | - | 5.5 | 11 |  | 3.9 | . |  |  |
| P.Channel | ${ }^{1} D^{P}$ | 4.5 | 5 | -3.1 | - | -2.5 | -5 | . | -1.8 | . | mA |  |
|  |  | 9.5 | 10 | -5.6 |  | -4.5 | -9 | - | -3.2 | . |  |  |
| Input Current | 11 |  |  | - | - |  | 10 | - |  |  | pA |  |
| Zener Breakdown Voltage | $V$ (BR) $Z$ | 1-100 2 A |  | 13.3 | 17.8 | 13.5 | 16.5 | 18 | 13.7 | 18.2 | V | 7 |


| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  | UNITS | CHARACTERISTIC CIIRVES \& TEST CIRCUITS Fig. No . |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | 4045 |  |  |  |  |  |
|  |  |  | VD <br> Volts | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device Current | 'L |  | 5 | - | 50 | - | 1 | 50 | $\cdots$ | 700 | $\mu \mathrm{A}$ | 11 |
|  |  |  | 10 | - | 100 | - | 2 | 100 | - | 1400 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | 0.25 | - | 0.005 | 0.25 | - | 3.5 | mW |  |
|  |  |  | 10 |  | 1 | - | 0.02 | 1 | - | 14 |  |  |
| Output Voltage Low-Level | $\mathrm{V}_{\mathrm{OL}}$ | Driving cos/mos | 5 |  | 0.01 | -- | 0 | 0.01 | - | 0.05 | v |  |
|  |  |  | 10 |  | 0.01 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | ${ }^{\mathrm{OH}}$ |  | 5 | 4.99 | .. | 4.99 | 5 | $\cdots$ | 4.95 | - |  |  |
|  |  |  | 10 | 9.99 | - | 9.99 | 10 | . | 9.95 | . |  |  |
| Noise Immunity (All Inputs) | $\mathrm{V}_{\mathrm{NL}}$ | $\begin{array}{r} \mathrm{V}_{\mathrm{O}} \\ \text { Volts } \end{array}$ | 5 | 1.5 | . | 1.5 | 2.25 |  | 1.4 | - | v |  |
|  |  |  | 10 | 3 |  | 3 | 4.5 | - | 2.9 | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 5 | 1.4 |  | 1.5 | 2.25 | . | 1.5 | - |  | 12 |
|  |  |  | 10 | 2.9 |  | 3 | 4.5 | - | 3 |  |  |  |
| Output Drive Current N-Channel | ${ }^{1} \mathrm{DN}$ | 0.5 | 5 | 2.2 |  | 1.8 | 7 | - | 1.3 | - | mA |  |
|  |  | 0.5 | 10 | 3.5 |  | 2.8 | 11 |  | 2.0 | . |  |  |
| P-Channel | ${ }_{10}{ }^{P}$ | 4.5 | 5 | -1.6 |  | -1.3 | -5 | - | -0.9 | - | mA |  |
|  |  | 9.5 | 10 | -2.8 |  | -2.3 | -9 | . | -1.6 | . |  |  |
| Input Current | 1 |  |  |  |  |  | 10 |  |  | - | DA |  |
| Zener Breakdown Voltage | $V(B R) Z$ | $1100 \mu \mathrm{~A}$ |  | 13.3 | 17.8 | 13.5 | 16.5 | 18 | 13.6 | 18.1 | V | 7 |

File No. 614

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$, and input rise and fall times $=20 \mathrm{~ns}$, except $\mathrm{t}_{\mathrm{r}} \phi$ and $\mathrm{t}_{\boldsymbol{f} \phi}$.
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$.



Fig. 4-Minimum n-channel drain characteristics.


92CS-20898

Fig. 5-Typical p-chaninel drain characteristics.


Fig. 7 - Typical zener diode characteristics.


Fig. 8-Typical propagation delay ( $\phi_{1}$ to $y$ or $y+d$ out) vs $V_{D D}$.


Fig. 9-Typical transition time vs $C_{L}$.


92cs-20903


Fig. 11 - Quiescent device current test circuit.


Fig. 12 - Noise immunity test circuit.


Solid State Division

## Digital Integrated Circuits

## COS/MOS Micropower Phase-Locked Loop

## Features:

- Very low power consumption . . $70 \mu \mathrm{~W}$ (typ.) at VCO $f_{0}=10 \mathrm{kHz}, \mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$
- Operating frequency range . . . . . . up to 1.2 MHz (typ.) at $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$

■ Wide supply-voltage range . . . . . . . . . . VDD - VSS $=5$ to 15 V

- Low frequency drift . . : . . . . . . $0.06 \% /{ }^{\circ} \mathrm{C}$ (typ.) at $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$
- Choice of two phase comparators . 1. Exclusive-OR network

2. Edge-controlled memory network with phase-pulse output for lock indication

- High VCO linearity
- VCO inhibit control for ON-OFF keying and ultra-low standby power consumption

The RCA-CD4046A COS/MOS Micropower Phase-Locked Loop (PLL) consists of a low-power, linear voltage-controlled oscillator (VCO) and two different phase comparators having a common signal-input amplifier and a common comparator input. A 5.2-V zener diode is provided for supply regulation if necessary. The CD4046A is supplied in a 16 -lead dual-in-line ceramic package (CD4046AD), a 16 -lead dual-in-line plastic package (CD4046AE), and a 16 -lead flat pack (CD4046AK). It is also available in chip form (CD4046AH).

## VCO Section

The VCO requires one external capacitor C1 and one or two external resistors (R1 or R1 and R2). Resistor R1 and capacitor C1 determine the frequency range of the VCO and resistor R2 enables the VCO to have a frequency offset if required. The high input impedance ( $10^{12 \Omega}$ ) of the VCO simplifies the design of low-pass filters by permitting the designer a wide choice of resistor-to-capacitor ratios. In order not to load the low-pass filter, a source-follower output of the VCO input voltage is provided at terminal 10 (DEMODULATED OUTPUT). If this terminal is used, a load resistor (RS) of $10 \mathrm{k} \Omega$ or more should be connected from this terminal to $\mathrm{V}_{\mathrm{SS}}$. If unused this terminal should be left open. The VCO can be connected either directly or through frequency dividers to the comparator input of the phase comparators. A full COS/MOS logic swing is available at the output of the VCO and allows direct coupling to COS/MOS frequency dividers such as the RCA-CD4024A,CD4018A,CD4020A,CD4022A, or CD4029A. One or more CD4018A (Presettable Divide-by-N Counter) or CD4029A (Presettable Up/Down Counter), together with the CD4046A (Phase-Locked Loop) can be used to build a micropower low-frequency synthesizer. A logic 0 on the INHIBIT input "enables" the VCO and the source follower, while a logic 1 "turns off" both to minimize stand-by power consumption.

- Source-follower output of VCO control input (Demod. output)
- Zener diode to assist supply regulation


## Applications:

- FM demodulator and modulator
- Frequency synthesis and multiplication
- Frequency discriminator
- Tone decoding
- Data synchronization
- FSK - Modems
- Voltage-to-frequency conversion . Signal conditioning
(See ICAN-6101 for application information and circuit details)


Fig. 1 - COS/MOS phase-locked loop block diagram.

## Phase Comparators

The phase-comparator signal input (terminal 14) can be directcoupled provided the signal swing is within COS/MOS logic levels [logic " 0 " $\leqslant 30 \%$ (VDD-VSS), logic " 1 " $\geqslant 70 \%$ ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ )]. For smaller swings the signal must be capacitively coupled to the self-biasing amplifier at the signal input.
Phase comparator I is an exclusive-OR network; it operates analagously to an over-driven balanced mixer. To maximize the lock range, the signal- and comparator-input frequencies must have a $50 \%$ duty cycle. With no signal or noise on the signal input, this phase comparator has an average output voltage equal to VDD/2. The low-pass filter connected to the output of phase comparator I supplies the averaged voltage to the VCO input, and causes the VCO to oscillate at the center frequency ( $\mathrm{f}_{\mathrm{o}}$ ).
The frequency range of input signals on which the PLL will lock if it was initially out of lock is defined as the frequency capture range $\left(2 f_{c}\right)$.
The frequency range of input signals on which the loop will stay locked if it was initially in lock is defined as the frequency lock range ( $2 \mathrm{f}_{\mathrm{L}}$ ). The capture range is $\leqslant$ the lock range.

With phase comparator I the range of frequencies over which the PLL can acquire lock (capture range) is dependent on the low-pass-filter characteristics, and can be made as large as the lock range. Phase-comparator I enables a PLL system to remain in lock in spite of high amounts of noise in the input signal.
One characteristic of this type of phase comparator is that it may lock onto input frequencies that are close to harmonics of the VCO center-frequency. A second characteristic is that the phase angle between the signal and the comparator input varies between $0^{\circ}$ and $180^{\circ}$, and is $90^{\circ}$ at the center frequency. Fig. 2 shows the typical, triangular, phase-to-output response charac-


Fig. 2 - Phase-comparator / characteristics at low-pass filter output.
teristic of phase-comparator I. Typical waveforms for a COS/ MOS phase-locked-loop employing phase comparator I in locked condition of $f_{0}$ is shown in Fig. 3.
Phase-comparator II is an edge-controlled digital memory network. It consists of four flip-flop stages, control gating, and a three-state output circuit comprising p - and n -type drivers having a common output node. When the p-MOS or n-MOS drivers are ON they pull the output up to $V_{D D}$ or down to $\mathrm{V}_{\text {SS }}$, respectively. This type of phase comparator acts only on the positive edges of the signal and comparator inputs. The


Fig. 3 - Typical waveforms for COS/MOS phase-locked loop employing phase comparator I in locked condition of $f_{0}$.
duty cycles of the signal and comparator inputs are not important since positive transitions control the PLL system utilizing this type of comparator. If the signal-input frequency is higher than the comparator-input frequency, the p-type output driver is maintained ON continuously. If the signal-input frequency is lower than the comparator-input frequency, the n-type output driver is maintained ON continuously. If the signal- and comparator-input frequencies are the same, but the signal input lags the comparator input in phase, the $n$-type output driver is maintained ON for a time corresponding to the phase difference. If the signal- and comparator-input frequencies are the same, but the comparator input lags the signal in phase, the p-type output driver is maintained ON for a time corresponding to the phase difference. Subsequently, the capacitor voltage of the low-pass filter connected to this phase comparator is adjusted until the signal and comparator inputs are equal in both phase and frequency. At this stable point both $p$ - and $n$-type output drivers remain OFF and thus the phase comparator output becomes an open circuit and holds the voltage on the capacitor of the low-pass filter constant. Moreover the signal at the "phase pulses" output is a high level which can be used for indicating a locked condition. Thus, for phase comparator II, no phase difference exists between signal and comparator input over the full VCO frequency range. Moreover, the power dissipation due to the low-pass filter is reduced when this type of phase comparator is used because both the p-and n-type output drivers are OFF for most of the signal input cycle. It should be noted that the PLL lock range for this type of phase comparator is equal to the capture range, independent of the low-pass filter. With no signal present at the signal input, the VCO is adjusted to its lowest frequency for phase comparator II. Fig. 4 shows typical waveforms for a COS/MOS PLL employing phase comparator II in a locked condition.


NOTE: DASHED LINE IS AN OPEN-CIRCUIT CONDITION
Fig. 4 - Typical waveforms for COS/MOS phase-locked loop employing phase comparator I/ in locked condition.

## DESIGN INFORMATION

This information is a guide for approximating the values of external components for the CD4046A in a Phase-LockedLoop system. The selected external components must be within the following ranges:

$$
\begin{aligned}
& 10 \mathrm{k} \Omega \leqslant \mathrm{R} 1, \mathrm{R} 2, \mathrm{R} \mathrm{~S} \leqslant 1 \mathrm{M} \Omega \\
& \mathrm{C} 1 \geqslant 100 \mathrm{pF} \text { at } \mathrm{VDD}_{\mathrm{DD}} \geqslant 5 \mathrm{~V} ; \\
& \mathrm{C} 1 \geqslant 50 \mathrm{pF} \text { at } \mathrm{V}_{\mathrm{DD}} \geqslant 10 \mathrm{~V}
\end{aligned}
$$

In. addition to the given design information refer to Fig. 5 for R1, R2, and C1 component selections.

| CHARACTERISTICS | USING PHASE COMPARATOR I |  | USING PHASE COMPARATOR II |  |
| :---: | :---: | :---: | :---: | :---: |
|  | VCO WITHOUT OFFSET $\mathrm{H}_{2}=\infty$ | VCO WITH OFFSET | VCO WITHOUT OFFSET $\mathrm{R}_{2}=\infty$ | VCO WITH OFFSET |
| VCO Frequency |  |  <br> VCO INPUT VOLTAGE |  <br> VCO inPut voltage |  <br> vco input voltage <br> 92CS-20012R1 |
| For No Signal Input | VCO in PLL system will adjust to center frequency, $\mathrm{fo}_{0}$ |  | VCO in PLL system will adjust to lowest operating frequency, $f_{\text {min }}$ |  |
| Frequency Lock Range, ${ }^{\text {2f }}$ L | $\begin{aligned} & 2 f_{L}=\text { full VCO frequency range } \\ & 2 f_{L}=f_{\text {max }}-f_{\text {min }} \end{aligned}$ |  |  |  |
| Frequency Capture Range, $\mathbf{2 f}^{\mathrm{f}} \mathrm{C}$ <br> Loop Filter Component Selection | (1),(2) <br> $2 \mathrm{f}_{\mathrm{C}} \approx \frac{1}{\pi} \sqrt{\frac{2 \pi f_{L}}{\pi}}$ |  | $f C=f L$ |  |
|  |  |  |  |  |
| Phase Angle between Signal and Comparator | $90^{\circ}$ at center frequency ( $f_{0}$ ), approximating $0^{\circ}$ and $180^{\circ}$ at ends of lock range ( $2 \mathrm{f}_{\mathrm{L}}$ ) |  | Always $0^{\circ}$ in lock |  |
| Locks on Harmonics of Center Frequency | Yes |  | No |  |
| Signal Input Noise Rejection | High |  | Low |  |
| vco <br> Component <br> Selection | - Given: $f_{0}$ <br> - Use $f_{0}$ with Fig.5a to determine R1 and C1 | - Given: $f_{0}$ and $f_{L}$ <br> - Calculate $f_{\text {min }}$ from the equation $f_{\min }=f_{o}-f_{L}$ <br> - Use $f_{\text {min }}$ withFig. 5 b to determine R2 and C1 <br> - Calculate $\frac{\boldsymbol{f}_{\text {max }}}{\boldsymbol{f}_{\text {min }}}$ from the equation $\begin{aligned} & \frac{f_{\text {max }}}{f_{\min }}=\frac{f_{0}+f_{L}}{f_{0}-f_{L}} \\ & -U_{s e} \frac{f_{\text {max }}}{f_{\text {min }}} \text { with } \end{aligned}$ <br> Fig.5c to determine ratio R2/R1 to obtain R1 | - Given: $f_{\text {max }}$ <br> - Calculate $\mathrm{f}_{\mathrm{o}}$ from the equation $f_{0}=\frac{f_{\max }}{2}$ <br> - Use $f_{o}$ with Fig.5a to determine R1 and C1 | - Given: $f_{\text {min }}$ \& $f_{\text {max }}$ <br> - Use $f_{\text {min }}$ with Fig.5b to determine R2andC1 <br> -Calculate $\frac{f_{\text {max }}}{f_{\text {min }}}$ <br> -Use $\frac{f_{\text {max }}}{f_{\text {min }}}$ with Fig.5c <br> to determine ratio R2/R1 to obtain R1 |

For further information, see
(1) F. Gardner,"Phase-Lock Techniques", John Wiley and Sons, New York, 1966
(2) G. S. Moschytz, "Miniaturized RC Filters Using Phase-Locked Loop", BSTJ, May, 1965.

ELECTRICAL CHARACTERISTICS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  |  | LIMITS |  | UNITS | CHARAC TERISTIC CURVES 8. TEST CIRCUITS FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4046AD, CD4046AK CD4046AE |  |  |  |  |
|  |  |  | $\begin{array}{\|c} \text { Volts } \\ \text { vol. } \\ \hline \end{array}$ | VDD VOLTS. |  |  |  |  |  |
|  |  |  |  |  | MIN. | TYP. | MAX. |  |  |
| VCO Section |  |  |  |  |  |  |  |  |  |
| Operating Supply Voltage | $V_{\text {DD }}-V_{S S}$ | As fixed oscillator only |  |  | 3 | - | 15 | V | - |
|  |  | Phase-lock-loop operation |  |  | 5 | - | 15 |  |  |
| Operating Power Dissipation | $P_{\text {D }}$ | $\begin{array}{lr} f_{0}=10 \mathrm{HZz} & R_{1}=1 \mathrm{M} \Omega \\ \mathrm{R}^{2}=\infty & \mathrm{VCO}_{I N}=\frac{V_{D D}}{2} \end{array}$ |  | 5 | - | 70 | - | $\mu N$ | 6 a |
|  |  |  |  | 10 | - | 600 | - |  |  |
|  |  |  |  | 15 | - | 2400 | - |  |  |
| Maximum Operating Frequency | $f$ max | $\begin{aligned} & R 1=10 k \Omega \\ & R 2=\infty \\ & V C O_{I N}=V_{D D} \end{aligned}$ | $C_{1}=100 \mathrm{pF}$ | 5 | 0.25 | 0.5 | - | MHz | - |
|  |  |  | $C 1=50 \mathrm{pF}$ | 10 | 0.6 | 1.2 | - |  |  |
|  |  |  |  | 15 | - | 1.5 | - |  |  |
| Center Frequency and | $f_{0}$ | Programmable with external components R1, R2, and C1 |  |  |  |  |  |  | See Design Info. |
| Frequency Range | $f_{\text {MAX }}-$ $f_{\text {MIN }}$ |  |  |  |  |  |  |  |  |
| Linearity | - | $\begin{aligned} \mathrm{VCO}_{\mathrm{IN}} & =2.5 \mathrm{~V} \pm 0.3 \mathrm{~V}, \mathrm{R}_{1}>10 \mathrm{k} \Omega \\ & =5 \mathrm{~V} \pm 2.5 \mathrm{~V}, \mathrm{R} 1>400 \mathrm{k} \Omega \\ & =7.5 \mathrm{~V} \pm 5 \mathrm{~V}, \mathrm{R}_{1}=1 \mathrm{M} \Omega \end{aligned}$ |  | 5 | - | 1 | - | \% | - |
|  |  |  |  | 10 | - | 1 | - |  | 8a,b |
|  |  |  |  | 15 | - | 1 | - |  |  |
| Temperature-Frequency Stability : <br> No Frequency Offset $f_{\text {MIN }}=0$ | - | $\mathrm{R2}=\infty \quad \% /{ }^{\circ} \mathrm{C} \propto \frac{1}{\mathrm{f} \cdot \mathrm{~V}_{\mathrm{DD}}}$ |  | $\begin{gathered} 5 \\ 10 \\ 15 \end{gathered}$ | - | $\begin{gathered} 0.12-0.24 \\ 0.04-0.08 \\ 0.015-0.03 \end{gathered}$ | - | $\% /{ }^{\circ} \mathrm{C}$ | - |
| Frequency Offset fMIN $\neq 0$ | - | $\% /{ }^{\circ} \mathrm{C} \propto \frac{1}{f \cdot V_{\mathrm{DD}}}$ |  | $\begin{gathered} 5 \\ 10 \\ 15 \\ \hline \end{gathered}$ | - | $\begin{gathered} 0.06-0.12 \\ 0.05-0.1 \\ 0.03-0.06 \\ \hline \end{gathered}$ | - |  | - |
| Input Resistance of $\mathrm{VCO}_{\text {IN }}$ (Term9) | RI |  |  | 5,10,15 | - | $10^{12}$ | - | $\Omega$ | - |
| VCO Output Voltage (Term 4) <br> Low Level <br> High Level | VOL | Driving COS/MOS-Type Load (e.g. Term 3 Phase Comparator Input) |  | 5,10,15 | - | - | 0.01 | V | - |
|  | $\mathrm{VOH}_{\text {O }}$ |  |  | $\begin{gathered} \hline 5 \\ 10 \\ 15 \\ \hline \end{gathered}$ | $\begin{gathered} 4.99 \\ 9.99 \\ 14.99 \end{gathered}$ | - | - |  | - |
| VCO Output Duty Cycle |  |  |  | 5,10,15 | - | 50 | - | \% | - |
| VCO Output Transition Times | tTHL. tTLH |  | Vo VOLTS | $\begin{gathered} 5 \\ 10 \\ 15 \end{gathered}$ | - | $\begin{aligned} & 75 \\ & 50 \\ & 40 \end{aligned}$ | $\begin{gathered} 150 \\ 100 \\ - \end{gathered}$ | ns | - |
| VCO Output Drive Current: n-Channel (Sink) | $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ |  | 0.5 <br> 0.5 | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{array}{r} 0.43 \\ 1.3 \\ \hline \end{array}$ | $\begin{array}{r} 0.86 \\ 2.6 \\ \hline \end{array}$ | - | mA | - |
| p-Channei (Source) | ${ }_{10}{ }^{P}$ |  | 4.5 9.5 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & -0.3 \\ & -0.9 \end{aligned}$ | $\begin{array}{r} -0.6 \\ -1.8 \end{array}$ | - |  | - |
| Source-Follower Output (Demodulated Output): Offset Voltage (VCO ${ }^{\prime N}-V_{D E M}$ ) | - | $\mathrm{R}_{\mathrm{S}}>10 \mathrm{k} \Omega$ |  | $\begin{gathered} 5,10 \\ 15 \\ \hline \end{gathered}$ | - | $\begin{aligned} & 1.5 \\ & 1.5 \\ & \hline \end{aligned}$ | 2.2 | V | - |
| Linearity | - | $\mathrm{R}_{\mathrm{S}}>50 \mathrm{k} \Omega$ | $\begin{aligned} O_{\text {IN }} & =2.5 \pm 0.3 \mathrm{~V} \\ & =5 \pm 2.5 \mathrm{~V} \\ & =7.5 \pm 5 \mathrm{~V}\end{aligned}$ | 5 10 15 | - | $\begin{aligned} & 0.1 \\ & 0.6 \\ & 0.8 \end{aligned}$ | - | \% | - |
| $\begin{aligned} & \text { Zener Diode Voltage } \\ & \text { CD4046AD, CD4046AK } \\ & \hline \text { CD4046AE } \end{aligned}$ | $v_{z}$ | $\mathrm{I}_{\mathrm{Z}}=50 \mu \mathrm{~A}$ |  |  | 4.7 | 5.2 | 5.7 | V | - |
| Zener Oynamic Resistance | $\mathrm{P}_{\mathbf{z}}$ | $I_{Z}=1 \mathrm{~mA}$ |  |  | - | 100 | - | $\Omega$ | - |

File No. 637

ELECTRICAL CHARACTERISTICS AT $\mathbf{T A}^{\mathbf{~}} \mathbf{2 5}^{\mathbf{\circ}} \mathbf{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | $\begin{gathered} \mathrm{VO}_{\mathrm{O}} \\ \text { VOLTS } \end{gathered}$ | $\begin{aligned} & \text { VDD } \\ & \text { VOLTS } \end{aligned}$ |  | LIMITS |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS FIG: NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4046AD, CD4046AK CD4046AE |  |  |  |  |
|  |  |  |  |  | MIN. | TYP. | MAX. |  |  |
| PHASE COMPARATOR Section |  |  |  |  |  |  |  |  |  |
| Operating Supply Voltage | $V_{D D}-V_{S S}$ | Amplifier Operation |  | - | 5 | - | 15 | V | - |
|  |  | Comparators only |  | - | 3 | - | 15 |  | - |
| Total Quiescent Device Current: Term. 14 Open | IL | Term. 15 open Term. 5 at $V_{D D}$ Terms. 3 \& 9 at $V_{S S}$ |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | - | $\begin{gathered} 25 \\ 200 \\ \hline \end{gathered}$ | $\begin{gathered} 55 \\ 410 \end{gathered}$ | $\mu \mathrm{A}$ | - |
| Term. 14 at $\mathrm{V}_{\text {SS }}$ or $\mathrm{V}_{\text {DD }}$ |  |  |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | - | $\begin{aligned} & 5 . \\ & 25 \end{aligned}$ | $\begin{aligned} & 15 \\ & 60 \\ & \hline \end{aligned}$ |  |  |
| Term. 14 (SIGNAL IN) Input Impedance | $z_{14}$ |  |  | $\begin{gathered} 5 \\ 10 \\ 15 \end{gathered}$ | $\begin{gathered} 1 \\ 0.2 \\ - \end{gathered}$ | $\begin{gathered} 2 \\ 0.4 \\ 0.2 \end{gathered}$ | - - - | $\mathrm{M} \Omega$ | - |
| AC-Coupled Signal Input Voltage Sensitivity |  |  |  | $\begin{gathered} 5 \\ 10 \\ 15 \\ \hline \end{gathered}$ | - | $\begin{aligned} & 200 \\ & 400 \\ & 700 \end{aligned}$ | $400$ $800$ $\qquad$ | mV | 7 |
| DC-Coupled Signal Input and Comparator Input Voltage Sensitivity: Low Level High Level |  | $\begin{array}{\|c\|} \hline \mathrm{V}_{\mathrm{O}} \\ \text { voLTS } \end{array}$ |  | $\begin{gathered} 5 \\ 10 \\ 15 \end{gathered}$ | $\begin{gathered} 1.5 \\ 3 \\ 4.5 \end{gathered}$ | $\begin{gathered} 2.25 \\ 4.5 \\ 6.75 \end{gathered}$ | - | v | - |
|  |  |  |  | $\begin{gathered} 5 \\ 10 \\ 15 \\ \hline \end{gathered}$ | - | $\begin{gathered} 2.75 \\ 5.5 \\ 8.25 \\ \hline \end{gathered}$ | $\begin{gathered} 3.5 \\ 7 \\ - \end{gathered}$ |  | - |
| Output Drive Current: <br> $n$-Channel (Sink) $\qquad$ <br> p-Channel (Source) | $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ | Phase Comparator I\& II Term. 2 \& 13 | $\begin{aligned} & 0.5 \\ & 0.5 \end{aligned}$ | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{gathered} 0.43 \\ 1.3 \\ \hline \end{gathered}$ | $\begin{gathered} 0.86 \\ 2.5 \\ \hline \end{gathered}$ | $\begin{aligned} & - \\ & - \end{aligned}$ | mA | - |
|  |  | Phase Pulses | $\begin{aligned} & 0.5 \\ & 0.5 \\ & \hline \end{aligned}$ | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{gathered} 0.23 \\ 0.7 \\ \hline \end{gathered}$ | $\begin{gathered} 0.47 \\ 1.4 \\ \hline \end{gathered}$ | $\begin{aligned} & - \\ & - \end{aligned}$ |  | - |
|  | $I_{D}{ }^{P}$ | Phase Comparator I\& II Term. 2 \& 13 | $\begin{array}{r} 4.5 \\ 9.5 \\ \hline \end{array}$ | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{array}{r} -0.3 \\ -0.9 \end{array}$ | $\begin{array}{r} -0.6 \\ -1.8 \\ \hline \end{array}$ | - |  | - |
|  |  | Phase Pulses | $\begin{aligned} & 4.5 \\ & 9.5 \end{aligned}$ | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & -0.08 \\ & -0.25 \end{aligned}$ | $\begin{aligned} & -0.16 \\ & -0.5 \end{aligned}$ | - |  | - |


| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to +150 |
| :---: | :---: |
| Operating Temperature Range: |  |
| Ceramic Package Types | $-55^{\circ} \mathrm{C}$ to +125 |
| Plastic Package Types. | $-40^{\circ} \mathrm{C}$ to +85 |
| DC Supply Voltage Range $\left(V_{D D}-V_{S S}\right)$ | -0.5 V to +15 |
| Device Dissipation (Per Pkg.) | 200 |
| All Inputs | $V_{S S} \leqslant V_{1} \leqslant V_{\text {DD }}$ |
| Lead Temperature (During sold At distance $1 / 16 \pm 1 / 32$ inch from case for 10 seconds max | $0.79 \mathrm{~mm})_{265}$ |



Fig.5(a) - Typical center frequency vs $C 1$ for $R 1=10 \mathrm{k} \Omega$, and $1 \mathrm{M} \Omega$.


Fig.5(b) - Typical frequency offset vs C1 for $R 2=10 k \Omega, 100 k \Omega$, and $1 \mathrm{M} \Omega$.

NOTE: Lower frequency values are obtainable if larger values of C1 than shown in Figs. 5(a) and 5(b) are used.


Fig.5(c) - Typical $f_{\text {max }} / f_{\text {min }}$ vs R2/R1.


Fig.6(b) - Typical VCO power dissipation at $f_{\text {min }}$ vs R2.


Fig.6(a) - Typical VCO power dissipation at center frequency vs R1.


Fig.6(c) - Typical source follower power dissipation vs $R_{S}$. NOTE: To obtain approximate total power dissipation of PLL system for no-signal input
$P_{D}($ Total $)=P_{D}\left(f_{0}\right)+P_{D}\left(f_{M I N}\right)+P_{D}\left(R_{S}\right)-$ Phase Comparator $I$
$P_{D}($ Total $)=P_{D}\left({ }^{(f}\right.$ MIN $)$ - Phase Comparator II

File No. 637


92CS-21889
Fig. 7 - Typical lock range vs signal input amplitude.


Fig.8(a) and (b) - Typical VCO linearity vs R1 and C1.

## Solid State Division

## CD4047AD

CD4047AE
CD4047 AK


# COS/MOS Low-Power Monostable/Astable Multivibrator 

## Special Features:

- Low power consumption: special COS/MOS oscillator configuration
- Monostable (one-shot) or astable (free-running) operation
- True and complemented buffered outputs
- Only one external $\mathbf{R}$ and $\mathbf{C}$ required

Monostable Multivibrator Features:

- Positive- or negative-edge trigger
- Output pulse width independent of trigger pulse duration

RCA-CD4047A consists of a gatable astable multivibrator with logic techniques incorporated to permit positive or negative edge-triggered monostable multivibrator action having retriggering and external counting options.
Inputs include + Trigger, - Trigger, Astable, $\overline{\text { Astable, }}$ Retrigger, and External Reset. Buffered outputs are $\mathrm{Q}, \overline{\mathrm{Q}}$, and Oscillator. In all modes of operation an external capacitor must be connected between C-Timing and RC-Common terminals, and an external resistor must be connected between the R-Timing and RC-Common terminals.
Astable operation is enabled by a high level on the Astable input. The period of the square wave at the Q and $\overline{\mathrm{Q}}$ outputs in this mode of operation is a function of the external components employed. "True" input pulses on the Astable input or "Complement" pulses on the $\overline{\text { Astable }}$ input allow the circuit to be used as a gatable multivibrator. An output whose period is half of that which appears at the $\mathbf{O}$ terminal is available at the Oscillator Output terminal. However, a $\mathbf{5 0 \%}$ duty cycle is not guaranteed at this output.


Fig. 1 - CD4047A logic block diagram.

- Retriggerable option for pulse width expansion
- Long pulse widths possible using small RC components by means of external counter provision
- Fast recovery time essentially independent of pulse width
- Pulse-width accuracy maintained at duty cycles approaching 100\%


## Astable Multivibrator Features:

- Free-running or gatable operating modes
- $50 \%$ duty cycle
- Oscillator output available
- Good astable frequency stability:

$$
\begin{aligned}
\text { frequency deviation } & = \pm 2 \%+0.03 \% /{ }^{\circ} \mathrm{C} @ 100 \mathrm{kHz}{ }^{*} \\
& = \pm 0.5 \%+0.015 \% /{ }^{\circ} \mathrm{C} @ 10 \mathrm{kHz}{ }^{*}
\end{aligned}
$$

## COS/MOS Features:

- Microwatt quiescent power dissipation: $0.5 \mu \mathrm{~W}$ (Typ)
- High noise immumity: $\mathbf{4 5 \%}$ of supply voltage (Typ)
- Wide operating-temperature range: ceramic package types, $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$; plastic package types, $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$


## Applications:

Digital equipment where low-power dissipation and/or high noise immunity are primary design requirements:

- Frequency discriminators - Envelope detection
- Timing circuits - Frequency multiplication
- Time-delay applications a Frequency division
* Circuits "trimmed" to frequency; $V_{D D}=10 \mathrm{~V} \pm 10 \%$.

A high level should be applied to the external reset whenever VDD is applied or removed. In the monostable mode positiveedge triggering is accomplished by application of a leading-edge pulse to the "+Trigger" input and a low level to the "-Trigger" input. For negative-edge triggering a trailing-edge pulse is applied to the "-Trigger" and a high level is applied to the "+Trigger". Input pulses may be of any duration relative to the output pulse. The multivibrator can be retriggered (on the leading edge only) by applying a common pulse to both the "Retrigger" and "+Trigger" inputs. In this mode the output pulse remains "high" as long as the input pulse period is shorter than the period determined by the RC components.
An external countdown option can be implemented by coupling " Q " to an external " N " counter (e.g. CD4017A) and resetting the counter with the trigger pulse. The counter output pulse is fed back to the Astable input and has a duration equal to N times the period of the multivibrator.
A high level on the External Reset input assures no output pulse during an "ON" power condition. This input can also be activated to terminate the output pulse at any time.

This device is supplied in a 14 -lead flat pack (CD4047AK), a 14 -lead dual-in-line ceramic package (CD4047AD), or a 14 -lead dual-in-line plastic package (CD4047AE). It is also available in chip form (CD4047AH).

## MAXIMUM RATINGS, Absolute-Maximum Values:



CD4047A FUNCTIONAL TERMINAL CONNECTIONS NOTE: IN ALL CASES EXTERNAL RESISTOR BETWEEN TERMINALS 2 AND 34 EXTERNAL CAPACITOR BETWEEN TERMINALS 1 AND 3A

| FUNCTION | TERMINAL CONNECTIONS |  |  | OUTPUT PULSE FROM | OUTPUT PERIOD OR PULSE WIDTH |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | TO VDD | TO VSS | $\begin{array}{\|c\|} \hline \text { INPUT PULSE } \\ \text { TO } \\ \hline \end{array}$ |  |  |
| Astable Multivibrator: <br> Free Running <br> True Gating <br> Complement Gating | $\begin{gathered} 4,5,6,14 \\ 4,6,14 \\ 6,14 \\ \hline \end{gathered}$ | $\begin{gathered} 7,8,9,12 \\ 7,8,9,12 \\ 5,7,8,9,12 \\ \hline \end{gathered}$ | 5 <br> 4 | $\begin{array}{r} 10,11,13 \\ 10,11,13 \\ 10,11,13 \\ \hline \end{array}$ | $\begin{gathered} \mathrm{t}_{\mathrm{A}}(10,11)=4.40 \mathrm{RC} \\ \mathrm{t}_{\mathrm{A}}(13)=2.20 \mathrm{RC} \end{gathered}$ |
| Monostable Multivibrator <br> Positive-Edge Trigger Negative-Edge Trigger Retriggerable External Countdown* | $\begin{gathered} 4,14 \\ 4,8,14 \\ 4,14 \\ 14 \end{gathered}$ | $\left\|\begin{array}{c} 5,6,7,9,12 \\ 5,7,9,12 \\ 5,6,7,9 \\ 5,6,7,8,9,12 \end{array}\right\|$ | $\begin{gathered} 8 \\ 6 \\ 8,12 \end{gathered}$ | $\begin{aligned} & 10,11 \\ & 10,11 \\ & 10,11 \\ & 10,11 \end{aligned}$ | $\mathrm{tm}_{\mathrm{M}}(10,11)=2.48 \mathrm{RC}$ |

[^10]

Fig. 2 - CD4047A logic diagram.


92CS-21386

Fig. 3 - Typical n-channel drain characteristics for $Q$ and $\bar{Q}$ buffers.


Fig. 4 - Minimum n-channel drain characteristics for $Q$ and $\bar{Q}$ buffers.

File No. 623

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4047AD, CD4047AK |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | VDD | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device | IL |  | 5 | - | - | 5 | - | 0.03 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 33 |
| Current |  |  | 10 | - | - | 10 | - | 0.05 | 10 | - | - | 600 |  |  |
| Quiescent Device Dissipation Package | $P_{0}$ |  | 5 | - | - | 25 | - | 0.15 | 25 | - | - | 1500 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 100 | - | 0.5 | 100 | - | - | 6000 |  |  |
| Output Voltage Low Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - | V |  |
| Noise Immunity <br> (All Inputs) |  | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 34 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\text {NH }}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current ( $0, \overline{\mathrm{a}}$ Outputs) <br> N -Channel | $10^{N}$ | 0.5 V | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.28 | - | - | mA | 3,4 |
|  |  | 0.5 V | 10 | 1.25 | - | - | 1 | 2 | - | 0.7 | - | - |  | - |
| P-Channel | ${ }_{10} P$ | 4.5 V | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.28 | - | - | mA | 5,6 |
|  |  | 9.5 V | 10 | -1.25 | - | - | -1 | -2 | - | -0.7 | - | - |  |  |
| Input Current | 11 | Any Input |  | - | - | - | - | 10 | - | - | - | - | pA |  |



92CS-21388
Fig. 5 - Typical p-channel drain characteristics for $Q$ and $\bar{Q}$ buffers.


92Cs-21389
Fig. 6 - Minimum p-channel drain characteristics for $\bar{Q}$ and $Q$ buffers.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4047AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | VDD | -400C |  |  | 250C |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device | IL |  | 5 | - | - | 50 | - | 0.1 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 33 |
| Current |  |  | 10 | - | - | 100 | - | 0.2 | 100 | - | - | 1400 |  |  |
| Quiescent Device | $P_{\text {D }}$ |  | 5 | - | - | 250 | - | 0.5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ |  |
| Dissipation Package |  |  | 10 | - | - | 1000 | - | 2 | 1000 | - | - | 14000 |  |  |
| Output Voltage | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
| Low Level |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity (All Inputs) |  | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 34 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\text {NH }}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current | $\mathrm{I}_{\mathrm{D}} \mathrm{N}$ | 0.5 V | 5 | 0.34 | - | - | 0.28 | 0.8 | - | 0.23 | - | - | mA | 3,4 |
| (0, a Outputs) <br> N -Channel |  | 0.5 V | 10 | 0.85 | - | - | 0.7 | 2 | - | 0.6 | - | - |  |  |
| P-Channel | $I_{1} P$ | 4.5 V | 5 | -0.34 | - | - | -0.28 | -0.8 | - | -0.23 | - | - | mA | 5,6 |
|  |  | 9.5 V | 10 | -0.85 | - | - | -0.7 | -2 | - | -0.6 | - | - |  |  |
| Input Current | 11 | Any Input |  | - | - | - | - | 10 | - | - | - | - | pA |  |



Fig. 7 - Typical low-to-high level propagation delay time vs. load capacitance for $Q$ and $\bar{Q}$ buffers.


Fig. 8 - Typical transition time vs. load capacitance for $Q$ and $\bar{Q}$ buffers.

File No. 623 $\qquad$

DYNAMIC ELECTRICAL CHARACTERISTICS at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{SS}}=\mathbf{0} \mathrm{V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$
Typical Temperature Coefficient at all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4047AKCD4047AD |  |  | CD4047AE |  |  |  |
|  |  |  | VDD <br> (Volts) | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |  |
| Propagation Delay Time: <br> Astable, Astable to <br> Osc. Out | tPHL, <br> tplh |  | 5 | - | 200 | 400 | - | 200 | 550 | ns |
|  |  |  | 10 | - | 100 | 200 | - | 100 | 275 |  |
| Astable, $\overline{\text { Astable }}$$\stackrel{\text { to }}{0, \bar{o}}$ |  |  | 5 | - | 550 | 900 | - | 550 | 1200 |  |
|  |  |  | 10 | - | 250 | 500 | - | 250 | 650 |  |
| + Trigger, -Trigger to , $\overline{\mathrm{o}}$ |  |  | 5 | -. | 700 | 1200 | - | 700 | 1600 |  |
|  |  |  | 10 | - | 300 | 600 | - | 300 | 800 |  |
| $\begin{aligned} & + \text { Trigger, Retrigger } \\ & \text { to } \\ & \mathrm{Q}, \overline{\mathrm{o}} \end{aligned}$ |  |  | 5 | - | 300 | 600 | - | 300 | 800 |  |
|  |  |  | 10 | -- | 175 | 300 | - | 175 | 400 |  |
| External Reset to |  |  | 5 | - | 300 | 600 | - | 300 | 800 |  |
| Q, $\overline{\mathrm{Q}}$ |  |  | 10 | - | 125 | 250 | - | 125 | 350 |  |
| Transition Time:$\mathrm{Q}, \overline{\mathrm{a}}$ | ${ }^{t}$ THL, ttLH |  | 5 | - | 75 | 125 | - | 75 | 150 | ns |
|  |  |  | 10 | - | 45 | 75 | - | 45 | 100 |  |
| Osc. Out |  |  | 5 | - | 75 | 150 | - | 75 | 180 |  |
|  |  |  | 10 | - | 45 | 100 | - | 45 | 130 |  |
| Minimum Input Pulse Duration (any input) | twL, <br> twh |  | 5 | - | 500 | 1000 | - | 500 | 1300 | ns |
|  |  |  | 10 | - | 200 | 400 | - | 200 | 600 |  |
| +Trigger,Retrigger,-Trigger Rise \& Fall Time | $\mathrm{t}_{\mathrm{r}}$. |  | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ |
|  | $t_{f}$ |  | 10 | - | - | 5 | - | - | 5 |  |
| Average Input Capacitance | $C_{1}$ | any input | - | - | 5 | - | - | 5 | - | pF |

* Input pulse widths below the minimum specified may cause malfunction of the unit.

See Application Note ICAN-6230.

## I. Astable Mode Design Information

A. Unit-to-Unit Transfer-Voltage Variations

The following analysis presents worst-case variations from unit-to-unit as a function of transfer-voltage ( $V_{T R}$ ) shift ( $33 \%-67 \% V_{D D}$ ) for free-running (astable) operation.


92CS-20027
Fig. 9 - Astable mode waveforms.

$$
\begin{aligned}
t_{1} & =-R C \ln \frac{\overline{V_{T R}}}{V_{D D}+V_{T R}} \\
t_{2} & =-R C \ln \frac{V_{D D}-V_{T R}}{2 V_{D D}-V_{T R}} \\
t_{A} & =2\left(t_{1}+t_{2}\right) \\
& =-2 R C \ln \frac{\left(V_{T R}\right)\left(V_{D D}-V_{T R}\right)}{\left(V_{D D}+V_{T R}\right)\left(2 V_{D D}-V_{T R}\right)}
\end{aligned}
$$

Typ: $V_{T R}=0.5 V_{D D}$
$\mathrm{t}_{\mathrm{A}}=4.40 \mathrm{RC}$
Min: $V_{T R}=0.33 V_{D D}$
${ }^{t} A=4.62 R C$
$t_{A}=4.62 R C$
thus if $t A=4.40 R C$ is used, the maximum variation will be $(+5.0 \%,-0.0 \%)$.
B. Variations Due to VDD and Temperature Changes In addition to variations from unit-to-unit, the astable period may vary as a function of frequency with respect to VDD and temperature. Typical variations are presented in graphical form in Figs. 10 to 20 with 10 V as reference for voltage variation curves and $25^{\circ} \mathrm{C}$ as reference for temperature variation curves.


Fig. 11 - Typical $Q$-and- $\bar{Q} \cdot$ period accuracy vs. supply voltage (medium frequency).


Fig. 13 - Typicai Q-and- $\bar{Q}$-period accuracy vs. supply voltage (very low frequency).


Fig. 10 - Typical $Q$-and- $\bar{Q}$-period accuracy vs. supply voltage (high frequency).


Fig. 12 - Typical Q-and- $\bar{Q}$-period accuracy vs. supply voltage (low frequency).


Fig. 14 - Typical Q-and- $\bar{O}$-period accuracy vs. frequency for $V_{D D}$ variation of $\pm 10 \%$ from value indicated.


Fig. 15 - Typical oscillator-output-period accuracy vs. supply voltage (high frequency).


Fig. 17 - Typical $Q$-and- $\bar{Q}$-period accuracy vs. temperature (medium frequency).


Fig. 19 - Typical oscillator-period accuracy vs. temperature (medium frequency).


Fig. 16 - Typical oscillator-output-period accuracy vs. supply voltage (medium frequency).


Fig. 18 - Typical Q-and- $\bar{Q}$-period accuracy vs. temperature (high frequency).


Fig. 20 - Typical oscillator-period accuracy vs. temperature (high frequency).

## II. Monostable Mode Design Information

The following analysis presents worst-case variations from unit-to-unit as a function of transfer-voltage ( $V_{T R}$ ) shift ( $33 \%-67 \% V_{D D}$ ) for one-shot (monostable) operation.


Fig. 21 - Monostable waveforms.

$$
\begin{aligned}
& t_{1}^{\prime}=-R C \ln \frac{V_{T R}}{2 V_{D D}} \\
& t_{M}=\left(t_{1}{ }^{\prime}+t_{2}\right) \\
& t_{M}=-R C \ln \frac{\left(V_{T R}\right)\left(V_{D D}-V_{T R}\right)}{\left(2 V_{D D}-V_{T R}\right)\left(2 V_{D D}\right)}
\end{aligned}
$$



Fig. 22 - Typical Q-and- $\bar{Q}$-pulse-width accuracy vs. supply voltage $\left(t_{M}=15,60,120 \mu \mathrm{~s}\right)$.


Fig. 24 - Typical Q-and- $\bar{Q}$-pulse-width accuracy vs. supply voltage $\left(t_{M} \geq 100 \mathrm{~ms}\right)$.
where $t_{M}=$ Monostable mode pulse width. Values for $t_{M}$ are as follows:

| Typ: | $V_{T R}=0.5 V_{D D}$ | $t_{M}=2.48 \mathrm{RC}$ |
| :--- | :--- | :--- |
| Min: | $V_{T R}=0.33 V_{D D}$ | $t_{M}=2.71 R C$ |
| Max. | $V_{T R}=0.67 V_{D D}$ | $t_{M}=2.48 R C$ |

Thus if $\mathrm{t}_{\mathrm{M}}=2.48 \mathrm{RC}$ is used, the maximum variation will be (+9.3\%, -0.0\%).

## Note:

In the astable mode, the first positive half cycle has a duration of $T_{M}$; succeeding durations are $t_{A} / 2$.

In addition to variations from unit to unit, the monostable pulse width may vary as a function of frequency with respect to $V_{D D}$ and temperature. These variations are presented in graphical form in Figs. 22 to 27 with 10 V as reference for voltage variation curves and $25^{\circ} \mathrm{C}$ as reference for temperature variation curves.


Fig. 23 - Typical Q-and- $\bar{Q}$-pulse-width accuracy vs. supply voltage $\left(t_{M}=0.5,1,10 \mathrm{~ms}\right)$.


Fig. 25 - Typical $Q$-and- $\bar{O}$-pulse-width accuracy vs $Q$ and $\bar{Q}$ pulse width for a variation of $\pm 10 \%$ from value indicated.


Fig. 26 - Typical $\mathbf{Q}$-and- $\bar{Q}$-pulse-width accuracy vs. temperature (high frequency).


Fig. 27 -- Typical $Q$-and- $\bar{Q}$-pulse-width accuracy range vs. temperature.


## III. Retrigger Mode Operation

The CD4047A can be used in the retrigger mode to extend the output-pulse duration, or to compare the frequency of an input signal with that of the internal oscillator. In the retrigger mode the input pulse is applied to terminals 8 and 12, and the output is taken from terminal 10 or 11. As shown in Fig.28, normal monostable action is obtained when one retrigger pulse is applied. Extended pulse duration is obtained when more than one pulse is applied. For two input pulses, $t_{R E}=t_{1}^{\prime}+t_{1}+2 t_{2}$. For more than two pulses, tre ( $Q$ OUTPUT) terminates at some variable time tD after the termination of the last retrigger pulse. tD is variable because tre ( $Q$ OUTPUT) terminates after the second positive edge of the oscillator output appears at flip-flop 4 (see Fig.2).

## IV. External Counter Option

Time $t_{M}$ can be extended by any amount with the use of external counting circuitry. Advantages include digitally controlled pulse duration, small timing capacitors for long time periods, and extremely fast recovery time. A typical implementation is shown in Fig.29. The pulse


$$
92 \mathrm{CS}-20030 \mathrm{RI}
$$

Fig. 29 - Implementation of external counter option.
duration at the output is

$$
t_{\mathrm{ext}}=(N-1)\left(\mathrm{t}_{\mathrm{A}}\right)+\left(\mathrm{t}_{\mathrm{M}}+\mathrm{t}_{\mathrm{A}} / 2\right)
$$

where $t_{\text {ext }}=$ pulse duration of the circuitry, and $N$ is the number of counts used.

## V. Timing-Component Limitations

The capacitor used in the circuit should be non-polarized and have low leakage (i. e. the parallel resistance of the capacitor should be an order of magnitude greater than the external resistor used). There is no upper or lower limit for either R or C value to maintain oscillation.

However, in consideration of accuracy, C must be much larger than the inherent stray capacitance in the system (unless this capacitance can be measured and taken into account). R must be much larger than the COS/MOS "ON" resistance in series with it, which typically is hundreds of ohms. In addition, with very large values of $R$, some short-term instability with respect to time may be noted.

The recommended values for these components to maintain agreement with previously calculated formulas without trimming should be:
$C \geq 100 \mathrm{pF}$, up to any practical value, for astable modes;
$C \geq 1000 \mathrm{pF}$, up to any practical value for monostable modes.

$$
10 \mathrm{~K} \Omega \leq \mathrm{R} \leq 1 \mathrm{M} \Omega
$$

## VI. Power Consumption

In the standby mode (Monostable or Astable), power dissipation will be a function of leakage current in the circuit, as shown in the static electrical characteristics. For dynamic operation, the power needed to charge the external timing capacitor $C$ is given by the following formulae:

Astable Mode: $\quad \mathbf{P}=2 \mathrm{CV}^{2} \mathrm{f}$. (Output at terminal No. 13)
$\mathrm{P}=4 \mathrm{CV}^{2} \mathrm{f}$. (Output at terminal Nos. 10 and 11)

Monostable Mode: $P=\frac{\left(2.9 \mathrm{CV}^{2}\right) \text { (Duty Cycle) }}{T}$
(Output at terminal
Nos. 10 and 11)


Fig. 30 - Power dissipation vs. output frequency $\left(V_{D D}=5 \mathrm{~V}\right)$.


Fig. 32 - Power dissipation vs. output frequency $\left(V_{D D}=15 \mathrm{~V}\right)$.

The circuit is designed so that most of the total power is consumed in the external components. In practice, the lower the values of frequency and voltage used, the closer the actual power dissipation will be to the calculated value.

Because the power dissipation does not depend on R, a design for minimum power dissipation would be a small value of C . The value of R would depend on the desired period (within the limitations discussed above). See Figs. 30-32 for typical power consumption in astable mode.


Fig. 31 - Power dissipation vs. output frequency $\left(V_{D D}=10 \mathrm{~V}\right)$.

## TEST CIRCUITS



Fig. 33 - Quiescent
device current.
Fig. 34 - Noise immunity.


## Solid State Division

CD4048AD CD4048AE CD4048AK



## COS/MOS Multi-Function Expandable 8-Input Gate

Special Features:<br>- Medium-power TTL drive capability<br>- Three-state output<br>- High-current source and sink capability 9 mA (typ.) $@ \mathrm{~V}_{\mathrm{DS}}=0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}$<br>- Many logic functions available in one package

## Applications:

- Selection of up to 8 logic functions
a Digital control of logic
- General-purpose gating logic
- Decoding
- Encoding

RCA-CD4048A is an 8-input gate having four control inputs. Three binary control inputs - $\mathrm{Ka}, \mathrm{Kb}$, and Kc - provide the implementation of eight different logic functions. These functions are OR, NOR, AND, NAND, OR/AND, OR/NAND, AND/OR, and AND/NOR.
A fourth control input - Kd - provides the user with 3-state outputs. When control input Kd is "high" the output is either a logic 1 or a logic 0 depending on the input states. When control input Kd is "low", the output is an open circuit. This feature enables the user to connect this device to a common bus line.

In addition to the eight input lines, an EXPAND input is provided that permits the user to increase the number of inputs to one CD4048A, (see Fig. 2). For example, two CD4048A's can be cascaded to provide a 16 -input multifunction gate. When the EXPAND input is not used, it should be connected to $V_{S S}$. The CD4048A is supplied in a 16 -lead dual-in-line ceramic package (CD4048AD), a 16 -lead dual-in-line plastic package (CD4048AE), or a 16 -lead flat pack (CD4048AK).


Fig. 1-Basic logic configurations.

## MAXIMUM RATINGS, Absolute-Maximum Values:




EXPAND Input=0
*See Figs. 1 and 3.


92CM-22251R1
Fig. 2- Logic diagram and truth table.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ )
3 to 15 V)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | - |  | CD40 | 48AD, | CD404 | 88АK |  |  |  |  |  |
|  |  | $v_{0}$ <br> Volts | $\begin{aligned} & V_{D D} \\ & \text { Volts } \end{aligned}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device <br> Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 1 | - | 0.005 | 1 | - | - | 60 | $\mu \mathrm{A}$ | 14 |
|  |  |  | 10 | - | - | 2 | - | 0.01 | 2 | - | - | 120 |  |  |
| Quiescent Device <br> Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 5 | - | 0.025 | 5 | - | - | 300 | $\mu \mathrm{W}$ |  |
|  |  |  | 10 | - | - | 20 | - | 0.1 | 20 | - | - | 1200 |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) <br> For definition, see Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 13 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | V | 13 |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: <br> N-Channel <br> (Sink) | ${ }_{1}{ }^{\prime}$ | 0.4 | 4.5 | 2 | - | - | 1.6 | 3.2 | - | 1.1 | - | - | mA | 5,6 |
|  |  | 0.5 | 10 | 5.6 | - | - | 4.5 | 9 | - | 3.1 | - | - |  |  |
| P-Channel (Source) | ${ }^{1} D^{P}$ | 4.6 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.1 | - | - | mA | 7.8 |
|  |  | 9.5 | 10 | -5.6 | - | - | -4.5 | -9 | - | -3,1 | - | - |  |  |



Fig. 3(c)- Actual-circuit logic configurations.

(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4048AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\begin{gathered} \mathrm{V}_{0} \\ \text { Volts } \end{gathered}$ | $V_{D D}$ <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 10 | - | 0.01 | 10 | - | - | 140 | $\mu \mathrm{A}$ | 14 |
| Current |  |  | 10 | - | - | 20 | - | 0.02 | 20 | - | - | 280 |  |  |
| Quiescent Device | $P_{\text {D }}$ |  | 5 | - | - | 50 | - | 0.05 | 50 | - | - | 700 | $\mu \mathrm{W}$ |  |
| Dissipation/Package |  |  | 10 | - | - | 200 | - | 0.2 | 200 | - | - | 2800 |  |  |
| Output Voltage: | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
| Low-Level |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | v |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
| Noise Immunity <br> (All Inputs) <br> For definition see Appendix | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 13 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - | v | 13 |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: N -Channel (Sink) | ${ }_{1}{ }^{N}$ | 0.4 | 4.5 | 1.9 | - | - | 1.6 | 3.2 | - | 1.3 | - | - | mA | 5,6 |
|  |  | 0.5 | 10 | 5.4 | - | - | 4.5 | 9 | - | 3.7 | - | - |  |  |
| P-Channel <br> (Source) | ${ }_{1}{ }^{P}$ | 4.6 | 5 | -1.9 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 7,8 |
|  |  | 9.5 | 10 | -3.8 | - | - | -3.15 | -9 | - | -2.6 | - | - |  |  |



Fig. 4- Typical power dissipation as a function of input frequency.


Fig. 5- Typical n-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ and 50 pF
Typical Temperature Coefficient for all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$
$\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARAC- <br> TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{aligned} & \text { CD4048AD } \\ & \text { CD4048AK } \end{aligned}$ |  |  | CD4048AE |  |  |  |  |
|  |  |  | $V_{\text {DD }}$ <br> (Volts) | MIN. | TYP. | MAX.* | MIN. | TYP. | MAX.* |  |  |
| Propagation Delay Time | ${ }^{t}$ PLH. <br> ${ }^{\text {tPHL }}$ |  | 5 | - | 750 | 1300 | - | 750 | 1600 | ns | 15,16 |
|  |  |  | 10 | - | 225 | 400 | - | 225 | 500 |  |  |
| Transition Time: <br> High-to-Low Level | ${ }^{\text {t }}$ THL |  | 5 | - | 90 | 140 | - | 90 | 170 | ns | 17 |
|  |  |  | 10 | - | 30 | 50 | - | 30 | 65 |  |  |
| Low-to-High Level | ${ }^{\text {t }}$ LLH |  | 5 | - | 130 | 250 | - | 130 | 300 | ns | 17 |
|  |  |  | 10 | - | 40 | 60 | - | 40 | 75 |  |  |
| Input Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF |  |

$C_{L}=50 \mathrm{pF}$

| Propagation Delay Time | ${ }^{\text {P PLH }}$, |  | 5 | - | 775 | 1350 | - | 775 | 1650 | ns | 15,16 | . |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | ${ }^{\text {t PHLL }}$ |  | 10 | - | 240 | 430 | - | 240 | 530 |  |  |  |
| Transition Time: <br> High-to-Low Level | ${ }^{\text {t }}$ THL |  | 5 | - | 105 | 170 | - | 105 | 200 | ns | 17 |  |
|  |  |  | 10 | - | 40 | 70 | - | 40 | 85 |  |  |  |
| Low-to-High Level | ${ }^{\text {t }}$ TLH |  | 5 | - | 145 | 280 | - | 145 | 330 | ns | 17 |  |
|  |  |  | 10 | - | 50 | 80 | - | 50 | 95 |  |  |  |
| Input Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF |  |  |

* Max. Limits represent worst-case limits for worst-case modes of operation shown in Figs. 15, 16, and 17

DYNAMIC ELECTRICAL CHARACTERISTICS, Driving TTL at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=5 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ CD4048AD, CD4048AK

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS Driving One TTL Load | LIMITS |  |  | UNITS | TYPICAL CHARACTERISTICS CURVES Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | MIN. | TYP. | MAX. |  |  |
| Propagation Delay Time: High-to-Low Level | ${ }^{\text {tPHL }}$ | Series 54L, 74L | - | 775 | - | ns | 12 |
|  |  | Series 54, 74 | - | 775 | - |  |  |
| Low-to-High Level | ${ }^{\text {P PLH }}$ | Series 54L, 74L | - | 710 | - | ns |  |
|  |  | Series 54, 74 | - | 600 | - |  |  |

## CD4048AE

| Propagation Delay Time: <br> High-to-Low Level | ${ }^{\text {tPHL }}$ | Series 54L, 74L | - | 775 | - | ns | 12 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Series 54, 74 | - | 775 | - |  |  |
| Low-to-High Level | ${ }^{\text {P PLH }}$ | Series 54L, 74L | - | 710 | - | ns |  |
|  |  | Series 54, 74 | - | 600 | - |  |  |



Fig. 6- Minimum n-channel drain characteristics.

Fig. 8- Minimum p-channel drain characteristics.


Fig. 10- Typical low-to-high level transition time as a function of load capacitance.


92C3-20244
Fig. 7- Typical p-channel drain characteristics.


Fig. 9- Typical propagation delay time as a function of load capacitance.


Fig. 11-Typical high-to-low level transition time as a function of load capacitance.


* HIGH-IMPEDANCE CONDITION AT OUTPUT (BOTH " $n$ " AND " $p$ " UNITS OFF)

$$
92 \text { Cs }-22262
$$

Fig. 12- Test circuit and waveforms for propagation delay time (CD4048A driving 1 TTL load).


Fig. 13 - Noise immunity. (can also be measured using one input; other inputs are tied to $V_{D D}$.


Input Conditions For Leakage Measurements:


$$
92 c 5-22259
$$

Fig. 14- Quiescent device current.

TEST CIRCUITS - DYNAMIC MEASUREMENTS


Fig. $15-t_{P L H}-N A N D$.


92Cs-22264

Fig. $16-t_{P H L}-A N D$.


Fig. ${ }^{17-t_{T H L}, t_{T L H}-A N D / N O R . ~}$


## COS/MOS Hex Buffer/Converters

\(\left.\begin{array}{l}CD4049AD <br>
CD4049AE <br>
CD4049AF <br>

CD4049AK\end{array}\right\}\)| INVERTING |
| :---: |
| TYPE |

Features:
Direct Drive to 2 TTL Loads at 5 V,

| VCC $=5 \mathrm{~V}, \mathrm{VOL} \leq 0.4 \mathrm{~V}$, |
| :--- |
| IDN $\geq 3 \mathrm{~mA}$ |
| I |
| High Source and Sink Current |
| Capability |
| - |
| General COS/MOS Characteristics |

.The CD4049A and CD4050A are inverting and non-inverting hex buffers, respectively, and feature logic-level conversion using only one supply voltage ( $\mathrm{V}_{\mathrm{CC}}$ ). The input-signal high level $\left(V_{\mid H}\right)$ can exceed the $V_{C C}$ supply voltage when these devices are used for logic-level conversions. These devices are intended for use as COS/MOS to DTL/TTL converters and can drive directly two DTL/TTL loads. $\quad \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$. $\mathrm{V}_{\mathrm{OL}} \leq 0.4 \mathrm{~V}$, and $\mathrm{I}_{\mathrm{D}} \mathrm{N} \geq 3 \mathrm{~mA}$.)

Table 1 shows the range of voltage-supply levels that can be utilized for such logic level conversions. Conversion to logiclevels greater than +6 V is permitted provided that $\mathrm{V}_{\mathrm{CC}}$ $\leq \mathrm{V}_{1 \mathrm{H}}$. At 15 V , the maximum allowable load capacitance is 5000 pF .

The CD4049A and CD4050A are designated as replacements for CD4009A and CD4010A, respectively. Because the CD4049A and CD4050A require only one power supply, they are preferred over the CD4009A and CD4010A and should be used in place of the CD4009A and CD4010A in all inverter, current driver, or logic-level conversion applications: In these applications the CD4049A and CD4050A are pin compatible with the CD4009A and CD4010A respectively, and can be substituted for these devices in existing as well as in new designs. Terminal No. 16 is not connected internally on the CD4049A or CD4050A, therefore, connection to this terminal is of no consequence to circuit operation.

The CD4049A and CD4050A are supplied in 16-lead dual inline welded-seal ceramic packages (CD4049AD and CD4050AD), 16-lead dual-in-line plastic packages (CD4049AE and CD4050AE), 16-lead dual-in-line frit-seal ceramic packages (CD4049AF and CD4050AF) and 16 -lead flat packages (CD4049AK and CD4050AK).

TABLE I

| FUNCTION | COS/MOS <br> VOLTAGE <br> RANGE (INPUT) | DTL/TTL <br> VOLTAGE <br> RANGE (OUTPUT) | POWER SUPPLY <br> VOLTAGE <br> RANGE (VCC) |
| :--- | :---: | :---: | :---: |
| HEX LEVEL SHIFTER | $3-15 \mathrm{~V}$ | $3-6 \mathrm{~V}$ | $3-6 \mathrm{~V}$ |
| HEX INVERTER <br> HEX BUFFER | $3-15 \mathrm{~V}$ | $3-15 \mathrm{~V}$ | $3-15 \mathrm{~V}$ |



Fig.1-a) Schematic diagram of CD4049A, 1 of 6 identical units; b) Schematic diagram of CD4050A, 1 of 6 identical units.

File No. 599

MAXIMUM RATINGS, Absolute-Maximum Values:

| Storaye-Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: |
| Operating-Temperature Range: |  |  |
| Ceramic Package Types | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Plastic Package Types | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| DC Supply Voltage Range ( $\mathrm{V}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{SS}}$ ) | -0.5 to +15 | V |
| Dissipation: |  |  |
| Per Package | 200 | mW |
| Per Buffer. | 100 | mW |
| All Inputs . | $\mathrm{V}_{\text {SS }} \leq \mathrm{V}_{1} \leq 15$ | V |
| Recommended Minimum DC Supply Voltage ( $\mathrm{V}_{\mathrm{cc}}-\mathrm{V}_{\mathrm{SS}}$ ). | 3 |  |
| ead Temperature (During soldering): |  |  |
| At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79$ from case for 10 seconds max. | ) 265 | ${ }^{\circ} \mathrm{C}$ |

STATIC ELECTRICAL CHARACTERISTICS (All Inputs $\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{\mathbf{1}} \leqslant \mathbf{1 5} \mathrm{V}$ )
(Recommended DC Supply Voltage (VCC $-\mathrm{V}_{\text {SS }}$ ) . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4049AD, CD4049AK, CD4049AF CD4050AD, CD4050AK, CD4050AF |  |  |  |  |  |  |  |  |  |
|  |  |  | $\mathrm{V}_{0}$ | VCC | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  | Volts | Volts | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| Quiescent Device Current | ${ }_{L}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{IH}}= \\ & \mathrm{V}_{\mathrm{CC}} \end{aligned}$ |  | 5 | - | - | 0.3 | - | 0.01 | 0.3 | - | - | 20 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | $30^{\prime}$ |  |
| Quiescent Device Dissipation Package | $P_{D}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{IH}}= \\ & \mathrm{V}_{\mathrm{CC}} \end{aligned}$ |  | 5 | - | - | 1.5 | - | 0.05 | 1.5 | - | - | 100 | $\mu \mathrm{W}$ |
|  |  |  |  | 10 | - | - | 5 | - | 0.1 | 5 | - | - | 300 |  |
| Output Voltage Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |
| $\begin{aligned} & \text { Noise Immunity (All } \\ & \text { Inputs) } \\ & \text { CD4049A } \end{aligned}$ | $\mathrm{V}_{\mathrm{NL}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}}= \\ & 3.6 \mathrm{~V} \end{aligned}$ |  | 5 | 1 | - | - | 1 | 2.25 | - | 0.9 | - | - |  |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}}= \\ & 7.2 \mathrm{~V} \end{aligned}$ |  | 10 | 2 | - | - | 2 | 4.5 | - | 1.9 | - | - |  |
| CD4050A |  | $\begin{aligned} & \mathrm{V}_{0 \mathrm{~L}}= \\ & 0.95 \mathrm{~V} \end{aligned}$ |  | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - |  |
|  |  | $\begin{aligned} & V_{O L}= \\ & 2.9 \mathrm{~V} \end{aligned}$ |  | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |
| CD4050A | $\mathrm{V}_{\mathrm{NH}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}}= \\ & 7.2 \mathrm{~V} \end{aligned}$ |  | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - | V |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{OH}}= \\ & 3.6 \mathrm{~V} \end{aligned}$ |  | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - |  |  |
| CD4049A |  | $\begin{aligned} & \hline \mathrm{VOL}_{\mathrm{OL}} \\ & 2.9 \mathrm{~V} \end{aligned}$ |  | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |
| For Definition, See Appendix |  | $\begin{aligned} & \mathrm{V}_{0 \mathrm{~L}}= \\ & 0.95 \mathrm{~V} \end{aligned}$ |  | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |
| Output Drive Current N-CHANNEL | ${ }_{1}{ }^{N}$ |  | 0.4 | 4.5 | 3.3 | - | - | 2.6 | 5.2 | - | 1.8 | - | - | mA |
|  |  |  | 0.4 | 5 | 3.75 | - | - | 3.0 | 6 | - | 2.1 | - | - |  |
|  |  |  | 0.5 | 10 | 10 | - | - | 8 | 16 | - | 5.6 | - | - |  |
| P.CHANNEL | $I_{0}{ }^{P}$ |  | 4.5 | 5 | -0.62 | - | - | -0.5 | -1 | - | -0.35 | - | - |  |
|  |  |  | 2.5 | 5 | -1.85 | - | - | -1.25 | -2.5 | - | -0.9 | - | - |  |
|  |  |  | 9.5 | 10 | -1.85 | - | - | -1.25 | -2.5 | - | -0.9 | - | - |  |
| Input Current | 1 | $\mathrm{V}_{1 \mathrm{H}}=\mathrm{V}_{\text {cc }}$ |  |  | - | - | - | - | 10 | - | - | - | - | pA |

STATIC ELECTRICAL CHARACTERISTICS (All Inputs
(Recommended DC Supply Voltage (VCC - VSS) . . . . . 3 to 15 V)



92cs-20479
Fig. 2 - Min. \& max. voltage transfer characteristics for CD4049A.


92Cs-20480

Fig. 3 - Min. \& max. voltage transfer characteristics for CD4050A.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, and input rise and fall times=20 ns Typical Temperature Coefficient for all values of $\mathbf{V C C}_{\mathbf{C C}}=\mathbf{0 . 3 \% /}{ }^{\circ} \mathrm{C}$. (See Appendix for Waveforms)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4049AD, AE CD4049AF, AK |  |  | CD4050AD, AE CD4050AF, AK |  |  |  |  |
|  |  |  | $V_{C C}$ <br> (Volts) | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time: High-to-Low Level | tPHL | $\mathrm{V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{CC}}$ | 5 10 | - | 15 10 | $\begin{aligned} & 55 \\ & 30 \end{aligned}$ | - | 55 25 | $\begin{array}{r} 110 \\ 55 \end{array}$ | ns | 10,11 |
| Low-to-High Level | ${ }^{\text {tPLH }}$ | $\mathrm{V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{CC}}$ | 5 10 | - | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ | $\begin{aligned} & 80 \\ & 55 \end{aligned}$ | - | 75 35 | 140 85 | ns | 12,13 |
| Transition Time: High-to-Low Level | ${ }^{\text {t }}$ HL | $\mathrm{V}_{\mathrm{IH}}=\mathrm{V}_{\mathrm{CC}}$ | 5 10 | - | $\begin{aligned} & 20 \\ & 16 \end{aligned}$ | $\begin{aligned} & 45 \\ & 40 \end{aligned}$ | - | $\begin{aligned} & 20 \\ & 16 \end{aligned}$ | $\begin{aligned} & 45 \\ & 40 \end{aligned}$ | ns | 14 |
| Low-to-High Level | ${ }^{\text {t }}$ TLH | $\mathrm{V}_{\text {IH }}=\mathrm{V}_{\mathrm{CC}}$ | 5 10 | - | 50 30 | $\begin{array}{r} 100 \\ 60 \end{array}$ | - | 50 30 | $\begin{array}{r} 100 \\ 60 \end{array}$ | ns | 15 |
| Input Capacitance (Any Input) | $C_{1}$ | $\begin{aligned} & \text { CD4049A } \\ & \text { CD4050A } \end{aligned}$ |  | - | 15 5 | - | - | 15 5 | - | pF |  |



Fig. 4 - Min. \& max. voltage transfer characteristics for CD4049A.


Fig. 5 - Min. \& max. voltage transfer characteristics for CD4050A.


Fig. 6 - Typ. voltage transfer characteristics as a function of temperature for CD4049A.


Fig. 8 - Typ. \& min. drain characteristics as a function of gate-tosource voltage ( $V_{G S}$ ) for CD4049A, CD4050A.


Fig. 10 - Typ. high-to-low level propagation delay time vs. $C_{L}$ for CD4049A.


Fig. 7 - Typ. voltage transfer characteristics as a function of temperature for CD4050A.


Fig. 9 - Typ. \& min. P-channel drain characteristics as a function of gate-to-source voltage ( $V_{G S}$ ) for CD4049A, CD4050A.


Fig. 11 - Typ. high-to-Iow level propagation delay time vs. $C_{L}$ for CD4050A.


Fig. 12 - Typ. low-to-high level propagation delay time vs. $C_{L}$ for CD4049A.


Fig. 14 - Typ. high-to-low level transition time vs. $C_{L}$ for CD4049A, CD4050A.


Fig. 13 - Typ. low-to-high level propagation delay time vs. $C_{L}$ for CD4050A.


92cs-20489
Fig. 15 - Typ. low-to-high level transition time vs $C_{L}$ for CD4049A, CD4050A.


Fig. 16 - Typ. dissipation characteristics for CD4049A, CD4050A.


Fig. 17 - Noise immunity test circuits.


Fig. 18 - Quiescent device current test circuit.



Fig. 19 - Typ. power dissipation vs transition time per inverter CD4049A.


Fig. 21 - Logic-level conversion application.

Fig. 20 - Typ. power dissipation vs. transition time per inverter CD4050A.

## Preliminary Data 4



# COS/MOS Analog Multiplexers/Demultiplexers 

## With Logic - Level Conversion

## CD4051A Single 8-Channel Multiplexer/Demultiplexer <br> CD4052A Differential 4-Channel Multiplexer/Demultiplexer <br> CD4053A Triple 2-Channel Multiplexer/Demultiplexer

## Applications:

- Analog and digital multiplexing and demultiplexing
- A/D and D/A conversion
- Signal gating

RCA COS/MOS Analog Multiplexers/Demultiplexers* Preliminary CD4051A, CD4052A, and CD4053A are digitally controlled analog switches having low "ON" impedance and very low "OFF" leakage current. Control of analog signals up to 15 V p-p can be achieved by digital signal amplitudes of 3 to 15 V . For example, if $\mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{EE}}=$ -5 V , analog signals from -5 V to +5 V can be controlled by digital inputs of 0 to 5 V . The multiplexer circuits dissipate extremely low quiescent power over the full $V_{D D}-V_{S S}$ and $V_{D D}-V_{E E}$ supply-voltage ranges, independent of the logic state of the control signals. When a logic " 1 " is present at the inhibit input terminal all channels are "OFF".
CD4051A is a single 8 -channel multiplexer having three binary control inputs, $A, B$, and $C$, and an inhibit input. The three binary signals select 1 of 8 channels to be turned "ON" and connect the input to the output.
CD4052A is a differential 4-channel multiplexer having two binary control inputs, $A$ and $B$, and an inhibit input. The two binary input signals select 1 of 4 pairs of channels to be turned on and connect the differential analog inputs to the differential outputs.
CD4053A is a triple 2-channel multiplexer having three separate digital control inputs, $A, B$, and $C$ and an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole double-throw configuration.

These devices are supplied in a 16 -lead dual-in-line ceramic package (CD4051AD, CD4052AD, and CD4053AD), a 16 -lead dual-in-line plastic package (CD4051AE, CD4052AE, and CD4053AE), or a 16 -lead flat pack (CD4051AK, CD4052AK, and CD4053AK).

[^11]
## Features:

- Wide range of digital and analog signal levels:
digital 3 to 15 V , analog to 15 V p-p
© Low "ON" resistance: $80 \Omega$ (typ.) over entire 15 V p-p signal-input range for $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{EE}}=15 \mathrm{~V}$
- High "OFF" resistance: input leakage $\pm 10 \mathrm{pA}$ (typ.) @ $V_{D D}-V_{E E}=10 \mathrm{~V}$
- Logic-level conversion for digital addressing signals of 3 to $15 \mathrm{~V}\left(\mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=3 \mathrm{~V}\right.$ to 15 V$)$ to switch analog signals to $15 \mathrm{~V} p-\mathrm{p}\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{EE}}=15 \mathrm{~V}\right)$
- Matched switch characteristics: $\Delta R_{O N}=5 \Omega$ (typ.) for $V_{D D}-V_{E E}=15 V$
- Very low quiescent power dissipation under all digitalcontrol input and supply conditions: $1 \mu \mathrm{~W}$ typ. @

$$
V_{D D}-V_{S S}=V_{D D}-V_{E E}=10 \mathrm{~V}
$$

- Binary address decoding on chip

| INPUT STATES |  |  |  | "ON" CHANNELS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INHIBIT | C | B | A | CD4051A | CD4052A | CD4053A |
| 0 | 0 | 0 | 0 | 0 | 0x, 0 y | cx, bx, ax |
| 0 | 0 | 0 | 1 | 1 | 1x, 1y | cx, bx, ay |
| 0 | 0 | 1 | 0 | 2 | 2x, 2y | cx, by, ax |
| 0 | 0 | 1 | 1 | 3 | $3 \mathrm{x}, 3 \mathrm{y}$ | cx, by, ay |
| 0 | 1 | 0 | 0 | 4 |  | cy, bx, ax |
| 0 | 1 | 0 | 1 | 5 |  | cy, bx, ay |
| 0 | 1 | 1 | 0 | 6 |  | cy, by, ax |
| 0 | 1 | 1 | 1 | 7 |  | cy, by, ay |
| 1 | * | * | * | NONE | NONE | NONE |

* $=$ Don't care condition


## MAXIMUM RATINGS, Absolute Maximum Values

Storage-Temperature Range . . . . . . . . . $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Operating-Temperature Range
Ceramic Packages . . . . . . . . . . . . . . $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
Plastic Packages $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Dissipation Per Package . . . . . . . . . . . . . . . . . . . . . . . 200 mW
DC Supply Voltages
$V_{D D}-V_{S S} ; V_{D D}-V_{E E} \ldots . . . . . .$.
Digital Control Inputs . . .................. $V_{S S} \leqslant V_{1} \leqslant V_{D D}$
Minimum Recommended Power Supply Voltages

Lead Temperature (During soldering)
At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds max. . . . . . . . . . ..... . $265^{\circ} \mathrm{C}$ Operating Precautions:

1. $R_{L} \geqslant 100 \Omega$
2. Signal Input Current Capability $<25 \mathrm{~mA}$

## OPERATING CONSIDERATIONS

## 1. Handling

All COS/MOS gate inputs have a resistor/diode gate protection network. All transmission gate inputs and all outputs have diode protection provided by inherent p-n junction diodes. These diode networks at input and output interfaces fully protect COS/MOS devices from gate-oxide failure ( 70 to 100 volt limit) for static discharge or signal voltage up to 1 to 2 kilovolts under most transient or low-current conditions.

Although protection against electrostatic effects is provided by built-in circuitry, the following handling precautions should be taken:

1. Soldering-iron tips and test equipment should be grounded.
2. Devices should not be inserted in non-conductive containers such as conventional plastic snow or trays.

## 2. Operating

## Unused Inputs

All unused input leads must be connected to either $\mathrm{V}_{\text {SS }}$ or $V_{D D}$, whichever is appropriate for the logic circuit involved. A floating input on a high-current type, such as the CD4009A, CD4010A, not only can result in faulty logic operation, but can cause the maximum power dissipation of 200 milliwatts to be exceeded and may result in damage to the device. Inputs to these types, which are mounted on printed-circuit boards that may temporarily become unterminated, should have a pull-up resistor to $V_{S S}$ or $V_{D D}$. A useful range of values for such resistors is from 0.2 to 1 megohm.

## Input Signals

Signals shall not be applied to the inputs while the device power supply is off unless the input current is limited to a steady state value of less than 10 milliamperes.

## Output Short Circuits

Shorting of outputs to $\mathrm{V}_{\mathrm{SS}}$ or $\mathrm{V}_{\text {DD }}$ can damage many of the higher-output-current COS/MOS types, such as the CD4007A, CD4009A, and CD4010A. In general, these types can all be safely shorted for supplies up to 5 volts, but will be damaged (depending on type) at higher power-supply voltages. For cases in which a short-circuit load, such as the base of a p-n-p or an n-p-n bipolar transistor, is directly driven, the device output characteristics given in the published data should be consulted to determine the requirements for a safe operation below $\mathbf{2 0 0}$ milliwatts.


Fig. 1 - Functional diagram preliminary CD4051A.

[^12]

Fig. 2 - Functional diagram preliminary CD4052A.


Fig. 3 - Functional diagram, preliminary CD4053A.

* See operating precautions, P. 2.

ELECTRICAL CHARACTERISTICS at TA $_{\text {A }}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL VALUES | UNITS | $\begin{array}{\|c\|} \hline \text { CURVE } \\ \& \\ \text { TEST } \\ \text { CIRCUIT } \\ \text { Fig. No. } \end{array}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ | $\mathrm{V}_{\mathrm{DD}}$ | $\mathrm{V}_{\text {SS }}$ | $\mathrm{V}_{\mathrm{EE}}$ | 0.1 | $\mu \mathrm{A}$ |  |
|  |  | $\begin{aligned} & +10 \mathrm{~V} \\ & +5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} \hline 0 \mathrm{~V} \\ \text { OV } \mathrm{OR}- \\ \text { NOTE } 1 \end{gathered}$ | ${ }_{-5 \mathrm{~V}}^{0 \mathrm{~V}}$ |  |  | - |
| Quiescent Device Dissipation per Package | ${ }^{\text {P }}$ D | $\begin{aligned} & +10 \mathrm{~V} \\ & +5 \mathrm{~V} \end{aligned}$ | $\begin{gathered} \hline 0 \mathrm{~V} \\ \mathrm{ov} \\ \text { OR }- \\ \text { NOTE } 1 \end{gathered}$ | $\underbrace{0 \mathrm{~V}}_{-5}$ | 1 | $\mu \mathrm{W}$ | - |

NOTE 1: All digital combinations on address inputs; all analog inputs
$V_{E E} \leqslant V_{1} \leqslant V_{D D}$

ELECTRICAL CHARACTERISTICS at TA $_{A}=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL <br> VALUES | UNITS |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SIGNAL INPUTS ( $\mathrm{V}_{\text {is }}$ ) AND OUTPUTS ( $\mathrm{V}_{\text {os }}$ ) |  |  |  |  |  |  |  |
| "ON" Resistance <br> (Peak for $\mathrm{V}_{\text {SS }} \leqslant \mathrm{V}_{\text {IS }} \leqslant \mathrm{V}_{\text {DD }}$ ) | $\mathrm{R}_{\mathrm{ON}}$ | $\begin{gathered} R_{\mathrm{L}}=10 \mathrm{k} \Omega 2 \\ \mathrm{~V}_{\mathrm{SS}}=0 \end{gathered}$ | V | VIS |  | $\Omega$ | 5 |
|  |  |  | $\begin{array}{l\|l} \hline+7.5 \mathrm{~V} & -7.5 \mathrm{~V} \\ \mathrm{OR} \\ +15 \mathrm{~V} & 0 \mathrm{~V} \\ \hline \end{array}$ | - | 80 |  |  |
|  |  |  | +5 V -5 V <br>   <br> +10 V 0 V | - | 120 |  |  |
|  |  |  |  | - | 270 |  |  |
| $\triangle$ "ON" Resistance <br> Between Any 2 Channels | $\Delta R_{\text {ON }}$ | (Any channel selected) | +7.5 V -7.5 V <br> +15 V $0 R$ <br> +5 V 0 OV <br> +10 V 0 V <br> +10 V  | - | 5 10 | $\Omega 2$ | - |
| Sine Wave Response (Distortion) |  | $\begin{aligned} & R_{\mathrm{L}}=10 \mathrm{kS} \\ & \mathrm{~V}_{\mathrm{SS}}=0 \\ & \mathrm{f}_{\mathrm{is}}=1 \mathrm{kHz} \end{aligned}$ | +7.5 V -7.5 V <br> +5 V -5 V <br> +2.5 V -2.5 V | $5 \vee(p \cdot p) \pm$ | $\begin{gathered} 0.1 \\ 0.2 \\ 1 \end{gathered}$ | \% |  |
| OFF Channel Leakage Current: Any Channel "OFF" |  | $\mathrm{V}_{\text {SS }}=0 \mathrm{~V}$ | $\left.+5 \mathrm{~V} \quad \begin{array}{l}\left(=V_{C}\right) \\ -5 \mathrm{~V}\end{array}\right)$ | - | $\pm 0.01$ | $n A$ | 11 |
| All Channels "OFF" (Common OUT/IN) |  | $\begin{aligned} & \text { INHIBIT } \\ & -+5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{SS}} \quad 0 \mathrm{~V} \end{aligned}$ | $\begin{array}{l\|l}  & \left(=V_{C}\right) \\ +5 V & -5 V \end{array}$ | $\begin{aligned} & \text { CD4051A } \\ & \text { CD4052A } \\ & \text { CD4053A } \end{aligned}$ | $\begin{array}{r}  \pm 0.08 \\ \pm 0.04 \\ \pm 0.02 \\ \hline \end{array}$ |  | 12 |
| Frequency ResponseChannel "ON" (Sine Wave Input) |  | $\begin{aligned} & R_{L}-1 \mathrm{k} \Omega 2 \\ & V_{\text {is }} \quad 5 \mathrm{~V}(\mathrm{p}-\mathrm{p}) \\ & \mathrm{V}_{\mathrm{SS}} 0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & V_{C} V_{D D}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5 \mathrm{~V} \\ & 20 \log _{10} \frac{V_{\mathrm{OS}}}{V_{\text {is }}}=-3 \mathrm{~dB} \end{aligned}$ |  | 40 | MHz |  |
| Feedthrough Channel "OFF" |  |  | $\begin{aligned} & V_{\mathrm{DD}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{C}} \\ & 20 \log _{10} \frac{V_{\mathrm{OS}}}{V_{\text {is }}}= \end{aligned}$ | $\begin{aligned} & V_{E E}=-5 V \\ & 10 \mathrm{~dB} \end{aligned}$ | 1 | MHz |  |
| Crosstalk Between any 2 Channels (Frequency at - 40 dB ) |  | $\begin{aligned} & R_{L}=1 \mathrm{ks} \\ & V_{1 S}(A)-5 \mathrm{~V}(\mathrm{p} \cdot \mathrm{p}) \\ & V_{S S} 0 \mathrm{~V} \end{aligned}$ | $\begin{array}{r} V_{C}(A)=V_{D D}=+9 \\ V_{C}(B)= \\ 20 \log _{10} \frac{V_{\text {OS }}}{V_{\text {IS }}}= \end{array}$ | $\begin{aligned} & J_{E E}=--5 V \\ & 10 \mathrm{~dB} \end{aligned}$ | 1 | MHz |  |
| Capacitance: $\begin{array}{ll}\text { Input } \\ & \\ & \left.\begin{array}{l}\text { Output } \\ \text { Common } \\ \text { OUT/IN }\end{array}\right) \\ \text { Feedthrough }\end{array}$ | $\begin{array}{\|l\|} \hline \mathrm{C}_{\mathrm{IS}} \\ \mathrm{C}_{\mathrm{OS}} \end{array}$ | $\begin{aligned} & V_{D D}=+5 \mathrm{~V} \\ & V_{C}=V_{E E}=-.5 \mathrm{~V} \\ & V_{S S}=0 \mathrm{~V} \end{aligned}$ |  |  | 5 | pF |  |
|  |  |  |  | CD4051A | 30 |  |  |
|  |  |  |  | CD4052A | 18 |  |  |
|  |  |  |  | CD4053A | 10 |  |  |
|  | $\mathrm{C}_{1 \mathrm{OS}}$ |  |  |  | 0.2 |  |  |
| Propagation Delay: <br> Signal Input-to- <br> Signal Output | ${ }^{1} \mathrm{PLH}$. <br> ${ }^{\text {tPHL }}$ | $\begin{aligned} & V_{C}=V_{D D}=+10 V \\ & V_{\text {is }}=10 V . V_{S S} \\ & t_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns} \text { (input } \end{aligned}$ | $\begin{aligned} & V_{E E}=0 \mathrm{~V}, C_{L}=15 \\ & V=\text { Inhibit } \\ & \text { nal) } \end{aligned}$ |  | 10 | ns |  |
| CONTROL ( $V_{\text {C }}$ ) INPUTS A, B, C, AND INHIBIT |  |  |  |  |  |  |  |
| Noise Immunity (Any control input) | $v_{N L}$ | $\begin{aligned} & V_{\text {is }}=V_{D D} \text { thru } 1 \mathrm{ks} \\ & V_{E E}=V_{S S} \\ & I_{\text {is }}=10 \mu A \\ & R_{L}=1 \mathrm{ks} \text { to } V_{E E} \end{aligned}$ | $\begin{aligned} & v_{D D}-v_{S S}=10 \mathrm{~V} \\ & v_{D D}-v_{S S}=5 \mathrm{~V} \\ & \hline \end{aligned}$ |  | $\begin{array}{r} 4.5 \\ 2.25 \end{array}$ | V | -- |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | $\begin{aligned} & V_{D D}-V_{S S}=10 \mathrm{~V} \\ & V_{D D}-V_{S S}=5 \mathrm{~V} \end{aligned}$ |  | $\begin{array}{r} 4.5 \\ 2.25 \end{array}$ |  |  |
| Average Input Capacitance | $C_{1}$ | $\begin{array}{ll} \mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V} & \mathrm{~V}_{\mathrm{EE}}=-5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{SS}}=0 \mathrm{~V} & \text { Channel "OFF" } \end{array}$ |  |  | 5 | pF | - |

[^13]
## ELECTRICAL CHARACTERISTICS at $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  |  | TYPICAL VALUES | UNITS |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CONTROL (VC) INPUTS A, B, C, AND INHIBIT |  |  |  |  |  |  |  |  |
| Turn "ON" Propagation Delay: <br> Contral Input-to-signal output | ${ }^{1} \mathrm{PLH}$. <br> ${ }^{\mathrm{t} P \mathrm{PHL}}$ | $\begin{aligned} & C_{L}=15 \mathrm{pF} \\ & R_{L}=10 \mathrm{ks} \\ & V_{\text {is }} \leqslant V_{D D} \\ & t_{1}, t_{\mathrm{f}}=20 \mathrm{~ns} \\ & V_{S S}=\text { Inhibit }=0 \mathrm{~V} \end{aligned}$ | $\begin{gathered} V_{C} \\ \hline 10 V \\ 5 V \\ +5 V \text { to } \\ -5 V \end{gathered}$ | $\begin{gathered} V_{D D} \\ \hline 10 \mathrm{~V} \\ 5 \mathrm{~V} \\ 5 \mathrm{~V} \end{gathered}$ | $\begin{array}{r} V_{\mathrm{EE}} \\ 0 \mathrm{~V} \\ 0 \mathrm{~V} \\ -5 \mathrm{~V} \end{array}$ | 200 400 400 | ns | 13 |
| Inhibit Input-to-Signal Output |  | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & R_{\mathrm{L}}=10 \mathrm{ks} \\ & \mathrm{~V}_{\mathrm{is}}=V_{\mathrm{DD}} \\ & \mathbf{t}_{\mathbf{r},} \mathbf{t}_{\mathrm{f}}=20 \mathrm{~ns} \end{aligned}$ | $\begin{aligned} & 10 \mathrm{~V} \\ & 5 \mathrm{~V} \end{aligned}$ | $\begin{array}{r} 10 \mathrm{~V} \\ 5 \mathrm{~V} \\ \hline \end{array}$ | $0 \vee$ $0 \vee$ | $\begin{aligned} & 300 \\ & 600 \end{aligned}$ | ns | 14 |
| Inhibit Recovery Time ${ }^{\text {- }}$ | - | $V_{D D}=10 \mathrm{~V}$ |  |  |  | 200 | ns |  |

- Time after inhibit is removed during which channel information is invalid
- Square wave


Fig. 4(a) - Typical Channel "ON" resistance vs. signal voltage for preliminary CD4051A.


Fig. 4(c) - Typical Channel "ON" resistance vs. signal voltage for preliminary CD4051A with supply voltage $\left(V_{D D}-V_{E E}\right)=10 \mathrm{~V}$.
Fig. 4(c) - Typical Channel "ON resistance vs. signal volta

Channei Overlap = Turn-on propagation delay, where channel overlap is defined as the duration after control signal change during which te:o channels may be on together.

Fig. 4(b) - Typical Channel "ON" resistance vs. signal voltage for preliminary CD4051A with supply voltage $\left(V_{D D}-V_{E E}\right)=5 \mathrm{~V}$.



92cs-22715
Fig. 4(d) - Typical Channel "ON" resistance vs. signal voltage for preliminary CD4051A with supply voltage
$\left(V_{D D}-V_{E E}\right)=15 V$.


Fig. 5 - Channel "ON" resistance measurement circuit.


Fig. 6 - Typical "ON" characteristics for 1 of 8 channels for preliminary CD4051A.


Fig. 7 - Typical dissipation (per package) vs. switching frequency for preliminary CD4051AD.


Fig. 8 - Typical dissipation (per package) vs. switching frequency for preliminary CD4052AD.


Fig. 9 - Typical dissipation (per package) vs. switching frequency for preliminary CD4053AD.

(a)

(b)

(c)

(d)

The ADDRESS (digital-control inputs) and INHIBIT logic levels are: " 0 " =
$\mathrm{V}_{\text {SS }}$ and " 1 " $=\mathrm{V}_{\mathrm{DD}}$. The analog signal (through the TG ) may swing from
Fig. 10 - Typical bias voltages.

## TEST CIRCUITS



Fig. 11 - OFF channel leakage current . . . any channel off.


Fig. 12 - OFF channel leakage current . . . all channels off.

## TEST CIRCUITS



Fig. 13 - Turn-on propagation delay . . . control input to signal output.


Fig. 14 - Turn-on propagation delay . . . inhibit input to signal output.


# COS/MOS Liquid-Crystal Display Drivers 

CD4054A - 4-Segment Display Driver<br>CD4055A - BCD io 7-Segmeni Decoder/Driver wiúi<br>"Display-Frequency" Output<br>CD4056A - BCD to 7-Segment Decoder/Driver with<br>Strobed-Latch Function

Features:

- Operation of liquid crystals with COS/MOS circuits provides ultra-low-power displays
- Equivalent AC output drive for liquid-crystal displays no external capacitor required
- Voltage doubling across display $\left[\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{EE}}\right)=15 \mathrm{~V}\right]$ results in effective $30 \mathrm{~V}(\mathrm{p}-\mathrm{p})$ drive across selected display segments

RCA-CD4055A and CD4056A are Single-Digit BCD-to-7Segment Decoder/Driver circuits that provide level-shifting functions on the chip. This feature permits the BCD inputsignal swings ( $V_{D D}$ to $V_{S S}$ ) to be the same as or different from the 7 -segment output-signal swings (VDD to $V_{E E}$ ). For example, the BCD input-signal swings ( $V_{D D}$ to $V_{S S}$ )may be as low as 0 to -3 V , whereas the output-display drive-signal swing (VDD to $V_{E E}$ ) may be from 0 to -15 V .
The 7 -segment outputs are controlled by the "Display-Frequency" (DF) input which causes the selected segment outputs to be "low", "high", or a "square-wave" output (for liquidcrystal displays). When the DF input is "low" the output segments will be "high" when selected by the BCD inputs. When the DF input is "high", the output segments will be "low" when selected by the BCD inputs. When a square wave is present at the DF input, the selected segments will have a square-wave output which is $180^{\circ}$ out of phase with the DF input. Those segments which are not selected will have a


Fig. 2 - CD4054A Functional block diagram

- Low- or high-output level DC drive for other types of displays
- On-chip logic - level conversion for different inputand output-level swings
- Full decoding of all input combinations: ${ }^{\prime \prime} 0-9$, L, H, P, A, -," and blank positions
- Strobed-latch function - CD4054A and CD4056A
- "Display-frequency" (DF) output for liquid-crystal common-line drive signal CD4054A and CD4055A


## Applications:

a General-purpose displays

- Portable lab instruments
- Calculators and meters
- Panel meters
- Wall and table clocks
- Auto dashboard displays
- Industrial control
a Appliance control panels panels


Fig. 3 - CD4056A Functional block diagram

## Maximum Ratings, Absolute-Maximum Values:

| Storage-Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ | Minimum Recommended |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Operating-Temperature Range: |  |  | DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{S S}$ ) or |  |  |
| Ceramic Package Types | -55 to +125 | ${ }^{\circ} \mathrm{C}$ | (VDD-VEE) . | 3 | V |
| Plastic Package Types | -40 to +85 | ${ }^{\circ} \mathrm{C}$ | Lead Temperature (During Soldering) |  |  |
| DC Supply-Voltage Range $\left(V_{D D}-V_{S S}\right) \text { or }\left(V_{D D}-V_{E E}\right)$ | -0.5 to +15 | V | At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$ from case |  |  |
| Device Dissipation (Per Pkg.) | 200 | mW | for 10 seconds max. | 265 | ${ }^{\circ} \mathrm{C}$ |
| All Inputs | $\mathrm{SS} \leqslant \mathrm{V}_{1} \leqslant \mathrm{~V}_{\text {DD }}$ |  |  |  |  |



COMMON ELECTRODE
92Cs-20095RI

Fig. 4 - Clock display: $V_{D D}=0$ V, $V_{S S}=-5 V, V_{E E}=-15 \mathrm{~V}$, $D F I N=30 \mathrm{~Hz}$ square wave


92CS-20096R1

Fig. 5 - Digital (0.5 V) to bidirectional analog control (+5 to -5 V) level shifter
square-wave output that is in phase with the input. The DF input square wave is required to provide equivalent ac drive to liquid-crystal displays such as RCA Dev. Nos. TA8054R, TA8054T, TA8055R, and TA8055T. DF square-wave repetition rates for liquid-crystal displays usually range from 30 Hz (well above flicker rate) to 200 Hz (well below the upper limit of the liquid-crystal frequency response). The CD4055A provides a level-shifted high amplitude DF output which is required for driving the common electrode in liquid-crystal displays. The CD4056A provides a strobed latch function at the BCD inputs. Decoding of all input combinations on the CD4055A and CD4056A provides displays of 0 to 9 as well as "L, H, P, A, -," and a blank position.
The CD4054A provides level shifting similar to the CD4055A and CD4056A, independently strobed latches, and common DF control on 4 signal lines. The CD4054A is intended to provide drive-signal compatibility with the CD4055A and CD4056A 7-segment decoder types for the decimal point, colon, polarity, and similar display lines. A level-shifted highamplitude DF output can be obtained from any CD4054A output line by connecting the corresponding input and strobe lines to a "low" and "high" level, respectively. The CD4054A may also be utilized for logic-level "up conversion" or "down conversion"', For example, input-signal swings (VDD to $V_{S S}$ ) from +5 to 0 V can be converted to output-signal swings
(VDD to $V_{E E}$ ) of +5 to -5 V . The level-shifted function on all three types permits the use of different input- and outputsignal swings. The input swings from a "low" level of VSS to a high level of VDD while the output swings from a "low" level of VEE to the same "high" level of VDD. Thus the input and output swings can be selected independently of each other over a 3 -to- 15 V range. $\mathrm{V}_{\text {SS }}$ may be connected to $\mathrm{V}_{\text {EE }}$ when no level-shift function is required.

For the CD4054A and CD4056A data is transferred from input to output by placing a "high" voltage level at the strobe input. A "low" voltage level at the strobe input latches the data input and the corresponding outputs.
Whenever the level-shifting function is required, the CD4055A can be used by itself to drive a liquid-crystal display (Figs. 4 and 7). However, the CD4056A must be used together with a CD4054A to provide the common DF output (see Fig. 8). The capability of extending the voltage swing on the negative end can be used to advantage in the setup of Fig.5. Fig. 6 is common to all three IC types.
These devices are available in 16-lead dual-in-line ceramic packages ("D suffix), dual-in-line plastic packages ("E" suffix), 16 -lead flat packages (" $K$ " suffix), or in chip form (" $H$ " suffix).

File No. 634

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathrm{v}_{\mathrm{SS}} \leq \mathrm{v}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ )


* For definition, see Appendix.

(a)

* RESULTANT LIQUID-CRYSTAL SEGMENT WAVEFORM IF DFOUT IS

DFIN $=$ DISPLAY-FREQUENCY INPUT
DFOUT: LEVEL-SHIFTED DISPLAY-FREQUENCY OUTPUT 92CS-20094RI
(b)

Fig. 6 - Display-driver circuit for one segment line and waveforms

STATIC ELECTRICAL CHARACTERISTICS (AII inputs
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{\mathbf{1}} \leq \mathrm{V}_{\mathrm{DD}}{ }^{\prime}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\text {DD }}-\mathrm{V}_{\text {SS }}$ ) . . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS <br> Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4054AE <br> CD4055AE <br> CD4056AE |  |  |  |  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{0}$ | $\begin{aligned} & \mathbf{v}_{\mathbf{D D}} \\ & \mathbf{v}_{\mathbf{S S}} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}- \\ & \mathrm{V}_{\mathrm{EE}} \\ & \hline \end{aligned}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | IL. |  | 5 | 10 | - | - | 10 | - | 0.5 | 10 | - | - | 50 | $\mu \mathrm{A}$ | 18,19,20 |
|  |  |  | 15 | 15 | - | - | 20 | - | 1 | 20 | - | - | 100 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | 10 | - | - | 100 | - | 5 | 100 | - | - | 500 | $\mu \mathrm{W}$ |  |
|  |  |  | 15 | 15 | - | - | 300 | - | 15 | 300 | - | - | 1500 |  |  |
| Output Voltage: Low-Level | $\mathrm{VOL}_{\text {OL }}$ |  | 5 | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V |  |
|  |  |  | 15 | 15 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | $\mathrm{VOH}_{\text {O }}$ |  | 5 | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - | V |  |
|  |  |  | 15 | 15 | 14.99 | - | - | 14.99 | 15 | - | 14.95 | - | - |  |  |
| Noise Immunity (All Inputs)* | $\mathrm{V}_{\text {NL }}$ | 1 | 5 | 10 | 1 | - | - | 1 | 2.25 | - | 1 | - | - | V | 15,16,17 |
|  |  | 1.5 | 15 | 15 | 2 | - | - | 2 | 6.75 | - | 2 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 9 | 5 | 10 | 1 | - | - | 1 | 2.25 | - | 1 | - | - | V |  |
|  |  | 13.5 | 15 | 15 | 2 | - | - | 2 | 6.75 | - | 2 | - | - |  |  |
| Output Drive Current: (All Outputs) | ${ }^{1} \mathrm{DN}$ |  |  |  |  |  |  |  |  |  |  |  |  | mA | 11.12 |
| N-Channel |  | 0.5 | 5 | 10 | 0.7 | - | - | 0.6 | 1.8 | - | 0.5 | - | - |  |  |
|  |  | 0.5 | 15 | 15 | 1.2 | - | - | 1 | 2.8 | - | 0.8 | - | - |  |  |
| (All Outputs) <br> P.Channel | ${ }_{1}{ }^{P}$ | 9.5 | 5 | 10 | -0.4 | - | - | -0.3 | -0.9 | - | -0.2 | - | - | mA | 13,14 |
|  |  | 14.5 | 15 | 15 | -0.6 | - | - | -0.5 | -1.4 | - | -0.4 | - | - |  |  |

* For definition, see Appendix.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$, and input rise and fall times $=\mathbf{2 0} \mathrm{ns}$ Typical Temperature Coefficient at all values of $\mathrm{V}_{\mathrm{DD}}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS | CHARACTERISTIC CURVES Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4054AD,AK CD4055AD,AK CD4056AD,AK |  |  | CD4054AE CD4055AE CD4056AE |  |  |  |  |
|  |  | $\mathrm{V}_{\text {DD }}-\mathrm{V}_{\text {SS }}$ | $V_{\text {DD }}-V_{\text {EE }}$ | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Propagation Delay Time (Any Input to Any Output) | tPHL.tPLH | 5 | 10 | - | 450 | 900 | - | 450 | 1200 | ns | - |
|  |  | 15 | 15 | - | 300 | 600 | - | 300 | 800 |  |  |
| Transition Time (Any Output) | tTHL.tTLH | 5 | 10 | - | 40 | 80 | - | 40 | 1.10 | ns | - |
|  |  | 15 | 15 | - | 30 | 60 | - | 30 | 80 |  |  |
| Data Setup Time* | $t_{s}$ | 5 | 10 | - | 70 | 140 | - | 70 | 200 | ns | 9 |
|  |  | 15 | 15 | - | 30 | 60 | - | 30 | 80 |  |  |
| Strobe Pulse* | ${ }^{\text {tw }}$ | 5 | 10 | - | 85 | 170 | - | 85 | 220 | ns | 9 |
| Duration |  | 15 | 15 | - | 40 | 80 | - | 40 | 110 |  |  |
| Input Capacitance | $C_{1}$ | Any Input |  | - | 5 | - | - | 5 | - | pF | - |

* CD4054A and CD4056A only.

| INPUT CODE |  |  |  | OUTPUT STATE |  |  |  |  |  |  | DISPLAY <br> CHARAC－ <br> TER |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 23 | 22. | $2^{1}$ | 20 | a | b | c | $d$ | e | $f$ | $g$ |  |
| 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 1－1 |
| 0 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 1 |
| 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1二 |
| 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 二 |
| 0 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | －1 |
| 0 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 |
| 0 | 1 | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | － |
| 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | ！ |
| 1 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | I－I |
| 1 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | ＇1 |
| 1 | 0 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 0 | 1 |
| 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | ： |
| 1 | 1 | 0 | 0 | 1 | 1 | 0 | 0 | 1 | 1 | 1 | － |
| 1 | 1 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 | 1 | 二： |
| 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | － |
| 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | BLANK |



Fig． 9 －Strobe pulse duration and data setup time

Fig． 8 －Truth table


Fig． 10 －Typical 3－1／2－digit liquid crystal display：$V_{D D}=+5 \mathrm{~V}, V_{S S}=0 \mathrm{~V}, V_{E E}=-10 \mathrm{~V}, D F I N=30 \mathrm{~Hz}$ square wave CHARACTERISTIC CURVES


Fig． 11 －Typical n－channel drain characteristics


Fig． 12 －Minimum n－channel drain characteristics


Fig. 13 - Typical p-channel drain characteristics


Fig. 15 - Noise-immunity test circuit tor CD4054A.


Fig. 14 - Minimum p-channel drain characteristics


Fig. 16 - Noise-immunity test circuit for CD4055A.


Fig. 18 - Quiescent-device-current test circuit for CD4054A.


Fig. 19 - Quiescent-device-current test circuit for CD4054A.


Fig. 20 - Quiescent-device-current test circuit for CD4056A.

File No. 635


## COS/MOS LSI 4-Bit Arithmetic Logic Unit

Applications:

- Parallel Arithmetic Units
- Remote Data Sets
- Process Controllers
- Graphic Display Terminals


## Features:

- LSI Complexity on a Single Chip
- Bidirectional Data Busses
- 16-Instruction Capability
-Add, Subtract, Count
-AND, OR, Exclusive-OR
-Right, Left, or Cyclic Shifts

RCA-CD4057A is a low-power arithmetic logic unit (ALU) designed for use in LSI computers. An arithmetic system of virtually any size can be constructed by wiring together a number of CD4057A ALU's. The CD4057A provides 4-bit arithmetic operations, time sharing of data terminals, and full functional decoding for all control lines. The distributed control system of this device provides great flexibility in system designs by allowing hard-wired connection of N units in 4 N unique combinations. Four control lines provide 16 instructions which include Addition, Subtraction, Bidirectional and Cycle Shifts, Up-Down Counting, AND, OR, and Exclusive-OR logic operations.


Fig. 1 - Block diagram - CD4057A.

- Easily Expandable to 8, 12, 16, . . . Bit Operation
- Conditional-Operation Controls on Chip
a Low Quiescent Device Dissipation . . . $10 \mu \mathrm{~W}$ (typ) at
$V_{D D}=10 \mathrm{~V}$
- Add Time (Data In-To Sum Out) $=375 \mathrm{~ns}$ (typ) at 10 V
- All Terminals Protected Against Static Discharge
- High Noise Immunity . . . 45\% of VDD (typ) Over Full Temperature Range
- Operation from Single Positive or Negative

Power Supply . . . 3 V to 15 V

- Full Military Temperature Range . . . $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$


Fig. 2 - Terminal assignments.

Two mode control lines allow the CD4057A to function as any 4 -bit section of a larger arithmetic unit by controlling the bidirectional serial transfer of data to adjacent arithmetic arrays. By means of three "Conditional Control" lines Overflow, All Zeros, and Negative State conditions may be detected and used to establish a conditional operation. Predetermined operation of the CD4057A on a conditional basis allows greater ALU flexibility. Although especially applicable as a parallel arithmetic unit, the CD4057A also finds use in virtually any application requiring one or more of its 16 basic instructions. The CD4057A is supplied in a hermetically sealed 28 -lead dual-in-line ceramic package (CD4057AD), in a flat-pack (CD4057AK), and in chip form (CD4057AH).

## MAXIMUM RATINGS, Absolute Maximum Values:

StORAGE-TEMPERATURE RANGE. ........... -65 to $+150^{\circ} \mathrm{C}$ OPERATING-TEMPERATURE RANGE $\ldots . . . .-55$ to $+125^{\circ} \mathrm{C}$
DISSIPATION PER PACKAGE.......................... 200 mW
DC SUPPLY-VOLTAGE RANGE $\left(V_{D D^{-}} \mathrm{V}_{\text {SS }}\right) \ldots \ldots$.
ALL INPUTS ................................ $\mathrm{v}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$
Lead Temperature (During soldering)
At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$
from case for 10 seconds max. $\ldots \ldots . \ldots \ldots . . .265{ }^{\circ} \mathrm{C}$
Minimum recommended
DC SUPPLY VOLTAGE ( $\mathrm{V}_{\mathrm{DD}}{ }^{-} \mathrm{V}_{\mathrm{SS}}$ )
3 V

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\mathbf{v}_{\mathbf{S S}} \leq \mathbf{v}_{\mathbf{I}} \leq \mathbf{V}_{\mathrm{DD}}{ }^{\mathbf{\prime}}$
(Recommended DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) . . . . . . . . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  | 4057 | AD, CD | 4057 |  |  |  |  |
|  |  | $V_{0}$ Volts | VDD <br> Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |
| Quiescent Device |  |  | 5 | - | - | 3.7 | - | 0.5 | 5 | - | - | 150 | $\mu \mathrm{A}$ |
| Current | L |  | 10 | - | - | 7.5 | - | 1 | 10 | - | - | 300 |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | 18.5 | - | 2.5 | 2.5 | - | - | 750 | $\mu \mathrm{W}$ |
|  |  |  | 10 | - | - | 75.0 | - | 10 | 100 | - | - | 3000 |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 | V |
|  |  |  | 10 | - | - | 0.01 | - | - | 0.01 | - | - | 0.05 |  |
| High Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - | V |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |
| Noise Immunity (All Inputs) | $\mathrm{V}_{\text {NIL }}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |
| For Definition See Appendix | $\mathrm{V}_{\text {NIH }}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |
| Output Drive Current: | ${ }^{1} \mathrm{D} N$ |  |  |  |  |  |  |  |  |  |  |  | mA |
| Zero Indicator <br> $n$-channel |  | 0.5 | 5. | 0.11 | - | - | 0.09 | 0.16 | - | 0.06 | - | - |  |
|  |  | 0.5 | 10 | 0.12 | - | - | 0.10 | 0.16 | - | 0.07 | - | - |  |
| p-channel | ${ }_{1}{ }^{P}$ | 3 | 5 | 0.04 | - | - | 0.03 | 0.06 | - | 0.02 | - | - |  |
|  |  | 7 | 10 | $0.08{ }^{\prime}$ | - | - | 0.07 | 0.13 | - | 0.05 | - | - |  |
| Negative Indicator n-channel | ${ }^{1} \mathrm{D} N$ | 0.5 | 5 | 0.11 | - | - | 0.09 | 0.30 | - | 0.06 | - | - |  |
|  |  | 0.5 | 10 | 0.12 | - | - | 0.10 | 0.40 | - | 0.07 | - | - |  |
| p-channel | ${ }^{1} D^{P}$ | 4.5 | 5 | 0.07 | - | - | 0.06 | 0.19 | - | 0.04 |  |  |  |
|  |  | 9.5 | 10 | 0.12 | - | - | 0.10 | 0.30 | - | 0.07 | - | - |  |
| Overflow Indicator n-channel | ${ }^{1} \mathrm{D}^{N}$ | 0.5 | 5 | 0.25 | - | - | 0.20 | 0.50 | - | 0.14 | - | - |  |
|  |  | 0.5 | 10 | 0.37 | - | - | 0.30 | 0.90 | - | 0.21 | - | - |  |
| p-channel | ${ }^{1} D^{P}$ | 4.5 | 5 | 0.08 | - | - | 0.07 | 0.21 | - | 0.05 | - | - |  |
|  |  | 9.5 | 10 | 0.12 | - | - | 0.10 | 0.38 | - | 0.07 | - | - |  |
| All Other Outputs $n$-channel | ${ }^{1} \mathrm{D} N$ | 0.5 | 5 | 0.11 | - | - | 0.09 | 0.10 | - | 0.06 | - | - |  |
|  |  | 0.5 | 10 | 0.06 | - | - | 0.05 | 0.12 | - | 0.03 | - | - |  |
| p-channel | ${ }_{1}{ }^{P}$ | 4.5 | 5 | 0.02 | - | - | 0.02 | 0.05 | - | 0.01 | - | - |  |
|  |  | 9.5 | 10 | 0.06 | - | - | 0.05 | 0.08 | - | 0.03 | - | - |  |

File No. 635

DYNAMIC ELECTRICAL CHARACTERISTICS, at $T_{A}=25^{\circ} \mathrm{C}$ and $C_{L}=15 \mathrm{pF}$
Typical Temperature Coefficient at all values of $V_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOLS | TEST CONDITIONS | $\begin{gathered} \text { LIMITS } \\ \text { CD4057AD, CD4057AK } \end{gathered}$ |  |  | UNITS | CHARAC- <br> TERISTIC CURVES \& TEST CIRCUITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Volts | Min. | Tvp. | Max. |  |  |
| Propagation Delay Time: DATA IN-toSUM OUT | $\begin{aligned} & \mathrm{t}_{\mathrm{PLH}}, \\ & \mathrm{t}_{\mathrm{PH}}, \end{aligned}$ | 5 | - | 1430 | 3900 | ns | 10 a |
|  |  | 10 | - | 375 | 720 |  |  |
| CARRY IN-toSUM OUT |  | 5 | - | 915 | 2550 |  | 10 b |
|  |  | 10 | - | 310 | 840 |  |  |
| DATA IN-toCARRY OUT |  | 5 | - | 950 | 2580 |  | 10 a |
|  |  | 10 | - | 265 | 720 |  |  |
| CARRY IN-toCARRY OUT |  | 5 | - | 485 | 1320 |  | 10 b |
|  |  | 10 | - | 175 | 480 |  |  |
| ZI Input <br> -toZI Output | ${ }^{\text {tPLH }}$ | 5 | - | 1980 | 5400 |  |  |
|  |  | 10 | - | 750 | 2040 |  |  |
|  | tPHL | 5 | - | 265 | 720 |  |  |
|  |  | 10 | - | 110 | 300 |  |  |
| Transition Time: | ${ }^{\text {t }}$ L ${ }^{\text {H }}$ |  |  |  |  | ns | 12 |
| ZI Output |  | 5 | - | 3700 | 10350 |  |  |
|  |  | 10 | - | 1650 | 4500 |  |  |
|  | ${ }^{\text {t }}$ HL | 5 | - | 420 | 1140 |  |  |
|  |  | 10 | - | 220 | 600 |  |  |
| Negative Indicator and Overflow Indicator | ${ }^{t}$ TLH, <br> ${ }^{t}$ THL | 5 | - | 300 | 825 |  |  |
|  |  | 10 | - | 165 | 450 |  |  |
| All Other Outputs |  | 5 | - | 1000 | 2775 |  |  |
|  |  | 10 | - | 475 | 1275 |  |  |
| Minimum Clock Pulse Width | ${ }^{t}$ WL, ${ }^{t}$ WH | 5 | - | 400 | 1200 | ns | 13 |
|  |  | 10 | - | 125 | 375 |  |  |
| Clock Rise and Fall Time | $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ | 5 | - | - | 15 | $\mu \mathrm{s}$ | 13 |
|  |  | 10 | - | - | 15 |  |  |
| Set Up Time: | ${ }^{\text {t }}$ SLH, ${ }^{\text {tSHL}}$ |  |  |  |  | ns | 14 |
| DATA |  | 5 | - | 20 | 40 |  |  |
|  |  | 10 | - | 10 | 20 |  |  |
| OP CODE |  | 5 | - | 1675 | 4590 | ns | 14 |
|  |  | 10 | - | 485 | 1320 |  |  |
| Data Hold Time | ${ }^{\text {t }}$ D | 5 | - | 20 | 40 | ns | 15 |
|  |  | 10 | - | 10 | 20 |  |  |
| Maximum Clock Frequency: | ${ }^{\mathrm{f}} \mathrm{CL}$ |  |  |  |  | MHz | 11 |
|  |  | 5 | 0.13 | 0.36 | - |  |  |
|  |  | 10 | 0.46 | 1.35 | - |  |  |
| Shift Mode | ${ }^{\text {f }} \mathrm{CL}$ | 5 | 0.33 | 0.90 | - |  |  |
|  |  | 10 | 1.4 | 3.8 | - |  |  |
| Input Capacitance | $C_{1}$ | ANY INPUT | - | 5 | - | pF |  |



Fig. 3-Simplified logic diagram.

## LOGIC DESCRIPTION

## OPERATIONAL MODES

The CD4057A arithmetic logic unit operates in one of four possible modes. These modes control the transfer of information, either serial data or arithmetic operation carries, to and from the serial-data lines. Fig. 5 shows the manner in which the four modes control the data on the serial-data lines.


Fig. 4 - Typical speed characteristics of a 16-bit ALU at $V_{D D}=10 \mathrm{~V}$.


In MODE 0, data can enter or leave from either the left or the right serial-data line.

In MODE 1, data can enter or leave only on the left serialdata line;

In MODE 2, data can enter or leave only on the right serialdata line.

In MODE 3, serial data can neither enter nor leave the register, regardless of the nature of the operation. Furthermore, the register is by-passed electrically, i.e., there is an electrical bidirectional path between the right and left serial data terminals.

The two input lines labeled C1 and C2 in the terminal assignment diagram define one of four possible modes shown in Table I.

Through the use of mode control, individual arithmetic arrays can be cascaded to form one large processor or many processors of various lengths.

TABLE I - MODE DEFINITION

| $C 2$ | $C 1$ | MODE |
| :---: | :---: | :---: |
| 0 | 0 | 0 |
| 0 | 1 | 1 |
| 1 | 0 | 2 |
| 1 | 1 | 3 |

Examples of how one "hard-wired" combination of three ALU's can form (a) a 12-bit parallel processor, (b) one 8-bit and one 4 -bit parallel processor, or (c) three 4 -bit parallel processors, merely by changes in the modes of each ALU are shown in Fig. 6.


Fig.6-"Mode" connections for parallel processor:
(a) 12-bit unit,
(b) one 8-bit and one 4-bit unit
(c) three 4 -bit units.

Data-flow interruptions are shown by shaded areas. With these three ALU's and the four available modes, 61 more system combinations can be formed. If 4 ALU's are used, $4^{4}$ combinations (256) are possible. Fig. 7 shows a diagram of 4 CD4057A's interconnected to form a 16 -bit parallel processor.

NOTE: The BYPASS terminal of the "most significant" CD4057A is connected to the bypass terminal of the "least significant" CD4057A. The bypass terminals on all other CD4057A's are left floating. This interconnection is performed whenever more than one CD4057A are used to form a processor.

## INSTRUCTION REPERTOIRE

Four encoded lines are used to represent 16 instructions. Encoded instructions are as follows:
abcd
0000 NO-OP (Operational Inhibit)
0001 AND
0010 Count down
0011 Count up
0100 Subtract Stored number from zero (SMZ)
0101 Subtract from parallel data lines (SM) (stored number from parallel data lines)
0110 Add (AD)
0111 Subtract (SUB) (Parallel data lines from stored number)
1000 Set to all ones (SET)
1001 Clear to all zeroes (CLEAR)
1010 Exclusive-OR
1011 OR
1100 Input Data (From parallel data lines)
1101 Left shift
1110 Right shift
1111 Rotate (cycle) right
All instructions ar executed on the positive edge of the clock.

## PARALLEL COMMANDS

a. CLEAR - sets register to zero.
b. SET - sets register to all ones.
c. OR - processes contents of register with value on parallel-data lines in a logical OR function.
d. AND - processes contents of register with value on parallel-data lines in a logical AND function.
e. Exclusive-OR - processes contents of register with data on parallel-data lines in a logical Exclusive-OR function.
f. IN - loads data on parallel-data lines into register.
g. DATA OUT CONTROL - unloads contents of register and overflow flip-flop onto parallel data lines and over. flow I/O independent of all other controls.
h. SUB:

In Mode 0, adds to the contents of the register the one's complement of the data on the parallel-data lines. Carries can enter on the right serial data line and can leave on the left serial data line. The overflow indicator does not change state.

In Mode 1, adds to the contents of the register the two's complement of the data on the parallel-data lines. Generated carries can leave on the left serial line. The CARRY IN is set to zero. The overflow indicator does not change state.
In Mode 2, same as Mode 0 , except carries cannot leave on the right serial-data line. The absence or presence of an overflow is registered.

In Mode 3, same as Mode 1, except carries cannot leave on the left serial-date line. The absence or presence of an overflow is registered.

## i. COUNT UP:

In Mode $\mathbf{0}$, adds to the contents of the register the data on the right serial-data line and permits any resulting carry to leave on the left serial-data line. No data enters the parallel-data lines.

In Mode 1, internally adds a one to the contents of the register and permits any resulting carry to leave on the left serial-data line. No data enters or leaves the right serial-data line.

In Mode 2, adds to the contents of the register the data on the right serial-data line. No data enters or leaves the left serial-data line.

In Mode 3, internally adds a one to the contents of the register. No data enters or leaves the register on any serial-data or parallel-data line.

In all modes, with the DATA OUT control "high" the count is presented on the parallel data lines (D1-D4).

## j. COUNT DOWN:

In Mode 0, subtracts a one (2's complement form) from the contents of the register and adds to this result the data on the right serial data line and permits any resulting carry to leave on the left serial-data line. No data enters on the parallel-data lines.
In Mode 1, internally subtracts a one from the contents of the register and permits any resulting carry to leave on the left serial-data line. No data enters or leaves the right serial-data line.

In Mode 2, subtracts a one from the contents of the register and adds to this result the data on the right serial-data line. No data enters or leaves on the left serial-data line.

In Mode 3, internally subtracts a one from the contents of the register. No data enters or leaves on the serial-data lines.

In all modes, with the DATA OUT control "high" the count is presented on the parallel data lines (D1-D4).

## k. ADD (AD):

In Mode 0, adds the contents of the register to the data on the paraliel-data lines and the right serial-data line. Any resulting carry can leave on the left serial-data line. The overflow indicator does not change state.

In Mode 1, adds the contents of the register to the data on the parallel-data lines and allows any resulting carry to leave on the left serial-data line. The right serial-data line is opencircuited. The overflow indicator does not change state. The CARRY-IN is set to zero.


Fig. 7 - Connection for 16-bit Arithmetic Logic Unit.

In Mode 2, adds the contents of the register to the data on the parallel data lines and the right serial data line. Any overflow sets the overflow indicator. The left serial data line is opencircuited. The absence or presence of an overflow is registered.
In Mode 3, adds contents of the register to the data on the parallel-data lines. Any resulting carry sets the overflow indicator. The two serialdata lines are open circuited. The absence or presence of an oyerflow is registered. The CARRY-IN is set to zero.
I. SM- same operation as AD except the cuntents of the register are two's complemented during addition in Mode 1 and Mode 3. In Mode 0 or Mode 2, the contents of the register are one's complemented and added to the data on the right serial-data line and the parallel-data lines. Overflows occurring in Mode 1 or Mode 0 do not alter the overflow indicator. The presence or absence of overflows is registered on the overflow indicator in Mode 2 or Mode 3.
m. SMZ:

In Mode 0, one's complements the contents of the register and adds the data on the right serial-data line to the contents of the register. Any resulting carry can leave on the left serial-data line. The overflow indicator does not change state.
In Mode 1, two's complements. the contents of the register and permits any carry to leave on the left serial-data line. No data can enter the right serial-data line. The overflow indicator does not change state. The CARRY. IN is set to zero.
In Mode 2, one's complements the contents of the register and adds the data on the right serial-data line to the contents of the register. Carries cannot leave the left serial data line. The absence or presence of an overflow alters the overflow indicator.

In Mode 3, two's complements the contents of the register. Serial data can neither enter the right serial-data line nor leave the left serial-data line. The overflow indicator is at zero. The CARRY-IN is set to zero.
n. NO-OP - no operation takes place. The clock input is inhibited and the state of all registers and indicators remains unchanged.

## SERIAL-SHIFT OPERATIONS

a. ROTATE (cycle) RIGHT - This operation is internal. The contents of the register shift to the right, cyclic fashion with the leftmost stage accepting data from the rightmost stage regardless of the mode. Data can leave the register serially on the right data line only while the
register is in Mode 2 or Mode 0. Data can enter the left data line serially while the register is in Mode 1 or Mode 0 . The Ro1 terminal of the "Most Significiant" CD4057A must be connected to the Ro2 terminal of the "Least Significant" CD4057A. All other Ro1 and Ro2 terminals must be left floating. When only one CD4057A is used, Ro1 must be connected to Ro2.
b. RIGHT SHIFT - The contents of the register shift to the right and serial operations are as follows:
In Mode 0, data can enter serially on the left data line, shift through the register, and leave on the right data line.
In Mode 1, data can enter serially on the left data line. The right data line effectively is opencircuited.
In Mode 2, data can leave serially on the right data line. The left data line effectively is opencircuited. Vacant spaces are filled with zeros.
In Mode 3, serial data can neither enter nor leave the register; however, the contents shift to the right and vacated places are filled with zeros.

In all modes, with the DATA OUT control "high" the data is presented on the parallel data lines (D1-D4).
c. LEFT SHIFT - The contents of the register shift to the left and serial operations are as follows:
In Mode 0, data can enter the right data line, shift through the register, and leave on the left data line.
In Mode 1, data can leave serially on the left data line. The right data line effectively is opencircuited. All vacant positions are filled with zeros.
In Mode 2, data can enter serially on the right data line. The left data line effectively is opencircuited.
In Mode 3, data can neither enter nor leave the register; however, the contents shift to the left, and vacated places are filled with zeros.

In all modes, with the DATA OUT control "high" the data is presented on the parallel data lines (D1-D4).

Because the "DATA OUT" control instruction is independent of the other 16 instructions, care must be taken not to activate this control when data are to be loaded into the processor. This instruction should only be activated when the processor is executing a NO-OP, any SHIFT, SMZ, COUNT UP or DOWN, CLEAR, or SET.

If a data line, serial or parallel, is used as an input and the logic state of that line is not defined (i.e., the line is an open circuit), then the result of any operation using that line is undefined.


NOTES: ROI CONNECTED TO Ro2; BY PASS IS OPEN; ZI CONNECTED TO VOD. REGISTER IN MODE 3.
*SOLID LINE REPRESENTS INPUT FROM EXTERIOR SOURCE WHEN "DATA OUT" IS LOW; DASHED LINE REPRESENTS OUTPUT WHEN "DATA OUT'IS HIGH.

92CL-2025IRI

Fig. 8 - Timing Diagram.

## OPERATIONAL SEQUENCE FOR ARITHMETIC ADD CYCLE

1. Apply IN Instruction and Word A on Parallel Data Lines (D1-D4).
2. Apply CLOCK to load Word $A$ into the register.
3. Apply OP CODE Instruction and Word B on Data Lines.
4. Apply CLOCK to load resulting function of $A$ and. $B$ into the register.
5. Apply "DATA OUT" control to present result to Parallel Data Lines.

NOTE: Transitions of Step 2 and Step 3 may occur almost simultaneously; i.e. separated by only one data-hold time.


* SOLID LINE REPRESENTS INPUT

FROM EXTERIOR SOURCE WHEN
"DATA OUT" IS LOW. DASHED LINES
REPRESENT OUTPUT WHEN "DATA
OUT" IS HIGH
92CS-21877

Fig. 9 - Add cycle waveforms.

## ZERO DETECTION

The condition of "all zeros" is indicated by a " 1 " on the Zero Indicator terminal of the "Most Significant" CD4057A. As shown in Fig. 7, terminal ZI of the CD4057A containing the least significant set of bits is connected to $V_{D D}$. Zero indication is independent of modes.

## NEGATIVE-NUMBER DETECTION

The NEG IND terminal of the CD4057A is connected to the output of the flip-flop that is in the most significant bit position. A " 1 " on the NEG IND terminal indicates a negative number is in the register. This detection is also independent of modes.

## COMPLEMENTING NUMBERS

1. One's complement of number in ALU register.
a) ALU must be in MODE 0 or MODE 2.
b) Zero on Rt. Data Line.
c) Execute an SMZ instruction.
2. One's complement of number to be loaded into ALU register.
a) If zero indicator output is low, execute a CLEAR instruction, and make Rt. Data Line $=0$.
b) ALU must be in MODE 0 or MODE 2.
c) Execute an SUB instruction.
3. Two's complement of number in ALU register.
a) ALU must be in MODE 1 or MODE 3.
b) Execute an SMZ instruction.
4. Two's complement of number to be loaded into ALU register.
a) If zero indicator output is low, execute a CLEAR instruction, and make Rt. Data Line $=0$.
b) ALU must be in MODE 1 or MODE 3.
c) Execute an SUB instruction.

The following algorithms are given as a general guideline to demonstrate some of the capabilities of the CD4057A.

MULTIPLICATON OF TWO N-BIT NUMBERS

| CD4057A <br> ALU <br> (2 N Bits) |
| :---: | | Register 1 |
| :---: |
| (2N Bits) |$\quad$| Register 2 |
| :---: |
| (2N Bits) |



* $A_{s}$ and $B_{s}$ are sign bits

Multiplication Algorithm

1. Clear ALU to Zero
2. Store $A_{s} \oplus B_{s}$ in External Flip-Flop.
3. If $A_{s}=1$, Complement Register 1.
4. If $\mathrm{B}_{\mathrm{s}}=1$, Complement Register 2.
5. Load Register 2 into ALU.
6. Do Shift Left on ALU N Times ( $N=$ number of bits).
7. Do $N$ Times:
(1)
a) If MSB of $\mathrm{ALU}=1$
(Negative Indicator = High),
Then shift ALU left 1 bit;
add Register 1 to ALU.
b) If MSB of $\mathrm{ALU}=0$
(Negative Indicator = Low),
Then shift ALU left 1 bit.
8. If $A_{s} \oplus B_{s}=1$, then Complement $A L U$.
9. Answer in ALU.

Division Algorithm

| CD4057A |
| :---: |
| ALU 1 |
| (N Bits) |


$\frac{A_{5} a_{1} \ldots a_{N-1} \quad a_{N} \cdots a_{2 N-1}}{\text { Dividend }}$

$$
\frac{\mathrm{B}_{\mathrm{s}} \mathrm{~b}_{1} \ldots \mathrm{~b}_{\mathrm{N}-1}}{\text { Divisor }^{1}}
$$

1. Store $A_{s} \oplus B_{s}$ in External Flip-Flop.
2. If $A_{s}=1$, complement ALU 1 and ALU 2.
3. If $B_{s}=1$, complement Register $A$.
4. Check for Divisor $=0$
a) If Divisor $=0$; stop, indicates division by 0 .
b) If Divisor $\neq 0$; continue.
5. Apply SUB instruction to ALU 1 and Register A to ALU 1 data lines.
a) If $\mathrm{C}_{\mathrm{o}}=0$ (Dividend $<$ Divisor), Stop, indicates overflow.
b) If $C_{0}=1$ (Dividend $\geq$ Divisor). Continue.
6. Put a zero on RT. data line of ALU 2 and shift ALU 1 \& ALU 2 left 1 bit.
7. Do "N" times.

Apply SUB instruction to ALU 1 and Register $A$ to ALU 1 data lines.
a) if $C_{o}^{-}=1$, then clock $A L U: 1$, and put a 1 on right data line of ALU 2.
b) If $\mathrm{C}_{\mathrm{O}}=0$, then no clock, and put a 0 on right data line of ALU 2.
8. If sign Flip Flop $=1$, complement ALU 2.
9. Answer in ALU 2.

## CONDITIONAL OPERATION

Inhibition of the clock pulse can be accomplished with a programmed NO-OP instruction or through conditional input terminals A, B, and C. In a system of many CD4057A's, each CD4057A can be made to automatically control its own operation or the operation of any other CD4057A in the system in conjunction with the Overflow, Zero, or Negative (Number) indicators. Table II, the conditional-inputs truth table, defines the interactions among $A, B$, and $C$.

TABLE $\|$ - CONDITIONAL-INPUTS TRUTH TABLE

| $A$ | $B$ | $C$ | OPERATION <br> PERMITTED |
| :---: | :---: | :---: | :---: |
| 0 | $X$ | $X$ | Yes |
| 1 | 0 | 0 | Yes |
| 1 | 0 | 1 | No |
| 1 | 1 | 0 | No |
| 1 | 1 | 1 | Yes |

$X=$ don't care

Two examples of how the conditional operation can be used are as follows:

1) For the Multiplication Algorithm
$A=1$, for step 7 (1)
$A=0$, for step 7 (2)
$B=1$
$C=$ negative Indicator
2) For the Division Algorithm
$A=1$, for $\operatorname{step} 7$ (1)
$A=0$, for step 7 (2)
$B=1$
$C=C_{0}$ (left data line)

## OVERFLOW DETECTION

The CD4057A is capable of detecting and indicating the presence or absence of an arithmetic two's-complement overflow. A two's-complement overflow is defined as having occurred if the signs of the two initial words are the same and the sign of the result is different while performing a carry-generating instruction.
0.011

For example: $\quad(+) \frac{0.110}{1.001}$
Overflows can be detected and indicated only during operation in Mode 2 or Mode 3 and can occur for only four instructions (AD, SMZ, SM, and SUB). If an overflow is detected and stored in the overflow flip-flop, any one of the five instructions AD, SMZ, SM, SUB, or IN can change the overflow indicator.
When any of the three subtraction instructions is used, the sign bit of the data being subtracted is complemented and this value is used as one of the two initial signs to detect overflows. If an overflow has occurred, the final sign of the sum or difference is one's complemented and stored in the most-significant-bit position of the register.
The overflow flip-flop is updated at the same time the new result is stored in the CD4057A. Whenever data on the parallel-data lines are loaded into the CD4057A, whatever is on the Overflow $1 / 0$ line is loaded into the overflow flip-flop. Also, whenever data are dumped on the parallel data lines from the CD4057A, the contents of the overflow flip-flop are dumped on the Overflow $1 / 0$ line. Thus overflows may be stored elsewhere and then fed into the CD4057A at another time.

OPERATIONAL SEQUENCE AND WAVEFORMS FOR PROPAGATION-DELAY MEASUREMENTS

1. DATA IN-to-CARRY OUT and DATA IN-to-SUM OUT
A. Apply Word A and IN instruction
B. Apply Clock to load word A into register
C. Apply AD instruction
D. Apply Word B (data in)
E. Apply Clock to load result (sum out)
F. Apply DATA OUT CONTROL to look at result

(2) carar out
(3) sum out
(1) - (2) DATA IN TO CARRY OUT
(1) $\rightarrow$ (3) DATA IN TO SUM OUT

* SOLID LINE REPRESENTS INPUT FROM EXTERIOR SOURCE WHEN
DATA OUT" IS LOW. DASHED LINES "DATA OUT" IS LOW. DASHED LINES REPRESENT OUTPUT WHEN "DATA OUT" IS HIGH 92CS-21878

2. CARRY IN-to-CARRY OUT and CARRY IN-to-SUM OUT
A. Apply Word A and IN instruction
B. Apply Clock to load word A into register
C. Apply AD instruction
D. Apply Word B
E. Apply CARRY IN (carry in)
F. Apply Clock to load result (sum out)
G. Apply DATA OUT CONTROL to look at result

(1) CARRY In
(2) carry out
(3) sum out
(1) - (2) Caray in to carry out (1) $\rightarrow$ (3)carat in to sum out

* SOLID Line represents input FROM EXTERIOR SOURCE WHEN DATA OUT" IS LOW. DASHED LINES REPRESENT OUTPUT WHEN "DATA
OUT" IS HGH OUT" is HIGH

92C5-21879
Fig. 10(b) - CARRY IN-to-CARRY OUT and CARRY IN-to-SUM OUT.


Fig. 12 - Transition time vs. load capacitance for Data Outputs (D1-D4).


Fig. 13 - Clock Pulse Rise and Fall Times.


Fig. 15 - Data hold time.


## TYPICAL APPLICATION

The CD4057A has been designed for use as a parallel processor in flexible, programmable, easily expandable, special or general purpose computers, where minimization of exter-
nal connections and data busing are primary design goals. The block diagram of Fig. 18 is an example of a computer that processes 8 bits in parallel.


Fig. 18 - Example of Computer Organization Using CD4057A.

| Preliminary Data ${ }^{\mathbf{A}}$ |
| :---: |
| TERMINAL DIAGRAM |

## COS/MOS Programmable Divide-by-"N" Counter

Features:

- Synchronous programmable $\div \mathbf{N}$ counter:

$$
N=3 \text { to } 9999 \text { or } 15,999
$$

- 4 BCD decades of counting on one chip
- Low power consumption: $\mathbf{3 0} \mu \mathrm{W}$ (typ.) at $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$
- Presettable down counters
- Fully static operation
- Mode select control of initial decade
counting function $(\div 10,8,5,4,2)$
- $T^{2} L$ drive capability
- Master preset initialization
- Latchable $\div \mathbf{N}$ output RCA Preliminary CD4059AD ${ }^{\circ}$ is a divide-by- $N$ down counter that can be programmed to divide an input frequency by any number " $N$ " from 3 to 15,999 . The output signal is a pulse one-clock-pulse wide occurring at a rate equal to the input frequency divided by N . This single output has TTL drive capability. The down counter is preset by means of 16 jam inputs.


## Applications:

- Communication set frequency synthesizers VHF, UHF, FM, AM, etc.
- Fixed or programmable frequency division
- "Time out" timer for consumer application industrial controls


Fig. 1-Functional block diagram.
92CM-22213

The three mode select inputs $\mathrm{Ka}, \mathrm{Kb}$, and Kc determine the modulus ("divide-by" number) of the first and last counting sections in accordance with the truth table shown in Table I. Every time the first (fastest) counting section goes through one cycle it reduces by 1 the number that has been preset (jammed) into the three decades of the intermediate counting section and into the last counting section, which consists of flip-flops that are not needed for operating the first counting section. For example, in the $\div 2$ mode only one flip-flop is needed in the first counting section. Therefore the last counting section has three flip-flops that can be preset to a maximum count of seven with a place value of thousands. If $\div 10$ is desired for the first section, set $K a=1, K b=1$, and $K c=0$; jam inputs J 1 , J 2 , J 3 , and J 4 are used to preset the first counting section and there is no last counting section. The intermediate counting section consists of three cascaded BCD decade $(\div 10)$ counters presettable by means of jam inputs J5 through J16.
The mode select inputs permit frequency synthesizer channel separations of 10, 12.5, 20, 25, or 50 parts. In addition, these inputs set the maximum value of $N$ at 9999 (when the first counting section divides by 5 or 10 ) or 15,999 (when the first counting section divides by 8,4 , or 2 ).

The three decades of the intermediate counting section can be preset to a binary 15 instead of a binary 9 , while their place values are still $1,10,100$, multiplied by the number of the $\div \mathrm{N}$ mode. For example, in the $\div 8$ mode, the number from which counting down begins can be preset to:

| 3rd decade: | 1500 |
| :---: | ---: |
| 2nd decade: | 150 |
| 1st decade: | 15 |
| Last counting section | 1000 |

$2665 \times 8=21,320$
plus the first counting section can be preset to 7
Therefore 21,327 is the
maximum possible count in the $\div 8$ mode.
The highest count of the various modes is shown in the column entitled: "extended" counter range, max., of Table I.

Control inputs Kb and Kc can be used to initiate and lock the counter in the "master preset" state. In this condition the flip-flops in the counter are preset in accordance with the jam inputs and the counter remains in that state as long as Kb and Kc both remain low. The counter begins to count down from the preset state when a counting mode other than the master preset mode is selected. Whenever the master preset mode is used, control signals $\mathrm{Kb}=0$ and $\mathrm{Kc}=0$ must be applied for at least 3 full clock pulses. A " 1 " on the latch input will cause the counter output to remain "high" until the latch input returns to " 0 ". If the latch input is " 0 " the output pulse will remain high for only $\mathbf{1}$ cycle of the clock-input signal.
After the master preset mode inputs have been changed to one of the $\div$ modes, the next positive-going clock transition changes an internal flip-flop so that the countdown begins at the second positive-going clock transition. Thus, after an MP mode, there is always one extra count before the output goes high. See illustration below for total count of 3 . $\div 8$ mode)


As illustrated in the sample applications, this device is particularly advantageous in communication digital frequency synthesis (VHF, UHF, FM, AM, etc.) where programmable divide-by-" N " counters are an integral part of the synthesizer phase-locked-loop subsystem. Note that the Preliminary CD4059A can also be used to perform the synthesizer "Fixed Divide by $R^{\prime \prime}$ counting function. For additional information, see RCA-ICAN-6716 "Low Power Digital Frequency Synthesizers Utilizing COS/MOS IC's." The Preliminary CD4059A can also be used in general-purpose counters for instrumentation functions such as totalizers, production counters, and "time out" timers.
The Preliminary CD4059A is available in 24-lead ceramic dual-in-line packages.

TABLE I

| MODE | MODE SELECT INPUT |  |  | FIRST COUNTING SECTION |  |  |  | LAST COUNTING SECTION |  | DESIGN COUNTER RANGE |  | EXTENDED COUNTER RANGE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| First counting section divides by: | Ka | Kb | Kc | Di- <br> vides <br> by: | Can be <br> preset <br> to a <br> maximum <br> of: | Jam <br> inputs <br> used: | Di- <br> vides <br> by: | Can be <br> preset <br> to a <br> maximum of: | Jam <br> inputs <br> used: | Min. | Max. | Max. |
| 2 | 1 | 1 | 1 | 2 | 1 | J1 | 8 | 7 | J2,J3,J4 | 3 | 15,999 | 17,331 |
| 4 | 0 | 1 | 1 | 4 | 3 | J1,J2 | 4 | 3 | J3, J4 | 3 | 15,999 | 18,663 |
| 5 | 1 | 0 | 1 | 5 | 4 | J1,J2,J3 | 2 | 1 | J4 | 3 | 9,999 | 13,329 |
| 8 | 0 | 0 | 1 | 8 | 7 | J1, J2, J3 | 2 | 1 | J4 | 3 | 15,999 | 21,327 |
| 10 | 1 | 1 | 0 | 10 | 9 | J1,J2, J3, J4 | 1 | 0 | - | 3 | 9,999 | 16,659 |
| Master Preset (MP) | X | 0 | 0 |  | MP |  |  | MP |  | - | - | - |

X = Don't Care

MAXIMUM RATINGS, Absolute-Maximum Values:


STATIC ELECTRICAL CHARACTERISTICS AT TA $=\mathbf{2 5}^{\circ} \mathrm{C}$
Typical Temperature Coefficient at all values of $V_{D D}=-0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{VO}_{0} \\ \text { Volts } \end{gathered}$ | VDD Volts | Min. | Typ. | Max. |  |
| Quiescent Device Current | ${ }_{1} \mathrm{~L}$ |  | 5 | - | 1 | - | $\mu \mathrm{A}$ |
|  |  |  | 10 | - | 3 | - |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | 5 | - | $\mu \mathrm{W}$ |
|  |  |  | 10 | - | 30 | - |  |
| Output Drive Current : n-Channel (Sink) | $I_{\text {d }}$ | 0.4 | 4.5 | 1.3 | 2.6 | - | mA |
|  |  | 0.5 | 10 | - | 12 | - |  |
| p-Channel (Source) | $I_{D} P$ | 4.1 | 4.5 | - | -0.4 | - | mA |
|  |  | 9.5 | 10 | - | -1.5 | - |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT TA $=25^{\circ} \mathrm{C}$ and $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$
Typical Temperature Coefficient for all values of $V_{D D}=0.3 \% /{ }^{\circ} \mathrm{C}$

| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | LIMITS |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { VDD } \\ & \text { Volts } \end{aligned}$ | Min. | Typ. | Max. |  |
| Propagation Delay Time | tPHL, tPLH | 5 | - | 280 | - | ns |
|  |  | 10 | - | 140 | - |  |
| Transition Time | tTHL | 5 | - | 35 | - | ns |
|  |  | 10 | - | 25 | - |  |
|  | tTLH | 5 | - | 90 | - |  |
|  |  | 10 | - | 50 | - |  |
| Clock Rise or Fall Time | $\begin{aligned} & \mathrm{t}_{\mathbf{r}} \mathrm{CL}, \\ & \mathrm{t}_{\mathrm{f}} \mathrm{CL} \end{aligned}$ | 5 | - | - | 15 | $\mu \mathrm{s}$ |
|  |  | 10 | - | - | 5 |  |
| Maximum Clock Frequency: <br> All $\div$ Modes | ${ }^{\text {f CL }}$ | 5 | - | 2.5 | - | MHz |
|  |  | 10 | - | 5 | - |  |
| Input Capacitance | $C_{1}$ | Any input | - | 5 | - | pF |

## "HOW TO PRESET PRELIMINARY CD4059AD TO DESIRED $\div N "$

The value N is determined as follows:
$N=\left[M O D E^{*}\right] \quad[1000 \times$ Decade 5 Preset $+100 \times$ Decade 4
Preset + 10X Decade 3 Preset + 1X Decade 2 Preset ] + Decade 1
Preset

* MODE $=$ First counting section divider (10, 8, 5, 4 or 2)

To calculate preset values for any N count, divide the N count by the Mode.
The resultant is the corresponding preset values of the 5th through 2nd decade with the remainder being equal to the 1st decade value.

$$
\begin{equation*}
\text { Preset Value }=\frac{\mathrm{N}}{\text { Mode }} \tag{2}
\end{equation*}
$$

Examples:


MODE SELECT $=5$
PROGRAM JAM INPUTS (BCD)

B) $\mathrm{N}=12382, \mathrm{Mode}=8$
$8 \longdiv { 1 5 4 7 + 6 }$
MODE SELECT $=8$
PROGRAM JAM INPUTS

|  |  |  |  | 6 |  | 1 |  |  | 7 |  |  |  | 4 |  |  | 5 |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Ka | Kb | Kc | J1 | J2 | J3 | J4 | J5 | J6 | J7 | J8 | J9 | J10 | J11 | J12 | $J 13$ | J14 | J15 | J16 |
| 0 | 0 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 1 | 0 |
| To verify: |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| $N=8(1000 \times 1+100 \times 5+10 \times 4+1 \times 7)+6$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| $N=12382$ |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |

C) $\mathrm{N}=8479$, Mode $=10$

$$
\begin{gathered}
0847+9 \\
1 0 \longdiv { 8 4 7 9 }
\end{gathered}
$$

MODE SELECT $=10$
PROGRAM JAM INPUTS


## APPLICATIONS

1) DIGITAL PLL FOR FM BAND SYNTHESIZER


Calculating Min \& Max " N " Values:

Output Freq. Range ( $\mathrm{f}_{\mathrm{o}}$ ) $=98.8$ to 118.6 MHz
Channel Spacing Freq. $\left(\mathrm{f}_{\mathrm{c}}\right)=200 \mathrm{kHz}$
Division Factor (k) $=40$

Reference Freq. (fr) $=\frac{\mathrm{f}_{\mathrm{c}}}{\mathrm{k}}=\frac{200}{40} \mathrm{kHz}=5 \mathrm{kHz}$

$$
\begin{aligned}
& f_{k}=\frac{f_{o}}{40}: f_{k} M a x .=\frac{118.6 \mathrm{MHz}}{40}=2.965 \mathrm{MHz} ; f_{k} \operatorname{Min}=\frac{98.8 \mathrm{MHz}}{40}=2.47 \mathrm{MHz} \\
& \therefore N=\frac{f_{0}}{f_{\mathrm{C}}} \\
& N_{\operatorname{Max}}=\frac{118.6 \mathrm{MHz}}{200 \mathrm{kHz}}=593 \quad N_{\operatorname{Min}}=\frac{98.8 \mathrm{MHz}}{200 \mathrm{kHz}}=494 \quad R=\frac{2.56 \mathrm{MHz}}{5 \mathrm{kHz}}=512
\end{aligned}
$$

2) $\div \mathrm{N}$ Counter Configuration for UHF - 220 to 400 MHz

Channel Spacing: 50 kHz or 25 kHz

3) $\div \mathrm{N}$ Counter Configuration for VHF - 116 to 160 MHz

Channel Spacing $=12.5 \mathrm{kHz}$


Preliminary CD4059AD $\qquad$
4) $\div$ N Counter Configuration for VHF - $\mathbf{3 0}$ to 80 MHz

Channel Spacing: $\mathbf{2 5}$ kHz


$$
N_{\text {Max }}=\frac{80 \mathrm{MHz}}{25 \mathrm{kHz}}=3,200 \quad \mathrm{~N}_{\mathrm{Min}}=\frac{30 \mathrm{MHz}}{25 \mathrm{kHz}}=1200
$$

5) $\div \mathrm{N}$ Counter Configuration for AM - 995 to 2055 kHz

Channel Spacing $=10 \mathrm{kHz}$


$$
N_{\text {Max }}=\frac{2055 \mathrm{kHz}}{10 \mathrm{kHz}}=205 \quad \mathrm{~N}_{\mathrm{Min}}=\frac{995 \mathrm{kHz}}{10 \mathrm{kHz}}=99
$$



## COS/MOS 14-Stage Ripple-Carry Binary Counter/Divider and Oscillator

## Features:

- 4- MHz operating frequency (typ.) at $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}$
- Common reset
- Fully static operation
- 10 buffered outputs available

The RCA-CD4060A consists of an oscillator section and 14 ripple-carry binary counter stages. The oscillator configuration allows design of either RC or crystal oscillator circuits. A RESET input is provided which resets the counter to the all-0's state and disables the oscillator. A high level on the RESET line accomplishes the reset function. All counter stages are master-slave flip-flops. The state of the counter is advanced one step in binary order on the negative transition of $\phi_{\mathrm{I}}\left(\phi_{\mathrm{O}}\right)$. All inputs and outputs are fully buffered.

The CD4060A is supplied in 16 -lead dual-in-line welded-seal ceramic packages (D), plastic packages (E), ceramic packages (F), flat packs (K), and in chip form (H).

MAXIMUM RATINGS, Absolute-Maximum Values:

| ORAGE-TEMPERATURE RANGE. . . . . . . . . . . -65 to $+150^{\circ}$ |  |
| :---: | :---: |
|  |  |
| CERAMIC-PACKAGE TYPES | -55 to +1 |
| PLASTIC-PACKAGE TYPES | 40 to $+85{ }^{\circ}$ |
| DC SUPPLY-VOLTAGE RANGE: |  |
|  |  |
|  |  |
| UTS |  |
| LEAD TEMPERATURE (DURING SOLDERING): <br> At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) <br> from case for 10 seconds max. . . . . . . . . . . . . . . . . $265^{\circ} \mathrm{C}$ |  |
| RECOMMENDED OPERATING CONDITIONS: |  |
| DC Supply-Voltage Range |  |
|  |  |
| nput Voltage Swi |  |

## Oscillator Features:

- All active components on chip
- RC or crystal oscillator configuration

Applications:

- Timers
- Frequency dividers


Fig. 1-Logic diagram of CD4060A oscillator, pulse shaper, and 1 of 14 counter stages.


Fig. 2-Schematic diagram of input pulse shapers, reset buffers, and 1 of 14 binary counter stages of the CD4060A.

STATIC ELECTRICAL CHARACTERISTICS (All inputs
$\left.\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{1} \leqslant \mathrm{~V}_{\mathrm{DD}}\right)$
(Recommended DC Supply Voltage ( $\mathrm{VDD}_{\mathrm{DD}} \mathrm{V}_{\mathrm{SS}}$ ).

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | CD4060AD CD4060AFCD4060AK CD4060AHCERAMIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} v_{\mathbf{O}} \\ \mathbf{v}^{2} \end{gathered}$ |  | VDD V | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device | $I_{L}$ |  |  |  | 5 | - | - | 15 | - | 0.5 | 15 | - | - | 900 | $\mu \mathrm{A}$ | 16 |
| Current |  |  |  | 10 | - | - | 25 | - | 1 | 25 | - | - | 1500 |  |  |  |
| Quiescent Device | $P_{\text {D }}$ |  |  | 5 | - | - | 75 | - | 2.5 | 75 | - | - | 4500 | $\mu \mathrm{W}$ | - |  |
| Dissipation/Package |  |  |  | 10 | - | - | 250 | - | 10 | 250 | - | - | 15000 |  |  |  |
| Output Voltage: | $\mathrm{V}_{\mathrm{OL}}$ | Fan |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |  |
| Low-Level |  | $\begin{aligned} & \text { Out } \\ & =50 \end{aligned}$ |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ | Fan |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |  |
|  |  | $\begin{aligned} & \text { Out } \\ & =50 \\ & \hline \end{aligned}$ |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |  |
| Noise Immunity <br> (Any Input) | $V_{N L}$ |  | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 17,18 |  |
|  |  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |  |
|  |  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |  |
| Output Drive Current N-Channel (Sink) | $I_{D} N$ |  | 0.5 | 5 | 0.22 | - | - | 0.18 | 0.36 | - | 0.125 | - | - | mA | 3,4 |  |
|  |  |  | 0.5 | 10 | 0.44 | - | - | 0.36 | 0.75 | - | 0.25 | - | - |  |  |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ |  | 4.5 | 5 | -0.15 | - | - | $-\mathrm{J} .125$ | -0.25 | - | -0.085 | - | - | $m A$ | 5,6 |  |
|  |  |  | 9.5 | 10 | -0.3 | - | - | -0.25 | -0.5 | - | -0.175 | - | - |  |  |  |
| Input Current | 11 | Any Input |  |  | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |  |

${ }^{4}$ Data does not apply to terminals 9 or 10.


Fig. 3-Typical n-channel drain characteristics.


Fig. 4-Minimum n-channel drain characteristics.

STATIC ELECTRICAL CHARACTERISTICS (All inputs.
$\mathbf{V}_{S S} \leqslant V_{1} \leqslant V_{D D}$
(Recommended DC Supply Voltage $\left(V_{D D}{ }^{-V_{S S}}\right.$ ) .... . 3 to 15 V )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | $\begin{gathered} \text { CD4060AE } \\ \text { PLASTIC PACKAGE LIMITS } \end{gathered}$ |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} v_{0} \\ v \end{gathered}$ |  | $V_{D D}$ <br> V | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{1}$ |  |  |  | 5 | - | - | 50 | - | 1 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 16 |
|  |  |  |  | 10 | - | - | 100 | - | 2 | 100 | - | - | 1400 |  |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  |  | 5 | - | - | 250 | - | 5 | 250 | - | - | 3500 | $\mu \mathrm{W}$ | - |  |
|  |  |  |  | 10 | - | - | 1000 | - | 20 | 1000 | - | - | 14000 |  |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ | $\begin{gathered} \text { Fan } \\ \text { Out } \\ =50 \\ \hline \end{gathered}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |  |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ | Fan <br> Out $=50$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |  |
| Noise Immunity <br> (Any Input) | $\mathrm{V}_{\mathrm{NL}}$ | - | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 17,18 |  |
|  |  |  | 1 | 10. | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |  |
|  |  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |  |
| Output Drive Current:N-Channel (Sink) | ${ }^{1}{ }^{N}$ |  | 0.5 | 5 | 0.21 | - | - | 0.18 | 0.36 | - | 0.15 | - | - | mA | 3,4 |  |
|  |  |  | 0.5 | 10 | 0.42 | - | - | 0.36 | 0.75 | - | 0.3 | - | - |  |  |  |
| P-Channel (Source) | $I^{p}$ |  | 4.5 | 5 | -0.145 | - | - | -0.125 | -0.25 | - | -0.1 | - | - | $m A$ | 5,6 |  |
|  |  |  | 9.5 | 10 | -0.29 | - | - | -0.25 | -0.5 | - | -0.2 | - | - |  |  |  |
| Input Current | 11 | Any Input |  |  | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$. | - | - | - | $\mu \mathrm{A}$ | - |  |

© Data does not apply to terminals 9 or 10.


92Cs-21511


92CS-21513
Fig. 6-Minimum p-channel drain characteristics.

File No. 813

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ (unless otherwise specified), Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | CERAMIC TYPES |  |  | PLASTIC TYPES |  |  | UNITS | FIG <br> NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | VDD | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |  |  |


| Input-Pulse Operation |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Propagation Delay Time $\phi_{\mathrm{I}}$ to $\mathrm{Q4}$ Out | ${ }^{\text {tPHL}}$, |  | 5 | - | 900 | 1800 | - | 900 | 1900 | ns | 7 |
|  | ${ }^{\text {t PLH }}$ |  | 10 | - | 450 | 900 | - | 450 | 950 |  |  |
| Propagation Delay Time, $\mathrm{Q}_{\mathrm{n}}$ to $\mathrm{O}_{\mathrm{n}+1}$ | ${ }^{\text {tPHL }}$, |  | 5 | - | 450 | 900 | - | 450 | 950 | ns | 8 |
|  | ${ }^{\text {P PLH }}$ |  | 10 | - | 225 | 450 | - | 225 | 475 |  |  |
| Transition Time | ${ }^{\mathrm{t}} \mathrm{THL}$. <br> ${ }^{t}$ TLH |  | 5 | - | 150 | 300 | - | 150 | 350 | ns | 9 |
|  |  |  | 10 | - | 75 | 150 | - | 75 | 175 |  |  |
| Min. Input-Pulse Width | ${ }^{\text {t WL }}$. | $\mathrm{f}=100 \mathrm{kHz}$ | 5 | - | 200 | 400 | - | 200 | 500 | ns | - |
|  | ${ }^{\text {twh }}$ |  | 10 | - | 75 | 110 | - | 75 | 125 |  |  |
| Input-Pulse <br> Rise \& Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{r} \phi} \\ & \mathrm{t}_{\mathrm{f} \phi} \end{aligned}$ |  | 5 | - | - | 15 | - | - | 15 | $\mu \mathrm{s}$ | - |
|  |  |  | 10 | - | - | 7.5 | - | - | 7.5 |  |  |
| $\begin{gathered} \text { Max. Input-Pulse } \\ \text { Frequency } \end{gathered}$ | ${ }^{\text {f }}$ ${ }^{\prime}$ |  | 5 | 1 | 1.75 | - | 0.9 | 1.75 | - | MHz | 10 |
|  |  |  | 10 | 3 | 4 | - | 2.75 | 4 | - |  |  |
| Input Capacitance | $1 /$ |  |  | - | 5 | - | - | 5 | - | pF | - |
| Reset Operation |  |  |  |  |  |  |  |  |  |  |  |
| Propagation Delay Time | ${ }^{\text {t PHL }}$ |  | 5 | - | 500 | 1000 | - | 500 | 1250 | ns | - |
|  |  |  | 10 | - | 250 | 500 | - | 250 | 600 |  |  |
| Minimum ResetPulse Width | ${ }^{\text {t }}$ WH |  | 5 | - | 500 | 1000 | - | 500 | 1250 | ns | - |
|  |  |  | 10 | - | 250 | 500 | - | 250 | 600 |  |  |



Fig. 7-Typical propagation delay time vs. load capacitance ( $\phi_{\mathrm{I}}$ to 04 output).


Fig. 8-Typical propagation delay time vs.
load capacitance $\left(Q_{n}\right.$ to $\left.Q_{n+1}\right)$.


Fig. 9-Typical output transition time vs. load capacitance.


Fig. 11-Typical dynamic power dissipation characteristics.


Fig. 13-Propagation delay and transition time test circuit-input-pulse operation.


Fig. 10-Typical maximum-input-pulse frequency vs. supply voltage.

tomanaranarandar


Fig. 12-Propagation delay time test circuit-input-pulse operation.


92CS-24559
Fig. 14-Test circuit for propagation delay time between reset pulse and any output.


Fig. 16-Quiescent device current test circuit.


Fig. 18-Reset-pulse noise immunity test circuit.



Fig. 17-Input-pulse noise immunity test circuit.


Fig. 20-Input pulse-shaping circuit (Schmitt-Trigger) for CD4060A.

TYPICAL COMPONENT VALUES AND CIRCUIT PERFORMANCE*

| OSCILLATOR FREQUENCY | $\begin{aligned} & \text { RS } \\ & \text { K } \Omega \end{aligned}$ | $\begin{aligned} & \mathbf{R}_{\mathbf{T}} \\ & \mathrm{K} \Omega \end{aligned}$ | $\mathrm{C}_{\text {T }}$ | ${ }^{\prime} \mathrm{DD}^{\mathrm{mA}}$ © $v_{D D}=10 \mathrm{~V}$ |
| :---: | :---: | :---: | :---: | :---: |
| 10 Hz | 450 | 45 | $1 \mu \mathrm{~F}$ | 0.3 |
| 100 Hz | 450 | 45 | $0.1 \mu \mathrm{~F}$ | 0.3 |
| 1000 Hz | 450 | 45 | $0.01 \mu \mathrm{~F}$ | 0.4 |
| 10 KHz | 450 | 45 | $0.001 \mu \mathrm{~F}$ | 0.5 |
| 100 KHz | 450 | 45 | 100 pF | 0.7 |
| 1 MHz | 45 | 4.5 | 100 pF | 1 |

- See Application Note ICAN-6267 Astable and Monostable Oscillator Using RCA COS/MOS Digital Integrated Circuits.

Fig. 19-Typical RC oscillator circuit.


Fig. 21-Input circuit characteristics for circuit in Fig. 20.


Fig. 22-Typical crystal oscillator circuit.


# COS／MOS 256－Word by 1－Bit Static Random－Access Memory 

## Features：

－Low standby power： 10 Nanowatts／bit（typ．）＠$V_{D D}=10 \mathrm{~V}$
m Access time： $\mathbf{3 8 0} \mathrm{ns}$（max．）＠$V_{D D}=10 \mathrm{~V}$ ．Noise immunity： $\mathbf{4 5 \%}$ of $\mathrm{V}_{\mathrm{DD}}$（typ．）
－Single 3－to－15 V power supply $\quad$ Fully decoded addressing
－COS／MOS input／output logic compatibility－Single write／read control line
－TTL output drive capability
－Three－state data outputs for bus－oriented systems
－1101－type pin designations＊
－Separate data output and data input lines

RCA－CD4061A is a single monolithic integrated circuit con－ taining a 256 －word by 1 －bit fully static，random－access，NDRO memory．The memory is fully decoded and requires 8 address input lines $\left(A_{0}-A_{7}\right)$ to select one of 256 storage locations． Additional connections are provided for a WRITE／READ command CHIP ENABLE，DATA IN，and DATA OUT and $\overline{\text { DATA OUT lines．}}$

To perform READ and WRITE operations the CHIP－ENABLE signal must be low．When the CHIP－ENABLE signal is high， read and write operations are inhibited and the output is a high impedance．To change addresses，the CHIP－ENABLE signal must be returned to a high level，regardless of the logic level of the WRITE／READ input．In a multiple package application，the CHIP－ENABLE signal may be used to permit the selection of individual packages．
Output－voltage levels appear on the outputs only when the CHIP－ENABLE and WRITE／READ signals are both low． Separate data inputs and outputs are provided；they may be tied together，or，to eliminate interaction between READ and WRITE functions，may be used separately．The circuit ar－ rangement permits the outputs from many arrays to be tied to a common bus．

All input and output lines are buffered．The CD4061A output buffers are capable of direct interfacing with TTL devices．
The CD4061A is available in a hermetically sealed 16－lead dual－in－line ceramic package（CD4061AD）or in chip form （CD4061AH）．

## MAXIMUM RATINGS，Absolute－Maximum Values：

STORAGE－TEMPERATURE RANGE ．．．．．．．．．．． $\mathbf{- 6 5}$ to $+150{ }^{\circ} \mathrm{C}$ OPERATING－TEMPERATURE RANGE ．．．．．．．．．-55 to $+125{ }^{\circ} \mathrm{C}$ DC SUPPLY－VOLTAGE RANGE
$\mathrm{V}_{\text {DD }}-\mathrm{V}_{\text {SS }}$ ）．．．．．．．．．．．．．．．．．．．．．．．．．．．．．-0.5 to +15 V DEVICE DISSIPATION（PER PKG．）．．．．．．．．．．．．．．．．．． 200 mW ALL INPUTS ．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．$V_{S S} \leqslant V_{1} \leqslant V_{D D}$
RECOMMENDED DC SUPPLY VOLTAGE

$$
\left(V_{D D}-V_{S S}\right) \ldots \ldots \ldots \ldots \ldots \ldots \ldots \ldots \ldots \ldots \ldots . .
$$

LEAD TEMPERATURE（DURING SOLDERING）
At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$
from case for 10 seconds max．
$265{ }^{\circ} \mathrm{C}$

[^14]

FOR SINGLE $n$ AND p dEVICES $\left\{\begin{array}{l}\text { ALL } p \text {-SUBSTRATES TIED TO } V_{D D} . \\ \text { ALL } n \text {-SUBSTRATES TIED TO } V_{S S} .\end{array}\right.$
92CL-23852

Fig. 1 - CD4061A logic diagram.

CD4061A OPERATIONAL MODES

| OPERATION | ADDRESS LINES | CHIP-ENABLE | WRITE/READ | DATA IN | DATA OUTPUTS |
| :--- | :---: | :---: | :---: | :---: | :--- |
| Write."0" | Stable | 0 | 1 | 0 | High-Impedance |
| Write "1" | Stable | 0 | 1 | 1 | High-Impedance |
| Read | Stable | 0 | 0 | X | Valid 1 or 0 |
| *Read/Write | Stable | 0 | $0 / 1$ | X | Valid 1 or 0/High- |
|  |  |  | X | X | Impedance <br> High-Impedance |

## X = Don't Care

* For a READNWRITE operation on the same address, chip-enable may be held to a logic 0 for both successive operations.

STATIC ELECTRICAL CHARACTERISTICS
(All inputs
$\mathbf{V}_{\mathbf{S S}} \leqslant \mathbf{V}_{\mathbf{1}} \leqslant \mathbf{V}_{\mathbf{D D}} \mathbf{\prime}$
(Recommended DC Supply Voltage ( $\mathbf{V D D}_{\mathbf{D D}}-\mathbf{V}_{\mathbf{S S}}$ )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  |  |  |  | UNITS | CHARAC. TERISTIC CURVES \& TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $v_{0}$Volts | $V_{D D}$ <br> Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device | 'L |  | 5 | - | - | 5 | - | 0.12 | 5 | - | - | 150 | $\mu \mathrm{A}$ | 14 |
| Current |  |  | 10 | - | - | 10 | - | 0.25 | 10 | - | - | 300 |  |  |
| Quiescent Device Dissipation/Package | $P_{\text {D }}$ |  | 5 | - | - | - | - | 0.6 | 25 | - | - | 750 | $\mu \mathrm{W}$ | - |
|  |  |  | 10 | - | - | - | - | 2.5 | 100 | - | - | 3000 |  |  |
| Output Voltage Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | $v$ | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
| High-Level | ${ }^{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  | - |
| Noise Immunity (All Inputs) | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | v | 17 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  | 17 |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
| Output Drive Current: (Data Out, Data Out) N-Channel (Sink) | ${ }_{1}{ }^{N}$ | 0.4 | 4.5 | 2 | - | - | 1.6 | 2.5 | - | 1.1 | - | - | mA | 3, 4, 12 |
|  |  | 0.5 | 10 | 4.3 | - | - | 3.5 | 5 | - | 2.4 | - | - |  |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | 2.5 | 5 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - | mA | 5. 6, 13 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
| Output Off Resistance <br> (High-impedance State) | $\mathrm{Ro}_{0}$ (Off) |  | 5 | 10 | - | - | 10 | - | - | 10 | - | - | $\mathrm{M} \Omega$ | - |
|  |  |  | 10 | 10 | - | - | 10 | - | - | 10 | - | - |  |  |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, and $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$

|  | CHARACTERISTICS | SYMBOLS | TEST CONDITIONS |  | LIMITS |  | UNITS | CHARAC. TERISTIC curves \& TEST |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{array}{\|l} \mathrm{V}_{\mathrm{DD}} \\ \text { (Volts) } \end{array}$ | Min.* | Typ. | Max.* |  | CIRCUITS <br> Fig. No. |
|  | Read Cycle Time | ${ }^{t} \mathrm{RC}$ | 5 | 1200 | 1000 | - | ns | 2 |
|  |  |  | 10 | 550 | 450 | - |  |  |
|  | Chip-Enable Hold Time | ${ }^{\text {t }}$ CEH | 5 | 40 | 0 | - | ns | 2 |
|  |  |  | 10 | 0 | - | - |  |  |
|  | Chip-Enable Pulse Width | ${ }^{t} \mathrm{CE}$ | 5 | 700 | 500 | - | ns | 2 |
|  |  |  | 10 | 350 | 250 | - |  |  |
|  | Chip-Enable Setup Time | ${ }^{\text {t }}$ CES | 5 | 460 | - | - | ns | 2 |
|  |  |  | 10 | 200 | - | - |  |  |
|  | Read Access Time | ${ }^{\text {tra }}$ | 5 | - | 450 | 750 | ns | 2, 9, 10 |
|  |  |  | 10 | - | 250 | 380 |  |  |
|  | Write Cycle Time | ${ }^{\text {t }}$ WC | 5 | 1200 | 1000 | - | ns | 2 |
|  |  |  | 10 | 550 | 450 | - |  |  |
|  | Chip-Enable Hold Time | ${ }^{\text {t }}$ CEH | 5 | 40 | 0 | - |  |  |
|  |  |  | 10 | 0 | - | - |  |  |
|  | Chip-Enable Pulse Width | ${ }^{\text {t }} \mathrm{CE}$ | 5 | 700 | 500 | - |  |  |
|  |  |  | 10 | 350 | 250 | - |  |  |
|  | Chip-Enable Setup Time | ${ }^{\text {t }}$ CES . | 5 | 460 | - | - |  |  |
|  |  |  | 10 | 200 | - | - |  |  |
|  | Write Hold Time | ${ }^{\text {t WH }}$ | 5 | 150 | 100 | - |  |  |
|  |  |  | 10 | 100 | 70 | - |  |  |
|  | Write Pulse Width | ${ }^{t}$ W | 5 | 150 | 100 | - |  |  |
|  |  |  | 10 | 100 | 70 | - |  |  |
|  | Data Setup Time | ${ }^{\text {t }}$ DS | 5 | 140 | 80 | - |  |  |
|  |  |  | $10^{\circ}$ | 80 | 35 | - |  |  |
|  | Data Hold Time | ${ }^{\text {t }} \mathrm{DH}$ | 5 | 25 | 10 | - |  |  |
|  |  |  | 10 | 20 | 10 | - |  |  |
|  | Output Transition Time | ${ }^{\text {t }}$ TLH | 5 | - | 60 | 100 | ns | 7 |
|  |  |  | 10 | - | 50 | 75 |  |  |
|  |  | ${ }^{\text {t }}$ HL | $\begin{array}{r} 5 \\ 10 \end{array}$ | - | $\begin{aligned} & 35 \\ & 25 \end{aligned}$ | $\begin{aligned} & 60 \\ & 40 \end{aligned}$ |  | 8 |
|  | Chip-Enable Input Rise and Fall Time | $\mathrm{t}_{\mathrm{r} C E}$, <br> ${ }^{t_{f C E}}$ | 5 | - | - | 15 | $\mu \mathrm{s}$ |  |
|  |  |  | 10 | - | - | 5 |  |  |
|  |  |  | 15 | - . | - | 1 |  |  |

[^15]

Fig. 2 - Typical write-read waveforms.

## SYMBOL DEFINITIONS

## READ CYCLE

$t_{\text {RC }}$ - READ CYCLE TIME - Time required between address changes during a read cycle. Minimum read cycle time is equal to ${ }^{\text {C }}$ CEH ( $\mathbf{m i n}$.) $+\mathrm{t}_{\mathrm{CE}}$ (min.) $+\mathrm{t}_{\mathrm{CES}}$ (min.). (See Definitions below).
${ }^{\text {t }}$ CEH - CHIP-ENABLE HOLD TIME - Time required before chip-enable level can be lowered after an address transition.
${ }^{\mathbf{t}}$ CE - CHIP-ENABLE PULSE WIDTH - Time required for the chip to be active for valid reading of output data.
${ }^{\text {t }}$ CES - CHIP-ENABLE SETUP TIME - Time required before ar address transition can tak-place after chip-enable level has been increased. ${ }^{\text {C }}$ ES $(\min )+.\mathrm{t}_{\mathrm{CEH}}(\mathrm{min}$.$) is the minimum time$ required to discharge internal nodes and allow settling of address decoders during an address transition. Chip-enable level must be raised during each address change, even if read cycles only or write cycles only are successively performed. However, if address is not changed, chip enable may remain in its active (low) state during successive read and write cycles.
${ }^{\mathbf{t}}$ RA - READ ACCESS TIME - Measured from chip-enable transition; time before output data is valid.

## WRITE CYCLE

twc - WRITE CYCLE TIME - Time required between address changes during a write cycle. This time sets the maximum
operating frequency for the memory, with minimum write cycle time equal to ${ }^{t_{C E H}}(\min )+.\mathrm{t}_{\mathrm{CE}}(\min )+.\mathrm{t}_{\mathrm{CES}}(\mathrm{min}$.$) .$
${ }^{\text {t }}$ CEH - CHIP-ENABLE HOLD TIME - See Definition under read cycle.
${ }^{\text {t }}$ CE - CHIP-ENABLE PULSE WIDTH - See Definition under read cycle.
${ }^{\text {t }}$ CES - CHIP-ENABLE SETUP TIME - See Definition under read read cycle.
tWH - WRITE HOLD TIME - Measured from chip-enable transition; time required before negative transition of write pulse can occur for successful write operation.
tw - WRITE PULSE WIDTH - Time required for W/R pulse to be high. Note that no specification for positive transition of this pulse is made - it may occur before or after the chipenable transition. In many applications, the W/R control is normally low and is strobed high during a write cycle.
${ }^{\text {t}}$ DS - DATA SETUP TIME - Measured from write-pulse negative transition; time required for data input to be valid.
tDH - DATA HOLD TIME - Measured from write-pulse negative transition; time required for data input to be valid after W/R is returned to a low level. The minimum data pulse width is equal to $\mathrm{t}_{\mathrm{DS}}(\mathrm{min})+.\mathrm{t}_{\mathrm{DH}}(\mathrm{min}$.$) .$


Fig. 3 - Typical n-channel drain characteristics.


Fig. 5 - Typical p-channel drain characteristics.


Fig. 7 - Typical low-to-high transition time ( ${ }^{T} T L H^{\prime}$ vs $C_{L}$.


Fig. 4 - Minimum n-channel drain characteristics.

DRAIN-TO-SOURCE VOLTAGE ( $V_{D S}$ )-V


92cs-23857
Fig. 6 - Minimum p-channel drain characteristics.


Fig. 8 - Typical high-to-low transition time ( ${ }^{T}$ THL ) vs $C_{L}$.


Fig. 9 - Typical read access time $\left(t_{R A}\right)$ vs $C_{L}$.


Fig. 11 - Typical power dissipation vs cycle time.


Fig. 10 - Typical read access time ( $\boldsymbol{t}_{\text {RA }}$ ) vs temperature.

## TEST CIRCUITS



Note: At address 0 , " 0 " stored in memory.


Note: At address 0, "1" stored in memory.

Fig. 12 - n-channel drive current. . Fig. 13 -p-channel drive current.

Note:
Power dissipation measured using random data pattern. Input puise delays and widths set to minimum values specified on data sheet with the exception of cycle time, 15 V setups identical to 10 V data sheet values, with the exception of ${ }^{t} C E=400 \mathrm{~ns}$.

Quiescent Device Current Test Conditions

| Test | A | B | Memory Cells |
| :---: | :---: | :---: | :---: |
| 1 | 0 | 0 | All 0 |
| 2 | 1 | 1 | All 0 |
| 3 | 0 | 1 | All 0 |
| 4 | 0 | 0 | All 1 |
| 5 | 1 | 1 | All 1 |
| 6 | 0 | 1 | All 1 |

Fig. 14 - Quiescent device current.


Fig. 15 - Operating life.


Description of Test:
Functional test run with random data input. All inputs toggle betweem $30 \%$ and $70 \%$ of VDD.



## COS/MOS 200-Stage Dynamic Shift Register

## Special Features:

- Operation from a single 3-V to $15-\mathrm{V}$ positive or negative power supply
- Minimum shift rates over full temperature range -

Single phase clock: $3 \mathrm{~V} \leqslant \mathrm{~V}_{\mathrm{DD}} \leqslant 10 \mathrm{~V}$; $\mathrm{f}_{\text {min }}=10 \mathrm{kHz}$;
$-55^{\circ} \mathrm{C} \leqslant \mathrm{T}_{\mathrm{A}} \leqslant+125^{\circ} \mathrm{C}\left(\mathrm{f}_{\min }=1 \mathrm{kHz}\right.$ up to $\mathrm{T}_{\mathrm{A}} \leqslant 75^{\circ} \mathrm{C}$ )
Two-phase clock: $3 \mathrm{~V} \leqslant \mathrm{~V}_{\mathrm{DD}} \leqslant 15 \mathrm{~V}$; $\mathrm{f}_{\min }=10 \mathrm{kHz}$; $-55^{\circ} \mathrm{C} \leqslant \mathrm{T}_{\mathrm{A}} \leqslant+125^{\circ} \mathrm{C}\left(\mathrm{f}_{\min }=1 \mathrm{kHz}\right.$ up to $\left.\mathrm{T}_{\mathrm{A}} \leqslant 75^{\circ} \mathrm{C}\right)$

The RCA-CD4062A is a 200-stage dynamic shift register with provision for either single- or two-phase clock input signals. Single-phase-clocked operation is intended for low-power, low clock-line capacitance requirements. Single-phase clocking is specified for medium-speed operation $(<1 \mathrm{MHz})$ at supply voltages up to 10 volts. Clock input capacitance is extremely low ( $<5 \mathrm{pF}$ ), and clock rise and fall times are non-critical. The clock-mode signal (CM) must be low for single-phase operation.
Two-phase clock-input signals may be used for high-speed operation (up to 5 MHz ) or to further reduce clock rise and fall time requirements at low speeds. Two-phase operation is specified for supply voltages up to 15 volts. Clock input capacitance is only $50 \mathrm{pF} /$ phase. The clock-mode signal (CM) must be high for two-phase operation. The single-phase-clock input has an internal pull-down device which is activated when CM is high and may be left unconnected in two-phase operation.
The logic level present at the data input is transferred into the first stage and shifted one stage at each positive-going clock transition for single-phase operation, and at the positive-going transition of $\mathrm{CL}_{1}$ for two-phase operation.
The CD4062A is supplied in a 16 -lead flat pack ( K ), a 12 -lead TO-5 style package (T), and in chip form (H).

- Low power dissipation $0.3 \mathrm{~mW} / \mathrm{bit}$ at 1 MHz and 10 V $0.04 \mathrm{~mW} / \mathrm{bit}$ at 0.5 MHz and 5 V (alternating 1-0 data pattern)
- Data output TTL-DTL compatible
- Recirculating capability
- Delayed two-phase clock outputs available for cascading registers
- Asynchronous ripple-type presettable to all 1's or 0's
- Ultra-low-power-dissipation standby operation


## Applications:

- Serial shift registers
a Time-delay circuits
- CRT refresh memory
- Long serial memory


## MAXIMUM RATINGS, Absolute-Maximum Values:

| Storage-temperature range | -65 to $+150^{\circ} \mathrm{C}$ |
| :---: | :---: |
| OPERATING-TEMPERATURE RANG | . -55 to $+125^{\circ} \mathrm{C}$ |
| DC SUPPLY-VOLTAGE RANGE (V) | $\mathrm{V}_{\text {SS }}$ )..... - 0.5 to +15 V |
| DEVICE DISSIPATION (PER PACK | 200 mW |
| ALL INPUTS | $\ldots . . v_{S S} \leqslant v_{1} \leqslant v_{\text {DD }}$ |
| LEAD TEMPERATURE (DURING SOL | DERING): |
| AT DISTANCE $1 / 16 \pm 1 / 32 \mathrm{IN}$. 11 FROM CASE FOR 10 S MAX. | $.59 \pm 0.79 \mathrm{MM}$ ) $265^{\circ} \mathrm{C}$ |
| RECOMMENDED OPERATING C | ONDITIONS |
| DC SUPPLY VOLTAGE ( $\mathrm{V}_{\text {DD }}{ }^{-} \mathrm{V}_{\text {SS }}$ ): | SINGLE-PHASE CLOCK 3 to 10 V |
|  | TWO-PHASE CLOCK |
|  | 3 to 15 V |
| INPUT VOLTAGE SWING | $\ldots \mathrm{V}_{\mathrm{DD}}$ to $\mathrm{V}_{S S}$ |



Fig. 2-Clock circuit logic diagram.

STATIC ELECTRICAL CHARACTERISTICS, All Inputs $\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{\mathbf{1}} \leqslant \mathrm{V}_{\mathrm{DD}}$
Recommended DC Supply Voltage ( $V_{D D} \mathbf{V}_{S S}$ ) 3 to 15 V

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  |  | UNITS | $\begin{aligned} & \text { FIG. } \\ & \text { NO. } \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{gathered} v_{0} \\ v \end{gathered}$ | $V_{D D}$ <br> V | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |
|  |  |  |  |  | Min. | Max. | Min. | Typ. | Max. | Min. | Max. |  |  |
| Quiescent Device | $I_{L}$ | $\begin{aligned} & \mathrm{CM}=\text { High } \\ & \mathrm{CL}_{1}=\text { High } \\ & \mathrm{CL}_{2}=\text { Low } \\ & \hline \end{aligned}$ |  | 5 | - | 12 | - | 0.5 | 12 | - | 720 | $\mu \mathrm{A}$ | 19 |
| Current |  |  |  | 10 | - | 25 | - | 1 | 25 | - | 1500 |  |  |
| Quiescent Device | $P_{\text {D }}$ | $\begin{aligned} & \mathrm{CM}=\mathrm{High} \\ & \mathrm{CL}_{1}=\mathrm{High} \\ & \mathrm{CL}_{2}=\text { Low } \\ & \hline \end{aligned}$ |  | 5 | - | 60 | - | 2.5 | 60 | - | 3600 | $\mu \mathrm{W}$ | - |
| Dissipation/Package |  |  |  | 10 | - | 250 | - | 10 | 250 | - | 15000 |  |  |
| Output Voltage: | $\mathrm{V}_{\mathrm{OL}}$ |  |  | 5 | - | 0.01 | - | 0 | 0.01 | - | 0.05 | V | - |
|  |  |  |  | 10 | - | 0.01 | - | 0 | 0.01 | - | 0.05 |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | 4.99 | 5 | - | 4.95 | - | V | - |
|  |  |  |  | 10 | 9.99 | - | 9.99 | 10 | - | 9.95 | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ |  | 0.8 | 5 | 1.5 | - | 1.5 | 2.25 | - | 1.4 | - | V | 20 |
| (Any Input) |  |  | 1.0 | 10 | 3 | - | 3 | 4.5 | - | 2.9 | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 4.2 | 5 | 1.4 | - | 1.5 | 2.25 | - | 1.5 | - |  |  |
|  |  |  | 9.0 | 10 | 2.9 | - | 3 | 4.5 | - | 3 | - |  |  |
| Output Drive Current: <br> N-Channel (Sink) | ${ }^{1} \mathrm{D} N$ | Q Output | 0.4 | 4.5 | 1.6 | - | 1.3 | 2.6 | - | 0.91 | - | mA | 13,21 |
|  |  |  | 0.5 | 10 | 5 | - | 4 | 8* | - | 3.2 | - |  |  |
|  |  | $\begin{aligned} & C L_{1 D} \\ & C L_{2 D} \end{aligned}$ | 0.5 | 5 | 0.87 | - | 0.7 | 1.4 | - | 0.49 | - |  |  |
|  |  |  | 0.5 | 10 | 2.2 | - | 1.8 | 3.6 | - | 1.26 | - |  |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | 0 Output | 4.5 | 5 | -0.31 | - | -0.25 | -0.5 | - | -0.17 | - | mA | 14,22 |
|  |  |  | 2.5 | 5 | -0.93 | - | -0.75 | -1.5 | - | -0.52 | - |  |  |
|  |  |  | 9.5 | 10 | -0.87 | - | -0.7 | -1.4 | - | -0.49 | - |  |  |
|  |  | $\begin{aligned} & C L_{1 D}, \\ & C_{2 D} \\ & \hline \end{aligned}$ | 4.5 | 5 | -0.43 | - | -0.35 | -0.7 | - | -0.24 | - |  |  |
|  |  |  | 9.5 | 10 | -1.1 | - | -0.9 | -1.8 | - | -0.63 | - |  |  |
| Input Current | 1 | Any Input | - | - | - | - | - | 10 | - | - | - | pA | - |

* Maximum power dissipation rating $\leqslant 200 \mathrm{~mW}$.


Fig. 3-Timing diagram-single-phase clock.


92CS-22703

Fig. 4-Timing diagram-two-phase clock.
$\qquad$

DYNAMIC CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{SS}}=\mathbf{0} \mathrm{V}, \mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ and $\mathrm{t}_{\mathrm{f}} \mathrm{CL}$
Single-Phase-Clock Operation; Clock Mode (CM) = Low; $\mathbf{3} \mathbf{V} \leqslant \mathrm{V}_{\mathrm{DD}} \leqslant 10 \mathrm{~V}$ (See Figure 3)

**If more than one unit is cascaded in single-phase parallel clocked application, $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ should be made less than or equal to the sum of the propagation delay at 15 pF , and the transition time of the output driving stage. (See Figs. 5 and 7 for cascading options.)
4 Use of delayed clock permits high-speed logic to precede CD4062A register (see cascade register operation).

File No. 816

Two -Phase Clock Operation (CL ${ }_{1}, C L_{2}$ ); Clock Mode $(C M)=$ High; $3 V \leqslant V_{D D} \leqslant 15 V$. See Figure 4.


CASCADED REGISTER OPERATION


FEATURES:

- Low clock capacitance $\sim 5$ pF/package
- Medium-speed operation ~ 1 MHz @ 10 V
- Stringent clock rise and fall times required

92CS-22691
Fig. 5-Single-phase clocking (CM = GND).


92CS-22696
Fig. 6-Two-phase clocking.

FEATURES:

- High-speed operation $\sim 5 \mathrm{MHz} @ V_{D D}=10 \mathrm{~V}$
- No clock rise and fall time requirements if clock overlap specification is met
- Clock input capacitance only 50 pF/phase/package


## CASCADED REGISTER OPERATION (CONT‘D)

a) single phase clock input (low speed)

b) SINGLE-PHASE - CLOCK INPUT (MEDIUM SPEED)

c) TWO - PHASE - CLOCK INPUT (HIGHER SPEED)


FEATURES:

- 5 pF clock capacitance
- Low speed-delayed clock introduces $\sim 200$ ns delay per cascaded package @ 10 V
- Non-stringent clock rise and fall times (delayed clock prevents race conditions when cascading registers)


## FEATURES:

- 5 pF clock capacitance
- Medium speed-two-phase delayed clocks add only 70 ns delay per cascaded package. Data must be rephased (as shown) every five packages at 10 V . (10 packages at 5 V )
- Non-stringent clock rise and fall times


## FEATURES:

- Low clock capacitance $\sim 50$ pF/phase
- Higher speed than single-phase delayed clocking Clock overlap required equals ( $40+20 \times N)$ ns $\mathrm{N}=$ number of cascaded registers

92cs-22699
Fig. 7-Use of delayed-clock outputs.


## FEATURES:

- Ripple-type set/reset to all 1's/0's
- Ultra-low standby power dissipation

92CS-22692RI
Fig. 8-Asynchronous set/reset and standby.


## FEATURES:

- 64 stage static register delayed clock compatible with single-phase clock input on CD4062A
- CLiD delayed clock output on CD4062A compatible with other COS/MOS registers

Fig. 9-Compatibility with other COS/MOS registers//ogic.


## FEATURES:

- Single TTL supply level
- "Race"-Free: High speed TTL driving medium speed COS/MOS
92CS-22698
Fig. 10-Compatibility with TTL/DTL systems.

SIMPLE TWO-PHASE CLOCK GENERATOR CIRCUITS FOR DRIVING CD4062A


REQUIRED:
1 QUAD 2 NAND OR TRIPLE 3 NAND
(SN5400/7400 OR (SN5410/7410)
1 HEX INVERTER (SN5404/7404)


92CM-22697
$\mathrm{td}_{1}$ AND td $_{2} \approx 40 \mathrm{~ns}$ WITH THIS CIRCUIT
$\mathrm{td}_{1}$ AND $\mathrm{td}_{2}$ MAY BE ADJUSTED BY ADDING MORE INVERTER DELAYS OR CAPACITIVELY LOADING POINTS a AND b.

Fig. 11-TTL-5-volt levels (only 2-gate packages required).


REQUIRED:
1 CD4001A-QUAD 2 INPUT NOR GATE 1 CD4050A-HEX BUFFER (NON-INVERTING)


92CM-2270I
$\mathrm{td}_{1}$ AND $\mathrm{td}_{2} \approx 100 \mathrm{~ns}$ WITH THIS CIRCUIT @ 10 V $t_{1}$ AND $\mathrm{td}_{2}$ MAY BE ADJUSTED BY ADDING MORE INVERTER DELAYS OR CAPACITIVELY LOADING a AND b.

Fig. 12-COS/MOS-3-15 volt levels (only 2-gate packages required).


Fig. 13-Typical n-channel drain characteristics for $Q$ output.


Fig. 14-Typical p-channel drain characteristics for $Q$ output.


Fig. 15-Typical transition time vs. $C_{L}$ for data outputs.


Fig. 17-Typical power dissipation vs. frequency.


Fig. 16-Typical transition time vs. $C_{L}$ for delayed clock output.


92CS-24667
Fig. 18-Minimum shift frequency vs. ambient temperature.

TEST CIRCUITS


In single-phase clock mode inputs $\mathrm{CL}_{1}$ and $\mathrm{CL}_{2}$ should be left unconnected.

In two-phase clock mode 1-phase clock input may be left unconnected because an internal pulldown device is provided.

Fig. 19-Quiescent device current.
Fig. 20-Noise immunity.


Solid State Division

## Digital Integrated Circuits

Monolithic Silicon
CD4063B Types


## COS/MOS 4-Bit Magnitude Comparator

Features:

- Standard B-series output drive
- Expansion to 8, $16 \ldots 4 \mathrm{~N}$ bits by cascading units
- Medium-speed operation: compares two 4-bit words in $\mathbf{2 5 0} \mathrm{ns}$ (typ.) at $\mathbf{1 0} \mathrm{V}$


## Applications:

- Servo motor controls
a Process controllers

The RCA-CD4063B is a low-power 4-bit magnitude comparator designed for use in computer and logic applications that require the comparison of two 4 -bit words. This logic circuit determines whether one 4-bit word (Binary or BCD) is "less than", "equal to", or greater than" a second 4-bit word.

The CD4063B has eight comparing inputs ( A 3 , B 3 , through $A 0, B O)$, three outputs $(A<B, A=B, A>B)$ and three cascading inputs ( $A<B, A=B, A>B$ ) that permit systems designers to expand the comparator function to $8,12,16 \ldots 4 \mathrm{~N}$ bits. When a single CD4063B is used, the cascading inputs are connected as follows: $(A<B)=$ low, $(A=B)=$ high, $(A>B)=$ low.

For words longer than 4 bits, CD4063B devices may be cascaded by connecting the outputs of the less-significant comparator to the corresponding cascading inputs of the moresignificant comparator. Cascading inputs ( $A<B, A=B$, and $A>B)$ on the least significant comparator are connected to a low, a high, and a low level, respectively.

All outputs have equal source- and sink-current capabilities and conform to standard B-series output drive (see Static Electrical Characteristics).

The CD4063B is supplied in 16 -lead dual-in-line welded-seal ceramic packages (D), plastic packages (E), ceramic packages (F), flat packs (K), and in chip form (H).

TRUTH TABLE

| INPUTS |  |  |  |  |  |  | OUTPUTS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| COMPARING |  |  |  | CASCADING |  |  |  |  |  |
| A3, B3 | A2, B2 | A1, B1 | AO, B0 | $A<B$ | $A=B$ | $A>B$ | $A<B$ | $A=B$ | $A>B$ |
| A3 $>$ B3 | X | X | X | X | X | X | 0 | 0 | 1 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2>\mathrm{B} 2$ | X | $x$ | $x$ | $x$ | $x$ | 0 | 0 | 1 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | A1>B1 | $x$ | $x$ | $x$ | $x$ | 0 | 0 | 1 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $A 2=B 2$ | $\mathrm{A} 1=\mathrm{B} 1$ | $A 0>B 0$ | X | X | X | 0 | 0 | 1 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $\mathrm{A} 1=\mathrm{B} 1$ | $\mathrm{A} 0=\mathrm{BO}$ | 0 | 0 | 1 | 0 | 0 | 1 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $\mathrm{A} 1=\mathrm{B} 1$ | $A 0=B 0$ | 0 | 1 | 0 | 0 | 1 | 0 |
| $A 3=B 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $\mathrm{A} 1=\mathrm{B} 1$ | $A 0=B 0$ | 1 | 0 | 0 | 1 | 0 | 0 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $\mathrm{A} 1=\mathrm{B} 1$ | $\mathrm{AO}<\mathrm{BO}$ | X | X | X | 1 | 0 | 0 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2=\mathrm{B} 2$ | $\mathrm{A} 1<\mathrm{B} 1$ | X | X | $x$ | $x$ | 1 | 0 | 0 |
| $\mathrm{A} 3=\mathrm{B} 3$ | $\mathrm{A} 2<\mathrm{B} 2$ | $x$ | $x$ | $x$ | X | $x$ | 1 | 0 | 0 |
| A3< B3 | X | X | X | X | X | X | 1 | 0 | 0 |
| X = Don't | are |  |  | High S |  |  |  | $0 \equiv$ L | State |

## STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4063BD, BK, BF, BH <br> CERAMIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. <br> NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $v_{0}$Volts | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.02 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 12 |
|  |  |  | 10 | - | - | 10 | - | 0.02 | 10 | - | - | 600 |  |  |
|  |  |  | 15 | - | - | - | - | 0.02 | - | - | - | - |  |  |
| Output Voltage Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 13 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: <br> N-Channel (Sink) | IDN |  |  |  |  |  |  |  |  |  |  |  | mA | 3,4 |
|  |  | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 5,6 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 11 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

MAXIMUM RATINGS, Absolute-Maximum Values:

STORAGE-TEMPERATURE RANGE
-65 to $+150^{\circ} \mathrm{C}$
OPERATING-TEMPERATURE RANGE
CERAMIC-PACKAGE TYPES . . . . . . . . . . . . . . . . . -55 to $+125^{\circ} \mathrm{C}$
PLASTIC-PACKAGE TYPES . . . . . . . . . . . . . . . . . -40 to $+85{ }^{\circ} \mathrm{C}$
DC SUPPLY-VOLTAGE RANGE

DEVICE DISSIPATION (PER PACKAGE) . . . . . . . . . . . . . . 200 mW
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ )
from case for 10 seconds max.

* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.

OPERATING CONDITIONS AT $T_{A}=\mathbf{2 5}^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing $^{(R e c o m m e n d e d ~} \mathrm{V}_{\mathrm{SS}}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> (Any one <br> input) | -0.5 V <br> to <br> $\mathrm{VDD}^{+}$ <br> 0.5 V | V | - |

File No. 805

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4063BE <br> PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|c\|} \hline \mathrm{V}_{\mathrm{O}} \\ \text { Volts } \end{array}$ | $\begin{array}{\|l\|} \hline \text { VDD } \\ \text { Volts } \end{array}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{1}$ |  | 5 | - | - | 50 | - | 0.02 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 12 |
|  |  |  | 10 | - | - | 100 | - | 0.02 | 100 | - | - | 1400 |  |  |
|  |  |  | 15 | - | - | - | - | 0.02 | - | - | - | - |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 13 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | IDN |  |  |  |  |  |  |  |  |  |  |  | mA | 3,4 |
| $\begin{aligned} & \text { N-Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D}{ }^{\text {P }}$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 5,6 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 11 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$, and $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$



Fig. 1-Logic diagram CD4063B.

$=250+2 \times(200)=650 \mathrm{~ns}$ (TYP.)
Fig. 2-Typical speed characteristics of a 12-bit comparator.


Fig. 3-TypiCal output-N-channel drain characteristics.


92Cs-24320
Fig. 5-Typical output-P-channel drain characteristics.


Fig. 7-Typical propagation delay time vs. load capacitance.


Fig. 4-Minimum output-N-channel drain characteristics.


92CS-24321
Fig. 6-Minimum output-P-channel drain characteristics.


Fig. 8-Typical propagation delay time vs. supply voltage ("comparing inputs" to outputs).


Fig. 9-Typical transition time vs. load capacitance.


Fig. 10-Typical dynamic power dissipation characteristics.


Fig. 11-Quiescent device current test circuit.


Fig. 12-Noise immunity test circuit.


Fig. 13-Dynamic power dissipation test circuit.


## Digital Integrated Circuits



## COS/MOS Quad Bilateral Switch

## For Transmission or Multiplexing of Analog or Digital Signals

## Applications:

- Analog signal switching/multiplexing

Signal gating
Squelch control
Chopper

- Digital signal switching/Multiplexing
- Transmission-gate logic implementation
- Analog-to-digital \& digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain

RCA-CD4066A is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. It is pin-for-pin compatible with RCA-CD4016A, but exhibits a much lower ON resistance. In addition, the ON resistance is relatively constant over the full input-signal range.
The CD4066A consists of four independent bilateral switches.
A single control signal is required per switch. Both the $p$ and the $n$ device in a given switch are biased ON or OFF simultaneously by the control signal. As shown in Fig. 1, the well of the $n$-channel device on each switch is either tied to the input when the switch is ON or to $\mathrm{V}_{\mathrm{SS}}$ when the switch is OFF. This configuration minimizes the variation of the switchtransistor threshold voltage with input signal, and thus keeps the ON resistance low over the full operating-signal range.
The advantages over single-channel switches include peak input-signal voltage swings equal to the full supply voltage, and more constant ON impedance over the input-signal range. For sample-and-hold applications, however, the CD4016A is recommended.


Fig. 1 - Schematic diagram of 1 of 4 identical switches and its associated control circuitry.

The CD4066A is supplied in a 14 -lead dual-in-line ceramic package (CD4066AD), in a 14 -lead dual-in-line plastic package (CD4066AE), or in a 14 -lead ceramic flat pack (CD4066AK). It is also available in chip form (CD4066AH).

## Special Features:

- 15-V digital or $\pm 7.5-\mathrm{V}$ peak-to-peak switching
- 80- $\Omega$ typical ON resistance for $15-\mathrm{V}$ operation
- Switch ON resistance matched to within $5 \Omega$ over 15-V signal-input range
- ON resistance flat over full peak-to-peak signal range
- High ON/OFF output-voltage ratio: 65 dB typ. $@ f_{\text {is }}=10 \mathrm{kHz}, R_{\mathrm{L}}=10 \mathrm{k} \Omega$
- High degree of linearity: $<0.5 \%$ distortion typ. @fis $=1 \mathrm{kHz}$, $V_{\text {is }}=5 \mathrm{~V}_{\text {p-p, }} V_{D D}-V_{S S} \geqslant 10 \mathrm{~V}, R_{L}=10 \mathrm{k} \Omega$
- Extremely low OFF switch leakage resulting in very low offset current and high effective OFF resistance:
10 pA typ. @ $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}=10 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
- Extremely high control input impedance (control circuit isolated from signal circuit): $1012 \Omega$ typ.
- Low crosstalk between switches:
-50 dB typ. @ $\mathrm{fis}_{\text {s }}=0.9 \mathrm{MHz}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$
- Matched control-input to signal-output capacitance: Reduces output signal transients
- Frequency response, switch $\mathrm{ON}=40 \mathrm{MHz}$ (typ.)

ELECTRICAL CHARACTERISTICS (All inputs . . . . . . . . . . . . . . . . . $\mathbf{V}_{\mathbf{S S}} \leqslant \mathrm{V}_{\mathbf{1}} \leqslant \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage (VDD-VSSL . . . . . . 3 to 15 V)


SIGNAL INPUTS ( $V_{\text {is }}$ ) AND OUTPUTS ( $V_{\text {os }}$ )


File No. 769
ELECTRICAL CHARACTERISTICS (All inputs . . . . . . . . . . . . . . . . . $\mathrm{V}_{\mathbf{S S}} \leqslant \mathrm{V}_{\mathbf{1}} \leqslant \mathrm{V}_{\mathrm{DD}}$ )
(Recommended DC Supply Voltage (VDD-VSS).

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | LIMITS |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | CD4066AD, CD4066AK |  |  |  |  |  |  |
|  |  |  |  | $-55^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  | $125^{\circ} \mathrm{C}$ |  |  |
|  |  |  |  | Typ. | Max. | Typ. | Max. | Typ. | Max. |  |
| Control (VC) |  |  |  |  |  |  |  |  |  |  |
| Noise Immunity | $\mathrm{V}_{\text {NL }}$ | $\mathrm{V}_{\text {is }} \leqslant \mathrm{V}_{\text {DD }}$ | $\begin{aligned} & -V_{S S}=10 \mathrm{~V} \\ & l_{\text {is }}=10 \mu \mathrm{~A} \end{aligned}$ | - | - | 4.5 | - | - | - | V |
| Input Current | I' |  | $\begin{aligned} & -v_{S S}=10 \mathrm{~V} \\ & \leqslant v_{D D}-v_{S S} \end{aligned}$ | - | - | $\pm 10$ | - | - | - | pA |
| Average Input Capacitance | $\mathrm{C}_{C}$ |  |  | - | - | 5 | - | - | - | pF |
| Crosstalk Control Input to Signal Output |  | $\begin{aligned} & V_{D D}-V_{S S}=10 \mathrm{~V} \\ & V_{C}=10 \mathrm{~V} \\ & \text { (square wave) } \\ & t_{\mathrm{rc}}=t_{\mathrm{fc}}=20 \mathrm{~ns} \end{aligned}$ | $R_{L}=10 \mathrm{k} \Omega$ | - | - | 50 | - | - | - | mV |
| Propagation Delays | ${ }^{t}{ }_{p d} \mathrm{C}$ |  | $\begin{aligned} R_{\mathrm{L}} & =300 \Omega \\ v_{\text {is }} \leqslant 10 \mathrm{~V}, \mathrm{C}_{\mathrm{L}} & =15 \mathrm{pF} \end{aligned}$ | - | - | 35 | - | - | - | ns |
| Maximum Allowable Control Input Repetition Rate |  | $\begin{aligned} & V_{D D}=10 \mathrm{~V}, V_{S S}=G N D, R_{L}=1 \mathrm{k} \Omega \\ & C_{L}=15 \mathrm{pf} \\ & V_{C}=10 \mathrm{~V} \text { (square wave) } \\ & t_{f}=t_{f}=20 \mathrm{~ns} \end{aligned}$ |  | - | - | 10 | - | - | - | MHz |

* Limit determined by minimum feasible leakage measurement for automatic testing.
m Minimum value for all temperatures shown is 2 V .
A Symmetrical about 0 volts.

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | LIMITS |  |  |  |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | CD4066AE |  |  |  |  |  |  |
|  |  |  |  |  | $-40^{\circ} \mathrm{C}$ |  | $25^{\circ} \mathrm{C}$ |  | $85^{\circ} \mathrm{C}$ |  |  |
|  |  |  |  |  | Typ. | Max. | Typ. | Max. | Typ. | Max. |  |
| Quiescent Dissipation per Package <br> All Switches OFF | $\mathrm{P}_{\mathrm{T}}$ |  | TERMINALS | VOLTS APPLIED |  |  |  |  |  |  |  |
|  |  | $V_{\text {DD }}$ | 14 | $+10$ |  |  |  |  |  |  |  |
|  |  | $v_{\text {SS }}$ | 7 | GND |  |  |  |  |  |  |  |
|  |  |  | 5,6,12,13 | GND | - | 50 | 0.1 | 50 | - | 300 | $\mu \mathrm{W}$ |
|  |  | $\begin{aligned} & v_{\text {is }} \\ & v_{\text {os }} \end{aligned}$ | $\begin{aligned} & 1,4,8,11 \\ & 2,3,9,10 \end{aligned}$ | $\begin{aligned} & \leqslant+10 \\ & \leqslant+10 \end{aligned}$ |  |  |  |  |  |  |  |
| All Switches ON |  |  | TERMINALS | VOLTS APPLIED |  |  |  |  |  |  |  |
|  |  | $V_{D D}$ | 14 | $+10$ |  |  |  |  |  |  |  |
|  |  | $V_{S S}$ |  | GND | - | 50 | 0.1 | 50 | - | 300 | $\mu \mathrm{W}$ |
|  |  | $\mathrm{V}_{\mathrm{C}}$ | 5,6,12,13 | +10 (Tr.ru |  |  | 0.1 |  |  |  |  |
|  |  | $\mathrm{v}_{\text {is }}=\mathrm{v}_{\text {os }}$ | $1.4,8.11$ | $\leqslant+10 \begin{gathered} \{\text { Tr.ru } \\ 100 \Omega 2\} \end{gathered}$ |  |  |  |  |  |  |  |

SIGNAL INPUTS ( $V_{\text {is }}$ ) AND QUTPUTS ( $V_{\text {os }}$ )

| ON Resistance | $\mathrm{R}_{\mathrm{ON}}$ | $R_{L}=10 \mathrm{ks} 2$ | $\mathrm{V}_{\mathrm{C}}=\mathrm{V}_{\mathrm{DD}}$ | $\mathrm{V}_{\text {SS }}$ | $v_{\text {is }}$ | 80 | 250 | 80 | 280 | 130 | 300 | S2 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | +7.5 V | $-7.5 \mathrm{~V}$ | $\begin{array}{r} -7.5 \mathrm{~V} \\ 10 \\ +7.5 \mathrm{~V} \\ \hline \end{array}$ |  |  |  |  |  |  |  |
|  |  |  | $+15 \mathrm{~V}$ | 0 V | $\begin{array}{cc} 0 \text { to } \\ +15 \mathrm{~V} \end{array}$ |  |  |  |  |  |  |  |
|  |  |  | +5 V | $-5 \mathrm{~V}$ | $\begin{gathered} -5 \mathrm{~V} \\ \text { to } \\ +5 \mathrm{~V} \end{gathered}$ | 100 | 450 | 120 | 500 | 170 | 520 |  |
|  |  |  | $+10 \mathrm{~V}$ | . 0 V | $\begin{gathered} 0 \text { to } \\ +10 \mathrm{~V} \end{gathered}$ |  |  |  |  |  |  |  |
|  |  |  | +2.5V | -2.5V | $\begin{array}{r} -2.5 \mathrm{~V} \\ 10 \\ +2.5 \mathrm{~V} \end{array}$ | 190 | 3500 | 270 | 5000 | 330 | 5200 |  |
|  |  |  | +5V | 0 V | $\begin{aligned} & 0 i o \\ & +5 \mathrm{~V} \end{aligned}$ |  |  |  |  |  |  |  |
| $\triangle$ ON Resistance Between Any 2 of 4 Switches | $\triangle R_{\text {ON }}$ | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | $\begin{gathered} +7.5 \mathrm{~V} \\ +15 \mathrm{~V} \\ \hline \end{gathered}$ |  | +7.5 to -7.5 | - | - | 5 | - | - | - | $\Omega$ |
|  |  |  |  |  | +15 to 0V |  |  |  |  |  |  |  |
|  |  |  | $+5 \mathrm{~V}$ | - -5 V | +5 V to -5V | - | - | 10 | - | - | - |  |
|  |  |  | $+10 \mathrm{~V}$ | $0 \mathrm{~V}$ | +10 V to 0 V |  |  |  |  |  |  |  |
| Sine Wave Response (Distortion) |  | $\begin{aligned} & R_{L}=10 \mathrm{ks} 2 \\ & \mathrm{f}_{\mathrm{is}}=1 \mathrm{kHz} \end{aligned}$ | +5V | -5V | $5 \mathrm{~V}(\mathrm{p} \cdot \mathrm{p})^{4}$ | - | - | 0.4 | - | - | - | \% |



Control ( $\mathbf{V}_{\mathbf{c}}$ )

| Noise Immunity | VNL | $\mathrm{v}_{\text {is }} \leqslant \mathrm{V}_{\text {DD }}$ | $\begin{gathered} V_{D O}-V_{S S}=10 \mathrm{~V} \\ \mathrm{I}_{\text {is }}=10 \mu \mathrm{~A} \end{gathered}$ |  | - | - | 4.5 | - | - | - | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Current | IC |  |  | $\begin{aligned} & -V_{S S}=10 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}} \end{aligned}$ | - | - | $\pm 10$ | - | - | - | pA |
| Average Input Capacitance | $\mathrm{C}_{C}$ | $\begin{aligned} & V_{D D}-V_{S S}=10 \mathrm{~V} \\ & V_{C}=10 \mathrm{~V} \\ & \text { (square wave) } \\ & t_{\mathrm{rc}}=\mathrm{t}_{\mathrm{fc}}=20 \mathrm{~ns} \end{aligned}$ |  |  | - | - | 5 | - | - | - | pF |
| Crosstalk Control Input to Signal Output |  |  |  | $R_{L}=10 \mathrm{k} \Omega$ | - | - | 50 | - | - | - | mV |
| Propagation Delays | ${ }^{t} \mathrm{pd} \mathrm{C}$ |  |  | $v_{\text {is }} \leqslant 10 \mathrm{~V} .$ | - | - | 35 | - | - | - | ns |
| Maximum Allowable Control Input Repetition Rate |  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=\mathrm{GND}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pf} \\ & \mathrm{~V}_{\mathrm{C}}=10 \mathrm{~V} \text { (square wave) } \\ & \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns} \end{aligned}$ |  |  | - | - | 10 | - | - | - | MHz |

* Limit determined by minimum feasible leakage measurement for automatic testing.
- Symmetrical about 0 volts.
- Minimum value for all temperatures shown is 2 V .


## MAXIMUM RATINGS, Absolute-Maximum Values:

STORAGE TEMPERATURE RANGE . . . . $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
OPERATING TEMPERATURE RANGE:


## SPECIAL CONSIDERATIONS - CD4066A

1. In applications where separate power sources are used to drive $V_{D D}$ and the signal inputs, the $V_{D D}$ current capability should exceed $V_{D D} / R_{L}\left(R_{L}=\right.$ effective external load of the 4 CD4066A bilateral switches). This provision avoids any permanent current flow or clamp action on the VDD supply when power is applied or removed from CD4066A.
2. In certain applications, the external load-resistor current may include both $V_{D D}$ and signal-line components. To avoid drawing $\mathrm{V}_{\mathrm{DD}}$ current when switch current flows into terminals $1,4,8$, or 11 , the voltage drop across the bidirectional switch must not exceed 0.8 volt (calculated from RON values shown).
No VDD current will flow through $R_{L}$ if the switch current flows into terminals $2,3,9$, or 10 . Failure to observe this condition may result in distortion of the signal.


Fig. 2 (a) - Typical channel ON resistance vs. signal voltage for three values of supply voltage ( $V_{D D^{-}} V_{S S}$ ).


Fig. 2 (c) - Typical channel ON resistance vs. signal voltage with supply voltage ( $V_{D D}-V_{S S}$ ) $=10 \mathrm{~V}$.


Fig. 3 - ChanneI ON resistance measurement circuit.


Fig. 2 (b) - Typical channel ON resistance vs. signal voltage with supply voltage ( $\left.V_{D D}-V_{S S}\right)=5 \mathrm{~V}$.


Fig. 2 (d) - Typical channel ON resistance vs. signal voltage with supply voltage $\left(V_{D D}-V_{S S}\right)=15 \mathrm{~V}$.


92CS-23917

Fig. 4 - Typical ON characteristics for 1 of 4 channels.

TEST CIRCUITS


Fig. 5 - Capacitance.


ALL UNUSED INPUTS ARE CONNECTED TO VSS.
92CS-23920

Fig. 7 - Propagation delay time signal input ( $V$ IS) to signal output (VOS).


ALL UNUSED TERMINALS ARE CONNECTED TO VSS
92CS-23922

Fig. 9 - Propagation delay tPLH, tPHL control-signal output.


Fig. 11 - Power dissipation per package vs switching frequency.


ALL UNUSED TERMINALS
ARE CONNECTED TO VSS
92Cs-23919

Fig. 6 - OFF switch input or output leakage


ALL UNUSED TERMINALS ARE CONNECTED TO VSS.

$$
92 \operatorname{cs}-23921
$$

Fig. 8 - Crosstalk-control input to signal output.

all unused inputs are connected to vss.

Fig. 10 - Maximum allowable control input repetition rate.


Fig. 12 - Bidirectional signal transmission via digital control logic.


Fig. 13 - 4-channel PAM multiplex system diagram.


The RCA-CD4067B and CD4097B COS/MOS analog multiplexers/demultiplexers" are digitally controlled analog switches having low "on" impedance, low "off" leakage current, and internal address decoding. In addition, the "on" resistance is relatively constant over the full input-signal range. The CD4067B is a 16 -channel multiplexer with four binary control inputs, A, B, C, D, and an inhibit input, arranged so that any combination of the inputs selects one switch. A logic " 1 " present at the inhibit input turns all channels off.
The CD4097B is a differential 8 -channel multiplexer having three binary control inputs A, B, C, and an inhibit input. The inputs permit selection of one of eight pairs of switches.
The CD4067B, CD4097B are supplied in a $24-\mathrm{lead}$ dual-in-line welded-seal ceramic package. (CD4067BD, CD4097BD).
"When the devices are used as demultiplexers, the in/out terminals are the outputs and the common out/in terminal(s) is(are) the input(s).

MAXIMUM RATINGS, Absolute-Maximum Values:
STORAGE-TEMPERATURE RANGE.............. -65 to $+150^{\circ} \mathrm{C}$
operating-temperature range............ -55 to $+125{ }^{\circ} \mathrm{C}$
dC SUPPLY-VOLTAGE RANGE

DEVICE DISSIPATION (PER PACKAGE) ................ 200 mW

LEAD TEMPERATURE (DURING SOLDERING):
At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds max.
$265^{\circ} \mathrm{C}$

- All voltage values are referenced to $\mathrm{V}_{\text {SS }}$ terminal.

OPERATING CONDITIONS AT TA $=\mathbf{2 5}^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be
selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing <br> (Recommended $\mathrm{V}_{\text {SS }}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> (Any one <br> input) | -0.5 V <br> to <br> $\mathrm{V}_{\mathrm{DD}}+$ <br> 0.5 V | V | - |
| Signal Input Current | - | - | 25 | mA | - |
| Output Load Resistance | - | 100 | - | $\Omega$ | - |

TERMINAL ASSIGNMENTS
CD4067B


ELECTRICAL CHARACTERISTICS at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{V}_{\text {DD }}(\mathrm{V})$ | $\mathrm{V}_{\text {SS }}(\mathrm{V})$ |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | 0 | 0.1 | $\mu \mathrm{A}$ |
|  |  |  | 10 | 0 | 0.2 |  |
|  |  |  | 15 | 0 | 0.5 |  |
| SIGNAL INPUTS ( $\mathrm{V}_{\text {is }}$ ) AND OUTPUTS ( $\mathrm{V}_{\text {os }}$ ) |  |  |  |  |  |  |
| "ON" Resistance <br> (Peak for $\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{\text {is }} \leqslant \mathrm{V}_{\mathrm{DD}}$ ) | $\mathrm{R}_{\mathrm{ON}}$ | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega$ | +7.5 | -7.5 | 140 | $\Omega$ |
|  |  |  | +15 | 0 |  |  |
|  |  |  | +5 | -5 | 200 |  |
|  |  |  | +10 | 0 |  |  |
|  |  |  | +2.5 | -2.5 | 400 |  |
|  |  | (Any <br> Channel <br> Selected) | +5 | 0 |  |  |
| $\triangle$ "ON" Resistance <br> Between Any 2 Channels | $\Delta \mathrm{R}_{\text {ON }}$ |  | +7.5 | -7.5 | 5 |  |
|  |  |  | +15 | 0 |  |  |
|  |  |  | +5 | -5 | 10 |  |
|  |  |  | +10 | 0 |  |  |
| Sine Wave Distortion |  | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{f}_{\mathrm{is}}=1 \mathrm{kHz} \\ & 5 \mathrm{~V}(\mathrm{p} \cdot \mathrm{p})^{\mathbf{4}} \end{aligned}$ | +7.5 | -7.5 | 0.1 | \% |
|  |  |  | +5 | -5 |  |  |
|  |  |  | +2.5 | -2.5 |  |  |
| "OFF" Any Channel OFF <br> Channel  <br> Leakage All Channels CD4067B <br> Current OFF (Output) CD4097B |  |  | +5 | -5 | $\pm 0.2$ | nA |
|  |  | Inhibit $=+5 \mathrm{~V}$ | +5 | -5 | $\pm 3.2$ |  |
|  |  |  | +5 | -5 | $\pm 1.6$ |  |
| Frequency ResponseChannel "ON" (Sine Wave Input) |  | $\begin{aligned} & R_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \mathrm{~V}_{\text {is }}=5 \mathrm{~V}(\mathrm{p}-\mathrm{p}) \\ & \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF} \end{aligned}$ | $\begin{gathered} \mathrm{V}_{\mathrm{C}}=\mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{SS}}=-5 \mathrm{~V} \\ 20 \mathrm{Vog}_{10} \frac{\mathrm{~V}_{\mathrm{os}}}{\mathrm{~V}_{\text {is }}}=-3 \mathrm{~dB} \end{gathered}$ |  | 40 | MHz |
| Feedthrough Channel "OFF" |  |  | $\begin{gathered} \mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{C}}=\mathrm{V}_{\mathrm{SS}}=-5 \mathrm{~V} \\ 20 \log _{10} \frac{\mathrm{~V}_{\mathrm{OS}}}{\mathrm{~V}_{\mathrm{is}}}=-40 \mathrm{~dB} \end{gathered}$ |  | 1 | MHz |
| Crosstalk Between Any 2 of the 16 Switches (Frequency at $\mathbf{- 4 0 \mathrm { dB } \text { ) }}$ |  | $\begin{gathered} R_{\mathrm{L}}=1 \mathrm{k} \Omega \\ \mathrm{~V}_{\text {is }}(\mathrm{A})= \\ 5 \mathrm{~V}(\mathrm{p}-\mathrm{p}) \\ \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF} \end{gathered}$ | $\begin{gathered} \mathrm{V}_{\mathrm{C}}(\mathrm{~A})=\mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{C}}(\mathrm{~B})=\mathrm{V}_{S S}=-5 \mathrm{~V} \\ \mathrm{~V}_{\text {oS }}(\mathrm{B}) \\ 20 \log _{10} \mathrm{~V}_{\text {is }}(\mathrm{A}) \end{gathered}=-40 \mathrm{~dB},$ |  | 1 | MHz |
| Input | $\mathrm{C}_{\text {IS }}$ |  | +5 | -5 | 5 | pF |
| Output | $\mathrm{C}_{\mathrm{OS}}$ |  | CD4067B |  | 60 |  |
| Capacitance (Common OUT/IN) |  |  |  | CD4097B | 30 |  |
| Feedthrough | $\mathrm{ClOS}^{\text {I }}$ |  |  |  | 0.2 |  |
| Propagation Delay: <br> Signal Input to Signal Output | $\begin{aligned} & \mathrm{t}_{\mathrm{PLH}}, \\ & \mathrm{t}_{\mathrm{PH}} \end{aligned}$ |  | $\begin{aligned} & =V_{D D}= \\ & S S=V_{i n h}= \\ & =50 \mathrm{pF} \\ & =10 \mathrm{~V} \mathrm{l} \\ & \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns} \end{aligned}$ | V. <br> V, <br> are wave) <br> ut signal) | 30 | ns |

[^16]ELECTRICAL CHARACTERISTICS (Cont'd)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{V}_{\text {DD }}-\mathrm{V}_{\text {SS }}(\mathrm{V})$ |  |  |
| CONTROL ( $\mathrm{V}_{\mathbf{C}}$ ) INPUTS A, B, C, D AND Inhibit |  |  |  |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$, <br> $\mathrm{V}_{\mathrm{NH}}$ | $\begin{aligned} & \mathrm{l}_{\text {is }}=10 \mu \mathrm{~A} \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \mathrm{~V}_{\text {is }}=\mathrm{V}_{\mathrm{DD}} \\ & \text { through } \\ & 1 \mathrm{k} \Omega \end{aligned}$ | 15 | 6.75 | V |
|  |  |  | 10 | 4.5 |  |
|  |  |  | 5 | 2.25 |  |
| Average Input Capacitance | $\mathrm{C}_{\mathrm{C}}$ |  | 10 | 5 | pF |
| Turn-On Propagation Delay: Control Input to Signal Output | ${ }^{\text {tpHL}}$. <br> ${ }^{\text {tpLH}}$ | $\begin{aligned} & C_{L}=50 \mathrm{pF} \\ & R_{L}=10 \mathrm{k} \Omega \\ & V_{C}=V_{D D} \text { (square) } \\ & V_{i \text { is }} \leqslant V_{D D} \\ & t_{r}, t_{f}=20 \mathrm{~ns} \end{aligned}$ | 15 | 140 | ns |
|  |  |  | 10 | 200 |  |
|  |  |  | 5 | 400 |  |
| Inhibit Input to Signal Output |  |  | 15 | 140 |  |
|  |  |  | 10 | 200 |  |
|  |  |  | 5 | 400 |  |
| Inhibit Recovery Time ${ }^{*}$ |  |  | 10 | 200 | ns |

* Time after Inhibit is removed during which channel information is valid.

CD4067B TRUTH TABLE

| $A$ | $B$ | $C$ | $D$ | Inh | Selected <br> Channel |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $X$ | $X$ | $X$ | $X$ | 1 | None |
| 0 | 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 1 |
| 0 | 1 | 0 | 0 | 0 | 2 |
| 1 | 1 | 0 | 0 | 0 | 3 |
| 0 | 0 | 1 | 0 | 0 | 4 |
| 1 | 0 | 1 | 0 | 0 | 5 |
| 0 | 1 | 1 | 0 | 0 | 6 |
| 1 | 1 | 1 | 0 | 0 | 7 |
| 0 | 0 | 0 | 1 | 0 | 8 |
| 1 | 0 | 0 | 1 | 0 | 9 |
| 0 | 1 | 0 | 1 | 0 | 10 |
| 1 | 1 | 0 | 1 | 0 | 11 |
| 0 | 0 | 1 | 1 | 0 | 12 |
| 1 | 0 | 1 | 1 | 0 | 13 |
| 0 | 1 | 1 | 1 | 0 | 14 |
| 1 | 1 | 1 | 1 | 0 | 15 |



CD4097B Functional Diagram

## SPECIAL CONSIDERATIONS

1. In applications where separate power sources are used to drive $V_{D D}$ and the signal inputs, the $V_{D D}$ current capability should exceed $V_{D D} / R_{L}\left(R_{L}=\right.$ effective external load). This provision avoids any permanent current flow or clamp action on the $V_{D D}$ supply when power is applied or removed from the CD4067B, CD4097B.
2. In certain applications, the external load-resistor current may include both $V_{D D}$ and signal-line components. To avoid drawing $V_{D D}$ current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8 volt (calculated from $\mathrm{R}_{\mathrm{ON}}$ values shown).
No $V_{D D}$ current will flow through $R_{L}$ if the switch current flows into terminal 1 on the CD4067B; terminals 1 and 17 on the CD4097B.

CD4097B TRUTH TABLE

| A | B | C | Inh | Selected <br> Channel |
| :---: | :---: | :---: | :---: | :---: |
| $X$ | $X$ | $X$ | 1 | None |
| 0 | 0 | 0 | 0 | $0 X, 0 Y$ |
| 1 | 0 | 0 | 0 | $1 X, 1 Y$ |
| 0 | 1 | 0 | 0 | $2 X, 2 Y$ |
| 1 | 1 | 0 | 0 | $3 X, 3 Y$ |
| 0 | 0 | 1 | 0 | $4 X, 4 Y$ |
| 1 | 0 | 1 | 0 | $5 X, 5 Y$ |
| 0 | 1 | 1 | 0 | $6 X, 6 Y$ |
| 1 | 1 | 1 | 0 | $7 X, 7 Y$ |



## COS/MOS 8-Input NAND Gate

## Features:

- Medium-Speed Operation - tpHL $=130 \mathrm{~ns}$, t PLH $^{=100} \mathbf{n s}$ (typ.) at 10 V
- Standard B-Series Output Drive

The RCA-CD4068B NAND gate provides the system designer with direct implementation of the positive-logic 8 -input NAND function and supplements the existing family of COS/MOS gates.
This device has equal source- and sink-current capabilities and
conforms to standard B-series output drive (see Static Electrical Characteristics).
The CD4068B is supplied in a 14 -lead dual-in-line welded-seal ceramic package (D), plastic package ( $E$ ), ceramic package ( $F$ ), flat package ( K ), and in chip form $(\mathrm{H})$.


Fig. 1-CD4068B schematic diagram.

## STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4068BD CD4068BF <br> CD4068BK CD4068BH <br> CERAMIC PACKAGE LIMITS  |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{V}_{\mathrm{O}} \\ \mathrm{Volts} \end{gathered}$ | VDD <br> Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{1} \mathrm{~L}$ |  | 5 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | VNH | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | ${ }^{1} \mathrm{DN}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 4, 5 |
| N -Channel (Sink) |  | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{\text {I }}$ P | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | $-1.15$ | - | - | mA | 6,7 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 1 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

## MAXIMUM RATINGS, Absolute-Maximum Values:

| STORAGE-TEMPERATURE RANGE............ -65 to $+150^{\circ} \mathrm{C}$ |  |
| :---: | :---: |
|  |  |
| CERAMIC-PACKAGE TYPES | -55 to $+125^{\circ} \mathrm{C}$ |
| PLASTIC-PACKAGE TYPES | -40 to +85 |
| DC SUPPLY-VOLTAGE RANGE |  |
| VDD*................. |  |
| DEVICE DISSIPATION (PER PACKAGE) |  |
| LEAD TEMPERATURE (DURING SOLDERING): |  |
| At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds max. | 265 |
|  |  |

OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ | -0.5 V | V | - |
| (Recommended $\mathrm{V}_{\mathrm{SS}}$ to $\mathrm{V}_{\mathrm{DD}}$ ) |  | to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> $($ Any <br> one | to <br> input | 0.5 V |  |

File No. 809 CD4068B

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4068BE <br> PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{V}_{0} \\ \text { Volts } \end{gathered}$ | $\begin{aligned} & \text { VDD } \\ & \text { Volts } \end{aligned}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.01 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | $I_{\text {IN }}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 4, 5 |
| $\begin{aligned} & \text { N-Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 6,7 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$, and $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$



Fig. 2-Typical voltage and current transfer characteristics.


Fig. 4-Typical output-N-channel drain characteristics.


92CS-24320


Fig. 3-Min. and max. voltage transfer characteristics.


Fig. 5-Minimum output-N-channel drain characteristics.


Fig. 7-Minimum output-P-channel drain characteristics.


Fig. 8-Typical high-to-low level propagation delay time vs. load capacitance.


Fig. 10-Typical propagation delay time vs. supply voltage.


Fig. 9-Typical low-to-high level propagation delay time vs. load capacitance.


Fig. 11-Typical transition time vs. load capacitance.


Fig. 12-Typical power dissipation vs. frequency.


Fig. 13 - Quiescent device current test circuit.


Fig. 14 - Noise immunity test circuit.

Solid State

## Digital Integrated Circuits <br> Monolithic Silicon

 Division

## COS/MOS Hex Inverter

Features:

- Medium Speed Operation - t $_{\text {PHL }}$, t $_{\text {PLH }}=\mathbf{4 0}$ ns (typ.) at 10 V
- Standard B-Series Output Drive

The RCA-CD4069B consists of six COS/MOS inverter circuits. All outputs have equal source and sink current capabilities and conform to the standard B-series output drive (see Static Electrical Characteristics).

This device is intended for all general-purpose inverter applications where the medium-power TTL-drive and logic-levelconversion capabilities of circuits such as the CD4009A and CD4049A Hex Inverter/Buffers are not required.

The CD4069B is supplied in 14-lead dual-in-line welded-seal ceramic packages (D), plastic packages (E), ceramic packages (F), ceramic flat packs (K), and in chip form (H).


Fig. 1-Schematic diagram of one of six identical inverters.

Applications:

- Logic inversion
- Pulse shaping
- Oscillators
- High-input-impedance amplifiers


## MAXIMUM RATINGS, Absolute-Maximum Values:

| STORAGE-TEMPERATURE RANGE. . . . . . . . . . . . -65 to $+150^{\circ} \mathrm{C}$ |  |
| :---: | :---: |
| OPERATING-TEMPERATURE RANGE: |  |
| CERAMIC-PACKAGE TYPES | 55 to $+125^{\circ} \mathrm{C}$ |
| PLASTIC-PACKAGE TYPE | -40 to $+85{ }^{\circ} \mathrm{C}$ |
| DC SUPPLY-VOLTAGE RANGE |  |
| DD | 0.5 to +18 V |
| VICE DISS |  |
| ALL INPUTS . . . . . . . . . . . . . . . . . . . . . . . $V_{\text {SS }} \leqslant V_{1} \leqslant V_{\text {DD }}$ |  |
| LEAD TEMPERATURE (DURING SOLDERING): |  |
| At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds max. | $265{ }^{\circ} \mathrm{C}$ |
| All voltage values are referenced to $\mathrm{V}_{\text {SS }}$ terminal. |  |

OPERATING CONDITIONS AT TA $=25^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing <br> (Recommended $\mathrm{V}_{\mathrm{SS}}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> $\left(\begin{array}{c}\text { Any one } \\ \text { input) }\end{array}\right.$ | -0.5 V <br> to <br> $\mathrm{V}_{\mathrm{DD}}+$ <br> 0.5 V | V | - |

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4069BD, BF, BK, BH CERAMIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. <br> NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{O}} \\ & \text { Volts } \end{aligned}$ | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 17 |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 3.6 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 18 |
|  |  | 7.2 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 10.8 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 1.4 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 2.8 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 4.2 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: <br> N -Channel '(Sink) | IDN |  |  |  |  |  |  |  |  |  |  |  | mA | 5,6 |
|  |  | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | IDP | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.15 | - | - | mA | 7.8 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 1 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathbf{n s}$, and $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | ALL TYPES LIMITS |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \text { VDD } \\ & \text { Volts } \end{aligned}$ | Typ. | Max. |  |  |
| Propagation Delay Time: | ${ }^{\mathrm{t}} \mathrm{PHL}$, <br> ${ }^{t} \mathrm{PLH}$ | 5 10 15 | 65 40 30 | 125 80 - | ns | 9,10 |
| Transition Time | ${ }^{\mathrm{t}}$ THL, <br> ${ }^{t}$ TLH | 5 10 15 | 100 50 40 | $\begin{gathered} 200 \\ 100 \\ 80 \end{gathered}$ | ns | 11 |
| Average Input Capacitance | $C_{1}$ | Any Input | 5 | - | pF | - |

STATIC ELECTRICAL CHARACTERISTICS

| CHARAC. TERISTIC | SYMBOL | TEST CONDI. TIONS |  | CD4069BEPLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|c\|} \hline V_{\mathbf{O}} \\ \text { Volts } \end{array}$ | $\begin{array}{\|c\|} \hline \text { VDD } \\ \text { Volts } \end{array}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | - | - | 5 | - | 0.01 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 17 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 3.6 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 18 |
|  |  | 7.2 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 10.8 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 1.4 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 2.8 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 4.2 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | ${ }^{1} \mathrm{DN}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 5, 6 |
| $\begin{aligned} & \text { N-Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D}{ }^{\text {P }}$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 7,8 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 11 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



92cs-24431

Fig. 2-Min. and max. voltage transfer characteristics.


Fig. 3-Typical voltage transfer characteristics as a function of temperature.


Fig. 4-Typical current and voltage transfer characteristics.


Fig. 6-Minimum output-N-channel drain characteristics.


Fig. 5-Typical output-N-channel drain characteristics.


Fig. 7-Typical output-P-channel drain characteristics.


92CS-24321
Fig. 8-Minimum output-P-channel drain characteristics.


Fig. 9-Typical propagation delay time vs. load capacitance.


Fig. 10-Typical propagation delay time vs. supply voltage.


Fig. 12-Typical dynamic power dissipation.


FOR TYPICAL COMPONENT VALUES AND CIRCUIT PERFORMANCE, SEE APPLICATION NOTE ICAN-6267

92Cs-24438

Fig. 14-Typical RC oscillator circuit.


92Cs-24439

Fig. 15-High-input impedance amplifier.


UPPER SWITCHING POINT:

$$
V_{P} \approx \frac{R_{S}+R_{f}}{R_{f}} \cdot \frac{V_{D D}}{2}
$$

LOWER SWITCHING POINT:

$$
\begin{gathered}
V_{N} \approx \frac{R_{f}-R_{S}}{R_{f}} \cdot \frac{V_{D D}}{2} \\
R_{f}>R_{S}
\end{gathered}
$$

92Cs-24440

Fig. 16-Input pulse shaping circuit (Schmitt trigger).

## TEST CIRCUITS



Fig. 17-Quiescent device current.


Fig. 18-Noise immunity.


92CM-24443

Fig. 19-Dynamic electrical characteristics test circuit and waveforms.


COS/MOS Quad Exclusive-OR Gate-CD4070B
Quad Exclusive-NOR Gate-CD4077B


TERMINAL ASSIGNMENT CD4070B


92CS-24499
TERMINAL ASSIGNMENT CD4077B

The RCA-CD4070B contains four independent exclusive-OR gates. RCA-CD4077B contains four independent exclusive-NOR gates.
Type CD4070B is pin-for-pin compatible with RCA-CD4030A and in addition has greater current-sourcing capability and a higher input impedance.
The CD4070B and CD4077B are supplied in 14-lead dual-inline plastic packages.

MAXIMUM RATINGS, Absolute-Maximum Values:

| STORAGE-TEMPERATURE RANGE | -65 to $+150^{\circ} \mathrm{C}$ |
| :---: | :---: |
| OPERATING-TEMPERATURE RANGE. | 40 to $+85{ }^{\circ} \mathrm{C}$ |
| DC SUPPLY-VOLTAGE RANGE: |  |
| (V)*) | -0.5 to +18 V |
| DEVICE DISSIPATION (PER PACKAGE) | 200 mW |
| ALL INPUTS.................. | $\leqslant v_{1} \leqslant v_{D}$ |
| LEAD TEMPERATURE (DURING SOLDERING) |  |
| At distance $1 / 16 \pm 1 / 32 \mathrm{in}$. $(1.59 \pm 0.79 \mathrm{~mm})$ from case for 10 s max. | $+265{ }^{\circ} \mathrm{C}$ |
| ge values are referenced to $\mathrm{V}_{\text {SS }}$ |  |

OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | v | - |
| Input Voltage Swing (Recommended $\mathrm{V}_{\mathrm{SS}}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \left(\begin{array}{c} \text { Any } \\ \text { input } \end{array}\right. \end{gathered}$ | $\left\|\begin{array}{c} -0.5 \mathrm{~V} \\ \text { to } \\ v_{D D}+ \\ 0.5 \mathrm{~V} \end{array}\right\|$ | v | - |

TRUTH TABLE CD4070B
1 of 4 Gates

| $A$ | $B$ | $J$ |
| :---: | :---: | :---: |
| 0 | 0 | 0 |
| 1 | 0 | 1 |
| 0 | 1 | 1 |
| 1 | 1 | 0 |

Where 1 = High Level
" $0=$ Low Level $J=A \oplus B$

TRUTH TABLE CD4077B
1 of 4 Gates

| $A$ | $B$ | $J$ |
| :---: | :---: | :---: |
| 0 | 0 | 1 |
| 1 | 0 | 0 |
| 0 | 1 | 0 |
| 1 | 1 | 1 |

Where 1 = High Level
" $0=$ Low Level
$\bar{J}=A \oplus B$

STATIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL VALUESCD4070BCD4077B | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{V}_{\mathbf{O}} \\ \text { Volts } \end{gathered}$ |  | $V_{D D}$ <br> Volts |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  |  | 5 | 0.01 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 | 0.01 |  |
| Output Drive Current: <br> N-Channel (Sink) | ${ }_{1} \mathrm{~N}$ | $V_{1}=V_{S S}$ |  |  |  | mA |
|  |  |  | 0.4 | 5 | 0.8 |  |
|  |  |  | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }^{1} D^{P}$ | $\mathrm{V}_{1}=\mathrm{V}_{\mathrm{DD}}$ | 4.6 | 5 | -0.8 |  |
|  |  |  | 2.5 | 5 | -1.8 |  |
|  |  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}}$

|  |  | TEST CONDITIONS | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: |
| CHARACTERISTIC | SYMBOL | VDD <br> Volts | $\begin{aligned} & \text { CD4070B } \\ & \text { CD4077B } \end{aligned}$ |  |
| Propagation Delay: |  |  |  |  |
| High-to-Low | tPHL | 5 | 175 | ns |
|  |  | 10 | 70 |  |
| Low-to-High | ${ }^{\text {tPLH }}$ | 5 | 175 | ns |
|  |  | 10 | 70 |  |
| Transition Time: | ${ }^{\text {t }} \mathrm{HL}$ |  |  | ns |
| High-to-Low |  | 5 | 100 |  |
|  |  | 10 | 50 |  |
| Low-to-High | ${ }^{\text {T TL }}$ H | 5 | 100 | ns |
|  |  | 10 | 50 |  |
| Average Input Capacitance | $\mathrm{C}_{1}$ | Any Input | 5 | pF |



Solid State Division

Digital Integrated Circuits CD4071B Types CD4072B Types CD4075B Types


## COS/MOS OR Gates

CD4071B Quad 2-Input OR Gate<br>CD4072B Dual 4-Input OR Gate<br>CD4075B Triple 3-Input OR Gate

## Features:

- Medium-Speed Operation tpLH $=\mathbf{7 0}$ ns (typ.); tpHL $=100 \mathrm{~ns}$ (typ.) at 10 V
- Standard B-Series Output Drive

The RCA-CD4071B, -CD4072B, and -CD4075B OR gates provide the system designer with direct implementation of the positive-logic OR function and supplement the existing family of COS/MOS gates. These devices have equal source- and sinkcurrent capabilities and conform to standard B-Series output drive (see Static Electrical Characteristics).
The CD4071B, CA4072B, and CD4075B are supplied in 14-lead dual-in-line plastic packages (E), welded-seal ceramic packages (D), ceramic packages (F), ceramic flat-packs (K), and in chip form (H).

MAXIMUM RATINGS, Absolute-Maximum Values:

| STORAGE-TEMPERATURE RANGE. . . . . . . . . . . -65 to $+150^{\circ} \mathrm{C}$ |  |
| :---: | :---: |
|  |  |
| CERAMIC-PACKAGE TYPES . . |  |
|  | 40 to |
| DC SUPPLY-VOLTAGE RANGE |  |
|  |  |
| DEVICE DISSIPATION (PER PACKAGE) .............. 200 mW |  |
| LEAD TEMPERATURE (DURING SOLDERING): |  |
| At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) | $5^{\circ}$ |
| values |  |


*all inputs protected gy standard COS/MOS PROTECTION CIRCUIT

92CS-23812RI

Fig. 1-CD4071B schematic diagram (1 of 4 identical OR gates).

File No. 807 CD4071B, CD4072B, CD4075B

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | $\begin{gathered} \text { CD4071BD, BF, BK, BH CD4072BD, BF, BK, BH } \\ \text { CD4075BD, BF, BK, BH } \\ \text { CERAMIC PACKAGE LIMITS } \end{gathered}$ |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{\mathrm{O}}$ | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 15 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 1 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 4, 5, 16 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | IDN |  |  |  |  |  |  |  |  |  |  |  | mA | 6,7 |
| N -Channel (Sink) |  | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.15 | - | - | mA | 8,9 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 11 |  | 15 | - | - | - | - | $\pm 10-5$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$, and $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | ALL TYPES LIMITS |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|l} \hline V_{D D} \\ \text { Volts } \end{array}$ | Typ. | Max. |  |  |
| Propagation Delay Time: <br> High-to-Low Level | ${ }^{\text {tPHL}}$ | 5 10 15 | $\begin{array}{r} 250 \\ 100 \\ 75 \end{array}$ | $\begin{gathered} 500 \\ 200 \\ - \\ \hline \end{gathered}$ | ns | 10, 12 |
| Low-to-High Level | ${ }^{\text {tPLH }}$ | 5 10 15 | $\begin{array}{r} 175 \\ 70 \\ 55 \end{array}$ | $\begin{gathered} 350 \\ 140 \\ - \end{gathered}$ | ns | 11, 12 |
| Transition Time | $\begin{aligned} & { }^{{ }^{\mathrm{THL}}} \\ & { }^{\mathrm{t}_{\mathrm{TLH}}} \end{aligned}$ | 5 10 15 | 100 50 40 | $\begin{array}{r} 200 \\ 100 \\ 80 \end{array}$ | ns | 13 |
| Average Input Capacitance | $C_{1}$ | Any Input | 5 | - | pF | - |

STATIC ELECTRICAL CHARACTERISTICS

| CHARAC. TERISTIC | SYMBOL | TEST CONDITIONS |  | CD4071BE, CD4072BE, CD4075BE PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{V}_{\mathrm{O}} \\ \text { Volts } \end{gathered}$ | $\begin{aligned} & \hline \text { VDD } \\ & \text { Volts } \end{aligned}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | - | - | 5 | - | 0.01 | 0.5 | - | - | 70 | $\mu \mathrm{A}$ | 15 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 4, 5, 16 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  | mA | 6,7 |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| $\begin{aligned} & \text { N-Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ | $I_{\text {d }}$ | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D P}$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 8,9 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 11 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



Fig. 2-CD4072B schematic diagram (1 of 2 identical OR gates).

File No. 807


92CS-23814R:
Fig. 3-CD4075B schematic diagram (1 of 3 identical OR gates).


Fig. 4-Typical voltage and current transfer characteristics.


Fig. 5-Min. and max. voltage transfer characteristics.


Fig. 7-Minimum output-N-channel drain characteristics.


92CS-24320
Fig. 8-Typical output-P-channel drain characteristics.


Fig. 10-Typical high-to-low level propagation delay time vs. load capacitance.


Fig. 12-Typical propagation delays vs. supply voltage.

DRAIN-TO-SOURCE VOLTAGE ( $V_{D S}$ )-V


92CS-24321
Fig. 9-Minimum output-P-channel drain characteristics.

Fig. 11-Typical low-to-high level propagation delay time vs. load capacitance.


Fig. 13-Typical transition time vs. load capacitance.


Fig. 14-Typical dynamic power dissipation vs. frequency.


Fig. 15-Quiescent current test circuits.


Fig. 16-Noise immunity test circuits.


Solid State Division

## Digital Integrated Circuits <br> Monolithic Silicon CD4081B Types CD4082B Types CD4073B Types



## COS/MOS AND Gates

CD4081B Quad 2-Input AND Gate<br>CD4082B Dual 4-Input AND Gate<br>CD4073B Triple 3-Input AND Gate

Features:

- Medium-Speed Operation - t $_{\text {PLH }}=85 \mathrm{~ns}$ (typ.); t $_{\text {PHL }}=65 \mathrm{~ns}$ (typ.) at 10 V
- Standard B-Series Output Drive

The RCA-CD4081B, -CD4082B, and -CD4073B AND gates provide the system designer with direct implementation of the AND function and supplement the existing family of COS/MOS gates. These devices have equal source- and sink-current capabilities and conform to standard B-series output drive (see

Static Electrical Characteristics).
The CD4081B, CD4082B, and CD4073B are supplied in 14lead dual-in-line plastic packages ( $E$ ), welded-seal ceramic package (D), ceramic packages (F), ceramic flat packs (K), and chip form (H).


Fig. 1-CD4081B schematic diagram (1 of 4 identical AND gates).

## MAXIMUM RATINGS, Absolute-Maximum Values:

```
STORAGE-TEMPERATURE RANGE. . . . . . . . . . . . - -65 to +150}\mp@subsup{0}{}{\circ}\textrm{C
OPERATING-TEMPERATURE RANGE:
    CERAMIC-PACKAGE TYPES . . . . . . . . . . . . . . . -55 to +1250
    PLASTIC-PACKAGE TYPES . . . . . . . . . . . . . . - -40 to +85 }\mp@subsup{}{}{\circ}\textrm{C
DC SUPPLY-VOLTAGE RANGE
    VDD * .................................... . - 0.5 to +18 V
DEVICE DISSIPATION (PER PACKAGE) ............... }200\textrm{mW
LEAD TEMPERATURE (DURING SOLDERING):
    At distance 1/16 \pm 1/32 inch (1.59 \pm0.79 mm)
        from case for }10\mathrm{ seconds max.
        265%
```

* All voltage values are referenced to $\mathrm{V}_{\text {SS }}$ terminal.

OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be
selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing <br> (Recommended $\mathrm{V}_{\mathrm{SS}}$ to $\left.\mathrm{V}_{\mathrm{DD}}\right)$ | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> $($ Any one <br> input) | -0.5 V <br> to <br> $\mathrm{V}_{\mathrm{DD}}+$ <br> 0.5 V | V | - |

File No. 806 CD4081B, CD4082B, CD4073B

## STATIC ELECTRICAL CHARACTERISTICS

| CHARAC. TERISTIC | SYMBOL | TEST CONDITIONS |  | CD4081BD, $\mathrm{BK}, \mathrm{BF}, \mathrm{BH}$ CD4082BD, BK, BF, BHCD4073BD, BK, BF, BHCERAMIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|l} \hline V_{0} \\ \text { Volts } \end{array}$ | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 15 |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 4, 5, 16 |
|  |  | 1 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | $I_{\text {d }}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 6,7 |
| N -Channel (Sink) |  | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{\text {P }}$ | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.15 | - | - | mA | 8,9 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 1 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$, and $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$


STATIC ELECTRICAL CHARACTERISTICS

| CHARAC. TERISTIC | SYMBOL | TEST CONDITIONS |  | CD4081BE, CD4082BE, CD4073BE PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|c\|} \hline \mathrm{V}_{\mathbf{O}} \\ \text { Volts } \end{array}$ | VDD <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $\prime^{2}$ |  | 5 | - | - | 5 | - | 0.01 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 15 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL | - | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | VOH |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ |  | 5 | 1.5 | - | - | 1.5 | 2.25 | - | . 1.4 | - | - | V | 4, 5, 16 |
|  |  |  | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  |  | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | $I_{\text {d }}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 6,7 |
| N-Channel (Sink) |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 8,9 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



92CS-23827

Fig. 2-CD4082B schematic diagram (1 of 2 identical AND gates).


Fig. 3-CD4073B schematic diagram (1 of 3 identical AND gates).


Fig. 4-Typical voltage and current transfer characteristics.


Fig. 6-Typical output-N-channel drain characteristics.


Fig. 5-Min. and max. voltage transfer characteristics.


Fig. 7-Minimum output-N-channel drain characteristics.


92Cs-24320

Fig. 8-Typical output-P-channel drain characteristics.


Fig. 10-Typical high-to-low level propagation delay vs. load capacitance.


Fig. 12-Typical propagation delays vs. supply voltage.


92Cs-24321
Fig. 9-Minimum output-P-channel drain characteristics.


Fig. 11-Typical low-to-hight level propagation delay vs. load capacitance.

Fig. 13-Typical transition time vs. load capacitance.



CD40738 - PUT METER IN SAME PLACE AS CD408I
TIE PINS $1,2,3,4,5,11,12,13$
TO SWITCH

CD4082B - PUT METER IN SAME PLACE AS CD4O81
TIE PINS 2,3,4,5,9,10,11,12 TO SWITCH.

Fig. 15-Quiescent current test circuits.

Fig. 14-Typical dynamic power dissipation vs. frequency.


92CM-24535
Fig. 16-Noise immunity test circuits.

Digital Integrated Circuits
Monolithic Silicon
Solid State Division


## COS／MOS 4－Bit D－Type Register

With 3－State Outputs


The RCA－CD4076BE four－bit register includes D－type flip－ flops that feature three－state outputs．Data Disable inputs are provided to control the entry of data into the flip－flops． When both Data Disable inputs are low，data at the $D$ inputs are loaded into their respective flip－flops on the next positive transition of the clock input．Output Disable inputs are also provided．When the Output Disable inputs are both low，the normal logic states of the four outputs are available to the load． The outputs are disabled（present a high impedance）independ－ ently of the clock by a high logic level at either Output Disable input．

CD4076BE
Truth Table

|  |  | Data Input <br> Disable |  | Data | Next <br> State <br> Output <br> Reset |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | Clock | G1 | G2 | D | Q |  |
| 0 | 0 | X | X | X | 0 |  |
| 0 | - | 1 | X | X | Q | Q |
| 0 | X | 1 | X | Q | NC |  |
| 0 |  | 0 | 0 | 1 | NC |  |
| 0 |  | 0 | 0 | 0 | 0 |  |
| 0 | 1 | X | X | X | Q | NC |
| 0 | X | X | X | Q | NC |  |

When either Output Disable M or N is high，the outputs are disabled（high impedance state）；however sequential operation of the flip－flops is not affected．

$1 \equiv$ High Level
$0 \equiv$ Low Level

X＝Don＇t Care
NC＝No Change

STATIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4076B <br> TYPICAL <br> VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{\mathrm{O}}(\mathrm{V})$ | $\mathrm{V}_{\text {DD }}(\mathrm{V})$ |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | 0.02 | $\mu \mathrm{A}$ |
|  |  |  | 10 | 0.02 |  |
| Output Device Current: $N$-Channel (Sink) | ${ }^{1} \mathrm{D} N$ |  |  |  | mA |
|  |  | 0.4 | 5 | 0.8 |  |
|  |  | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | 4.6 | 5 | -0.8 |  |
|  |  | 2.5 | 5 | -3.2 |  |
|  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$

| CHARACTERISTIC | SYMBOL | $\mathrm{V}_{\text {DD }}(\mathrm{V})$ | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: |
| Propagation Delay | ${ }^{\text {tPHL, }}$ tPLH | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{aligned} & 260 \\ & 120 \end{aligned}$ | ns |
| Transition Time | ${ }^{\text {t }}$ HL, ${ }^{\text {tPLH }}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{gathered} 100 \\ 50 \end{gathered}$ | ns |
| Data Setup Time | ${ }^{\text {t }}$ SUHL, ${ }^{\text {t }}$ SULH | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{aligned} & 100 \\ & 60 \end{aligned}$ | ns |
| Minimum Clock Pulse Width | ${ }^{t}$ WL, ${ }^{\text {tWH }}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{gathered} 125 \\ 50 \end{gathered}$ | ns |
| Minimum Reset Pulse Width | ${ }^{\text {W }} \mathrm{WH}^{(R)}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{aligned} & 75 \\ & 40 \end{aligned}$ | ns |
| Reset Propagation Delay | ${ }^{\text {P PHL }}$ (R) | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{aligned} & 230 \\ & 120 \end{aligned}$ | ns |
| Data Input Disable Setup Time | ${ }^{\text {t }}$ U ${ }^{(D I S)}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{gathered} 100 \\ 60 \end{gathered}$ | ns |
| Clock Rise and Fall Time | $\mathrm{t}_{\mathrm{r}} \mathrm{CL}, \mathrm{t}_{\mathrm{f}} \mathrm{CL}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{aligned} & 15 \\ & 15 \end{aligned}$ | $\mu \mathrm{s}$ |
| Clock Frequency | ${ }^{\text {f }} \mathrm{CL}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{gathered} 4 \\ 10 \end{gathered}$ | MHz |
| 3-State Propagation Delay Output 1 or 0 to High Impedance | $\begin{aligned} & \text { tp }(\mathrm{I}-\mathrm{H}), \\ & \mathrm{tp}(\mathrm{O}-\mathrm{H}) \end{aligned}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{gathered} 110 \\ 65 \end{gathered}$ | ns |
| 3-State Propagation Delay, High Impedance to 1 or 0 | $\begin{aligned} & t_{p}(\mathrm{H}-\mathrm{I}) \\ & t_{p}(\mathrm{H}-\mathrm{O}) \end{aligned}$ | $\begin{array}{r} 5 \\ 10 \end{array}$ | $\begin{aligned} & 80 \\ & 45 \end{aligned}$ | ns |

MAXIMUM RATINGS, Absolute-Maximum Values:
STORAGE-TEMPERATURE RANGE.
-65 to $+150^{\circ} \mathrm{C}$ OPERATING-TEMPERATURE RANGE. ........... -40 to $+85{ }^{\circ} \mathrm{C}$ DC SUPPLY-VOLTAGE RANGE

$$
\begin{aligned}
& \mathrm{v}_{\mathrm{DD}} \text { * } \\
& -0.5 \text { to }+18 \mathrm{~V}
\end{aligned}
$$

DEVICE DISSIPATION (PER PACKAGE) ................. . 200 mW

LEAD TEMPERATURE (DURING SOLDERING):
At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds max. $265^{\circ} \mathrm{C}$

* All voltage values are referenced to $\mathbf{V}_{\text {SS }}$ terminal.


## OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathrm{C}$

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathbf{V}_{\mathbf{D D}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ | -0.5 V | V | - |
| (Recommended $\mathrm{V}_{\text {SS }}$ to $\mathrm{V}_{\mathrm{DD}}$ ) |  | to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> $\mathrm{V}_{\mathrm{DD}}+$ <br> (Any one <br> input) | 0.5 V |  |  |



Fig. 2-Timing diagram.

$V_{D D}=14$
$V_{S S}=7$

$$
92 C S-23877 R 1
$$

CD4078B Functional Diagram

## COS/MOS 8-Input NOR Gate

## Features:



- Standard B-series output drive

The RCA-CD4078B NOR Gate provides the system designer with direct implementation of the positive-logic 8 -input NOR
 function and supplements the existing family of COS/MOS gates.
This device has equal source- and sink-current capability and conforms to standard B-series output drive (see Static Electrical Characteristics).

The CD4078B is supplied in a 14 -lead dual-in-line welded-seal ceramic package (D), plastic package (E), frit-seal ceramic package (F), 14-lead flat package (K), and in chip form (H).

* all inputs protected by STANDARD COS/MOS PROTECTION NETWORK


Fig. 1-CD4078B schematic diagram.

## STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4078BD CD4078BF <br> CD4078BK CD4078BH <br> CERAMIC PACKAGE LIMITS  |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{V}_{\mathbf{O}} \\ \text { Volts } \end{gathered}$ | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{1} \mathrm{~L}$ |  | 5 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: |  |  |  |  |  |  |  |  |  |  |  |  | mA | 4,5 |
| N-Channel (Sink) | IDN | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D}{ }^{P}$ | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.15 | - | - | mA | 6,7 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

## MAXIMUM RATINGS, Absolute-Maximum Values:

```
STORAGE-TEMPERATURE RANGE. ............ . - -65 to +150}\mp@subsup{0}{}{\circ}\textrm{C
OPERATING-TEMPERATURE RANGE:
    CERAMIC-PACKAGE TYPES . . . . . . . . . . . . . . . - -55 to +125}\mp@subsup{}{}{\circ}\textrm{C
    PLASTIC-PACKAGE TYPES . . . . . . . . . . . . . . . - 40 to +85 %
DC SUPPLY-VOLTAGE RANGE
    VDD* ...................................... - 0.5 to +18 V
DEVICE DISSIPATION (PER PACKAGE)
LEAD TEMPERATURE (DURING SOLDERING):
    At distance 1/16 \pm 1/32 inch (1.59 \pm0.79 mm)
        from case for }10\mathrm{ seconds max.
    All voitage values are referenced to }\mp@subsup{V}{SS}{}\mathrm{ terminal.
```


## OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathrm{C}$

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathbf{V}_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $\mathrm{V}_{\mathrm{SS}}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \begin{array}{c} \text { (Any one } \\ \text { input) } \end{array} \end{gathered}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{\mathrm{DD}}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | V | - |

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4078BE <br> PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|c\|} \hline \mathrm{V}_{\mathbf{O}} \\ \text { Volts } \end{array}$ | $\begin{array}{l\|} \hline \text { VDD } \\ \text { Volts } \end{array}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} L$ |  | 5 | - | - | 5 | - | 0.01 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  | mA | 4,5 |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| N -Channel (Sink) | $I_{\text {d }}$ | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 6,7 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 11 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$, and $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$



Fig. 2-Typical voltage and current transfer characteristics.


Fig. 4-Typical output n-channel drain characteristics.


Fig. 3-Min. and max. voltage transfer characteristics.


Fig. 5-Minimum output n-channel drain characteristics.


92Cs-24320
Fig. 6-Typical output p-channel drain characteristics.

DRAIN-TO-SOURCE VOLTAGE ( $V_{D S}$ )-V


92CS-24321

Fig. 7-Minimum output p-channel drain characteristics.

File No. 810


Fig. 8-Typical high-to-low level propagation delay time vs. load capacitance.


Fig. 10-Typical propagation delay time vs. supply voltage.


92CS-24323

Fig. 12-Typical power dissipation vs. frequency.


Fig. 9-Typical low-to-high level propagation delay time vs. load capacitance.


Fig. 11-Typical transition time vs. Ioad capacitance.


Fig. 13-Quiescent device current test circuit.

Monolithic Silicon
Solid State Division

## CD4085B Type



# COS／MOS Dual 2－Wide 2－Input AND－OR－INVERT Gate 

The RCA－CD4085B contains a pair of AND－OR－INVERT gates， each consisting of two 2 －input AND gates driving a 3－input OR gate followed by an inverter．Individual inhibit controls are provided for both A－O－I gates．This device has equal source－ and sink－current capabilities and conforms to standard B－series
output drive（see Static Electrical Characteristics）．
The CD4085B is supplied in a 14－lead dual－in－line welded－seal ceramic package（D），plastic package（E），ceramic package（F）， ceramic flat pack（K），and chip form（ H ）．

## MAXIMUM RATINGS，Absolute－Maximum Values：

| orage－temperature range | -65 to $+150^{\circ} \mathrm{C}$ |
| :---: | :---: |
| OPERATING－TEMPERATURE RANGE： |  |
| CERAMIC－PACKAGE TYPES | -55 to $+125^{\circ} \mathrm{C}$ |
| PLASTIC－PACKAGE TYPES | -40 to $+85{ }^{\circ} \mathrm{C}$ |
| DC SUPPLY－VOLTAGE RANGE |  |
| $V_{\text {DD }}$＊ | -0.5 to +18 V |
| DEVICE DISSIPATION（PER PACKAGE） | 200 mW |
| ALLINPUTS．．．．．．．．．．．．．．．．．．．．．．．．．．．．．． $\mathrm{V}_{\text {S }}$ | $\leqslant \mathrm{v}_{1} \leqslant \mathrm{v}_{\mathrm{DD}}$ |
| LEAD TEMPERATURE（DURING SOLDERING）： |  |
| At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$ from case for 10 seconds max． | $265{ }^{\circ} \mathrm{C}$ |
| All voltage values |  |

OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathrm{C}$
For maximum reliability，nominal operating conditions should be selected so that operation is always within the following ranges．

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min． | Max． | Units | Fig． |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing <br> （Recommended $\mathrm{V}_{\text {SS }}$ to $\mathrm{V}_{\mathrm{DD}}$ ） | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> （Any one <br> input） | -0.5 V <br> to <br> $\mathrm{V}_{\mathrm{DD}}+$ <br> 0.5 V | V | - |



Fig. 1-CD4085B schematic diagram.

## STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4085BD CD4085BK <br> CD4085BF CD4085BH <br> CERAMIC PACKAGE LIMITS  |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $V_{0}$ <br> Volts | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 5 | - | 0.02 | 5 | - | - | 30 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 10 | - | 0.02 | 10 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.02 | - | - | - | - |  |  |
| Output Voltage Low-Level | $\mathrm{V}_{\text {OL }}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | $I_{\text {d }}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 4,5 |
| N -Channel (Sink) |  | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.15 | - | - | mA | 6,7 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



Fig. 2-Typical voltage and current transfer characteristics.


Fig. 3-Min. and max. voltage transfer characteristics.

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4085BE <br> PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{V}_{\mathrm{O}} \\ \mathrm{Volts} \end{gathered}$ | VDD <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | - | - | 5 | - | 0.01 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 13 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 14 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | $I_{\text {IN }}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 4, 5 |
| N -Channel (Sink) |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 6,7 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



DRAIN-TO-SOURCE VOLTAGE $\left(V_{D S}\right)-V$
92C5-24318


DRAIN - TO - SOURCE VOLTAGE $\left(V_{D S}\right)-V$

Fig. 5-Minimum output n-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS AT T $A=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | LIMITS |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{v}_{\mathrm{DD}}$ | Typ. | Max. |  |  |
| Propagation Delay Time (Data): High-to-Low Level | ${ }^{\text {tPHL }}$ | 5 | 225 | 450 | ns | 8, 10 |
|  |  | 10 | 90 | 180 |  |  |
|  |  | 15 | 65 | - |  |  |
| Low-to-High Level | ${ }_{\text {tPLH }}$ | 5 | 310 | 620 | ns | 9, 10 |
|  |  | 10 | 125 | 250 |  |  |
|  |  | 15 | 90 | - |  |  |
| Propagation Delay Time (Inhibit): High-to-Low Level | ${ }_{\text {tpHL }}($ INH $)$ | 5 | 150 | 300 | ns | - |
|  |  | 10 | 60 | 120 |  |  |
|  |  | 15 | 40 | - |  |  |
| Low-to-High Level | ${ }^{\text {tpLLH}}$ (INH) | 5 | 250 | 500 | ns | - |
|  |  | 10 | 100 | 200 |  |  |
|  |  | 15 | 70 | - |  |  |
| Transition Time | ${ }^{\text {t }}$ THL, ${ }^{\text {t }}$ TLH | 5 | 100 | 200 | ns | 11 |
|  |  | 10 | 50 | 100 |  |  |
|  |  | 15 | 40 | 80 |  |  |
| Average Input Capacitance | $c_{1}$ | Any Input | 5 | - | pF | - |



92C5-24320
Fig. 6-Typical output p-channel drain characteristics.


92CS-24321
Fig. 7-Minimum output p-channel drain characteristics.

File No. 811


Fig. 8-Typical data high-to-low level propagation delay time vs. load capacitance.


Fig. 10-Typical data propagation delay time vs. supply voltage.


Fig. 12-Typical power dissipation vs. frequency.


Fig. 9-Typical data low-to-high level propagation delay time vs. load capacitance.


92Cs-24322
Fig. 11-Typical transition time vs. load capacitance.


Fig. 13-Quiescent device current test circuit.


Fig. 14-Noise immunity test circuit.


Solid State Division

## Digital Integrated Circuits

Monolithic Silicon

## CD4086B Type



## COS/MOS Expandable 4-Wide 2-Input AND-OR-INVERT Gate

## Features:

- Medium-speed operation - $\mathbf{t}_{\text {PHL }}=\mathbf{9 0} \mathrm{ns}$; $\mathbf{t P L H}^{\mathbf{m}} \mathbf{1 4 0} \mathbf{n s}$ (typ.) at $\mathbf{1 0} \mathrm{V}$
- INHIBIT and ENABLE inputs
- Standard B-series output drive

The RCA-CD4086B contains one 4 -wide 2 -input AND-ORINVERT gate with an INHIBIT/EXP input and an ENABLE/ EXP input. For a 4 -wide A-O-I function INHIBIT/EXP is tied to $\mathrm{V}_{\mathrm{SS}}$ and ENABLE/EXP to $\mathrm{V}_{\mathrm{DD}}$. See Fig. 2 and its associated explanation for applications where a capability greater than 4 -wide is required. This device has equal source- and
sink-current capabilities and conforms to standard B-series output drive (see Static Electrical Characteristics).
The CD4086B is supplied in the 14 -lead dual-in-line weldedseal ceramic package (D), ceramic package (F), plastic package $(E)$, ceramic flat pack ( $K$ ), and in chip form ( $H$ ).

MAXIMUM RATINGS, Absolute-Maximum Values:

| RAGE-TEMPERATURE RANGE. ............... -65 to $+150^{\circ} \mathrm{C}$ OPERATING-TEMPERATURE RANGE: |  |
| :---: | :---: |
|  |  |
| CERAMIC-PACKAGE TYPES | -55 to $+125^{\circ} \mathrm{C}$ |
| PLASTIC-PACKAGE TYPES | -40 to $+85{ }^{\circ} \mathrm{C}$ |
| DC SUPPLY-VOLTAGE RANGE |  |
| $\mathrm{V}_{\text {DD }}{ }^{*} \ldots \ldots \ldots \ldots . . . . . . .$. |  |
| DEVICE DISSIPATION (PER PACKAGE) |  |
| LEAD TEMPERATURE (DURING SOLDERING): |  |
| At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) |  |
| from case for 10 seconds m | $265^{\circ} \mathrm{C}$ |

* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.

OPERATING CONDITIONS AT TA $=25^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathbf{D D}}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | v | - |
| Input Voltage Swing (Recommended $\mathbf{V}_{\mathbf{S S}}$ to $\mathbf{V}_{\mathbf{D D}}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \text { (Any one } \\ \text { input) } \end{gathered}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{v}_{\mathrm{DD}}+ \\ 0.5 \mathrm{v} \end{gathered}$ | v | - |



Fig. 1-CD4086B schematic diagram.


Fig. 2-Two CD4086B's connected as an 8-wide 2-input A-O-I gate.

Fig. 2 above shows two CD4086B's utilized to obtain an 8 -wide 2 -input A-O-I function. The output (J1) of one CD4086B is fed directly to the ENABLE/EXP2 line of the second CD4086B. In a similar fashion, any NAND gate
output can be fed directly into the ENABLE/EXP input to obtain a 5 -wide A-O-I function. In addition, any AND gate output can be fed directly into the INHIBIT/EXP input with the same result.

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4086BD CD4086BK <br> CD4086BF CD4086BH <br> CERAMIC PACKAGE LIMITS  |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{\mathrm{O}}$ <br> Volts | VDD Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $\underline{125}{ }^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }_{1} \mathrm{~L}$ |  | 5 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 14 |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 15 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | IDN |  |  |  |  |  |  |  |  |  |  |  | mA | 5,6 |
| N-Channel (Sink) |  | 0.4 | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - |  |  |
|  |  | 0.5 | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.15 | - | - | mA | 7,8 |
|  |  | 4.6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |
|  |  | 9.5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



Fig. 3-Typical voltage and current transfer characteristics.


Fig. 4-Min. and max. voltage transfer characteristics.

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4086BE <br> PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|c\|} \hline \text { VO } \\ \text { Volts } \end{array}$ | VDD <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | - | - | 5 | - | 0.01 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 14 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | VOL |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | VNL | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 15 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | ${ }^{\prime} \mathrm{DN}$ |  |  |  |  |  |  |  |  |  |  |  | mA | 5,6 |
| $\begin{aligned} & \text { N-Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 7,8 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



92CS-24318
Fig. 5-Typical output n-channel drain characteristics.


92CS-24319
Fig. 6-Minimum output n-channel drain characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=\mathbf{2 5}^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | LIMITS |  | UNITS | Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | VDD Volts | TYP. | MAX. |  |  |
| Propagation Delay Time (Data): <br> High-to-Low Level | ${ }^{\text {tPHL }}$ | 5 | 225 | 450 | ns | 9,11 |
|  |  | 10 | 90 | 180 |  |  |
|  |  | 15 | 60 | - |  |  |
| Low-to-High Level | tPLH | 5 | 350 | 700 | ns | 10, 11 |
|  |  | 10 | 140 | 280 |  |  |
|  |  | 15 | 100 | - |  |  |
| Propagation Delay Time (Inhibit): High-to-Low Level | ${ }^{\text {tPHL }}$ (INH) | 5 | 150 | 300 | ns | - |
|  |  | 10 | 60 | 120 |  |  |
|  |  | 15 | 40 | - |  |  |
| Low-to-High Level | tPLH(INH) | 5 | 250 | 500 | ns | - |
|  |  | 10 | 100 | 200 |  |  |
|  |  | 15 | 70 | - |  |  |
| Transition Time | ${ }^{\mathrm{t}}$ THL. <br> ${ }^{t}$ TLH | 5 | 100 | 200 | ns | 12 |
|  |  | 10 | 50 | 100 |  |  |
|  |  | 15 | 40 | 80 |  |  |
| Average Input Capacitance | $C_{1}$ | Any Input | 5 | - | pF | - |



Fig. 7-Typical output p-channel drain characteristics.


Fig. 8-Minimum output p-channel drain characteristics.


Fig. 9-Typical DATA or ENABLE high-to-low level propagation delay time vs. load capacitance.


Fig. 10-Typical DATA or ENABLE low-to-high level propagation delay time vs. load capacitance.


Fig. 12-Typical transition time vs. load capacitance.


Fig. 13-Typical power dissipation vs. frequency.


Fig. 14-Quiescent device current test circuit.


Fig. 15-Noise immunity test circuit.


## COS／MOS Binary Rate Multiplier

The RCA－CD4089B is a low－power 4－bit digital rate multiplier that provides an output pulse rate that is the clock－input－pulse rate multiplied by $1 / 16$ times the binary input．For example， when the binary input number is 13 ，there will be 13 output pulses for every 16 input pulses．This device may be used to perform arithmetic operations（add，subtract，divide，raise to a power），solve algebraic and differential equations，generate natural and trigonometric functions，$A / D$ and $D / A$ conversions， and frequency division．

For words of more than 4 bits CD4089B devices may be cascaded in two different modes：an Add mode and a Multiply mode（see Figs． 3 and 4）．In the Add mode some of the gaps left by the more significant unit at the count of 15 are filled in by the less significant units．For example，when two units are cascaded in the Add mode and programmed to 11 and 13， respectively，the more significant unit will have 11 output pulses for every 16 input pulses and the other unit will have 13 output pulses for every 256 input pulses for a total of

$$
\frac{11}{16}+\frac{13}{256}=\frac{189}{256}
$$

In the Multiply mode the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second multiplier．Thus the output rate will be

$$
\frac{11}{16} \times \frac{13}{16}=\frac{143}{256}
$$

The CD4089B has an internal synchronous 4－bit counter which， together with one of the four binary input bits，produces pulse trains as shown in Fig． 1.
If more than one binary input bit is high，the resulting pulse train is a combination of the above separate pulse trains．

сьок ЛЛЛЛЛЛЛЛЛЛЛЛЛЛЛЛ


[^17]Fig．1－Timing diagram．

STATIC ELECTRICAL CHARACTERISTICS AT TA $=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\overline{v_{0}}$ | $v_{D D}$ $\mathbf{v}$ |  |  |
| Quiescent Device Current | ${ }^{\prime} L$ |  | 5 | 0.02 | $\mu \mathrm{A}$ |
|  |  |  | 10 | 0.02 |  |
| Output Drive Current: All Outputs N-Channel (Sink) |  | 0.4 | 5 | 0.8 | mA |
|  | ${ }^{\prime} N$ | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }^{1} D^{P}$ | 4.6 | 5 | -0.8 |  |
|  |  | 2.5 | 5 | -3.2 |  |
|  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT TA $=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}$ $\overline{\mathbf{v}}$ |  |  |
| Propagation Delay | ${ }^{\text {tpHL}}$, <br> ${ }^{\text {tpLH}}$ | Clock to "Out" | 5 | 180 | ns |
|  |  |  | 10 | 90 |  |
|  |  | Clock to "Inhibit Out" | 5 | 260 |  |
|  |  |  | 10 | 130 |  |
| Transition Time | ${ }^{\mathrm{t}}$ TLH, <br> ${ }^{\mathrm{t}}$ THL |  | 5 | 100 | ns |
|  |  |  | 10 | 50 |  |
| Maximum Clock Frequency | ${ }^{\text {f }}$ CL (Max.) |  | 5 | 2 | MHz |
|  |  |  | 10 | 4.5 |  |
| Maximum Clock Rise and Fall Time | $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ (Max.) |  | 5 | 15 | $\mu \mathrm{s}$ |
|  |  |  | 10 |  |  |

MAXIMUM RATINGS, Absolute-Maximum Values:

-65 to $+150^{\circ} \mathrm{C}$
OPERATING-TEMPERATURE RANGE -40 to $+85^{\circ} \mathrm{C}$
DC SUPPLY-VOLTAGE RANGE

DEVICE DISSIPATION (PER PACKAGE) . . . . . . . . . . . . . 200 mW
ALL INPUTS . . . . . . . . . . . . . . . . . . . . . . . . . . . $V_{S S} \leqslant V_{I} \leqslant V_{D D}$
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds max. $265^{\circ} \mathrm{C}$

* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.

OPERATING CONDITIONS AT TA $=25^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| $\begin{array}{l}\text { Input Voltage Swing } \\ \text { (Recommended } \mathrm{V}_{\text {SS }} \text { to } \mathrm{V}_{\mathrm{DD}} \text { ) }\end{array}$ | - | $\begin{array}{r}0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to }\end{array}$ | -0.5 V | V | - |
| to |  |  |  |  |  |
| $0.8 \mathrm{~V}_{\mathrm{DD}}$ |  |  |  |  |  |
| (Any one |  |  |  |  |  |
| input) |  |  |  |  |  |$)$

$\qquad$

TRUTH TABLE

| Inputs |  |  |  |  |  |  |  |  |  | Number of Pulses or Output Logic Level ( H or L) |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| D | C | B | A | No. of Clock Pulses | Inhin | Strobe | Cascade | Clear | Set | $\begin{aligned} & \text { Pin } 6 \\ & \text { OUT } \end{aligned}$ | $\overline{\text { Pin } 5}$ | Pin 7 <br> Inh OUT | $\begin{aligned} & \text { Pin } 1 \\ & \text { " } 15 \text { " } \end{aligned}$ |
| 0 | 0 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | L | H | 1 | 1 |
| 0 | 0 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |
| 0 | 0 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 2 | 2 | 1 | 1 |
| 0 | 0 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 3 | 3 | 1 | 1 |
| 0 | 1 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 4 | 4 | 1 | 1 |
| 0 | 1 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 5 | 5 | 1 | 1 |
| 0 | 1 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 6 | 6 | 1 | 1 |
| 0 | 1 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 7 | 7 | 1 | 1 |
| 1 | 0 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 0 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 0 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 10 | 10 | 1 | 1 |
| 1 | 0 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 11 | 11 | 1 | 1 |
| 1 | 1 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 12 | 12 | 1 | 1 |
| 1 | 1 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 13 | 13 | 1 | 1 |
| 1 | 1 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 14 | 14 | 1 | 1 |
| 1 | 1 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 15 | 15 | 1 | 1 |
| X | X | X | X | 16 | 1 | 0 | 0 | 0 | 0 | Depends on internal state of counter |  |  |  |
| X | X | X | X | 16 | 0 | 1 | 0 | 0 | 0 | L | H | 1 | 1 |
| X | X | X | X | 16 | 0 | 0 | 1 | 0 | 0 | H | * | 1 | 1 |
| 1 | X | X | X | 16 | 0 | 0 | 0 | 1 | 0 | 16 | 16 | H | L |
| 0 | X | X | X | 16 | 0 | 0 | 0 | 1 | 0 | L | H | H | L |
| X | X | X | X | 16 | 0 | 0 | 0 | 0 | 1 | L | H | L | H |

* Output same as the first 16 lines of this truth table (depending on values of $A, B, C, D$ ).


Fig. 2-Logic diagram, CD4089B.


Fig. 3-Two CD4089B's cascaded in the "Add" mode with a preset number of 189.


Fig. 4-Two CD4089B's cascaded in the "Multiply" mode with a preset number of 143.


Solid State Division

## Digital Integrated Circuits

Monolithic Silicon
CD4093B Type


CD4093B Functional Diagram

## COS/MOS Quad 2-Input NAND Schmitt Triggers

Features:

- Schmitt-trigger action on each input with no external components
- Hysteresis voltage typically 0.6 V at $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ and 2 V at $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$
- Noise immunity greater than 50\%
- Equal source and sink currents
- No limit on input rise and fall times
- Standard B-series output drive

The RCA-CD4093B consists of four Schmitt-trigger circuits. Each circuit functions as a two-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive- and negative-going signals. The difference between the positive voltage ( $V_{P}$ ) and the negative voltage ( $\mathrm{V}_{\mathrm{N}}$ ) is defined as hysteresis voltage ( $\mathrm{V}_{\mathrm{H}}$ ) (see Fig. 2).
All outputs have equal source and sink currents and conform to standard B-series output drive (see Static Electrical Characteristics).

The CD4093B is supplied in 14 -lead dual-in-line plastic packages (E), welded-seal ceramic packages (D), ceramic packages (F), ceramic flat packs (K), and in chip form (H).


92CS-2388।

Fig. 1-Functional diagram-1 of 4 Schmitt triggers.

## Applications:

- Wave and pulse shapers
- High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators
- NAND logic

MAXIMUM RATINGS, Absolute-Maximum Values:
Storage-temperature range. . . . . . . . . . . . . -65 to $+150^{\circ} \mathrm{C}$ OPERATING-TEMPERATURE RANGE:

$$
\text { CERAMIC-PACKAGE TYPES . . . . . . . . . . . . . . . . . } 55 \text { to }+125^{\circ} \mathrm{C}
$$

$$
\text { PLASTIC-PACKAGE TYPES . . . . . . . . . . . . . . . . }-40 \text { to }+85^{\circ} \mathrm{C}
$$ DC SUPPLY-VOLTAGE RANGE

$$
\text { DEVICE DISSIPATION (PER PACKAGE) . . . . . . . . . . . . . . } 200 \mathrm{~mW}
$$

$$
\text { ALL INPUTS.................................... } v_{S S} \leqslant v_{1} \leqslant v_{D D}
$$

LEAD TEMPERATURE (DURING SOLDERING):
At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$ from case for 10 seconds max.

* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.

OPERATING CONDITIONS AT TA $=\mathbf{2 5}^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> (Recommended $\mathrm{V}_{\text {SS }}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | -0.5 V <br> to | V | - |
|  |  | (Any one <br> input) | $\mathrm{V}_{\mathrm{DD}}+$ <br> 0.5 V |  |  |

File No. 836 $\qquad$

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4093BD, BF, BK, BH CERAMIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\stackrel{v_{0}}{\mathbf{v}}$ | $\begin{gathered} \mathrm{v}_{\mathrm{DD}} \\ \mathrm{~V} \end{gathered}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | - | - | 0.5 | - | 0.01 | 0.5 | - | - | 30 | $\mu \mathrm{A}$ | 20 |
|  |  |  | 10 | - | - | 1 | - | 0.01 | 1 | - | - | 60 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Positive Trigger Threshold Voltage | $V_{P}$ |  | 5 | - | 3 | - | 2.3 | 2.9 | 3.5 | - | 2.9 | - | V | 2.4 |
|  |  |  | 10 | - | 5.9 | - | 4.5 | 5.9 | 7 | - | 5.9 | - |  |  |
|  |  |  | 15 | - | - | - | - | 8.9 | - | - | - | - |  |  |
| Negative Trigger Threshold Voltage | $\mathrm{V}_{N}$ |  | 5 | - | 2.6 | - | 1.5 | 2.3 | 2.7 | - | 2.1 | - | V | 2,4 |
|  |  |  | 10 | - | 4 | - | 3 | 3.9 | 5.5 | - | 3.8 | - |  |  |
|  |  |  | 15 | - | - | - | - | 5.4 | - | - | - | - |  |  |
| Hysteresis Voltage | $\mathrm{V}_{\mathrm{H}}$ |  | 5 | - | 0.4 | - | 0.4 | 0.6 | - | - | 0.8 | - | V | 2,4 |
|  |  |  | 10 | - | 1.9 | - | 1 | 2 | - | - | 2.1 | - |  |  |
|  |  |  | 15 | - | - | - | - | 3.5 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0 | 5 | - | 3 | - | 2.3 | 2.9 | 3.5 | - | 2.9 | - | V | 3, 21 |
|  |  | 0 | 10 | - | 5.9 | - | 4.5 | 5.9 | 7 | - | 5.9 | - |  |  |
|  |  | 0 | 15 | - | - | - | - | 8.9 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 5 | 5 | - | 2.2 | - | 2.3 | 2.7 | 3.5 | - | 2.9 | - |  |  |
|  |  | 10 | 10 | - | 6 | - | 4.5 | 6.1 | 7 | - | 6.2 | - |  |  |
|  |  | 15 | 15 | - | - | - | - | 9.6 | - | - | - | - |  |  |
| Output Drive Current: <br> N -Channel (Sink) | ${ }^{1} \mathrm{D} N$ | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - | mA | 6,7 |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 8,9 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERIStIC | SYMBOL | TEST CONDITIONS |  | CD4093BE <br> PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{array}{\|c\|} \hline v_{0} \\ v \end{array}$ | $\begin{gathered} \mathbf{v}_{\mathrm{DD}} \\ \mathrm{v} \end{gathered}$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{1}$ |  | 5 | - | - | 5 | - | 0.01 | 5 | - | - | 70 | $\mu \mathrm{A}$ | 20 |
|  |  |  | 10 | - | - | 10 | - | 0.01 | 10 | - | - | 140 |  |  |
|  |  |  | 15 | - | - | - | - | 0.01 | - | - | - | - |  |  |
| Output Voltage: Low-Level | $\mathrm{v}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | v | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Positive Trigger Threshold Voltage | $\mathrm{v}_{\mathrm{p}}$ |  | 5 | - | 3 | - | 2.3 | 2.9 | 3.5 | - | 2.9 | - | $v$ | 2,4 |
|  |  |  | 10 | - | 5.9 | - | 4.5 | 5.9 | 7 | - | 5.9 | - |  |  |
|  |  |  | 15 | - | - | - | - | 8.9 | - | - | - | - |  |  |
| Negative Trigger Threshold Voltage | $\mathrm{v}_{\mathrm{N}}$ |  | 5 | - | 2.6 | - | 1.5 | 2.3 | 2.7 | - | 2.1 | - | v | 2,4 |
|  |  |  | 10 | - | 4 | - | 3 | 3.9 | 5.5 | - | 3.8 | - |  |  |
|  |  |  | 15 | - | - | - | - | 5.4 | - | - | - | - |  |  |
| Hysteresis Voltage | $\mathrm{V}_{\mathrm{H}}$ |  | 5 | - | 0.4 | - | 0.4 | 0.6 | - | - | 0.8 | - | $v$ | 2,4 |
|  |  |  | 10 | - | 1.9 | - | 1 | 2 | - | - | 2.1 | - |  |  |
|  |  |  | 15 | - | - | - | - | 3.5 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0 | 5 | - | 3 | - | 2.3 | 2.9 | 3.5 | - | 2.9 | - | v | 3, 21 |
|  |  | 0 | 10 | - | 5.9 | - | 4.5 | 5.9 | 7 | - | 5.9 | - |  |  |
|  |  | 0 | 15 | - | - | - | - | 8.9 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 5 | 5 | - | 2.2 | - | 2.3 | 2.7 | 3.5 | - | 2.9 | - |  |  |
|  |  | 10 | 10 | - | 6 | - | 4.5 | 6.1 | 7 | - | 6.2 | - |  |  |
|  |  | 15 | 15 | - | - | - | - | 9.6 | - | - | - | - |  |  |
| Output Drive Current: N -Channel (Sink) | ${ }^{1} \mathrm{D}$ N | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - | mA | 6,7 |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P.Channel (Source) | ${ }_{1}{ }^{P}$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 8,9 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 1 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

File No. 836

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathbf{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$, and $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | ALL TYPES LIMITS |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | VDD <br> Volts | Typ. | Max. |  |  |
| Propagation Delay Time | ${ }^{\text {tPHL}}$. ${ }^{\text {tpLLH}}$ | 5 10 15 | $\begin{aligned} & 300 \\ & 150 \\ & 120 \\ & \hline \end{aligned}$ | $\begin{aligned} & \hline 600 \\ & 300 \\ & 240 \\ & \hline \end{aligned}$ | ns | 10, 12 |
| Transition Time | ${ }^{t}$ THL <br> ${ }^{t}$ TLH | 5 10 15 | 100 50 40 | $\begin{array}{r} 200 \\ 100 \\ 80 \\ \hline \end{array}$ | ns | 11 |
| Average Input Capacitance | $\mathrm{C}_{1}$ | Any Input | 5 | - | pF | - |


a) Definition of $V_{P} V_{N}$, and $V_{H}$

b) Transfer characteristic of 1 of 4 gates

c) Test setup

Fig. 2-Hysteresis definition, characteristic, and test setup.
92CM-23882


Fig. 3-Input and output characteristics.


Fig. 5-Typical voltage transfer characteristics as a function of temperature.


Fiq. 4-Typical current and voltage transfer characteristics.


DRAIN-TO-SOURCE VOLTAGE ( $\mathrm{V}_{\mathrm{DS}}$ )-V 92CS-24318
Fig. 6-Typical output-N-channel drain characteristics.


Fig. 7-Minimum output-N-channel drain characteristics.

DRAIN - TO-SOURCE VOLTAGE ( $V_{D S}$ )- $V$


92Cs-24321
Fig. 9-Minimum output-P-channel drain characteristics.


Fig. 11-Typical transition time vs. Ioad capacitance.


92cs-24320
Fig. 8-Typical output-P-channel drain characteristics.


Fig. 10-Typical propagation delay time vs. supply voltage.


Fig. 12-Propagation delay and transition time test circuit.


Fig. 13-Typical trigger threshold voltage vs. $V_{D D}$.


92cs-24832
Fig. 14-Typical per cent hysteresis vs. supply voltage.


Fig. 15-Typical dissipation characteristics.

Fig. 16-Power dissipation vs. rise and fall times.



Fig. 17-Wave shaper.

Fig. 18-Monostable multivibrator. 92cs-23886


Fig. 19-Astable multivibrator.
Fig. 20-Quiescent device current test circuit.
Fig. 21-Noise immunity test circuit.


# COS／MOS 8－Stage Shift－and－Store Bus Register 

The RCA－CD4094B is an 8 －stage serial shift register having a storage latch associated with each stage for strobing data from the serial input to parallel buffered 3 －state outputs．Data is shifted on positive clock transitions．The data in each shift register stage is transferred to the storage register when the strobe input is high．Data in the storage register appears at the outputs whenever the output－enable signal is high．
Two serial outputs are available for cascading a number of CD4094B devices．Data is available at the O＇S serial output terminal on positive clock edges to allow for high－speed operation in cascaded systems in which the clock rise time is fast．The same serial information，available at the O＇S terminal on the next negative clock edge，provides a means for cascading CD4094B devices when the clock rise time is slow．
The CD4094B is supplied in a 16 －lead dual－in－line plastic package．

[^18]TRUTH TABLE

| CL ${ }^{\text {4 }}$ | Output Enable | Strobe | Data | $\begin{aligned} & \mathbf{Q}_{1} \\ & \text { Out } \end{aligned}$ | $\mathbf{a}_{\mathrm{N}}$ Out |  | $\mathbf{Q}_{\mathbf{S}}^{\prime}$ <br> Serial <br> Output |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 0 | $x$ | X | OC | OC | Q7 | NC |
|  | 0 | $x$ | $x$ | OC | OC | NC | 07 |
|  | 1 | 0 | $x$ | NC | NC | 07 | NC |
|  | 1 | 1 | 0 | 0 | $\mathrm{a}_{\mathrm{N}-1}$ | 07 | NC |
|  | 1 | 1 | 1 | 1 | $\mathrm{a}_{\mathrm{N}-1}$ | Q7 | NC |
|  | 1 | 1 | 1 | NC | NC | NC | 07 |

$4=$ Level Change
Logic $1 \equiv$ High
X＝Don＇t Care
Logic $0 \equiv$ Low
NC＝No Change
OC $=$ Open Circuit

OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=25^{\circ} \mathrm{C}$
For maximum reliability，nominal operating conditions should be selected so that operation is always within the following ranges．

| Characteristic | $V_{D D}$ | Min． | Max． | Units | Fig． |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | － | 3 | 18 | V | － |
| Input Voltage Swing （Recommended $V_{S S}$ to $V_{D D}$ ） | － | $\begin{gathered} \hline 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \begin{array}{c} \text { Any one } \\ \text { input) } \end{array} \\ \hline \end{gathered}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{v}_{\mathrm{DD}}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | v | － |

STATIC ELECTRICAL CHARACTERISTICS AT TA $=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $v_{0}$Volts |  | $V_{D D}$ Volts |  |  |
| Quiescent Device Current | $I_{L}$ |  |  | 5 | 0.5 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 | 1 |  |
| Output Drive Current: |  |  |  |  |  | mA |
| N -Channel (Sink) | ${ }^{1} \mathrm{D} N$ | $V_{1}=V_{\text {SS }}$ | 0.4 | 5 | 0.8 |  |
|  |  |  | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | $V_{1}=V_{D D}$ | 4.6 | 5 | -0.8 |  |
|  |  |  | 2.5 | 5 | -3.2 |  |
|  |  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$ (except $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ and $\mathrm{t}_{\mathrm{f}} \mathrm{CL}$ )

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: |
|  |  | $V_{D D}$ <br> Volts |  |  |
| Propagation Delay Time: <br> Clock to Serial Out $\mathrm{Q}_{\mathrm{S}}$ | $\begin{aligned} & \mathrm{t}_{\mathrm{PHL}} \\ & \mathrm{t}^{\prime} \end{aligned}$ |  |  | ns |
|  |  | 5 | 300 |  |
|  |  | 10 | 120 |  |
| Clock to Serial Out $\mathrm{Q}^{\prime}$ S |  | 5 | 215 |  |
|  |  | 10 | 90 |  |
| Clock to Parallel Out |  | 5 | 375 |  |
|  |  | 10 | 150 |  |
| Strobe to Parallel Out |  | 5 | 300 |  |
|  |  | 10 | 120 |  |
| Output Enable to Output |  | 5 | 175 |  |
|  |  | 10 | 70 |  |
| Transition Time | ${ }^{\mathrm{t}}$ THL, <br> ${ }^{t}$ TLH | 5 | 100 | ns |
|  |  | 10 | 50 |  |
| Minimum Strobe Pulse Width | ${ }^{t}$ WL, <br> ${ }^{t}$ WH | 5 | 75 | ns |
|  |  | 10 | 40 |  |
| Clock Rise and Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{r}} \mathrm{CL}, \\ & \mathrm{t}_{\mathrm{f}} \mathrm{CL} \end{aligned}$ | 5 | $>15$ | $\mu \mathrm{s}$ |
|  |  | 10 | $>15$ |  |
| Setup Time | ${ }^{\text {t }} \mathrm{SU}$ | 5 | 45 | ns |
|  |  | 10 | 30 |  |
| Maximum Clock Frequency | ${ }^{\mathrm{f}} \mathrm{CL}$ <br> (50\% Duty Cycle) | 5 | 2 | MHz |
|  |  | 10 | 4 |  |
| Average Input Capacitance | $C_{1}$ | Any Input | 5 | pF |



Solid State Division

Digital Integrated Circuits
Monolithic Silicon
Preliminary CD4095BE
Preliminary CD4096BE


## COS/MOS Gated J-K Master-Slave Flip-Flops

With Set-Reset Capability
CD4095B Non-Inverting J and K Inputs
CD4096B Inverting and Non-Inverting J and K Inputs

SYNCHRONOUS OPERATION ( $\mathbf{S}=0, \mathrm{R}=0$ )

| Inputs Before Positive Clock Transition |  | Inputs After Positive Clock Transition |  |
| :---: | :---: | :---: | :---: |
| J* | K* | 0 | $\overline{\mathbf{0}}$ |
| 0 | 0 | No Change |  |
| 0 | 1 | 0 | 1 |
| 1 | 0 | 1 | 0 |
| 1 | 1 | Toggles |  |

*For CD4095B
$\mathrm{J}=\mathrm{J} 1 \cdot \mathrm{~J} 2 \cdot \mathrm{~J} 3$
$K=K 1 \cdot K 2 \cdot K 3$
For CD4096B
$\mathrm{J}=\mathrm{J} 1 \cdot \mathrm{~J} 2 \cdot \sqrt{3}$
$K=K 1 \cdot K 2 \cdot \overline{K 3}$
Flops featuring separate AND4096B are.JK Master/Slave FlipThe gated JK inputs control transfer of information into the master section during clocked operation. Information on the JK inputs is transferred to the $\mathbf{Q}$ and $\overline{\mathrm{Q}}$ outputs on the positive edge of the clock pulse. SET and RESET inputs (active high). are provided for asynchronous operation.
The CD4095B and CD4096B are supplied in 14-lead dual-inline plastic packages (CD4095BE, CD4096BE).
MAXIMUM RATINGS, Absolute-Maximum Values:

| STORAGE-TEMPERATURE RANGE. | -65 to $+150^{\circ} \mathrm{C}$ |
| :---: | :---: |
| OPERATING-TEMPERATURE RANGE. | -40 to $+85{ }^{\circ} \mathrm{C}$ |
| DC SUPPLY-VOLTAGE RANGE: |  |
| ( $V_{\text {DD }}{ }^{*}$ ) | -0.5 to +18 V |
| DEVICE DISSIPATION (PER PACKAGE) | 200 mW |
| ALL INPUTS . | $\leqslant \mathrm{V}_{1} \leqslant \mathrm{~V}_{\mathrm{DD}}$ |
| LEAD TEMPERATURE (DURING SOLD |  |
| At distance $1 / 16 \pm 1 / 32 \mathrm{in}$. (11.59 $\pm 0.79$ |  |
| from case for 10 s max. . | $+265^{\circ} \mathrm{C}$ |

[^19]OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\mathbf{\circ}} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing <br> (Recommended $\mathrm{V}_{\text {SS }}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> (Any one <br> input) | -0.5 V <br> to <br> $\mathrm{V}_{\mathrm{DD}}+$ <br> 0.5 V | V | - |

STATIC ELECTRICAL CHARACTERISTICS AT TA $=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4095B, CD4096B TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{v}_{0}$ | $\mathrm{V}_{\text {DD }} \mathrm{V}^{\text {SS }}$ |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | 0.01 | $\mu \mathrm{A}$ |
|  |  |  | 10 | 0.02 |  |
| Output Device Current: <br> N -Channel (Sink) | ${ }^{1} \mathrm{DN}$ |  |  |  | mA |
|  |  | 0.4 | 5 | 0.8 |  |
|  |  | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | 4.6 | 5 | -0.8 |  |
|  |  | 2.5 | 5 | -1.8 |  |
|  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4095B, CD4096B TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{0}$ | $\mathrm{V}_{\text {DD }}{ }^{-\mathrm{V}_{\text {SS }}}$ |  |  |
| Clocked Operation (Synchronous) |  |  |  |  |  |
| Propagation Delay Time | ${ }^{\mathrm{t}} \mathrm{PHL}$. <br> ${ }^{\text {tpLH}}$ |  | 5 | 200 | ns |
|  |  |  | 10 | 100 |  |
| Transition Time | ${ }^{t}$ THL, <br> ${ }^{t}$ TLH |  | 5 | 100 | ns |
|  |  |  | 10 | 50 |  |
| Minimum Clock Pulse Width | ${ }^{t}$ WL. <br> ${ }^{t}$ WH |  | 5 | 75 | ns |
|  |  |  | 10 | 30 |  |
| Maximum Clock Rise and Fall Time | $\begin{aligned} & \mathrm{t}_{\mathrm{r}} \mathrm{CL}, \\ & \mathrm{t}_{\mathrm{f}} \mathrm{CL} \end{aligned}$ |  | 5 | 15 | $\mu \mathrm{s}$ |
|  |  |  | 10 | 5 |  |
| Setup Time | ${ }^{\text {t }}$ SUHL. <br> ${ }^{\text {t SULH }}$ |  | 5 | 150 | ns |
|  |  |  | 10 | 75 |  |
| Maximum Clock Frequency (Toggle Mode) | ${ }^{\mathrm{f}} \mathrm{CL}$ |  | 5 | 6 | MHz |
|  |  |  | 10 | 16 |  |
| Set and Reset Operation (Asynchronous) |  |  |  |  |  |
| Propagation Delay Time | $\begin{aligned} & \text { tPHL(R), } \\ & t_{\text {PLLH }}(\mathrm{S}) \\ & \hline \end{aligned}$ |  | 5 | 175 | ns |
|  |  |  | 10 | 85 |  |
| Minimum Pulse Width | $\begin{aligned} & { }^{t} W H(S) \\ & { }^{2} W H(R) \end{aligned}$ |  | 5 | 100 | ns |
|  |  |  | 10 | 50 |  |
| Average Input Capacitance | $\mathrm{C}_{1}$ | Any Input |  | 5 | pF |

## Digital Integrated Circuits

Monolithic Silicon

Preliminary CD4098BE

# COS/MOS Dual Monostable Multivibrator 

Retriggerable/Resettable

Features:

- Trigger propagation delays independent of $\mathrm{R}_{\mathbf{X}}, \mathrm{C}_{\mathbf{X}}$
- Triggering from leading or trailing edge
- $\mathbf{Q}$ and $\overline{\mathrm{Q}}$ buffered outputs available
- Separate resets
- Wide range of output-pulse widths
- Equal source and sink currents


## Applications:

- Pulse delay and
timing
- Pulse shaping
- Astable Multivibrator

The RCA CD4098BE dual monostable multivibrator provides stable retriggerable/resettable one-shot operation for any fixedvoltage timing application.
An external resistor ( $R_{X}$ ) and an external capacitor ( $C_{X}$ ) control the timing for the circuit. Adjustment of $R_{X}$ and $C_{X}$ provides a wide range of output pulse widths from the $\mathbf{Q}$ and $\overline{\mathrm{Q}}$ terminals. The time delay from trigger input to output transition (trigger propagation delay) is independent of $R_{X}$ and $C_{X}$.
Leading-edge-triggering ( $+T_{R}$ ) and trailing-edge-triggering ( $-T_{R}$ ) inputs are provided for triggering from either edge of an input pulse. An unused $+T_{R}$ input should be tied to $V_{S S}$. An unused $-T_{R}$ input should be tied to $V_{\text {DD }}$. A RESET (on low level) is provided for immediate termination of the output pulse or to prevent output pulses when power is turned on. An unused RESET input should be tied to $\mathrm{V}_{\text {DD }}$. However, if an entire
MAXIMUM RATINGS, Absolute-Maximum Values:

| STORAGE-TEMPERATURE RANGE | -65 to +150 |
| :---: | :---: |
| OPERATING-TEMPERATURE RANGE | -40 to +85 |
| DC SUPPLY-VOLTAGE RANGE |  |
| $V_{\text {DD }}$ * | -0.5 to +18 |
| DEVICE DISSIPATION (PER PKG.) | 200 |
| ALL INPU | $. \mathrm{v}_{\text {SS }} \leqslant \mathrm{v}$ |

OPERATING CONDITIONS AT $\mathrm{T}_{A}=\mathbf{2 5}^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathbf{V}_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $V_{S S}$ to $V_{D D}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \left(\begin{array}{c} \text { Any one } \\ \text { input }) \end{array}\right. \end{gathered}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{\mathrm{DD}}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | V | - |

* All voltage values are referenced to $\mathrm{V}_{\mathbf{S S}}$ terminal.
section of the CD4098BE is not used, its RESET should be tied to $\mathrm{V}_{\mathrm{SS}}$. See Table I.
In normal operation, the circuit retriggers on the application of each new pulse. To prevent retriggering when leading-edge triggering is used, $\overline{\mathbf{Q}}$ must be connected to $-T_{R}$. To prevent retriggering when trailing-edge triggering is used, $\mathbf{O}$ must be connected to ${ }^{+} \mathrm{T}_{\mathbf{R}}$.
The time period ( $T$ ) for this multivibrator can be approximated by: $T_{X}=R_{X} C_{X}$. Time periods as a function of $R_{X}$ for values of $C_{X}$ and $V_{D D}$ are given in Fig. 1.
All outputs are independently buffered to provide equal soiurce- and sink-current capabilities. The CD4098BE is available in a 16 -lead dual-in-line plastic package (CD4098BE). This device is similar to type MC14528.


Fig. $1-R_{X}$ vs. time period for various values of $V_{D D}$ and $C_{X}$.

TABLE I
CD4098BE FUNCTIONAL TERMINAL CONNECTIONS

| FUNCTION | TO V ${ }_{\text {DD }}$ |  | TO V ${ }_{\text {SS }}$ |  | INPUT PULSE TO |  | OTHER CONNECTIONS |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mathrm{MONO}_{1}$ | $\mathrm{MONO}_{2}$ | $\mathrm{MONO}_{1}$ | $\mathrm{MONO}_{2}$ | $\mathrm{MONO}_{1}$ | $\mathrm{MONO}_{2}$ | $\mathrm{MONO}_{1}$ | $\mathrm{MONO}_{2}$ |
| LEADING-EDGE TRIGGER/ <br> RETRIGGERABLE | 3, 5 | 11, 13 |  |  | 4 | 12 |  |  |
| LEADING-EDGE TRIGGER/ NON-RETRIGGERABLE | 3 | 13 |  |  | 4 | 12 | 5.7 | $11-9$ |
| TRAILING-EDGE <br> TRIGGER/ RETRIGGERABLE | 3 | 13 | 4 | 12 | 5 | 11 |  |  |
| TRAILING-EDGE TRIGGER/ NON-RETRIGGERABLE | 3 | 13 |  |  | 5 | 11 | 4.6 | 12-10 |
| UNUSED SECTION | 5 | 11 | 3, 4 | 12, 13 |  |  |  |  |

## NOTES:

1. A RETRIGGERABLE ONE-SHOT MULTIVIBRATOR HAS A TIME PERIOD TX REFERENCED FROM THE APPLICATION OF THE LAST INPUT PULSE.
2. A NON-RETRIGGERABLE ONE-SHOT MULTIVIBRATOR HAS A TIME PERIOD $T_{X}$ REFERENCED FROM THE APPLICATION OF THE FIRST INPUT PULSE.

## INPUT PULSE TRAIN

RETRIGGERABLE MODE PULSE WIDTH (+TR MODE)

आ几几


NON-RETRIGGERABLE MODE PULSE
WIDTH
(+TR MODE)


Fig. 2 - CD4098BE dual monostable multivibrator logic diagram.

Preliminary CD4098BE
STATIC ELECTRICAL CHARACTERISTICS at TA $_{\text {A }}=\mathbf{2 5} \mathbf{~} \mathbf{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{V}_{\mathrm{DD}}$ VOLTS |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | 0.01 | $\mu \mathrm{A}$ |
|  |  |  | 10 | 0.02 |  |
| Quiescent Device Dissipation/ Package | PD |  | 5 | 0.05 | $\mu \mathrm{W}$ |
|  |  |  | 10 | 0.2 |  |
| Noise Immunity (Any Input) | $V_{\text {NL }}$ | 0.8 | 5 | 2.25 | V |
|  |  | 1 | 10 | 4.5 |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 5 | 2.25 |  |
|  |  | 9 | 10 | 4.5 |  |
| Output Drive Current:$\qquad$ | ${ }^{1} \mathrm{D} N$ | 0.4 | 5 | 0.8 | mA |
|  |  | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }^{\prime}{ }^{P}$ | 4.6 | 5 | -0.8 | mA |
|  |  | 9.5 | 10 | -1.8 |  |
|  |  | 2.5 | 5 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}, \mathrm{t}_{\mathrm{f}}}=\mathbf{2 0} \mathrm{ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | $\begin{gathered} \mathrm{v}_{\mathrm{DD}} \\ \mathrm{v} \end{gathered}$ | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{R}_{\mathrm{X}}(\mathrm{k} \Omega$ ) | $\mathrm{C}_{\mathrm{X}}(\mathrm{pF})$ |  |  |  |
| Trigger Propagation Delay Time$\text { +TR, }-T R \text { to } Q, \bar{\alpha}$ | ${ }^{t}$ PLH. ${ }^{\text {t PHL }}$ | 5 | 15 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 350 \\ & 125 \end{aligned}$ | ns |
|  |  | 10 | 1000 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 350 \\ & 125 \end{aligned}$ |  |
| Minimum Trigger Pulse Width | ${ }^{t}$ WL. ${ }^{t}$ WH | 5 | 15 | $\begin{gathered} \hline 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 75 \\ & 30 \end{aligned}$ | ns |
|  |  | 10 | 1000 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 75 \\ & 30 \end{aligned}$ |  |
| Transition Time | ${ }^{\mathrm{t}} \mathrm{tHL}$. <br> ${ }^{t}$ TLH | 5 | 15 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{array}{r} 100 \\ 50 \end{array}$ | ns |
|  |  | 10 | 1000 | $\begin{gathered} \hline 5 \\ 10 \end{gathered}$ | $\begin{array}{r} 125 \\ 75 \end{array}$ |  |
| Reset Propagation Delay Time | ${ }^{\text {t }}$ PLH. <br> ${ }^{\text {t }}$ PHL | 5 | 15 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 400 \\ & 150 \end{aligned}$ | ns |
|  |  | 10 | 1000 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{array}{r} 1100 \\ 700 \end{array}$ |  |
| Minimum Reset Pulse Width | ${ }^{\text {t W }}$ L | 5 | 15 | $\begin{gathered} \hline 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 50 \\ & 25 \\ & \hline \end{aligned}$ | ns |
|  |  | 10 | 1000 | $\begin{gathered} \hline 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 750 \\ & 500 \end{aligned}$ |  |
| Average Input Capacitance | $\mathrm{C}_{1}$ | Any Input |  |  | 5 | pF |

## APPLICATIONS



Fig. 3 - Pulse delay.


Fig. 4 - Astable multivibrator.

## Solid State Division

## Preliminary CD4099BE



The RCA-CD4099B 8-bit addressable latch is a serial-input, parallel-output storage register that can perform a variety

Data is input to a particular bit in the latch when that bit is addressed (by means of inputs AO, A1, A2) and when WRITE DISABLE is at a low level. When WRITE DISABLE is high, data entry is inhibited; however, all 8 outputs can be continuously read independent of WRITE DISABLE and address

A master RESET input is available, which resets all bits to a logic " 0 " level when RESET and WRITE DISABLE are at a high level. When RESET is at a high level, and WRITE DISABLE is at a low level, the latch acts as a 1-of-8 demultiplexer; the bit that is addressed has an active output which follows the data input, while all unaddressed bits are held to a logic " 0 " level.
The CD4099B is supplied in a 16 -lead dual-in-line plastic
of functions. inputs. package (CD4099BE).

## COS/MOS 8-Bit Addressable Latch

| MODE SELECTION |  |  |  |
| :---: | :---: | :---: | :---: |
| Write Disable | Reset | Addressed Latch | Unaddressed Latch |
| 0 | 0 | Follows Data | Holds Previous State |
| 0 | 1 | (Active High 8-Channel Demultiplexer) |  |
|  |  |  |  |
| 1 | 0 | Holds Previous State | Holds Previous State |
| 1 | 1 | Reset to "0" | Reset to "0" |

## MAXIMUM RATINGS, Absolute-Maximum Values:

Storage-temperature range. . . . . . . . . . . . . . 65 to $+150^{\circ} \mathrm{C}$ OPERATING-TEMPERATURE RANGE. ........... -40 to $+85{ }^{\circ} \mathrm{C}$ DC SUPPLY-VOLTAGE RANGE:

DEVICE DISSIPATION (PER PACKAGE) ................. 200 mW

LEAD TEMPERATURE (DURING SOLDERING)
At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 s max.
$+265^{\circ} \mathrm{C}$

* All voltage values are referenced to $\mathrm{V}_{\text {SS }}$ terminal.


## OPERATING CONDITIONS AT $T_{A}=25^{\circ} \mathrm{C}$

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing <br> (Recommended $\mathrm{V}_{\text {SS }}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $0.2 \mathrm{~V}_{\mathrm{DD}}$ <br> to <br> $0.8 \mathrm{~V}_{\mathrm{DD}}$ <br> (Any one <br> input) | -0.5 V <br> to <br> $\mathrm{V}_{\mathrm{DD}}+$ <br> 0.5 V | V | - |



STATIC ELECTRICAL CHARACTERISTICS at TA $_{\text {A }}=\mathbf{2 5}^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{gathered} \mathrm{V}_{\mathrm{O}} \\ \text { Volts } \end{gathered}$ | $V_{D D}$ Volts |  |  |
| Quiescent Device Current | 'L |  |  | 5 | 0.01 | $\mu \mathrm{A}$ |
|  |  |  |  | 10 | 0.02 |  |
| Output Drive Current: N-Channel (Sink) | ${ }^{1} \mathrm{~N}$ | $V_{1}=V_{D D}$ | 0.4 | 5 | 0.8 | mA |
|  |  |  | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }_{1}{ }^{P}$ | $V_{1}=V_{S S}$ | 4.6 | 5 | -0.8 | mA |
|  |  |  | 2.5 | 5 | -3.2 |  |
|  |  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$


[^20]


## COS/MOS Strobed Hex Inverter/Buffer

## Special Features:

- 2-TTL-Load Output-Drive Capability
- 3-State Outputs
- Common Output-Disable Control
- Inhibit Control


## Applications:

- 3-State Hex Inverter for Interfacing IC's with Data Buses
- COS/MOS-to-TTL Hex Buffer

RCA-CD4502B contains six inverter/buffers with 3 -state outputs. When the disable control input is at a logical 1, all six outputs become high impedance ( $>10 \mathrm{M} \Omega$ ). This feature simplifies design by allowing common bussing of the outputs.
The CD4502B is also provided with an inhibit control which, when at logical 1 , switches all six outputs to logical 0 .
The CD4502B is supplied in a 16 -lead dual-in-line plastic package (CD4502BE).
This device is similar to type MC14502.
OPERATING CONDITIONS AT $T_{A}=25^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathbf{V}_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $V_{S S}$ to $V_{D D}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \text { (Any one } \\ \text { input) } \end{gathered}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{\mathrm{DD}}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | V | - |


| MAXIMUM RATINGS, Absolute-Maximum Values: |  |
| :---: | :---: |
| STORAGE-TEMPERATURE RANGE. . . . . . . . . . . -65 to $+150^{\circ} \mathrm{C}$ |  |
| OPERATING-TEMPERATURE RANGE: |  |
| CERAMIC-PACKAGE TYPES | -55 to $+125^{\circ} \mathrm{C}$ |
| PLASTIC-PACKAGE TYPES | -40 to $+85{ }^{\circ} \mathrm{C}$ |
| DC SUPPLY-VOLTAGE RANGE |  |
| $V_{\text {DD }}$ | -0.5 to +18 V |
| DEVICE DISSIPATION (PER PACKAGE) | 200 mW |
| LEAD TEMPERATURE (DURING SOLDERING): |  |
| At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds max. | $265^{\circ} \mathrm{C}$ |
| * All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal. |  |

MAXIMUM RATINGS, Absolute-Maximum Values:
STORAGE-TEMPERATURE RANGE . . . . . . . . . . . . . -65 to $+\mathbf{1 5 0 ^ { \circ }} \mathbf{C}$ PERATING-TEMPERATURE RANGE:
CERAMIC-PACKAGE TYPES . . . . . . . . . . . . . . . . . -55 to $+125^{\circ} \mathrm{C}$
PLASTIC-PACKAGE TYPES . . . . . . . . . . . . . . . . . . -40 to +85 ${ }^{\circ} \mathrm{C}$ VOLTAGE RANGE

EVICE DISSIPATION (PER PACKAGE) . . . . . . . . . . . . . 200 mW
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ )
from case for 10 seconds max. . . . . . . . . . . . . . . . . . . $265^{\circ} \mathrm{C}$

* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.


STATIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL VALUES | UNITS | CHARACTERISTIC CURVES AND TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{V}_{0}$ | VDD |  |  |  |
| Quiescent Device Current | 'L |  |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 0.002 \\ & 0.004 \end{aligned}$ | $\mu \mathrm{A}$ | - |
| Quiescent Device Dissipation/Package | PD |  |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 0.01 \\ & 0.04 \end{aligned}$ | $\mu \mathrm{W}$ | - |
| Output Voltage: <br> Low Level | $\mathrm{V}_{\mathrm{OL}}$ | $\begin{aligned} & V_{1}=V_{D D} \\ & I_{O}=0 \end{aligned}$ |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | V | - |
| High Leve! | VOH | $\begin{aligned} & V_{1}=V_{S S} \\ & I_{O}=0 \end{aligned}$ |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | V | - |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | $10=0$ | 4.2 <br> 9 | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{gathered} 2.25 \\ 3.5 \\ \hline \end{gathered}$ | V | - |
|  | $\mathrm{V}_{\mathrm{NH}}$ |  | $\begin{gathered} \hline 0.8 \\ 1 \\ \hline \end{gathered}$ | $\begin{gathered} \hline 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{gathered} 2.25 \\ 6.5 \\ \hline \end{gathered}$ | V | - |
| Output Drive Current : n-Channel (Sink) | IDN | $V_{1}=V_{\text {DD }}$ | $\begin{aligned} & 0.4 \\ & 0.5 \end{aligned}$ | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{gathered} 5.7 \\ 12.5 \end{gathered}$ | mA | 4 |
| p-Channel (Source) | $I_{0} P$ | $\mathrm{V}_{1}=\mathrm{V}_{\text {SS }}$ | 4.6 2.5 9.5 | 5 5 10 | $\begin{aligned} & -0.8 \\ & -3.2 \\ & -1.8 \end{aligned}$ | mA | 5 |



92CM-24098

Fig. 2 - Data transition times \& delay times test circuit \& waveforms.
$\qquad$

DYNAMIC CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}$ AND $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{tf}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS | CHARACTERISTIC CURVES AND TEST CIRCUITS Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\begin{gathered} \mathrm{V}_{\mathrm{DD}} \end{gathered}$ |  |  |  |
| Data or Inhibit Delay Times: High to Low | ${ }^{t}{ }^{\text {PHL}}$ |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{array}{r} 135 \\ 55 \end{array}$ | ns | 2 |
| Low to High | ${ }^{\text {tpLH }}$ |  | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 295 \\ & 130 \end{aligned}$ | ns |  |
| Disable Delay Times: Output 1 to High Impedance | t1-H | See Fig. 3 | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 65 \\ & 30 \end{aligned}$ | ns | 3 |
| High Impedance to Output 1 | ${ }_{\text {ther }}$ |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{aligned} & 260 \\ & 105 \end{aligned}$ | ns |  |
| Output 0 to High Impedance | ${ }^{\text {to. }} \mathrm{H}$ |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{aligned} & 150 \\ & 70 \\ & \hline \end{aligned}$ | ns |  |
| High Impedance to Output 0 | ${ }^{\mathrm{t}} \mathrm{H} \cdot \mathrm{O}$ |  | $\begin{gathered} 5 \\ \hline 5 \\ \hline \end{gathered}$ | $\begin{array}{r} 160 \\ 65 \\ \hline \end{array}$ | ns |  |
| Transition Times: Low to High | tLLH |  | $\begin{gathered} 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{aligned} & 100 \\ & 50 \end{aligned}$ | ns | 2 |
| High to Low | THL |  | $\begin{gathered} \hline 5 \\ 10 \\ \hline \end{gathered}$ | $\begin{aligned} & 40 \\ & 20 \\ & \hline \end{aligned}$ | ns |  |
| Average Input Capacitance | $\mathrm{Cl}_{1}$ |  |  | 5 | pF |  |



Fig. 3 - Disable delay times test circuit and waveforms.


Fig. 4 - Typical n-channel drain characteristics.


92CS-24320
Fig. 8-Typical output-P-channel drain characteristics.


Monolithic Silicon
Solid State
Division
Preliminary CD4511BE


The RCA-CD4511B is a BCD-to-Seven-Segment Latch Decoder Driver constructed with COS/MOS logic and n-p-n bipolar transistor output drivers on a single monolithic structure. This device combines the low quiescent power dissipation and high noise immunity features of RCA COS/MOS with n-p-n bipolar output transistors capable of sourcing up to 25 mA . This capability allows the CD4511B to drive LED's and other displays directly.

Lamp Test ( $\overline{\mathrm{LT}}$ ) Blanking ( $\overline{\mathrm{BI}) \text { and Latch Enable (LE) inputs }}$ are provided to test the display, shut off or intensity modulate it, and store a BCD code, respectively. Several different signals may be multiplexed and displayed when external multiplexing circuitry is used.
The CD4511B is supplied in a 16 -lead dual-in-line plastic package (CD4511BE).
This device is similar to type MC14511.

## OPERATING CONDITIONS AT $\mathbf{T}_{\mathbf{A}}=\mathbf{2 5}^{\circ} \mathrm{C}$

For maximum reliability, nominal operating conditions should be
selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $\mathrm{V}_{\text {SS }}$ to $\mathrm{V}_{\text {DD }}$ ) | - | $\begin{array}{\|c\|} \hline 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \text { (Any one } \\ \text { input) } \end{array}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{D D}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | V | - |

STATIC ELECTRICAL CHARACTERISTICS AT T ${ }_{A}=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{I}_{\mathrm{OH}}$ $\mathrm{mA}$ | $\mathrm{V}_{\mathrm{OL}}$ | $v_{D D}$ $\bar{v}$ |  |  |
| Quiescent Device Current | $I_{L}$ |  |  | 5 | 5 | nA |
|  |  |  |  | 10 | 10 |  |
| Output Drive Voltage | $\mathrm{V}_{\mathrm{OH}}$ | 0 |  | 5 | 4.5 | V |
|  |  | 10 |  | 5 | 4.1 |  |
|  |  | 25 |  | 5 | 3.5 |  |
| High-Level (Source) |  | 0 |  | 10 | 9.5 |  |
|  |  | 10 |  | 10 | 9.1 |  |
|  |  | 25 |  | 10 | 8.7 |  |
| Output Drive Current (Sink) | ${ }^{\prime} \mathrm{OL}$ |  | 0.4 | 5 | 0.8 | mA |
|  |  |  | 0.5 | 10 | 2 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT T ${ }_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=\mathbf{1 5} \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}, \mathrm{t}_{\mathrm{f}}}=\mathbf{2 0} \mathrm{ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $V_{D D}$ <br> V |  |  |
| Propagation Delay: High-to-Low | ${ }^{\text {tPHL }}$ |  | 5 | 720 | ns |
|  |  |  | 10 | 290 |  |
| Low-to-High | ${ }^{\text {tPLH }}$ |  | 5 | 640 |  |
|  |  |  | 10 | 250 |  |
| Transition Time: High-to-Low | ${ }^{\text {t }}$ THL |  | 5 | 30 | ns |
|  |  |  | 10 | 17 |  |
| Low-to-High | ${ }^{\text {t }}$ LLH |  | 5 | 1000 |  |
|  |  |  | 10 | 1000 |  |
| Setup Time | ${ }^{\text {t }}$ SU | . | 5 | 90 | ns |
|  |  |  | 10 | 38 |  |
| Hold Time | ${ }^{\text {theld }}$ |  | 5 | -90 | ns |
|  |  |  | 10 | -38 |  |
| Minimum Latch Enable Pulse Width | ${ }^{t} W^{(L E)}$ |  | 5 | 260 | ns |
|  |  |  | 10 | 110 |  |
| Average Input Capacitance | $C_{1}$ | Any Input |  | 5 | pF |

TRUTH TABLE

| LE | $\overline{\text { BI }}$ | $\overline{L T}$ | D | C | B | A |  | a | b | c | d |  |  | $f$ | g | Display |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| X | X | 0 | X | X | X | X |  | 1 | 1 | 1 |  |  |  | 1 | 1 | $\square$ |
| X | 0 | 1 | X | X | X | $x$ |  | 0 | 0 | 0 | 0 |  |  | 0 | 0 | Blank |
| 0 | 1 | 1 | 0 | 0 | 0 | 0 |  | 1 | 1 | 1 | 1 |  |  | 1 | 0 |  |
| 0 | 1 | 1 | 0 | 0 | 0 | 1 |  | 0 | 1 | 1 | 0 |  |  | 0 | 0 | $\dagger$ |
| 0 | 1 | 1 | 0 | 0 | 1 | 0 |  | 1 | 1 | 0 | 1 |  |  | 0 | 1 |  |
| 0 | 1 | 1 | 0 | 0 | 1 | 1 |  | 1 | 1 | 1 | 1 | 0 |  | 0 | 1 |  |
| 0 | 1 | 1 | 0 | 1 | 0 | 0 |  | 0 | 1 | 1 | 0 | 0 |  | 1 | 1 |  |
| 0 | 1 | 1 | 0 | 1 | 0 | 1 |  | 1 | 0 | 1 | 1 | 0 |  | 1 | 1 |  |
| 0 | 1 | 1 | 0 | 1 | 1 | 0 |  | 0 | 0 | 1 | 1 | 1 |  | 1 | 1 |  |
| 0 | 1 | 1 | 0 | 1 | 1 | 1 |  | 1 | 1 | 1 | 0 | 0 |  | 0 | 0 |  |
| 0 | 1 | 1 | 1 | 0 | 0 | 0 |  | 1 | 1 | 1 | 1 | 1 |  | 1 | 1 |  |
| 0 | 1 | 1 | 1 | 0 | 0 | 1 |  |  | 1 | 1 | 0 | 0 |  | 1 | 1 |  |
| 0 | 1 | 1 | 1 | 0 | 1 | 0 |  | 0 | 0 | 0 | 0 | 0 |  | 0 | 0 | Blank |
| 0 | 1 | 1 | 1 | 0 | 1 | 1 |  | 0 | 0 | 0 | 0 | 0 |  |  | 0 | Blank |
| 0 | 1 | 1 | 1 | 1 | 0 | 0 |  | 0 | 0 | 0 | 0 | 0 |  |  | 0 | Blank |
| 0 | 1 | 1 | 1 | 1 | 0 | 1 |  | 0 | 0 | 0 | 0 | 0 |  |  | 0 | Blank |
| 0 | 1 | 1 | 1 | 1 | 1 | 0 |  | 0 | 0 | 0 | 0 | 0 |  |  | 0 | Blank |
| 0 | 1 | 1 | 1 | 1 | 1 | 1 |  |  |  | 0 | 0 |  |  | 0 | 0 | Blank |
| 1 | 1 | 1 |  |  | X | X |  |  |  |  |  |  |  |  |  | * |

Note: Display is blank for all illegal input codes ( $B C D>1001$ ).


Solid State Division

Digital Integrated Circuits
Monolithic Silicon CD4514B Types CD4515B Types


## COS/MOS 4-Bit Latch/4-to-16 Line Decoder

CD4514B Output "High" on Select CD4515B Output "Low" on Select

Features:

- Strobed input latch
m Inhibit control

The RCA-CD4514B ${ }^{\mathbf{A}}$ and -CD4515BA ${ }^{\text {are monolithic integrated }}$ circuits consisting of a 4 -bit strobed latch and a 4-to-16line decoder. The latches hold the last input data presented prior to the strobe transition from 1 to 0 . Inhibit control allows all outputs to be placed at 0 (CD4514B) or 1 (CD4515B) regardless of the state of the data or strobe inputs.
The decode truth table indicates all combinations of data inputs and appropriate selected outputs.
These devices are supplied in 24 -lead ceramic packages. They are also available in chip form. These devices are similar to the types MC14514 and MC14515.
Formerly CD4064A and CD4065A, respectively.

MAXIMUM RATINGS, Absolute-Maximum Values:


* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.


## Applications:

- Digital multiplexing
- Address decoding
- Hexadecimal/BCD decoding
- Program-counter decoding
- Control decoder

DECODE TRUTH TABLE (Strobe $=1$ )

| INHIBIT | DATA INPUTS |  |  |  | SELECTED OUTPUT CD4514B = Logic 1 (High) CD4515B = Logic 0 (Low) |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | D | C | B | A |  |
| 0 | 0 | 0 | 0 | 0 | So |
| 0 | 0 | 0 | 0 | 1 | S1 |
| 0 | 0 | 0 | 1 | 0 | S2 |
| 0 | 0 | 0 | 1 | 1 | S3 |
| 0 | 0 | 1 | 0 | 0 | S4 |
| 0 | 0 | 1 | 0 | 1 | S5 |
| 0 | 0 | 1 | 1 | 0 | S6 |
| 0 | 0 | 1 | 1 | 1 | S7 |
| 0 | 1 | 0 | 0 | 0 | S8 |
| 0 | 1 | 0 | 0 | 1 | S9 |
| 0 | 1 | 0 | 1 | 0 | S10 |
| 0 | 1 | 0 | 1 | 1 | S11 |
| 0 | 1 | 1 | 0 | 0 | S12 |
| 0 | 1 | 1 | 0 | 1 | S13 |
| 0 | 1 | 1 | 1 | 0 | S14 |
| 0 | 1 | 1 | 1 | 1 | S15 |
| 1 | X | X | X | X | $\begin{aligned} & \text { All Outputs }=0, \text { CD4514B } \\ & \text { All Outputs }=1, \text { CD4515B } \\ & \hline \end{aligned}$ |

X = Don't Care

## OPERATING CONDITIONS AT TA $=25^{\circ} \mathrm{C}$

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $V_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| -Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $V_{S S}$ to $V_{D D}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \end{gathered}$ <br> (Any one input) | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{\mathrm{DD}}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | V | - |
| Setup Time | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 250 \\ & 100 \end{aligned}$ | None | ns | A |
| Strobe Pulse Width | $\begin{gathered} 5 \\ 10 \end{gathered}$ | $\begin{aligned} & 350 \\ & 100 \end{aligned}$ | None | ns | A |



Fig. A-Waveforms for setup time and strobe pulse width.


92CL-23770RI

File No. 814

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | CERAMIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{0}$ (V) |  | $\mathrm{V}_{\mathrm{DD}}$$\mathbf{v}$ | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  | - | $\bullet$ |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  |  | 5 | - | - | 5 | - | 0.02 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 3 |
|  |  |  |  | 10 | - | - | 10 | - | 0.02 | 10 | - | - | 600 |  |  |
|  |  |  |  | 15 | - | - | - | - | 0.02 | - | - | - | - |  |  |
| Output Voltage Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity Any Input | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 2 |
|  |  | 1 | 9 | 10 | 3 | - | -- | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 1.5 | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 4.2 | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 9 | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 13.5 | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: <br> N -Channel (Sink) | IDN | 0.4 |  | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | -. | mA | 4.7.8 |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
|  |  |  | . 5 | 10 | 1.1 | - | - | 0.9 | 2 | - | 0.65 | - |  |  |  |
|  |  |  | . 5 | 15 | - | - | - | - | 7.8 | - | - | - | - |  |  |
| P-Channel (Source) | $1^{1} P$ |  | . 6 | 5 | -0.25 | - | - | -0.2 | -0.4 | - | -0.15 | - | - | mA | 4, 9,10 |
|  |  |  | . 5 | 5 | -1 | - | - | -0.8 | -1.6 | - | -0.60 | - | - |  |  |
|  |  |  | . 5 | 10 | -0.62 | - | - | -0.5 | -0.9 | - | -0.35 | - | - |  |  |
|  |  |  | 3.5 | 15 | - | - | - | - | -3.5 | - | - | - | - |  |  |
| Input Current | $1 /$ | Any | Input | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

## $\triangle$ For CD4514B

- For CD4515B


Fig. 2-Noise immunity test circuit.


Fig. 3-Quiescent device current test circuit.

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}$; Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}, \mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathrm{pF}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | LIMITS |  | UNITS | CHARACTERISTIC CURVES \& TEST CKTS. Fig. No. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{DDD}} \\ & \text { Volts } \end{aligned}$ | TYP. | MAX. |  |  |
| Propagation <br> Delay Time: <br> Strobe or Data $\qquad$ <br> Inhibit | ${ }^{\text {tpHL }}$. <br> ${ }^{\text {tpLH }}$ | 5 | 550 | 1100 | ns | 6, 11, 15 |
|  |  | 10 | 225 | 450 |  |  |
|  |  | 15 | 150 | - |  |  |
|  |  | 5 | 400 | 800 |  |  |
|  |  | 10 | 150 | 300 |  | 6,12 |
|  |  | 15 | 100 | - |  |  |
| Transition Time: <br> High-to-Low | ${ }^{\text {t }}$ THL | 5 | 100 | 200 | ns | 6, 14 |
|  |  | 10 | 50 | 100 |  |  |
|  |  | 15 | 40 | 80 |  |  |
| Low-to-High | ${ }^{\text {T }}$ LH | 5 | 200 | 400 |  | 6,13 |
|  |  | 10 | 100 | 200 |  |  |
|  |  | 15 | 80 | 160 |  |  |
| Average Input Capacitance | $C_{1}$ | Any Input | 5 | - | pF | - |



92CS-24541

Fig. 4-Drain characteristics test circuit.


Fig. 5-Dynamic power dissipation test circuit and waveform.


Fig. 6-Switching time test circuit and waveforms.


92CS-24543


Fig. 7-Typical output-N-channel drain characteristics.


92CS-24545

Fig. 8-Minimum output-N-channel drain characteristics.


Fig. 9-Typical output-P-channel drain characteristics.


Fig. 11-Typical strobe or data propagation delay time vs. load capacitance.


Fig. 13-Typical low-to-high transition time vs. load capacitance.

DRAIN-TO-SOURCE VOLTAGE $\left(V_{D S}\right)-V$


Fig. 10-Minimum output-P-channel drain characteristics.


Fig. 12-Typical inhibit propagation delay time vs. load capacitance.


Fig. 14-Typical high-to-fow transition time
vs. load capacitance.


Solid State Division

## Digital Integrated Circuits

Monolithic Silicon
CD4518B Types CD4520B Types


# COS/MOS Dual Up Counters 

CD4518B Dual BCD Up Counter
CD4520B Dual Binary Up Counter
Features:

- Medium-speed operation - 6-MHz typical clock frequency at 10 V
- Positive- or negative-edge triggering
- Standard B-series output drive
- Synchronous internal carry propagation


## Applications:

- Multistage synchronous counting
- Multistage ripple counting
- Synchronous frequency dividers

The RCA-CD4518B* Dual BCD Up Counter and CD4520B* Dual Binary Up Counter each consist of two identical, internally synchronous 4 -stage counters. The counter stages are D-type flip-flops having interchangeable Clock and Enable lines for incrementing on either the positive-going or negative-going transition. For single-unit operation the Enable input is maintained "high" and the counter advances on each positive-going transition of the Clock. The counters are cleared by high levels on their Reset lines.

The counter can be cascaded in the ripple mode by connecting Q4 to the enable input of the subsequent counter while the clock input of the latter is held low.
All outputs have equal source- and sink-current capabilities and conform to standard B-Series output drive (see Static Electrical Characteristics).
The CD4518B and CD4520B are available in 16 -lead dual-inline plastic packages ( E ), dual-in-line welded-seal ceramic packages (D), dual-in-line ceramic packages (F), ceramic flat packs (K), and in chip form (H).
These devices are similar to types MC14518 and MC14520.

* Formerly CD4083A and CD4084A, respectively.

MAXIMUM RATINGS, Absolute-Maximum Values:
STORAGE-TEMPERATURE RANGE. . . . . . . . . . . . . -65 to $+150^{\circ} \mathrm{C}$
OPERATING-TEMPERATURE RANGE:
CERAMIC-PACKAGE TYPES . . . . . . . . . . . . . . . . -55 to $+125^{\circ} \mathrm{C}$
PLASTIC-PACKAGE TYPES . . . . . . . . . . . . . . . . . -40 to $+85{ }^{\circ} \mathrm{C}$
DC SUPPLY-VOLTAGE RANGE

DEVICE DISSIPATION (PER PACKAGE) . ................ 200 mW
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$ from case for 10 seconds max.
$265^{\circ} \mathrm{C}$
© All voltage values are referenced to $\mathrm{V}_{\text {SS }}$ terminal.

OPERATING CONDITIONS AT TA $=\mathbf{2 5}{ }^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $V_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $V_{S S}$ to $V_{D D}$ ) | - | $\begin{array}{\|c\|} \hline 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \text { (Any one } \\ \text { in put) } \end{array}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{\mathrm{DD}}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | v | - |
| Enable Pulse Width | $\begin{gathered} 5 \\ 10 \\ 15 \\ \hline \end{gathered}$ | $\begin{aligned} & 440 \\ & 200 \\ & 140 \end{aligned}$ | None | ns | - |
| Clock Pulse Width | 5 10 15 | $\begin{array}{r} 200 \\ 100 \\ 70 \end{array}$ | None | ns | - |
| Clock Input Frequency | $\begin{gathered} 5 \\ 10 \\ 15 \end{gathered}$ | DC | $\begin{aligned} & 1.5 \\ & 3 \\ & 4 \end{aligned}$ | MHz | - |
| Clock or Enable Input Rise or Fall Time | 4-15 | None | 15 | $\mu \mathrm{s}$ | - |
| Reset Pulse Width | $\begin{gathered} 5 \\ 10 \\ 15 \end{gathered}$ | $\begin{array}{r} 250 \\ 110 \\ 80 \end{array}$ | None | ns | - |

## STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  |  | CD4518BD, BF, BK, BH CD4520BD, BF, BK, BH CERAMIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $V_{0}$ Volts |  | VDD <br> Volts | $-55^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $125^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  |  |  | 5 | - | - | 5 | - | 0.02 | 5 | - | - | 300 | $\mu \mathrm{A}$ | 16 |
|  |  |  |  | 10 | - | - | 10 | - | 0.02 | 10 | - | - | 600 |  |  |  |
|  |  |  |  | 15 | - | - | - | - | 0.02 | - | - | - | - |  |  |  |
| Output Voltage Low-Level | VOL |  |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |  |
|  |  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |  |
|  |  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |  |
|  |  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |  |
|  |  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 15 |  |
|  |  | 1 | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |  |
|  |  | 1.5 | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |  |
|  | VNH | 0.8 | 4.2 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |  |
|  |  | 1 | 9 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |  |
|  |  | 1.5 | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |  |
| Output Drive Current: <br> N -Channel (Sink) | $I_{\text {IN }}$ | 0.4 |  | 5 | 0.5 | - | - | 0.4 | 0.8 | - | 0.3 | - | - | mA | 4,5 |  |
|  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
|  |  | 0.5 |  | 10 | 1.1 | - | - | 0.9 | 1.8 | - | 0.65 | - | - |  |  |  |
|  |  | 1.5 | . 5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |  |
| P-Channel (Source) | $I^{\prime} P$ | 2.5 | . 5 | 5 | -2 | - | - | -1.6 | -3.2 | - | -1.2 | - | - | mA | 6,7 |  |
|  |  |  | . 6 | 5 | -0.5 | - | - | -0.4 | -0.8 | - | -0.3 | - | - |  |  |  |
|  |  | 9.5 | . 5 | 10 | -1.1 | - | - | -0.9 | -1.8 | - | -0.65 | - | - |  |  |  |
|  |  |  | 3.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |  |
| Input Current | 1 |  |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |  |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$, and $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | ALL TYPES LIMITS |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | VDD Volts | Typ. | Max. |  |  |
| Propagation Delay Time: Clock or Enable to Output | ${ }^{t} \mathrm{PHL}$. <br> ${ }^{\text {tPLH}}$ |  | 5 <br> 10 <br> 15 | $\begin{array}{r} 280 \\ 115 \\ 80 \end{array}$ | $\begin{gathered} 560 \\ 230 \\ - \end{gathered}$ | ns | 8 |
| Reset to Output |  |  | 5 10 15 | $\begin{array}{r} 330 \\ 130 \\ 90 \end{array}$ | $\begin{gathered} 660 \\ 260 \\ - \\ \hline \end{gathered}$ | ns | 8 |
| Transition Time | ${ }^{\mathrm{t}}$ THL, <br> ${ }^{\text {t TLH }}$ |  | 5 10 15 | $\begin{array}{r} 100 \\ 50 \\ 40 \end{array}$ | $\begin{array}{r} 200 \\ 100 \\ 80 \end{array}$ | ns | 9 |
| Average Input Capacitance | $C_{1}$ | Any Input |  | 5 | - | pF | - |

File No. 808

STATIC ELECTRICAL CHARACTERISTICS

| CHARAC. TERISTIC | SYMBOL | TEST CONDITIONS |  | CD4518BE, CD4520BE PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. <br> NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{O}} \\ & \text { Volts } \end{aligned}$ | $\left.\begin{array}{\|l\|} \hline \text { VDD } \\ \text { Volts } \end{array} \right\rvert\,$ | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | ${ }^{\text {L }}$ L |  | 5 | - | - | 50 | - | 0.02 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 16 |
|  |  |  | 10 | - | - | 100 | - | 0.02 | 100 | - | - | 1400 |  |  |
|  |  |  | 15 | - | - | - | - | 0.02 | - | - | - | - |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity | $\mathrm{V}_{\mathrm{NL}}$ | 0.8 4.2 <br> 1  | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 15 |
|  |  | 179 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 1.5 13.5 <br> 0.8  | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 4.2 <br> 1  | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | $1{ }^{1} 9$ | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | ${ }^{1} \mathrm{D} N$ |  |  |  |  |  |  |  |  |  |  |  | mA | 4,5 |
| $\begin{aligned} & \text { N-Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | 6,7 |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.36 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | 1 |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |



Fig. 1-Decade counter (CD4518B) logic diagram for one of two identical counters.

TRUTH TABLE


Fig. 2-Binary counter (CD4520B) logic diagram for one of two identical counters.


Fig. 3-Timing diagrams for CD4518B and CD4520B.


Fig. 5-Minimum output-N-channel drain characteristics.


Fig. 6-Typical output-P-channel drain characteristics.


92C5-24321
Fig. 7-Minimum output-P-channel drain characteristics.


Fig. 9-Typical transition time vs. load capacitance.


Fig. 8-Typical propagation delay vs. load capacitance (clock or enable to output).


Fig. 10-Typical maximum-clock-frequency vs. supply voltage.


Fig. 11-Typical power dissipation characteristics.


Fig. 12-Power dissipation test circuit and waveform.


Fig. 13-Ripple cascading of four counters with positive-edge triggering.


Fig. 14-Synchronous cascading of four binary counters with negative-edge triggering.


Fig. 15-Noise immunity test circuit.


Fig. 16-Quiescent device current test circuit.

Preliminary Data


## COS/MOS BCD Rate Multiplier

The RCA-CD4527B is a low-power 4-bit digital rate multiplier that provides an output-pulse rate which is the clock-inputpulse rate multiplied by $1 / 10$ times the $B C D$ input. For example, when the BCD input is 8 , there will be 8 output pulses for every 10 input pulses. This device may be used to perform arithmetic operations (add, subtract, divide, raise to a power), solve algebraic and differential equations, generate natural logarithms and trigonometric functions, A/D and D/A conversion, and frequency division.

For fractional multipliers with more than one digit, CD4527B devices may be cascaded in two different modes: the Add mode and the Multiply mode. See Figs. 3 and 4. In the Add mode,

$$
\begin{gathered}
\text { Output Rate }=\text { (Clock Rate) } \\
\left(0.1 \mathrm{BCD}_{1}+0.01 \mathrm{BCD}_{2}+0.001 \mathrm{BCD}_{3}+\cdots .\right)
\end{gathered}
$$

In the Multiply mode, the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second one,

$$
\text { e.g. } \frac{9}{10} \times \frac{4}{10}=\frac{36}{100}, \text { or } 36 \text { output }
$$

pulses for every 100 clock input pulses.

MAXIMUM RATINGS, Absolute-Maximum Values:


* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.


## OPERATING CONDITIONS AT TA $=25^{\circ} \mathrm{C}$

For maximum reliability, nominal operating conditions should be
selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $V_{S S}$ to $V_{D D}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \text { (Any one } \\ \text { input) } \end{gathered}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{\mathrm{DD}}+ \\ 0.5 \cdot \end{gathered}$ | V | - |

TRUTH TABLE

| Inputs |  |  |  |  |  |  |  |  |  | Number of PulsesorOutput Logic Level(H or L) |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| D | C | B | A | No. of Clock Pulses | Inhin | Strobe | Cascade | Clear | Set | Pin 6 OUT | $\overline{\text { Pin } 5}$ | Pin 7 <br> Inhout | Pin 1 "9" |
| 0 | 0 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | L | H | 1 | 1 |
| 0 | 0 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |
| 0 | 0 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 2 | 2 | 1 | 1 |
| 0 | 0 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 3 | 3 | 1 | 1 |
| 0 | 1 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 4 | 4 | 1 | 1 |
| 0 | 1 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 5 | 5 | 1 | 1 |
| 0 | 1 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 6 | 6 | 1 | 1 |
| 0 | 1 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 7 | 7 | 1 | 1 |
| 1 | 0 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 0 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 0 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 0 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 1 | 0 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 1 | 0 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 1 | 1 | 0 | 10 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 1 | 1 | 1 | 10 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| X | X | X | X | 10 | 1 | 0 | 0 | 0 | 0 | Depends on internal state of counter |  |  |  |
| $x$ | X | x | x | 10 | 0 | 1 | 0 | 0 | 0 | L | H | 1 | 1 |
| X | X | x | x | 10 | 0 | 0 | 1 | 0 | 0 | H | * | 1 | 1 |
| 1 | $\mathbf{x}$ | x | x | 10 | 0 | 0 | 0 | 1 | 0 | 10 | 10 | H | L |
| 0 | X | X | x | 10 | 0 | 0 | 0 | 1 | 0 | L | H | H | L |
| X | X | X | x | 10 | 0 | 0 | 0 | 0 | 1 | L | H | L | H |

* Output same as the first 16 lines of this truth table (depending on values of A, B, C, D).

STATIC ELECTRICAL CHARACTERISTICS AT TA $=\mathbf{2 5}^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} v_{0} \\ \mathbf{v} \end{gathered}$ | $\underset{\mathbf{V D}}{\mathbf{V}_{\mathbf{D D}}}$ |  |  |
| Quiescent Device Current | ${ }^{\prime} \mathrm{L}$ |  | 5 | 0.02 | $\mu \mathrm{A}$ |
|  |  |  | 10 | 0.02 |  |
| Output Drive Current: <br> All Outputs N-Channel (Sink) |  | 0.4 | 5 | 0.8 | mA |
|  | ${ }^{\prime}{ }^{N}$ | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | $I_{D}{ }^{P}$ | 4.6 | 5 | -0.8 |  |
|  |  | 2.5 | 5 | -3.2 |  |
|  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathrm{v}_{\mathrm{DD}}$ $\overline{\mathbf{v}}$ |  |  |
| Propagation Delay | tpHL. <br> ${ }^{\text {tpLH }}$ | Clock to "Out" | 5 | 180 | ns |
|  |  |  | 10 | 90 |  |
|  |  | Clock to "Inhibit Out" | 5 | 260 |  |
|  |  |  | 10 | 130 |  |
| Transition Time | ${ }^{\mathrm{t}}$ TLH. <br> ${ }^{t}$ THL |  | 5 | 100 | ns |
|  |  |  | 10 | 50 |  |
| Maximum Clock Frequency | ${ }^{\text {f CL }}$ (Max.) |  | 5 | 2 | MHz |
|  |  |  | 10 | 4.5 |  |
| Maximum Clock Rise and Fall Time | $\mathrm{t}_{\mathrm{r}, \mathrm{t}_{\mathrm{f}} \text { (Max.) }}$ |  | 5 | 15 | $\mu \mathrm{s}$ |
|  |  |  | 10 |  |  |



Fig. 1-Logic diagram.


Fig. 2-Timing diagram.




ONE OF FOUR OUTPUT PULSES CONTRIBUTED GY
DRM (2) TO OUTPUT FOR EVERY 100 CLOCK PULSES IN FOR PRESET No. 94

Fig. 3-Two CD4527B's cascaded in the "Add" mode with a preset number of 94.


Fig. 4-Two CD4527B's cascaded in the "Multiply" mode with a preset number of 36 .


The RCA-CD4532B consists of combinational logic that encodes the highest priority input (D7-D0) to a 3-bit binary code. The eight inputs, D7 through D0, each have an assigned priority; D7 is the highest priority and D0 is the lowest. The priority encoder is inhibited when the chip-enable input $E_{1}$ is low. When $E_{l}$ is high, the binary representation of the highestpriority input appears on output lines $\mathrm{Q} 2-\mathrm{OO}$, and the group

MAXIMUM RATINGS, Absolute-Maximum Values:
Storage-temperature range........... -65 to $+150^{\circ} \mathrm{C}$
OPERATING-TEMPERATURE RANGE. $. . . . . . . \quad-40$ to $+85{ }^{\circ} \mathrm{C}$
DC SUPPLY-VOLTAGE RANGE:
( $\mathrm{V}_{\mathrm{DD}}{ }^{*}$ )
-0.5 to +18 V
DEVICE DISSIPATION (PER PACKAGE) ...... . 200 mW
ALL INPUTS ................................ $v_{S S} \leqslant v_{1} \leqslant v_{D D}$
LEAD TEMPERATURE (DURING SOLDERING)
At distance $1 / 16 \pm 1 / 32 \mathrm{in}$. $(1.59 \pm 0.79 \mathrm{~mm})$
from case for 10 s max. $\ldots \ldots \ldots \ldots \ldots . . . .$.

* All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.
select line GS is high to indicate that priority inputs are present. The enable-out ( $\mathrm{E}_{\mathrm{O}}$ ) is high when no priority inputs are present.
The CD4532B is available in the 16 -lead dual-in-line plastic package (CD4532BE).

This device is similar to type MC14532.

## OPERATING CONDITIONS AT $T_{A}=\mathbf{2 5}^{\circ} \mathrm{C}$

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\mathrm{DD}}$ | Min. | Max. | Units | Fig. |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| $\begin{array}{l}\text { Input Voltage Swing } \\ \text { (Recommended } \mathrm{V}_{\mathrm{SS}} \text { to } \mathrm{V}_{\mathrm{DD}} \text { ) }\end{array}$ | - | $\begin{array}{r}0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}}\end{array}$ | -0.5 V | V | $\mathrm{~V}_{\mathrm{DD}}+$ |
| (Any one |  |  |  |  |  |
| input) |  |  |  |  |  |$)$

TRUTH TABLE

| Input |  |  |  |  |  |  |  |  | Output |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $E_{1}$ | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 | GS | 02 | Q1 | Q0 | $E_{0}$ |
| 0 | X | X | X | X | X | X | X | X | 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| 1 | 1 | X | X | X | X | X | X | X | 1 | 1 | 1 | 1 | 0 |
| 1 | 0 | 1 | X | X | X | X | X | X | 1 | 1 | 1 | 0 | 0 |
| 1 | 0 | 0 | 1 | X | X | X | x | X | 1 | 1 | 0 | 1 | 0 |
| 1 | 0 | 0 | 0 | 1 | X | X | X | X | 1 | 1 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 1 | X | X | X | 1 | 0 | 1 | 1 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 1 | X | X | 1 | 0 | 1 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | X | 1 | 0 | 0 | 1 | 0 |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 |

X = Don't Care
Logic $1 \equiv$ High
Logic $0 \equiv$ Low
$\qquad$

STATIC ELECTRICAL CHARACTERISTICS AT T ${ }^{\mathbf{A}}=25^{\circ} \mathrm{C}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | tYpical values | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \hline \mathrm{v}_{\mathrm{O}} \\ \text { Volts } \end{gathered}$ | VDD Volts |  |  |
| Quiescent Device Current | 'L | * | 5 | 0.02 | $\mu \mathrm{A}$ |
|  |  |  | 10 | 0.02 |  |
| Output Drive Current: <br> N-Channel (Sink) | ${ }^{1} \mathrm{D} N$ | 0.4 | 5 | 0.8 | mA |
|  |  | 0.5 | 10 | 1.8 |  |
| P-Channel (Source) | ${ }_{10}{ }^{P}$ | 4.6 | 5 | -0.8 |  |
|  |  | 2.5 | 5 | -3.2 |  |
|  |  | 9.5 | 10 | -1.8 |  |

DYNAMIC ELECTRICAL CHARACTERISTICS AT $T_{A}=25^{\circ} \mathrm{C} ; \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=20 \mathrm{~ns}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS $V_{D D}$ Volts | TYPICAL VALUES | UNITS |
| :---: | :---: | :---: | :---: | :---: |
| Propagation Delay Time: | ${ }^{\text {tpHL}}$. <br> ${ }^{\text {tpLH }}$ | 5 | 150 | ns |
| $E_{1}$ to $E_{0}$ |  | 10 | 80 |  |
| $E_{1}$ to GS |  | 5 | 120 |  |
|  |  | 10 | 60 |  |
| $E_{1}$ to Qn |  | 5 | 225 |  |
|  |  | 10 | 110 |  |
| Dn to Qn |  | 5 | 250 |  |
|  |  | 10 | 120 |  |
| Dn to GS |  | 5 | 225 |  |
|  |  | 10 | 100 |  |
| Transition Time | $\begin{aligned} & { }_{\mathrm{t}}^{\mathrm{t} \mathrm{HLL}} \\ & { }_{\mathrm{t}} \mathrm{FLLH} \end{aligned}$ | 5 | 60 | ns |
|  |  | 10 | 30 |  |

For Operating and Handling Considerations, see RCA Application Note ICAN-6000.



# COS/MOS Dual Binary to 1 of 4 Decoder/Demultiplexers 

CD4555B: Outputs High on Select
CD4556B: Outputs Low on Select
Features:

- Standard "B" series output drive
- Expandable with multiple packages


## Applications:

- Decoding - Code conversion - Function selection
- Demultiplexing (using Enable input as a data input)
- Memory chip-enable selection

The RCA-CD4555B and CD4556B* are dual one-of-four decoders/demultiplexers. Each decoder has two select inputs ( $A$ and $B$ ), an Enable input ( $\bar{E}$ ), and four mutually exclusive outputs. On the CD4555B the outputs are high on select; on the CD4556B the outputs are low on select.
When the Enable input is high, the outputs of the CD4555B remain low and the outputs of the CD4556B remain high regardless of the state of the select inputs $A$ and $B$. All outputs have equal source- and sink-current capabilities and conform to standard " $B$ " series output drive (see Static Electrical Characteristics). The CD4555B and CD4556B are similar to types MC14555 and MC14556, respectively.
These devices are supplied in 16 -lead dual-in-line plastic packages (E), welded-seal ceramic packages (D), ceramic packages (F), ceramic flat packs (K), and in chip form (H).

[^21]MAXIMUM RATINGS, Absolute-Maximum Values:

| STORAGE-TEMPERATURE RANGE. $\ldots \ldots \ldots \ldots .-65$ to $+150^{\circ} \mathrm{C}$OPERATING-TEMPERATURE RANG: |  |
| :---: | :---: |
|  |  |
| CERAMIC-PACKAGE TYPES | -55 to $+125^{\circ} \mathrm{C}$ |
| PLASTIC-PACKAGE TYPES. | -40 to $+85{ }^{\circ} \mathrm{C}$ |
| DC SUPPLY-VOLTAGE RANGE |  |
| $V_{\text {DD }}{ }^{*}$ | -0.5 to +18 V |
| DEVICE DISSIPATION (PER PACKAGE) | 200 mW |
| ALL InPUTS............................... $\mathrm{V}_{\text {S }}$ | $\leqslant \mathrm{v}_{1} \leqslant \mathrm{v}_{\mathrm{DD}}$ |
| LEAD TEMPERATURE (DURING SOLDERING): At distance $1 / 16 \pm 1 / 32$ inch $(1.59 \pm 0.79 \mathrm{~mm})$ from case for 10 seconds max. | $265^{\circ} \mathrm{C}$ |
| All voltage values are referenced to $\mathrm{V}_{\mathbf{S S}}$ terminal. |  |

TRUTH TABLE

| INPUTS |  |  | OUTPUTS CD4555B |  |  |  | OUTPUTS CD4556B |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ENABLE | SELECT |  |  |  |  |  |  |  |  |  |
| $\overline{\mathrm{E}}$ | B | A | Q3 | 02 | Q1 | 00 | $\overline{\text { Q3 }}$ | $\overline{\mathrm{Q} 2}$ | Q1 | $\overline{\mathrm{QO}}$ |
| 0 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 |
| 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 1 |
| 0 | 1 | 0 | 0 | 1 | 0 | 0 | 1 | 0 | 1 | 1 |
| 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 1 |
| 1 | X | X | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |
| X = DON'T CARE |  |  | LOGIC $1 \equiv$ HIGH <br> LOGIC 0 ㅌ LOW |  |  |  |  |  |  |  |

OPERATING CONDITIONS AT $\mathbf{T}_{A}=25^{\circ} \mathrm{C}$
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

| Characteristic | $\mathrm{V}_{\text {DD }}$ | Min. | Max. | Units | Fig. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | - | 3 | 18 | V | - |
| Input Voltage Swing (Recommended $\mathrm{V}_{S S}$ to $\mathrm{V}_{\mathrm{DD}}$ ) | - | $\begin{gathered} 0.2 \mathrm{~V}_{\mathrm{DD}} \\ \text { to } \\ 0.8 \mathrm{~V}_{\mathrm{DD}} \\ \left(\begin{array}{c} \text { Any one } \\ \text { input) } \end{array}\right. \end{gathered}$ | $\begin{gathered} -0.5 \mathrm{~V} \\ \text { to } \\ \mathrm{V}_{\mathrm{DD}}+ \\ 0.5 \mathrm{~V} \end{gathered}$ | $\checkmark$ | - |

STATIC ELECTRICAL CHARACTERISTICS


Fig. 1-CD4555B logic diagram (1 of 2 identical circuits).

File No. 858

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | CD4555BE, CD4556BE PLASTIC PACKAGE LIMITS |  |  |  |  |  |  |  |  | UNITS | FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{gathered} \mathrm{VO}_{\mathbf{O}} \\ \text { Volts } \end{gathered}$ | VDD <br> Volts | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $8^{\circ} \mathrm{C}$ |  |  |  |  |
|  |  |  |  | Min. | Typ. | Max. | Min. | Typ. | Max. | Min. | Typ. | Max. |  |  |
| Quiescent Device Current | $I_{L}$ |  | 5 | - | - | 50 | - | 0.02 | 50 | - | - | 700 | $\mu \mathrm{A}$ | 15 |
|  |  |  | 10 | - | - | 100 | - | 0.02 | 100 | - | - | 1400 |  |  |
|  |  |  | 15 | - | - | - | - | 0.02 | - | - | - | - |  |  |
| Output Voltage: Low-Level | $\mathrm{V}_{\mathrm{OL}}$ |  | 5 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 | V | - |
|  |  |  | 10 | - | - | 0.01 | - | 0 | 0.01 | - | - | 0.05 |  |  |
|  |  |  | 15 | - | - | - | - | 0 | - | - | - | - |  |  |
| High-Level | $\mathrm{V}_{\mathrm{OH}}$ |  | 5 | 4.99 | - | - | 4.99 | 5 | - | 4.95 | - | - |  |  |
|  |  |  | 10 | 9.99 | - | - | 9.99 | 10 | - | 9.95 | - | - |  |  |
|  |  |  | 15 | - | - | - | - | 15 | - | - | - | - |  |  |
| Noise Immunity (Any Input) | $\mathrm{V}_{\mathrm{NL}}$ | 4.2 | 5 | 1.5 | - | - | 1.5 | 2.25 | - | 1.4 | - | - | V | 16, 17 |
|  |  | 9 | 10 | 3 | - | - | 3 | 4.5 | - | 2.9 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
|  | $\mathrm{V}_{\mathrm{NH}}$ | 0.8 | 5 | 1.4 | - | - | 1.5 | 2.25 | - | 1.5 | - | - |  |  |
|  |  | 1 | 10 | 2.9 | - | - | 3 | 4.5 | - | 3 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | - | 6.75 | - | - | - | - |  |  |
| Output Drive Current: | $I^{\text {d }}$ |  |  |  |  |  |  |  |  |  |  |  | mA | - |
| $\begin{aligned} & \text { N-Channel } \\ & \text { (Sink) } \\ & \hline \end{aligned}$ |  | 0.4 | 5 | 0.45 | - | - | 0.4 | 0.8 | - | 0.36 | - | - |  |  |
|  |  | 0.5 | 10 | 1 | - | - | 0.9 | 1.8 | - | 0.75 | - | - |  |  |
|  |  | 1.5 | 15 | - | - | - | 3 | 6 | - | - | - | - |  |  |
| P-Channel (Source) | $I_{D} P$ | 2.5 | 5 | -1.8 | - | - | -1.6 | -3.2 | - | -1.3 | - | - | mA | - |
|  |  | 4.6 | 5 | -0.45 | - | - | -0.4 | -0.8 | - | -0.35 | - | - |  |  |
|  |  | 9.5 | 10 | -1 | - | - | -0.9 | -1.8 | - | -0.75 | - | - |  |  |
|  |  | 13.5 | 15 | - | - | - | -3 | -6 | - | - | - | - |  |  |
| Input Current | $1 /$ |  | 15 | - | - | - | - | $\pm 10^{-5}$ | $\pm 1$ | - | - | - | $\mu \mathrm{A}$ | - |

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{A}=25^{\circ} \mathrm{C}$, Input $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}=\mathbf{2 0} \mathrm{ns}$, and $\mathrm{C}_{\mathrm{L}}=\mathbf{5 0} \mathbf{~ p F}$

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS |  | ALL TYPES LIMITS |  | UNITS | CHARACTERISTIC CURVES \& TEST CIRCUITS FIG. NO. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | VDD Volts | Typ. | Max. |  |  |
| Propagation Delay Time: A or B Input to Any Output | ${ }^{\text {tpHL, }}$ <br> ${ }^{\text {tPLH }}$ |  | 5 10 15 | 220 95 70 | $\begin{aligned} & \hline 440 \\ & 190 \\ & 140 \\ & \hline \end{aligned}$ | ns | 7, 9, 19, 20 |
| $\bar{E}$ Input to Any Output |  |  | 5 10 15 | $\begin{array}{r} 200 \\ 85 \\ 65 \\ \hline \end{array}$ | $\begin{aligned} & 400 \\ & 170 \\ & 130 \\ & \hline \end{aligned}$ | ns | 8, 9, 19, 20 |
| Transition Time | ${ }^{\mathrm{t}} \mathrm{THL}$ <br> ${ }^{t}$ TLH |  | 5 10 15 | $\begin{array}{r} 100 \\ 50 \\ 40 \end{array}$ | $\begin{array}{r} 200 \\ 100 \\ 80 \end{array}$ | ns | 10 |
| Average Input Capacitance | $\mathrm{C}_{1}$ | Any Input |  | 5 | - | pF | - |



92CS-24320
Fig. 3-Typical output-P-channel drain characteristics.


Fig. 5-Typical output-N-channel drain characteristics.


Fig. 7-Typical propagation delay time vs. load capacitance ( $A$ or B input to any output).

DRAIN - TO-SOURCE VOLTAGE ( $V_{D S}$ ) - $V$


92Cs-24321
Fig. 4-Minimum output-P-channel drain characteristics.


Fig. 6-Minimum output- $N$ channel drain characteristics.

Fig. 8-Typical propagation delay time vs. load capacitance ( $\bar{E}$ input to any output).


Fig. 9-Typical propagation delay time vs. supply voltage.


Fig. 11-Typical dynamic power dissipation vs. frequency.


Fig. 10-Typical transition time vs. load capacitance.

## APPLICATIONS



92CS-24229
TRUTH TABLE

| SELECT <br> INPUTS |  | OUTPUTS |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| B | A | O0 | Q1 | Q2 | Q3 |  |
| 0 | 0 | DATA | 0 | 0 | 0 |  |
| 0 | 1 | 0 | DATA | 0 | 0 |  |
| 1 | 0 | 0 | 0 | DATA | 0 |  |
| 1 | 1 | 0 | 0 | 0 | DATA |  |

Fig. 12-1-of-4 line data demultiplexer using CD4555B.

TRUTH TABLE

| INPUTS |  |  |  |  | Q OUTPUTS |  |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\bar{E}$ | D | c | B | A | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 |
| 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 | 0 |
| 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 |
| 0 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 | 0 |
| 0 | 1 | 1 | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 | 0 |
| 0 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 | 0 |
| 0 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| 1 | $\times$ | $\times$ | X | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

Fig. 13-1-of-16 decoder using CD4555B/CD4556B.


92CS-24227
Fig. 14-1-of-8 decoder using CD4555B.



Fig. 17-CD4556B noise immunity test circuit. Fig. 18-Dynamic power dissipation test circuit.

${ }^{\prime} \mathrm{I}=1 \mathrm{MHz} ; 50 \%$ DUTY CYCLE
92Cs-24223
Fig. 19-CD4555B B input to Q3 output dynamic signal waveforms.

${ }^{\prime} I=1$ MHz, $50 \%$ DUTY CYCLE
Fig. 21-CD4555B $\bar{E}$ input to 03 output dynamic signal waveforms.

${ }^{\mathrm{t}} \mathrm{I}=1 \mathrm{MHz}, 50 \%$ DUTY CYCLE
92CS-24224
Fig. 20-CD4556B $B$ input to $\overline{03}$ output dynamic signal waveforms.

$f_{I}=1 \mathrm{MHz}, 50 \%$ DUTY CYCLE
Fig.22-CD4556B $\bar{E}$ input to $\bar{Q}_{3}$ output dynamic signal waveforms.

## Appendix

DRIVE CURRENT TEST CIRCUIT CONNECTIONS To be used as an example of test method.

| Example:$\text { CD4000A }{ }^{1} D^{P}$ |  | Example: <br> 16-Lead Types |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |
| Type | M ${ }^{+}$ | Ground | VDD | Vo |
| CD4000A | $I_{\text {dN }}$ | 1-4,7,8,11,13 | 5,14 | 6 |
|  | $I_{D}{ }^{P}$ | 1-5,7,8,11-13 | 14 |  |
| CD4001A | $I_{0 N}$ | 2,5-9,12,13 | 1,14 | 3 |
|  | $I_{D} P$ | 1,2,5-9,12,13 | 14 |  |
| CD4002A | $I_{10 N}$ | 3-5,7,9-12 | 2,14 | 1 |
|  | $1_{0}{ }^{\text {P }}$ | 2-5,7,9-12 | 14 |  |
| CD4006A* | $1 \mathrm{IN}^{\text {N }}$ | 1,4-7 | 14 | 13 |
|  | $I_{D} P$ | 4-7 | 1,14 |  |
| CD4007A | $1 \mathrm{I}^{\text {N }}$ | 3,7.10 | 6,14 | 8 |
|  | ${ }_{10}{ }^{\text {P }}$ | 3,6,7,10 | 14 | 13 |
| CD4008A | $I_{\text {I }}{ }^{10}$ | 1-9,15 | 16 | 14 |
|  | ${ }_{10}{ }^{\text {P }}$ | 8 | 1-7,9,15,16 |  |
| CD4009A | $I_{0 N}$ | 5,7-9,11,14 | 1,3,16 | 2 |
|  | $1_{0}{ }^{\text {P }}$ | 3,5,7-9,11,14 | 1,16 |  |
| CD4010A | $1_{0}{ }^{1}$ | 3,5,7-9,11,14 | 1,16 | 2 |
|  | $I_{D}{ }^{P}$ | 5,7-9,11,14 | 1,3,16 |  |
| CD4011A | $I_{\text {d }} \mathrm{N}$ | 5-9,12,13 | 1,2,14 | 3 |
|  | $I_{D} P$ | 1,5-9,12,13 | 2,14 |  |
| CD4012A | $1_{0} \mathrm{~N}$ | 7,9-12 | 2-5,14 | 1 |
|  | ${ }_{10}{ }^{\text {P }}$ | 2,7,9-12 | 3-5,14 |  |
| CD4013A | $I_{0} N$ | 3,5-11 | 4,14 | 1 |
|  | ${ }_{1} D^{P}$ | 3-5,7-11 | 6,14 |  |
| CD4014A* | ${ }_{10} \mathrm{~N}$ | 1,4-8,11,13-15 | 9,16 | 3 |
|  | $1_{0}{ }^{\text {P }}$ | 4-8,11,13-15 | 1,9,16 |  |
| CD4015A* | $I_{0}{ }^{\text {N }}$ | 1,6-8,14,15 | 16 | 5 |
|  | ${ }_{10}{ }^{\text {P }}$ | 1,6,8,14,15 | 7.16 |  |
| CD4017A | $\mathrm{I}^{1} \mathrm{~N}$ | 8 | 13-16 | 3 |
|  | $1_{0}{ }^{P}$ | 8 | 13-16 | 2 |
| CD4018A | ${ }_{1} \mathrm{D}^{\mathrm{N}}$ | 1-3,7-10,12 | 14-16 | 11 |
|  | ${ }_{1} \mathrm{D}^{P}$ | 1-3,7,8,10 | 9,12,14-16 |  |
| CD4019A | ${ }_{1} \mathrm{D}^{\mathrm{N}}$ | 1-9 | 14-16 | 13 |
|  | ${ }_{1} D^{P}$ | $1-8$ | 9,14-16 |  |
| CD4020A* | ${ }_{1}{ }^{1} \mathrm{~N}$ | 8,11 | 16 | 9 |
|  | $1_{1}{ }^{P}$ | 8,11 | 16 |  |
| CD4021A | ${ }^{1} \mathrm{DN}$ | $\begin{aligned} & 1,4-8,10,11 \\ & 13-15 \end{aligned}$ | 9,16 | 3 |
|  | ${ }_{10}{ }^{P}$ | 4-8,10,11,13-15 | 1,9,16 |  |
| CD4022A* | ${ }_{10} \mathrm{~N}$ | 8,13,15 | 16 | 2 |
|  | ${ }^{1} D^{P}$ | 8,13,15 | 16 |  |
| CD4023A | $\mathrm{I}_{0} \mathrm{~N}$ | 1,2,7,8,11-13 | 3-5,14 | 6 |
|  | ${ }_{1} D^{P}$ | 1-3,7,8,11-13 | 4,5,14 |  |

Refer to applicable data sheet for $\mathrm{V}_{\mathrm{O}}$ values.
Voltage outputs shall be supplied by an external power supply.

| Type | M ${ }^{*}$ | Ground | VDD | $V_{0}$ |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{gathered} \text { CD4024A* } \\ (\mathrm{K}, \mathrm{D}, \mathrm{E}) \end{gathered}$ | $I_{\text {d }}$ | 1,7 | 2,14 | 12 |
|  | $I_{D} P$ | 2,7 | 14 |  |
| $\begin{gathered} \text { CD4024A* } \\ (T) \end{gathered}$ | $I^{1} \mathrm{~N}$ | 1,12 | 2,3 | 11 |
|  | $I_{D} P$ | 3.12 | 2 |  |
| CD4025A | $I_{\text {I }}$ | 1-4,7,8,11-13 | 5,14 | 6 |
|  | $1_{D}{ }^{\text {P }}$ | 1-5,7,8,11-13 | 14 |  |
| CD4026A | $I_{0 N}$ | 1-3,8,15 | 16 | 10 |
|  | $I_{0}{ }^{\text {P }}$ | 1,2,8 | 3,15,16 |  |
| CD4027A | $I_{\text {d }} N$ | 3,5-13 | 4,16 | 1 |
|  | $I_{D} P$ | 3-6,8-13 | 7,16 |  |
| CD4028A | $I_{\text {IN }}$ | 8,10-13 | 16 | 2 |
|  | $I_{D}{ }^{P}$ | 8,10-13 | 16 | 3 |
| CD4029A | $I_{\text {I }}$ | $\begin{aligned} & 3,4,8,10,12 \\ & 13,15 \end{aligned}$ | 1,5,9,16 | 6 |
|  | $I_{D} P$ | 5,8,15 | $\begin{aligned} & 1,3,4,9,10,12 \\ & 13,16 \\ & \hline \end{aligned}$ |  |
| CD4030A | ${ }^{1} \mathrm{D} N$ | 1,2,5-9,12,13 | 14 | 3 |
|  | $I_{D} P$ | 2,5-9,12,13 | 1,14 |  |
| CD4031A | $\mathrm{I}_{\mathrm{DN}}$ | 1,2,8,10,15 | 7,16 | 6 |
|  | $I_{D} P$ | 1,2,7,8,10,15 | 16 |  |
| CD4032A | $I_{\text {d }}$ | 2,3,5-8,10-15 | 16 | 9 |
|  | $I_{\text {I }}{ }^{\text {P }}$ | 2,3,5,6,8,10-15 | 7,16 |  |
| CD4033A | $I_{\text {d }} \mathrm{N}$ | 1-3,8,14 | 15,16 | 10 |
|  | $I_{D} P$ | 1-3,8,15 | 14,16 |  |
| CD4034A | $I_{D} N$ | 1-8,10-12,15 | 9,13,14,24 | 16 |
|  | $I_{D} P$ | 10-12,15 | 1-9,13,14,24 |  |
| CD4035A | $I_{\text {d }}$ | 2-4,6-12 | 2,5,16 | 1 |
|  | $1_{D} P$ | 2-4,6-12 | 5,16 |  |
| CD4036A | $I_{0} N$ | 3-12,21-23 | 1,2,24 | 13 |
|  | $I_{D} P$ | 11,12,21-23 | 1-10,24 |  |
| CD4037A | $I_{D} N$ | 7 | 1-5,14 | 10 |
|  | $I_{D}{ }^{\text {P }}$ | $2-7$ | 14 |  |
| CD4038A | ${ }_{1}{ }^{\text {N }}$ | 2,3,5-8,10-15 | 10,11,16 | 9 |
|  | $I_{D} P$ | 2,3,5,6,8,12-15 | 7,10,11,16 |  |
| CD4039A | ${ }_{10} \mathrm{~N}$ | 3-12,21-23 | 1,2,24 | 13 |
|  | $1_{1}{ }^{P}$ | 11,12,21-23 | 1-10,24 |  |
| CD4040A* | $I_{\text {d }} \mathrm{N}$ | 8,10 | 11,16 | 9 |
|  | $I_{\text {I }} \mathrm{N}$ | 8,11 | 16 |  |
| $\begin{aligned} & \text { CD4041A } \\ & \text { (TRUE) } \end{aligned}$ | $1 \mathrm{I}^{\mathrm{N}}$ | 3,6,7,10,13 | 14 | 1 |
|  | ${ }^{1} D^{P}$ | 6,7,10,13 | 3,14 |  |
| $\begin{aligned} & \text { CD4041A } \\ & \text { (COMP) } \end{aligned}$ | ${ }_{10} \mathrm{~N}$ | 6,7,10,13 | 3,14 | 2 |
|  | $I_{1}{ }^{P}$ | 3,6,7,10,13 | 14 |  |

$\mathrm{M}=$ Measurement

* These types must be clocked into the proper state.

DRIVE-CURRENT TEST-CIRCUIT CONNECTIONS (Cont'd)

| Type | M ${ }^{*}$ | Ground | VDD | $\mathbf{V}_{0}$ | Type | M | Ground | VDD | Vo |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CD4042A | $I_{\text {d }} \mathrm{N}$ | 4,7,8,13,14 | 5,6,16 | 2 | $\begin{aligned} & \text { CD4062AK* } \\ & \text { CLD } \end{aligned}$ | $I_{\text {d }}$ | 2-5,8 | 11,13,16 | 7 |
|  | $1_{D}{ }^{P}$ | 7,8,13,14 | 4-6,16 |  |  | $I_{D} P$ | 3-5,8 | 2,11,13,16 |  |
| CD4043A | ${ }_{1} \mathrm{DN}^{\text {N }}$ | $\begin{aligned} & 4,6-8,11,12 \\ & 14,15 \end{aligned}$ | 3,5,16 | 2 | Q | $I_{D} \mathrm{~N}$ | 2-5,8 | 11,13,16 | 12 |
|  | ${ }^{1} \mathrm{D} P$ | $\begin{aligned} & 3,6-8,11,12 \\ & 14,15 \end{aligned}$ | 4,5,16 |  |  | $I_{D}{ }^{\text {P }}$ | 3-5,8 | 2,11,13,16 |  |
|  |  |  |  |  | $\begin{aligned} & \text { CD4062AT* } \\ & \text { CLD } \end{aligned}$ | ${ }_{1}{ }^{1} \mathrm{~N}$ | 2-5,7 | 9,11,12 | 6 |
| CD4044A | $I_{0}$ | 4,8 | $\begin{aligned} & 3,5-7,11,12, \\ & 14-16 \end{aligned}$ | 13 |  | ${ }_{1}{ }^{\text {P }}$ | 3-5,7 | 2,9,11,12 |  |
|  | $I_{D} P$ | 3,8 | $\begin{aligned} & 4-7,11,12, \\ & 14-16 \end{aligned}$ |  | Q | ${ }^{1} \mathrm{D}^{\text {N }}$ | 2-5,7 | 9,11,12 | 10 |
|  |  |  |  |  |  | $I_{D}{ }^{P}$ | 3-5,7 | 2,9,11,12 |  |
| $\begin{array}{\|c\|} \hline C D 4045 A \\ (\phi \text { to } 16) \end{array}$ | $I_{\text {d }} \mathrm{N}$ | 2,14 | 1,3 | 8 | CD4063B | $I_{D} N$ | 1,3,4,8-15 | 3,16 | 5 |
|  | $1_{D} P$ | 2,14 | 1,3 |  |  | $I_{D} P$ | 1-3,8-15 | 4,16 |  |
| $\begin{gathered} \text { CD4046A } \\ \text { COMP } 1 \end{gathered}$ | $1 \mathrm{I}^{\text {N }}$ | 5,8,9 | 3,14,16 | 2 | CD4066A | $I_{\mathrm{D}} \mathrm{N}$ | NO $I_{D} N, I_{D} P$ |  | 13 |
|  | $I_{D} P$ | 5,8,9,14 | 3,16 |  |  | $I_{D}{ }^{P}$ |  |  |  |
|  | $I_{\text {dN }}$ | 5,8,9,14 | 3,16 | 13 | CD4068B | ${ }_{1} \mathrm{D}^{(0}$ | 7 | 2-5,9-12,14 |  |
| COMP 2 | IDP | 5,8,9 | 3,14,16 |  |  | $1 D^{P}$ | 2-5,7,9-12 | 14 |  |
| CD4047A | IDN | 5,7,12 | 4,6,8,9,14 | 10 | CD4069B | ${ }_{1}{ }^{1} \mathrm{~N}$ | 7 | 1,3,5,9,11,13,14 | 2 |
|  | d |  | 4,6,8,9,14 |  |  | $I_{D}{ }^{\text {P }}$ | 1,3,5,7,9,11,13 | 14 |  |
|  | $1_{0}{ }^{P}$ | 7,9 | 3-6,8,12,14 |  | CD4071B | $I_{\text {d }}$ | 1,2,5-9,12,13 | 14 | 10 |
| CD4048A | IoN | 3-14 | 2,15,16 | 1 |  | ${ }_{1}{ }^{\text {P }}$ | 7 | 1,2,5-9,12,13,14 |  |
|  | $I_{D} P$ | 2-14 | 15,16 |  | CD4072B | IDN | 2-5,7,9-12 | 14 | 1 |
| CD4049A | $I_{\text {dN }}$ | 5,7-9,11,14 | 1,3 | 2 |  | $I_{D} P$ | 7 | 2-5,9-12,14 |  |
|  | ${ }_{10}{ }^{\text {P }}$ | 5,7-9,11,14 | 1 |  | CD4073B | $I_{D}{ }^{\text {N }}$ | 1-5,7,8,11-13 | 14 | 6 |
| CD4050A | ${ }_{1} \mathrm{DN}$ | 3,5,7-9,11,14 | 1 | 2 |  | ${ }_{10}{ }^{P}$ | 7 | 1-5,8,11-14 |  |
|  | $I^{\prime} P$ | 5,7-9,11,14 | 1,3 |  | CD4075B | IDN | 1-5,7,8,11-13 | 14 | 6 |
|  | $1 \mathrm{IDN}^{1}$ | 2,7-15 | 1,16 |  |  | $I_{D} P$ | 7 | 1-5,8,11-14 |  |
| CD4054A | $\mathrm{I}^{\prime}$ | 2,7-15 | 1,16 | 3 | CD4078B | $I_{\text {d }} \mathrm{N}$ | 7 | 2-5,9-12,14 | 13 |
|  | $I_{D} P$ | 2,7-14 | 1,15,16 |  |  | $I_{D}{ }^{P}$ | 2-5,7,9-12 | 14 |  |
| CD4055A | $I^{\prime} \mathrm{NN}$ | 2-4,6-8 | 5,16 | 9 | CD4081B | $1 \mathrm{D}^{\text {N }}$ | 1,2,5-9,12,13 | 14 | 3 |
|  | $1_{D} P$ | 2-8 | 16 |  |  | ${ }^{1} \mathrm{D} P$ | 7 | $\begin{aligned} & 1,2,5,6,8,9, \\ & 12-14 \\ & \hline \end{aligned}$ |  |
| CD4056A | $I^{\prime} N$ | 2-4,6-8 | 1,5,16 | 9 | CD4082A | $I_{\text {D }}$ | 2-5,7,9-12 | 14 | 1 |
|  | $I_{D}{ }^{P}$ | 2-8 | 1,16 |  |  | $I_{D}{ }^{\text {P }}$ | 7 | 2-5,9-12,14 |  |
| CD4057AZERO IND | $1 D^{\prime}$ | $\begin{aligned} & 1-3,6,7,14,21 \\ & 23,25,27,28 \\ & \hline \end{aligned}$ | $\begin{array}{\|l} \hline 8,9,13,15,19 \\ 22,26 \\ \hline \end{array}$ | 24 | CD4085B | $I_{\text {d }}$ | 1,2,5-9,11-13 | 10-14 | 3 |
|  |  |  |  |  |  | $I_{D}{ }^{\text {P }}$ | 1,2,5-13 | 14 |  |
|  | ${ }^{1} D^{P}$ | $\begin{aligned} & 6,14,21,23 \\ & 25,28 \\ & \hline \end{aligned}$ | $\begin{aligned} & 1-3,7-9,13,15, \\ & 19,20,22,26,27 \\ & \hline \end{aligned}$ |  | CD4086B | $I_{D} N$ | 1,2,5-9,11,13 | 11,14 | 3 |
| NEG IND | $I_{\text {d }}$ | $\begin{aligned} & 1-3,6,14,21,23 \\ & 25,27,28 \\ & \hline \end{aligned}$ | $\begin{aligned} & 7-9,13,15,19 \\ & 20,22,26 \\ & \hline \end{aligned}$ | 4 |  | ${ }_{1} \mathrm{D}^{\text {P }}$ | 1,2,5-10,12,13 | 11,14 |  |
|  |  |  |  |  | CD4093B | ${ }^{1} \mathrm{D} N$ | 7 | $\begin{aligned} & 1,2,5,6,8,9 \\ & 12-14 \end{aligned}$ | 10 |
|  | $I_{D}{ }^{P}$ | $\begin{aligned} & 1-3,6,7,14,21 \\ & 23,25,27,28 \\ & \hline \end{aligned}$ | $\begin{array}{\|l} \hline 8,9,13,15,19 \\ 20,22,26 \\ \hline \end{array}$ |  |  | $I_{D}{ }^{P}$ | 1,2,5-9,12,13 | 12-14 |  |
| OVERFLOW IND | ${ }^{1} \mathrm{DN}$ | $\begin{aligned} & 1-3,5,7-9,14,19 \\ & 22,23,25,27,28 \\ & \hline \end{aligned}$ | $\begin{aligned} & 6,13,15,20, \\ & 21,26 \end{aligned}$ | 17 | CD4514B | $I_{\text {I }}$ N | 2,3,12,21,22 | 1,2,3,24 | 11 |
|  | $I_{D}{ }^{\text {P }}$ | $5,7-9,14,19,22$ | $1-3,6,13,15,20$ |  |  | $I_{D}{ }^{\text {P }}$ | 2,3,12,21-23 | 1,24 |  |
|  | D | $23,25,28$ | 21,26,27 |  | CD4515B | ${ }_{1}{ }^{\text {N }}$ | 2,3,12,21-23 | 1,24 | 11 |
| OTHER OUTPUTS DATA OUT 1 \& 3 | ${ }^{1} \mathrm{DN}$ | 6,7,21,25 | $\begin{aligned} & 8,9,13,15,19,20, \\ & 22,23,26 \end{aligned}$ | 1 |  | $I_{D}{ }^{*}$ | 2,3,12,21,22 | 1,23,24 |  |
|  | $\mathrm{I}^{\text {P }}$ | 6,7,21,22,25 | $\begin{aligned} & 8,9,13,15,19,20 \\ & 23,26 \\ & \hline \end{aligned}$ | 27 | CD4518B* | $I_{\text {D }}$ | 1,2,7-10 | 15,16 | 14 |
|  |  |  |  |  |  | $I_{D}{ }^{\text {P }}$ | 1,2,7,8,10,15 | 16 |  |
| CD4060A* | $I_{\text {d }}$ | 8,11 | 12,16 | 7 | CD4520B | $I_{1} \mathrm{~N}$ | 1,2,7-10 | 15,16 | 14 |
|  | $I_{D}{ }^{\text {P }}$ | 8,12 | 16 |  |  | ${ }_{1}{ }^{P}$ | 1,2,7,8,10,15 | 16 |  |
| CD4061A* | $I_{\text {dN }}$ | $\begin{aligned} & 1-4,6,7,9-12, \\ & 15,16 \end{aligned}$ | 5 | 13 | - $M=$ Measurement <br> * These types must be clocked into the proper state. |  |  |  |  |
|  | $1_{D}{ }^{\text {P }}$ | $\begin{aligned} & 1-4,6,7,9-11, \\ & 15,16 \end{aligned}$ | 5,12 |  |  |  |  |  |  |  |  |  |



CD4000A


CD4006A


CD4008A


92CS-24453
CD4011A



92CS-24446
CD4001A


92CS-24447
CD4002A



92CS-24451
CD4009A


92CS-24454
CD4012A


92CS-24458
CD4016A

## TERMINAL ASSIGNMENT DIAGRAMS - Top View



92CS-24459
CD4017A


92CS-24462
CD4020A



92CS-24460
CD4018A



92CS-24461
CD4019A


92CS-24464
CD4022A

CD4024AT


92CS-24467


$92 C S-24468$
CD4025A



92CS-24466
CD4024A (D, E, F, K)


92Cs-24470
CD4027A


92Cs-24471
CD4028A


92Cs-24472
CD4029A

## TERMINAL ASSIGNMENT DIAGRAMS - Top View



92CS-20743R1
CD4031A



92C5-24474
CD4032A


CD4036A


CD4039A



CD4037A


92CS-20747RI
CD4040A


92CS-20756R
CD4042A


CD4038A


92CS-20755R!
CD4041A


92CS-24476
CD4043A


TERMINAL ASSIGNMENT DIAGRAMS - Top View


* NOTE : NON - STANDARD TERMINAL LOCATIONS FOR
$V_{S S}$ AND $V_{D D}$. MOST OTHER COS/MOS TYPES
USE CORNER TERMINALS FOR POWER-
SUPPLY CONNECTIONS
92CS-20253RI
CD4057A



CD4062AT

92CS-22693


CD4066A

$\mathrm{CL}_{1}=$ PHASE $\mid$ OF 2-PHASE CLOCK
CL ID $=$ DELAYED CL।
$\mathrm{CL}_{2}=$ PHASE 2 OF 2-PHASE CLOCK CL2D $=$ DELAYED CL2

CD4062AK
92Cs-22694


CD4067B




## TERMINAL ASSIGNMENT DIAGRAMS - Top View



92cs-24593


92CS-23889RI


92Cs-24835


92CS-23869RI


92CS-25005


CD4095B
92Cs-24428

## TERMINAL ASSIGNMENT DIAGRAMS - Top View



92CS-24554
CD4514B, CD4515B




DIMENSIONAL OUTLINES
Ceramic Flat Packs

## NOTES:

1. Refer to Rules for Dimensioning Peripheral Lead Outlines.
2. Leads within .005' (. 12 mm ) radius of True Position (TP) at maximum material condition.
3. $N$ is the maximum quantity of lead positions.
4. $Z$ and $Z_{1}$ determine a zone within which all body and lead irregularities lie:

JEDEC MO-004-AF 14-LEAD


| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.008 | 0.100 |  | 0.21 | 2.54 |
| B | 0.015 | 0.019 | 1 | 0.381 | 0.482 |
| C | 0.003 | 0.006 | 1 | 0.077 | 0.152 |
| e | 0.050 TP |  | 2 | 1.27 TP |  |
| E | 0.200 | 0.300 |  | 5.1 | 7.6 |
| H | 0.600 | 1.000 |  | 15.3 | 25.4 |
| L | 0.150 | 0.350 |  | 3.9 | 8.8 |
| N | 14 |  | 3 | 14 |  |
| Q | 0.005 | 0.050 |  | 0.13 | 1.27 |
| S | 0.000 | 0.050 |  | 0.00 | 1.27 |
| 2 | 0.300 |  | 4 | 7.62 |  |
| $\mathrm{Z}_{1}$ | 0.400 |  | 4 | 10.16 |  |

JEDEC MO-004-AG 16-LEAD

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.008 | 0.100 |  | 0.21 | 2.54 |
| B | 0.015 | 0.019 | 1 | 0.381 | 0.482 |
| C | 0.003 | 0.006 | 1 | 0.077 | 0.152 |
| e | 0.050 TP |  | 2 | 1.27 TP |  |
| E | 0.200 | 0.300 |  | 5.1 | 7.6 |
| H | 0.600 | 1.000 |  | 15.3 | 25.4 |
| L | 0.150 | 0.350 |  | 3.9 | 8.8 |
| N | 16 |  | 3 | 16 |  |
| Q | 0.005 | 0.050 |  | 0.13 | 1.27 |
| s | 0.000 | 0.025 |  | 0.00 | 0.63 |
| Z | 0.300 |  | 4 | 7.62 |  |
| $z_{1}$ | 0.400 |  | 4 | 10.16 |  |

92CS-1727IR!

## 24-LEAD

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.075 | 0.120 |  | 1.91 | 3.04 |
| B | 0.018 | 0.022 | 1 | 0.458 | 0.558 |
| C | 0.004 | 0.007 | 1 | 0.102 | 0.177 |
| e | 0.050 TP |  | 2 | 1.27 TP |  |
| E | 0.600 | 0.700 |  | 15.24 | 17.78 |
| H | 1.150 | 1.350 |  | 29.21 | 34.29 |
| L | 0.225 | 0.325 |  | 5.72 | 8.25 |
| N | 24 |  | 3 | 24 |  |
| 0 | 0.035 | 0.070 |  | 0.89 | 1.77 |
| S | 0.060 | 0.110 | 1 | 1.53 | 2.79 |
| 2 | 0.700 |  | 4 | 17.78 |  |
| $\mathrm{Z}_{1}$ | 0.750 |  | 4 | 19.05 |  |

92CS-19949

28-LEAD

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.075 | 0.120 |  | 1.91 | 3.04 |
| B | 0.018 | 0.022 | 1 | 0.458 | 0.558 |
| C | 0.004 | 0.007 | 1 | 0.102 | 0.177 |
| e | 0.050 TP |  | 2 | 1.27 TP |  |
| E | 0.600 | 0.700 |  | 15.24 | 17.78 |
| H | 1.150 | 1.350 |  | 29.21 | 34.29 |
| L | 0.225 | 0.325 |  | 5.72 | 8.25 |
| N | 28 |  | 3 | 28 |  |
| 0 | 0.035 | 0.070 |  | 0.89 | 1.77 |
| S | 0 | 0.060 | 1 | 0 | 1.53 |
| Z | 0.700 |  | 4 | 17.78 |  |
| $\mathrm{Z}_{1}$ | 0.750 |  | 4 | 19.05 |  |

92CS-20972

When these devices are supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed $0.013^{\prime \prime}$.
$\qquad$
DIMENSIONAL OUTLINES
Ceramic Dual-in-Line Packages


NOTES:

1. Refer to Rules for Dimensioning (JEDEC Publication No. 13) for Axial Lead Product Outlines.
2. Leads within $0.005^{\prime \prime}(0.12 \mathrm{~mm})$ radius of True Position (TP) at gauge plane with maximum material condition and unit installed.
3. $e_{A}$ applies in zone $L_{2}$ when unit installed.
4. a applies to spread leads prior to installation.
5. $N$ is the maximum quantity of lead positions.
6. $N_{1}$ is the quantity of allowable missing leads.

JEDEC MO-001-AD
14-Lead Welded-Seal

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.120 | 0.160 |  | 3.05 | 4.06 |
| $A_{1}$ | 0.020 | 0.065 |  | 0.51 | 1.65 |
| B | 0.014 | 0.020 |  | 0.356 | 0.508 |
| B1 | 0.050 | 0.065 |  | 1.27 | 1.65 |
| C | 0.008 | 0.012 |  | 0.204 | 0.304 |
| D | 0.745 | 0.770 |  | 18.93 | 19.55 |
| E | 0.300 | 0.325 |  | 7.62 | 8.25 |
| E1 | 0.240 | 0.260 |  | 6.10 | 6.60 |
| e1 | $\begin{aligned} & 0.100 \mathrm{TP} \\ & 0.300 \mathrm{TP} \end{aligned}$ |  | 2 | 2.54 TP <br> 7.62 TP |  |
| eA |  |  | 2, 3 |  |  |
| L | 0.125 | 0.150 |  | 3.18 | 3.81 |
| L2 | 0.000 | 0.030 |  | 0.000 | 0.76 |
| $a$ | 00 | 150 | 4 | 00 | 150 |
| N | $\begin{array}{r} 14 \\ 0 \end{array}$ |  | 5 | 140 |  |
| $\mathrm{N}_{1}$ |  |  | 6 |  |  |
| $\mathrm{O}_{1}$ | 0.050 | 0.085 |  | 1.27 | 2.15 |
| S | 0.065 | 0.090 |  | 1.66 | 2.28 |

92SS-44IIRI

JEDEC MO-001-AE
16-Lead Welded-Seal

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.120 | 0.160 |  | 3.05 | 4.06 |
| $A_{1}$ | 0.020 | 0.065 |  | 0.51 | 1.65 |
| B | 0.014 | 0.020 |  | 0.356 | 0.508 |
| $\mathrm{B}_{1}$ | 0.035 | 0.065 |  | 0.89 | 1.65 |
| C | 0.008 | 0.012 |  | 0.204 | 0.304 |
| D | 0.745 | 0.785 |  | 18.93 | 19.93 |
| E | 0.300 | 0.325 |  | 7.62 | 8.25 |
| $\mathrm{E}_{1}$ | 0.240 | 0.260 |  | 6.10 | 6.60 |
| $e_{1}$ | $\begin{aligned} & 0.100 \mathrm{TP} \\ & 0.300 \mathrm{TP} \end{aligned}$ |  | 2 | $\begin{aligned} & \text { 2.54 TP } \\ & \text { 7.62 TP } \end{aligned}$ |  |
| ${ }^{\mathbf{e}}$ A |  |  | 2, 3 |  |  |
| L | 0.125 | 0.150 |  | 3.18 | 3.81 |
| $\mathrm{L}_{2}$ | 0.000 | 0.300 |  | 0.000 | 0.76 |
| $a$ | $0^{\circ}$ | $15^{\circ}$ | 4 | $0^{\circ}$ | $15^{\circ}$ |
| N | 160 |  | 5 | 160 |  |
| $\mathrm{N}_{1}$ |  |  | 6 |  |  |
| $\mathrm{Q}_{1}$ | 0.050 | 0.085 |  | 1.27 | 2.15 |
| S | 0.015 | 0.060 |  | 0.39 | 1.52 |

92SS-4286R2

When these devices are supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed 0.013'".

## DIMENSIONAL OUTLINES

Ceramic Dual-in-Line Packages (Cont'd)


NOTES:

1. REFER TO RULES FOR DIMENSIONING (JEDEC PUBLICATION No. 13) AXIAL LEAD PRODUCT OUTLINES.
2. WHEN BASE OF BODY IS TO BE ATTACHED TO HEAT SINK, TERMINAL LEAD STAND. OFFS ARE NOT REQUIRED AND $A_{1}=0$. WHEN $A_{1}=0$, THE LEADS EMERGE FROM THE BODY WITH THE B ${ }_{1}$ DIMENSION AND REDUCE TO THE B DIMENSION ABOVE THE SEATING PLANE.
3. $e_{1}$ AND e $e_{A}$ APPLY IN ZONE $L_{2}$ WHEN UNIT INSTALLED. LEADS WITHIN .005" RADIUS OF TRUE POSITION (TP) AT GAUGE PLANE WITH MAXIMUM MATERIAL CONDITION.
4. APPLIES TO SPREAD LEADS PRIOR TO INSTALLATION.
5. N IS THE MAXIMUM QUANTITY OF LEAD POSITIONS.
6. $\mathrm{N}_{1}$ IS THE QUANTITY OF ALLOWABLE MISSING LEADS.

JEDEC MO-015-AH
28-Lead Welded-Seal

| SYMBOL | INCHES |  | MILLIMETERS |  | NOTES |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. | MIN. | MAX. |  |
| $\begin{gathered} A_{1} \\ \mathbf{A}_{1} \end{gathered}$ | $\begin{aligned} & .100 \\ & .000 \end{aligned}$ | $\begin{aligned} & .200 \\ & .070 \end{aligned}$ | $\begin{gathered} 2.6 \\ 0 \end{gathered}$ | $\begin{gathered} 5.0 \\ 1.77 \end{gathered}$ | 2 |
| $\begin{gathered} \mathrm{B} \\ \mathrm{~B}_{1} \end{gathered}$ | $\begin{aligned} & .015 \\ & .015 \end{aligned}$ | $\begin{aligned} & .020 \\ & .055 \end{aligned}$ | $\begin{gathered} .381 \\ .39 \end{gathered}$ | $\begin{aligned} & .508 \\ & 1.39 \end{aligned}$ |  |
| $\begin{aligned} & \mathrm{C} \\ & \mathrm{D} \end{aligned}$ | $\begin{gathered} .008 \\ 1.380 \\ \hline \end{gathered}$ | $\begin{gathered} .012 \\ 1.420 \\ \hline \end{gathered}$ | $\begin{gathered} .204 \\ 35.06 \\ \hline \end{gathered}$ | $\begin{gathered} .304 \\ 36.06 \end{gathered}$ |  |
| $\begin{gathered} E \\ \mathbf{E}_{1} \\ \hline \end{gathered}$ | $\begin{array}{r} .600 \\ .485 \\ \hline \end{array}$ | $\begin{aligned} & .625 \\ & .515 \end{aligned}$ | $\begin{aligned} & 15.24 \\ & 12.32 \end{aligned}$ | $\begin{aligned} & 15.87 \\ & 13.08 \\ & \hline \end{aligned}$ | . |
| $\begin{aligned} & \mathbf{e}_{1} \\ & \mathbf{e}_{\mathbf{A}} \\ & \hline \end{aligned}$ | $\begin{aligned} & .100 \mathrm{TP} \\ & .600 \mathrm{TP} \end{aligned}$ |  | $\begin{aligned} & \text { 2.54 TP } \\ & \text { 15.24 TP } \end{aligned}$ |  | $\begin{aligned} & 3 \\ & 3 \end{aligned}$ |
| $\begin{gathered} \mathrm{L} \\ \mathrm{~L}_{2} \end{gathered}$ | $\begin{aligned} & .100 \\ & .000 \end{aligned}$ | $\begin{aligned} & .200 \\ & .030 \end{aligned}$ | $\begin{gathered} 2.6 \\ 0 \end{gathered}$ | $\begin{aligned} & 5.0 \\ & .76 \end{aligned}$ |  |
| a | 0 | 15 | 00 | 150 | 4 |
| N | 28 |  | 28 |  | 5 |
| $\mathrm{N}_{1}$ | 0 |  | 0 |  | 6 |
| $\begin{gathered} \mathbf{Q}_{1} \\ \mathrm{~S} \end{gathered}$ | $\begin{aligned} & .020 \\ & .040 \end{aligned}$ | $\begin{array}{r} .070 \\ .070 \\ \hline \end{array}$ | $\begin{gathered} .51 \\ 1.02 \end{gathered}$ | $\begin{aligned} & 1.77 \\ & 1.77 \end{aligned}$ |  |
| See Note | 1 |  |  |  |  |

92CM-20250

[^22]$\qquad$

## DIMENSIONAL OUTLINES

## Ceramic Dual-in-Line Packages (Cont'd)



NOTES

1. Refer to Rules for Dimensioning (JEDEC Publication No. 13) for Axial Lead Product Outlines.
2. Leads within $0.005^{\prime \prime}(0.12 \mathrm{~mm})$ radius of True Position (TP) at gauge plane with maximum material condition and unit installed.
3. $e_{A}$ applies in zone $L_{2}$ when unit installed.
4. $a$ applies to spread leads prior to installation.
5. $N$ is the maximum quantity of lead positions.
6. $N_{1}$ is the quantity of allowable missing leads.
7. $B_{1}$ applies to all leads except the four end leads which have one-half the normal width ( $\mathrm{B}_{1} \mathrm{~min}$. $=0.025 \mathrm{in}$.)

## JEDEC MO-001-AB

14-Lead

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.155 | 0.200 |  | 3.94 | 5.08 |
| $A_{1}$ | 0.020 | 0.050 |  | 0.51 | 1.27 |
| B | 0.014 | 0.020 |  | 0.356 | 0.508 |
| B1 | 0.050 | 0.065 |  | 1.27 | 1.65 |
| C | 0.008 | $\bullet 0.012$ |  | 0.204 | 0.304 |
| D | 0.745 | 0.770 |  | 18.93 | 19.55 |
| E | 0.300 | 0.325 |  | 7.62 | 8.25 |
| E1 | 0.240 | 0.260 |  | 6.10 | 6.60 |
| e1 | $\begin{aligned} & 0.100 \mathrm{TP} \\ & 0.300 \mathrm{TP} \end{aligned}$ |  | 2 | $\begin{aligned} & 2.54 \mathrm{TP} \\ & \text { 7.62 TP } \end{aligned}$ |  |
| eA |  |  | 2,3 |  |  |
| L | 0.125 | 0.150 |  | 3.18 | 3.81 |
| $L_{2}$ | 0.000 | 0.030 |  | 0.000 | 0.76 |
| $a$ | 00 | 150 | 4 | 00 | 150 |
| N | 14 |  | 5 | 14 |  |
| $\mathrm{N}_{1}$ | 0 |  | 6 | 0 |  |
| Q1 | 0.040 | 0.075 |  | 1.02 | 1.90 |
| S | 0.065 | 0.090 |  | 1.66 | 2.28 |

JEDEC MO-001-AC
16-Lead
(except types CD4026AF, CD4029AF, CD4031AF, CD4033AF)

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.155 | 0.200 |  | 3.94 | 5.08 |
| $\mathrm{A}_{1}$ | 0.020 | 0.050 |  | 0.51 | 1.27 |
| B | 0.014 | 0.020 |  | 0.356 | 0.508 |
| $\mathrm{B}_{1}$ | 0.035 | 0.065 |  | 0.89 | 1.65 |
| C | 0.008 | ${ }^{\bullet} 0.012$ |  | 0.204 | 0.304 |
| D | 0.745 | 0.785 |  | 18.93 | 19.93 |
| E | 0.300 | 0.325 |  | 7.62 | 8.25 |
| $\mathrm{E}_{1}$ | 0.240 | 0.260 |  | 6.10 | 6.60 |
| ${ }^{1} 1$ | $\begin{aligned} & 0.100 \mathrm{TP} \\ & 0.300 \mathrm{TP} \end{aligned}$ |  | 2 | $\begin{aligned} & 2.54 \mathrm{TP} \\ & 7.62 \mathrm{TP} \end{aligned}$ |  |
| ${ }^{\text {e }}$ A |  |  | 2, 3 |  |  |
| L | 0.125 | 0.150 |  | 3.18 | 3.81 |
| $L_{2}$ | 0.000 | 0.030 |  | 0.000 | 0.76 |
| $a$ | $0^{\circ}$ | $15^{\circ}$ | 4 | $0^{0}$ | $15^{\circ}$ |
| N | 16 |  | 5 | 16 |  |
| $\mathrm{N}_{1}$ | 0 |  | 6 | 0 |  |
| $\mathrm{a}_{1}$ | 0.040 | 0.075 |  | 1.02 | 1.90 |
| S | 0.015 | 0.060 |  | 0.39 | 1.52 |

92CM-15967RI

JEDEC MO-001-AG
16-Lead
(Types CD4026AF, CD4029AF, CD4031AF, CD4033AF)

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.165 | 0.210 |  | 4.20 | 5.33 |
| $A_{1}$ | 0.015 | 0.045 |  | 0.381 | 1.14 |
| B | 0.015 | 0.020 |  | 0.381 | 0.508 |
| $\mathrm{B}_{1}$ | 0.045 | 0.070 | 7 | 1.15 | 1.77 |
| C | 0.009 | $\bullet 0.011$ |  | 0.229 | 0.279 |
| D | 0.750 | 0.795 |  | 19.05 | 20.19 |
| E | 0.295 | 0.325 |  | 7.50 | 8.25 |
| $\mathrm{E}_{1}$ | 0.245 | 0.300 |  | 6.23 | 7.62 |
| ${ }^{1} 1$ | $\begin{aligned} & 0.100 \mathrm{TP} \\ & 0.300 \mathrm{TP} \end{aligned}$ |  | 2 | $\begin{aligned} & 2.54 \mathrm{TP} \\ & 7.62 \mathrm{TP} \end{aligned}$ |  |
| ${ }^{\text {en }}$ |  |  | 2, 3 |  |  |
| L | 0.120 | 0.160 |  | 3.05 | 4.06 |
| L. 2 | 0.000 | 0.030 |  | 0.000 | 0.76 |
| $a$ | 20 | $15^{\circ}$ | 4 | 20 | $15^{\circ}$ |
| N | 16 |  | 5 | 16 |  |
| $\mathrm{N}_{1}$ | 0 |  | 6 | 0 |  |
| $\mathrm{Q}_{1}$ | 0.050 | 0.080 |  | 1.27 | 2.03 |
| S | 0.010 | 0.060 |  | 0.254 | 1.52 | 92CM-22284

This outline differs from the standard 16Lead frit-seal ceramic package MO-001-AC as indicated by the values in italics shown in the chart above.

When these devices are supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed 0.013'.

## DIMENSIONAL OUTLINES

Ceramic Dual-in-Line Welded Seal
16-Lead Side-Brazed


* WHEN THIS DEVICE IS SUPPLIED SOLDER-DIPPED, THE MAX. LEAD

THICKNESS (NARROW PORTION) WILL NOT EXCEED 0.013 ( 0.33 mm )
NOTE: DIMENSIONS IN PARENTHESES ARE IN MILLIMETERS AND ARE DERIVED FROM THE BASIC INCH DIMENSIONS

Plastic Dual-in-Line Packages


NOTES:

1. Refer to Rules for Dimensioning (JEDEC Publication No. 13) for Axial Lead Product Outlines.
2. Leads within $0.005^{\prime \prime}(0.12 \mathrm{~mm})$ radius of True Position (TP) at guage plane with maximum material condition and unit installed.
3. $e_{A}$ applies in zone $L_{2}$ when unit installed.
4. a applies to spread leads prior to installation.
5. N is the maximum quantity of lead positions.
6. $N_{1}$ is the quantity of allowable missing leads.

JEDEC MO-001-AB
14-Lead

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.155 | 0.200 |  | 3.94 | 5.08 |
| $A_{1}$ | 0.020 | 0.050 |  | 0.51 | 1.27 |
| B | 0.014 | 0.020 |  | 0.356 | 0.508 |
| B1 | 0.050 | 0.065 |  | 1.27 | 1.65 |
| C | 0.008 | ${ }^{\bullet} 0.012$ |  | 0.204 | 0.304 |
| D | 0.745 | 0.770 |  | 18.93 | 19.55 |
| E | 0.300 | 0.325 |  | 7.62 | 8.25 |
| $\mathrm{E}_{1}$ | 0.240 | 0.260 |  | 6.10 | 6.60 |
| e1 | $\begin{aligned} & 0.100 \mathrm{TP} \\ & 0.300 \mathrm{TP} \end{aligned}$ |  | $\begin{array}{r} 2 \\ 2,3 \end{array}$ | $\begin{aligned} & 2.54 \mathrm{TP} \\ & 7.62 \mathrm{TP} \end{aligned}$ |  |
| eA |  |  |  |  |  |
| L | 0.125 | 0.150 |  | 3.18 | 3.81 |
| $\mathrm{L}_{2}$ | 0.000 | 0.030 |  | 0.000 | 0.76 |
| $a$ | 00 | 150 | 4 | 00 | 150 |
| N | 14 |  | 5 | 14 |  |
| $\mathrm{N}_{1}$ | 0 |  | 6 | 0 |  |
| $\mathrm{Q}_{1}$ | 0.040 | 0.075 |  | 1.02 | 1.90 |
| S | 0.065 | 0.090 |  | 1.66 | 2.28 |

JEDEC MO-001-AC 16-Lead

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| A | 0.155 | 0.200 |  | 3.94 | 5.08 |
| $\mathrm{A}_{1}$ | 0.020 | 0.050 |  | 0.51 | 1.27 |
| B | 0.014 | 0.020 |  | 0.356 | 0.508 |
| $\mathrm{B}_{1}$ | 0.035 | 0.065 |  | 0.89 | 1.65 |
| C | 0.008 | ${ }^{\bullet} 0.012$ |  | 0.204 | 0.304 |
| D | 0.745 | 0.785 |  | 18.93 | 19.93 |
| E | 0.300 | 0.325 |  | 7.62 | 8.25 |
| $\mathrm{E}_{1}$ | 0.240 | 0.260 |  | 6.10 | 6.60 |
| $\mathrm{e}_{1}$ | 0.100 TP |  | 2 | 2.54 TP |  |
| ${ }^{\text {e }}$ A | 0.300 TP |  | 2, 3 | 7.62 TP |  |
| L | 0.125 | 0.150 |  | 3.18 | 3.81 |
| $L_{2}$ | 0.000 | 0.030 |  | 0.000 | 0.76 |
| $a$ | $0^{0}$ | $15^{\circ}$ | 4 | $0^{\circ}$ | $15^{\circ}$ |
| N | 16 |  | 5 | 16 |  |
| $N_{1}$ | 0 |  | 6 | 0 |  |
| $\mathrm{O}_{1}$ | 0.040 | 0.075 |  | 1.02 | 1.90 |
| S | 0.015 | 0.060 |  | 0.39 | 1.52 |

When these devices are supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed $0.013^{\prime \prime}$.


JEDEC MO-006-AG
12-Lead

| SYMBOL | INCHES |  | NOTE | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | MAX. |  | MIN. | MAX. |
| a | 0.230 TP |  | 2 | 5.84 TP |  |
| A1 | 0 | 10 |  | 0 | 0 |
| A2 | 0.165 | 0.185 |  | 4.19 | 4.70 |
| $\phi$ B | 0.016 | 0.019 | 3 | 0.407 | 0.482 |
| $\phi \mathrm{B}_{1}$ | 0 | 0 |  | 0 | 0 |
| $\phi \mathrm{B}_{2}$ | 0.016 | 0.021 | 3 | 0.407 | 0.533 |
| $\phi$ D | 0.335 | 0.370 |  | 8.51 | 9.39 |
| $\phi \mathrm{D}_{1}$ | 0.305 | 0.335 |  | 7.75 | 8.50 |
| F1 | 0.020 | 0.040 |  | 0.51 | 1.01 |
| j | 0.028 | 0.034 |  | 0.712 | 0.863 |
| k | 0.029 | 0.045 | 4 | 0.74 | 1.14 |
| L1 | 0.000 | 0.050 | 3 | 0.00 | 1.27 |
| L2 | 0.250 | 0.500 | 3 | 6.4 | 12.7 |
| L3 | 0.500 | 0.562 | 3 | 12.7 | 14.27 |
| $\boldsymbol{\alpha}$ | 360 TP |  |  | 360 TP |  |
| N | 12 |  | 6 | 12 |  |
| $\mathrm{N}_{1}$ | 1 |  | 5 | 1 |  |

NOTES:

1. Refer to Rules for Dimensioning Axial Lead Product Outlines.
2. Leads at gauge plane within $0.007^{\prime \prime}(0.178 \mathrm{~mm})$ radius of True Position (TP) at maximum material condition.
3. $\phi \mathrm{B}$ applies between $\mathrm{L}_{1}$ and $\mathrm{L}_{2}$. $\phi \mathrm{B}_{2}$ applies between $\mathrm{L}_{2}$ and $0.500^{\prime \prime}(12.70 \mathrm{~mm})$ from seating plane. Diamerer is uncontrolled in $\mathrm{L}_{1}$ and beyond $0.500^{\prime \prime}(12.70 \mathrm{~mm})$.
4. Measure from Max. $\phi \mathrm{D}$.
5. $N_{1}$ is the quantity of allowable missing leads.
6. $N$ is the maximum quantity of lead positions.

## Application Notes

## Operating Considerations for RCA Solid State Devices

Solid state devices are being designed into an increasing variety of electronic equipment because of their high standards of reliability and performance．However，it is essential that equipment designers be mindful of good engineering practices in the use of these devices to achieve the desired performance．

This Note summarizes important operating recommen－ dations and precautions which should be followed in the interest of maintaining the high standards of performance of solid state devices．

The ratings included in RCA Solid State Devices data bulletins are based on the Absolute Maximum Rating System，which is defined by the following Industry Standard （JEDEC）statement：

Absolute－Maximum Ratings are limiting values of opera－ ting and environmental conditions applicable to any electron device of a specified type as defined by its published data， and should not be exceeded under the worst probable conditions．

The device manufacturer chooses these values to provide acceptable serviceability of the device，taking no responsi－ bility for equipment variations，environmental variations，and the effects of changes in operating conditions due to variations in device characteristics．

The equipment manufacturer should design so that initially and throughout life no absolute－maximum value for the intended service is exceeded with any device under the worst probable operating conditions with respect to supply－ voltage variation，equipment component variation，equip－ ment control adjustment，load variation，signal variation， environmental conditions，and variations in device charac－ teristics．

It is recommended that equipment manufacturers consult RCA whenever device applications involve unusual electrical， mechanical or environmental operating conditions．

## GENERAL CONSIDERATIONS

The design flexibility provided by these devices makes possible their use in a broad range of applications and under
many different operating conditions．When incorporating these devices in equipment，therefore，designers should anticipate the rare possibility of device failure and make certain that no safety hazard would result from such an occurrence．

The small size of most solid state products provides obvious advantages to the designers of electronic equipment． However，it should be recognized that these compact devices usually provide only relatively small insulation area between adjacent leads and the metal envelope．When these devices are used in moist or contaminated atmospheres，therefore， supplemental protection must be provided to prevent the development of electrical conductive paths across the relatively small insulating surfaces．For specific information on voltage creepage，the user should consult references such as the JEDEC Standard No． 7 ＂Suggested Standard on Thyristors，＂and JEDEC Standard RS282＂Standards for Silicon Rectifier Diodes and Stacks＂．

The metal shells of some solid state devices operate at the collector voltage and for some rectifiers and thyristors at the anode voltage．Therefore，consideration should be given to the possibility of shock hazard if the shells are to operate at voltages appreciably above or below ground potential．In general，in any application in which devices are operated at voltages which may be dangerous to personnel，suitable precautionary measures should be taken to prevent direct contact with these devices．

Devices should not be connected into or disconnected from circuits with the power on because high transient voltages may cause permanent damage to the devices．

## TESTING PRECAUTIONS

In common with many electronic components，solid－state devices should be operated and tested in circuits which have reasonable values of current limiting resistance，or other forms of effective current overload protection．Failure to observe these precautions can cause excessive internal heating of the device resulting in destruction and／or possible shattering of the enclosure．

## TRANSISTORS AND THYRISTORS WITH FLEXIBLE LEADS

Flexible leads are usually soldered to the circuit elements. It is desirable in all soldering operatings to provide some slack or an expansion elbow in each lead to prevent excessive tension on the leads. It is important during the soldering operation to avoid excessive heat in order to prevent possible damage to the devices. Some of the heat can be absorbed if the flexible lead of the device is grasped between the case and the soldering point with a pair of pliers.

## TRANSISTORS AND THYRISTORS WITH MOUNTING FLANGES

The mounting flanges of JEDEC-type packages such as the TO-3 or TO-66 often serve as the collector or anode terminal. In such cases, it is essential that the mounting flange be securely fastened to the heat sink, which may be the equipment chassis. Under no circumstances, however, should the mounting flange of a transistor be soldered directly to the heat sink or chassis because the heat of the soldering operation could permanently damage the device. Soldering is the preferred method for mounting thyristors; see "Rectifiers and Thyristors," below. Devices which cannot be soldered can be installed in commercially available sockets. Electrical connections may also be made by soldering directly to the terminal pins. Such connections may be soldered to the pins close to the pin seals provided care is taken to conduct excessive heat away from the seals; otherwise the heat of the soldering operation could crack the pin seals and damage the device.

During operation, the mounting-flange temperature is higher than the ambient temperature by an amount which depends on the heat sink used. The heat sink must have sufficient thermal capacity to assure that the heat dissipated in the heat sink itself does not raise the device mountingflange temperature above the rated value. The heat sink or chassis may be connected to either the positive or negative supply.

In many applications the chassis is connected to the voltage-supply terminal. If the recommended mounting hardware shown in the data bulletin for the specific solid-state device is not available, it is necessary to use either an anodized aluminum insulator having high thermal conductivity or a mica insulator between the mounting-flange and the chassis. If an insulating aluminum washer is required, it should be drilled or punched to provide the two mounting holes for the terminal pins. The burrs should then be removed from the washer and the washer anodized. To insure that the anodized insulating layer is not destroyed during mounting, it is necessary to remove the burrs from the holes in the chassis.

It is also important that an insulating bushing, such as glass-filled nylon, be used between each mounting bolt and the chassis to prevent a short circuit. However, the insulating bushing should not exhibit shrinkage or softening under the operating temperatures encountered. Otherwise the thermal resistance at the interface between device and heat sink may increase as a result of decreasing pressure.

## PLASTIC POWER TRANSISTORS AND THYRISTORS

RCA power transistors and thyristors (SCR's and triacs) in molded-silicone-plastic packages are available in a wide range of power-dissipation ratings and a variety of package configurations. The following paragraphs provide guidelines for handling and mounting of these plastic-package devices, recommend forming of leads to meet specific mounting requirements, and describe various mounting arrangements, thermal considerations, and cleaning methods. This information is intended to augment the data on electrical characteristics, safe operating area, and performance capabilities in the technical bulletin for each type of plastic-package transistor or thyristor.

## Lead-Forming Techniques

The leads of the RCA VERSAWATT in-line plastic packages can be formed to a custom shape, provided they are not indiscriminately twisted or bent. Although these leads can be formed, they are not flexible in the general sense, nor are they sufficiently rigid for unrestrained wire wrapping

Before an attempt is made to form the leads of an in-line package to meet the requirements of a specific application, the desired lead configuration should be determined, and a lead-bending fixture should be designed and constructed. The use of a properly designed fixture for this operation eliminates the need for repeated lead bending. When the use of a special bending fixture is not practical, a pair of long-nosed pliers may be used. The pliers should hold the lead firmly between the bending point and the case, but should not touch the case.

When the leads of an in-line plastic package are to be formed, whether by use of long-nosed pliers or a special bending fixture, the following precautions must be observed to avoid internal damage to the device:

1. Restrain the lead between the bending point and the plastic case to prevent relative movement between the lead and the case.
2. When the bend is made in the plane of the lead (spreading), bend only the narrow part of the lead.
3. When the bend is made in the plane perpendicular to that of the leads, make the bend at least $1 / 8$ inch from the plastic case.
4. Do not use a lead-bend radius of less than $1 / 16$ inch.
5. Avoid repeated bending of leads.

The leads of the TO-220AB VERSAWATT in-line package are not designed to withstand excessive axial pull. Force in this direction greater than 4 pounds may result in permanent damage to the device. If the mounting arrangement tends to impose axial stress on the leads, some method of strain relief should be devised.

Wire wrapping of the leads is permissible, provided that the lead is restrained between the plastic case and the point of the wrapping. Soldering to the leads is also allowed. The maximum soldering temperature, however, must not exceed $275^{\circ} \mathrm{C}$ and must be applied for not more than 5 seconds at a distance not less than $1 / 8$ inch from the plastic case. When
wires are used for connections, care should be exercised to assure that movement of the wire does not cause movement of the lead at the lead-to-plastic junctions.

The leads of RCA molded-plastic high-power packages are not designed to be reshaped. However, simple bending of the leads is permitted to change them from a standard vertical to a standard horizontal configuration, or conversely. Bending of the leads in this manner is restricted to three 90 -degree bends; repeated bendings should be avoided.

## Mounting

Recommended mounting arrangements and suggested hardward for the VERSAWATT package are given in the data bulletins for specific devices and in RCA Application Note AN-4142. When the package is fastened to a heat sink, a rectangular washer (RCA Part No. NR231A) is recommended to minimize distortion of the mounting flange. Excessive distortion of the flange could cause damage to the package. The washer is particularly important when the size of the mounting hole exceeds 0.140 inch ( $6-32$ clearance). Larger holes are needed to accommodate insulating bushings; however, the holes should not be larger than necessary to provide hardware clearance and, in any case, should not exceed a diameter of 0.250 inch.

Flange distortion is also possible if excessive torque is used during mounting. A maximum torque of 8 inch-pounds is specified. Care should be exercised to assure that the tool used to drive the mounting screw never comes in contact with the plastic body during the driving operation. Such contact can result in damage to the plastic body and internal device connections. An excellent method of avoiding this problem is to use a spacer or combination spacer-isolating bushing which raises the screw head or nut above the top surface of the plastic body. The material used for such a spacer or spacer-isolating bushing should, of course, be carefully selected to avoid "cold flow" and consequent reduction in mounting force. Suggested materials for these bushings are diallphtalate, fiberglass-filled nylon, or fiberglass-filled polycarbonate. Unfilled nylon should be avoided.

Modification of the flange can also result in flange distortion and should not be attempted. The package should not be soldered to the heat sink by use of lead-tin solder because the heat required with this type of solder will cause the junction temperature of the device to become excessively high.

The TO-220AA plastic package can be mounted in commercially available TO-66 sockets, such as .UID Electronics Corp. Socket No. PTS-4 or equivalent. For testing purposes, the $T O-220 \mathrm{AB}$ in-line package can be mounted in a Jetron Socket No. DC74-104 or equivalent. Regardless of the mounting method, the following precautions should be taken:

1. Use appropriate hardware.
2. Always fasten the package to the heat sink before the leads are soldered to fixed terminals.
3. Never allow the mounting tool to come in contact with the plastic case.
4. Never exceed a torque of 8 inch-pounds.
5. Avoid oversize mounting holes.
6. Provide strain relief if there is any probability that axial stress will be applied to the leads.
7. Use insulating bushings to prevent hot-creep problems. Such bushings should be made of diallphthalate, fiber-glass-filled nylon, or fiberglass-filled polycarbonate.
The maximum allowable power dissipation in a solid state device is limited by the junction temperature. An important factor in assuring that the junction temperature remains below the specified maximum value is the ability of the associated thermal circuit to conduct heat away from the device.

When a solid state device is operated in free air, without a heat sink, the steady-state thermal circuit is defined by the junction-to-free-air thermal resistance given in the published data for the device. Thermal considerations require that a free flow of air around the device is always present and that the power dissipation be maintained below the level which would cause the junction temperature to rise above the maximum rating. However, when the device is mounted on a heat sink, care must be taken to assure that all portions of the thermal circuit are considered.

To assure efficient heat transfer from case to heat sink when mounting RCA molded-plastic solid state power devices, the following special precautions should be observed:

1. Mounting torque should be between 4 and 8 inchpounds.
2. The mounting holes should be kept as small as possible.
3. Holes should be drilled or punched clean with no burrs or ridges, and chamfered to a maximum radius of 0.010 inch.
4. The mounting surface should be flat within 0.002 inch/inch.
5. Thermal grease (Dow Corning 340 or equivalent) should always be used on both sides of the insulating washer if one is employed.
6. Thin insulating washers should be used. (Thickness of factory-supplied mica washers range from 2 to 4 mils).
7. A lock washer or torque washer, made of material having sufficient creep strength, should be used to prevent degradation of heat sink efficiency during life.

A wide variety of solvents is available for degreasing and flux removal. The usual practice is to submerge components in a solvent bath for a specified time. However, from a reliability stand point it is extremely important that the solvent, together with other chemicals in the solder-cleaning system (such as flux and solder covers), do not adversely affect the life of the component. This consideration applies to all non-hermetic and molded-plastic components.

It is, of course, impractical to evaluate the effect on long-term device life of all cleaning solvents, which are marketed with numerous additives under a variety of brand names. These solvents can, however, be classified with
respect to their component parts as either acceptable or unacceptable. Chlorinated solvents tend to dissolve the outer package and, therefore, make operation in a humid atmosphere unreliable. Gasoline and other hydrocarbons cause the inner encapsulant to swell and damage the transistor. Alcohol is an acceptable solvent. Examples of specific, acceptable alchols are isopropanol, methanol, and special denatured alcohols, such as SDA1, SDA30, SDA34, and SDA44.

Care must also be used in the selection of fluxes for lead soldering. Rosin or activated rosin fluxes are recommended, while organic or acid fluxes are not. Examples of acceptable fluxes are:

1. Alpha Reliaros No. 320-33
2. Alpha Reliaros No. 346
3. Alpha Reliaros No. 711
4. Alpha Reliafoam No. 807
5. Alpha Reliafoam No. 809
6. Alpha Reliafoam No. 811-13
7. Alpha Reliafoam No. 815-35
8. Kester No. 44

If the completed assembly is to be encapsulated, the effect on the molded-plastic transistor must be studied from both a chemical and a physical standpoint.

## RECTIFIERS AND THYRISTORS

A surge-limiting impedance should always be used in series with silicon rectifiers and thyristors. The impedance value must be sufficient to limit the surge current to the value specified under the maximum ratings. This impedance may be provided by the power transformer winding, or by an external resistor or choke.

A very efficient method for mounting thyristors utilizing the "modified TO-5" package is to provide intimate contact between the heat sink and at least one half of the base of the device opposite the leads. This package can be mounted to the heat sink mechanically with glue or an expoxy adhesive, or by soldering, the most efficient method.

The use of a "self-jigging" arrangement and a solder preform is recommended. If each unit is soldered individually, the heat source should be held on the heat sink and the solder on the unit. Heat should be applied only long enough to permit solder to flow freely. For more detailed thyristor mounting considerations, refer to Application Note AN3822, "Thermal Considerations in Mounting of RCA Thyristors".

## MOS FIELD-EFFECT TRANSISTORS

Insulated-Gate Metal Oxide-Semiconductor Field-Effect Transistors (MOS FETs), like bipolar high-frequency transistors, are susceptible to gate insulation damage by the electrostatic discharge of energy through the devices. Electrostatic discharges can occur in an MOS FET if a type with an unprotected gate is picked up and the static charge, built in the handler's body capacitance, is discharged through the device. With proper handling and applications procedures, however, MOS transistors are currently being extensively used in production by numerous equipment manufacturers in military, industrial, and consumer applica-
tions, with virtually no problems of damage due to electrostatic discharge.

In some MOS FETs, diodes are electrically connected between each insulated gate and the transistor's source. These diodes offer protection against static discharge and in-circuit transients without the need for external shorting mechanisms. MOS FETs which do not include gateprotection diodes can be handled safely if the following basic precautions are taken:

1. Prior to assembly into a circuit, all leads should be kept shorted together either by the use of metal shorting springs attached to the device by the vendor, or by the insertion into conductive material such as "ECCOSORB" LD26" or equivalent.
(NOTE: Polystyrene insulating "SNOW" is not sufficiently conductive and should not be used.)
2. When devices are removed by hand from their carriers, the hand being used should be grounded by any suitable means, for example, with a metallic wristband.
3. Tips of soldering irons should be grounded.
4. Devices should never be inserted into or removed from circuits with power on.

## RF POWER TRANSISTORS

## Mounting and Handling

Stripline rf devices should be mounted so that the leads are not bent or pulled away from the stud (heat sink) side of the device. When leads are formed, they should be supported to avoid transmitting the bending or cutting stress to the ceramic portion of the device. Excessive stresses may destroy the hermeticity of the package without displaying visible damage.

Devices employing silver leads are susceptible to tarnishing; these parts should not be removed from the original tarnish-preventive containers and wrappings until ready for use. Lead solderability is retarded by the presence of silver tarnish; the tarnish can be removed with a silver cleaning solution, such as thiourea.

The ceramic bodies of many rf devices contain beryllium oxide as a major ingredient. These portions of the transistors should not be crushed, ground, or abraded in any way because the dust created could be hazardous if inhaled.

## Operating

Forward-Biased Operation. For Class A or AB operation, the allowable quiescent bias point is determined by reference to the infrared safe-area curve in the appropriate data bulletin. This curve depicts the safe current/voltage combinations for extended continuous operation.

Load VSWR. Excessive collector load or tuning mismatch can cause device destruction by over-dissipation or secondary breakdown. Mismatch capability is generally included on the data bulletins for the more recent rf transistors.

See RCA RF Power Transitor Manual, Technical Series RMF-430, pp 39-41, for additional information concerning the handling and mounting of rf power transistors.

[^23]
## INTEGRATED CIRCUITS

## Handing

All COS/MOS gate inputs have a resistor/diode gate protection network. All transmission gate inputs and all outputs have diode protection provided by inherent p-n junction diodes. These diode networks at input and output interfaces protect COS/MOS devices from gate-oxide failure in handling environments where static discharge is not excessive. In low-temperature, low-humidity environments, improper handling may result in device damage. See ICAN-6000, "Handling and Operating Considerations for MOS Integrated Circuits", for proper handling procedures.

## Mounting

Integrated circuits are normally supplied with lead-tin plated leads to facilitate soldering into circuit boards. In those relatively few applications requiring welding of the device leads, rather than soldering, the devices may be obtained with gold or nickel plated Kovar leads.* It should be recognized that this type of plating will not provide complete protection against lead corrosion in the presence of high humidity and mechanical stress. The aluminum-foil-lined cardboard "sandwich pack" employed for static protection of the flat-pack also provides some additional protection against lead corrosion, and it is recommended that the devices be stored in this package until used.

When integrated circuits are welded onto printed circuit boards or equipment, the presence of moisture between the closely spaced terminals can result in conductive paths that may impair device performance in high-impedance applications. It is therefore recommended that conformal coatings or potting be provided as an added measure of protection against moisture penetration.

In any method of mounting integrated circuits which involves bending or forming of the device leads, it is extremely important that the lead be supported and clamped between the bend and the package seal, and that bending be done with care to avoid damage to lead plating. In no case should the radius of the bend be less than the diameter of the lead, or in the case of rectangular leads, such as those used in RCA 14-lead and 16-lead flat-packages, less than the lead thickness. It is also extremely important that the ends of the bent leads be straight to assure proper insertion through the holes in the printed-circuit board.

## Operating

## Unused Inputs

All unused input leads must be connected to either $\mathrm{V}_{\mathrm{SS}}$ or $V_{D D}$, whichever is appropriate for the logic circuit involved. A floating input on a high-current type, such as the CD4049 or CD4050, not only can result in faulty logic operation, but can cause the maximum power dissipation of 200 milliwatts to be exceeded and may result in damage to the device. Inputs to these types, which are mounted on printed-circuit boards that may temporarily become unterminated, should have a pull-up resistor to $\mathrm{V}_{\mathrm{SS}}$ or $\mathrm{V}_{\mathrm{DD}}$. A useful range of values for such resistors is from 10 kilohms to 1 megohm.

## Input Signals

Signals shall not be applied to the inputs while the device power supply is off unless the input current is limited to a steady state value of less than 10 milliamperes. Input currents of less than 10 milliamperes prevent device damage; however, proper operation may be impaired as a result of current flow through structural diode junctions.

## Output Short Circuits

Shorting of outputs to $\mathrm{V}_{\text {SS }}$ or $\mathrm{V}_{\mathrm{DD}}$ can damage many of the higher-output-current COS/MOS types, such as the CD4007, CD4041, CD4049, and CD4050. In general, these types can all be safely shorted for supplies up to 5 volts, but will be damaged (depending on type) at higher power-supply voltages. For cases in which a short-circuit load, such as the base of a p-n-p or an n-p-n bipolar transistor, is directly driven, the device output characteristics given in the published data should be consulted to determine the requirements for a safe operation below 200 milliwatts.

For detailed COS/MOS IC operating and handling considerations, refer to Application Note ICAN-6000 "Handling and Operating Considerations for MOS Integrated Circuits".

## SOLID STATE CHIPS

Solid state chips, unlike packaged devices, are nonhermetic devices, normally fragile and small in physical size, and therefore, require special handling considerations as follows:

1. Chips must be stored under proper conditions to insure that they are not subjected to a moist and/or contaminated atmosphere that could alter their electrical, physical, or mechanical characteristics. After the shipping container is opened, the chip must be stored under the following conditions:
A. Storage temperature, $40^{\circ} \mathrm{C}$ max.
B. Relative humidity, $50 \% \max$.
C. Clean, dust-free environment.
2. The user must exercise proper care when handling chips to prevent even the slightest physical damage to the chip.
3. During mounting and lead bonding of chips the user must use proper assembly techniques to obtain proper electrical, thermal, and mechanical performance.
4. After the chip has been mounted and bonded, any necessary procedure must be followed by the user to insure that these non-hermetic chips are not subjected to moist or contaminated atmosphere which might cause the development of electrical conductive paths across the relatively small insulating surfaces. In addition, proper consideration must be given to the protection of these devices from other harmful environments which could conceivably adversely affect their proper performance.
*Mil-M-38510A, paragraph 3.5.6.1 (a), lead material.

# Handling and Operating Considerations for MOS Integrated Circuits 

by S．Dansky<br>R．E．Funk

This Note describes practices for handling and operating MOS integrated circuits that will guard against device damage and assure optimum performance．

## Handling Considerations

The input protection networks incorporated in all RCA COS／MOS devices are effective in a wide variety of device handling situations．To be totally safe，however，it is desirable to restate the general conditions for eliminating all possibilities of device damage．

Because MOS devices have extremely high input resistance． they are susceptible to damage when exposed to extremely high static electrical charges．To avoid possible damage to the devices during handling，testing，or actual operation． therefore，the following procedures should be followed：

1．The leads of devices should be in contact with a conductive material，except when being tested or in actual operation，to avoid build－up of static charge．
2．Soldering－iron tips，metal parts of fixtures and tools， and handling facilities should be grounded．
3．Devices should not be inserted into or removed from circuits with the power on because transient voltages may cause permanent damage．
4．Signals should not be applied to the inputs while the device power supply is off．
5．All unused input leads must be connected to either $\mathrm{V}_{\text {SS }}$（ground）or $\mathrm{V}_{\mathrm{DD}}$（device supply），whichever is appropriate for the logic circuit involved．
Table I indicates general handling procedures recommended to prevent damage from static electrical charges．

## Handling of Unmounted Chips

In handling of unmounted chips，care should be taken to avoid differences in voltage potential．A conductive carrier， or a carrier having a conductive overlay，should be used．

Another important consideration is the sequence in which bonds are made；the $\mathrm{V}_{\mathrm{DD}}$（device supply）connection should always be made before the $\mathrm{V}_{\mathrm{SS}}$（ground）bond．

## Handling of Subassembly Boards

After COS／MOS units have been mounted on circuit boards，proper handling precautions should still be observed． Until these subassemblies are inserted into a complete system

Table I－General Handling Considerations

|  | Should be conductive | Should be grounded to common point |
| :---: | :---: | :---: |
| Handling Equipment | X |  |
| Metal Parts of Fixtures and Tools |  | $x$ |
| Handling Trays | $x$ | $x$ |
| Soldering Irons |  | X |
| Table Tops | $x$ | $x$ |
| Transport Carts |  | （Static Dis－ charge Straps） |
| Manufacturing Operating Personnel |  | －（Utilize grounded metal wrist straps） |
| General Handling of Devices |  | －（Utilize grounded metal wrist straps） |

Total protection results when personnel and materials are all at the same or ground potential．
Dry weather（relative humidity less than 30\％）tends to multiply the accumulation of static charges on any surface．Conversely， higher humidity levels tend to reduce the magnitude of the static voltage generated．In a low－humidity environment，the handling precautions listed above take on added importance and should be adhered to without exceptions．

[^24]in which the proper voltages are applied，the board is no more than an extension of the leads of the device mounted on the board．

It is good practice to put conductive clips or conductive tape ${ }^{1}$ on the circuit－board terminals．This precaution prevents static charges from being transmitted through the board wiring to the devices mounted on the board．

## Automatic Handling Equipment

When automatic handling equipment is used，static electricity may not always be eliminated through grounding

[^25]techniques alone. Automatic feed mechanisms must be insulated from the devices under test at the point where the devices are connected to the test set. The device-insulated part of the automatic handling mechanism (anvil transport) can generate very high levels of static electricity which are developed by the continuous flow of devices sliding over and then separating from the anvil. Total control of these static voltages is critical because of the high throughputs associated with automatic handling.

Fortunately, the resolution of this problem is simple, practical, and inexpensive. Ionized-air blowers, which supply large volumes of ionized air to objects that are to be charge neutralized, are commercially available from many supply sources. Field experience with ionized-air techniques reveals this method to be extremely effective in eliminating static electricity when grounding techniques cannot be used.

## Lead Bending and Forming Considerations

Other problems that can occur in handling COS/MOS devices relate to the proper handling of leads during mounting of devices. In any method of mounting integrated circuits that involves bending or forming of the device leads, it is extremely important that the leads be supported and clamped between the bend and the package seal, and that bends be made with extreme care to avoid damage to lead plating. In no case should the radius of the bend be less than the diameter of the lead, or in the case of rectangular leads, such as those used in RCA 14-lead flat-packaged integrated circuits, less than the lead thickness. It is also extremely important that the ends of the bent leads be perfectly straight and parallel to assure easy insertion through the holes in the printed-circuit board.

Bending, forming, and clinching of integrated-circuit leads produce stresses in the leads and can cause stresses in the seals if the above precautions are not taken. In addition, wide variations in temperature during normal use result in stresses in the device leads. Tests of 14-lead flat-pack integrated circuits, conducted under worst-case conditions in which the packages were rigidly attached to posts extending from the printed-circuit board, showed that over a temperature swing of $180^{\circ} \mathrm{C}$ (from $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ ) the stress developed in the leads, the tensile pull on the leads, the shear stress introduced on the seal, and the tensile stress developed in the seal were all well within the limits for these materials. The use of thermal-stress-relief bends is, therefore, not necessary.

## Soldering Time and Temperature

All device leads can withstand exposure to temperatures as high as $265^{\circ} \mathrm{C}$ for as long as ten seconds, and as close as $1 / 16 \pm 1 / 32$ inch from the body of the device.

## Storing of COS/MOS Chips

COS/MOS chips, unlike most packaged devices, are non-hermetic devices, fragile and small in physical size, and
therefore require the following special handling considerations:

1. Chips must be stored under proper conditions to assure that they are not subjected to a moist and/or contaminated atmosphere that could alter their electrical, physical, or mechanical characteristics. After the shipping container is opened, the storage temperature should not exceed $40^{\circ} \mathrm{C}$ and the environment should be clean, dust-free, and less than $50 \%$ relative humidity.
2. After mounting and bonding, these non-hermetic chips should not be subjected to moist or contaminated atmospheres that might cause the development of electrical conductive paths across the relatively small insulating surfaces. In addition, proper consideration must be given to the protection of these devices from other harmful environments which could conceivably adversely affect their proper performance.
For further information on COS/MOS chip handling, refer to File No. 517, "CD4000AH Series COS/MOS Chips".

## Storing of Printed-Circuit Boards

Excessive humidity (greater than 60\%) should be avoided during circuit-board check-out to prevent the false impression of excessive device internal leakage. High relative humidity may cause leakage paths between closely spaced elements of the circuit boards, such as the terminals and insulated metallized connection strips. Normally this added leakage is not significant in non-COS/MOS devices. However, when the nanoampere-leakage advantages of COS/MOS devices are desired, leakage currents on circuit boards or non-hermetic modules which are affected by high humidity become of major concern and must be controlled by coating, cleaning, or better environmental controls.

## Effects of Humidity on Static Electricity

Dry weather (relative humidity less than $30 \%$ ) tends to multiply the accumulation of static charges on any surface. Conversely, higher humidity levels tend to reduce the magnitude of the static voltage generated. In a low-humidity environment, the handling precautions listed in Table I take on added importance and should be adhered to without exceptions.

## Electrical Failure Modes Due To Improper Handling

When the possibilities exist for appreciable static-energy discharge, and proper handling techniques are not used, electrical damage can result as follows:
(a) shorted input protection diodes,
(b) shorted or open gates,
(c) opening in metal paths from the device input.

The presence of this type of device damage can be detected by curve-tracer checks of the input protection diodes of the gate-oxide protection circuits described on page 3 , and also by a check of the device characteristics, especially mutual transconductance (gm).

## Operating Considerations

Maximum Ratings<br>Storage-Temperature Range<br>Operating-Temperature Range:<br>Ceramic-Package Types<br>Plastic-Package Types<br>DC Supply-Voltage Range:<br>\[ \begin{aligned} \& V_{D D}-V_{S S}<br>\& V_{D D}-V_{E E}<br>\& V_{C C}-V_{S S}<br>\& D C Input-Voltage Range<br>\& for CD4009A, CD4010A<br>\& for CD4049A, CD4050A<br>\& for CD4051A, CD4052A, CD4053A:<br>\&<br>\&<br>\&<br>\&<br>\&<br>\&<br>\& Controls<br>\& Signals \end{aligned} \]<br>Device Dissipation (per package)<br>Lead Temperature (during soldering) at a distance $1 / 16 \pm 1 / 32$ inch ( $1.59 \pm 0.79 \mathrm{~mm}$ ) from case for 10 seconds maximum

## CD4000A Series

-65 to $+150^{\circ} \mathrm{C}$
-55 to $+125^{\circ} \mathrm{C}$
-40 to $+85^{\circ} \mathrm{C}$
-0.5 to +15 V
-0.5 to +15 V
-0.5 to $+15 V$
$V_{S S} \leqslant V_{1} \leqslant V_{D D}$
$\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{1} \leqslant \mathrm{~V}_{\mathrm{DD}} \geqslant \mathrm{V}_{\mathrm{CC}}$
$\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{\mathrm{I}} \leqslant 15 \mathrm{~V}$
$\mathrm{V}_{\mathrm{SS}} \leqslant \mathrm{V}_{1} \leqslant \mathrm{~V}_{\mathrm{DD}}$
$V_{E E} \leqslant V_{1} \leqslant V_{D D}$
200 mW
$+265^{\circ} \mathrm{C}$

## Operating Voltage

When operating near the maximum supply-voltage range of 15 volts, care should be taken to avoid or suppress power-supply turn-on or turn-off transients, power-supply ripple or regulation, and ground noise; any of the above conditions must not cause ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$ ) to exceed the absolute maximum rating.

Power supplies should have a current compliance compatible with actual COS/MOS current drain.

Another good power-supply practice is to use a zener protection diode in parallel with the power bus. The zener value should be above the expected maximum regulation excursion, but should not exceed 15 volts. Fig. 1 illustrates a practical zener shunt circuit. A current-limiting resistor is included if the supply-current compliance is higher than the zener power-dissipation rating for a given zener voltage. The shunt capacitance value is chosen to supply required peak current switching transients.


Fig. 1 - Zener-diode shunt circuit.

## Unused Inputs

All unused input leads must be connected to either $\mathrm{V}_{\mathrm{SS}}$ or $\mathrm{V}_{\mathrm{DD}}$, whichever is appropriate for the logic circuit
involved. A floating input on a high-current type (such as the CD4009A. CD4010A. CD4041A, CD4049A, CD4050A) not only can result in faulty logic operation, but can cause the maximum power dissipation of 200 milliwatts to be exceeded and may result in damage to the device. Another consideration with these high-current types is that a pull-up resistor from their inputs to $\mathrm{V}_{\mathrm{SS}}$ or $\mathrm{V}_{\mathrm{DD}}$ should be used if there is any possibility that the device may become temporarily unterminated (e.g., if the printed circuit board driving the high-current types is removed from the chassis). A useful range of values for such resistors is from 0.2 to 1 megohm.

## Input Signals

Signals shall not be applied to the inputs while the device power supply is off unless the input current is limited to a steady-state value of typically less than 10 milliamperes. Input signal interfaces having the allowable 0.5 volt above $V_{D D}$ or below $\dot{\mathrm{V}}_{\text {SS }}$, respectively, should be current-limited to typically 10 milliamperes or less.

Whenever the possibility of exceeding 10 milliamperes of input current exists, a resistor in series with the input is recommended. The value of this resistor can be as high as 10 kilohms without affecting static electrical characteristics. Speed, however, will be reduced due to the added RC delay. Particular attention should be given to long input-signal lines where high inductance can increase the likelihood of large signal pickup in noisy environments. In these cases, series resistance with shunt capacitance at the IC input terminals is
recommended. The shunt capacitance should be made as large as possible consistent with the system speed requirements.

## Interfacing with $T^{2} \mathrm{~L}$ Devices

The COS/MOS hex buffers (CD4009A, CD4010A, CD4049A, and CD4050A) are designed to drive two normal-power $\mathrm{T}^{2} \mathrm{~L}$ loads. Other device types (such as the CD4041A, CD4048A, and CD4031A) can also directly drive at least one $\mathrm{T}^{2} \mathrm{~L}$ load. Always consult the published data on the particular COS/MOS type for this capability. Most gates and inverters and some MSI types can drive one or more low-power $\mathrm{T}^{2} \mathrm{~L}$ loads. To provide a good noise margin in the logic " 1 " state, $\mathrm{T}^{2} \mathrm{~L}$ devices that drive COS/MOS devices require a pull-up resistor at the COS/MOS input. The COS/MOS hex buffers can also convert COS/MOS logic levels ( 5 to 15 volts) to $\mathrm{T}^{2} \mathrm{~L}$ logic levels ( 5 volts), i.e., down-level conversion.

Rules for safe system design when COS/MOS interfaces with $\mathrm{T}^{2} \mathrm{~L}$ and both logic systems have independent power supplies of the same voltage level but possibly on at different times are as follows:
a) $\mathrm{T}^{2} \mathrm{~L}$ driving COS/MOS -- use 1 kilohm in series with COS/MOS input
b) COS/MOS driving $T^{2} L$ - connect directly

## Interfacing with p-MOS Devices

COS/MOS devices can operate at $\mathrm{V}_{\mathrm{DD}}=0$ and $\mathrm{V}_{\mathrm{SS}}=-3$ to -15 volts to interface directly with p-MOS devices with no degradation in noise immunity or other characteristics.

## Interfacing with n-MOS Devices

COS/MOS devices can be interfaced directly with n-MOS devices over the +3 to +15 volt range of power supplies.

## Fan-Out - COS/MOS to COS/MOS

All RCA COS/MOS devices have a dc fan-out capability of 50 . The reduction in COS/MOS switching speed caused by added capacitive loading should, however, be consistent with high-speed system design. The input capacitance is typically 5 pF for most types; the CD4009A and CD4049A buffers have an input capacitance of typically 15 pF .

## Maximum Clock Rise and Fall Time

All COS/MOS clocked devices show maximum clock riseand fall-time ratings (normally 5 to 15 microseconds). With longer rise or fall times, a device may not function properly.

## Parallel Clocking

When two or more different COS/MOS devices use a common clock, the clock rise time must be kept at a value less than the sum of the propagation delay time, the output transition time, and the setup time. Most flip-flop and shift-register types are included in this rule and are so noted in the indiv fual data sheets.

## Noise Immunity

COS/MOS inputs normally switch at 30 to 70 per cent of the power-supply voltage. For example, for a 10 -volt supply,
a logic " 0 " is 0 to 3 volts, and a logic " 1 " is 7 to 10 volts. For 5 -volt operation, a logic " 0 " is 0 to 1.5 volts, and a logic " 1 " is 3.5 to 5 volts. COS/MOS noise immunity is 30 per cent of the supply voltage for the range from +3 to +15 volts.

The inherent 30 -per-cent noise immunity of COS/MOS also permits a 1 -volt noise margin when interfaced with $\mathrm{T}^{2} \mathrm{~L}$ or DTL. For example, standard $T^{2} \mathrm{~L}$ and DTL interfacing with COS/MOS at a nominal $\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\mathrm{CC}}=5$ volts provides at least 1 -volt noise margin; i.e., $\mathrm{V}_{\mathrm{OL}} \max \left(\mathrm{T}^{2} \mathrm{~L}\right)=0.4$ volt and $\mathrm{V}_{\mathrm{OL}} \min (\mathrm{DTL})=0.45$ volt $; 30 \%$ of 5 volts $=1.5$ volts.

This example applies typically to the $5400 / 7400$ series, the 9000 series, and the 8000 series. HI NIL ( 300 series) can interface with COS/MOS at a nominal $\mathrm{V}_{\mathrm{DD}}=\mathrm{V}_{\mathrm{CC}}=12$ volts with a worst-case noise margin of 2.1 volts.

Because COS/MOS voltage-transfer switching characteristics vary from 30 to 70 per cent of the supply voltage, system designers employing COS/MOS multivibrators, level detectors, and RC networks must consider this variation. Application Note ICAN-6267 illustrates an accurate multivibrator design technique which minimizes the switching-point variation.

## Output Short Circuits

Shorting of outputs to $\mathrm{V}_{\mathrm{SS}}$ or $\mathrm{V}_{\mathrm{DD}}$ can cause the device power dissipation to exceed the safe value of 200 milliwatts for high-output-current types such as the CD4007A, CD4009A, CD4010A, CD4041A, CD4049A, and CD4050A. In general, outputs of these types can all be safely shorted when operated with $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}} \leqslant 5$ volts, but may exceed the 200 -milliwatt dissipation rating at higher power-supply voltages. For cases in which a short-circuited load, such as the base of a p-n-p or n-p-n bipolar transistor, is directly driven, the device output characteristics given in the published data should be consulted to determine the requirements for safe operation below 200 milliwatts.

## COS/MOS Characteristics

Quiescent Device Leakage Current ( $\mathrm{I}_{\mathrm{L}}$ ):
Quiescent device leakage is measured for inputs tied high ( $\mathrm{I}_{\mathrm{DD}}$ ) and also for all inputs tied low ( $\mathrm{I}_{\mathrm{SS}}$ ), as illustrated below:


Output Voltage Levels (COS/MOS driving COS/MOS):
$\mathrm{V}_{\text {OL }}=$ Low-Level(" ${ }^{\prime}$ ")Output $=10 \mathrm{mV} *$ at $25^{\circ} \mathrm{C}$
$\mathrm{V}_{\mathrm{OH}}=$ High-Level(" 1 ")Output $=\mathrm{V}_{\mathrm{DD}}-10 \mathrm{mV}{ }^{*}$ at $+25^{\circ} \mathrm{C}$

Noise Immunity:
$\mathrm{V}_{\mathrm{NL}}=$ the maximum noise voltage that can be applied to a logic " 0 " input (added to $\mathrm{V}_{\mathrm{SS}}$ ) before the output changes state.
$\mathrm{V}_{\mathrm{NH}}=$ the maximum noise voltage that can be applied to a logic " 1 " input (subtracted from $V_{D D}$ ) before the output changes state.

Output Drive Current:
Sink Current $\left(\mathrm{l}_{\mathrm{D}} \mathrm{N}\right)=$ the output sink current provided by the $n$-channel transistor without exceeding a given output voltage $\left(\mathrm{V}_{\mathrm{o}}\right)$ as shown on each data sheet.
Source Current ( $\mathrm{I}_{\mathrm{D}} \mathrm{P}$ ) = the output source current provided by the p-channel transistor without dropping below a given output voltage ( $\mathrm{V}_{\mathrm{o}}$ ) as shown on each data sheet.

Input Current ( $\mathrm{I}_{\mathrm{I}}$ ):
Input current is typically 10 picoamperes ( 3 to 15 volts) at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$. Maximum input currents for COS/MOS devices are normally below 10 nanoamperes at 15 volts, and below 50 nanoamperes at $\mathrm{T}_{\mathrm{A}}=+125^{\circ} \mathrm{C}$.
AC (Dynamic) Characteristics:
Test parameters shown in the published data are measured at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ with a $15-\mathrm{pF}$ load and an input-signal rise or fall time of 20 nanoseconds. Actual system delays and transition times may be increased due to longer input rise and fall times. Graphs are included in the individual data sheets to illustrate typical variation of delays and transition times with capacitive loading. The designer should use a typical temperature coefficient of $0.3 \% /{ }^{\circ} \mathrm{C}$ for estimating speeds at temperatures other than $+25^{\circ} \mathrm{C}$. Propagation delays and transition times increase with rising temperature; maximum clock input frequencies decrease with rising temperatures.

Dynamic power dissipation for each device type is shown graphically in the published data as a function of device operating frequency.

[^26]
## Gate-Oxide Protection Circuits

Most COS/MOS gate inputs have the protection shown in Fig. 2. An exception to this statement is the input network for the CD4049A and CD4050A shown in Fig. 3. Figs. 4 and 5 illustrate the protection diodes inherently present at all transmission-gate input/output terminals and all inverter outputs. ICAN-6218 gives further information on protection circuits.

The protection networks can typically protect against $1-2$ kilovolts of energy discharge from a $250-\mathrm{pF}$ source.


Fig. 2 - Normal gate-input-protection circuit.


Fig. 3 - CD4049A/CD4050A gate-input-protection circuit.


Fig. 4 - Transmission gate-input-output protection.


Fig. 5 - Active (inverter) output protection.

* THESE DIODES ARE INHERENTLY PART OF THE MANUFACTURING PROCESS

Table II - Partial List of Materials and Equipment Available for the Control of Static Charge

| Company | Conductive <br> Foam | Conductive <br> Envelopes | Static <br> Neutralizing <br> Air Blowers | Anti-Static <br> Sprays | Conductive <br> Tape |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Custom Material Inc. <br> Chelmsford, Mass. | Velofoam <br> $\# 7672$ | Velobags <br> $\# 1798 \mathrm{M}$ | TEC Dynastat <br> DS120 |  | P. C. <br> Contab Shunt |
| 3M Company <br> St. Paul, Minn. |  | lonized Air <br> Blower \#905 | See Technical <br> Bulletins | Scotch <br> Shielding Tapes |  |
| Scientific Enterprises, Inc. <br> Bloomfield, Colo. |  | Micro Stat <br> 575 Portable <br> lonizer |  |  |  |
| Emerson \& Cuming, Inc. <br> Canton, Mass. | ECCOSORB <br> LD26 |  |  | See Technical <br> Bulletins |  |

# Digital-to-Analog Conversion Using the RCA-CD4007A COS/inOS IC 

By O. H. Schade, Jr.

RCA COS/MOS integrated circuits have demonstrated outstanding performance in a wide variety of DIGITAL applications. Simplified circuitry, design flexibility, low power consumption, moderate speed, and high noise immunity of these devices can complement the high transconductance of bipolar IC's in an extension to LINEAR signal processing applications. This Note demonstrates the use of The RCA-CD4007A COS/MOS Dual Complementary Pair Plus Inverter as the Digital-to-Analog (D/A) switch; the op-amp output stage for a Digital-to-Analog Converter (DAC) uses COS/MOS and bipolar transistor-array IC's.

## General Considerations

In combination with a p-channel input pair (two p-channels of the CD4007A), a buffer-follower COS/MOSbipolar op-amp has been designed with the capability to attain essentially the negative supply voltage at both the input and output terminals. Therefore, to consider inexpensive single-supply operation becomes possible without the sacrifice of speed and bandwidth that results with many monolithic bipolar IC op-amps. An additional advantage is the use of an MOS input stage to provide exceptionally high input resistance and low input current.

A 9-bit DAC is described in this Note to illustrate this design approach. This system combines the concepts of multiple-switch COS/MOS IC's, a low-cost ladder network of discrete metal-oxide film resistors, a COS/MOS-bipolar op-amp follower, and an inexpensive monolithic regulator in a simple single-supply system. An additional feature which complements the ever-increasing use of COS/MOS IC's for digital signal processing is the readily interfaced COS/MOSDAC input logic.

Although the accuracy of a DAC system depends on many factors, it is the ladder network which must initiate properly-proportioned current or voltage outputs. Recognition of various ladder types and an appreciation of the design flexibility and constraints are paramount to a well executed DAC development.

## Resistance Networks for DAC's

Ladder networks for DAC's can take many forms, although three types are most generally encountered. Among the best-known variations is the current ladder shown in Fig. 1. This network is frequently used in combination with bipolar current switches which utilize a reference potential at the transistor base terminals to establish emitter currents having binary proportions. Because current summing is accomplished at the collectors of these transistors, the extent of $\mathrm{V}_{\mathrm{BE}}$ - and beta-matching of these transistors depends on the degree of accuracy and temperature-range requirements. The use of a $10 / 20 / 40 / 80-\mathrm{k} \Omega$ network in conjunction with a "quad" switch, a follower amplifier, and dual power supplies is common.

[^27]

Fig. 1- Current ladder-network for bipolar DAC.

Fig. 2 shows an $\mathrm{R} / 2 \mathrm{R}$ current ladder commonly employed in monolithic DAC's. Similar resistance values can simplify the problem of meeting ratio-match accuracy requirements. This ladder must be terminated in a single potential (or at least invariable values) to maintain proper current proportions. Although the absolute resistance values of the circuit in Fig. 1 must temperature track the summing resistor (or additional compensation must be employed), the $\mathrm{R} / 2 \mathrm{R}$ current ladder must maintain only a resistance ratio; it is the current sink which must remain stable under external influences.


Fig. 2- R/2R current ladder-network for monolithic DAC.

However, the proper selection of parallel connection of switches for the most significant bit (MSB) to minimize channel resistance can result in COS/MOS-DAC speeds which approach those of the best bipolar systems, particularly when consideration is given to follower-amplifier speed limitations.

In the illustrative 9 -bit application, a modified voltageladder design is employed. The use of $1 \%$-tolerance metaloxide film resistors can result in inexpensive networks suitable to about the 10 -bit level. Such networks are readily constructed for system evaluations and may also prove to be suitable for production. Practical tolerance considerations call for variations from the "pure" $R / 2 R$ configuration, as discussed later.


Fig. 3- R/2R voltage ladder-network for COS/MOS DAC.

## The COS/MOS Switch

A typical COS/MOS switch (CD4007A) is shown in Fig. 4. A change in input logic level causes the output to swing to eitrar the positive or the negative supply voltage. Power consumption is low, typically a few microwatts to a few milliwatts, depending on the ladder resistance and voltage choice. Large DAC ladder resistance values can be used to minimize the effects of switch resistance. Fig. 5 shows the minimum ladder resistance value for a given saturation resistance to produce an accuracy of $1 / 2$ LSB (Least Significant Bit), with bit number as a parameter. For example, the CD4007A which has a channel resistance of approximately 250 -ohms ( $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ ), requires a minimum ladder resistance of $100 \mathrm{k} \Omega$ to maintain a 9 -bit accuracy level. Reference to the dashed "settling time" line and the rightside ordinate shows that the approximate settling time of such a network having a $10-\mathrm{pF}$ node capacitance is $6 \mu \mathrm{~s}$. This settling time has been based on six time constants for settling to $1 / 2 \mathrm{LSB}$, an average value for the bit range illustrated. If a faster settling time is required, circuits employing the RCA-CD4041A can be used.

The CD4041A ${ }^{\circ}$ can drive (in a theoretical example) a $4-\mathrm{k} \Omega, 6$-bit ladder network which has a settling time of approximately 250 ns. This is as fast as the best presently available monolithic bipolar switches. High-slew-rate voltagefollower amplifiers are needed to maintain these speed levels; when a COS/MOS bipolar op-amp is used, the slew rate is approximately $30 \mathrm{~V} / \mu \mathrm{s}$ and the settling time is several hundred nanoseconds for a $10-\mathrm{V}$ full-scale signal. This performance approaches the state-of-the-art for monolithic op-amps, especially in low-cost systems. In fact, high-speed op-amps capable of swinging to the negative supply have not generally been available.

## A Voltage-Follower Amplifier for Single-Supply Operation

It is practical to utilize commercially available COS/MOS and bipolar transistor-array IC's to provide a composite op-amp suitable for single-supply DAC systems. Fig. 6 shows a unity-gain follower amplifier having a COS/MOS p-channel input, an n-p-n second gain stage, and a COS/MOS inverter output. The IC building blocks are two CA3600E's ${ }^{4}$ (COS/MOS Transistor Pairs) and a CA3046 ${ }^{\text {a }}$ n-p-n transistor array. A zener-regulated leg provides bias for a $400-\mu \mathrm{A}$ p-channel current source feeding the input stage, which is terminated in an n-p-n current mirror. Amplifier voltage-offset is nulled with the $10-\mathrm{k} \Omega$ balance potentiometer. The secondstage current level is established by the $20-\mathrm{k} \Omega$ load, and is selected to approximate the first-stage current level, to assure similar positive and negative slew rates. The COS/MOS inverter portion forms the final output stage and is terminated in a $2-\mathrm{k} \Omega$ load, a typical value used with monolithic op-amps. Voltage gain is affected by the choice of load resistance value. The output stage of this amplifier is easily driven to within 1 mV of the negative supply voltage.


Fig. 4- CD4007A schematic diagram.


Fig. 5- COS/MOS-DAC voltage-network requirements.

[^28]

Fig. 6- Voltage-follower amplifier for single-supply opera-
tion.

Compensation for the unity-gain non-inverting mode is provided by Miller feedback of 39 pF and a $300-\mathrm{pF}$ by-pass capacitor shunting one-half the driving current ( $1-2 \mathrm{MHz}$ ). Unity-gain bandwidth is just under 10 MHz and the open-loop gain is 75 dB . Fig. 7 shows the gain-bandwidth characteristics for this circuit. A potential latch situation at the bipolar mirror is avoided by use of resistor-capacitor network ( $\mathrm{R}=1 \mathrm{k} \Omega, \mathrm{C}=150 \mathrm{pF}$ ), which limits the dc feedback through the p-channel gate-protective diode.

The amplifier response to $4-\mathrm{V}$ input pulses is shown in Fig. 8. Although the slew rate is approximately $30 \mathrm{~V} / \mu \mathrm{s}$, the settling time is significantly prolonged (approximately $2 \mu \mathrm{~s}$ ) as a result of the method of second-stage biasing when the output swings near the negative supply. For many applications, this speed loss is not significant. If a faster amplifier is desired, the load resistor can be replaced with a p-channel CA3600E current source similar to that used for the first stage. In fact, it may be desirable to change the current and resistance values to optimize the gain/speed trade-off for a particular application. For example, if higher gain is desired for less follower offset, the $20-\mathrm{k} \Omega$ resistance value can be increased. The choice of output load resistance also affects the gain/speed compromise.


Fig. 7- Voltage-follower open-loop gain characteristics.

## A 9-Bit COS/MOS DAC

An example of a 9-bit DAC is shown in Fig. 9. Three CD4007A IC packages perform the switch function using a 10-V logic level. A single $15-\mathrm{V}$ supply provides a positive bus for the follower amplifier and feeds the CA3085 ${ }^{\boldsymbol{4}}$ voltage regulator. The "scale-adjust" function is provided by the regulator output control which is set to a nominal 10 V in this system. The line-voltage regulation (approximately $0.2 \%$ ) permits 9 -bit accuracy to be maintained with a variation of several volts in the supply. System power consumption ranges between 70 and 200 mW ; a major portion is dissipated in the load resistor and op-amp. The regulated supply provides a maximum current of $440 \mu \mathrm{~A}$ of which $370 \mu \mathrm{~A}$ flows through the scale-adjust leg.

The resistor ladder is composed of 1 -per-cent tolerance metal-oxide film resistors available from several manufacturers at modest cost. The five arms requiring the highest accuracy are built of series and parallel combinations of $806-\mathrm{k} \Omega$ resistors from the same manufacturing lot. The ratio match between resistance values is in the order of $0.2 \%$, usually without need for special selection. The construction of a "standard" with eight parallel resistors assures a high probability that ratio matching will be satisfactory. If the usual assumption that tolerances can be improved with the square-root of the sample number is adopted, the loss of
tolerance is slower than the increase of resistance value toward the LSB. Once the most critical match has been attained, therefore, subsequent ratio matches should be more than adequate. An impedance-matching resistor is used between the fifth and sixth bits to permit ladder completion with individual resistors of the most desirable values where a $1 \%$ tolerance is adequate. This resistor value is chosen as R5-1/2R6, to terminate the first five bits in a fifth-bit value (the impedance is $1 / 2 \mathrm{R} 6$ looking left into that node).


Fig. 8- Amplifier response to 4-V input pulses.


Fig. 9- 9-bit DAC using COS/MOS CD4OO7A.

The follower amplifier has the offset adjustment nulled at approximately a 1 -volt output level. System operating potentials are shown in Table I, where each bit is set "low" individually to observe the progression of output values. The positive ladder-supply voltage was adjusted to 10.010 V to provide a small compensation for the MSB switch resistance. A high-impedance 5 -digit multimeter, such as the DANA 5330 or equivalent, is needed for direct measurement of the ladder output, and is invaluable during system development and evaluation. Table I shows ideal potential values, system output, and ladder output and illustrates the sources of system inaccuracy. The system output maintains proportional accuracy within $\pm 5.6 \mathrm{mV}$, or $\pm 1 / 4$ LSB.

Fig. 10 shows the system output response to a 4 V logic pulse. The ringing is caused by the voltage follower, and the more gradual transients are caused by voltage-follower and ladder time constants. Settling time to $1 / 2$ LSB is $5 \mu \mathrm{~s}$.

This 9-bit COS/MOS-DAC demonstrates accuracy and simplicity with economical components and modest powersupply requirements. In addition, the design flexibility afforded by the COS/MOS building blocks simplifies the generation of DAC systems tailored to individual needs. COS/MOS switches used in conjunction with COS/MOS counters also find application in Analog-to-Digital Conversion Systems. The low-power and high noise-immunity features of these devices make them attractive $A / D$ system components.


Fig. 10-System response to most-significant-bit logic pulse.


#### Abstract

When incorporating RCA Solid State Devices in equipment, it is recommended that the designer refer to "Operating Considerations for RCA Solid State Devices", Form No. 1CE-402, available on request from RCA Solid State Division, Box 3200, Somerville, N.J. 08876.


# Timekeeping Advances Through COS/MOS Technology 

by S.S. Eaton

Most COS/MOS timing circuits consist of three basic parts: an oscillator, or main timing standard; some digital processing logic, usually in the form of frequency-dividing circuits; and logic-circuit drivers for mechanical or electrical output devices controlled by the digital processing logic. The oscillator is perhaps the most important because the accuracy of the total COS/MOS timing system is entirely dependent upon the accuracy of the oscillator. This Note discusses basic oscillator design considerations, practical COS/MOS oscillator circuits, and some typical COS/MOS timing-circuit applications.

## BASIC OSCILLATOR DESIGN CONSIDERATIONS

A basic oscillator circuit consists of an amplifier and a feedback section, as shown in Fig. 1. For oscillation to occur, the gain of the amplifier times the attenuation of the feedback network must be greater than one. In addition, the total phase shift through the amplifier and feedback network must be equal to $n$ times 360 degrees, where $n$ is an integer. These conditions imply that oscillations occur in any system in which an amplified signal is returned in phase to the amplifier input after being attenuated less than it was originally amplified. In such a system, any noise present at


Fig. 1- Basic oscillator circuit.
the amplifier input causes oscillation to build up at a rate determined by the loop gain, or $a \beta$ product, of the over-all circuit.

The frequency stability of an oscillator is primarily dependent upon the phase-changing properties of the feedback network. For high stability, quartz crystals and tuning forks are commonly used as feedback network elements. The quartz crystal is the more popular because of its higher $Q$ or greater inherent frequency stability.

## Selection of Crystal Operating Mode

Fig. 2 shows the equivalent circuit of a quartz crystal, and Table I lists typical component values of the elements included in the equivalent circuit for different crystal cuts and operating frequencies. The basic circuit can be resolved into equivalent resistive ( $\mathrm{R}_{\mathrm{e}}$ ) and reactive ( $\mathrm{X}_{\mathrm{e}}$ ) components. Fig. 3 shows curves of these components as functions of frequency for a typical $32.768-\mathrm{kHz}$ crystal. Fig. 3(b) shows two points at which the crystal appears purely resistive, (i.e., points at which $\mathrm{X}_{\mathrm{e}}=0$ ). These points are defined as the resonant ( $f_{r}$ ) and antiresonant ( $f_{a}$ ) frequencies. Seriesresonant oscillator circuits are designed to oscillate at or near $f_{r}$. Parallel-resonant circuits oscillate between $f_{r}$ and $f_{a}$, depending upon the value of a parallel loading capacitor, as discussed later. In contrast to series-resonant circuits, parallel resonant-circuits work best with amplifiers that have high input impedances. The parallel-resonant circuit, therefore, is most applicable to crystal oscillators that employ COS/MOS amplifiers. ${ }^{1}$

## Feedback-Circuit Configuration

A feedback circuit suitable for use with a parallelresonant oscillator circuit is shown in Fig. 4. This circuit, known as a crystal pi network, is intended for use after an amplifier that provides a 180 -degree phase shift. The pi network is designed to provide the additional 180 -degree phase shift required for oscillation. The phase angle for this type of feedback circuit is extremely sensitive to a change in frequency, a condition necessary for stable oscillation. If the equivalent resistance of the crystal were in fact zero (infinite


Fig. 2- Equivalent circuit for a quartz crystal.
Table I - Typical Component Values for Common Cuts of Quartz Oscillator Crystals

| FREQUENCY | 32 kHz | 280 kHz | 525 kHz | 2 MHz |
| :--- | :--- | :--- | :--- | :--- |
| Cut | XY Bar | DT | DT | AT |
| $R_{\text {S }}$ (ohms) | 40 K | 1820 | 1400 | 82 |
| L (Hy) | 4800 | 25.9 | 12.7 | 0.52 |
| $\mathrm{C}_{1}(\mathrm{pF})$ | 0.00491 | 0.0125 | 0.00724 | 0.0122 |
| $\mathrm{C}_{\mathrm{o}}(\mathrm{pF})$ | 2.85 | 5.62 | 3.44 | 4.27 |
| $\mathrm{C}_{\mathrm{o}} / \mathrm{C}_{1}$ | 580 | 450 | 475 | 350 |
| Q | 25000 | 25000 | 3000 | 8000 |

Q), a change in the phase angle of the feedback circuit would not cause any change in oscillator frequency; the frequency, therefore, would be insensitive to any phase change in the amplifier. Though practical crystals allow only a slight change in frequency for large variations in phase angle, the amplifier phase angle should, to the extent possible, be made independent of temperature and supply-voltage variations in order to minimize the phase compensation required of the feedback network. Any required phase compensation will, of course, dictate a corresponding change in the frequency of oscillation consistent with practical values of crystal Q. For this reason, the equivalent resistance of the crystal should be maintained as low as possible, and the amplifier should be designed to roll off at frequencies greater than the crystal frequency.

## Oscillator Amplifier

Fig. 5 shows a COS/MOS amplifier circuit that may be used to provide the amplification function in a crystalcontrolled oscillator. The amplifier is biased so that the output voltage VOUT is equal to the input voltage VIN or typically is equal to one-half the supply voltage $V_{D D}$, (i.e., $\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{DD}} / 2$ ). Biasing is accomplished by means of a resistor that has a value high enough to prevent loading of the feedback network, yet that is low in comparison to the amplifier input resistance. Resistor values of 10 to 500 megohms will satisfy these criteria; however, lower values in the order of 15 megohms are generally used to allow greater input leakage without.any severe change in bias point. The gain of the amplifier varies with supply voltage, the size of the n - and p -channel MOS transistors, and the sum of the threshold voltages of the n - and p -channel transistors. When an oscillator amplifier is designed to roll off at frequencies greater than the crystal frequency, care must be taken to


Fig. 3- Impedance characteristics of a quartz oscillator crystal: (a) equivalent crystal resistance as a function of frequency; (b) equivalent crystal reactance as a function of frequency.


Fig. 4- Crystal pi-type feedback network.


Fig. 5- COS/MOS amplifier.
assure that the transistor sizes are large enough for the particular supply voltage used and range of threshold voltages expected. For any circuit, though, the sum of the threshold voltages of the n - and p-channel transistors must always be less than the supply voltage.

The oscillator amplifier governs, to a certain extent, the selection of the components for the feedback network. The amplifier current consumption is strongly dependent upon the attenuation across the feedback network. As the attenuation becomes greater, the signal at the amplifier input becomes smaller, which, in turn, increases the amplifier current consumption. Large voltage swings at the amplifier input cause little current to flow because the resistance of either the n - or p -channel transistor is high during a large portion of the cycle. On the basis of power considerations, it is best to design the feedback network for a small attenuation.

## Equivalent Crystal Resistance

The equivalent resistance $R_{S}$ of the crystal should be maintained as small as possible in order to obtain minimum attenuation across the feedback network. For any given circuit, the oscillator current always increases with a rise in crystal resistance. This factor and stability considerations provide strong arguments for the purchase of crystals that have low series resistance, although the usual cost tradeoffs prevail.

## Crystal Load Capacitance

Another factor that influences the over-all power consumption is the size of the pi-network capacitor at the amplifier output. For minimum current consumption, this capacitor, obviously, should be kept small. This condition, however, does not always imply high frequency stability. The choice of the capacitor value first involves a determination of the over-all crystal load capacitance. The phase angle of the feedback network approaches 180 degrees when the crystal equivalent reactive component $X_{e}$ is equal to the reactance ( XCL ) of a capacitor placed in parallel with the crystal. Fig. 4 shows that the effective capacitance across the crystal consists of the two pi-network capacitors in series. If the value of the equivalent reactance $\mathrm{X}_{\mathrm{e}}$ at the crystal frequency, as may be determined from Fig. 3(b), is equal to the value of the crystal load capacitance $C_{L}$, then the equivalent value of the two series-connected pi-network capacitors can be calculated from the following relationship:

$$
\begin{equation*}
C_{L}=1 / \omega X_{\mathrm{e}} \tag{1}
\end{equation*}
$$

The value of the load capacitance $\mathrm{C}_{\mathrm{L}}$, in general, is chosen first, and the crystal manufacturer is required to cut the crystal to oscillate at the desired frequency for the specified value of load capacitance.

The choice of a load capacitance is important in terms of over-all power consumption and frequency stability. Higher values of $\mathrm{C}_{\mathrm{L}}$ generally improve frequency stability, but also increase power dissipation. The timing industry presently seems to have standardized on values of $C_{L}$ between 10 and 20 picofarads.

The choice of the total equivalent load capacitance $C_{L}$ only fixes the series sum of the two pi-network capacitors. The individual capacitors themselves can be found from the following equations:

$$
\begin{align*}
& \mathrm{C}_{\mathrm{T}}=4 \mathrm{C}_{\mathrm{L}} /\left(1-5 \mathrm{fR}_{\mathrm{e}} \mathrm{C}_{\mathrm{L}}\right)  \tag{2}\\
& \mathrm{C}_{\mathrm{S}}=4 \mathrm{C}_{\mathrm{L}} /\left(3+5 \mathrm{fR}_{\mathrm{e}} \mathrm{C}_{\mathrm{L}}\right) \tag{3}
\end{align*}
$$

The actual value of $\mathrm{C}_{\mathrm{S}}$ used in the feedback circuit should be about 3 picofarads less than the calculated value to allow for the amplifier input capacitance. The value of the amplifier output capacitor $\mathrm{C}_{\mathbf{T}}$ should not normally be fixed. A trimmer capacitor should be placed in parallel with, or used in place of, a fixed output capacitor to allow for variations in stray capacitance and circuit components. The mid-range value of the output capacitor combination should be equal to the calculated value of $\mathrm{C}_{\mathrm{T}}$.

## Frequency-Trimming Capability

The required capacitance range for the oscillator trimmer capacitor is determined by the variation in oscillation frequency with a change in load capacitance. ${ }^{2}$ The total frequency-trimming range of a crystal-controlled oscillator circuit is mainly a function of the crystal characteristics, or more explicity, is inversely proportional to the slope of the crystal reactance curve, shown in Fig. 3(b). The slope of this curve is a function of the difference between the resonant frequency $f_{r}$ and the antiresonant frequency $f_{a}$. This frequency difference, in turn, is a function of the crystal capacitance ratio $C_{0} / C_{1}$, where $C_{0}$ and $C_{1}$ are the inherent shunt and series capacitances, respectively, of the crystal structure, as shown in Fig. 2. The slope of the reactance curve is also a function of the total external crystal load capacitance $\mathrm{C}_{\mathrm{L}}$. As shown in Fig. 3(b), this slope decreases as the equivalent reactance increases, (i.e., for smaller values of the capacitance $\mathrm{C}_{\mathrm{L}}$ ). Fig. 6 and Table II show trimming-range data for a typical $32.768-\mathrm{kHz}$ crystal that has a capacitance ratio $\mathrm{C}_{0} / \mathrm{C}_{1}$ of 580 . These data show that smaller values of load capacitance result in greater trimming-range capability.

## Temperature Stability

Another important oscillator consideration is temperature stability. Most crystals have a negative parabolic temperature coefficient. ${ }^{2}$ Fig. 7 shows a typical curve of the variation in crystal frequency as a function of temperature. The frequency of the total oscillator circuit also exhibits a similar temperature dependence. Temperature compensation of the over-all oscillator circuit can be achieved by use of a capacitor that has a positive parabolic temperature coefficient in the pi feedback network. ${ }^{3}$ For comparison, Fig. 7 also shows a typical resultant curve for the over-all circuit.

The temperature characteristics of a crystal are determined to a large extent by the crystal cut. Popular low-frequency cuts include the NT and XY Bar. The XY Bar is the more popular of the two types because it can be made smaller for a given Q and is easier to trim. The disadvantage of a slightly lower shock resistance of XY Bar crystals is compensated by the superior aging chacteristics of this type.


Fig. 6- Frequency as a function of load capacitance for a typical $32-\mathrm{kHz}$ crystal.

AT-cut crystals, when used at frequencies greater than 1 MHz , are characterized by excellent temperature stability and ruggedness. Temperature characteristics for this type of crystal cut as well as for the XY Bar and NT types are shown in Fig. 8.

## Crystal Dimensions

Size is also an important consideration in the design of oscillator crystals. The length of quartz required for any given cut is inversely proportional to the square root of frequency. Dimensions for a typical packaged $32-\mathrm{kHz}, \mathrm{XY}$ Bar crystal are 0.6 inch by 0.2 inch by 0.11 inch. The smallest XY Bar crystals currently available have dimensions in the order of 0.53 inch by 0.2 inch by 0.11 inch. A $1-\mathrm{MHz}$ AT-cut crystal is significantly larger; however, dimensions again decrease with frequency. Crystal manufacturers are currently working to develop wristwatch-size AT-cut crystals with the anticipation of circuit improvements that will allow low-current operation at high frequencies.

## Crystal Shock Resistance and Aging Rate

A prime concern of the timing industry today is that of crystal shock resistance and aging. The aging of a crystal results primarily from aging of the mounting material rather

Table II - Trimming Data for a Typical $32-\mathrm{kHz}$ Quartz Oscillator Crystal

| TRIM | LOAD CAPACITANCE, CL |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | 5 pF | 11.5 pF | 20 pF | 32 pF |
| $\pm 20 \mathrm{PPM}$ | $\begin{aligned} & -0.45 \mathrm{pf} \\ & +0.51 \end{aligned}$ | $\begin{aligned} & -1.6 \mathrm{pf} \\ & +2.0 \end{aligned}$ | $\begin{aligned} & -3.7 \\ & +5.5 \end{aligned}$ | $\begin{gathered} -8.0 \\ +14.7 \end{gathered}$ |
| $\pm 25$ PPM | $\begin{aligned} & -.55 \mathrm{pf} \\ & +.65 \end{aligned}$ | $\begin{aligned} & -1.9 \mathrm{pf} \\ & +2.6 \end{aligned}$ | $\begin{aligned} & -4.5 \\ & +7.3 \end{aligned}$ | $\begin{gathered} -9.4 \\ +20.5 \end{gathered}$ |
| $\pm 30$ PPM | $\begin{aligned} & -0.66{ }^{2} \mathrm{pf} \\ & +0.79 \end{aligned}$ | $\begin{aligned} & -2.3 \mathrm{pi} \\ & +3.3 \end{aligned}$ | $\begin{aligned} & -5.2 \mathrm{pf} \\ & +9.3 \end{aligned}$ | $\begin{aligned} & -10.7 \\ & +27.9 \end{aligned}$ |



Fig. 7- Effect of temperature on crystal frequency.


Fig. 8- Frequency-temperature characteristics for various crystal cuts: (a) XY-Bar and NT cuts; (b) AT cut.
than from aging of the quartz itself. The mounting material enters into the crystal equivalent circuit, and the slowest aging rate results when the mount consists of the least amount of supporting material. This condition of course, results in lower shock resistance, and an optimum trade-off must be achieved. At present, $32-\mathrm{kHz}$ crystals can be made that can withstand a mechanical shock of about 1500 G 's applied for 0.5 millisecond and that have aging rates that result in a frequency change of 2 to 5 parts per million for
the first year and essentially no aging thereafter. Any mechanical or thermal shock, however, will interrupt the normal aging process. The aging rate of 2 to 5 parts per million presently appears acceptable to the timing industry, although shock resistances of 3,000 to $5,000 \mathrm{G}$ 's are desired. This shock level corresponds approximately to the shock experienced by dropping the crystal from a height of one meter onto a hardwood floor.

## PRACTICAL OSCILLATOR CIRCUITS

The basic amplifier, feedback-network, and crystal considerations discussed in the preceding paragraphs can be combined in the design of COS/MOS oscillator circuits. In the circuits, the crystal selected has an equivalent resistance $\mathrm{R}_{\mathrm{e}}$ of 50 kilohms and is cut to operate at a frequency of 32.768 kHz with a load capacitance $\mathrm{C}_{\mathrm{L}}$ of 10 picofarads. The values of pi feedback-network capacitors $\mathrm{C}_{\mathrm{T}}$ and $\mathrm{C}_{\mathrm{S}}$ can be calculated by use of Eqs. (2) and (3) as $\mathrm{C}_{\mathrm{T}}=43$ picofarads and $\mathrm{C}_{\mathrm{S}}=13$ picofarads. The value of the feedback-network resistance R can be calculated as follows:

$$
\begin{aligned}
\mathrm{R} & =\frac{\left(3 \mathrm{X}_{\mathrm{e}}+0.27 \mathrm{R}_{\mathrm{e}}\right)\left(\mathrm{X}_{\mathrm{e}}-0.8 \mathrm{R}_{\mathrm{e}}\right)}{16 \mathrm{R}_{\mathrm{e}}} \\
& \approx 1 \mathrm{M} \Omega
\end{aligned}
$$

This value is the maximum value of resistance allowd for a minimum feedback-network attenuation of 0.75 , a value chosen on the basis of power and stability considerations. ${ }^{1}$ The calculated value of $R$ includes any fixed resistance plus the amplifier output resistance. Because the output resistance is often appreciable and varies with supply voltage, transistor size, and threshold voltages, it is generally best to add resistance experimentally until the desired power consumption and frequency stability are reached. The effect of this resistance on operating current and frequency stability can be predicted from data given in Table III for the three different COS/MOS crystal oscillator circuits shown in Fig. 9. In each circuit, the pi-network capacitors $\mathrm{C}_{\mathrm{T}}$ and $\mathrm{C}_{\mathrm{S}}$ are 39 picofarads and 10 picofarads, respectively. These capacitances are slightly less than the calculated values because of stray and amplifier capacitances.

The circuit shown in Fig. 9(a) combines the amplifier and feedback circuits shown in Fig. 4 and 5. Although theory predicts that an increase in the values of the feedbacknetwork resistor $\mathbf{R}$ will result in increased frequency stability, the circuit performance data given in Table III show no significant improvement in this characteristic. This result indicates that the circuit instability can be attributed almost entirely to phase instabilities of the amplifier. This assumption is verified by data taken from the circuits shown in Figs. 9(b) and 9(c) in which the required feedback-network resistance is incorporated into the amplifier as a fixed value. The resistors essentially fix the amplifier phase shift so that greater stability results. As the data show, use of these resistors also results in a decrease in the total current consumption. Because of the two fixed resistors, the circuit of Fig. 9(b) shows the least current consumption and also the greatest stability.

Table III - Typical Oscillator Data

| Circuit | Value of $R(\Omega)$ | VDD (Volts) | Current ( $\mu \mathrm{A}$ ) | Frequency Stability $\begin{gathered} \mathrm{VDD}=1.45 \mathrm{~V} \\ \text { to } 1.6 \mathrm{~V} \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: |
| 9(a) | 0 | 1.60 | 4.0 | 2.8 |
| " | 0 | 1.45 | 3.1 |  |
| " | 100K | 1.60 | 3.1 | 2.6 |
| " | " | 1.45 | 2.4 |  |
| " | 200K | 1.60 | 2.9 | 2.6 |
| " | " | 1.45 | 2.1 |  |
| 9(b) | 100K | 1.60 | 2.3 | . 3 |
| " | " | 1.45 | 2.0 |  |
| " | " | 1.1 | 1.5 |  |
| " | 150K | 1.60 | 1.8 | . 2 |
| " | " | 1.45 | 1.6 |  |
| " | " | 1.1 | . 95 |  |
| 9(c) | 200K | 1.60 | 5.0 | . 6 |
| " | " | 1.45 | 4.4 |  |
| " | 300K | 1.60 | 3.5 | . 5 |
| " | - " | 1.45 | 3.0 |  |

As mentioned previously, the amplifier feedback resistor should not significantly load the crystal feedback network. The resistor value at which loading begins to occur can be determined from a curve of circuit operating frequency as a function of feedback resistance. Fig. 10 shows such a curve for the circuit shown in Fig. 9(b). This curve indicates that 15 megohms is a suitable value for the feedback resistor.

## FREQUENCY DIVIDERS

Because of restrictions on crystal size and cost, oscillator frequencies of 8192 Hz , or higher, are generally used for electronic timing circuits. The use of such high crystal frequencies usually requires division of the oscillator frequency to a more convenient value. Synchronous motors, for example, are often driven by frequencies between 0.5 Hz and 64 Hz . Numeric readouts for digital clocks or wristwatches require pulses at least every second, minute, and hour. The necessity for frequency division becomes clear if one considers the wide variety of timing intervals that may be required for certain applications.

The basic frequency-dividing circuit, shown in Fig. 11, consists of a master-slave D-type flip-flop connected as a binary counter stage. N stages may be cascaded with the final output frequency equal to $2-\mathrm{N}$ times the input frequency. Division by integers other than powers of 2 can also be accomplished by use of gating techniques. For example, a divide-by- 60 counter implemented as shown in Fig. 12, can be used to obtain minutes from seconds.


Fig. 9- Typical COS/MOS crystal-oscillator circuits.
A basic block diagram of a typical digital clock that employs divide-by-60 counters is shown in Fig. 13. The display for the clock is designed to be multiplexed in that new information is provided to only one of the six readout characters, while the eye itself holds the previous state of the other five. The multiplexing unit consists of COS/MOS transmission gates controlled by a six-stage ring counter that also addresses each character sequentially. This type of


Fig. 10-Oscillator frequency as a function of amplifier feedback resistance.

(a) A BIDIRECTIONAL LOW IMPEDANCE WHEN CONTR
INPUT I IS "LOW"AND CONTROL INPUT 2 IS "HIGH". INPUT I IS "LOW" AND CONTROL INPUT 2 IS "HIGH". AN OPEN CIRCUIT WHEN CONTROL INPUT I IS"HIGH" AND CONTROL INPUT 2 IS LOW."
92cs-20511

Fig. 11- Basic frequency-dividing stage.
circuit is particularly applicable for driving light-emitting diode displays.

Light-emitting diodes, as well as other readout devices, require some form of driving circuitry which is often unique to the driven device. Other typical readout devices include stepping motors, balance-wheel motors, tuning-fork motors, and liquid-crystal displays.

Motors are frequently driven by low-impedance MOS transistor drivers. The waveforms required depend upon the particular type of motor. Rotary stepping motors require a pulsed waveform such as that shown in Fig. 14(a). The motor advances one position (for example 180 degrees) on each pulse. Fig. 14(b) shows a COS/MOS circuit that may be used to generate this type of waveform. The crystal frequency and the number of countdown stages for this circuit determine the pulse frequency. The duty factor is controlled by two resettable flip-flops that are clocked inversely by the last counting stage and reset by an intermediate stage. The output waveform from this circuit will have a duty factor that is exactly given by $2 I-1-N$ where $I$ is the number of the intermediate stage used to reset the shaping flip-flops and N is the total number of frequency-divider stages.

A tuning-fork motor consists of two coils wired in series and wound on either side of the fork. A subdivision of the crystal frequency drives the coils which electromagnetically vibrate the fork. The fork can be linked to an index wheel that, in turn, can drive the hands of a watch.

A balance-wheel motor consists of a coil fixed near the periphery of a pivoted balance wheel. Permanent magnets are attached to one side of the wheel and counterweights to the other. The coil can be energized by pulses supplied to the gate of an n-channel MOS transistor with the coil connected between the drain and the supply voltage of the transistor. When the coil is energized, the balance wheel swings toward the coil. The momentum of the wheel moves it beyond the coil, and spring action then forces it back. Repeated cycles generate a back-and-forth type motion which can be linked to a wheel for driving the hands of a watch or clock.

Seven-segment liquid-crystal numerals can be driven as shown in Fig. 15. An ac voltage is required across each


Fig. 12- COS/MOS divide-by-60 counter.


Fig. 13- Typical COS/MOS digital clock.
segment of the display to assure long life. For this purpose, a $60-\mathrm{Hz}$ square wave is applied to one input of each of seven exclusive-OR gates. The logic state present at the other input determines whether the segment will transmit or scatter light.

Liquid-crystal displays can be made for operation in either transmissive or reflective modes. The transmissivemode type requires a light source behind the display. The light will either be transmitted or not depending upon the voltage across the segment. In the reflective-mode type, ambient light can be scattered by the liquid crystal material, or reflected from a mirrored surface placed behind the numeral. If displayed correctly, excellent contrast between "on" and "off" segments can be obtained when reflecting or scattering only ambient light.

The light scattering property of liquid-crystal displays offers two major advantages. First, the problem of washout in high intensity light is prevented. Washout has always been a problem with light generating displays. Second, because the displays do not generate light, they require negligible power.

In fact, liquid crystals require the least amount of power of any currently available type of display. ${ }^{4}$

Light-emitting diodes are somewhat simpler to drive than liquid crystals because signals to individual segment and/or numerals can be easily multiplexed. Fig. 16 shows a typical multiplexed driving circuit. The n-p-n transistor, which is common to the cathode of all segments in each numeral, can be turned on to address only one particular numeral. The eye will hold the reading from all off segments long enough for at least six numerals to be multiplexed.

## COS/MOS TIMING-CIRCUIT APPLICATIONS

The choice of a readout device depends, of course, upon the application involved and to a certain extent upon the individual characteristics of the device itself. Special considerations for readout devices are perhaps best treated in a discussion of special requirements for three important timing-circuit applications, namely, wristwatches, wall clocks, and automobile clocks.


Fig. 14- Generation of required stepping-motor waveforms: (a) required driving waveform across stepping motor; (b) COS/MOS driving circuit and output waveforms applied to motor control winding.

## Wristwatches

In any wristwatch application, size and total operating current are perhaps the two most important considerations. The total timing circuitry, together with the battery and readout device, must fit into a relatively fixed size and have a current consumption small enough to allow at least one year of life. Size and power considerations also become important in crystal selection. The size and cost of a crystal decreases with increases in frequency up to about 1 MHz . The power consumption of the oscillator and counter increases with frequency. On the basis of these considerations, the most
popular crystal frequency for wristwatches at present is 32.768 kHz . Typical packaged sizes for this crystal and various available crystal oscillator circuits were discussed in an earlier section of this Note.

The choice of a readout device also involves considerations of size and power as well as, of course, marketing considerations. If conventional-hand movements are chosen, a motor type of drive must be selected. No great size advantage exists over any of the various motor types used in this type of application. In addition, all types can be designed to operate from 1.1 to 1.6 volts with average


Fig. 15- COS/MOS liquid-crystal driving circuit.


Fig. 16-Multiplexing driving circuit for light-emitting diodes.
current consumptions of about 10 microamperes. Sensitivity to vibration, however, is one separating characteristic. Although balance-wheel motors can be designed to compensate to a certain extent for speed variations produced by vibrations, the stepping motor, which is insensitive to vibration, remains superior in this respect. At present, however, the stepping motor is the more expensive of the two types.

Light-emitting diodes require a minimum of two battery cells for proper operation. The required current can be kept to about 2 milliamperes per segment when the diodes are pulsed from a six-stage ring counter, as showṇ in Fig. 13. A duty factor of 16 per cent is achieved with this arrangement. Because of the high current, however, a continuously operating battery-powered display is not possible, and a "readout on demand" watch is then necessary.

Continuously operating liquid-crystal displays are possible and practical. RCA wristwatch displays employ liquid-crystal material having resistivities of about $5 \times 10^{9}$ ohms per centimeter, which at a 0.5 -mil spacing results in a resistance of 6.3 megohms per square centimer. With all segments energized, the display consumes only about 1 microampere of current at 15 volts. Liquid crystals, however, require a minimum supply of 12 volts to assure good contrast between on and off segments. For single-cell operation, a dc-to-dc converter must be used to step the voltage up to the required 12 -to- 15 -volt level. Transformer and capacitor voltage-doubling circuits with conversion efficiencies of about 75 per cent are typically used for this purpose.

Because current consumption is such an important consideration for wristwatch circuits, the careful consideration given to the choice of a battery is easily understood. Small silver-oxide and mercury cells are presently popular for wristwatch use. Pertinent information on these types of

Mallory cells is shown in Table IV. Most of the cells listed will last at least one year with a motor current of 10 microamperes and a total oscillator and divider current less than 5 microamperes at an oscillator frequency of 32.768 kHz . The voltage for both types of cells is relatively constant during the active life listed and falls off rapidly thereafter. Typical end-of-life voltages at 1.1 volts for mercury cells and 1.45 volts for silver-oxide cells. Either type of cell works equally well with RCA silicon-gate COS/MOS circuits which operate from supply voltages as low as 1.1 volts.

## Wall Clocks

Size and power limitations for clocks are not as restrictive as those for wristwatches. For this reason, lower-cost, higher-frequency crystals may be used. The optimum range of crystal frequencies presently appears to be from 131 kHz to 524 kHz . All the oscillator considerations given previously for operation at 32 kHz apply equally well to this higher frequency range. The oscillator circuit configuration shown in Fig. 9(b) is still the optimum type; however, the value of the source resistors must be decreased to assure adequate gain at the higher frequencies. Source resistors are often best chosen experimentally by gradually increasing the resistance until an output voltage swing of 30 to 70 per cent of the supply voltage VDD is reached. Data taken from a typical $262-\mathrm{kHz}$ oscillator circuit that employs two 10 -kilohm source resistors and a DT-cut, $262-\mathrm{kHz}$ crystal are shown in Table V. The table also shows typical counter current.

The most popular readout devices for clocks are conventional-hand movements and liquid-crystal displays. Continuously operating light-emitting-diode numerals consume too much current even for long life of $C$ - and $D$-size batteries. In contrast, a typical RCA four-digit liquid-crystal

Table IV - Typical Data for Mallory Watch Cells

| Type | Voltage | Capacity <br> $\mu$ A yrs. | Height <br> (in.) | Diameter <br> (in.) |
| :--- | :---: | :---: | :---: | :---: |
| WH3 | 1.35 | 25 | 0.208 | 0.455 |
| WS 14 <br> Type A | 1.55 | 19 | 0.210 | 0.455 |
| W4 | 1.35 | 11 | 0.139 | 0.455 |
| WS11 | 1.55 | 11 | 0.164 | 0.455 |
| 10 R 101 <br> (EXP) | 1.35 | 36 | 0.190 | 0.610 |
| 10 L 19 <br> (EXP) | 1.55 | 27 | 0.190 | 0.610 |
| WD4 | 1.36 | 14 | 0.149 | 0.594 |
| WD5 | 1.36 | 23 | 0.110 | 1.003 |

display having a 0.4 -inch-by- 0.6 -inch numeral consumes only 100 microamperes of current with all segments energized.

Motors for driving the clock hands are typically of the balance-wheel or continuously rotating synchronous types. Sensitivity to vibration is usually not a restriction; hence, the balance wheel motor can be successfully used in place of the more expensive stepping motor. Clock motors typically require about 300 to 450 microwatts of power, or average currents of 200 to 300 microamperes at 1.5 volts.

These currents, together with the oscillator and counter currents given in Table V, can now be compared with typical battery capacities. Battery information extrapolated from published Eveready data on popular AA-, C-, and D-size cells is listed in Table VI. ${ }^{5}$ Most of the battery current is consumed by the motor, and if a total current of 250 microamperes is assumed, the data show a carbon-zinc C cell as the minimum size battery required for one year of life.

## Auto Clocks

Auto clock circuits are somewhat unique in that power considerations are not nearly as restrictive as in other portable applications. Although the low-power feature of COS/MOS circuits is helpful, the main advantages obtained

Table V - Typical Data for $\mathbf{2 6 2 - k H z}$ Oscillator
and Counter Circuits

| Product | VDD <br> $($ Volts $)$ | Oscillator <br> Current <br> $(\mu \mathrm{A})$ | Counter <br> Current <br> $(\mu \mathrm{A})$ | Freq. <br> Stability <br> $($ ppm $)$ |
| :---: | :---: | :---: | :---: | :---: |
| Silicon-Gate | 1.1 V | 7 | 7 | 2.0 ppm |
| $"$ | 1.3 V | 9.5 | 9 |  |
| $"$ | 1.5 V | 11.5 | 10 | 1.2 |
| $"$ | 1.6 V | 12.5 | 11 |  |
| Low-Voltage | 2.2 V | 21 | 10 | 1.8 |
| $"$ | 3.0 V | 35 | 13 |  |

Table VI - Life Data for Typical Batteries

| Eveready <br> Type \# | Mallory <br> Type \# | Size | Type | Life <br> (Days) |
| :--- | :--- | :--- | :--- | :--- |
| 915 | M15F | AA | Carbon- <br> Zinc | 150 |
| E91 | MN1500 | AA | Alkaline | 200 |
| 935 | M14F | C | Carbon- <br> Zinc | 385 |
| E93 | MN1400 | C | Alkaline | 575 |
| 950 | M13F | D | Carbon- <br> Zinc | 800 |
| E95 | MN1300 | D | Alkaline | 1100 |

All life data assumes a continuous drain of $250 \mu \mathrm{~A}$ and an end-of-life voltage of 1.1 V .
from the use of COS/MOS in automobile clocks, or in any automotive application, are those of wide operating voltage and temperature range and high noise immunity.

With little restriction on power, the choice of a crystal depends mainly on cost. Crystals typically used for automobile timing applications are AT-cut types that operate at frequencies between 1 MHz and 4.2 MHz . The oscillator considerations discussed earlier also apply to these frequencies; however, as the frequency increases, it becomes increasingly difficult to maintain a low starting voltage at a low current. At high frequencies, the starting voltage and current are inversely proportional and are controlled mainly by the values of the capacitors on the pi-type feedback network and the size of the COS/MOS amplifier transistors. For minimum starting voltage, relatively small capacitors should be used in the pi-feedback network, and no source resistors should be added to the amplifier. As indicated by data taken on the circuit shown in Fig. 9(b) and shown in Table VII, low power can still be maintained even when the source resistors are not used.

The upper limit of the crystal frequency depends not so much on power consumption as on the minimum supply voltage allowed for circuit operation. The minimum automobile battery voltage is generally considered to be 5 volts; however, the supply voltage for the timing circuit can be considerably less than this value depending upon the design of the transient protection circuit, as discussed later. Table VIII lists minimum COS/MOS supply voltages for typical oscillator circuits. The values shown permit design at two temperatures. The lower temperature is often considered adequate by auto companies with the opinion that the minimum battery voltage of 5 volts rarely, if ever, occurs at high temperatures.

The oscillator in a typical auto clock circuit is followed by a number of frequency-dividing stages, the last stage of which is frequently used to drive a motor. Long counter chains are required because of the high oscillator frequency; however, the power dissipation of COS/MOS circuits is so low that the number of stages is only restricted by chip size

## Table VII - Typical High-Frequency Data for COS/MOS Oscillator and Counter Circuits (Low-Voltage Product)

| VDD <br> (Volts) | Freq. $(\mathrm{MHz})$ | Oscillator <br> Current <br> (mA) | Counter Current (mA) | Motor Current (mA) |
| :---: | :---: | :---: | :---: | :---: |
| 5 | 1 | 0.28 | 0.125 | $\begin{aligned} & 5 \mathrm{~V} \\ & 2-5 \mathrm{~mA} \\ & 12 \mathrm{~V} \\ & 5-10 \mathrm{~mA} \end{aligned}$ |
| 12 | 1 | 1.3 | 0.275 |  |
| 5 | 2 | 0.37 | 0.250 |  |
| 12 | 2 | 1.5 | 0.550 |  |
| 5 | 3 | 0.40 | 0.375 | $\begin{aligned} & 5 \mathrm{~V} \\ & 3.8 \mathrm{~mA} \\ & 12 \mathrm{~V} \\ & 8-20 \mathrm{~mA} \end{aligned}$ |
| 12 | 3 | 1.9 | 0.825 |  |
| 5 | 4 | 0.43 | 0.500 |  |
| 12 | 4 | 2.3 | 1.1 |  |

limitations. Because COS/MOS circuits consume current only during switching transitions, each counter stage averages one-half the current of the previous stage. The first counter stage, therefore, consumes as much current as all of the following stages combined for a counter of infinite length. Little difference, then, exists between the power consumption of a ten-stage or thirty-stage COS/MOS counter. Table VII lists, in addition to the oscillator current, typical values of counter current, as well as some typical ranges of peak and average motor currents.

Current data, such as that shown in Table VII, are necessary for a proper design of the transient protection circuit, an essential part of any automobile digital logic system. Automobile manufacturers disagree on the maximum amplitude and decay of transient voltage; however, values often used are maximum transients of +120 volts and -90 volts, each decaying exponentially with a maximum time constant of 45 milliseconds. Because standard COS/MOS circuits are rated for a maximum supply of 15 volts, a protection circuit must be included between the battery and the COS/MOS logic.

Fig. 17 shows a transient-voltage protection circuit that is frequently used. The zener diode regulates the voltage supply

## Table VIII - Minimum Operating Voltages for COS/MOS Integrated Circuits

|  | Low-Voltage Product |  |  | Silicon-Gate Product |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Freq. <br> $(\mathrm{MHz})$ | 1 | 2 | 3 | 4 | 1 | 2 | 3 | 4 |
| Min. <br> Voltage <br> at $25^{\circ} \mathrm{C}$ | 2.9 | 3.1 | 3.5 | 4.0 | 1.6 | 2.0 | 2.6 | 3.0 |
| Min. <br> Voltage <br> at $82^{\circ} \mathrm{C}$ <br> $180^{\circ} \mathrm{F}$ | 3.0 | 3.3 | 4.0 | 5.0 | 1.8 | 2.6 | 3.4 | 4.0 |



Fig. 17- Automobile transient-protection circuit.
for the clock circuits, and the capacitor and series diode prevent timing losses during negative transients. For minimum zener current during transients, the maximum value of R should be based on the minimum circuit operating voltage and the peak current drawn by the logic circuit and motor at the minimum battery voltage. The minimum zener breakdown voltage is then determined by subtraction of the product of the minimum current drain at the normal battery voltage and the value of R just chosen from the battery voltage. A zener breakdown greater than this voltage assures that no unnecessary current will be drawn by the zener during normal automobile operation.

Another important zener characteristic is dynamic impedance. During a current surge, the voltage across the zener must not rise to a damaging level. A value of 22 volts for the 45 -millisecond time constant appears safe for standard COS/MOS circuits.

In the design of a typical transient-voltage protection circuit, it is assumed that the minimum battery voltage is 5 volts, that the minimum circuit operating voltage is 3.5 volts at a crystal frequency of 3.145728 MHz , and that a peak current of 3 milliamperes is obtained at 5 volts. The value of the resistance R is then found as $(5-3.5+0.7) / 3 \approx 250$ ohms. With a minimum current of 5 milliamperes at 12 volts, the minimum zener voltage becomes $12-5(0.250)=11.75$ volts. For a +120 -volt transient, the zener could then consume a peak current of $(120-11.8) / 250=0.4$ ampere. For a maximum zener voltage of 13 volts, the dynamic impedance of the zener must be less than $(22 \mathrm{~V}-13 \mathrm{~V}) / .4 \mathrm{~A}=$ 22 ohms. Components chosen in this manner will provide adequate protection for anticipated transients.

Both protection-circuit diodes can be integrated onto the COS/MOS chip. When located as shown in Fig. 17, the series diode need only have a breakdown rating of about 12 volts. Zener diodes that have breakdown ratings of 4.5 to 6.0 volts or any multiple thereof can also be integrated onto the COS/MOS chip. The breakdown rating can also be increased in 0.7 -volt steps by addition of forward-biased diodes in series. Characteristics of two typical zener diodes integrated in series are shown in Fig. 18. Fig. 18(a) shows the area around the "knee" of the breakdown region, and Fig. 18(b) shows the higher-current region useful for determining the dynamic resistance. From the slope of the line, the typical dynamic resistance for two diodes is found to be 17.6 ohms total, or 8.8 ohms per diode. The diodes are rated to withstand a 0.5 -ampere surge current that decays with an 80 -millisecond time constant. The zener diode, then, is compatible with present automobile protection requirements,


Fig. 18- Oscillograph tracings showing characteristics of an integrated zener diode: (a) low-current region; (b) high-current region.
and integration of this component should represent a considerable cost saving, especially when integrated with the series diode.

## Other Applications

Although wristwatches and clocks of various types are important applications of COS/MOS timing circuits, they are certainly not the only timing applications which can benefit from the unique features of COS/MOS logic. Applications such as fuze timers, feeding systems, automatic sprinklers,
incubator timers, and other similar systems can be designed from information provided on the oscillator and counter with only the output device unique to the particular application. Automobile applications for COS/MOS circuits are almost endless. One can think of speed controllers, digital speedometers, miles per gallon indicators, and perhaps even estimated-time-of-arrival indicators that, on the basis of the given total mileage, would update the time on a dynamic basis from information provided by the speedometer, odometer, and clock.

## CONCLUSIONS

The primary advantage of electronic timing circuits over conventional mechanical methods of timekeeping lies in the greatly increased accuracy permitted by the highly stable crystal-controlled oscillator circuit. Although crystal oscillator circuits have existed for some time, their usefulness in portable applications has been somewhat limited because of the high current consumption required by the following digital logic. The advent of COS/MOS integrated circuits now permits the design of complete low-power timing systems. The impact of COS/MOS on timing applications is perhaps equalled by the recent development of liquid-crystal displays and dc-to-dc converters that allow low-power continuously operating digital displays. Certainly, no great technological barriers now exist for the use of electronic timing circuits in a wide variety of applications. The search, no doubt, will always continue for the ideal timekeeping device; however, it should be apparent from the information presented that the ideal timekeeping unit can now be more closely approached than ever before.

## REFERENCES

1. Eaton, S.S., "Micropower Crystal-Controlled Oscillator Design Using RCA COS/MOS Inverters," RCA Application Note ICAN 6539, 1971.
2. "Frequency Control Devices," Catalog No. 670, Northern Enginnering Laboratories, Burlington, Wisconsin.
3. Yoda, H., "Low Power Crystal Oscillator for Electronic Wrist Watch," Mihon Dempa Kogyo Co., Ltd., Japan, 1971.
4. Schindler, H.C., "Liquid Crystal Dynamic Scattering for Display Devices," RCA Publication PE-533, 1972.
5. Eveready Battery Applications Engineering Data, Union Carbide Corp., 1971.

# The RGA COS/關OS Phaserackedu Loop A Versatile Building Block for Micro-Power Digitail ancianalog Appilcations 

by David K. Morgan

## INTRODUCTION

Phase-locked-loops (PLL's), especially in monolithic orm, are finding significantly increased usage in signalrocessing and digital systems. FM demodulation, FSK emodulation, tone decoding, frequency multiplication, gnal conditioning, clock synchronization, and frequency ynthesis are some of the many applications of a PLL. The LL described in this Note is the COS/MOS CD4046A, which consumes only 600 microwatts of power at 10 kHz , a eduction in power consumption of 160 times when ompared to the 100 milliwatts required by similar monoithic bipolar PLL's. This power reduction has particular ignificance for portable battery-operated equipment. This Jote discusses the basic fundamentals of phase-locked-loops, and presents a detailed technical description of the COS/ IOS PLL as well as some of its applications.

## REVIEW OF PLL FUNDAMENTALS

The basic phase-locked-loop system is shown in Fig. 1; it zonsists of three parts: phase comparator, low-pass filter, and roltage-controlled oscillator (VCO); all are connected to form a closed-loop frequency-feedback system.

With no signal input applied to the PLL system, the error voltage at the output of the phase comparator is zero. The voltage, $\mathrm{Vd}(\mathrm{t})$, from the low-pass filter is also zero, which causes the VCO to operate at a set frequency, fo, called the center frequency. When an input signal is applied to the PLL, the phase comparator compares the phase and frequency of the signal input with the VCO frequency and generates an error voltage proportional to the phase and frequency


Fig. 1- Block diagram of PLL.
difference of the input signal and the VCO. The error voltage, $\mathrm{Ve}(\mathrm{t})$, is filtered and applied to the control input of the $\mathrm{VCO} ; \mathrm{Vd}(\mathrm{t})$ varies in a direction that reduces the frequency difference between the VCO and signal-input frequency. When the input frequency is sufficiently close to the VCO frequency, the closed-loop nature of the PLL forces the VCO to lock in frequency with the signal input; i.e., when the PLL is in lock, the VCO frequency is identical to the signal input except for a finite phase difference. The range of frequencies over which the PLL can maintain this locked condition is defined as the lock range of the system. The lock range is always larger than the band of frequencies over which the PLL can acquire a locked condition with the signal input. This latter band of frequencies is defined as the capture range of the PLL system.

## TECHNICAL DESCRIPTION OF COS/MOS PLL

Fig. 2 shows a block diagram of the COS/MOS CD4046A, which has been implemented on a single


Fig. 2- COS/MOS PLL block diagram.
monolithic integrated circuit. The PLL structure consists of a low-power, linear, voltage-controlled oscillator (VCO), and two different phase comparators having a common signalinput amplifier and a common comparator input. A 5.2 -volt zener is provided for supply regulation if necessary. The VCO can be connected either directly or through frequency dividers to the comparator input of the phase comparators. The low-pass filter is implemented through external parts because of the radical configuration changes from application to application and because some of the components are non-integrable. The CD4046A is supplied in a 16 -lead, dual-in-line, ceramic package (CD4046AD); a 16-lead, dual-in-line, plastic package (CD4046AE); or a 16-lead flat-pack (CD4046AK). It is also available in chip form (CD4046AH).

## Phase Comparators

Most PLL systems utilize a balanced mixer composed of well-controlled analog amplifiers for the phase-comparator section. Analog amplifiers with well-controlled gain characteristics cannot easily be realized using COS/MOS technology. Hence, the COS/MOS design shown in Fig. 3 employs digital-type phase comparators. Both phase comparators are driven by a common-input amplifier configuration composed of a bias stage and four inverting-amplifier stages. The phase-comparator signal input (terminal 14) can be direct-coupled provided the signal swing is within COS/MOS logic levels [logic $0 \leqslant 30 \%$ (VDD-VSS), logic $1 \geqslant 70 \%$ (VDD.VSS) ]. For smaller input signal swings, the signal must be capacitively coupled to the self-biasing amplifier at the signal input to insure an over-driven digital signal into the phase comparators.

Phase-comparator I is an exclusive-OR network; it operates analagously to an over-driven balanced mixer. To maximize the lock range, the signal and comparator input frequencies must have 50 -percent duty cycle. With no signal or noise on the signal input, this phase comparator has


Fig. 3- Schematic of COS/MOS PLL phase-comparator section.
an average output voltage equal to VDD/2. The low-pass filter connected to the output of phase-comparator I supplies the averaged voltage to the VCO input, and causes the VCO to oscillate at the center frequency ( $\mathrm{f}_{\mathrm{o}}$ ). With phase-comparator $I$, the range of frequencies over which the PLL can acquire lock (capture range) is dependent on the low-pass-filter characteristics, and can be made as large as the lock range. Phase-comparator I enables a PLL system to remain in lock in spite of high amounts of noise in the input signal.

One characteristic of this type of phase comparator is that it may lock onto input frequencies that are close to harmonics of the VCO center-frequency. A second characteristic is that the phase angle between the signal and the comparator input varies between $0^{\circ}$ and $180^{\circ}$, and is $90^{\circ}$ at the center frequency. Fig. 4 shows the typical, triangular, phase-to-output, response characteristic of phase-comparator I. Typical waveforms for a COS/MOS phase-locked-loop employing phase-comparator $I$ in locked condition of $f_{O}$ is shown in Fig. 5.

Phase-comparator II is an edge-controlled digital memory network. It consists of four flip-flop stages, control gating, and a three-state output circuit comprising $p$ and $n$ drivers having a common output node as snown in Fig. 3. When the p-MOS or n-MOS drivers are ON, they pull the output up to $\mathrm{V}_{\mathrm{DD}}$ or down to $\mathrm{V}_{\mathrm{SS}}$, respectively. This type of phase comparator acts only on the pusitive edges of the signaland comparator-input signals. The duty cycles of the signal and comparator inputs are not important since positive transitions control the PLL system utilizing this type of comparator. If the signal-input frequency is higher than the comparator-input frequency, the p-MOS output driver is maintained ON continuously. If the signal-input frequency is lower than the comparator-input frequency, the $n$-MOS output driver is maintained ON continuously. If the signaland comparator-input frequencies are the same, but the signal input lags the comparator input in phase, the n-MOS output driver is maintained ON for a time corresponding to the phase difference. If the signal- and comparator-input frequencies are the same, but the signal input leads the comparator input in phase, the p-MOS output driver is maintained ON for time corresponding to the phase difference. Subsequently, the capacitor voltage of the low-pass filter connected to this type of phase comparator is adjusted until the signal and comparator input are equal in both phase and frequency. At this stable operating point, both p - and n -MOS output drivers remain OFF, and thus the phase-comparator


Fig. 4- Phase-comparator I characteristics at low-pass filter output.


Fig. 5- Typical waveforms for COS/MOS phaselocked loop employing phase-comparator I in locked condition of $f_{o}$.
output becomes an open circuit and holds the voltage on the capacitor of the low-pass filter constant. Moreover, the signal at the "phase pulses" output is at a high level, and can be used for indicating a locked condition. Thus, for phase-comparator II, no phase difference exists between signal and comparator input over the full VCO frequency range. Moreover, the power dissipation due to the low-pass filter is reduced when this type of phase comparator is used because both the p-and nMOS output drivers are OFF for most of the signal-input cycle. It should be noted that the PLL lock range for this type of phase comparator is equal to the capture range, independent of the low-pass filter. With no signal present at the signal input, the VCO is adjusted to its lowest frequency for phase-comparator II. Fig. 6 shows typical waveforms for a COS/MOS PLL employing phase-comparator II in a locked condition.

Fig. 7 shows the state diagram for phase-comparator II; each circle represents a state of the comparator. The number at the top inside each circle represents the state of the comparator, while the logic state of the signal and comparator inputs, represented by a 0 or a 1 , are given by the left and right numbers, respectively, at the bottom of each circle. The transitions from one state to another result from either a logic change on the signal input (I) or the comparator input (C). A positive transition and a negative transition are shown by an arrow pointing up or down, respectively. The state diagram assumes that only one transition on either the signal input or the comparator input occurs at any instant. States 3,5,9, and 11 represent the condition at the output of phase-comparator II when the p-MOS driver is ON , while states $2,4,10$, and 12 determine the condition when the n-MOS driver is ON. States $1,6,7$, and 8 represent the condition when the output of phasecomparator II is in its high impedance state; i.e., both p- and n -devices are OFF, and the phase-pulses output (terminal 1) is high. The condition at the phase-pulses output for all other states is low.

As an example of how one may use the state diagram shown in Fig. 7, consider the operation of phase-comparator II in the locked condition shown in Fig. 6. The waveforms shown in Fig. 6 are broken up into three sections: section I corresponds to the condition in which the signal input leads the comparator input in phase, while section II corresponds to a finite phase difference. Section III depicts the condition when the comparator input leads the signal input in phase. These three sections all correspond to a locked condition for the COS/MOS PLL; i.e., both signal- and comparator-input


NOTE: DASHED LINE IS AN OPEN-CIRCUIT CONDITION 92CS-200IRI
Fig. 6 - Typical waveforms for COS/MOS phase-locked loop. employing phase-comparator // in locked condition.
signals are of the same frequency but differ slightly in phase. Assume that both the signal inputs begin in the 0 state, and that phase-comparator II is initially in its high-impedance output condition (state 1), as shown in Figs. 7 and 6, respectively. The signal input makes a positive transition
 Assume that both the signal inputs begin in the 0 state, and
that phase-comparator II is initially in its high-impedance

Fig. 7- State diagram of phase-comparator II.
first, which brings phase-comparator II to state 3. State 3 corresponds to the condition of the comparator in which the signal input is a 1 , the comparator input is a 0 , and the output p-device is ON . The comparator input goes high next, while the signal input is high, thus bringing the comparator to state 6 , a high-impedance output condition. The signal input goes to zero next, while the comparator input is high, which corresponds to state 7. The comparator input goes low next, bringing phase-comparator II back to state 1 . As shown for section I, the p-device stays on for a time corresponding to the phase difference between the signal input and the comparator input. Starting in state 1 at the beginning of section III, the comparator input goes high first, while the signal input is low, bringing the comparator to state 2 . Following the example given for section I, the comparator proceeds from state 2 to states 6 and 8 and then back to 1 . The output of phase-comparator II for section III corresponds to the n -device being on for a time corresponding to the phase difference between the signal and comparator inputs.

The state diagram of phase-comparator II completely describes all modes of operation of the comparator for any input condition in a phase-locked-loop.

## Voltage-Controlled Oscillator

Fig. 8 shows the schematic diagram of the voltagecontrolled oscillator (VCO). To assure low system-power dissipation, it is desirable that the low-pass filter consume little power. For example, in an RC filter, this requirement dictates that a high-value R and a low-value C be utilized. The VCO input must not, however, load down or modify the characteristics of the low-pass filter. Since the VCO design shown utilizes an n-MOS input configuration having practically infinite input resistance, a great degree of freedom is allowed in selection of the low-pass filter components.

The VCO circuit shown in Fig. 8 operates as follows: when the inhibit input is low, $\mathrm{P}_{3}$ is turned full ON , effectively connecting the sources of $\mathrm{P}_{1}$ and $\mathrm{P}_{2}$ to VDD; and gates 1 and 2 are permitted to function as NOR-gate flip-flops. N1 together with external-resistor R1 form a source-follower configuration. As long as the resistance of R1 is at least an order of magnitude greater than ON resistance of $\mathrm{N}_{1}$ (greater than 10 kilohms), the current through R1 is linearly dependent on the VCO input voltage. This current flows through $\mathrm{P}_{1}$, which, together with P 2 , forms a current-mirror network. External resistor R2 adds an additional constant current through P1; this current offsets the VCO operating frequency for VCO input signals of 0 volts. In the current-mirror network, the current of P2 is effectively equal to the current through P1 independent of the drain voltage at P 2 . (This condition is true provided P 2 is maintained in saturation; in the circuit shown, $\mathrm{P}_{2}$ is saturated under all possible operating conditions and modes). The set/reset flip-flop composed of gates 1 and 2 turns ON either P4 and N3, or P5 and N2. One side of the external capacitor C1 is, therefore, held at ground, while the other side is charged by the constant current supplied by P2. As soon as C1 charges to the point at which the transfer point of inverters 1 or 5 is reached, the flip-flop changes state. The


Fig. 8- Schematic of COS/MOS VCO section.
charged side of the capacitor is now pulled to ground. The other side of the capacitor goes negative, and discharges rapidly through the drain diode of the OFF $n$-device. Subsequently, a new half-cycle starts. Since inverters 1 and 5 have the same transfer points, the VCO has a 50 -percent duty-cycle. Inverters 1 through 4 and 5 through 8 serve several purposes: (1) they shape the slow-input ramp from capacitor C 1 to a fast waveform at the flip-flop input stage, (2) they maintain low power dissipation through the use of high-impedance devices at inverters 1 and 5 (slow-input wave-forms), and (3) they provide four inverter delays before removal of the set/reset flip-flop triggering pulse to assure proper toggling action.

In order not to load the low-pass filter, a source-follower ouput of the VCO input voltage is provided (demodulated output). If this output is used, a load resistor (Rs) of 10 kilohms or more should be connected from this terminal to ground. If unused, this terminal should be left open. A logic 0 on the inhibit input enables the VCO and the source follower, while a logic 1 turns off both to minimize stand-by power consumption.

## Performance Summary of COS/MOS PLL

The maximum ratings for the CD4046A COS/MOS PLL, as well as its general operating-performance characteristics are outlined in Table 1. The VCO and comparator characteristics are shown in Tables II and III, respectively. Table IV summarizes some useful formulas as a guide for approximating the values of external components for the CD4046A in a phase-locked-loop system. When using Table IV, one should keep in mind that frequency values are in kilohertz, resistance values are in kilohms, and capacitance values are in microfarads. The selected external components must be within the following ranges:

$$
\begin{aligned}
& 10 \mathrm{~K} \Omega \leqslant \mathrm{R}_{1}, \mathrm{R}_{2}, \mathrm{R}_{\mathrm{s}} \leqslant 1 \mathrm{M} \Omega \\
& \mathrm{C}_{1} \geqslant 100 \mathrm{pF} \text { at } \mathrm{V}_{\mathrm{DD}} \geqslant 5 \mathrm{~V} \\
& \mathrm{C}_{1} \geqslant 50 \mathrm{pF} \text { at } \mathrm{V}_{\mathrm{DD}} \geqslant 10 \mathrm{~V}
\end{aligned}
$$

In addition to the given design information, refer to Fig. 9 for $\mathrm{R}_{1}, \mathrm{R}_{2}$, and $\mathrm{C}_{1}$ component selections. The use of Table IV in designing a COS/MOS PLL system for some familiar applications is discussed below.

## APPLICATIONS OF THE COS/MOS PLL

The COS/MOS phase-locked-loop is a versatile building block suitable for a wide variety of applications, such as FM demodulators, frequency synthesizers, split-phase data synchronization and decoding, and phase-locked-loop lock detection.

## FM Demodulation

When a phase-locked-loop is locked on an FM signal, the voltage-controlled oscillator (VCO) tracks the instantaneous frequency of that signal. The VCO input voltage, which is the filtered error voltage from the phase detector, corresponds to the demodulated output. Fig. 11 shows the connections for the COS/MOS CD4046A PLL as an FM demodulator. For this example, an FM signal consisting of a 10-kilohertz carrier frequency was modulated by a $400-\mathrm{Hz}$ audio signal. The total

Table 1-Maximum ratings and general operating characteristics

## MAXIMUM RATINGS, Absolute-Maximum Values:

| Storage Temperature Range . . . . . . . - $65^{\circ} \mathrm{C}$ to $+150{ }^{\circ} \mathrm{C}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| Operating Temperature Range: |  |  |  |
| Ceramic Package Types . . . . . . . . $-55^{\circ} \mathrm{C}$ to +125 |  |  |  |
| Plastic Package Types . . . . . . . . . $-40^{\circ} \mathrm{C}$ to +85 |  |  |  |
| DC Supply Voltage Range |  |  |  |
| $\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\text {SS }}\right.$ ) . . . . . . . . . . . . -0.5V to +15 |  |  |  |
| Device Dissipation (Per Pkg.) . . . . . 200 mW |  |  |  |
| All inputs . . . . . . . . . . . . . . . . . . $\mathrm{V}_{\text {SS }} \leqslant \mathrm{V}_{1} \leqslant \mathrm{~V}_{\text {DD }}$ |  |  |  |
| Recommended |  |  |  |
| DC Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\text {SS }}$ ). 5 to 15 V |  |  |  |
| Recommended |  |  |  |
| Input Voltage Swing .......... $V_{\text {DD }}$ to $V_{\text {SS }}$ |  |  |  |
| $\begin{aligned} & \text { General Characteristics (Typical Values at } V_{D D}-V_{S S} \\ &\left.=10 \mathrm{~V} \text { and } \mathrm{T}_{A}=25^{\circ} \mathrm{C}\right) \end{aligned}$ |  |  |  |
| Operating Supply Voltage ( $\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\text {SS }}$ ) . ..... 5 to 15 V |  |  |  |
| Operating Supply Current: |  |  |  |
| $\begin{array}{ll} \text { Inhibit }={ }^{\prime} 0^{\prime \prime} & f_{0}=10 \mathrm{kHz}, V_{D D}=5 \mathrm{~V} \ldots 70 \mu \mathrm{~W} \\ @ C_{1}=0.0001 \mu \mathrm{~F} \\ R_{1}=1 \mathrm{M} \Omega & f_{0}=10 \mathrm{kHz}, V_{D D}=10 \mathrm{~V} \ldots 600 \mu \mathrm{~W} \end{array}$ |  |  |  |
|  |  |  |  |
|  |  |  |  |

Table II-VCO electrical characteristics

$$
\begin{aligned}
& \text { VCO Characteristics (Typical Values at } V_{D D}-V_{S S} \\
&=10 \mathrm{~V} \text { and } T_{A}=25^{\circ} \mathrm{C} \text { ) }
\end{aligned}
$$

| Maximum Frequency . . . . . . . . . . . . . . 1.2 MHz |  |
| :---: | :---: |
| Temperature Stability | $600 \mathrm{ppm} /{ }^{\circ} \mathrm{C}$ |
| Linearity ( $\mathrm{V}_{\mathrm{VCO}}$ in $=5 \mathrm{~V} \pm 2.5 \mathrm{~V}$ ) .... 1\% |  |
| Center Frequency | Programmable with |
|  | $\mathrm{R}_{1}$ and $\mathrm{C}_{1}$ |
| Frequency Range | Programmable with |
|  | $\mathrm{R}_{1}, \mathrm{R}_{2}$, and $\mathrm{C}_{1}$ |
| Input Resistance | $10^{12} \Omega$ |
| Output Voltage | $10 V_{p-p}$ |
| Duty Cycle | 50\% |
| Rise \& Fall Times | 50 ns |
| Output Current Capability |  |
| "1' Drive @ $\mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V}$ | -1.8 mA |
| "0' Sink @ $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$. | 2.6 mA |

Demodulated Output:
Offset Voltage
$\left(V_{\text {VCO in }}-V_{\text {DEMOD out }}\right) @ 1 \mathrm{~mA} \cdot 1.5 \mathrm{~V}$

Table III - Comparator electrical characteristics
Comparator Characteristics (Typical Values at $\mathrm{V}_{\text {DD }}{ }^{-} \mathrm{V}_{\text {SS }}$

$$
\left.=10 \mathrm{~V} \text { and } \mathrm{T}_{A}=25^{\circ} \mathrm{C}\right)
$$

Signal Input:

| Input Impedance | $400 \mathrm{~K} \Omega$ |
| :---: | :---: |
| Input Sensitivity : |  |
| ac coupled | 400 mV |
| dc coupled | $\left\{\begin{array}{l} { }^{\prime} 0 \cdot \leqslant 30 \%\left(V_{D D}-v_{S S}\right) \\ { }^{\prime \prime} \cdot \prime \geqslant 70 \%\left(v_{D D}-v_{S S}\right) \end{array}\right.$ |
| Comparator Input L | $\begin{aligned} & \prime 0 " \leqslant 30 \%\left(V_{D D}-v_{S S}\right) \\ & " 1 " \geqslant 70 \%\left(V_{D D}-V_{S S}\right) \end{aligned}$ |

Output Current Capability
Comparator I (term. 2) and C̣omparator II (term. 13):

$$
\begin{aligned}
& " 1 " \text { Drive @ } V_{O}=9.5 \mathrm{~V} \ldots .-1.8 \mathrm{~mA} \\
& " 0 " \text { Sink @ } \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \ldots \ldots \quad 2.6 \mathrm{~mA}
\end{aligned}
$$

Comparator II Phase Pulses (term. 1):

$$
\begin{aligned}
& { }^{\prime} 1 " \text { Drive @ } \mathrm{V}_{\mathrm{O}}=9.5 \mathrm{~V} \ldots .-0.5 \mathrm{~mA} \\
& { }^{\prime} 0^{\prime \prime} \text { Sink @ } \mathrm{v}_{\mathrm{O}}=0.5 \mathrm{~V} \ldots \ldots .1 .4 \mathrm{~mA}
\end{aligned}
$$

FM signal amplitude is 500 millivolts, therefore the signal must be ac coupled to the signal input (terminal 14). Phase-comparator I is used for this application because a PLL system with a center frequency equal to the FM carrier frequency is needed. Phase comparator I lends itself to this application also because of its high signal-input-noiserejection characteristics.

The formulas shown in Table IV for phase-comparator I with $\mathrm{R}_{2}=\infty$ are used in the following considerations. The center frequency of the VCO is designed to be equal to the carrier frequency, 10 kHz . The value of capacitor $\mathrm{C}_{1}, 500 \mathrm{pF}$, was found by assuming an $\mathrm{R}_{1}=100 \mathrm{~K} \Omega$ for a supply voltage $\mathrm{V}_{\mathrm{DD}}=5$ volts.

These values determined the center frequency:

$$
\mathrm{f}_{\mathrm{O}}=10 \mathrm{kHz}
$$

The PLL was set for a capture-range of

$$
\mathrm{f}_{\mathrm{c}} \approx \pm \frac{1}{2 \pi} \frac{2 \pi \mathrm{fl}}{\mathrm{R}_{3} \mathrm{C}_{2}}= \pm 0.4 \mathrm{kHz}
$$



Fig. 9(a)- Typical center frequency vs. $C_{1}$ for $R_{1}=10 \mathrm{~K} \Omega, 100 \mathrm{~K} \Omega$, and $1 \mathrm{M} \Omega$.


Fig. 9(b)- Typical frequency offset vs. $C_{1}$ for $R_{2}=10 \mathrm{~K} \Omega, 100 \mathrm{~K} \Omega$, and $1 \mathrm{M} \Omega$.


Fig. 9(c)- Typical $f_{\max } / f_{\min }$ vs. $R_{2} / R_{1}$.

| CHARACTERISTICS | USING PHASE COMPARATOR I |  | USING PHASE COMPARATOR II |  |
| :---: | :---: | :---: | :---: | :---: |
|  | VCO WITHOUT OFFSET $\mathbf{R}_{2}=\infty$ | VCO WITH OFFSET | VCO WITHOUT OFFSET $\mathbf{R}_{2}=\infty$ | VCO WITH OFFSET |
| VCO Frequency |  vCO input voltage |  <br> vCO INPUT VOLTAGE |  <br> vCoinput vertage |  <br> VCO INPUT VOLTAGE 92CS-20012R1 |
| For No Signal Input | VCO in PLL system will adjust to center frequency, $\mathrm{f}_{0}$ |  | VCO in PLL system will adjust to lowest operating frequency, $f_{\text {min }}$ |  |
| Frequency Lock Range, $\mathbf{2 f}_{\text {L }}$ | $\begin{aligned} & 2 f_{L}=\text { full VCO frequency range } \\ & 2 f_{L}=f_{m a x^{-}} \mathrm{f}_{\mathrm{min}} \end{aligned}$ |  |  |  |
| Frequency Capture Range, ${ }^{2 f} \mathrm{C}$ <br> Loop Filter Component Selection |  | $\begin{gathered} (1),(2) \\ { }^{f} \mathrm{C}=\frac{1}{\pi} \sqrt{\frac{2 \pi f_{L}}{\pi}} \end{gathered}$ |  |  |
|  |  | For 2 f $\mathbf{C}$, see Ref. (2) |  |  |
| Phase Angle between Signal and Comparator | $90^{\circ}$ at center frequency ( $f_{0}$ ), approximating $0^{\circ}$ and $180^{\circ}$ at ends of lock range ( $2 f \mathrm{~L}$ ) |  | Always $0^{\circ}$ in lock |  |
| Locks on Harmonics of Center Frequency | Yes |  | No |  |
| Signal Input Noise Rejection | High |  | Low |  |
| vco <br> Component <br> Selection | - Given: $f_{0}$ <br> - Use $f_{0}$ with Fig.9a to determine R1 and C1 | - Given: $f_{0}$ and $f_{L}$ <br> - Calculate $\mathrm{f}_{\text {min }}$ from the equation $f_{\min }=f_{0}-f_{L}$ <br> - Use $f_{\text {min }}$ with Fig.9b to determine R2 and C1 <br> - Calculate $\frac{f_{\text {max }}}{f_{\text {min }}}$ <br> from the equation $\begin{aligned} & \frac{f_{\max }}{f_{\min }}=\frac{f_{0}+f_{L}}{f_{0}-f_{L}} \\ & -U_{\text {se }}^{f_{\text {max }}} f_{\text {min }} \text { with } \end{aligned}$ <br> Fig.5c to determine ratio R2/R1 to obtain R1 | - Given: $f_{\text {max }}$ <br> - Calculate $f_{0}$ from the equation $f_{0}=\frac{f_{\max }}{2}$ <br> - Use fo with Fig.9a to determine R1 and C1 | - Given: $f_{\text {min }}$ \& $f_{\text {max }}$ <br> - Use $f_{\text {min }}$ with Fig.5b to determine R2andC1 <br> - Calculate $\frac{t_{\text {max }}}{f_{\text {min }}}$ <br> -Use $\frac{f^{f^{m a x}}}{f_{\text {min }}}$ with Fig.9c <br> to determine ratio R2/R1 to obtain R1 |

For further information, see
er, "Phase-Lock Techniques", John Wiley and Sons, New York, 1966
(2) G. S. Moschytz, "Miniaturized RC Filters Using Phase-Locked Loop", BSTJ, May, 1965.


Fig. 10- FM demodulator.
to allow for the deviation of the carrier frequency due to the audio signal. The components shown in Fig. 10 for the low-pass filter ( $\mathrm{R}_{3}=100 \mathrm{k} \Omega, \mathrm{C}_{2}=0.1 \mu \mathrm{~F}$ ) determine the above capture frequency.

The total current drain at a supply voltage of 5 volts for this FM-demodulator application is 132 microamperes for a 4 $\mathrm{dB} \mathrm{S} / \mathrm{N}$-ratio on the signal input, and 90 microamperes for a $10 \mathrm{~dB} \mathrm{~S} / \mathrm{N}$ ratio. The power consumption decreases because the signal-input amplifier goes into saturation at higher input levels.

Fig. 11 shows the performance of the FM/demodulator circuit of Fig. 10 at a $4 \mathrm{~dB} \mathrm{~S} / \mathrm{N}$-ratio. The demodulated output is taken off the VCO-input source follower using a resistor Rs ( $\mathrm{R}_{\mathrm{S}}=100 \mathrm{k} \Omega$ ). The demodulation gain for this circuit is $250 \mathrm{mV} / \mathrm{kHz}$.

## Frequency Synthesizer

The PLL system can function as a frequency-selective frequency multiplier by inserting a frequency divider into the feedback loop between the VCO output and the comparator input. Fig. 12 shows a COS/MOS low-frequency synthesizer with a programmable divider consisting of three decades. N , the frequency-divider modulus, can vary from 3 to 999 in steps of 1 . When the PLL system is in lock, the signal and comparator inputs are at the same frequency and

$$
\mathrm{f}=\mathrm{N} \times 1 \mathrm{kHz}
$$

Therefore, the frequency range of this synthesizer is 3 to 999 kHz in $1-\mathrm{kHz}$ increments, which is programmable by the switch position of the Divide-by-N counter.


Fig. 11- Voltage waveforms of FM demodulator.

Phase-comparator II is used for this application because it will not lock on harmonics of the signal-input reference frequency (phase-comparator I does lock on harmonics). Since the duty cycle of the output of the Divide-by-N frequency divider is not 50 percent, phase-comparator II lends itself directly to this application.

Using the formulas for phase-comparator II shown in Table IV, the VCO is set up to cover a range of 0 to 1.1 MHz . The low-pass filter for this application is a two-pole, lag-lead filter which enables faster locking for step changes in frequency. Fig. 13 shows the waveforms during switching between output frequencies of 3 and 903 kHz . The figure shows that the transient going towards 3 kHz on the VCO control voltage is overdamped, while the transient to 903 kHz is underdamped. This condition could be improved by changing the value of $\mathrm{R}_{3}$ in the low-pass filter by means of adjustment of the switch-position hundreds in the Divide-by- N counter.

## Split-Phase Data Synchronization and Decoding

Fig. 14 shows another application of COS/MOS PLL, split-phase data synchronization and decoding. A splitphase data signal consists of a series of binary digits that occur at a periodic rate, as shown in waveform A in Fig. 14, The weight of each bit, 0 or 1 , is random, but the duration of each bit, and therefore the periodic bit-rate, is essentially constant. To detect and process the incoming signal, it is necessary to have a clock that is synchronous with the data-bit rate. This clock signal must be derived from the incoming data signal. Phase-lock techniques can be utilized to recover the clock and the data. Timing information is contained in the data transitions, which can be positive or negative in direction, but both polarities have the same meaning for timing recovery. The phase of the signal determines the binary bit weight. A binary 0 or 1 is a positive or negative transition, respectively, during a bit interval in split-phase data signals.


Fig. 12- Low-frequency synthesizer with threedecade programmable divider.


Fig. 13- Frequency-synthesizer waveforms.


Fig. 14-Split-phase data synchronization and decoding.

As shown in Fig. 14, the split-phase data-input (A) is first differentiated to mark the locations of the data transitions. The differentiated signal, (B), which is twice the bit rate, is gated into the COS/MOS PLL. Phase-comparator II in the PLL is used because of its insensitivity to duty cycle on both the signal and comparator inputs. The VCO output is fed into the clock input of FF1 which divides the VCO frequency by two. During the ON intervals, the PLL tracks the differentiated signal (B); during the OFF intervals the PLL remembers the last frequency present and still provides a clock output. The VCO output is inverted and fed into the clock input of FF2 whose data input is the inverted output of FF1. FF2 provides the necessary phase shift in signal (C) to obtain signal (D), the recovered clock signal from the split-phase data transmission. The output of FF3, (E), is the recovered binary information from the phase information contained in the split-phase data. Initial synchronization of this PLL system is accomplished by a string of alternating 0's and 1 's that precede the data transmission.

## Phase-Locked-Loop Lock Detection

In some applications that utilize a PLL, it is sometimes necessary to have an output indication of when the PLL is in lock. One of the simplest forms of lock-condition indicator is
a binary signal. For example, a 1 or a 0 output from a lock-detection circuit would correspond to a locked or unlocked condition, respectively. This signal could, in turn, activate circuitry utilizing a locked PLL signal. This detection could also be used in frequency-shift-keyed (FSK) data transmissions in which digital information is transmitted by switching the input frequency between either of two discrete input frequencies, one corresponding to a digital 1 and the other to a digital 0 .

Fig. 15 shows a lock-detection scheme for the COS/MOS PLL. The signal input is switched between two discrete frequencies of 20 kHz and 10 kHz . The PLL system uses phase-comparator II; the VCO bandwidth is set up for an $\mathrm{f}_{\min }$ of 9.5 kHz and an $\mathrm{f}_{\max }$ of 10.5 kHz . Therefore, the PLL locks and unlocks on the $10-\mathrm{kHz}$ and $20-\mathrm{kHz}$ signals, respectively. When the PLL is in lock, the output of phase-comparator I is low except for some very short pulses that result from the inherent phase difference between the signal and comparator inputs; the phase-pulses output (terminal 1) is high except for some very small pulses resulting from the same phase difference. This low condition of phase comparator $I$ is detected by the lock-detection circuit shown in Fig. 15. Fig. 16 shows the performance of this circuit when the input signal is switched between 20 and 10 kHz . It can be seen that after about five input cycles the lock detection signal goes high.


Fig. 15- Lock-detection circuit.


Fig. 16- Lock-detection-circuit waveforms.

# COS/MOS MSI Counter and Register Design and Applications 

by R. Heuner, J. Litus, Jr., A. Havasy

COS/MOS (Complementary-Symmetry Metal-OxideSemiconductor) technology offers economical MSI (Medium-Scale Integration) arrays on a single monolithic silicon chip. Added performance benefits are derived from micropower quiescent power dissipation; moderately fast operation; excellent dc and dynamic noise immunity; high dc fanout; stable performance over wide ranges of supply voltage, temperature, and device parameter variation; simple circuit and subsystem design; and compatible logic and memory circuitry from simple gates and flip-flops to complex MSI circuits.

In the COS/MOS MSI area, RCA has several counter and register types presently available commercially. These devices are available in both plastic and ceramic packages intended for military, commercial and industrial uses. Devices with the suffix " $E$ " are plastic package types; suffix " $D$ " are ceramic package types.

CD4006A - Eighteen-Stage Static Shift Register
CD4014A - Eight-Stage Synchronous Parallel-Input/SerialOutput Static Shift Register
CD4015A - Dual Four-Stage Serial-Input/Parallel-Output Static Shift Register
CD4017A - Decade Counter/Divider Plus 10 Decoded Decimal Outputs
CD4018A - Presettable Divide-by-"N" Counter
CD4020A - Fourteen-Stage Ripple-Carry Binary Counter
CD4021A - Eight Stage Asynchronous Parallel-Input/SerialOutput Static Shift Register
CD4022A— Divide-by-8 Counter Plus 8 Decoded Outputs
CD4024A - Seven-Stage Ripple-Carry Binary Counter
This Note shows logic and schematic diagrams for each of the counter and register types listed above, outlines circuit designs, and discusses device-design tradeoffs. Performance criteria are summarized, and applications by type are outlined by logic or subsystems diagrams and waveform photographs. Possible extensions of design into other areas of application are given.

The applications shown also utilize other RCA COS/MOS family types such as the CD4000A-CD4002A "NOR" gate types; CD4013A Dual-D Flip-Flop type; CD4007A Dual

Complementary Pair Plus Inverter; CD4009A and CD4010A Hex-Buffer/Logic-Level Converter types; and the CD4011A and CD4012A Quad-2 and Dual-4 "NAND" gate types.

## General COS/MOS Design

The COS/MOS counter and register types described consist of between 100 and 300 MOS devices, supporting interconnect tunnels and metal runs, and bond pads, all on a single monolithic pellet.

Table I summarizes the major operating characteristics of the counter and register types. A complete description of the advantages and operating characteristics of the RCA COS/ MOS line is given in Refs. 1, 2, 3 and 4. The applications shown in this Note for each type are not intended to be all-inclusive, but rather to highlight sample uses.

Fig. 1 illustrates the basic static master-slave flip-flop


Fig. 1 - Basic COS/MOS master-slave flip-flop stage.
circuit configuration utilized in all the designs described. The logic level present at the "D" (Data) input is transferred to the "Q" output during the positive-going transition of the clock pulse. DC "Reset" or "Set" is accomplished by a high level at the respective input.
loosely specified input waveshape requirement. As shown in Table I, the basic flip-flop configuration operates from a non-critical single-phase clock input signal. Both " 1 " and " 0 " clock-pulse durations can go to infinity, and rise and fall times of 5 microseconds or less are permissible.

## Table I - Typical Features and Characteristics of COS/MOS Counters and Registers - All Types.

## FEATURES:



Both "Reset" and/or "Set" functions are easily omitted, as shown for some of the designs. Output lead isolation at the " Q " and/or " Q " outputs is realized by use of inverters. These inverters eliminate all possibility of MOS gate oxide damage at the output leads, and also improve circuit speed, noise immunity, and drive capability. The sizes of the p-channel and n-channel MOS devices in the output inverters are tailored to meet the desired drive and sink current requirements. The internal clock shaping shown permits a

## CD4024A Seven-Stage Ripple-Carry Binary Counter

Fig. 2 shows the logic diagram of the CD4024A, a 7 -stage ripple-carry binary counter. Fig. 3 illustrates in more detail the schematic and logic diagrams for one of the seven counter stages. Operation is similar to that of the basic master-slave flip-flop, with the following exceptions: the " $D$ " line connection is derived from the Q output of that stage so that it complements the stage at the negative clock-pulse transition. The clocking of a stage is derived from


Fig. 2 - Logic diagram of CD4024A binary counter.
the previous counter stage (ripple-carry). The dc "Reset" function is realized by raising the ground return path of the $\overline{\mathrm{Q}}$ outputs of all seven stages (both master and slave sections). This mode of resetting saves four devices and associated interconnections per counter stage.

Fig. 4 illustrates the use of the CD4024A as a binary frequency-divider. Multiple CD4024A units can be stacked for added frequency division. The clock input of a subsequent CD4024A is derived directly from the last output stage of the previous CD4024A.


NOTE : SUBSTRATES FOR ALL "P" UNITS
ARE CONNECTED TO VDD SUB-
STRATES FOR ALL " $N$ " UNITS,
UNLESS OTHERWISE SHOWN, ARE
CONNECTED TO GROUND.
RESET RIFUT HAS SAME PRO-
TECTION CIRCUITRY AS THAT SHOWN FOR THE $\$$ INPUT.

Note: Reset line drive impedance must be such that the specified conditions are met. For example, with $\mathrm{V}_{\mathrm{DD}}=$ 10 V the reset line voltage must not exceed 1 volt. For a typical peak current of 2 mA this requires that the


R = HIGH DOMINATES (RESETS ALL STAGES).
*ACTION OCCURS ON NEGATIVE GOING TRANSITION OF INPUT PULSE. COUNTER ADVANCES ONE BINARY COUNT ON EACH NEGATIVE $\Phi$ TRANSITION
(I28 TOTAL BINARY COUNTS) ( 128 TOTAL BINARY COUNTS).

Fig. 3-Schematic and logic diagrams for one of the seven counter stages in the CD4024A.


Fig. 4-CD4024A "Binary frequency-divider" application.

Fig. 5 shows how the CD4024A is used to derive a desired pulse-output delay time. Varied delay times can be realized by detecting different CD4024A outputs. A finer control of delay time is possible if more than one CD4024A output is detected. Extremely long and accurate delay times can be realized by use of an accurate oscillator* and multiple CD4024A units.

Fig. 6 illustrates the use of the CD4024A to derive various divide-by-N counter configurations. Fig. $6 \mathrm{a} \& 6 \mathrm{~b}$ illustrate 2 reliable reset methods for counting to the number $\mathrm{N},(\mathrm{N}=60)$. Reset mode 1 is shown in Fig. 6a. The type D-Flip-Flop is set at the coincidence of count 59 and the positive clock transition. At the next negative clock transition, a reset pulse is generated, whose duration is
one-half the clock cycle time. This resets the CD4024A to zero. Note that only count 59 needs to be detected for the reset operation, and no $\mathrm{N}+1$ count occurs.

Reset mode 2 is şhown in Fig. 6b. The N+1 count (60) is detected, sets the R-S Flip-Flop, which in turn resets the CD4024A to the zero state. The reset pulse width is one-half the clock cycle time, and is removed by gating count zero with the positive clock transition to reset the R-S Flip-Flop.

Fig. 6c illustrates a divide-by-60, divide-by-60 and divide-by-24 timer system using the reset scheme (mode 1) of Fig. 6a. Similar use of one CD4024A unit permits any divide-by-N from 2 to 128 . In applications where decimal display outputs are required, the RCA type CD4017A can be used to advantage, as described later in this Note.


Fig. 5-CD4024A "Pulse-delay-control" application.


Fig. 6 - CD4024A used to derive various divide-by- $N$ counter

[^29] configurations.


Fig. 6b-Counter of 60 using reset mode 2.


Fig. 6c-CD4024A "Divide-by-N counter" configuration; diagram shows divide-by-60, divide-by-60 and divide-by-24 configurations.

Fig. 7a shows how the CD4024A is used with a weighted resistor network to realize analog to digital conversion (A to D). The CD4010A (Hex-Buffer, Non-Inverting) is used to reduce the more significant counter output " 1 " level impedances (which have poor tolerances) to well below the precision resistor network values.

Varied ranges of analog signals can be handled by control of the resistor network and comparator.

As the CD4024A counter advances, the voltage input to the comparator rises until it equals the analog input. The comparator then switches and inhibits further counter advancement, thus holding the digital representation of the analog signal in the counter. Because the CD4024A can
count to $2^{7}$, or 128 , division of an analog voltage range into 100 parts is easily realized. (The example shows a 1 -volt range broken into 10 -millivolt steps.)

Fig. 7b shows the CD4024A used with an R-2R ladder network for A to D conversion. The R-2R network, while requiring added resistors, utilizes only 2 resistor values, permits ready expansion to greater than 7 stages, and provides better resistor temperature tracking and allows elimination of the CD4010A's. The photographs, for the R-2R network, show a stepping input from zero to 12.8 volts, divided into 100 -millivolt steps. The CD4010A Buffers may be used to permit lower R-2R values, if desired.


Fig. 7a - Weighted resistor network.


Fig. 7b - Analog-to-digital conversion-resistor ladder network.

Fig. 7- CD4024A "Analog-to-digital conversion" application.

Fig. 8 shows the Logic Diagram of the CD4020A, a 14-Stage Binary Counter. Applications are similar to the CD4024A.


Fig. 8 - Logic diagram of CD4020A 14-stage binary counter.

## RCA CD4017A Decade Counter/Divider Plus 10 Decoded Decimal Outputs

Fig. 9 shows the logic diagram of the CD4017A a decade counter plus 10 decoded decimal outputs. A five-stage "Johnson Counter" configuration is used to implement the decade counter. The basic flip-flop stages are similar to that described in Fig. 1. "Clock", "Reset", "Inhibit", and "Carry Out" signals are provided. The decade counter advances one count at the positive clock-signal transition provided the inhibit signal is low. Counter advancement by way of the clock line is inhibited when the inhibit signal is high. A high


TERMINAL NO. $\mathrm{B}=$ GND

Fig. 9 - Logic diagram of CD4017A-decade counter.
reset signal clears the decade counter to its zero count. Use of the "Johnson" decade counter configuration permits high-speed operation, two-input decimal decode gating, and spike-free decoded output. Anti-lock gating is provided to permit only the proper counting sequence. The ten decimal outputs are normally low and go high only at their respective. decoded decimal time slot. Each decimal output remains high for one full clock cycle. The carry-out signal completes one cycle for every ten clock input cycles, and is used to clock the following decade directly in any multi- decare application.

Fig. 10 shows the use of the CD4017A in a "MultiDecade Counter/Decimal Display" application. Two typical lamp-driver interface circuits are shown. When one-sixth of a CD4009A is used as the lamp driver, current ranges up to 20 -milliamperes and 7.5 -milliamperes can be realized for COS/MOS supply voltages of 10 volts and 5.0 volts, respectively.


2 TYPICAL LAMP DRIVER CIRCUITS


Fig. 10-CD4017A "Multi-decade counter/decimal display" application.

Fig. 11. illustrates the use of the CD4017A in a "Multi-Decade Frequency Division" application; decimal display is optional. Fig. 12 shows the use of the CD4017A to obtain various divide-by-N counter configurations. Figs. 12a \& 12 b illustrate two reset methods in counting to the number 60. Fig. 12c shows an example of divide-by-60, divide-by- 60 and divide-by-24. The CD4017A permits easy decimal display of each divide-by-N section. The CD4017A can also be used in applications requiring multiplexing, demultiplexing and commutation of signals.

## RCA CD4022A Divide-by-8 Counter Plus 8 Decoded Outputs

Fig. 13 shows the logic diagram of the CD4022A, a divide-by- 8 counter and 8 decoded outputs. A four-stage "Johnson Counter" is used to implement the divide-by-8 counter. The basic flip-flop stages are similar to that described in Fig. 1. "Clock", "Clock-Enable", "Reset" and "Carry-Out" signals are provided on the divide-by- 8 counter.

The divide-by- 8 counter is advanced one count at the positive clock-signal transistion. A high reset signal returns the divide-by- 8 counter to its zero count. Use of the "Johnson" divide-by- 8 counter configuration permits highspeed operåtion, two-input decode gating, and spike-free decoded output. Anti-lock gating is provided to permit only the proper counting sequence. The eight decoded outputs are normally low and go high only at their respective decoded time slot. Each decoded output remains high for one full clock cycle. The carry-out signal completes one cycle for every eight clock input cycles, and is used to clock the following counter stage directly, in multi-stage applications.

Fig. 14 shows the CD4022A used in a "Divide-by-8 Counter/Decoder" application. One CD4022A unit provides the counting as well as the decoding function.


Fig. 12a - Counter of 60-using reset mode 1.


Fig. 11-CD4017A "Multi-decade frequency division" application.

PACKAGE COUNT:
1-CD4001A I-CD4O12A
1-CD4013A 2-CD4017A


Fig. 12b-Counter of 60-using reset mode 2.
Fig. 12-CD4017A "Divide-by-N counter" configurations.

## "divide by n counter with decimal display"

(EXAMPLE SHOWN $\div 60 ; \div 60 ; \div 24$ )



## PACKAGE COUNT

$6-C D 4017 A$
$2-C D 4011 A$
$2-C D 4001 A$
$2-C D 4013 A$
$2-C D 4009 A$

Fig. 12c - Divide-by-60, divide-by-60 and divide-by-24 configuration.


TERMINAL No. $16=V_{D O}$
TERMINAL No. $8=$ GND


Fig. 14-CD4022A "Divide-by-8 counter/decoder" application.

Fig. 15 shows a "Divide-by-64 Counter/Decoder" application. The partial decode function performed by the CD4022A significantly simplifies the external gating to complete the $1-\mathrm{in}-64$ decode function. Other binary counter/decoder applications can also be realized.


Fig. 15a - Block diagram.


Fig. 15b-Logic diagram.

Fig. 15c-Waveforms.

Fig. 15-CD4022A "Divide-by-64" counter/decoder" application.

## RCA CD4018A Presettable Divide-by-N Counter

Fig. 16 shows the logic diagram of the CD4018A, a presettable divide-by-N counter. The CD4018A consists of five flip-flops which can be configured as a $5-, 4-$, $3-$, or 2-stage Johnson counter with buffered $\bar{Q}$ outputs from each stage, and counter preset control gating. "Clock", "Reset", "Data", "Preset", and 5 "Jam" inputs are provided. $\overline{\mathrm{Q}}$ outputs are provided from each of the five counter stages. The basic flip-flop stages are similar to that shown in Fig. 1.

Divide-by-10, $8,6,4$, or 2 counter configurations can be implemented by feeding the $\overline{\mathrm{Q}}_{5}, \overline{\mathrm{Q}}_{4}, \overline{\mathrm{Q}}_{3}, \overline{\mathrm{Q}}_{2}$, or $\overline{\mathrm{Q}}_{1}$, signals, respectively, back to the data input. Divide-by- $9,7,5$, or 3 counter configurations can be implemented by use of the CD4011A gate package to gate the proper feedback connection to the data input. Divide-by-functions greater than 10 can be achieved by use of multiple CD4018A packages. The counter configuration is advanced one count at the positive clock-signal transition. A high reset signal clears the counter to an all-zero condition. A high preset
signal allows information on the Jam inputs to preset the counter configuration. Anti-lock gating is provided to assure the proper counting sequence.

Fig. 17 shows the CD4018A utilized in constructing fixed counters of divide-by-9, 7,5 or 3 . Operation in a divide-by- 7 configuration is shown in detail in Fig. 18.


Fig. 16 - Logic diagram of the CD4018A-presettable divide-by-N counter.


Fig. 17 -External connections for divide-by-10, 9, 8, 7, 6, 5, 4, 3 operation.


Fig. 18-CD4018A "Fixed divide-by-7" configuration.


Fig. 19-Three-decade, programmable, divide-by-N counter with frequency division from 2 to 999: (a) logic diagram; (b) counting sequence; (c) timing waveforms at various points in the circuit; (d) divide-by-N output for various values of $N$;


Fig. 19 illustrates the use of the CD4018A in a programmable divide-by- N counter, where N is any number from 2 to 999 for the example shown. Extension to higher $\mathbf{N}$ ranges is realized by use of additional CD4018A units. The Johnson-counter configuration of the CD4018A permits simpler switch arrangements at the Jam inputs controlling the programmable preset state. The programmable divide-by-N configuration can be utilized in frequency-synthesis applications.

The CD4018A can also be utilized as a five stage parallel input/output holding register. "Holding Register" parallel entry can be controlled by means of the "Preset Enable Line", resulting in a five stage latch operation.

## CD4006A 18-Stage Static Shift Register

Fig. 20 shows the logic diagram of the CD4006A, an 18 -stage static shift register. The register stages are similar to those shown in Fig. 1. The CD4006A consists of four separate shift-register sections, two four-stage sections and two five-stage sections with output taps at the fourth stage. Each register section has independent "Data" inputs to the first stage. The clock input is common to all 18 register stages. Through appropriate connection of inputs and outputs, multiple register sections of $4,5,8$, and 9 stages or single register sections of $10,12,13,14,16,17$, and 18 stages can be implemented using one CD4006A. Longer shift-register sections can be assembled by use of more than one CD4006A.


Fig. 20-Logic diagram of the CD4006A - 18-stage static shift register.

Fig. 21 shows in more detail the schematic and logic diagrams for one of the 18 register stages. Register shifting occurs on the negative clock-pulse transition.


NOTE: ALL " $P$ "-UNIT SUBSTRATES ARE CONNECTED TO VDD
ALL " $N$ " - UNIT SUBSTRATES ARE CONNECTED TO VSS



 $\cdots$ - Lemil There

Fig. 21-Schematic and logic diagrams for one of the 18 register sections of the CD4006A.

## RCA CD4015A Dual 4-Stage Serial-Input/Parallel-Output

 Static Shift RegisterFig. 22 shows the logic diagram of the CD4015A. The CD4015A consists of two identical, independent, four-stage serial-input/parallel-output registers. Each register has independent "Clock" and "Reset" inputs, as well as a serial "Data" input. "Q" outputs are available from each of the four stages on both registers. All register stages are similar to that shown in Fig. 1. The logic level present at the data input is transferred into the first register stage and shifted over one stage at each positive clock transition. Reset of a four-stage section is accomplished by a high level on the reset line. Register expansion to 8 stages with one CD4015A or to more than 8 stages with multiple CD4015A packages, is possible.

Fig. 23 shows the use of the CD4015A in an 8 -stage serial-input/parallel-output register application. This circuit operates as follows: The CD4015A connected as an 8-stage register is reset and " 1 "s are shifted through the register. The scope trace shows the " 1 " pattern loading into the register until a " 1 " reaches the eighth stage and initiates reset. After two clock pulses, the reset is removed and " 1 "s again shift into the register. Low-speed-to-high-speed data queueing and serial/parallel data conversion are typical applications.


Fig. 22-Logic diagram of the CD4015A - dual 4-stage serial-input/parallel-output register.

## RCA CD4014A 8-Stage Synchronous

## Parallel-Input/Serial-Output Static Shift Register

Fig. 24 shows the logic diagram of the CD4014A, an 8 -stage synchronous parallel-input/serial-output register. A "Clock" input and a single serial "Data" input along with individual parallel "Jam" inputs to each register stage and a common "Parallel/Serial" control signal are provided. "Q" outputs from the 6th, 7th, and 8th stages are available. All register stages are similar to that shown in Fig. 1, except that extra transmission gates permit parallel or serial entry. Parallel or serial entry is made into the register synchronous with the positive clock transition and under control of the parallel/serial input. When the parallel/serial input is low, data is serially shifted into the 8 -stage register synchronous with the positive clock transition. When the parallel/serial input is high, data is jammed into the 8 -stage register by way of the parallel input lines and synchronous with the positive clock transition. Register expansion with multiple CD4014A packages is possible.


Fig. 23-CD4015A 8-stage serial-input/parallel-output register application.


Fig. 24 - Logic diagram of the CD4014A 8-stage synchronous parallel-input/serial-output register.

Fig. 25 shows the use of the CD4014A in an 8-stage synchronous parallel-input/serial-output register application. In this configuration, the CD4013A allows a parallel transfer to be made into the CD4014A register once every 8 clock pulses. Use of the divide-by-2 outputs of the CD4013A as parallel inputs to alternate CD4014A stages permits changeover from a 10101010 to a 01010101 parallel input pattern every 8 pulses. The scope trace shows the parallel transfer of the 01010101 pattern into the register followed by eight shift pulses and subsequently another parallel transfer of 10101010 and eight shift pulses. High-speed-to-low-speed data queueing and parallel/serial data conversion are typical applications.


Fig. 25-CD4014A 8-stage synchronous parallel-input/serialoutput register application.

The CD4014A can be utilized in pseudo-randon-code generation applications via combined control of the parallel input conditions and gating of the 6th, 7th, and 8th stage register feedback to the serial input. Fig. 26 shows the photomicrograph of the CD4014A pellet.


Fig. 26 - Photomicrograph of the CD4014A pellet.

## RCA CD4021A 8-Stage Asynchronous Parallel-Input/Serial-Output Static Shift Register

Fig. 27 shows the logic diagram of the CD4021A 8-stage asynchronous parallel-input/serial-output register. Operation is basically the same as that of the CD4014A except that parallel transfers are made as soon as the parallel/serial control input goes high. Parallel transfers are thus made asynchronous with the clock input. Serial shifting is still performed synchronously with the clock input. The CD4014A thus permits the parallel transfer to be synchronized with a different clocking signal than that of the serial transfer. Thus, in high-speed-to-low-speed data queueing, for example, an externally gated high-speed clock may control the parallel transfer while the low-speed clock may control the serial shifting.


Fig. 27-Logic diagram of the CD4021A 8-stage asynchronous parallel-input/serial-output register.

Fig. 28 shows the use of the CD4021A in an 8 -stage asynchronous high-speed parallel-input/low-speed serialoutput application. For the example shown, the high-speed portion of the system is simulated by simplified control logic. A 10 kHz slow-speed clock and 1 MHz high-speed clock are assumed. Signal lines " $a$ " and " $b$ ", as well as the eight data lines, are representative of the information transfer requirements, between the high-and-low-speed systems. At the slow-speed output sections, the CD4021A shifts out stored information at a 10 kHz clock rate. The CD4022A
counts to eight at the 10 kHz rate and at count zero, sends a high "Flag" signal to the high-speed system over line "a", indicating that the low-speed section is ready to accept eight bits on the data lines.

In the simulated high-speed section, a high on line " $a$ ", allows Flip-Flop " $A$ " to set on the positive transition of the 1 MHz clock. The Q output of Flip-Flop " $A$ " is gated with the 1 MHz clock to form a gated 1 MHz clock signal on line " $b$ ". This clock signal along with count zero at the slow speed section puts a single 1 MHz gated clock pulse at the Parallel/Serial Control of the CD4021A to permit an eight bit parallel transfer of data from the high-speed system to the low-speed system.

R-S Flip-Flops 1 \& 2 remove the "Flag" signal " $a$ " after a 1 MHz gated clock pulse on line " $b$ " has generated the parallel transfer signal. These flip-flops also prevent any further activation of line "a" (and line " $b$ ") and subsequent parallel transfers until the CD4022A counts back to zero. Thus, the eight bits transferred into the CD4021A are shifted out at the 10 kHz clock rate before a new set of data is transferred into the CD4021A. Note that the extra pulse edge generated at line " $b$ " (one clock pulse after the gated 1 MHz clock pulse) is ignored. (See the Logic of the slow-speed section.) For Scope Display purposes, Flip-Flop B , in the high-speed system is used to change the pattern transferred every eight 10 kHz clock pulses from a 10101010 to a 01010101 pattern.

In an actual system the high signal at line "a" would represent a "Flag" bit, enabling the high-speed system to transfer eight bits of new data, any time during the count zero. ( 10 kHz clock cycle duration.) This allows the high-speed system time to service its many other input and output lines and to satisfy internal process requirements at the 1 MHz rate. At the same time, the high-speed system is still conditioning the eight transfer lines (just prior to activation of line " $b$ ") with a pulse to enable the parallel transfer of data. The re-sync Flip-Flop in the slow-speed section helps avoid any gap in the output data due to the variable delay possible in line servicing between the eighth shifted bit out of the CD4021A and the next parallel transfer of the eight valid bits of information.

## Conclusions

This note has shown the use of several COS/MOS MSI counters and static shift registers in systems designs. The designs described are useful in a variety of applications.

The availability of an increasing number of standard low-cost COS/MOS devices now permits the systems designer greater freedom and versatility as well as increased reliability in his designs.


Fig. 28 - CD4021A "8 bit asynchronous high-speed parallel-input/low-speed serial-output" application; (a) logic diagram, (b) block diagram; (c) slow-speed system waveforms; (d) slow-speed system waveforms; (e) high-speed system (expanded scale) waveforms.

## References:

1. RCA COS/MOS Commercial Data Sheets, CD4000A series and Developmental Data Sheets by "TA" Number
2. "Power Supply Considerations For RCA COS/MOS IC's" by H. Pujol, ICAN-6576
3. "Design of Fixed and Programmable Counters Using the RCA CD4018A COS/MOS Presettable Divide-by-N Counter", by J. Litus, Jr., ICAN-6498
4. "Complementary MOS Transistor Logic Integrated Circuits", ICAN-5593
5. 'Micropower Crystal-Controlled Oscillator Design using RCA-COS/MOS Inverters", by S.S. Eaton, ICAN-6539
6. "Astable and Monostable Oscillators Using RCA COS/ MOS Digital IC's", by J.A. Dean and J.P. Rupley, ICAN-6267

Digital Integrated Circuits<br>Application Note

ICAN-6176

# Noise Immunity of COS/MOS Integrated-Circuit Logic Gates 

by S.S. Eaton

The immunity of a COS/MOS integrated-circuit logic gate to noise signals is a function of many variables, such as individual chip differences, fan-in and fan-out, stray inductance and capacitance, supply voltage, location of the noise, shape of the noise signal, and temperature. Moreover, the immunity of a system of gates usually differs from that of any individual gate. Because of the many variables involved, a generalized analysis of the noise immunity of a logic circuit is a complex process. In general, it is more practical to analyze immunity of a system for a specific set of conditions and then to generalize or extrapolate the results to make them applicable to other sets of conditions.

This Note describes the types of noise usually encountered in a logic system and evaluates the noise immunity of a COS/MOS integrated-circuit logic-gate test setup in relation to system variables. The evaluation is performed on a setup that includes a CD4000A dual 3-input gate plus inverter and a CD4001A quad 2-input gate connected in cascade to drive a CD4013A flip-flop. Measurement of the voltage required at various gate leads to switch the flip-flop defines the noise-immunity threshold of the gate circuits.

## TYPES OF NOISE

The following listing indicates and briefly explains the types of noise usually encountered in logic systems:

1. External noise - noise that is generated externally by electric motors, arcing relay contacts, circuit breakers, and other similar types of devices. Such noise is usually inductively coupled into the logic system.
2. Crosstalk - noise that results from coupling (usually capacitive) between adjacent signal lines.
3. Transmission-line reflections - noise introduced into the logic system when an impedance mismatch exists at the receiving end of the line. The energy reflected back along the line causes ringing, and voltage levels produced may exceed the noiseimmunity threshold of the receiving gate. This type of noise is most prevalent when the switching time of the gate is short in comparison to the time delay of the line.
4. Power-line noise - noise that results from transient currents produced in the supply line by coupling from external sources or by stray or junction capacitances at the gate outputs.
5. Ground-line noise - noise that is produced on the ground line because of improper ground returns.

This Note evaluates the noise immunity of the CD4000A and CD4001A COS/MOS integrated-circuit logic gates with respect to each type of noise listed above with the exception of that produced by transmission-line reflections. Because this type of noise is specifically a function of the transmission line, a generalized analysis is not as effective as in the case of the other types of noise. However, transmission-line reflections are not significant in COS/MOS circuit systems because the switching speed of a COS/MOS circuit is generally slow in comparison to the time delay of a line. The schematic and logic diagrams of the CD4000A and CD4001A gates are shown in Figs. 1 and 2, respectively.


Fig. 1 - Schematic and logic diagrams of the CD4000A dual 3-input gate plus inverter.

(b)
(a)


Fig. 2 - Schematic and logic diagrams of the CD4001A quad 2-input gate.

## SIGNAL-LINE EXTERNAL NOISE IMMUNITY

The following analysis was used to determine the immunity of a COS/MOS gate to noise on the input line at both the " O " (low-level) and " 1 " (high-level) states.

## " 0 "-State Analysis

The signal-line noise immunity of COS/MOS gates was evaluated by use of the test circuit shown in Fig. 3(a). The COS/MOS gate under test was the inverter section of a CD4000A. Fig. 3(b) shows the results obtained. The test setup
is designed to measure the voltage required at the input of the inverter to trigger a CD4013A flip-flop. The logic diagram of the CD4013A is shown in Fig. 4.

During test, a noise pulse is introduced on the signal line of the CD4000A inverter. At some voltage level, depending on the width of the pulse and the gate thresholds, this pulse causes the flip-flop to be "set" because of the rising voltage on the set input that results from the decreasing voltage at the output of the inverter. This level defines the permissible input range for a logical " 0 ." The measured value for a supply voltage of 10 volts was 4.4 volts. For a supply voltage


Fig. 3-(a) Test circuit and (b) measured results for " $O$ "-state signal-line noise-immunity test.
of 14 volts, the measured value of the voltage required to trigger the flip-flop was approximately 6.2 volts.
A dc analysis of the transfer characteristics of the components included in the test setup, shown in Fig. 5, can also be used to determine the noise level required to set the flip-flop. Fig. 5(a) shows that an input of 5.5 volts is required
to trigger the CD4013A flip-flop at a supply voltage $\mathrm{V}_{\mathrm{DD}}$ of 10 volts. Fig. 5(b) shows that a signal of 5.45 volts is required at the input to the CD4001A gate to produce an output of 5.5 volts.

Similarly, Fig. 5(c) shows that the CD4000A inverter requires an input of 4.45 volts to provide 5.45 volts to the input of the CD4001A gate. An input of 4.45 volts to the CD4000A inverter, therefore, should trigger the CD4013A flip-flop. The actual measured value of the voltage required to trigger the flip-flop, as shown in the curve for $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ in Fig. 3(b), is 4.4 volts. (All measured values shown on all graphs are typical, obtained from measurements on gates that have typical threshold switching characteristics.)

## "1"-State Analysis

Fig. 6 shows the test setup used and the results obtained from noise-immunity measurements on the COS/MOS logic gates when the input to the CD4000A inverter gate is high and a negative-going pulse is superimposed on the signal line. As in the case of the " 0 "-state evaluation, a dc analysis of the component transfer characteristics may be made to verify the measured noise immunity. Fig. 5(c) shows that the input to the CD4000A must decrease from 10 volts to 4.5 volts (a margin of 5.5 volts) to provide the 5.5 -volt output required to trigger the flip-flop. The measured value of the required decrease in voltage, as shown in Fig. 6(b), is 5.3 volts.

## POWER-SUPPLY NOISE IMMUNITY

The test configuration shown in Fig. 7(a) measures the ability of the CD4000A inverter to withstand a negative-going noise pulse on the supply line without a change in state. A pulse of sufficient amplitude causes the output of the gate to decrease so that, at some point, the CD4013A flip-flop will be


TERMINAL $14=V_{D D}$
TERMINAL $7=$ GND


TRUTH TABLE


A = LEVEL CHANGE

* = DON'T CARE CASE

Fig. 4-Logic diagram and truth table for the CD4013A COS/MOS integrated circuit flip-flop.

(a)

(b)


Fig. 5 - Transfer characteristics for (a) the CD4013A flip-flop, (b) the CD4001A quad 2-input NOR gates, and (c) the CD4000A inverter gate.


Fig. 6 - (a) Test circuit and (b) measured results for the " 1 "-state signal-line noise immunity test.
triggered from the rising voltage at the output of the driving inverter stage. The curves in Fig. 7(b) show the noise immunity level for noise pulses on the power supply to be 4.2 volts at 10 volts and 5.7 volts at 14 volts.

(b)

Fig. 7-(a) Test circuit and (b) measured results for the power-line noise-immunity test.

## GROUND-LINE NOISE IMMUNITY

Noise on the power line may be effectively reduced or eliminated by use of decoupling capacitors; ground-line noise, however, cannot be reduced so easily and, therefore, is more objectionable. Fig. 8(a) shows the test circuit used to measure the ground-line noise immunity of the COS/MOS gate, and Fig. 8(b) shows curves of the measured results


Fig. 8 - (a) Test circuit and (b) measured results for the ground immunity test.
obtained. The noise pulse introduced on the ground line of the CD4000A inverter raises the potential of the output of the gate until the flip-flop is triggered. The close similarity of the COS/MOS flip-flop switching curves shown in Fig. 9(b) and the noise-immunity curves shown in Fig. 8(b) confirms a volt-for-volt change at the gate output with a change in ground potential for the COS/MOS circuit.

## CROSSTALK NOISE IMMUNITY

A test circuit that may be used to evaluate crosstalk is shown in Fig. 10. A noise pulse from a pulse generator is coupled to the signal line of the CD4000A gate through a capacitor. The noise voltage necessary to trigger the flip-flop is then measured for different values of capacitance under "high" and "low" input conditions. Fig. 11 shows the results of these tests. As expected, the noise amplitudes required to trigger the flip-flop are higher for lower capacitance values. A more meaningful evaluation of the circuit is provided by the curves in Fig. 12, which show the noise amplitude as a percentage of the supply voltage. Because crosstalk is caused


(b)

Fig. 9 - Switching curves for the CD4013A COS/MOS flip-flop.


Fig. 10 - Circuit used for test of noise voltage as a function coupling capacitance.


Fig. 11 - Noise immunity as a function of coupling capacitance.


Fig. 12-Noise immunity in terms of percentage of supply voltage.
by varying signals coupled from adjacent lines and the logic swing of these signals is limited and approaches the supply voltage, the percentage of the supply voltage coupled at the time when the flip-flop is set is a more meaningful value than the actual value of the voltage at this instant. For example, if the amplitude of crosstalk noise required to trigger the CD4013A flip-flop at a supply voltage of 10 volts is less than that required at a supply voltage of 14 volts, this condition does not imply that a COS/MOS logic circuit operated at 14 volts is more immune to crosstalk than a similar circuit operated at 10 volts because of the different logic swings involved.

The results shown in Figs. 11 and 12 also provide a meaningful comparison between low- and high-state operation of the COS/MOS gates. In general, a greater noise immunity is achieved in the low state.

Although the test circuit shown in Fig. 10 yields reliable data, the measured values are not entirely representative of actual operating conditions. The circuit shown in Fig. 13


Fig. 13 - Test circuit used to determine crosstalk noise susceptibility.
more closely approximates crosstalk caused by adjacent signal lines. In this circuit, CD4001A gates are used as the driving inverters for the CD4013A flip-flop. The output of inverter No. 1 can be made either high or low for crosstalk tests in both logic states. The response of this test circuit to a noise pulse may be explained by analysis of the response of a high-pass RC circuit to a ramp input of $\mathrm{V}_{\mathrm{i}}=a t$. The output voltage $\mathrm{V}_{\mathrm{O}}$ may be expressed by the following equation:

$$
\begin{equation*}
v_{0}=a R C\left(1-e^{-t / R C}\right) \tag{1}
\end{equation*}
$$

The equivalent circuit for the part of the test configuration used in this analysis is shown in Fig. 14. On the basis of this equivalent circuit, Eq. (1) may be rewritten as follows:

$$
\begin{equation*}
v_{o_{\max }} \cong \alpha\left(z_{0} / / z_{i n}\right) c\left[1 \cdot e^{\left.-t /\left(z_{0} / / z_{i n}\right) c\right]}\right. \tag{2}
\end{equation*}
$$

If $\mathrm{V}_{\mathrm{i}}$ is assumed to be $a t$ (where t is the rise time) during the period in which the output voltage switches from 10 to 90 per cent of its total value, this change in output voltage can be expressed as follows:

$$
\begin{equation*}
\Delta v_{0_{\max }} \approx \frac{v_{i}\left(z_{0} / / z_{i n}\right) c}{t}\left[1-e^{\left.-t /\left(z_{0} / / z_{i n}\right) c\right]}\right. \tag{3}
\end{equation*}
$$



Fig. 14 - Equivalent circuit for noise analysis of the test configuration shown in Fig. 13.

The results of this analysis may be applied to the various crosstalk waveforms obtained. Fig. 15 shows photographs of $\mathrm{V}_{\mathrm{O}}$ with the output of inverter No. 1 in the high state. Fig. 15(a) shows the crosstalk pulses obtained for the CD4001A COS/MOS gate for a capacitance $\mathbf{C}$ of 100 picofarads. Noise pulses are obtained only at certain time intervals which correspond to the rising and falling edges of the voltage $\mathrm{V}_{\mathrm{i}}$. Only the falling pulses are considered in the following analysis because they are responsible for triggering the flip-flop.

Eq. (3) may be used to calculate the amplitude of the pulses. The noise pulse introduced to the test circuit switches from 90 to 10 per cent of its final value in 17 nanoseconds (fall time). Because of the 100 -picofarad capacitance C at the output of inverter No. 3, the fall time at this point should be somewhat greater than 17 nanoseconds. The actual measured value is 130 nanoseconds. In Eq. (3), therefore, $\mathrm{t}=130$ nanoseconds, $\Delta \mathrm{V}_{\mathrm{i}}=(0.090)(10)-(0.10)(10)=8$ volts, $\mathrm{Z}_{\mathrm{in}} \approx 10^{12_{\mathrm{ohms}},} \mathrm{Z}_{\mathrm{O}} \approx 550$ ohms (for the COS/MOS
integrated-circuit gate used), and $\mathrm{C}=100$ picofarads. The output voltage swing $\Delta \mathrm{V}_{\mathrm{o}_{\text {max }}}$ is then calculated as follows:

$$
\begin{aligned}
& \Delta V_{o_{\max }} \approx \frac{(8 \mathrm{~V})(550 \Omega)\left(10^{-10} \mathrm{~F}\right)}{130 \times 10^{-9} \mathrm{~s}} \\
& {[1-\mathrm{e}} \\
&\left.130 \times 10^{-9} \mathrm{~s} /(550 \Omega)\left(10^{-10} \mathrm{~F}\right)\right]
\end{aligned}
$$

$$
=3.1 \mathrm{~V}
$$

Fig. 15(a) shows that the measured value of the fall voltage (about 2.9 volts) is in close agreement with the calculated value. Fig. 15(b) shows the crosstalk pulse for the same COS/MOS circuit with a noise pulse rate of 500 kHz rather than 54 kHz . As Eq. (3) implies, the pulse rate does not seem to change the noise amplitudes.

(a)

(b)

Fig. 15-"1"-state crosstalk waveforms: (a) frequency $=54$ kHz , pulse width $=5 \mu \mathrm{~s} / \mathrm{cm}$, and pulse amplitude $=5 \mathrm{~V} / \mathrm{cm}$; (b) frequency $=500 \mathrm{kHz}$, pulse width $=1 \mu \mathrm{~s} / \mathrm{cm}$ and pulse amplitude $=5 \mathrm{~V} / \mathrm{cm}$.

In the low state, the output impedances of the COS/MOS logic circuit are low enough ( 550 ohms ) and the rise times sufficiently slow that the flip-flop could not be triggered at any value of capacitance used (up to 10 microfarads).

Crosstalk measurements that simulate actual operation are made by use of the test circuit shown in Fig. 16. In this


Fig. 16-Crosstalk test circuit which uses tightly coupled cable to simulate actual operating conditions.
circuit, a sense line is placed tightly within five surrounding wires (No. 22 gauge) to form a 7 -foot-long cable which has a capacitance of 30 picofarads per foot (determined by measurement). The cable is used to simulate a worst-case cable with 5 gates switching on lines adjacent to one wire. The results of this test are shown by the photographs in Figs. 17 and 18. Fig. 17 shows the effect of the capacitive loading


Fig. 17 - Crosstalk waveform showing effect of load capacitance (output of CD4001A inverter No. 3; frequency $=$ 500 kHz , pulse width $=1 \mu \mathrm{~s} / \mathrm{cm}$, and pulse amplitude $=2$ $\mathrm{V} / \mathrm{cm}$ ).
$\qquad$

on the fall time of the inverted output waveform. Fig. 18 shows the " 0 "-and " 1 "-state crosstalk coupled to the sense line. In both cases, the forward crosstalk, or noise, at the receiver end of the cable (the input to inverter No. 2 in Fig. 16) matched back crosstalk, or noise at the driver end of the cable (the output of inverter No. 1). The crosstalk does not trigger the flip-flop in either the " $O$ " or " 1 " state. Even with a tightly coupled 7 -foot cable, the COS/MOS gate does not change state falsely.

## CONCLUSIONS

The results of all tests show exceptionally high noise immunity for COS/MOS integrated-circuit gates. Typical noise-immunity values range from 4.5 to 5.5 volts for a supply voltage VDD of 10 volts, and 5.5 to 8.5 volts for a

VDD of 14 volts. These high values are achieved with gate power consumptions in the microwatt range, as compared with much higher (milliwatt) consumptions and much lower noise immunities (about 1 volt) for saturated bipolar logic. Factors contributing to the high noise immunity of COS/MOS gates are the relatively slow speeds and relatively low ( 500 ohms) output impedances.

Because it is impossible to study all cases of noise immunity, the cases chosen are meant only to be representative. Noise pulses are certainly not all rectangular in shape, and the same type of integrated circuit may have widely differing characteristics. It is hoped, however, that enough information is presented to permit gencralization to other cases not specifically studied.

# A Typical Data-Gathering \& Processing System Using CD4000A-Series COS/MOS Parts 

by D. Block

## INTRODUCTION

The broad line of COS/MOS standard parts in the CD4000A series, ${ }^{1}$ including many MSI functions not available in other logic families, provides the design engineer with the tools to implement a large number of digital functions. The well-known characteristics of COS/MOS circuits, ${ }^{2}$ such as low power dissipation, wide supply-voltage range, high noise immunity, and excellent temperature stability, can make possible cost-effective systems for a variety of applications, and have opened up new areas where electronic controls were not previously suitable for a variety of reasons.

This Note considers the area of data gathering and processing, and is developed in terms of a typical system for process controls. Emphasis is placed on applications of the newer parts in the CD4000A line. Also stressed are the flexibility of system design and common data-bus architecture made possible by the three-state outputs and bidirectional input/outputs incorporated in many COS/MOS circuits and the ease of system design for data handling in increments of 4 bits made possible by the careful planning of the CD4000A family.

The implementation of the system described is shown in terms of the COS/MOS standard parts which can be used to perform the desired system functions. Specific details, such as pin numbers, are not provided; rather attention is focused on the multiplicity of applications which can be handled by a single product and the scope of information processing which can be covered by standard parts.

The fine points of circuit design, which would have to be dealt with in any real-world design, are not treated here. The approach adopted is one of "filling in the blocks" to show which COS/MOS standard parts can be used to implement a particular function, and how these blocks tie together to create a system.

## SYSTEM DESCRIPTION

The over-all system described is one which accepts asynchronous inputs of analog or digital data and operates on that data; the output is display and control information. Fig. 1 shows a block diagram of the entire system. It is assumed that the input signals from remote sensors are digitally encoded and transmitted to the central Processor Unit for data manipu-


Fig. 1 - Block diagram of the Data-Gathering and Processing System.
lation. It is also assumed that the controlled functions are at a distance from the Processor and that data is transmitted from the Processor to the Controller by frequency-modulation techniques. At the Controller, data is reconstructed to an NRZ data-word format which can then be used for direct digital control or converted to an analog voltage for proportional control of servos, etc.

The display output at the Processor is a 4 -digit, liquidcrystal display located in reasonable proximity to the rest of the logic. Thus, the areas to be considered for COS/MOS implementation include A/D and D/A conversion, data transmission and reception, and data processing. Serial-to-parallel and parallel-to-serial conversion are included since a common data bus architecture is assumed in the Processor Unit.

Two power supplies, +10 volts and -5 volts, are used in the system. All COS/MOS parts require only a single power supply and single-phase clock, and logic levels in the system will be from $\mathrm{V}_{\mathrm{SS}}=0$ volts to $\mathrm{V}_{\mathrm{DD}}=10$ volts. However, the negative supply can be used to advantage, as examples in this Note will show, to permit transmission of signal levels above and below ground, and to develop 15 volts across the liquidcrystal display for good readability.

## INPUT SIGNAL CONDITIONING AND TRANSMISSION

Fig. 2 shows the conversion of analog input voltages to a serial-data stream. The CD4051A's are used as multiplexers to connect, one at a time, each of the 16 analog input voltages to the $A / D$ converter. When the conversion is completed, a signal from the converter gates an oscillator ON which causes the 8 -bit result of the A/D conversion to be multiplexed into a serial-data stream. This data, along with a clock, is transmitted to the Processor Unit. A CD4047A used in the negative-trigger, astable mode provides a reset pulse to the $A / D$ converter on the negative transition of Q3. The pulse indicates that the 8-bit data stream has been transmitted and that the input multi-
plexer has been stepped to the next address. By taking advantage of the capability of the CD4051A's to operate from two power supplies, analog voltages above and below ground can be switched by control-signal inputs of 0 to 10 volts. Note that the CD4051A is suitable for both analog and digital multiplexing applications and that, because of the Inhibit input, which entirely disconnects the common outputs, two or more units can be wire-OR'ed.

The A/D converter can also be assembled with COS/MOS standard parts, as shown in Fig. 3(a). The CD4040A binary counter, used in conjunction with an $\mathrm{R} / 2 \mathrm{R}$ resistor ladder network, generates a staircase ramp at the negative input to the comparator as shown in Fig. 3(b). When the ladder voltage matches the analog input, the comparator output goes low. This signal is inverted by the CD4007A and becomes a logic 1 latched into the flip-flop. This action inhibits additional clocks to the counter and indicates that the conversion is complete. The output of the counter, which is buffered by high-current CD4041A's to minimize switch impedance effects on the resistor ladder, is the digital equivalent of the analog input voltage. A reset clears the flip-flop and resets the counter so that the next conversion can begin.

To generate a staircase from -5 volts to 10 volts, one end of the resistor ladder is connected to -5 volts, and the counter is connected with a $\mathrm{V}_{\mathrm{DD}}$ of 10 volts and a $\mathrm{V}_{\mathrm{SS}}$ of -5 volts. Since the clock and reset signals to the counter must then swing from -5 volts to 10 volts, a CD4054A is used as a level translator.

A micropower op-amp, the CA3080A, is used as a voltage comparator for the D/A converter. The op-amp is gated off after the conversion is completed by turning off a p-device of the CD4007A supplying bias current to the unit. In this way, power dissipation is reduced to a few microwatts in the standby state during those times in which a conversion is not actually being performed. With the active bias current ( $\mathrm{I}_{\mathrm{abc}}$ ) set at 15 microamperes, typical power dissipation for the CA3080 is


Fig. 2 - The conversion of analog input voltages to a serial-data stream.
about 500 microwatts with a $\mathrm{V}+$ of 10 volts and a $\overline{\mathrm{V}}-$ of -5 volts. Dissipation during a conversion would be approximately 20 milliwatts at a clock rate of 100 kHz for the circuit shown in Fig. 3. Standby dissipation, however, would typically be less than 50 microwatts. Care must be taken not to exceed the common-mode input voltage of the op-amp.

## DIGITAL PROCESSOR UNIT

A block diagram of the Processor Unit is shown in Fig. 4. Four internal bus systems are used. The Control Bus carries discrete control and timing signals from the Control Unit to the various sub-units; the other three bus systems are 8 -bit, parallel transfer buses. The Memory Bus (M) carries memory


Fig. 3 - (a) The A/D converter assembled with COS/MOS standard parts, (b) staircase ramp generated by the CD4040A binary counter.


Fig. 4 - Block diagram of the Processor Unit.
address information from the Control Unit to the Memory and Output Buffer, while the Data Bus (D) is used for common data transfers between all subsystems. The third parallel bus is internal to the Arithmetic Unit and is used for high-speed transfer of data between registers in that unit. It is assumed that, because of bandwidth limitations, data input and output rates are asynchronous with respect to the system internal clocking and, therefore, that the I/0's are interfaced with the D bus under command of the Control Unit.

## RECEIVER

Fig. 5 shows the Receiver portion of the Processor. A CD4034A is used in the serial-in/parallel-out mode for data serial-to-parallel conversion, and also functions as a holding register for input data until the Control Unit calls for it to be strobed onto the D bus. A CD4017A associated with each register counts input clocks and, when output number " 8 " goes high, indicates that its associated register is full. A scanner, consisting of a CD4052A dual-4-channel multiplexer,


Fig. 5 - Receiver portion of the Processor.
sequentially examines each counter and reports to the Control Unit when any register is ready to be read out. A pulse from the Control Unitback through the CD4052A resets the counter and strobes the appropriate register onto the D bus.

## MEMORY

The Memory portion of the Processor is shown in Fig. 6(a). Eight CD4061A's are paralleled to form the 8 -bit
structure required for the $D$ bus. A chip enable feature allows the Data Input and Data Output terminals of these units to be tied together since both are disconnected when the Chip Enable input is high. (The Chip Enable input must be high prior to any change of address.) The Read/Write control determines whether parallel data will be written from or read onto the Data Bus when the memory is enabled. With reasonable capacitive loading, read access times of about 400 nano-

seconds are achievable. The CD4042A's, which are quadclocked latches, are used as a memory address register.

An expanded memory organization to 4096 words is shown in Fig. 6(b). Here the eight-package organization of Fig. 6(a) is taken as a basic building block and repeated 16 times. Four more address bits on the M Bus can be decoded into 16 discrete block-enabling signals by using a CD4028A. The decoded outputs must be inverted to provide the "low" enabling signal required by the CD4061A memories. The entire memory can be disabled, i.e., effectively disconnected from the D Bus, by maintaining the Memory Disable signal low.

The memory could be used in this system to store programming instructions for the Control Unit, parameter limits against which new inputs are to be compared, instruction words which are to be sent to the remote controller, etc.

## ARITHMETIC UNIT

An extremely flexible Arithmetic Unit can be configured by using two CD4057A 4-bit arithmetic arrays and three CD4034A shift registers, as shown in Fig. 7. The CD4057A's have a 16 -instruction repertoire, as shown in Table I. The addition of four operational modes which control transfer of information, either serial data or arithmetic carries, and the I/0 control, makes the CD4057A a powerful tool for arithmetic operations. The results of these operations are fed back to the Control Unit of the D bus and overflow indicator, and are used to determine the next sequence of operations.

The bidirectional data input/output capability of the CD4057A's and CD4034A's enables units to be arrayed on their own Arithmetic Bus A and to communicate directly with all other subsystems.

Register A contains two CD4057A's for arithmetic operations and a CD4034A to allow left shifting of results as

## Table I - The 16-Instruction Repertoire of the CD4057A

NO-OP (Operational Inhibit)
AND
Count down
Count up
Subtract from zero (SMZ) (Stored number)
Subtract from memory (SM) (Stored number from memory)
Add (AD)
Subtract (SUB) (Memory from stored number)
Set to one
Clear to zero
Exclusive-OR
OR
Input Data (From parallel data lines)
Left shift
Right shift
Rotate (cycle) right


Fig. 7 - The Arithmetic Unit.
would be required in a multiplication algorithm. Parallel data entry or access to the A bus is possible for the shift register from the A side of the CD4034A. When all inputs on the B side are grounded, the shift register can be reset by performing a parallel-input operation on the $B$ side.

Register B is a general-purpose register which could be used to hold intermediate results, a multiplicand, or for shiftright expansion of register A . With the configuration shown, i.e., with the output of Q8 connected to the input of Q7 and so forth, register B can be made to shift left as well as right, its normal mode of shifting. Left shifting is accomplished by enabling synchronous data entry on the B side and clocking the register. The addition of a CD4030A exclusive-OR gate causes the register to be complemented when the True/ Complement Control signal is high and data is right shifted around once. With the control signal low, data is recirculated without modification. Here again, the three-state outputs on the A side of the B register allow parallel or serial data transfer to and from the $A$ bus.

The C register is used as an interface buffer between the A and D buses and for data storage or right-hand expansion of the A register. Table II shows the modes of operation for buffering and the required control-signal levels. The one mode which is not realizable directly from Table II could be accomplished by putting two CD4016A transmission-gate packages between the B side of the CD4034A and the A bus. Register C can be cleared by setting the Recirculate-Zeros control-line low and shifting data around once. Of course, a parallel entry of zeros from either the A or D bus would also serve as a reset for this register.

## DISPLAY OUTPUT

The display unit for numerical outputs is shown in Fig. 8. The CD4056A is used as interface with a 4-digit liquid-crystal display, the TA8054R. Each CD4056A contains a 4-bit latch, a BCD-to-7-segment decoder, level shifters, and display drivers. When a square wave is applied to the Display-Frequency input of the CD4056A and as a common to one side of the display, the selected segment outputs consist of a square wave $180^{\circ}$

Table II - Modes of Operation for Buffering and the Required Control-Signal Levels for the C Register


1. Input from $D$, disconnect from $A$ * 2. Input from $D$, connect to $A$ 3. Disconnect from $D$, connect to $A$
2. Disconnect from $D$, disconnect from $A$
3. Input from $A$, disconnect from $D$
4. Input from $A$, connect to $D$
5. Disconnect from $A$, connect to $D$
6. Disconnect from $A$, disconnect from $D$

| Control Lines |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| AE | A/B | A/S | P/S | C |
| - | - | - | - | - |
| H | H | H | H | L |
| L | H | H | H |  |
| L | L | L | X |  |
| L | $L$ | H | H |  |
| H | L | H | H |  |
| H | L | L | H | , |
| L | L | L | X | $\nabla$ |

*Note:
These "A's" refer to the A (Arithmetic) Bus, not to the "A side" of the CD4034A.
92CS-22324
out of phase with the common. The signal causes the appropriate segment to become visible. Unselected outputs are in phase with the common, and the appropriate segment is then not visible. The two voltage-supply terminals of the CD4056A permit a higher voltage to be used across the display than appears on the control inputs to the device and allows for maximum contrast ratio on the display. At 15 volts and a frequency of 60 Hz , typical operating current for the display is only 125 microamperes.

Assuming that the normal data-bus information is in standard binary notation, conversion to BCD for the display can be handled in the Arithmetic Unit by using the Couleur ${ }^{3}$ technique or hard-wired, IC-implemented schemes. ${ }^{4,5}$ Since the D bus is 8 bits, two transfers are necessary to display all 4 digits.


Fig. 8 - Display unit for numerical outputs.

## OUTPUT BUFFER

The Output-Buffer circuitry, shown in Fig. 9, is realized by using a memory in a parallel-write/serial-read mode. The CD4051A is used as a multiplexer to enable one CD4061A memory circuit at a time when the Read/Write control line is low (for Read) and the Inhibit input of the CD4051A is also low. If the Inhibit input were high in the read mode, then all multiplexer outputs would be off since, with both inputs low to each gate, all NOR outputs will be high, and the memory will be disabled. Note that pull-down resistors are used to define a logic 0 level to the NOR gate since the tri-state outputs of the CD4051A would otherwise leave those inputs floating. Whenever the Read/Write control line goes high, all NOR gate outputs will be forced low and a parallel Write operation will be enabled.

For the greatest flexibility in this buffer application, CD4029A up/down presettable counters have been used for the address register. A starting address is strobed into the register by using the Preset Enable inputs of the CD4029A's. The clock is then enabled to provide a serial-memory readout where the address is automatically advanced or decremented at a rate suitable for the transmission medium. A faster clock can be used to fill the memory initially from the D Bus in the Write Mode. A CD4019A AND/OR select gate is used to switch between the two clocks. By disabling the clock entirely, the CD4029A can be made to perform as a simple, 4-bit latch to randomly access any particular memory location.

As an example of the use and operation of the entire Control Unit, consider the case where one of the system
analog inputs represents water pressure being monitored in a pipe. The digitized pressure reading would be entered into the Arithmetic Unit and then subtracted from a maximum or minimum limit number brought from memory. In addition, the present reading could be compared against the last reading stored in memory and the result compared with yet another stored parameter to determine whether the difference in two readings lay within expected bounds. A rapid pressure drop, for instance, could indicate a leak in the line and would require a warning message to be generated and special action to be taken by the controls.

## OUTPUT TRANSMITTER

The Transmitter portion of the system, shown in Fig. 10(a), consists of an NRZ-to-biphase data converter (CD4037A) and a VCO (CD4046A), so that output data will be in the form of biphase FSK. This type of modulation is preferred in many applications since one zero-crossing is generated during each bit period; this arrangement simplifies clock recovery. However, this technique is relatively wasteful of bandwidth. The CD4037A generates biphase data, as shown in Fig. 10(b), when supplied with a clock and clock at twice the bit rate. The output of the circuit is used to control a transmission gate (CD4016A) which switches R3 in parallel with R2, thus changing the input voltage to the VCO. The VCO output, then, is two discrete frequencies determined by the ratios of R1 and R2 for a logic 1 and R1 to R2/R3 for a logic 0 .


Fig. 9 - Output-Buffer circuit.


Fig. 10 - (a) Transmitter, (b) biphase data generated by the CD4037A.

## RECEIVER

The block diagram of the Receiver is shown in Fig. 11(a). After amplification, the FSK signal is detected in a phaselocked loop using the CD4046A and a threshold detector (Fig. 11(b)). Clock and data reconstruction is accomplished by the circuit shown in Fig. 11(c).

The flexibility of COS/MOS devices is demonstrated in Fig. 12 in which an op-amp circuit that can be used to amplify the incoming signal to the Receiver is configured. The op-amp consists of two CA3600E packages, which are CD4007A units specially tested for linear applications, and one CA3046 bipolar-transistor array. This circuit is unusual in that it is responsive to small-signal, ground-referenced inputs, and the output stage can easily be driven to within 10 millivolts of $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$ when $\mathrm{R}_{\mathrm{L}}$ is very high.

In Fig. 11(b), the phase-locked loop locks onto the incoming frequency. The voltage controlling the VCO then assumes two discrete values corresponding to whether the loop is locked onto $f_{1}$, representing a binary 1 , or $f_{2}$, representing a binary 0 . A Schmitt trigger, constructed of a CD4007A and used here for threshold detection, discriminates between the two voltages and produces a clean 1 or 0 output. This action completes the demodulation of FSK into a biphase data stream.

The next step is to reconvert the data in the biphase data stream to the original NRZ and recover the clock signal; Fig. 11(c) shows how this can be done. The biphase data (A) is
differentiated to mark the locations of data transitions. This differentiation provides a reference frequency at twice the bit rate of the phase-locked loop. However, some of the pulses will be missing where transitions occurred in the original data stream (B). To provide a reliable clock, the VCO is forced to

(a)

(b)

(c)

Fig. 11 - (a) Receiver, (b) phase-locked loop consisting of a CD4046A and a threshold detector, (c) circuit for clock and data reconstruction.
run at twice the bit rate by FF1, which divides the VCO output by two before returning it to the phase comparator (D). The differentiated signal is gated such that only every other pulse is permitted through to the phase comparator (C). In this way, the PPL does not see the missing pulses, and the VCO output remains constant at twice the bit rate. FF2 provides the necessary $90^{\circ}$ phase shift to generate a clock signal for incoming data (E). The output of FF3 is the recovered binary information (F). Initial synchronization of the system is accomplished by preceding actual data transmission with a string of alternating 0 's and 1 's. 6

Typical data rates up to 600 kHz can be realized within the frequency range of the VCO incorporated in the CD4046A with the VCO operating at 10 volts.

## CONTROL UNIT

Binary information recovered at the Control Unit can be used directly to control on/off functions by a particular bit in the data word, or a complete word can be converted to an equivalent analog voltage for proportional control of servos, for example. An A/D converter realizable with COS/MOS standard parts is shown in Fig. 13. In a configuration analogous to the Receiver portion of the Control Unit, a data word is clocked into a CD4034A register and, after all 8 bits have


Fig. 13 - A D/A converter that can be made up of COS/MOS standard parts.
been received, the output of a CD4017A (connected in a divide-by- 8 mode) strobes the word into a CD4042A holding register. Register outputs are buffered by CD4041A's to an $\mathrm{R} / 2 \mathrm{R}$ resistor ladder and a voltage follower. The COS/MOS op-amp shown in Fig. 12 can be used as the follower.


Fig. 12 - Op-amp circuit that can be used to amplify the incoming signal to the Receiver or as a voltage follower in the Control Unit.

## SUMMARY

The wide range of logic functions available as standard parts in the ever-expanding CD4000A line provides the design engineer with the building blocks for a wide variety of digital functions. Complex logic functions realized on a single IC permit the designer to think in large-scale system terms. The flexibility of design made possible by such features as bidirectional inputs and outputs and three-stage logic results in a minimum package count, even for complex systems. These features, coupled with the well-known advantages of COS/MOS circuits in the areas of noise immunity, low power, high fanout, power-supply tolerance, temperature stability, and off-the-shelf availability of parts for both bread-boarding and production, make a very attractive combination for the designer.

## REFERENCES

1. COS/MOS Digital Integrated Circuits Databook, RCA Solid State Databook Series, SSD-203A, 1973.
2. RCA COS/MOS Integrated Circuits Manual, Technical Series CMS-271, 1972
3. J.F. Couleur, "BIDEC - A Binary to Decimal or Decimal to Binary Converter," IRE Transactions on Electronic Computers, Dec. 1958. Also see ref. 1, pp. 176-178.
4. Z.M. Benedek and B. Moskowitz, "Converter Binary to BCD Without Flip-Flops,"Electronic Design, Oct. 10, 1968.
5. John R. Linford, "Binary to BCD Conversion with Complex IC Functions," Computer Design, Sept. 1970.
6. See ref. 1, pp 325-326.

# Gate-Oxide Protection Circuit in RCA COS/MOS Digital Integrated Circuits 

by R.R. Painter

One of the most frequently encountered handling and testing problems with early MOS devices was failure of the gate oxide. Although this problem existed during handling and testing of devices prior to their installation in a circuit (because normal circuit impedances and voltages make damage of this nature less likely), a solution to the problem was necessary to reduce failure of MOS devices and integrated circuits during manufacture, reliability testing, shipping, incoming inspection, and assembly by equipment designers.

The breakdown voltage of an MOS gate oxide is generally in the order of 70 to 100 volts, and the dc resistance is in the order of $10^{12}$ ohms. In contrast to other semiconductor diodes, in which the breakdown can be tested any number of times without damage, the MOS gate oxide will be shorted as a result of only one voltage excursion to the breakdown limit. Because of the extremely high resistance of the gate oxide, even a very-low-energy source (such as a static charge) is capable of developing this voltage.

Fig. 1 shows a protection circuit developed by RCA which is incorporated in COS/MOS integrated circuits to minimize this problem. The results to date have shown that this approach is effective in minimizing occurrences of gate-oxide
failure; when the handling guidance contained in ICAN-6000* is followed, the problem is eliminated.

A value of 200 to 2000 ohms (depending on design and process variations) is used for the input resistor R in Fig. 1. This value is chosen, in conjunction with the capacitance of the gate and the associated protective diodes, to integrate and clamp the device voltages at a safe level. The diagrams shown in Fig. 2 demonstrate that the input circuit limits extraneous voltages to safe levels for all operating conditions. Because of its low RC time constant, this network has no noticeable effect on circuit speed.
Because of the presence of this integral protection circuit, the $V_{\text {DD }}$ power supply should not be turned off while a signal from a low-impedance generator is applied at an input of a COS/MOS integrated circuit. If the VDD supply is turned off while a low-impedance pulse generator is connected to an input, the $\mathrm{V}_{\mathrm{DD}}$ line is essentially grounded and a positive voltage from the pulse generator is impressed across diode $\mathrm{D}_{2}$. This voltage of up to 15 volts can cause permanent damage to the diode or can burn out the $\mathrm{V}_{\mathrm{DD}}$ metallization. If any input excursion exceeds $+V_{D D}$ or goes below $-\mathrm{V}_{\mathrm{SS}}$, the current through the input diodes should be limited to 10 milliamperes for safe operation.

* "Handling Considerations for MOS Integrated Circuits"


Fig. 1 - Gate-oxide protection circuit used in COS/MOS integrated circuits.

(c)


Fig. 2 - Circuits used to provide: (a) protection between input pin and $V_{D D}$ pin; (b) protection between input pin and ground pin; (c) protection between input pin and output pin.

# Radiation Resistance of the COS／MOS CD4000A Series 

by M．N．Vincoff

Complementary MOS（COS／MOS）integrated circuits possess many advantages which recommend their use in radiation－susceptible space and military environments． Several of the most significant of these advantages are： ultra－low standby－power consumption，high noise im－ munity，${ }^{1}$ extremely high packaging density，and inherently high reliability．${ }^{2}$ These advantages，along with the improved radiation resistance of the RCA CD4000A series over the CD4000 series described in earlier radiation studies，${ }^{3}$ exhibit the maturity reached by the MOS technology since 1971.

A number of studies of the radiation resistance of complementary MOS devices by NASA，the Navy and various companies in the space industry have revealed two areas of prime concern．${ }^{4-15}$ The first，permanent radiation exposure， as experienced in a space environment，causes a shift in threshold or switching voltage and a possible increase in leakage current， $\mathrm{I}_{\mathrm{L}}$ ．The second，transient radiation exposure， as experienced in an atomic environment，causes the output－ voltage levels to respond to a pulse of ionizing radiation；this effect could change the state of the logic circuitry and require resetting of that circuitry for proper equipment or system operation．

## Permanent－Radiation Resistance

The CD4000 series was resistant to permanent radiation levels of $2 \times 10^{4}$ rads（approximately $10^{12} \mathrm{e} / \mathrm{cm}^{2}$ ）．Now， however，RCACD4000A－series devices without special shielding have been found to be resistant to radiation levels up to $2 \times 10^{5}$ rads（approximately $10^{13} \mathrm{e} / \mathrm{cm}^{2}$ ），as shown in Fig．1．${ }^{3}$ In this figure the change in switching voltage $\Delta V_{S}$ is plotted as a function of dose．The value of $\Delta V_{S}$ was calculated from the average value of $\Delta \mathrm{V}_{\mathrm{TN}}$ and $\triangle \mathrm{V}_{\mathrm{TP}}$ for the devices mentioned．The new radiation level of the CD4000A series represents a significant improvement over the CD4000 series．In addition，with minimal shielding（for example， $1 / 16$－inch of aluminum）the CD4000A series can be used in application with levels of radiation up to $3 \times 10^{6}$ rads （approximately $10^{14} \mathrm{e} / \mathrm{cm}^{2}$ ）．${ }^{15}$


Fig． 1 －Permanent radiation resistance of CD4000A－and CD4000－ series devices．

## Transient－Radiation Resistance

The resistance of the CD4000A series to transient radiation is expected to be ten times better than that of the CD4000 series，which can withstand pulses of radiation of approximately $10^{10} \mathrm{rads} / \mathrm{s} .5$

## Design Considerations

The resistance of the CD4000A－series devices to either permanent－or transient－radiation exposure can be increased by providing either minimal shielding through the design of the equipment enclosure containing the devices or by locating the devices deep within the equipment in which they are used．In any case，the action taken will depend on the constraints dictated by the radiation environment imposed by the system or program．Each application must be tested and the results analyzed with the data in this Note as criteria． Test items to be considered are radiation environment，which
will vary greatly depending on dosage rate; time of exposure; amount of normal shielding; distance of the device from the radiation source; shielding afforded by the atmosphere; power-supply voltage selection; and switching cycles used during exposure. For example, consider the effects of permanent radiation on two spacecraft in 90 -degree orbits at 600 and 1500 nautical miles from the earth, respectively. The dose-depth is determined as shown in the curves of Fig. 2. In these curves the dose in rads(A1)/day is plotted as a function of the thickness of spacecraft aluminum required to shield the devices from trapped electrons and protons. ${ }^{4}$


Fig. 2 - Dose-depth curves for trapped electrons and protons in spacecraft in orbit.

## Conclusion

The RCA COS/MOS CD4000A series exhibits improved radiation resistance over the CD4000 series, and is well suited for use in many applications in which permanent and transient radiation effects are factors. When stringent radiation requirements are imposed, additional shielding can be employed to increase the radiation life of COS/MOS CD4000A-series devices to any desired level, i.e., to make their radiation resistance equivalent to that of bipolar devices.

Custom COS/MOS devices that can resist a radiation level of $10^{6}$ rads are now being developed by means of an aluminum implantation process which requires one additional masking step in the production line. 11-14

## References

1. Eaton, S. S., "Noise Immunity of RCA COS/MOS Integrated Circuit Logic Gates", RCA Application Note ICAN-6176.
2. Vincoff, M. N. and Schnable, G. L., "COS/MOS is a High-Reliability Technology", RCA Technical Publication ST-61 12.
3. Ezzard, G., "Radiation Effects on COS/MOS Devices", RCA Application Note ICAN-6604 (covers CD4000 series).
4. Brucker, G. J., "COS/MOS Device Sensitivity in OuterSpace Radiation Environment", Report No. X72002, Oct. 17, 1973, RCA Astro Electronics Division.
5. Dennehy, W. J., et al., "Transient Radiation Response in Complementary-Symmetry MOS Integrated Circuits", RCA Technical Publication ST-4308.
6. Poch, W. J., and Holmes-Siedle, A. G., "Permanent Radiation Effects in COS/MOS Integrated Circuits", RCA Technical Publication ST-4174 (covers CD4000 series).
7. Schambeck, W., "Radiation Resistance and Typical Applications of RCA COS/MOS Circuits in Spacecrafts", Telemetry Journal, June/July 1970 (covers CD4000 series).
8. Schambeck, W., "Effects of Ionizing Radiation on Low-Threshold C-MOS Integrated Circuits", DFVLR Institute for Satellite Electronics, Oberpfaffen-hofen, W. Germany, April 1972 (covers CD4000A series).
9. Danchenko, V., "Radiation Damage in MOS Integrated Circuits, Part I", Sept. 1971, Goddard Space Flight Center, Report X-711-71-410 (covers CD4000A series).
10. Poch, W. J., and Holmes-Siedle, A. G., "The Long-Term Effects of Radiation on Complementary MOS Logic Networks", IEEE Transactions on Nuclear Science NS-17 (6), Dec. 1970 (covers CD4000 series).
11. Smith, J. M., and Murray, L. A., "Radiation Resistant COS/MOS Devices", RCA Technical Publication ST-4723.
12. King, E. E., Nelson, G. P., and Hughes, H. L., "The Effects of Ionizing Radiation on Various COS/MOS Integrated Circuit Structures", IEEE Transaction in Nuclear Science, No. 6, pg. 264, Dec. 1972, RCA Technical Publication ST-6161.
13. Peel, John L., et al., "Radiation-Hardened Complementary MOS Using $\mathrm{SiO}_{2}$ Gate Insulators", IEEE Transactions on Nuclear Science, No. 6, pg. 271, Dec. 1972.
14. Schlesier, K. M., et al., "COS/MOS Hardening Techniques", IEEE Transactions on Nuclear Science, No. 6, pg. 275, Dec. 1972.
15. Novell, J., "Radiation Test of RCA COS/MOS CD4000A Series Logic for IUE Orbit, Types CD4011AK/1 with and without shielding, and $1 \times 256$ RAM", U. S. Gov't. Spacecraft Data Management Branch, Code 734.1, June 28, 1973.

ICAN-6230

# Using the CD4047A in COS/MOS Timing Applications 

by J. Paradise

Many applications exist today for COS/MOS multivi-brators- both oscillators and one-shots-in analog and digital circuits. The requirements for these applications vary widely in such parameters as voltage range, temperature stability, power dissipation, drive capability, and external-component cost. No design is optimum for all of the above considerations. However, the RCA-CD4047A Monostable/Astable Multivibrator fulfills the needs of most applications in this timing area. It can function as either an oscillator or one-shot with many additional features, and will meet the power dissipation, stability, and speed requirements of most COS/MOS systems.

This Note compares some simpler types of oscillator circuits with the CD4047A in both theoretical and actual performance, and provides application information on the CD4047A which should prove useful to COS/MOS circuit and system designers.

## COS/MOS DISCRETE RC OSCILLATOR

The simplest type of RC-oscillator is shown in Fig. 1. It consists of two inverters (which may be taken from standard


Fig. 1 - Simplest COS/MOS RC oscillator.
RCA COS/MOS parts, i.e., CD4007A, CD4001A, CD4011A, etc.) and a single resistor and capacitor. The operating waveforms for this circuit are shown in Fig. 2.

The circuit operates as follows: depending on the output levels of inverters $A$ and $B$, at any instant $C$ will be charging or discharging through $R$. When the waveform at point (2) in the circuit passes through the transfer voltage of inverter $A$, this inverter will switch and cause inverter B to switch. Subsequently, the waveform at point (2) would be exponentially


Fig. 2 - RC-oscillator operating waveforms.
increasing or decreasing with discontinuities equal in magnitude to $\mathrm{V}_{\mathrm{DD}}$ during the instant of switching. However, since point (2) is protected by a standard input-protection circuit common to COS/MOS devices, the waveform is clamped at one diode voltage drop above $\mathrm{V}_{\mathrm{DD}}$ and below $\mathrm{V}_{\mathrm{SS}}$. (Refer to waveforms in Figs. 2 and A1). The calculations for the period of this multivibrator circuit are shown in Appendix A; the final equation for the period $T$ is

$$
\begin{equation*}
\mathrm{T}=-\mathrm{RC} \ln \frac{\left(\mathrm{~V}_{\mathrm{TR}}\right)\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}\right)}{\left(\mathrm{V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{D}}\right)^{2}} \tag{1}
\end{equation*}
$$

where $\mathrm{V}_{\mathrm{TR}}$ is the switching or transfer point of the inverter, and $V_{D}$ is the diode forward voltage drop.

Equation (1) shows that the period of the multivibrator, $T$, is sensitive to changes in $\mathrm{V}_{\mathrm{DD}}$, as illustrated by the graph of time period, $T$, vs transfer voltage as a function of $V_{D D}$ in Fig. 3. In addition to the strong dependence of actual time period on the $\mathrm{V}_{\mathrm{DD}}$ chosen, the graph also illustrates that, for a given $\mathrm{V}_{\mathrm{DD}}$, a full transfer voltage spread of 30 to 70 per cent of $\mathrm{V}_{\mathrm{DD}}$ (unit-to-unit worst-case variations) yields a change in time period of about 10 per cent from the nominal 50 -per-cent transfer-voltage percentage values.

The above analysis is valid only at low frequencies (i.e., less than 50 kHz ). As the multivibrator frequency approaches this value, other considerations must be taken into account:


Fig. 3 - Discrete RC-oscillator time period as a function of transfer voltage.

1. The input protection circuit has a $\mathrm{V}_{\mathrm{DD}}$ diode with a finite resistance and capacitance; the diode will discharge at the rate associated with this small time constant.
2. In the negative direction, there is a diode as well as a series protection resistor ( 1 to 3 kilohms); the time constant of this diode is even longer than that of the $\mathrm{V}_{\mathrm{DD}}$ diode.
3. The propagation delay of the inverters used is added to the time period during each charge and discharge cycle. Since the delay is a function of $\mathrm{V}_{\mathrm{DD}}$, small changes in $\mathrm{V}_{\mathrm{DD}}$ at high frequencies will cause the time period to vary.
4. There is a finite output impedance associated with the inverter which is in series with the external timing resistor. Since this output impedance also changes with $\mathrm{V}_{\mathrm{DD}}$, at high frequencies where the external resistor becomes small, the multivibrator stability decreases with small variations in $\mathrm{V}_{\mathrm{DD}}$.

The negative features of the input protection circuit can be partially compensated for by the addition of a resistor, $\mathrm{R}_{\mathrm{S}}$, in series with the input protection circuit, as shown in Fig. 4. Although the input inverter $A$ is still clamped at one diode drop above $\mathrm{V}_{\mathrm{DD}}$ or one diode drop below $\mathrm{V}_{\mathrm{SS}}$, the waveform at point (4) is allowed to swing well above $\mathrm{V}_{\mathrm{DD}}$ and below $\mathrm{V}_{\mathrm{SS}}$. The larger swing reduces the dependency of transfer-voltage variations upon stability; the variable characteristics of the input protection circuit and their effect upon stability are greatly reduced. An analysis of this circuit is presented in


Fig. 4-RC-oscillator with the addition of $R_{S}$.

Appendix B; the equation for the period. T. for this circuit is shown in Eq. 2.

When $K=\frac{R_{S}}{R}, T$ is:

$$
\left\{\begin{align*}
\mathrm{T}= & -\mathrm{RC} \ln \frac{\left(\mathrm{~V}_{\mathrm{TR}}\right)\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}\right)}{\left(\mathrm{V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{D}}\right)^{2}}  \tag{2}\\
& -\frac{(\mathrm{K})}{(\mathrm{K}+1)} \mathrm{RC} \ln \frac{\mathrm{~K}\left[\mathrm{~V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{D}} \mid\right.}{\mathrm{K}\left[\mathrm{~V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{TR}}\right]+\left[\mathrm{V}_{\mathrm{TR}}-\mathrm{V}_{\mathrm{D}} \mid\right.} \\
& -\frac{(\mathrm{K})}{(\mathrm{K}+1)} \mathrm{RC} \ln \frac{\mathrm{~K}\left[\mathrm{~V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{D}}\right]}{\mathrm{K}\left[2 \mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}\right]+\left\{\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}-\mathrm{V}_{\mathrm{D}} \mid\right.}
\end{align*}\right\}(2
$$

In this form it is easy to see that when $K$ approaches zero, the circuit and associated waveforms are equivalent to those of Fig. A-1. On the other hand, as K approaches infinity, the variation in period as a function of $\mathrm{V}_{\mathrm{DD}}$ is reduced to zero. This result is shown in Fig. 5, where period as a function of trans-


Fig. 5 - Discrete RC-oscillator time period as a function of transfer voltage.
fer voltage is plotted for different value of $\mathrm{V}_{\mathrm{DD}}$ and K , and Fig. 6, which shows period as a function of $K$ for different values of $\mathrm{V}_{\mathrm{DD}}$. Variation in period with transfer voltage is also reduced as $K$ increases. This variation decreases from 10 per cent for $K=0$ to about 5 per cent as $K$ gets large.

There are some obvious limitations in the value of $\mathrm{R}_{\mathrm{S}}$ that can be used. Besides the disadvantages in this circuit if R is to


Fig. 6 - Discrete RC-oscillator time period as a function of constant, $k$.
be made adjustable, the user must be careful with component layout, if $\mathrm{R}_{\mathrm{S}}$ is made very large, to take advantage of the improvement in stability. A time constant and phase shift is produced by $\mathrm{R}_{\mathrm{S}}$ and stray wiring and breadboard capacitance, see Fig. 7. This shift creates a switching delay in the circuit which changes the time period and, in addition, may cause spurious oscillations and glitches in the multivibrator circuit. A reasonable value for K would be anywhere from 2 to 10 , with maximum and minimum values for $\mathrm{R}_{\mathrm{S}}$ determined by the above considerations.


92C5-22677
Fig. 7 - RC-oscillator circuit with stray capacitance.

## COS/MOS INTEGRATED RC OSCILLATORS

The RCA-CD4047A is an integrated RC oscillator that eliminates most of the disadvantages of the discrete circuits previously discussed. The primary reason for this improved performance is the special input-protection circuit which allows the capacitor charging waveform to swing above $\mathrm{V}_{\mathrm{DD}}$ and below $\mathrm{V}_{\mathrm{SS}}$ without the need for an external resistor. This circuit, shown in Fig. 8, has the same time period and stability as the circuit in Fig. 4 for the case where the value of $R_{S}$ is infinite. However, a resistor is eliminated, as well as the disadvantages of a time constant caused by the resistor.


Fig. 8 - CD4047A oscillator sectiun
There are two additional reasons for expected improvement with the CD4047A. First, the transfer-voltage point of the input inverter, $A$, is tested between 33 and 67 per cent of $V_{D D}$ instead of between 30 and 70 per cent; this narrower test range improves stability by reducing unit-to-unit variations. In addition, large buffers are used for inverters D and E ; this practice reduces the effect of changes of device output impedance with period stability. A derivation of period, T, for this circuit is presented in the Appendix $C$; the final equation for $T$ becomes:

$$
\begin{equation*}
\mathrm{T}=-\mathrm{RC} \ln \frac{\left(\mathrm{~V}_{\mathrm{TR}}\right)\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}\right)}{\left(\mathrm{V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{TR}}\right)\left(2 \mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}\right)} \tag{3}
\end{equation*}
$$

Figure 9 shows a graph of stability as a function of transfer voltage based on this equation.

The graph of Fig. 9 shows a maximum variation of 5 per cent between minimum ( 2.197 RC ) and maximum ( 2.307 RC ) time periods. A value of 2.25 RC yields a $\pm 2.5$ per-cent variation. Typical values of period variations at high frequencies and temperature extremes are included in the published data for the CD4047A. ${ }^{1}$


Fig. 9 - CD4047 time period as a function of transfer voltage.
An additional advantage of the CD4047A is a reduction in power dissipation as compared to the discrete multivibrators discussed previously. Inverter A in Fig. 8 is designed with highimpedance components that limit power dissipation during the time that the inverter operates in the middle of its transfer region. Four additional inverters are used to gradually shift from a very-high-impedance inverter at the input to a very-lowimpedance driver in series with the external timing resistor. Calculations for power dissipation and a comparison of $\mathrm{P}_{\text {diss }}$ for the CD4047A and a discrete oscillator are presented in Appendix D; the result is

$$
\begin{equation*}
P_{\mathrm{diss}}=2 \mathrm{CV}^{2} \mathrm{f} \tag{4}
\end{equation*}
$$

This equation specifies the power dissipated in the external components only. At low frequencies, where most of the power will be dissipated in R , power can be minimized by using a small value of $C$, since the formula shows the power is a function of $C$ and not $R$.

Additional power is consumed in the CD4047A chip as a function of frequency. Fig. 10 shows curves for theoretical minimum power dissipation, actual CD4047A oscillator-power dissipation, and discrete oscillator-power dissipation as a function of frequency.

## CMOS DISCRETE ONE-SHOTS

Fig. 11 illustrates one of several simple monostable circuits which can be employed in non-critical timing circuits. ${ }^{2}$ The


Fig. 10 - Comparison of $P_{\text {diss }}$ for discrete oscillator and CD4047 with theory.


Fig. 11 - COS/MOS monostable circuit.
circuit pulse width is dependent upon the transfer voltage of inverter B as time constant RC charges to $\mathrm{V}_{\mathrm{DD}}$ from $\mathrm{V}_{\mathrm{SS}}$. The pulse width is defined as

$$
\begin{equation*}
T=-R C \ln \frac{\left(V_{D D}-V_{T R}\right)}{\left(V_{D D}\right)} \tag{5}
\end{equation*}
$$

Fig. 12 shows the variation in pulse width as a function of transfer voltage for this device.

There are several alternatives to the circuit shown in Fig. 12. ${ }^{2}$ These alternatives have the advantage of greater stability, but at the expense of two time constants required in circuit and, in some cases, the addition of a diode.


Fig. 12 - Simple one-shot time period as a function of transfer voltage.

## COS/MOS INTEGRATED ONE-SHOTS

The CD4047A, when used in the monostable mode, again has several advantages over discrete designs. A high degree of accuracy can be achieved with one time constant, and power dissipation is lower than with discrete designs. Fig. 13 shows that many functions can be achieved with the CD4047A, including leading and trailing-edge triggering, and retriggering.

The pulse width, $\mathrm{T}_{\mathrm{M}}$, is expressed below: its derivation is given in Appendix E.

$$
\begin{equation*}
\mathrm{T}_{\mathrm{M}}=-\mathrm{RC} \ln \frac{\left.\left(\mathrm{~V}_{\mathrm{TR}}\right)\left(\mathrm{V}_{\mathrm{DD}}\right)-\mathrm{V}_{\mathrm{TR}}\right)}{\left(2 \mathrm{~V}_{\mathrm{DD}}\right)\left(2 \mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}\right)} \tag{6}
\end{equation*}
$$

Fig. 14 is a graph of pulse width versus transfer voltage based on the above equation.

The equations for monostable-mode power dissipation are also derived in Appendix E. For a repetitive output on the CD4047A, power dissipation can be expressed by the following equation:

$$
\begin{equation*}
\mathrm{P}_{\text {diss }}=\frac{2.875 \mathrm{CV}_{\mathrm{DD}}{ }^{2}}{\mathrm{~T}_{\mathrm{M}}} \times \text { (duty cycle) } \tag{7}
\end{equation*}
$$

## USING THE CD4047A - SPECIAL CONSIDERATIONS

A number of circuit considerations are explained below which will aid the user of the CD4047A.

A clamping circuit is provided on the chip to reduce the recovery time ( tr ) that would normally exist in other monostable circuits; see Figs. 15 and 16. Fig. 17 shows a plot of monostable-pulse-width stability as a function of duty cycle for specific R and C external components. Note that there is no appreciable change in pulse width until the duty cycle approaches 100 per cent. A disadvantage to the clamping circuit is that it introduces additional capacitance at the RC common node (Fig. 16), which may be noticeable for short pulse widths in the monostable mode only. Some diffusion capacitance present at the base of the $n-p-n$ transistor is used to quickly


Fig. 13 - CD4047A logic diagram.


Fig. 14 - CD4047A one-shot pulse width as a function of transfer voltage.


Fig. 15 - CD4047A one-shot RC waveform.


Fig. 16 - CD4047A clamping circuit.


Fig. 17 - CD4047A monostable accuracy as a function of duty cycle.
charge $C$ to $\mathrm{V}_{\mathrm{DD}}$ after the one-shot cycle has terminated. This capacitance is multiplied by the beta of the transistor, and is in parallel with the external C during the time interval that the transistor is on $\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{BE}}<\mathrm{t}<\mathrm{V}_{\mathrm{BE}}\right)$. Thus, when values of C less than 1000 picofarads are used, the actual width will be longer than that predicted by the formula. Fig. 18 is a graph of actual, typical pulse widths as a function of external C used under these conditions. Note that the minimum values of C used in the graph are the smallest that can be used in the CD4047A to assure proper operation of the circuit.

The waveform in Fig. 15 shows that two positive transitions are encountered by the control circuitry in the CD4047A. These transitions are necessary to make the output flip-flop at pin 10 toggle properly to produce the single pulse nceded in monostable operation. However, at pin 13, the waveform of


Fig. 18 - CD4047A pulse width as a function of capacitance.
Fig. 19 results; the pulse width of the spike is equivalent to the propagation delay of the circuit. This spike will normally prevent the user from using pin 13 in the monostable mode. In the astable mode, however, pin 13 can be used whenever a 50 -per-cent duty cycle and higher drive capability are not


Fig. 19 - CD4047A one-shot output at pin 13.
required. The advantage to the use of pin 13 under these conditions is that the frequency of the waveform at pin 13 is twice that of pin 10 for the same external timing components.

When the CD4047A is used in the retrigger mode, the retrigger input is connected directly to the set input of FF4,
as shown in Fig. 13. This connection means that the output at pin 10 will be high during the time that a high level is present on pin 12. Thus, if normal one-shot operation is required at any time that the circuit is in the retrigger mode, the input pulse should be shorter than the expected pulse at the output. Note that in the retrigger mode the output pulse width is not referenced to the last positive-going edge produced at the input because of the asynchronous nature of the circuit. The output actually terminates when two internal-oscillator leading edges have been received by FF4, after the high level present on pin 12 has been removed. The output width variation will then be between one and two time constants referenced to the trailing edge of the input at pin 12, see Fig. 20.


Fig. 20 - CD4047A retrigger-mode waveforms.
A section on timing-component limitations is presented in the CD4047A data sheet. ${ }^{1}$ It should be emphasized that it is desirable to use a small value of capacitance wherever possible. The circuit will work well even when the value of $R$ approaches or exceeds 1 megohm. For very low frequencies, where a large value of capacitance is needed, the selection of the capacitor is very important. It must be nonpolarized because there is no reference ground at either of the two pins to which C is connected. The capacitor parallel resistance (i.e., leakage) must also be at least an order of magnitude higher than the external $R$ used. This criterion generally eliminates electrolytic capacitors and those made of materials which could produce greater leakage current than that permitted for proper circuit operation.

Because of the internal circuit construction, there is no guarantee as to what de level will be present on the output at pin 10 or 11 when power is first turned on. If this condition must be guaranteed, a system-power on pulse input to pin 9 can be made to assure that pin 10 will initially be at a low logic level. The pulse can be generated from one of the circuits shown in Fig. 21.


Although the CD4047A data sheet calls for a minimum input pulse duration of 200 nanoseconds at 10 volts and 500 nanoseconds at 5 volts, shorter pulses (due to transients, etc.) occur frequently in system applications where the CD4047A is used. Such narrow pulses may not be ignored by the CD4047A, but may instead cause Q to go high permanently or until a reset input occurs. The circuit shown in Fig. 22 eliminates this problem by essentially "lengthening" the trigger pulse by feeding back through $\mathrm{R}_{\mathrm{A}}$ and $\mathrm{C}_{\mathrm{A}}$ a current pulse when Q goes from 0 to a 1 . The particular values shown have been tried and found to work well, even for extremely short input pulses (less than 20 nanoseconds).


Fig. 22 - Input-pulse stretcher circuit.

## APPLICATIONS

## NOISE DISCRIMINATOR

Fig. 23 illustrates an application of the CD4047A in a noisediscriminator circuit. By adjusting the external time constant, a pulse width narrower than that determined by the time constant will be rejected by the circuit. The output pulse will


Fig. 23 - Noise-discriminator circuit.
follow the desired input, but the leading edge will be delayed by the selected time constant. Fig. 24 shows ty'pical waveforms with the circuit in operation.


Fig. 24 - Noise-discriminator circuit waveforms.

## FREQUENCY DISCRIMINATOR

The CD4047A can be used as a frequency-to-voltage converter, as shown in Fig. 25. A waveform of varying frequency is applied to the + TR input. The one-shot will produce a pulse of constant width for each positive transition on the input. The


Fig. 25 - Frequency-discriminator circuit.
resultant pulse train is integrated to produce a waveform whose amplitude is proportional to the input frequency. The waveforms of Fig. 26 were taken with the circuit in operation.


Fig. 26 - Frequency-discriminator-circuit waveforms.

## LOW-PASS FILTER

A simple circuit using the CD4047A as a low-pass filter is shown in Fig. 27. The time constant chosen for the multivibrator will determine the upper cutoff frequency for the filter. The circuit essentially compares the input frequency


Fig. 27 - Low-pass filter circuit.
with its own reference, and produces an output which follows the input for frequencies less than $\mathrm{f}_{\text {cutoff }}$, and a low output for frequencies greater than $f_{\text {cutoff }}$. Figs. 28 and 29 show waveforms with the low-pass filter circuit in operation.

## BANDPASS FILTER

Two CD4047A low-pass filters can be employed to construct a bandpass filter, as illustrated by the circuit in Fig. 30.

The pass band is determined by the time constants of the two filters. If the output of filter No. 2 is delayed by $\mathrm{C}_{1}$, the CD4013A flip-flop will clock high only when the cutoff frequency of filter No. 2 has been exceeded; this point is illustrated in the timing diagram in Fig. 30. The $\overline{\mathrm{Q}}$ output of the CD4013A is gated with the output of filter No. 1 to produce


Fig. 28 - Low-pass filter-circuit waveforms.


Fig. 29 - Low-pass-circuit waveforms.


Fig. 30 - Bandpass filter circuit and waveforms.
the desired output. Typical operation of the circuit is shown in Fig. 31, where the input frequency is swept through the pass band.


Fig. 31 - Bandpass-filter-circuit waveforms.

## ENVELOPE DETECTOR

The CD4047A can be used as an envelope detector by employing it in the retrigger mode, as shown in Fig. 32. The time constant is selected so that the circuit will retrigger at the


Fig. 32 - Envelope-detector circuit.
frequency of the input pulse burst. A dc level appears at the output for the duration of the input pulse train. Fig. 33 shows waveforms taken with the circuit in operation.


Fig. 33 - Envelope-detector-circuit waveforms.

## PULSE GENERATOR

Several CD4047A units can be connected together to produce a general-purpose laboratory pulse generator, as shown in Fig. 34. The circuit shown has variable-frequency and pulsewidth control, as well as gating and delayed sync capability.


Fig. 34 - Pulse-generator circuit.

Gating can be controlled from a high- or low-level input. Automatic 50-per-cent duty-cycle capability is included, as normal or inverted output.

CD4047A No. 1 is connected as a gated, astable multivibrator, and, with the RC values shown, can produce overlapping ranges of frequencies from 2 Hz to 1 MHz . For freerunning operation, the Gate/Free-Run switch is closed, and the Gate Level switch is placed in the high-level position. Standby operation can be achieved with the Gate Level switch in the low-level position. When gating, the Gate/FreeRun switch is open, and the Gate Level switch is set to the appropriate position. The gate signal is applied to the Gate In jack.

CD4047A No. 2 is triggered from the gated, astable multivibrator, and produces a narrow sync pulse which can trigger an oscilloscope or generator. The sync pulse is obtained from the Sync Out jack.

If a 50 -per-cent duty cycle is desired, the Duty Cycle switch is set in the 50 -per-cent position, and the output is obtained from CD4047A No. 1. The Signal Polarity switch determines whether the Q and $\overline{\mathrm{Q}}$ output is used.

CD4047A No. 3 produces a variable, delayed (from 1.5 microseconds to 250 milliseconds) output with respect to the sync pulse when the Delay switch is in the IN position. This
one-shot is bypassed when the Delay switch is in the OUT position (the inherent delay is approximately 400 nanoseconds).

CD4047A No. 4 is a monostable multivibrator which receives trigger pulses from CD4047A No. 1 or No. 3. It can produce overlapping ranges of pulse widths from 1.5 microseconds to 200 milliseconds with the values shown.

The signal output is buffered with the CD4041A to allow the pulse generator to drive any required load. The circuit shown has the advantages of being compact, batterypowered, and COS/MOS compatible. In addition, it is capable of being run from the same power supply as the device under test to assure that the input levels are the same as $\mathrm{V}_{\mathrm{DD}}$ when the power-supply voltage is varied.

## MISCELLANEOUS APPLICATIONS

The basic properties of good stability in the astable mode, and stable pulse delay and width control in the monostable mode, make the CD4047A a useful building block in many systems, such as PMOS clock generation, audio tone generation, semiconductor memory systems, semiconductor memory exercisers, and general-purpose functional-testing systems. This Application Note will serve as a guideline in incorporating the CD4047A in a system design.

## Appendix A -

Calculation of the Period of an Astable Multivibrator Using a Single RC Time Constant


Fig. A-1 - RC oscillator waveform for the circuit of Fig. 1.

In Fig. A-1:

$$
\begin{aligned}
& t_{1}: v_{T R}=\left(v_{D D}+v_{D}\right) e^{t_{1} / R C} \\
& t_{1}=-R C \ln \frac{v_{T R}}{v_{D D}+v_{D}} \\
& t_{2}: V_{D D}-V_{T R}=\left(V_{D D}+v_{D}\right) e^{-t_{2} / R C} \\
& t_{2}=R C \ln \frac{V_{D D}-v_{T R}}{v_{D D}+v_{D}}
\end{aligned}
$$

And the period of an astable multivibrator using a single RC time constant is:

$$
T=t_{1}+t_{2}=-R C \ln \frac{\left(V_{T R}\right)\left(V_{D D}-V_{T R}\right)}{\left(V_{D D}+V_{D}\right)^{2}}
$$



In Fig. B-1:

$$
\begin{aligned}
t_{1}: V_{T R} & =\left(V_{D D}+V_{D}\right) e^{-t_{1} / R C} \\
t_{1} & =-R C \ln \frac{V_{T R}}{V_{D D}+V_{D}} \\
t_{2}: V_{D D} & -V_{T R}=\left(V_{D D}+V_{D}\right) e^{-t_{2} / R C} \\
t_{2} & =-R C \ln \frac{V_{D D}-V_{T R}}{V_{D D}+V_{D}}
\end{aligned}
$$

Fig. B-1-RC waveform for the circuit of Fig. 4.
$\qquad$

## ${ }^{t} \mathrm{~A}$



Fig. B-2 - Initial conditions for solving period t $\boldsymbol{A}_{\boldsymbol{A}}$.

Circuit initial conditions are shown in Fig. B-2. In the figure
$-C \frac{d v}{d t}=\frac{V+V_{D D}}{R}+\frac{V+V_{D D}-\left(V_{D D}+V_{D}\right)}{R_{S}}$

Eq. (B-1) is solved for V; the final voltage across the capacitor is
$\mathrm{V}=\mathrm{C}_{1} \mathrm{e}^{-\mathrm{K}_{1} \mathrm{t}_{\mathrm{A}}}+\frac{\mathrm{K}_{2}}{\mathrm{~K}_{1}}$
where $\mathrm{C}_{1}=\mathrm{V}_{\mathrm{TR}}=$ initial voltage across capacitor

$$
\begin{aligned}
K_{1} & =\frac{R_{S}+R}{R_{S} R C} \\
K_{2} & =\frac{V_{D} R-R_{S} V_{D D}}{R_{S} R C}
\end{aligned}
$$

By inserting these values into Eq. (B-2) and setting the final voltage across the capacitor, V , to $\mathrm{V}_{\mathrm{D}}, \mathrm{t}_{\mathrm{A}}$ becomes

$$
t_{A}=-\left[\frac{R_{S} R C}{R_{S}+R}\right] \ln \frac{R_{S}\left[V_{D D}+V_{D}\right]}{R_{S}\left[V_{D D}+V_{T R}\right]+R\left[V_{T R}-V_{D}\right]}
$$

## ${ }^{t_{B}}$



Fig. B-3-Initial conditions for solving period $t_{B}$.

Circuit initial conditions as shown in Fig. B-3. In the figure
$C \frac{d v}{d t}=\frac{V_{D D}-V}{R}-\frac{V_{D}+V}{R_{S}}$
Solving Eq. (B-3) for $V$ the final voltage across the capacitor, yields
$V=C_{2} e^{-K_{1} t_{B}}-\frac{K_{2}}{K_{1}}$
where $\mathrm{C}_{2}=\mathrm{V}_{\mathrm{TR}}-\mathrm{V}_{\mathrm{DD}}=$ initial voltage across capacitor $K_{1}, K_{2}$ are same values as for above for $t_{A}$.

Insertion of these values into Eq. (B-4), with $\mathrm{V}=-\mathrm{V}_{\mathrm{D}}$ yields
${ }^{t} B=\left[\frac{R_{S} R C}{R_{S}+R}\right] \ln \frac{R_{S}\left|V_{D D}+V_{D}\right|}{R_{S}\left|2 V_{D D} \quad V_{T R}\right|+R\left|V_{D D}-V_{T R}-V_{D}\right|}$
and $T=t_{1}+t_{2}+t_{A}+t_{B}$
The equations for $t_{A}, t_{B}$, and $T$ can be simplified by expressing $\mathrm{R}_{\mathrm{S}}$ as a multiple of R . Let $K=\frac{R_{S}}{R}$ and combining the expressions for $t_{1}$ and $t_{2}$. The resulting expression for $T$ is

$$
\mathrm{T}=-\mathrm{RC} \ln \frac{\left(\mathrm{~V}_{\mathrm{TR}}\right)\left(\mathrm{V}_{\mathrm{DD}}-\cdot \mathrm{V}_{\mathrm{TR}}\right)}{\left(\mathrm{V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{D}}\right)^{2}}
$$

$$
-\left(\frac{\mathrm{K}}{\mathrm{~K}+1}\right) \mathrm{RC} \ln \frac{\mathrm{~K}\left[\mathrm{~V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{D}}\right]}{\mathrm{K}\left[\mathrm{~V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{TR}}\right]+\left[\mathrm{V}_{\mathrm{TR}}-\mathrm{V}_{\mathrm{D}}\right]}
$$

$-\left(\frac{K}{K+1}\right) R C \ln \frac{K\left[V_{D D}+V_{D}\right]}{K\left[2 V_{D D}-V_{T R}\right]+\left[V_{D D}-V_{T R}-V_{D}\right]}$

## Appendix C -

## Calculation for Period of Astable Multivibrator Using Integrated Techniques



Fig. C.1-CD4047A RC oscillator waveform.

In Fig. C-1

$$
\begin{aligned}
t_{1}: V_{T R} & =\left(V_{D D}+v_{V T R}\right) e^{-t_{1} / R C} \\
t_{1} & =R C \ln \frac{v_{T R}}{V_{D D}+V_{T R}} \\
t_{2}: V_{D D}-V_{T R} & =\left(V_{D D}+v_{T R}\right) e^{-t_{1} / R C} \\
t_{2} & =-R C \ln \frac{v_{D D}-v_{T R}}{2 V_{D D}-V_{T R}}
\end{aligned}
$$

And the period of the astable multivibrator using integrated techniques is

$$
T=-R C \ln \frac{\left(V_{T R}\right)\left(V_{\mathrm{DD}}-V_{\mathrm{TR}}\right)}{\left(\mathrm{V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{TR}}\right)\left(2 \mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{TR}}\right)}
$$

Appendix D -
Power Needed for Charge and Discharge of an External Capacitor During One Cycle


$$
\begin{aligned}
P & =\frac{1}{(T / 2)} \int_{0}^{T / 2} C V \frac{d v}{d t} d t \\
& =\frac{2 C}{T} \int_{0}^{T / 2}\left(1.5 V_{D D} e^{-t / R C}\right) \\
& =\frac{4.5 C}{T} \frac{V_{D D}}{R C} \int_{0}^{T / 2} e^{-2 t / R C} d_{d t}
\end{aligned}
$$

Fig. D-1 - Waveform for calculating power dissipation.
Assume for this calculation that $\mathrm{V}_{\mathrm{TR}}=50$-per-cent $\mathrm{V}_{\mathrm{DD}}$,

$$
=-\left.\frac{2.25 \mathrm{C}}{\mathrm{~T}} \mathrm{~V}_{\mathrm{DD}^{2}} \mathrm{e}^{-2 \mathrm{t} / \mathrm{RC}}\right|_{0} ^{\mathrm{T} / 2}
$$ and that $\mathrm{T}=2.2 \mathrm{RC}$. Since charge and discharge cycles are symmetrical, the calculation can be performed by analyzing a discharge cycle only. See Fig. D-1.

$$
\begin{gathered}
\mathrm{V}=1.5 \mathrm{~V}_{\mathrm{DD}} \mathrm{e}^{-\mathrm{t} / \mathrm{RC}} \\
\frac{\mathrm{dv}}{\mathrm{dt}}=-\left(\frac{1}{\mathrm{RC}}\right)\left(1.5 \mathrm{~V}_{\mathrm{DD}}\right)\left(\mathrm{e}^{-\mathrm{t} / \mathrm{RC}}\right)
\end{gathered}
$$

Substituting $\mathrm{T}=2.2 \mathrm{RC}$

$$
\mathrm{P}=-\frac{\mathrm{C}}{\mathrm{~T}}(2.25) \mathrm{V}_{\mathrm{DD}^{2}}\left[\mathrm{e}^{-2.2}-1\right]=\frac{2.0}{\mathrm{C}} \mathrm{~V}_{\mathrm{DD}^{2}}
$$

$$
\mathrm{P}=2 \mathrm{CV}^{2} \mathrm{f}
$$

## Appendix E-

## Equations for Pulse Width $\mathbf{T}_{\mathbf{M}}$ of CD4047A in Monostable Mode



Fig. E.1-CD4047A RC waveform, monostable mode.

Note that the waveform in Fig. E-1 is not symmetrical because the timing capacitor is initially charged to $\mathrm{V}_{\mathrm{DD}}$. In the monostable mode, the circuit goes through one cycle only.

## Monostable Power Dissipation

To calculate the power dissipation for the circuit in the monostable mode, refer to Fig. E-1. If it is assumed that $\mathrm{V}_{\mathrm{TR}}=50$-per-cent $\mathrm{V}_{\mathrm{DD}}$, Fig. 14 shows that $\mathrm{T}_{\mathrm{M}}=2.485 \mathrm{RC}$. $t_{2}$ is the same as in the astable calculation, i.e., $t_{2}=1.10 \mathrm{RC}$ and $\mathrm{P}_{\mathrm{t} 2}=\mathrm{CV}^{2} \mathrm{f}$ for $\mathrm{V}_{\mathrm{TR}}=50$-per-cent $\mathrm{V}_{\mathrm{DD}}$. Thus, $\mathrm{t}_{1}$ in the monostable mode $=2.485 \mathrm{RC}-1.10 \mathrm{RC}=1.385 \mathrm{RC}$.

$$
\begin{aligned}
P & =\frac{1}{T_{M}}\left[\int _ { 0 } ^ { t _ { 1 } } \frac { C V \frac { d v } { d t } d t + \int _ { t _ { 1 } } ^ { t _ { 2 } } C V \frac { d v } { d t } d v } { } \left[\begin{array}{l}
T_{M} \\
\\
\end{array} \int_{0}^{t_{1}} \quad C V \frac{d v}{d t} d t+\frac{1}{T_{M}} C V^{2}\right.\right.
\end{aligned}
$$

where $V=2 V_{D D} e^{-t / R C}$ and

$$
\frac{\mathrm{dv}}{\mathrm{dt}}=-\left(-\frac{1}{\mathrm{RC}}\right)\left(2 \mathrm{~V}_{\mathrm{DD}}\right) \mathrm{e}^{-\mathrm{t} / \mathrm{RC}}
$$

$$
\begin{aligned}
& t_{1}: V_{T R}=2 V_{D D} e^{-t_{1} / R C} \\
& t_{1}=-R C \ln \frac{V_{T R}}{2 V_{D D}} \\
& t_{2}: V_{D D}-V_{T R}=\left(2 V_{D D}-V_{T R}\right) e^{-t_{2} / R C} \\
& t_{2}=-R C \ln \frac{V_{D D}-V_{T R}}{2 V_{D D}-V_{T R}}
\end{aligned}
$$

And the equation for the pulse width, $\mathrm{T}_{\mathrm{M}}$, of a CD4047A in the monostable mode is:
$T_{M}=t_{1}+t_{2}=-R C \ln \frac{\left(V_{T R}\right)\left(V_{D D}-V_{T R}\right)}{\left(2 V_{D D}\right)\left(2 V_{D D}-V_{T R}\right)}$
$P t_{1}=\frac{C}{T_{M}} \int_{0}^{t_{1}}\left(2 V_{d d} e^{-t / R C}\right)\left(\frac{1}{R C}\right)\left(2 V_{d d} e^{-t / R C}\right) d t$
$=\frac{C}{T_{M}} \frac{4 V_{d d}^{2}}{R C} \int_{0}^{t_{1}} e^{-2 t / R C} d t$
$=-\left.\frac{C}{T_{M}} \quad 2 V_{d d^{2}}{ }^{2} e^{-2 t / R C} \quad\right|_{0} ^{t_{1}}$
Substituting $\mathrm{t}_{1}=1.385 \mathrm{RC}$
$\mathbf{P}_{\mathrm{tl}}=-\frac{\mathrm{C}}{\mathrm{T}_{\mathrm{M}}} 2 \mathrm{Vdd}^{2}\left[\mathrm{e}^{-2.77}-1\right]=\frac{1.875 \mathrm{C} \mathrm{Vdd}^{2}}{\mathrm{~T}_{\mathrm{M}}}$
$\mathrm{P}=\mathrm{P}_{\mathrm{t} 1}+\mathrm{P}_{\mathrm{t} 2}=(1.875+1) \frac{\mathrm{C} \mathrm{Vdd}^{2}}{\mathrm{~T}_{\mathrm{M}}}=2.875 \frac{\mathrm{CVdd}^{2}}{\mathrm{~T}_{\mathrm{M}}}$
For a repetitive output from the CD4047A

$$
\mathrm{P}=\frac{2.875 \mathrm{C} \mathrm{Vdd}^{2}}{\mathrm{~T}_{\mathrm{M}}} \mathrm{x} \text { duty cycle }
$$

## ACKNOWLEDGMENTS

The assistance of R. Vaccarella in the designing of some of the application circuits shown and in obtaining laboratory measurements used in plotting the curves shown in this Note is acknowledged.

# Astable and Monostable Oscillators Using RCA COS/MOS Digital Amtegratea Circuits 

by J. A. Dean and J. P. Rupley

COS/MOS integrated logic circuits are being widely used in digital and other applications because of their inherent advantages of high noise immunity, extremely low power dissipation, and tolerance to wide variations in power-supply voltages and operating-temperature ranges. In addition to these features, COS/MOS gates and inverters can provide cost and size reductions in multivibrator circuits because their high input impedance makes it possible to obtain large time constants without the use of large capacitors. This Note describes several techniques which may be used to compensate for the normal threshold variation of MOS devices in the design of stable multivibrator circuits for operation at frequencies up to 1 MHz . The circuits shown can be formed by use of COS/MOS inverters and NAND or NOR gates connected in an inverter configuration. NAND and NOR gates perform the inverter function when all of the gate inputs are tied together. This Note also describes various applications for COS/MOS multivibrator circuits, (i.e., voltage-controlled oscillators, voltage controlled-pulse-width circuits, phased-locked voltage controlled oscillators, frequency multipliers, and modulator/ demodulator (envelope detectors). (Note: COS/MOS Hex Buffers CD4009A and CD4049A and Quad Buffer CD4041A are not recommended for use as multivibrators because of the very high power consumption in the linear mode for long time constants. In addition, the Hex Buffers have large imbalance between source and sink current capability which makes oscillator start-up more unpredictable. The COS/MOS General-Purpose Hex Inverter CD4069B is recommended for use in the multivibrator applications illustrated in this Note. The CD4069B is well adapted to MV applications, having balanced output drive capability of $\pm 0.4$ milliampere for 5 V operation at an output voltage level of $\pm 0.4$ volt. Specific data in this Note relate to the use of " A " series gates as shown; performance using the CD4069B may differ slightly from the data shown herein.

## ASTABLE CIRCUITS

Fig. 1(a) shows an astable multivibrator circuit that uses two COS/MOS inverters, and Fig. 1(b) shows the related waveforms. This simple circuit requires only two resistors and one capacitor, and operates in the following manner. When the waveform 1 at the output of inverter B is in a high or "one" state, capacitor $\mathrm{C}_{\mathrm{tc}}$ becomes charged positive. As a result, the input to inverter A is high and its output is low or "zero". Resistor $\mathrm{R}_{\mathrm{tc}}$ is returned to the output of inverter A to provide a path to ground for discharge of capacitor $\mathrm{C}_{\mathrm{tc}}$.

As long as the output of $A$ is low, the output of inverter $B$ is high. As capacitor $C_{t c}$ discharges, however, the voltage generated [waveform 2 in Fig. 1(b)] approaches and passes through the transfer voltage point of inverter A. At the instant that this crossover occurs, the output of A becomes high; as a result, the output of B becomes low and the capacitor $C_{t c}$ is charged negative (or low). The resistor $R_{t c}$ connected to the output of A then provides a charge path to a supply voltage. Capacitor $\mathrm{C}_{\mathrm{tc}}$ begins to charge to this voltage, and again the voltage approaches and passes through the transfer voltage point of inverter A. At that instant, the circuit again changes state (the output of A becomes low and that of $B$ high) and the cycle repeats.

Because of the input-diode protection circuits included in the COS/MOS IC, shown in Fig. 2, the generated drive waveform


Fig. 1 - Circuit diagram and voltage waveforms for astable multivibrator circuit that uses two COS/MOS inverters.
is clamped between $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$. Consequently, the time to complete one cycle is approximately 1.4 times the RC time constant because one time constant is used to control the switching of both states of the multivibrator circuit. Resistor $\mathrm{RX}_{\mathrm{X}}$ (Fig.1) limits the current through D1 (Fig.2) to a safe level. Switching occurs when the charge or discharge reaches the transfer voltage level, or when the time. period reaches 70.7 per cent of its discharge. As shown in waveform 2 of Fig.1(b), the transfer voltage point $\mathrm{V}_{\text {tr }}$ is the same for $t_{1}$ and $t_{2}$. The time period $T$ for one cycle can be computed as follows:
$T=t_{1}+t_{2}$
$\mathrm{t}_{1}=-\mathrm{RC} 1 \mathrm{n} \frac{\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{tr}}\right)}{\mathrm{V}_{\mathrm{DD}}}$

$$
\mathrm{t}_{2}=-\mathrm{RC}\left[\ln \frac{\mathrm{~V}_{\mathrm{tr}}}{\mathrm{~V}_{\mathrm{DD}}}\right]
$$

$$
\begin{equation*}
T=-R C\left[\ln \frac{\left(\mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{tr}}\right)}{\mathrm{V}_{\mathrm{DD}}}+\ln \frac{\mathrm{V}_{\mathrm{tr}}}{\mathrm{~V}_{\mathrm{DD}}}\right] \tag{1}
\end{equation*}
$$


92Cs-22871

Fig. 2 - Diode protection circuit.
If the time constant is assumed to be $1 \times 10^{-6}$ second and the transfer voltage $\mathrm{V}_{\mathrm{tr}}$ is allowed to vary from 33 to 67 per cent of $\mathrm{V}_{\mathrm{DD}}$,the period T varies from 1.4 microseconds at a value of $\mathrm{V}_{\mathrm{tr}}$ equal to half of $\mathrm{V}_{\mathrm{DD}}$ to 1.5 microseconds at either the 33 or 67 per cent value of VDD. Therefore, the maximum variation in the time period T is only 9 per cent with a $\pm 33$-per-cent variation in transfer voltage from unit to unit.

The oscillator can be made independent of supply-voltage variations by use of a large resistance in series with the input lead to inverter A, shown in Fig.3(a). This resistor $\mathrm{R}_{\mathbf{S}}$ should be at least twice as large as the resistor $R_{t c}$ of the time constant to allow the voltage waveform generated at the junction of $R_{s}, R_{t c}$, and $C_{t c}$ to rise to $V_{D D}+V_{t r}$. The waveform is still clamped at the input between $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$, as shown by the waveforms in Fig. 3(b). The use of resistor $R_{s}$
provides several advantages in the circuit. First, because the RC time constant controls the frequency, the over-all maximum variations in the time period are reduced to less than 5 per cent with variations in transfer voltage, as determined by the following equation:

$$
\begin{equation*}
\mathrm{T}=-\mathrm{RC}\left[\ln \frac{\mathrm{~V}_{\mathrm{tr}}}{\left(\mathrm{~V}_{\mathrm{DD}}+\mathrm{V}_{\mathrm{tr}}\right)}+\ln \frac{\left(\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{tr}}\right)}{2 \mathrm{~V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{tr}}}\right] \tag{2}
\end{equation*}
$$

The resistor $\mathrm{R}_{\mathrm{S}}$ also makes the frequency independent of supply-voltage variations. Table I shows data measured on typical units with and without the resistor

(a)
(1)

(2)

(3)

(4)

(b)

Fig. 3 - Addition of resistor in series with input to one COS/MOS inverter to make oscillator circuit independent of supply-voltage variations: (a) circuit diagram; (b) voltage waveforms.

Fig. 4 shows a typical transfer characteristic as a function of temperature. It can be seen that there is very little change in the characteristic from low to high temperature. Because the oscillator can also tolerate changes in the transfer characteristic without frequency instability, it requires no thermal compensation. The frequency at $-55^{\circ} \mathrm{C}$ is the same as at $+125^{\circ} \mathrm{C}$. Table II shows data measured on typical units at temperature extremes.

Table 1-Frequency variations of astable multivibrator with and without series resistor.

| Unit No. | $\begin{gathered} \mathrm{v}_{\mathrm{tr}}{ }^{\varrho} \\ \mathrm{v}_{\mathrm{DD}}=10 \mathrm{~V} \end{gathered}$(v) | Period Without Rs - (ms) |  |  | Period With Rs - (ms) |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{\mathrm{DD}}=6 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=14 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=6 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ | $\mathrm{V}_{\mathrm{DD}}=14 \mathrm{~V}$ |
| 2 | 4.71 | 0.735 | 0.66 | 0.645 | 1.04 | 1.00 | 1.02 |
| 6 | 5.78 | 0.715 | 0.665 | 0.63 | 1.06 | 1.04 | 1.03 |
| 11 | 5.58 | 0.695 | 0.66 | 0.625 | 1.03 | 1.02 | 1.03 |
| 13 | 5.00 | 0.70 | 0.665 | 0.64 | 1.03 | 1.01 | 1.02 |
| 20 | 5.56 | 0.70 | 0.665 | 0.64 | 1.04 | 1.03 | 1.03 |

$\mathrm{R}_{\mathrm{tc}}=0.4 \mathrm{megohm}, \mathrm{C}_{\mathrm{tc}}=1000 \mathrm{pF}, \mathrm{R}_{\mathrm{s}}=0.8 \mathrm{megohm}$


Fig. 4 - Transfer characteristic as a function of temperature.

The astable multivibrator shown in Fig. 1 can be gated on the off by use of a NOR gate as the first inverter, as shown in Fig. 5 .

Table II - Frequency variations of astable multivibrator at temperature extremes.

| Unit No. | Period - (ms) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mathrm{V}_{\text {DD }}=6 \mathrm{~V}$ |  | $\mathrm{V}_{\text {DD }}=10 \mathrm{~V}$ |  | $V_{D D}=14 \mathrm{~V}$ |  |
|  | ${ }^{-55^{\circ} \mathrm{C}}$ | $+125^{\circ} \mathrm{C}$ | $-55^{\circ} \mathrm{C}$ | $+125^{\circ} \mathrm{C}$ | ${ }^{-55^{\circ} \mathrm{C}}$ | $+125^{\circ} \mathrm{C}$ |
| 2 | 1.04 | 1.04 | 1.02 | 1.01 | 1.03 | 1.02 |
| 6 | 1.06 | 1.07 | 1.06 | 1.04 | 1.04 | 1.03 |
| 11 | 1.03 | 1.03 | 1.04 | 1.02 | 1.04 | 1.01 |
| 13 | 1.02 | 1.02 | 1.02 | 1.02 | 1.03 | 1.01 |
| 20 | 1.04 | 1.03 | 1.04 | 1.03 | 1.04 | 1.02 |

[^30]

Fig. 5 - Astable multivibrator in which a NOR gate is used as the first inverter to permit gating of the multivibrator. The NOR and NAND gates can also be reversed with suitable change in control polarity.

COMPENSATION FOR 50-PER-CENT DUTY CYCLES
The variation in transfer voltage described above affects the output-pulse duty cycle, as shown in Fig. 6. A true square-wave pulse is obtained only when the transfer voltage
$\odot$



(3)


Fig. 6-Waveforms showning effects of transfer voltage on multivibrator frequency.
occurs at the 50 -per-cent point. However, the duty cycle can be controlled if part of the resistance in the RC time constant is shunted out with a diode, as shown in Fig. 7. Because adjustment of this diode shunt to obtain a specific pulse duty factor causes the frequency of the circuit to vary, a frequency control $R_{3}$ is added to compensate for this variation. It may also be necessary to.reverse the diode to obtain the desired duty factor. The frequency of any of the circuits shown can be made variable by use of a potentiometer for resistor $\mathrm{R}_{\mathrm{tc}}$.


Fig. 7-Astable multivibrator in which a duty-cycle control is added.

## MONOSTABLE CIRCUITS

Basic Configuration. Fig. 8(a) shows a basic "one-shot" circuit that uses a single RC time constant. This circuit operates well provided it is adjusted to the particular COS/MOS unit used. If no adjustment is made, however, the period T can vary from unit to unit by as much as -40 per cent to +60 per cent if the transfer voltage varies by $\pm 33$ per cent, as shown by the waveforms in Fig. 8(b).


Fig. 8 - Basic one-shot multivibrator circuit: (a) circuit diagram; (b) waveforms.

Compensated Monostable Circuit. Fig. 9 shows a compensated monostable multivibrator type of circuit that can be triggered with a negative-going pulse ( $\mathrm{V}_{\mathrm{DD}}$ to ground). In the quiescent state, the input to inverter $A$ is high and the output low; therefore, the output of inverter B is high. When a negative-going pulse or spike is introduced into the circuit, as


Fig. 9 - Compensated monostable multivibrator circuit.
snuwn in the waveforms of Fig. 10, capacitor $C_{1}$ becomes negatively charged to ground and the output of inverter $A$ becomes high. Capacitor $\mathrm{C}_{2}$ then charges to $\mathrm{V}_{\mathrm{DD}}$ through the diode $D_{1}$ and inverter $A$, and the output of inverter $B$ becomes low. As capacitor $C_{1}$ discharges negatively, it charges through resistor $\mathrm{R}_{1}$ to $\mathrm{V}_{\mathrm{DD}}$ (waveform 2). The output of inverter A remains high until the voltage waveform generated by the charge of $C_{1}$ passes through the transfer voltage of inverter A ; at that instant its output becomes low. Diode $\mathrm{D}_{1}$ temporarily prevents the discharge of capacitor $\mathrm{C}_{2}$, which was charged when inverter A was high (waveform 3). Capacitor $C_{2}$ then commences to discharge to ground through resistor $R_{2}$ (waveform 4). The output of inverter $B$ remains low until the waveform generated by the discharge of $C_{2}$ passes through the transfer voltage point of inverter $B$; at that point the output returns to its high state (waveform 5).


Fig. 10 - Voltage waveforms for monostable multivibrator circuit when a negative-going trigger pulse is applied.

The advantage of using two gates connected as inverters fabricated on the same chip is that they have sintilar transfer voltages. When two equal RC time constants are used $\left(R_{1} C_{1}\right.$ equals $\left.R_{2} C_{2}\right)$, the effects of variations in transfer voltage from device to device are effectively cancelled out, as shown in Fig.11. By use of Eq.(1) derived for the astable oscillator, it can be shown that the maximum variation in the time period T is less than 9 per cent. The total time for one period $\mathrm{T}_{1}$ is approximately 1.4 times the $\mathrm{R}_{1} \mathrm{C}_{1}$ time constant.

Unlike the astable circuit, which shows no variation in frequency over the temperature range from $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$,


Fig. 11 - Waveíorms sinowing the cancelling effects of transfer-voltage variations of the two COS/MOS inverters when two equal time constants are used.
the monostable multivibrator shows some change in time period. The variation is less than 10 per cent. Table III shows data measured on five units over the temperature range. At $25^{\circ} \mathrm{C}$, the variation in the time period T from unit to unit is quite small, usually less than 5 per cent at a $V_{D D}$ of 10 volts.

The output from inverter $B$ can be held in the low or zero state as long as the $\mathrm{R}_{2} \mathrm{C}_{2}$ time constant is recharged by another triggering pulse before the discharge waveform it generates passes through the transfer voltage of inverter B.

Table III - Frequency variations of monostable multivibrator at three temperatures.

| Unit No. | Period @ $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}-(\mathrm{ms})$ |  |  |
| :---: | :---: | :---: | :---: |
|  | $-55^{\circ} \mathrm{C}$ | $+25^{\circ} \mathrm{C}$ | $+125^{\circ} \mathrm{C}$ |
|  | 1.06 | 1.08 | 1.00 |
| 6 | 1.015 | 1.03 | 0.99 |
| 11 | 1.00 | 1.02 | 0.98 |
| 13 | 1.01 | 1.03 | 0.97 |
| 20 | 1.02 | 1.02 | 0.99 |

$\mathrm{R}_{1}=\mathrm{R}_{2}=1$ megohm, $\mathrm{C}_{1}=\mathrm{C}_{2}=0.001 \mu \mathrm{~F}$

Diode $\mathrm{D}_{2}$ in Fig. 9 is internal to the COS/MOS-circuit. As discussed for the astable oscillator, it is part of the input protection circuit shown in Fig. 2, and serves to clamp the input at $V_{D D}$.

Figs. 12 and 13 show two variations of the monostable circuit, together with their associated waveforms. The circuit of Fig. 12 triggers on the negative-going excursions of the input pulse, in the same manner as the circuit of Fig. 9. The output pulse is positive-going and is taken from the first inverter. This circuit does not need an external diode. The circuit of Fig. 13 triggers on the positive-going excursion of the input pulse, and then locks back on itself until the RC time constants complete their discharge. The circuits of Figs. 12 and 13 cannot be retriggered until they return to their quiescent states.

(a)

(b)

Fig. 12 - Monostable multivibrator that is triggered by a negative-going input pulse: (a) circuit diagram; (b) waveforms.


Fig. 13 - Monostable multivibrator that is triggered by a positive-going input pulse: (a) circuit diagram; (b) waveforms.

Low-Power Monostable Circuit. The monostable circuits discussed thus far dissipate some power because one or both of the inverters are on during the charging or discharging of the RC time constants. This power dissipation will be extremely low provided the "one-shot" pulse width is short compared to the over-all cycle time. Fig. 14 shows the current waveform associated with the circuit of Fig. 9. This


Fig. 14 - Current waveforms for the diode-compensated multivibrator shown in Fig. 9.
waveform is quite wide at the base, and some current flows for approximately twice the time period. Fig. 15(a) shows a circuit using the CD4007A which dissipates much less power than the other circuits shown, but does not have the same stability. This circuit oderates as shown by the waveforms in Fig.15(b). In the quiescent state, the p-channel transistor of the first inverter is biased off, while the n-channel transistor (which derives its control from the output of the second inverter) is biased on. Therefore, the output at $C$ is low, and that at $D$ is high. When a negative-going pulse is introduced into the circuit through capacitor $C_{1}$, the $R_{1} C_{1}$ time constant becomes negatively charged, and the p-channel device is turned on. Capacitor $\mathrm{C}_{2}$ then charges to $\mathrm{V}_{\mathrm{DD}}$, the output at D becomes low, and the $n$-channel device of the first inverter is turned off. Capacitor $\mathrm{C}_{1}$ immediately begins to charge to $\mathrm{V}_{\mathrm{DD}}$ through $\mathrm{R}_{1}$ (waveform B ). The p-channel transistor remains on, keeping capacitor $C_{2}$ charged to $V_{D D}$, until the waveform generated passes through its threshold voltage level and turns it off. The n-channel transistor of the first inverter is still off because the output of the second inverter (waveform D ) is still low. When the p-channel device of the first inverter turns off, capacitor $C_{2}$ begins to discharge through resistor $R_{2}$ (waveform C) to ground. As it discharges, it passes through the threshold voltage of the second p -channel transistor so that it begins to turn on. The voltage waveform at $D$ then begins to rise, and the $n$-channel device of the first inverter turns on and provides a second discharge path for the capacitor $\mathrm{C}_{2}$. As a result, the output waveform changes state from low to high quite rapidly to complete the cycle.

The major advantage of the circuit of Fig. 15 is its low power dissipation. Because the circuit depends on the p-channel transistor threshold, the time period T varies from unit to unit or with temperature variations. Some compensation can


Fig. 15 - Low-power monostable multivibrator: (a) circuit diagram; (b) waveforms.
be provided if the $\mathrm{R}_{2} \mathrm{C}_{2}$ time constant is made approximately 3 times larger than the $\mathrm{R}_{1} \mathrm{C}_{1}$ time constant, as shown in Table IV.
Table IV - Frequency variations of monostable multivibrator with temperature when $\mathbf{R}_{2} \mathbf{C}_{\mathbf{2}}$ time constant is increased.

|  | Period with $V_{D D}=10 \mathrm{~V}-(\mu \mathrm{s})$ |  |  |
| :---: | :---: | :---: | :---: |
| Unit No. | $-55^{\circ} \mathrm{C}$ | $+25^{\circ} \mathrm{C}$ | $+125^{\circ} \mathrm{C}$ |
| 553 | 1090 | 1120 | 1160 |
| 554 | 1060 | 1090 | 1120 |
| 810 | 1030 | 1030 | 1020 |
| 900 | 1000 | 1020 | 990 |
| 939 | 1080 | 1100 | 1050 |

$R_{1}=0.35$ megohm, $C_{1}=0.001 \mu \mathrm{~F}$
$R_{2}=1$ megohm, $C_{2}=0.001 \mu \mathrm{~F}$
$\mathrm{R}_{2} \mathrm{C}_{2}$ is approximately 3 times the time constant $\mathrm{R}_{1} \mathrm{C}_{1}$
$\mathrm{R}_{3}=4700$ ohms

For minimum current in the circuit of Fig. 15, capacitor $\mathrm{C}_{2}$ can be removed so that only stray capacitance is present at the input of the second inverter. A comparison of timeperiod variations under this condition is shown in Table $V$. Again, the variations from unit to unit are caused by differences in p-channel transistor threshold.

Table V - Frequency variations of monostable multivibrator with temperature when $\mathrm{C}_{\mathbf{2}}$ consists of stray capacitance only.

|  | Period with $V_{D O}=10 \mathrm{~V} \cdot(\mu \mathrm{~s})$ |  |  |
| :---: | :---: | ---: | ---: |
| Unit No. | $.55^{\circ} \mathrm{C}$ | $+25^{\circ} \mathrm{C}$ | $+125^{\circ} \mathrm{C}$ |
| 553 | 870 | 940 | 1020 |
| 554 | 900 | 970 | 1050 |
| 810 | 900 | 1000 | 1080 |
| 900 | 810 | 880 | 960 |
| 939 | 780 | 850 | 920 |

$R_{1}=0.62 \mathrm{meg} \mathrm{ohm}, C_{1}=0.001 \mu \mathrm{~F}$

$$
R_{2}=1 \text { megohm }, C_{2}=\text { strays }
$$

## Applications

Fig. 16 shows a circuit similar to the circuit in Fig. 3a. $\mathrm{C}_{\mathrm{tc}}$ is variable (by adjustment of $\mathrm{C}_{\mathrm{X}}$ ) and $\mathrm{R}_{\mathrm{tc}}$ is variable (by adjustment of $\mathrm{V}_{\mathrm{A}}$ ). The value of $\mathrm{R}_{\mathrm{tc}}$ varies from $\approx 1 \mathrm{k} \Omega$ to $10 \mathrm{k} \Omega$. These limits are determined by the parallel combination of R1 ( $10 \mathrm{k} \Omega$ ) and the n-channel device resistance. This varies from $1 \mathrm{k} \Omega\left(\mathrm{R}_{\mathrm{ON}}\right)$ to $\approx 10^{9} \Omega$ ( $\mathrm{R}_{\mathrm{OFF}}$ ).

When $\mathrm{V}_{\mathrm{A}}=\mathrm{V}_{\mathrm{SS}}$, the n -channel device is "OFF" and $\mathrm{R}_{\mathrm{tc}}=\mathrm{R}_{\mathrm{OFF}} / / \mathrm{R} 1 \approx \mathrm{R} 1=10 \mathrm{k} \Omega$
because ROFF $\gg \mathrm{R} 1$.
When $\mathrm{V}_{\mathrm{A}}=\mathrm{V}_{\mathrm{DD}}$, the n-channel device is fully "ON.. and $\mathrm{R}_{\mathrm{tc}}=\mathrm{R}_{\mathrm{ON}} / / \mathrm{R1} \approx \mathrm{R}_{\mathrm{ON}}=1 \mathrm{k} \Omega$
because $\mathrm{R}_{\mathrm{ON}} \ll \mathrm{R} 1$.


NOTE:
INVERTERS AND $n-$ CHANNEL DEVICE ARE AVAILABLE IN A SINGLE COS/MOS PACKAGF:
CD4007A*
TYPICAL VALUES:

$$
R_{1}=10 \mathrm{k} \Omega \quad C_{X}=0.001-0.004 \mu \mathrm{~F}
$$

$$
R_{S}=100 \mathrm{k} \Omega \quad \hat{0} \leq V_{A} \leq V_{D D}
$$

* use proper suffix to denote package REQUIRED - SEE APPENDIX

Fig. 16 - Voltage-controlled oscillator.
The oscillator center frequency is varied by adjustment of $\mathrm{C}_{\mathrm{x}}$. Table VI shows a comparison of the period of the output wavetorm as a function of $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{A}}$.

Table VI - Period of Output as a function of Va and $\mathrm{V}_{\mathrm{DD}}$ V.C.O. of Fig. 16.

| Period ( $\mu \mathrm{sec}$ ) |  |  |  |
| :---: | :---: | :---: | :---: |
| $V_{A}$ | $V_{D D}=5 \mathrm{~V}$ | $V_{D D}=10 \mathrm{~V}$ | $V_{D D}=15 \mathrm{~V}$ |
| 0 | 120 | 54 | 48 |
| 5 | 115 | 45 | 41 |
| 10 | -- | 32 | 30 |
| 15 | -- | -- | 24 |

## Voltage-Controlled Pulse-Width Circuit

Fig. 17a shows a further modification of the circuit of Fig. 3a which modulates the pulse width (by varying $\mathrm{V}_{\mathrm{A}}$ ) only if $\mathrm{R}_{\mathbf{X}}$ is sufficiently high. As an example; if $\mathrm{C}=$ $0.0022 \mu \mathrm{~F}$, then $\mathrm{R}_{\mathrm{X}} \approx 35 \mathrm{k} \Omega$. Lower values of $\mathrm{R}_{\mathrm{X}}$ cause the frequency to be affected. If $R_{x}<10 \mathrm{k} \Omega$, there is a value of $\mathrm{V}_{\mathrm{A}}$ which will cause the oscillator to cut off. Table VII lists values of pulse width (B in Fig. 17b) for various values of $V_{A}$ and VDD. Fig. 17b shows the output waveform for the cịcuit described.


Fig. 17-(a) V.C. pulse-width circuit; (b) output waveform.

Table VII - Pulse Width as a Function of $V_{A}$ and VDD.

| $V_{A}$ | Pulse Width (B) $\mu \mathrm{sec}$ |  |  |
| :---: | :---: | :---: | :---: |
|  | $V_{D D}=5 \mathrm{~V}$ <br> Period-41.5 | $V_{\mathrm{DD}}=10 \mathrm{~V}$ <br> Period-35 | $V_{\mathrm{DD}}=15 \mathrm{~V}$ <br> Period-33 |
|  | 23 | 19.3 | 17 |
| 5 | 20 | 17.7 | 16.2 |
| 10 | -- | 16.2 | 15.5 |
| 15 | -- | --- | 14.3 |
| $C_{t \mathrm{C}}=0.0015 \mu \mathrm{~F}$ |  |  |  |

## Phase Locked VCO

The voltage controlled oscillator can be operated as a phase locked oscillator by the application of a frequency controlled voltage to the gate of the n-channel device. Fig. 18 shows the block diagram an FM discriminator using the phase locked VCO. Block $A$ is the same circuit as Fig. 16. The output of the phase comparator is fed to the gate of the n-channel device $\left(\mathrm{V}_{\mathrm{A}}\right)$. If the two inputs to the phase comparator are different, the change of $\mathrm{V}_{\mathrm{A}}$ causes the output frequency of the VCO to change. This change is divided by 2 N and fed back to the phase comparator.


Fig. 18 - VCO used in phase-locked loop.

## Frequency Multipliers

Fig. 19a shows a frequency doubler. A 2 N multiplier can be realized by cascading this circuit with $\mathrm{N}-1$ other identical circuits. The leading edge of the input signal is differentiated by R1 and C1, applied to the input No. 1 of the NAND gate, and produces a pulse at the output. The trailing edge of the input pulse, after having been inverted, is differentiated, applied to the input No. 2 of the NAND gate, and produces the second output pulse from the NAND gate. The waveforms for 5 points in the circuit are shown in Fig. 19b.


Fig. 19-(a) Frequency doubler schematic; (b) waveforms.

## Modulation/Demodulation (Envelope Detection).

Pulse modulation may be accomplished by use of the circuit shown in Fig. 20a. This circuit is a variation of Fig. 3. The oscillator is gated ON or OFF by the signal input No. 1 to the NAND gate. The waveforms are shown in Fig. 20b.

Demodulation or envelope detection of pulse modulated waves is performed by the circuit shown in Fig. 21a. The carrier burst is inverted (by Inverter A), and its first negative transition at point 2 , turns on the diode (D) to provide a charging path for $\mathrm{C}_{\mathrm{tc}}$ through the n-channel resistance to ground. On the positive transition of the signal (at point 2 ), the diode is cut off and $\mathrm{C}_{\mathrm{tc}}$ discharges through $\mathrm{R}_{\mathrm{tc}}$. The discharge time constant ( $\mathrm{R}_{\mathrm{tc}} \mathrm{C}_{\mathrm{tc}}$ ) is much greater than the time of the burst duration. Point 3, therefore, never reaches the switch point of inverter B until the burst has ended. The waveforms for 4 points in the circuit are shown in Fig. 21b.


Fig. 21 - (a) Demodulator circuit; (b) waveforms.


Fig. 20-(a) Modulator circuit; (b) waveforms.

# A COS／MOS PCM Telemetry and Remote Data Acquisition Design 

by A．Young and D．Block

## Introduction

The data explosion has brought with it a tremendous demand for acquisition stations capable of providing information to a central location for recording and processing．A particular challenge to designers is remote stations for geologic，oceano－ graphic，and space applications where high reliability of data must be combined with low power dissipation to conserve power supplies．

Pulse code modulation（PCM）and COS／MOS are an excellent combination for these applications since COS／MOS devices have inherently low standby and operational power requirements． The wide range of supply voltages（ 3 to 15 volts）from which COS／MOS circuits can operate reduces power－supply regulation requirements and，in addition，permits emergency power sourcing from convenient alternate supplies．PCM telemetry systems designed to work in severe electrical－noise environments can also benefit from the inherently high noise immunity of COS／MOS devices（typically 45 percent of the supply voltage）． Finally，both analog and digital data can be switched through COS／MOS devices；this feature allows convenient multiplexing and interfacing of the telemetry logic with the external world．

The wide range of circuits from simple gates to complex multiplexers and arithmetic units available as standard parts in the COS／MOS CD4000 family allows the realization of the functional elements of PCM telemetry systems with a minimum number of components．The ease of system design resulting from the availability of MSI functions and the tolerant nature of the COS／MOS devices can result in reduced design time and re－ liable system operation．For critical applications，COS／MOS parts are also available in Hi－Rel versions processed to MIL－STD－ 883 or MIL－STD－ 38510.

This note contains descriptive background material on tele－ metry systems plus examples of typical systems for both immediate and remote data conversion and transmission．Parts from the CD4000 family are used to show how various sections of the system may be realized in the general case．The exact configuration of any specific system would，of course，depend on the unique requirements of the application．

GENERAL CONCEPTS

## Format

The order in which data channels are sampled is of funda－ mental importance to the operation of the systems．This order－ ing of data is called the＂format．＂The smallest unit of digital data is a＂bit＂（either a logic 1 or logic 0 ）and the smallest number of bits handled as a single entity is called a＂word．＂The word length or number of bits in each word is determined by the accuracy with which analog information is to be converted to an equivalent digital word；the greater the accuracy the more bits required．Two types of words are used in a telemetry system： control words containing synchronization or parity bits and data words containing the actual information to be transmitted． Words are grouped together into frames．A frame contains one control word and an integral number of data words．The format， then，refers to the sequence of words within a frame．Fig． 1 shows a typical format of N words grouped into a frame．


## Information Transmission Rates

To accurately reconstruct at the receiver end of a telemetry system events occurring at the transmitting end，data must be sampled at a rate at least as fast as the fastest changing bit in the data word．Once this rate is determined，the bit rate to be trans－ mitted can be found from the following expression：

Bit Rate $=($ Word Length $)($ Frame Length $)($ Sampling Rate $)$

Thus, for a sampling rate (SR) of 100 samples per second (SPS), a frame length of 10 words, and a word length of eight bits, the bit rate (BR) is 8 kilobits per second (kBPS).

A disadvantage of the format in Fig. 1 is that it requires the sampling rate to be the same for each input. However, many applications have inputs which change at different rates, and for maximum efficiency a range of sampling rates is desirable. There are two techniques which may be used to accomplish sampling rate variation: subcommutation and supercommutation.
Slot


| Man Fiame | (d) |  |  |  |  |  |  |  | $\begin{aligned} & \text { Word } \\ & \text { Sliot } \\ & \frac{\text { Ftame Number }}{1} \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 |  |
|  | Sync | D1 | Subfiame Sync. | D3 | D4: | D1 | D5 | D6 |  |
| Subtrame | Sync | D1 | D2.s | D3 | D4b | D1 | D5 | DG | 2 |
| Subframe | Sync | D1 | D2b | D3 | D4a | D1 | D5 | D6 | 3 |
| Subframe | Sync | D1 | D2c | D3 | D4h | D1 | D5 | D6 | 4 |
| Man Frame | Sync | D1 | Subtrane Syme | D3 | D4. | D1 | D5 | D6 | 1 |


| Sync | D1 | Subframe <br> Sync | D3 | D4, | D1 | D5 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | D2d |  |  |  |  |  |
|  | D2b |  |  |  |  |  |
| D2c |  |  |  |  |  |  |

Fig. 2-(a) Supercommutation of channel D1 in word slots 2 and 6;
(b) subcommutation of word slots 3 and 5; (c) shorthand representation of (b).
In supercommutation, as shown in Fig. 2(a), data channels are repeatedly sampled within the same frame to obtain sampling rates that are multiples of the fundamental rate. For the format parameters shown, D1 is sampled at 200 samples per second, twice the fundamental rate. The process of supercommutation is equivalent to dividing the frame-length term of Eq. (1) by the number of repetitions of a given channel. Proper supercommutation requires that the word slots be evenly spaced in a frame.

Subcommutation, Fig. 3(b), is an alternate sampling of data channels from frame to frame to obtain sampling rates that are less than the fundamental rate. In Fig. 2(b), channel D2a is sampled every fourth frame, as are channels D2b, D2c, and the subframe sync channel. Channels D4a and D4b are sampled every other frame. Fig. 2(c) is a shorthand notation of this format. The process of subcommutation is equivalent to multiplying the frame-length term of Eq. (1) by the subcommutation length.

The entire data cycle (the smallest number of words that repeat periodically) is called a "subframe" and includes the main frame and subsequent frames. Subcommutation can be applied to more than one main frame word, but the number of subcommutations must have an integral relationship to all other subcommutation lengths. For example, subcommutation lengths of 2,4 and 16 in the same format are acceptable, but lengths of 2,8 and 10 are not because 10 is not an integral multiple of 8 . The maintenance of integral relationships in subcommutation assures the synchronization of subcommutated channels required for decommutation.

## A DESIGN EXAMPLE

## Format

Manipulation of the bit-rate, frame-length, and sub-frame-length parameters is required to obtain an optimum format from sampling rate requirements. Consider, for example, the requirements for transmitting 8 channels of analog information, identified as A1 through A8 in Fig. 3(a), and one


Fig. 3-(a) Format configuration 1; (b) format configuration 2.
channel of digital information (D1) where the required sampling rates are:
(a) 200 samples per second (SPS) for one analog channel
(b) 100 SPS for two analog and one digital channel
(c) 50 SPS for two analog channels
(d) 25 SPS for three analog channels

One solution would be to sample all channels at 200 SPS. This sampling rate meets the requirement of the most active channel at the cost of over-sampling the others. The resultant ten-word frame shown in Fig. 3(a) would require a bit rate of 16 kBPS for an eight-bit word length. This format is inefficient and results in having to record and process redundant data.

An alternate format, shown in Fig. 3(b), consists of eight $100-$ SPS main frame words with supercommutation and subcommutation used to generate alternate sampling rates. Supercommutation of word slots 2 and 6 produces a 200-SPS channel. Subcommutation of word slot 5 twice and slot 3 four times produces 50 - and $25-$ SPS channels, respectively. The bit rate required by this format is 6.4 kBPS or roughly one-third of that required by the previous format. The reduction is accomplished with only a small increase in programming hardware.

## System Hardware

A block diagram of the functions needed for the telemetry system of the design example above is shown in Fig. 4. The system includes both analog and digital multiplexers, an analog-to-digital converter and digital data-signal conditioner, a programmer, and an output formatter, synchronizer and serializer. The following sections discuss the implementation of these functions with standard COS/MOS CD4000-family parts.


Fig. 4-PCM telemetry system.

## Programmer

The Programmer provides basic timing and system synchronization by reducing the bit-rate clock timing to words, frames, and subframes. In general, counters and decoders are required to generate the format matrix column and row dimensions. The COS/MOS IC family includes several devices that aid in the design of format counters and decoders; one such device is the CD4018A, Presettable Divide-by-N Counter. One or more CD4018A's can provide a large selection of frame and subframe
lengths. The CD4017A (Decade Counter plus Ten Decoded Outputs) or the CD4022A (Divide-by-Eight Counter with Eight Decoded Outputs) may be used instead to generate 8 or 10 decoded states. The internal decoding of these devices greatly reduces the number of IC's required in the Programmer. The CD4024A, CD4040A, and CD4020A, 7,12 , and 14 -stage binary counters, respectively, can be used to generate longer binary frame/subframe lengths. Decoding of these counters can be performed by standard COS/MOS gates. The Programmer of Fig. 5 has been designed with six COS/MOS IC's.


Fig. 5-Programmer timing generation.

## Handling Analog Inputs

Analog input channels to the PCM system of Fig. 4 are switched to an A/D converter, and the resultant digital word transferred to a parallel-to-serial converter for serial readout. Synchronization of the A/D operation is explained below. Analog switching can be done with CD4066A transmission gates, as shown in Fig. 6. Switching of the gates is controlled by the word and frame counters properly decoded to generate the format of Fig. 3(b).


Fig. 6-Analog multiplexer.

The accurate conversion of analog inputs to digitally coded words is a major function of PCM systems. The logic required to control conversions using the successive approximation technique can be implemented with standard COS/MOS circuits. Also, the analog portion of the A/D converter can be simplified by the use of COS/MOS devices, depending upon the accuracy and speed required.

A COS/MOS A/D converter design using the successive approximation technique is shown in Fig. 7. A timing sequence to encode an analog input of 1.480 volts is given in Fig. 8. The converter works as follows. Operation is initiated by the programmer when the next word-slot is assigned to an analog input. At that time (SO) the A/D holding register is set to 1000000 (half scale). This action generates a reference voltage ( $\mathrm{V}_{\mathrm{R}}$ ) of 2.5 volts which is applied to comparator A1. The comparator output is zero if $\mathrm{V}_{\mathrm{R}}$ is greater than AMUX (AMUX is the sampled input voltage from the multiplexer), hence the D inputs to the register elements are zero. At time S1 the first flip-flop is clocked to zero and the second flip-flop is set to the one state. The resulting reference voltage ( 1.25 volts) is less than AMUX this time, and the comparator output goes to the one state. At time S2, the second flip-flop is clocked to one, and the third flip-flop is set to the one state. This procedure continues until all the bit weights have been considered for inclusion in the encoded word. For an 8 -bit system with a 5 -volt reference, the lowest discrete level of quantization is 19.6 millivolts, and the maximum theoretical accuracy is 0.4 percent. However, for the system shown in Fig. 7 where COS/MOS flip-flops drive a 200 -kilohm resistor ladder directly, an accuracy of 1.5 to 2 percent can be expected with conversion rates of approximately 10 kBPS . This encoder can handle the data requirements of most operational and surveillance applications as well as some experimental applications. The system can be made to operate more accurately if the impedance of the most significant bit (MSB) switches is reduced. This can be done by using CD4041 A low-impedance buffer units between the flip-flop outputs and the resistor ladder on the first two flip-flops. The CD4041A's have output impedances of less than 200 ohms at 5 volts, either sourcing or sinking current, and permit construction of an 8 -bit converter with a relative accuracy of one percent or less.

An alternate method of constructing the A/D converter so that analog signals both above and below ground can be handled is shown in Fig. 9. Here the CD4054A's are used as level shifters to convert the 0 - to +5 -volt levels from the holding register to -5 to +5 -volt signals to the resistor ladder. By connecting one end of the ladder to -5 volts, $\mathrm{V}_{\mathrm{R}}$ is allowed to range between -5 volts and +5 volts. By judicious choice of power supplies, analog voltages between $\pm 7.5$ volts could be accommodated using this scheme. (Another scheme for A/D conversion is given in reference 2.) The entire telemetry system could have been run with $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{SS}}=-5 \mathrm{~V}$; level translators would not then be necessary. However, to minimize overall dissipation (dynamic power is proportional to $\mathrm{V}^{2}$ ) the system was designed to operate with $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$.
$\mathrm{A} / \mathrm{D}$ converters are subject to numerous error sources, many of which are rather subtle. Temperature variation is one of the major causes of error. Changes as small as $10^{\circ} \mathrm{C}$ can cause an output variation equivalent to a quantizing level. Other sources of error which must be considered in a practical design include such parameters as sampling-rate variations, aperture time, interpolation errors, source impedance, and multiplexer leakage. Trade-offs between cost, size and power must also be made in determining the optimum system for a given application.

A timing diagram showing bit-timing assignments in relation to the A/D conversion cycle is shown in Fig. 8.


92CL-2 3362
Fig. 7-Successive-approximation $A / D$ converter.

## Handling Digital Inputs

In the most general case, the digital-word input to the PCM system could have logic levels degraded as the result of noise, offsets, or other causes, or it could consist of simple analog voltages to be quantized to single-bit resolution. In the latter case, the concern is only that the input voltage is above or below a given threshold. In the former case, comparison of the in-
put-voltage level against a reference would be used to re-establish solid logic one and zero-voltage levels. This process is referred to as "signal conditioning." Thus, Fig. 7 shows digital inputs being put through comparator A2 for conditioning and being stored in the A/D holding register. In the case of digital data, the ladder network hanging on the register is superfluous. Digital data is simply stored in this register for convenience (to avoid having to create a separate register and controls) and to keep timing and synchronization constant.


Fig. 8-A/D timing for encoding an analog input of 1.480 volts.


Fig. 9-Alternate $A / D$ analog section.


Fig. 10-Bit timing assignment.


Fig. 11-Digital multiplexing.

The digital input word is first multiplexed into a serial data stream using the CD4051A, as shown in Fig. 11. At time SO, the first flip-flop of the holding register is set to the 1 state, and will be conditionally reset depending on the output of comparator

A2 at the end of time SO. (Refer to the description of operation of the A/D converter for a more detailed explanation of this cycle.) The sequence is repeated for each bit until the entire word has been entered into the holding register.

## Data Output

At the appropriate time determined by the format, the output serializer gathers data from one of three sources: a data word from the A/D holding register, or control words from the main frame-sync word generator or the subframe-sync word generator. The 8 -bit parallel word is loaded into a CD4021A shift register, as shown in Fig. 12, at the end of bit period T7,
and then clocked out at the bit rate. To preserve the symmetry of the last bit period, a flip-flop is added to the end of the register. Selection of data to the register can be performed by a double rank of CD4019A's. Sync-bit patterns are normally fixed for a given system, and the bit lines are hand-wired to $\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\mathrm{SS}}$ in correspondence with the ones and zeros of the chosen sync pattern.

The output data can feed a computer directly or can modulate an rf carrier for telemetering to a distant data sink. ${ }^{2}$


Fig. 12-Sync and subframe sync word generator, output data formatter, and serializer.

## System Integration

A diagram of the entire PCM telemetry system of Fig. 4 is shown in Fig. 13; system timing is shown in Fig. 10.

## Remote Data Acqe-isition

Many industrial-control and data-management systems are not efficiently served by fixed-format PCM systems. Their requirements are better satisified by slaved-data acquisition subsystems in which data and control is provided on request, a method that substantially reduces redundant data and transmission rates and that provides control capability at remote locations. The PCM telemetry system previously described is adaptable to this form of operation. The implementation of the
logic of remote slaved-data acquisition systems with COS/MOS devices is desirable because the power consumption of the system is reduced significantly as the switching activity of the circuit decreases.

A slaved Programmer must include a channel address-register, data-request recognition logic, and output transfer-control logic. The format is defined by an external programming source and is not constrained by the acquisition system except for maximum channel capacity; format words-per-frame and frames-per-subframe counters are not necessary. The interface can range from a single wire to several parallel buses; Figure 14 shows a block diagram of a typical interface scheme. There are five control lines in the system: CLOCK, DATA REQUEST, REQUEST ACCEPTED, BUSY and DATA READY. A single, bi-directional line is used to send the desired channel address to the slaved programmer and to return the requested data.


Fig. 13-Diagram of PCM telemetry system of Fig. 4.

The block diagram in Fig. 15 shows the main functional units of the interface scheme of Fig. 14. A request is initiated by


Fig. 14-Slaved system.
applying a logic 1 to the DATA REQUEST line. The control logic services requests on a first-in-first-out basis, and ignores any requests initiated while it is in the BUSY state. When a request is initiated at a valid time, a REQUEST ACCEPTED pulse is generated, the BUSY line is set to 1 , and the input to the channel-address register is enabled for loading. After the channel-address
information is received, the requested data is digitized, the DATA READY line is set to 1 and the output data register is clocked onto the ADDRESS/DATA line. The control logic then resets itself, and the system is ready to acquire a new data word.

The implementation of a 16 -channel analog system using COS/MOS standard parts is shown in Fig. 16; the associated timing diagram is shown in Fig. 17. A DATA REQUEST sets the data-request flip-flop (REQUEST ACCEPTED) and enables the Clock and Address lines to the CD4015A channel-address register. When the CD4017A address bit-counter indicates that the address has been received, the DATA REQUEST flip-flop is reset, all inputs to the channel-address register are disabled, and one of the 16 input channels is switched to the converter through a CD4051A. The BUSY flip-flop, which was set by the REQUEST ACCEPTED signal, disables any further inputs until the cycle is completed.

A/D conversion can be performed as described above or in reference 2 . At the end of the A/D conversion period, the results of the conversion are loaded into a CD4021A shift register, and the DATA READY flip-flop is set. A CD4016A transmission gate is turned on by this signal, and the shift-register output to the ADDRESS/DATA line is enabled.A separate flip-flop is used to synchronize the output with the master clock, assuring that a full clock period is available for each bit. Output data is clocked onto the ADDRESS/DATA line and the clock pulses counted in a CD4017A counter to determine the end of the transfer time. At the end of this time period, the BUSY and DATA READY signals are cleared, and the control flip-flops and counters are reset for the next request.


Fig. 15-Slaved programmer.


Fig. 16-Channel-slaved programmer using COS/MOS standard parts.


Fig. 17-Slaved programmer timing diagram.

## Conclusions

The options available to the designers of data acquisition systems to meet operational requirements are as numerous as the applications for such designs. Features such as extended accuracy, sample-and-hold, selectable input levels, high data-input impedance, control outputs, limit checking, serial data acquisition, calibration-signal output, and digital data processing can be added to the basic system described here. The COS/MOS CD4000 integrated-circuit family provides features particularly suited to telemetry or related data-systems design, and the large number of standard parts available gives the designer consider-
able flexibility to achieve the goals of his application.

## References

1. "Design of Fixed and Programmable Counters Using the RCA CD4018A Presettable Divide-By-"N" Counter," J. Litus, Jr. RCA Application Note ICAN-6498.
2. A technique for generating and subsequently decoding biphase FSK is described in: "A Typical Data-Gathering and Processing System Using CD4000A-Series COS/MOS Parts"; D. Block, RCA Application Note ICAN-6210.

# Power Supplies for COS/MOS 

## D. Blandford

A. Bishop

Two of the major advantages of COS/MOS logic systems are their low power dissipation and ability to operate over a wide range of supply voltages. These features permit the use of simple, small, low-cost power supplies. Examples of various COS/MOS power-supply circuits and their relative costs are given in the following Note along with the factors important in their design. These examples are intended as a guide rather than the optimum design for a particular system.

## DESIGN EXAMPLES

Ten examples of power-supply circuits for use in COS/MOS logic systems are described below. The systems are employed in applications ranging from general-purpose, low-frequency types to those operating at high noise immunity and high frequency. The component values for each power-supply circuit are given for three system sizes, 20,50 , and 100 COS/MOS devices. It is assumed that each system is composed 60 per cent of gate circuits and 40 per cent of MSI circuits, although, as explained below in the section concerning design considerations, these proportions are, in general, not important.

## Low-Frequency Systems

The main requirement in a low-frequency $(50-\mathrm{kHz})$ system is low cost. A VDD of 5 volts yields a low supply current of 60 microamperes per device and a reasonable noise immunity of 1.5 volts in each logic state. This type of power supply, Fig. 1,


Fig. 1 - Power supply for a low-frequency system.
is used in general-purpose applications, such as digital instruments, remote monitoring equipment, and computer peripherals.
If higher noise immunity is required, for example, in an industrial-control application, a higher value of $\mathrm{V}_{\mathrm{DD}}$ would be needed. At 12 volts, the noise immunity is 3.6 volts in each logic state. Fig. 2 shows the circuit used in this type of application.


92cs-25121
Fig. 2 - Power supply yielding higher noise immunity than the circuit of Fig. 1.
If an application calls for the highest obtainable noise immunity, a $V_{D D}$ of 14.5 volts could be used. The minimum noise immunity in this case is 4.35 volts in each logic state. Operation at 14.5 volts causes an increase in power consumption and requires that the supply be regulated to ensure that the supply rail does not exceed the maximum rating of 15 volts. Fig. 3 shows the circuit for applications of this type.

## Mixed Systems of $\mathbf{2 - M H z}$ and $50-\mathbf{k H z}$ Circuits

10 per cent at $2 \mathrm{MHz}, 90$ per cent at 50 kHz . A nominal VDD of 10 volts is selected to enable most COS/MOS circuits to operate at toggle rates greater than 2 MHz , Fig. 4 .
50 per cent at $2 \mathrm{MHz}, 50$ per cent at 50 kHz . The simple zener-diode circuit shown in Fig. 5 is all that is required to provide the nominal 10 -volt supply, the power rating of the zener diode depends on the number of devices in the system.


Fig. 3 - Power supply yielding highest obtainable noise immunity.


Fig. 4 - Power supply for mixed system consisting of 10 per cent $2-\mathrm{MHz}$ and 90 per cent $50-\mathrm{kHz}$ COS/MOS circuits.


Fig. 5 - Power supply for mixed system consisting of 50 per cent $\mathbf{2 - M H z}$ and 50 per cent $50-\mathrm{kHz}$ COS/MOS circuits.

## COS/MOS System Powered by 5-Volt TTL Supply

COS/MOS circuits can be added to or mixed with TTL circuits in a system. The COS/MOS circuits can operate directly from the 5 -volt TTL power supply. At 50 kHz the supply current required by the COS/MOS circuit is only 60 microamperes per device, so that for $100 \mathrm{COS} / \mathrm{MOS}$ devices, the supply current required is only 6 milliamperes. This current is less than that required by a single TTL quad-gate device, so that the 100 device COS/MOS system can be added to an existing TTL power supply without the need to modify the supply.

## Battery-Powered Systems

COS/MOS circuits, with their low power consumption, are ideally suited for application in portable systems. The wide supply-voltage range permits operation from inexpensive, light-weight dry batteries, which may undergo a large change in voltage capacity from start to end of life. For example, a system containing twenty COS/MOS circuits operating at 10 kHz from three 1.5 -volt zinc-carbon dry cells consumes only 220 microamperes. The logic system would operate for more than a year before requiring a battery change.
Retention of data in a semiconductor memory when the main power supply is interrupted or turned off can easily be accomplished by using COS/MOS memory circuits and a standby battery. The battery used could be either a rechargeable nickel-cadmium type, as shown in the memory standby system of Fig. 6, or a dry battery. The memory system shown


Fig. 6 - Memory standby system.
is a 4 K by 8 bit system that uses the CD4061AD, 256 -bit RAM. The operating supply voltage is 10 volts, and at a 1 -microsecond cycle time, the supply current required is 50 milliamperes. The system power supply trickle-charges the standby battery during normal operation; for the system shown, recharge time is 35 hours. When the main power supply is turned off, the memory is powered by the standby battery. In the system shown, the 32 k -bit memory would be powered for approximately one week.
In portable applications requiring operation from a single battery cell, a dc-to-dc converter, Fig. 7, can be used to generate a higher voltage to power the COS/MOS circuits and, possibly, a liquid-crystal display.


Fig. 7 -DC-to-dc converter.

## DESIGN CONSIDERATIONS

The primary technical considerations in designing a power supply for a COS/MOS system are the required operating frequency, noise immunity, and power dissipation of the circuits in the system.

## Operating Frequency

Toggle frequency and propagation delay improve as the supply voltage of a COS/MOS circuit is increased, as shown in Figs. 8 and 9. This improvement occurs because the output resistance of the MOS transistors used in the COS/MOS circuits decreases with increased VDD while the output mode capacitance remains virtually unchanged, thus reducing the output time constant. The designer should ensure that the worst-case supply voltage is sufficiently high to yield the required switching speed. ${ }^{1}$


Fig. 8-Typical clock frequency versus supply voltage for the CD4013A.


Fig. 9 - Minimum propagation delay time versus supply voltage.

## Noise Immunity

The switching point of a COS/MOS circuit is typically half the supply voltage, $\mathrm{V}_{\mathrm{DD}}$, so that the noise immunity is typically 45 per cent of $\mathrm{V}_{\mathrm{DD}}$ in each logic state. Thus, an increase in VDD will cause a proportionate increase in noise immunity. ${ }^{2}$ The worst-case noise immunity is 30 per cent of VDD, as shown in Fig. 10. For example, if the required noise


Fig. 10 - Worst-case noise immunity versus supply voltage.
immunity is 1.5 volt in each logic state, then $V_{D D}$ should be 5 volts or more. Maximum noise immunity is obtained by operating with a 15 -volt supply, and is dependent upon maintaining good power-supply rail regulation during peak switching-current conditions. For example, a COS/MOS gate draws 10 milliamperes peak for approximately 50 nanoseconds during a switching mode for a 15 -volt supply.

It is good practice to keep the power-bus dynamic impedance low throughout the $\operatorname{COS} / \mathrm{MOS}$ system. In addition to good ground and supply-bus distribution, 0.01 -to 0.1 -microfarad ceramic capacitors should be distributed throughout the system and connected from VDD to VSS. As a general rule, a 0.01 -microfarad capacitor should be used for every four-gate package, and a 0.1 microfarad capacitor for every four MSI packages.

## Power Dissipation

The two previous sections explain the advantages of operating a COS/MOS system at high values of VDD. However, use of high supply voltages is accompanied by high power consumption. The total power consumed has two components, quiescent or dc power consumption, which increases approximately linearly with VDD, and switching or ac power consumption, which increases as $\mathrm{V}_{\mathrm{DD}}{ }^{2}$. Fig. 11 illustrates the typical dissipation of a COS/MOS device.


Fig. 11 - Typical dissipation of a CD4011A with a 15-picofarad load at 10 kHz versus supply voltage.
The expected power consumption of a given COS/MOS logic system can be calculated by summing the combinations of dc and ac power consumption of individual devices for expected values of supply voltage, operating frequency, and load capacitance. Generally, for a system larger than about ten devices, it should be sufficient to consider the typical values of power consumption.
A useful guide for calculating system power consumption is shown in Fig.12. This graph shows the average power


Fig. 12 - Average power dissipation of a CD4000A-series device versus frequency.
consumption per device (e.g., quad NAND, counter, shiftregister) versus frequency for various supply voltages at a practical loading of 50 picofarads. For example, assume that the power consumption for a mixture of 100 CD4000A circuits at a $V_{D D}$ of 5 volts and an operating frequency of 50 kHz is desired. From Fig. 12, the dissipation per device is 300 microwatts, so that the total system dissipation is 30 milliwatts for a supply current of 6 millamperes (see practical circuit, Fig. 1). In this example, the dc power is not significant and would typically total less than 1 milliwatt.
If a more accurate value of the system power consumption is required, the contributions from each device may be calculated and summed to give the total. To do this, the value of quiescent dissipation given in the data sheet for the device is used together with the value of ac dissipation. The latter value is taken from the data-sheet graph of dissipation versus frequency at 15 -picofarads load. The value obtained is valid for three loads or less; for more than three loads, Fig. 13 is


Fig. 13 - Power dissipation per load of 5 picofarads as a function of frequency.
used to determine the power dissipation contributed by the extra loads. For example, assume that the power consumption of a CD4011AE NAND gate at a $\mathrm{V}_{\mathrm{DD}}$ of 5 volts and a frequency of 1 kHz with seven loads is desired. From the data sheet, the quiescent power dissipation $\mathrm{PQ}_{\mathrm{Q}}$ is 25 nanowatts. The dynamic dissipation $\mathrm{P}_{\mathrm{D}}$ for a 15 -picofarad load is given in the data sheet as 700 nanowatts. From Fig. 13 the power dissipation PXL for the four extra loads is 500 nanowatts, so that the total power dissipation $\mathrm{P}_{\mathrm{T}}$, where $\mathrm{P}_{\mathrm{T}}=\mathrm{P}_{\mathrm{Q}}+\mathrm{P}_{\mathrm{D}}+$ $\mathrm{P}_{\mathrm{XL}}$, is 1225 nanowatts or approximately 1.2 microwatts.
Certain circuits require additional consideration because of their higher than normal power consumption. Such cases include gate circuits having slow input rise and fall times, as shown in Fig. 14. Examples of this type of circuit are RC monostable or astable circuits, and gate circuits with inputs at the end of long transmission lines. Circuits driving large capacitive loads, such as long transmission lines or the clock inputs of non-complementary MOS shift registers, are also representative of circuits with above-normal power consumption. Higher power consumption can also occur at the interface between COS/MOS circuits and transistor drivers, other logic families, and digital displays.


Fig. 14 - Power dissipation as a function of transistion time for a CD4049A.

## Regulation

The regulation of a COS/MOS power supply should be designed to maintain VDD at a value equal to or greater than the value needed to obtain the required switching speed and noise immunity and less than either the maximum VDD rating of 15 volts or the maximum VDD required to yield a specific, expected, over-all power-dissipation rating, whichever is lower. The regulator circuit must also suppress any voltage transients that might cause the supply to exceed 15 volts.

## REfERENCES

1. For more information on switching speed see the CD4000A-family data sheets, which contain graphs of switching speed as a function of VDD.
2. A precise definition of noise immunity is given in the RCA Solid-State DATABOOK Series SSD-203, "COS/MOS Digital Integrated Circuits".

# Design of Fixed and Programmable Counters Using the RCA CD4018A C0S/MOS Presettable Divide -by-"N"Counter 

by J. Litus Jr.

The RCA CD4018* COS/MOS (ComplementarySymmetry Metal-Oxide-Semiconductor) presettable divide-by-" N " counter is designed for use in digital equipment where low power dissipation, low package count, and high noise immunity are primary design requirements. The counter is particularly useful in such systems applications as channel-preset counters in digital frequency synthesizers and
*Supplied in plastic dual-in-line package as the CD4018AE, in ceramic dual-in-line package as the CD4018AD and in ceramic flat-pack as the CD4018AK.
program-counter control. TheCD4018Acan also be used as a 5 -stage parallel input/output holding register. In this application the parallel entry can be controlled by the preset-enable line to perform a 5 -stage "latch" operation. This Note describes the use of theCD4018Ain single-decade and multi-decade fixed and programmable divide-by-" N " counters. System considerations such as switch simplifications, components minimization, and speed are also discussed.

The logic diagram for theCD4018Ais shown in Fig. 1. Fig. 2 shows the counting sequence and timing diagram for this device connected as a decade counter.


Fig. 1 - Logic diagram for CD4018A.

| Count | $\overline{\mathrm{a}}_{1}$ | $\overline{\mathrm{a}}_{2}$ | $\overline{\mathrm{Q}}_{3}$ | $\overline{\mathrm{Q}}_{4}$ | $\overline{\mathrm{Q}}_{5}$ |
| :---: | :--- | :--- | :--- | :--- | :--- |
| 0 | 1 | 1 | 1 | 1 | 1 |
| 1 | 0 | 1 | 1 | 1 | 1 |
| 2 | 0 | 0 | 1 | 1 | 1 |
| 3 | 0 | 0 | 0 | 1 | 1 |
| 4 | 0 | 0 | 0 | 0 | 1 |
| 5 | 0 | 0 | 0 | 0 | 0 |
| 6 | 1 | 0 | 0 | 0 | 0 |
| 7 | 1 | 1 | 0 | 0 | 0 |
| 8 | 1 | 1 | 1 | 0 | 0 |
| 9 | 1 | 1 | 1 | 1 | 0 |

(a)

(b)

Fig. 2-(a) counting sequence for decade-counter operation; (b) timing diagram for decade-counter operation.

The CD4018A consists of five flip-flops that can be connected as a five-, four-, three-, or two-stage Johnson Counter with buffered $\overline{\mathbf{Q}}$ outputs from each stage. Gating is included for presetting the counter. "Clock", "Reset", "Data", "Preset-Enable", and five "Jam" inputs are also provided. The counter is advanced one count at the positive-going transition of the clock. A "high" Reset signal clears the counter to an "all-zero" ( $\overline{\mathrm{Q}}$ outputs are all "ones") condition, and a "high" Preset Enable signal allows information on the Jam inputs to preset the counter.

## FIXED SINGLE-STAGE DIVIDE-BY-"N" COUNTERS

Divide-by-10, $8,6,4$, or 2 counter configurations can be implemented by feeding the $\overline{\mathrm{Q}} 5, \overline{\mathrm{Q}} 4, \overline{\mathrm{Q}} 3, \overline{\mathrm{Q}} 2$, or $\overline{\mathrm{Q}} 1$ signals, respectively, back to the Data input. Divide-by-9, 7, 5, or 3 counter configurations can be implemented by the use of NOR- or NAND- gate packages to gate the proper feedback connection to the Data input line. Fig. 3 shows the feedback connections for divide-by- $9,7,5$, and 3 functions using the CD4011A NAND gate as the feedback circuit.

DIVIDE BY 10
DIVIDE BY 8 DIVIDE BY 6 DIVIDE BY 4 DIVIDE BY 2


DIVIDE BY 9


DIVIDE BY 7


DIVIDE BY 3


Fig. 3-External connections for divide by $10,9,8,7,6,5$, 4,3, and 2 operation.

Fig. 4 shows the divide-by-seven configuration in detail. The logic diagram and pertinent waveforms are shown in Figs. 4 a and b . Fig. 4 c shows the counting sequences for a divide-by-eight and a divide-by-seven configuration. Division


| Count | $\overline{\mathrm{Q}}_{1}$ | $\overline{\mathrm{Q}}_{2}$ | $\overline{\mathrm{Q}}_{3}$ | $\overline{\mathrm{Q}}_{4}$ |
| :--- | :--- | :--- | :--- | :--- |
| 0 | 1 | 1 | 1 | 1 |
| 1 | 0 | 1 | 1 | 1 |
| 2 | 0 | 0 | 1 | 1 |
| 3 | 0 | 0 | 0 | 1 |
| 4 | 0 | 0 | 0 | 0 |
| 5 | 1 | 0 | 0 | 0 |
| 6 | 1 | 1 | 0 | 0 |
| 7 | 1 | 1 | 1 | 0 |


| Count | $\overline{\mathrm{Q}}_{1}$ | $\overline{\mathrm{Q}}_{2}$ | $\overline{\mathrm{Q}}_{3}$ | $\overline{\mathrm{Q}}_{4}$ |
| :---: | :--- | :--- | :--- | :--- |
| 0 | 1 | 1 | 1 | 1 |
| 1 | 0 | 1 | 1 | 1 |
| 2 | 0 | 0 | 1 | 1 |
| 3 | 0 | 0 | 0 | 1 |
| 4 | 1 | 0 | 0 | 0 |
| 5 | 1 | 1 | 0 | 0 |
| 6 | 1 | 1 | 1 | 0 |

(c)

Fig. 4.CD4018A in a fixed divide-by-7 counter configuration: ${ }^{\prime}$ (a) logic diagram; (b) timing waveforms; (c) counting sequences for $a \div 8$ and $a \div 7$ Johnson Counter.
of the clock frequency by seven is accomplished by altering the counting sequence so as to skip the "all zeros" state of a divide-by-eight counter. The divide-by-seven counting sequence proceeds as in a normal 4 -stage Johnson counter until count 3 (0001) at which point $\overline{\mathrm{Q}} 3=0$ and $\overline{\mathrm{Q}} 4=1$. At this point theCD4011Agates $\overline{\mathrm{Q}} 3$ and $\overline{\mathrm{Q}} 4$ to put a 0 on the Data input to the first stage. Thus, count 4 will be 1000 instead of 0000 as in the unaltered divide-by-ight sequence. The remainder of the counting sequence proceeds in the normal 4 -stage manner.

## PROGRAMMABLE MULTI-DECADE DIVIDE-BY-"N" COUNTERS

The CD4018Ais especially useful in applications requiring low-power, programmable, divide-by-" N " counting. Two such applications are channel preset counters in digital frequency synthesizers and program counter control.

Fig. 5 illustrates the use of three CD4018 units in a programmable divide by " N " counter, where " N " may be any number from 2 to 999 (counter output is equal to clock frequency divided by N ). Extension to higher " N " ranges is readily accomplished by the use of additional CD4018 units. The counter is preset to the value of " N " via the three selector switches. The switches are arranged so that switch position 9 is equivalent to a " 0 " count in the counter, position 8 is equivalent to a " 1 " count, position 7 to a " 2 " count, etc. The counter counts up from the preset value (the N value) to its maximum count (999) and recycles, starting again from the preset value. Fig. 5b shows the counting sequence; oscillograph photographs of the waveform. at various points in the circuit (of Fig. 5a) are shown in Fig. 5c. Fig. 5d shows the N -counter output for various values of N .

The Johnson-Counter configuration utilized in the CD4018A design permits significantly simpler "programswitch" ("N"-Select) implementation than is required in systems that use a BCD decade counter arrangement. The program switch is composed of three standard single-wafer switches, one for each CD4018A (one per decade). This compares with a four-wafer (4-pole) switch per decade for a BCD decade-counter arrangement. Also, the count decoding is much simpler in that only two outputs perCD4018Amust be decoded as compared to four for a BCD arrangement. The Johnson-type counter can also operate at higher speeds and provides spike-free decoded outputs.

The configuration shown in Fig. 5 permits frequency division by 2 as a result of performing the Preset function during half a clock cycle. In this mode the maximum allowable frequency of operation is reduced, however. If this reduction in frequency is not acceptable, the logic diagram shown in Fig. 6 can be employed. In this circuit the Preset function is allowed a full clock cycle but the range of frequency division is reduced to 3 to 999 . The counting sequence and pertinent timing waveforms for this circuit are shown in Figs. 6b, c, and d, respectively. Typical maximum operating frequency is 4 megahertz, for the counter in Fig. 5 and 6 megahertz for the counter in Fig. 6.


FIRST DECADE
(UNITS)

| SW. <br> POS. <br> N |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |  |
| Count | $\overline{\mathrm{Q}}_{1}$ | $\overline{\mathrm{Q}}_{2}$ | $\overline{\mathrm{Q}}_{3}$ | $\overline{\mathrm{Q}}_{4}$ | $\overline{\mathrm{Q}}_{5}$ |  |
| 9 | 0 | 1 | 1 | 1 | 1 | 1 |
| 8 | 1 | 0 | 1 | 1 | 1 | 1 |
| 7 | 2 | 0 | 0 | 1 | 1 | 1 |
| 6 | 3 | 0 | 0 | 0 | 1 | 1 |
| 5 | 4 | 0 | 0 | 0 | 0 | 1 |
| 4 | 5 | 0 | 0 | 0 | 0 | 0 |
| 3 | 6 | 1 | 0 | 0 | 0 | 0 |
| 2 | 7 | 1 | 1 | 0 | 0 | 0 |
| 1 | 8 | 1 | 1 | 1 | 0 | 0 |
| 0 | 9 | 1 | 1 | 1 | 1 | 0 |

SECOND DECADE
(TENS)

| SW. <br> POS. <br> N |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :--- |
|  |  |  |  |  |  |  |
| 9 | 0 | 1 | 1 | 1 | 1 | 1 |
| 8 | 1 | 0 | 1 | 1 | 1 | 1 |
| 7 | 2 | 0 | 0 | 1 | 1 | 1 |
| 6 | 3 | 0 | 0 | 0 | 1 | 1 |
| 5 | 4 | 0 | 0 | 0 | 0 | 1 |
| 4 | 5 | 0 | 0 | 0 | 0 | 0 |
| 3 | 6 | 1 | 0 | 0 | 0 | 0 |
| 2 | 7 | 1 | 1 | 0 | 0 | 0 |
| 1 | 8 | 1 | 1 | 1 | 0 | 0 |
| 0 | 9 | 1 | 1 | 1 | $\bar{Q}_{1}$ | $\bar{Q}_{2}$ |

THIRD DECADE
(HUNDREDS)

| $\begin{array}{\|c\|} \hline \text { SW. } \\ \text { POS. } \\ \mathrm{N} \\ \hline \end{array}$ | Count | $\mathrm{a}_{1}$ | $\mathrm{O}_{2}$ | $\mathrm{a}_{3}$ | $\overline{\mathrm{a}}_{4}$ | $\overline{\mathrm{a}}_{5}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 9 | 0 | 1 | 1 | 1 | 1 | 1 |
| 8 | 1 | 0 | 1 | 1 | 1 | 1 |
| 7 | 2 | 0 | 0 | 1 | 1 | 1 |
| 6 | 3 | 0 | 0 | 0 | 1 | 1 |
| 5 | 4 | 0 | 0 | 0 | 0 | 1 |
| 4 | 5 | 0 | 0 | 0 | 0 | 0 |
| 3 | 6 | 1 | 0 | 0 | 0 | 0 |
| 2 | 7 | 1 | 1 | 0 | 0 | 0 |
| 1 | 8 | 1 | 1 | 1 | 0 | 0 |
| 0 | 9 | 1 | 1 | 1 | 1 | $0{ }^{*}$ |

"These digits, representative of count " 9 " in each decade, are decoded to give the preset strobe


Fig. 5 - Three-decade, programmable, divide-by-" $N$ " counter with frequency division from 2 to 999: (a) logic diagram; (b) counting sequence; (c) timing waveforms at various points in the circuit (d) $\div N$ output for various values of $N$.

(a) LOGIC DIAGRAM

FIRST DECADE
(UNITS)

| SW. <br> POS. |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| N | Count | $\overline{\mathrm{Q}}_{1}$ | $\overline{\mathrm{O}}_{2}$ | $\overline{\mathrm{Q}}_{3}$ | $\overline{\mathrm{Q}}_{4}$ | $\overline{\mathrm{Q}}_{5}$ |
| 9 | 0 | 1 | 1 | 1 | 1 | 1 |
| 8 | 1 | 0 | 1 | 1 | 1 | 1 |
| 7 | 2 | 0 | 0 | 1 | 1 | 1 |
| 6 | 3 | 0 | 0 | 0 | 1 | 1 |
| 5 | 4 | 0 | 0 | 0 | 0 | 1 |
| 4 | 5 | 0 | 0 | 0 | 0 | 0 |
| 3 | 6 | 1 | 0 | 0 | 0 | 0 |
| 2 | 7 | 1 | 1 | 0 | 0 | 0 |
| 1 | 8 | 1 | 1 | 1 | 0 | 0 |
| 0 | 9 | 1 | 1 | 1 | 1 | 0 |

SECOND DECADE (TENS)

| $\begin{gathered} \text { SW. } \\ \text { POS. } \\ \mathrm{N} \end{gathered}$ | Count | $\overline{\mathrm{Q}}_{1}$ | $\overline{\mathrm{O}}_{2}$ | $\overline{\mathrm{a}}_{3}$ | $\overline{\mathrm{a}}_{4}$ | $\overline{\mathrm{Q}}_{5}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 9 | 0 | 1 | 1 | 1 | 1 | 1 |
| 8 | 1 | 0 | 1 | 1 | 1 | 1 |
| 7 | 2 | 0 | 0 | 1 | 1 | 1 |
| 6 | 3 | 0 | 0 | 0 | 1 | 1 |
| 5 | 4 | 0 | 0 | 0 | 0 | 1 |
| 4 | 5 | 0 | 0 | 0 | 0 | 0 |
| 3 | 6 | 1 | 0 | 0 | 0 | 0 |
| 2 | 7 | 1 | 1 | 0 | 0 | 0 |
| 1 | 8 | 1 | 1 | 1 | 0 | 0 |
| 0 | 9 | 1 | 1 | 1 | 1 | 0 |

THIRD DECADE (HUNDREDS)

| $\left.\begin{gathered} \text { SW. } \\ \text { POS. } \\ \mathrm{N} \end{gathered} \right\rvert\,$ | Count | $\overline{\mathrm{O}}_{1}$ | $\overline{\mathrm{a}}_{2}$ | $\overline{\mathrm{a}}_{3}$ | $\mathrm{a}_{4}$ | $\overline{\mathrm{O}}_{5}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 9 | 0 | 1 | 1 | 1 | 1 | 1 |
| 8 | 1 | 0 | 1 | 1 | 1. | 1 |
| 7 | 2 | 0 | 0 | 1 | 1 | 1 |
| 6 | 3 | 0 | 0 | 0 | 1 | 1 |
| 5 | 4 | 0 | 0 | 0 | 0 | 1 |
| 4 | 5 | 0 | 0 | 0 | 0 | 0 |
| 3 | 6 | 1 | 0 | 0 | 0 | 0 |
| 2 | 7 | 1 | 1 | 0 | 0 | 0 |
| 1 | 8 | 1 | 1 | 1 | 0 | 0 |
| 0 | 9 | 1 | 1 | 1 | 1 | 0 |

NOTE: " $N$ " IS SELECTED BY DIALING IN THE DESIRED PRESET COUNT INDICATED BY THE SWITCH SETTINGS: THE " 9 " COUNTS FROM THE SECOND AND THIRD DECADE (SHOWN AS 1 [0] I ARE GATED WITH THE " 7 " COUNT (SHOWN AS $1[0$ ) FROM THE FIRST DECADE TO ACTIVATE THE "PRESET ENABLE", ONCE PER COUNTER CYCLE.
(b)

(c)

(d)

Fig. 6 - Three-decade, programmable, divide-by-" $N$ " counter with frequency division from 3 to 999: (a) logic diagram; (b) counting sequence; (c) timing waveforms at various points in the circuit; (d) divide-by-N output for various values of $N$.

## PROGRAM-SWITCH ("N"-SELECT) OPTIONS

Fig. 7a is a detailed drawing of a standard Centralab 12-position wafer switch and the associated resistor network as used in Fig. 5a. The resistors connected to VDD are required to prevent floating inputs on the "JAM" lines. In applications that require lower power dissipations or where component count or space considerations become important, the resistor network can be eliminated by the redesign of the switch. Two such options are shown in Figs. 7b and 7c.

As previously mentioned in the discussion of Fig. 5, the range of N can be extended by adding moreCD4018A units. In addition to this type of expansion each stage in the programmable divide-by- N counter can be designed to count to any base or radix. For example, the single stage divide-by-seven counter of Fig. 4 may be used as each stage in a multi-stage programmable counter.


(c)

Fig. 7-Switch configurations; (a) single wafer (standard) per decade; (b) two wafers (modified standard) per decade; (c) single wafer (nonstandard) per decade.

## SUMMARY

The RCA-CD4018A is a versatile counter. Because of the Johnson-Counter design employed, This device permits the design of simple decoding and preset switching circuits. The system can also operate at higher speeds and with much less power dissipation than a comparable BCD decade counter arrangement. Also the CD4018A, a COS/MOS device, possesses all the inherent advantages of this technology.

This versatile device can be used in fixed or programmable divide-by-" N " counters where " N " can vary from two to ten for a single CD4018A and greater than ten for multiple CD4018A stages. From an economical viewpoint, its versatility and low power requirement at high speeds make the RCA-CD4018A the logical choice for counter applications in control and frequency synthesization equipments.

# Power-Supply Considerations for COS/MOS Devices 

by H.L. Pujol

RCA COS/MOS Digital Integrated Circuits operate at extremely low power dissipation levels. They function reliably with high noise immunity over a wide operatingvoltage range. The RCA-CD4000A COS/MOS product line is designed to operate from 3 to 15 volts, which enables system designers to operate RCA COS/MOS devices from unregulated, poorly-filtered supplies, or from a wide variety of single- or multiple-cell battery sources.

This Note describes the salient features of COS/MOS devices which permit operation from such a wide range of power sources and provides the system designer with the necessary information to permit him to design the most economical power source for his COS/MOS system. This Note is applicable to both COS/MOS product lines mentioned above.


Fig. 1- Cross-section of COS/MOS transistor.

## CHARACTERISTICS OF A BASIC COS/MOS <br> LOGIC INVERTER

## Quiescent Device Dissipation.

The basic logic inverter (or gate) formed by use of only a $p$ - and an n-type device in series is shown schematically in Fig. 2. When the input lead is grounded or otherwise connected to 0 volts (logical ' 0 '), the n -device is cut-off, and the p-device is biased on. As a result, there is a low-impedance path from the output to $\mathrm{V}_{\mathrm{DD}}$, and an open circuit to ground. The resultant output voltage is essentially $\mathrm{V}_{\mathrm{DD}}$, or a logic " 1 ".

Similarly, when the input voltage is a logic " 1 ", or $\mathrm{V}_{\mathrm{DD}}$, then the n-channel device becomes a low impedance, while the p-channel device becomes an open circuit. The resultant output becomes essentially zero volts (logic " 0 ").


Fig. 2- Basic COS/MOS inverter (schematic).

Note that one of the devices is always cut-off at either logic extreme, and that no current flows into the insulating gates. As a result, the inverter quiescent power dissipation is negligible (equal to the product of $\mathrm{V}_{\mathrm{DD}}$ times the leakage current).

A cross section of the COS/MOS inverter as it is formed in an integrated circuit on an n-type substrate is illustrated in Fig. 1. The source-drain diffusions and the p-well diffusion form parasitic diodes (in addition to the desired transistors) at the basic inverter nodes, as shown in Fig. 3. These parasitic elements are back-biased (across the power supply) and contribute, in part, to the device leakage current and thus to the quiescent power dissipation.


Fig. 3- Basic inverter showing parasitic diodes.

RCA's product line of COS/MOS devices consists of circuits of varying complexity (i.e., from the dual 4 -input logic gate that contain 16 MOS devices, to the more complex 64-bit static shift registers that contain over 1000 devices). These devices occupy different amounts of silicon area and are composed of varying numbers of circuits formed from inverters. Consequently, each device in the family exhibits a particular magnitude of leakage current, depending upon the total effect of device count and parasitic diode area. For example, some logic gates are specified to operate with a typical power dissipation of $5 \mathrm{nW}\left(\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}\right)$, but 7-stage counters or registers are specified to operate with a typical power dissipation of $5 \mu \mathrm{~W}\left(\mathrm{~V}_{\mathrm{DD}}=10 \mathrm{~V}\right)$. Published data includes both typical device quiescent-current levels and maximum levels ( $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$ ). The maximum values are rarely encountered in RCA devices.

## Device - Switching Characteristics.

The input/output characteristics for the COS/MOS inverter are shown in Fig. 4. As mentioned earlier the signal extremes at the input and output are approximately zero volts (logic " 0 ") and VDD (logic " 1 "). The switching point is shown to be typically 45 to $55 \%$ of the magnitude of the power-supply voltage (regardless of the magnitude of the power-supply voltage) over the entire range from 3 to 15 volts. Note the negligible change in operating point from $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$.

These excellent switching characteristics permit COS/ MOS devices to be operated reliably over a wide range of voltages, a property not found in other logic forms.

## AC Dissipation Characteristics.

During the transition from a logic " 0 " to a logic " 1 ", both devices are momentarily on. This condition results in a pulse of instantaneous current being drawn from the power supply. The magnitude and duration of this current depends upon the following factors:
(a) the impedance of the particular devices being used in the inverter circuit
(b) the magnitude of the power-supply voltage
(c) the magnitude of the individual device threshold voltages
(d) the input driver rise and fall times


Fig. 4- Typical COS/MOS transfer characteristics as a function of temperature.

An additional component of current must also be drawn from the power supply to charge and discharge the internal parasitic node capacitances and the load capacitances seen at the output.

The device power dissipation which results from the above current components is a frequency-dependent parameter. The more often the circuit switches, the greater is the resultant power dissipation. The heavier the capacitive loading, the greater is the resultant power dissipation. The power dissipation is not duty-cycle dependent. For all intents and purposes it may be considered frequency (repetition-rate) dependent.

Because the RCA COS/MOS product line ranges widely in circuit complexity from device to device, the ac device dissipations vary widely from device to device. The effect of capacitive loading on the individual devices also varies. Figs. 5 and 6 show a family of curves for a typical gate device and a typical MSI device. These curves, from the published data for the individual devices, illustrate how device power dissipation varies as a function of frequency, supply voltage and capacitive loading.

## AC Performance Characteristics.

During switching, the node capacitances, within a given circuit, and the load capacitances external to the circuit, are charged and discharged through the p- or n-type device conducting channel. As the magnitude of $\mathrm{V}_{\mathrm{DD}}$ increases, the impedance of the conducting channel decreases accordingly. This lower impedance results in a shorter RC time constant (this non-linear property of MOS devices is due to current saturation at large values of drain-to-source voltage). The result is that the maximum switching frequency of a COS/MOS device increases with increasing supply voltage. (See Fig. 7a).


Fig. 5- Basic gate power dissipation characteristics.


Fig. 6- MSI device power dissipation characteristics.

Fig. 7 b shows curves of propagation delay as a function of supply voltage for a typical gate device. However, the the trade-off for low supply voltage (i.e., lower output current to drive a load) is lower speed of operation.

The power dissipated during switching (if the load is assumed to be capacitive) is equal to:
$C_{o} V_{D D}^{2} f$ [power is equal to energy per unit time]
where $\mathrm{C}_{\mathrm{o}}$ is the output and load capacitance, $\mathrm{V}_{\mathrm{DD}}$ is the supply voltage, and $f$ is the operating frequency in hertz. A measure of this power dissipation as function of frequency can be obtained from the model shown in Figs. 8a and 8 b which assumes step inputs and zero mode capacitance.

The average power for the square-wave input voltage shown (repetition rate $f_{0}=1 / t_{0}$ ) is calculated as follows:

$$
P=\frac{1}{t_{o}} \int_{0}^{\frac{t_{0}}{2}} I_{N}(t) V_{o} d t+\frac{1}{t_{0}} \int_{\frac{t_{o}}{2}}^{t_{0}} I_{P}(t)\left(V_{D D}-V_{o}\right) d t
$$



Fig. 7- Operating frequency and propagation delay as a function of power-supply voltage (a) Maximum guaranteed operating frequency as a function of power-supply voltage (b) Propagation delay as a function of power-supply voltage for the basic gate.

For $P$ with $I_{N}(t)=I_{P}(t)=C_{0} \frac{d V_{o}}{d t} \quad$ (step inputs only),

$$
\begin{aligned}
& P=\frac{C_{0}}{t_{0}} \int_{0}^{V_{D D}} V_{o} d V_{o}+\frac{C_{o}}{t_{o}} \int_{V_{D D}}^{o}\left(V_{D D}-V_{o}\right) d\left(V_{D D}-V_{o}\right) \\
& \therefore P=\frac{C_{0} V^{2 \prime} D D}{t_{0}}=C_{o} V_{D D f}^{2}
\end{aligned}
$$

Thus, for a step input, the average power dissipated is directly related to the energy required to change and discharge the circuit capacitance to the supply voltage, VDD. It should be noted that this power is independent of the device parameters. Although this equation was derived using an input voltage with a rise time of zero, it has also been shown to be a good approximation for circuits where the input voltage rise and fall times are small with respect to the repetition rate.

## Calculating System Power

The foregoing material presented fundamental reasons why COS/MOS devices exhibit extremely low quiescent power. Also presented were reasons why ac power dissipation increases with operating frequency and why it varies from device to device.

For these reasons certain guidelines have been developed to assist the designer in estimating system power. Total system power is equal to the sum of quiescent power and dynamic power. Therefore, the two-step approach outlined below can be used:

1. Add up all typical package quiescent power dissipations (as shown in the RCA COS/MOS published data). Because quiescent power dissipation is equal to the product of quiescent device current times supply voltage, this parameter may also be obtained by adding all typical quiescent device currents, and multiplying the sum by the supply voltage, VDD. Quiescent device current is shown in the published data for supply voltages of 5 volts and 10 volts only.
In cases where the supply voltage is other than that shown in the published data, the quiescent device current can be interpolated because this current varies approximately linearly with voltage.

(a)


Fig. 8- Model for the evaluation of power dissipation (a) Waveforms (b) Circuit.
2. Add up all dynamic power dissipations using typical curves of dissipation per package as a function of frequency shown in the published data. In a fast-switching system, most of the power dissipation is dynamic, therefore, quiescent power dissipation may be neglected.

The example below illustrates how these rules are used to calculate total system power dissipation. The system illustrated consists of ten 2-input NOR gates, eleven inverters, one D-type flip-flop, and one 7 -stage binary counter. The system operates with a supply voltage of 10 V at a frequency of 100 kHz , and has a load capacitance of 15 pF . (See Table 1)

Table I

| Types | PQuiescent <br> $\mu \mathrm{W}$ | PDynamic <br> mW |
| :--- | :---: | :---: |
| Gates | 0.03 | 2 |
| Inverters | 0.01 | 2 |
| D-type F/F | 0.05 | 0.2 |
| Counter | 5 | 0.6 |
| $\mathrm{P}_{\mathrm{T}}=\mathrm{P}_{\mathrm{Q}}+\mathrm{P}_{\mathrm{D}}=4.8 \mathrm{~mW}$ (neglecting $\mathrm{P}_{\mathrm{Q}}$ ) |  |  |

This example assumes that all devices are switching at the clock-rate ( 100 kHz ). Not all of the logic circuits will be switching states at this rate, thus, the total power dissipation will be significantly lower than that stated in the example.

## Power-Supply Regulation Requirements.

The preceding discussion demonstrated that COS/MOS devices exhibit reliable switching properties over a wide range of power-supply voltages. This fact implies that an unregulated supply may be used with the provision that
(1) maximum voltage limits are not exceeded or
(2) system speed is no greater than the speed which can be supported by the COS/MOS devices operating at the lowest value of the $\mathrm{V}_{\mathrm{DD}}$ expected from the unregulated supply.

To establish the extent of the regulation required, the system designer must first determine the maximum operating frequency required. Usually, the maximum frequency of the system is limited by the slowest responding devices in a logic chain. By reference to the curve of frequency as a function of $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{C}_{\mathrm{L}}$ given in the published data for that device, a minimum $V_{D D}$ voltage (required for proper operation) can be determined. Any value above this $\mathrm{V}_{\mathrm{DD}}$ (minimum) will provide acceptable performance in the system. By selection of a nominal $V_{D D}$ half way between $V_{D D}$ (mini-
mum) and the 15 -volt maximum rating for COS/MOS devices, the designer can estimate the percentage regulation required for his system to perform adequately.

For example, the published data of the RCA CD4024A 7 -stage binary counter shows a curve (shown in Fig. 9) of frequency as a function of operating voltage for that device. For operation of this counter at 5 MHz , with a loading capacitance of 15 pF , the minimum operating $V_{D D}$ permitted for reliable operation is 10 volts, as shown on the curve.

Because the maximum $\mathrm{V}_{\mathrm{DD}}$ is 15 volts, a half-way voltage of 12.5 volts should be the nominal value used. In this case, the maximum percentage regulation is $20 \%$. If the designer desires a nominal $\mathrm{V}_{\mathrm{DD}}$ closer to $\mathrm{V}_{\mathrm{DD}}$ minimum, then better regulation is required, (for example in battery-operated equipment where a standard cell is available).

## Filtering Requirements

Power-supply filtering requirements for COS/MOS systems are minimal. Two factors account for this situation: (1) the low quiescent power dissipations involved, and (2) the fact that the peak value of the ripple does not go below a minimum $V_{D D}$ (which supports the required switching frequency), so that the COS/MOS logic performs satisfactorily.


Fig. 9- Maximum frequency as a function of powersupply voltage for the CD4024A types.

This performance has been demonstrated in the laboratory (see Fig. 10). The amount of ripple on the power supply is quite high, yet the device functions properly.

## Typical Supplies

The following circuits indicate some examples of adequate supplies for COS/MOS systems.


Fig. 10-Peak-to-peak ripple voltage as a function of frequency.

## Battery Standby System



Fig. 11-Battery standby for COS/MOS systems.

This system is advantageous in cases where the dc supply becomes open or short-circuited.

With a low battery voltage the COS/MOS system will continue to function without interruption. In order to drive this system the battery voltage and dc supply voltage should relate as follows:

$$
\begin{aligned}
& \mathrm{V}_{\text {battery }}=\mathrm{V}_{\min .}+0.7 \mathrm{~V},(0.7 \mathrm{~V} \approx \text { one diode drop }) \\
& \mathrm{V}_{\max .}>\mathrm{V}_{\mathrm{DC}} \text { supply }>\mathrm{V}_{\min .}+1.4 \mathrm{~V}
\end{aligned}
$$

In the event the supply drops below $\mathrm{V}_{\text {min }}$, the battery will forward bias diode D2 to form a closedcircuit and the COS/MOS system will continue to function properly through the battery.

## High DC Source

For applications (especially in aircraft equipment) where the supply voltage exceeds the RCA COS/MOS maximum rating of $\mathrm{V}_{\mathrm{DD}}$, the circuit of Fig. 12 can be used to reduce the high supply voltage to the normal COS/MOS voltage range. This configuration uses a Zener diode, a resistor $\mathbf{R}$ and a capacitor $\mathbf{C}$.

The low current demand of the COS/MOS system permits an inexpensive but effective Zener diode regulator.

Some of the design considerations are as follows:


Fig. 12-Circuit for interface of COS/MOS systems to high-voltage supply.

1. Selection of Zener Diode and Resistor R

The amount of current that must be maintained through the diode ( $I_{d}$ ) is a function of the difference between the worst-case average current required by the COS/MOS systems and the current required by the Zener diode for regulation based on its particular breakdown characteristics.
The diode current ( $\mathrm{I}_{\mathrm{d}}$ ) and the worst-case average system current ( $\mathrm{I}_{\mathrm{avg}}$ ) determine the value of the resistor $(\mathrm{R})$ for a particular Zener regulating voltage.
2. Selection of Capacitance C

Before the proper capacitance can be selected the following system requirements must be decided upon:
a. Peak charge requirement. This requirement is a function of the peak current and its pulse width. It must be measured for the particular system speed and load capacitance.
b. Permissible VDD minimum: As mentioned in previous sections, this minimum voltage will determine the maximum operating speed of the COS/MOS system.
The size of the capacitor (C) may then be determined from the following formula:

$$
\left.\mathrm{Q}=\mathrm{I}_{\mathrm{p}} \mathrm{(charge}=\text { peak current } \times \text { pulse width }\right)
$$

## SUMMARY

This Note shows that RCA COS/MOS devices offer many advantages in the area of simplified power-supply requirements. The wide operating voltage range ( 3 to 15 volts) from a single supply, low power dissipation, and high noise immunity permit system designers to use less expensive, unregulated, power supplies. This wide voltage range makes COS/MOS logic circuits ideal for battery-operated equipment because a better selection of cells is feasible. Another advantage is the direct compatibility of COS/MOS devices with bipolar devices which eliminates expensive and power-consuming interface circuits. (See Ref. 1.)

COS/MOS transistors show great potential for use in large arrays because of the low power dissipation and effective use of chip area. The relatively small area consumed by COS/MOS circuits, as well as the elimination of area and power-consuming resistors, results in high circuit-density per unit-silicon-area.

The performance features mentioned in this Note, as well as the reduced costs inherent in IC technology make COS/ MOS circuits extremely attractive in many digital systems.

1. "Interfacing COS/MOS WITH OTHER LOGIC Families", ICAN6602 by A. Havasy and M. Kutzin.

# Arithmetic Arrays using Standard COS/MOS Building Blocks 

By A. Havasy

This Note describes tne aesign of a COS/MOS arithmetic unit. The RCA COS/MOS product line includes a standard line of devices designed to operate from voltage supplies of 5 to 15 V and a low voltage " A " series designed to operate from voltage supplies of 3 to 15 V . These devices are available in any of the package types or temperature ranges shown in Table I.
tABLE I

| Package |  | Operating Temperature <br> Range $\left({ }^{\circ} \mathrm{C}\right)$ |  |
| :--- | :---: | :---: | :---: |
| Type | Suffix |  |  |
| Dual-in-line <br> ceramic | D | D |  |
| Plastic | E | E | -55 to +125 |
| Flat Pack | - | K | -40 to +85 |

When ordering COS/MOS devices, the appropriate suffix should be affixed to the number of the device required, (i.e., if a low voltage, plastic package, four bit full adder is desired, order CD4008AE). This Note is applicable to both COS/MOS product lines, and all package types mentioned above.

## Arithmetic Unit

This arithmetic unit is capable of adding, subtracting, multiplying, and dividing. It is also able to perform the logical functions of "OR", "AND" and the "Exclusive OR" of two 4 -bit words. Three 4 -bit registers are provided that permit either of two words to perform a desired operation with a third word. The system is configured with standard, commercially available, COS/MOS devices which include registers, AND-OR select gates, a full adder, as well as NOR and NAND gates. A block diagram of the 4 -bit arithmetic
unit is shown in Fig. 1. The required package count and the function performed by each package are shown in Table II.

A brief description of each COS/MOS device used in the arithmetic system follows:

## Four-Bit Full Adder - CD4008 or CD4008A

The CD4008 or CD4008A consists of four full-adder stages with fast look-ahead carry provision from stage to stage. Circuits are included to provide a fast parallel-carry-out bit, which permit high-speed operation in arithmetic sections that use several CD4008's or CD4008A's.

The CD4008 or CD4008A inputs include the four sets of bits to be added ( $\mathrm{A}_{1}$ to $\mathrm{A}_{4}$ and $\mathrm{B}_{1}$ to B ), and the carry-in bit from a previous section. CD4008 or CD4008A outputs include the four sum bits, S1 to S4, and the high-speed parallel-carry-out, which may be used as the input to a succeeding CD4008 or CD4008A section.

The logic diagram for this device is shown in Fig. 2. The electrical characteristics and more detailed information (for the CD4008 or CD4008A) are given in the RCA Data Bulletin File No. 405 or 479 , respectively.

## Quad AND-OR Select Gate - CD4019 or CD4019A

The CD4019 or CD4019A consists of four AND-OR select gate configurations, each of which have two 2 -input AND gates driving a single 2 -input OR gate. Selection is performed by control bits $\mathrm{K}_{\mathrm{a}}$ and $\mathrm{K}_{\mathrm{b}}$. In addition to the selection of either channel A or channel B information, the control bits can be applied in combination to accomplish a third selection of data. The logic diagram for the CD4019 or CD4019A is shown in Fig. 3. The electrical characteristics and additional application diagrams for the CD4019A are given in the RCA Data Bulletin, File No. 439 or 479 , respectively. Applications of this device to shifting and logic selection operations are discussed later in this Note.

## Dual D-Type Flip-Flop - CD4013 or CD4013A

The RCA CD4013 or CD4013A consists of two identical, independent data-type flip-flops on a single monolithic silicon chip. Each flip-flop has independent data, reset, set, and clock inputs and complementary buffered outputs.


Fig. 1- Four-bit arithmetic unit, block diagram

These devices can be used in shift register applications, and in counter and toggle type flip-flop applications, by connection of the $\bar{Q}$ output back to the data input. The logic level present at the D input is transferred to the Q output during the positive-going transition of the clock pulse. Resetting or setting is accomplished by the application of a high logic level to the reset line or set line, respectively. Fig. 4 shows the logic diagram for one flip-flop section of the CD4013 or CD4013A. The electrical characteristics and additional information for this flip-flop are given in the RCA Data Bulletin, File No. 411 or 479 , respectively.

## Quad 2 - Input NAND Gates - CD4011 or CD4011A

The RCA CD4011 or CD4011A consists of four, identical, iņdependent 2 -input positive-logic NAND gates. Fig. 5 shows the logic diagram and Boolean equations for this device. The electrical characteristics and additional information for these logic gates are given in the RCA Data Bulletin, File No. 420 or 479 , respectively.

## Quad 2 - Input NOR Gates - CD4001 or CD4001A

The RCA CD4001 or CD4001A consists of four, identical, independent 2 -input positive-logic NOR gates. Fig. 6 shows the logic diagram and Boolean equations for this device. The electrical characteristics and additional information for these logic gates are given in the RCA Data Bulletin, File No. 345 or 479 , respectively.

## Arithmetic Unit Operation

The A register uses a CD4019 or CD4019A quad AND-OR select gate to present either the true or the complemented data to the logic circuits and the adder. Thus, the data in the A register can be either added or subtracted from the B or C registers.

The CD4019 or CD4019A at the input of the B register has two control lines which permit data to be shifted right or left, or which permit new data to be accepted from the bus lines. Fig. 7 shows the interconnection diagram of two CD4019's or CD4019A's that perform the shift-right shift-left and arithmetic/logic shift functions.

| FUNCTION | PACKAGES |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\begin{aligned} & \hline \text { CD4008 } \\ & \text { CD4008A } \end{aligned}$ | $\begin{aligned} & \text { CD4019 } \\ & \text { CD4019A } \end{aligned}$ | $\begin{array}{l\|} \text { CD4013 } \\ \text { CD4013A } \end{array}$ | $\begin{aligned} & \text { CD4011 } \\ & \text { CD4011A } \end{aligned}$ | $\begin{aligned} & \text { CD4001 } \\ & \text { CD4001A } \end{aligned}$ |
| A Register lincludes <br> A, $\bar{A}$ select capability and buffered outputs) |  | 1 | 2 |  |  |
| B Register (includes shift capability and buffered outputs for $B$ and $\bar{B}$ ) |  | 3 | 2 |  |  |
| C Register (includes shift capability and buffered outputs) |  | 2 | 2 |  |  |
| Select B or C |  | 1 |  |  |  |
| Add | 1 |  |  |  |  |
| Perform logic |  | 1 |  |  | 5 |
| Select logic or addition |  | 1 |  |  |  |
| Overflow detector |  |  |  |  | 1 |
| Clock inhibit (enable) |  |  |  | 1 |  |
| TOTALS | 1 | 9 | 6 | 1 | 6 |



Fig. 2- Four-bit fuill adder,logic diagram.

The arithmetic shift mode is used only on the highest order bits and insures that the sign bit does not change during the shifting. On the lowest order bits the left shift input for the $B$ register (BRSI) is tied to the $\mathrm{B}_{0}$ output of the next higher set of bits.

The C register is identical to the B register but does not provide for arithmetic mode shifting. Separate shift-right and shift-left controls are provided for the $B$ and $C$ registers. (BSL and BSR is provided for the B register, and CSL and CSR for the C register). Another CD4019 or CD4019A is used to select either the $B$ or the $C$ register information for the logic and arithmetic operations.


Fig. 3- CD4019 or CD4019A - Logic diagram.

The logic block diagram for the AND/OR/Exclusive-OR logic selector is shown in detail in Fig. 8. One and one-quarter CD4001's or CD4001A's and one-quarter CD4019/CD4019A are used per bit, (or five CD4001 or CD4001A and the CD4019 or CD4019A per four-bit word). The control inputs are labeled $K(\cdot)$ (K-AND) and $K(\Theta)$ (K-Exclusive OR). An example of logic selection is as follows:

Assume that $B_{1}$ is an output from the $B$ register and $A_{1}$ is a true output from the A register via the True/Complement Switch. (Refer to Fig. 1) When $K(\cdot)$ is "high" and $K(\oplus)$ is "low", the logic generated is AB . When $\mathrm{K}(\cdot)$ is low and $K(\Theta)$ is high, the logic generated is $A \oplus B=A \bar{B}+\bar{A} B$. When both $K(\bullet)$ and $K(\oplus)$ are "high", the logic is $A B+(A \oplus B)=$ $\mathrm{AB}+\mathrm{A} \overline{\mathrm{B}}+\overline{\mathrm{A}} \mathrm{B}=\mathrm{A}+\mathrm{B}$.

The adder is a single CD4008 or CD4008A previously described. The carry input of this adder will be tied to the carry output of the adder on the next-lower-order CD4008 or CD4008A. The carry input of the lowest-order bits will be a logic " 0 " for addition and a logic " 1 " for the 2 's complement subtraction.

The output buffer is also a CD4019 or CD4019A. In this application the device is used to select either the arithmetic or the logic outputs and to provide more output drive.

The output overflow circuit (shown in Fig. 9) will go "high" if the adder result exceeds the total bit capacity of the arithmetic unit. This overflow occurs only when two numbers that have the same sign bit are added and, the result is a sum which has the opposite sign.


- = INVALID CONDITION
TERMINAL $14=$ VDD
TERMINAL $7=$ GND

| CL* | D | R | 5 | 0 | $\overline{0}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\Gamma$ | 0 | 0 | 0 | 0 | 1 |
| $\Gamma$ | 1 | 0 | 0 | 1 | 0 |
| L | $\times$ | 0 | 0 | 0 | $\bar{\square}$ |
| x | $\times$ | 1 | 0 | 0 | 1 |
| $x$ | $x$ | 0 | 1 | 1 | 0 |
| * | $\times$ | 1 | 1 | * | - |



Fig. 4- CD4013 or CD4013A - Logic diagram and truth table (one of two identical flip-flops).


Fig. 5- CD4011 or CD4011A - Logic diagram and equations.

A larger arithmetic unit of any desired word length can be made by cascading additional circuits. The interconnection of eight systems to form a 32-bit arithmetic unit is shown in Fig. 10. The three inhibit signals, common control signals, and


Fig. 6- CD4001 or CD4001A - Logic diagram and equations.
inverted clock signal (which are common to all eight subsystems) are not shown. Table III shows the functions and the symbols.


$$
\begin{aligned}
\text { RSI } & =\text { RIGHT SERIAL INPUT } \\
\text { LSI } & =\text { LEFT SERIAL INPUT } \\
\text { BR }_{n} & =\text { OUTPUT OF } n^{\text {th }} \text { BIT } \\
& \text { OF "B" REGISTER } \\
\text { NU } & =\text { NOT USED }
\end{aligned}
$$

Fig. 7- Shift-Right/Shift-Left - Arithmetic/Logic shift Interconnection diagram.

TRUTH TABLE

| $K[\cdot]$ | $K[\oplus]$ | OUT |
| :---: | :---: | :---: |
| 0 | 0 | 0 |
| 1 | 0 | $A \cdot B$ |
| 0 | 1 | $A \oplus B$ |
| 1 | 1 | $A+B$ |

Fig. 8- AND/OR/EXCLUSIVE-OR Selector.


Fig. 9- Overflow logic circuit.

## TABLE III FUNCTIONS AND SYMBOLS

## SYMBOLS

VDD Input for positive power supply
GND Ground
$\overline{C L}$
$\mathrm{IN}_{0}$
$\mathrm{IN}_{1}$
$\mathrm{IN}_{2} \quad$ Third lowest order bus input
$\mathrm{IN}_{3}$
Enable A
Enable B Enables the $B$ register
Enable C
A
$\bar{A}$
SEL B $\quad$ Selects B register data for output function with A register data
SEL C Selects $C$ register data for output function with $A$ register data
Arith-
metic
shift
Logic
shift
B Bus
B shift
BSR
BSL
BSRI
BSLI
C Bus
C shift
CSR
CSL
CSRI Input to lowest order bit of C register when shifting right
CSLI Input to highest order bit of C register when shifting left
Arith-
metic
Logic
CIN
COUT Carry out from highest order bit of adder

## TABLE III (CONTINUED)

| SYMBOLS | FUNCTIONS |
| :--- | :--- |
|  |  |
| Overflow | Indicates if addition exceeds limit of adder |
| $\mathrm{K}(\cdot)$ | Generates logical AND of logic circuits |
| $\mathrm{K}(\oplus)$ | Generates logical EXCLUSIVE-OR of logic circuits |
| $\mathrm{S}_{0}$ | Lowest order sum output |
| $\mathrm{S}_{1}$ | Second lowest order sum output |
| $\mathrm{S}_{2}$ | Third lowest order sum output |
| $\mathrm{S}_{3}$ | Highest order sum output (sign bit) |

## Performance Data

In a 32 -bit arithmetic unit constructed in the laboratory the delay time, (under worst-case logic conditions) for the inverted clock to be inverted, for data to be written into the register, and for that data to get to the adder and generate a carry-out from a 4-bit system was found to be 782 nanoseconds. The delay time (under worst-case logic conditions) for a carry-in to generate a carry-out was found to be 87 nanoseconds. The delay time under worst-case logic conditions for a carry-in to generate a sum at the adder and for this sum to appear at the outputs was found to be 623
nanoseconds. These numbers result in an addition time of 1927 [782 + (6 x 87) +623$]$ nanoseconds for two 32-bit words and 1579 [782 $+(2 \times 87)+623]$ nanoseconds for two 16-bit words.

Since the construction of this adder, improved processing techniques permit faster operation. The delay from the clock to the carry out can be expected to be less than 500 ns ; the delay from the carry-in to the carry-out can be expected to be less than 50 ns ; and the delay from the carry in to the sum out can be expected to be less than 400 ns. Thus, the maximum addition time for a 32 -bit arithmetic unit would be approximately 1200 ns ; for a 16 -bit unit, 1000 ns (maximum) would be required.

Calculations indicate a typical power dissipation of 100 $\mu \mathrm{W}$ and $2350 \mu \mathrm{~W}$ for the 4 -bit arithmetic unit. These calculations are based on typical and maximum device quiescent power dissipations at a 10 -volt supply and $+25^{\circ} \mathrm{C}$ temperature.

## Summary

A complete 32-bit full adder/arithmetic logic system that uses standard COS/MOS devices (commercially available in quantity) is shown. This system offers many adantages to the systems designer: low powèr dissipation, high noise immunity and reliability.


Fig. 10- Major interconnections to form 32-bit arithmetic unit from 4-bit subsystems.

# Transmission and Multiplexing of Analog or Digital Signals Utilizing the CD4016A Quad Bilateral Switch 

by J. Litus, Jr., S. Niemiec, and J. Paradise

RCA type CD4016A Quad Bilateral Switch is an extremely flexible device. It has many advantages unique to a COS/MOS* switch configuration and can be used for the transmission of analog or digital signals with low distortion. The CD4016A is the ideal semiconductor switch for use in a multitude of switching applications. This note describes some of the features and several applications of COS/MOS transistor bilateral signal switches (transmission gates).

## FEATURES OF THE CD4016A

The functional diagram of the CD4016A is shown in Fig. 1. The CD4016A consists of four independent bilateral signal switches on a single silicon monolithic chip. Each switch consists of an $n$-channel and a p-channel device. The source of the $p$-channel device is connected to the drain of the n -channel device and vice-versa. Only one control signal $\mathrm{V}_{\mathrm{C}}$ is required per switch. $\mathrm{V}_{\mathrm{C}}$ directly controls the n -channel unit; the p -channel unit is controlled by $\overline{\mathrm{V}}_{\mathrm{C}}$ (an inverter is included on the chip). Both channels are biased "ON" or "OFF" simultaneously by the control signal VC. Fig. 2 shows the schematic diagram of the CD4016A.

Unlike the bipolar switch, the COS/MOS switch has no voltage offset. It is a bi-directional switch. The COS/MOS switch does not require an excessively large control voltage (compared with the incoming signal level), as does the single channel MOS switch. The control voltage required by the COS/MOS switch is of approximately the same amplitude as the input signal. The incoming signal can be a maximum of $\left|\mathrm{V}_{\mathrm{DD}} \cdot \mathrm{V}_{\mathrm{SS}}\right|=15 \mathrm{~V}$., or a minimum of $\left|\mathrm{V}_{\mathrm{DD}} \cdot \mathrm{V}_{\mathrm{SS}}\right|=3 \mathrm{~V}$.

Figs. 3 and 4 show the typical "ON" transfer characteristics of the COS/MOS switches. Figs. 5 and 6 show the output voltage as a function of time for an input sine wave and square wave voltage respectively.
*Complementary-Symmetry Metal-Oxide-Semiconductor

## OPERATION OF THE COS/MOS SWITCH

Fig. 7 shows the transfer characteristics of a single p-channel MOSFET switch (with a high value of load resistance $\mathrm{R}_{\mathrm{L}}$ ) in the "ON" condition. If it is assumed that this application calls for an input signal voltage ( $\mathrm{V}_{\mathrm{I}}$ ) in the range of -5 to +5 V ., and that the output signal voltage $\mathrm{V}_{\mathrm{O}}$ follows the input signal voltage linearly within this voltage range, the switch will be "ON" for the following conditions:

Threshold voltage $\left(\mathrm{V}_{\mathrm{TH}}\right)=+5 \mathrm{~V}$.
Gate voltage $\left(\mathrm{V}_{\mathrm{G}}\right)=-10 \mathrm{~V}$.
Substrate voltage $\left(\mathrm{V}_{\text {sub }}\right)=+5 \mathrm{~V}$
Input signal voltage $\left(\mathrm{V}_{\mathrm{I}}\right)>-5 \mathrm{~V}$.
When the switch is "ON", the input signal voltage is transmitted to the output terminal (subject to the above conditions). However, if the input signal voltage falls below


Fig. 1- Functional diagram (top view).
-5 V., (i.e., $V_{T H}$ ), the switch operates as a source follower. To avoid this condition, the magnitude of the p-channel gate voltage must be increased by the sum of the threshold voltage and the peak input voltage, $\left|\mathrm{V}_{\mathrm{I}}(\max )+\mathrm{V}_{\mathrm{TH}}\right|$.

The problems encountered in the single channel

MOSFET switch can be eliminated by the use of a parallel complementary MOSFET arrangement, shown in Fig. 8a. The voltage transfer characteristics ( $\mathrm{V}_{\mathrm{O}}$ as a function of $\mathrm{V}_{\mathrm{I}}$ ) are shown in Figs. 8b (single p-channel device), 8c (single n-channel device), and 8 d (composite for both devices in


NOTE: All switch P-channel substrates are internally connected to terminal No. 14.
All switch N -channel substrates are internally connected to terminal No. 7.
NORMAL OPERATION:
Control Line Biasing
Switch "ON": $V_{C}$ "1" = VDD
SIGNAL-LEVEL RANGE:
Switch "OFF": $\mathrm{V}_{\mathrm{C}}{ }^{\prime \prime} \mathrm{O}^{\prime \prime}=\mathrm{V}_{\mathrm{SS}}$
$v_{S S} \leq v_{\text {is }} \leq v_{D D}$
Fig. 2- Schematic diagram.


Fig. 3- Typ. "ON" characteristics for 1 of 4 switches with $V_{D D}=+10 \mathrm{~V}, V_{S S}=O V(C D 4016 A)$.


Fig. 4- Typ. "ON" characteristics for 1 of 4 switches with $V_{D D}=+5 V, V_{S S}=-5 V(C D 4016 A)$.
parallel). The load resistance, $\mathrm{R}_{\mathrm{L}}$ is assumed to be large compared with the MOSFET "ON" resistance (RON). The composite characteristics are obtained by the graphic addition of the individual characteristics. The "ON" characteristics show that at least one device is "ON" at any given instant, because one gate is controlled by $\mathrm{V}_{\mathrm{C}}$ and the other by the complement, $\overline{\mathrm{V}}_{\mathrm{C}}$.

(a)


SCALE: $X=0.2 \mathrm{~ms} /$ DIV $\mathrm{Y}=2.0 \mathrm{~V} / \mathrm{DIV}$
$V_{D D}=V_{C}=+2.5 \mathrm{~V}, V_{S S}=-2.5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=10 \mathrm{~K} \Omega$
$C_{L}=15 \mathrm{pF}$
$\mathrm{f}_{\mathrm{IS}}=1 \mathrm{kHz} \quad \mathrm{V}_{\text {IS }}=5 \mathrm{~V} \mathrm{p}-\mathrm{p}$
DISTORTION $=3 \%$
(b)

Fig. 5- a) Typ. Sine wave response of $V_{D D}=+7.5 \mathrm{~V}, V_{S S}=$ -7.5 V ; b) Typ. sine wave response of $V D D=+2.5 \mathrm{~V}$, $V_{S S}=2.5 \mathrm{~V}$.

(a)

(b)

Fig. 6- a) Typ. square wave response at $V_{D D}=V_{C}=+15 \mathrm{~V}$, $V_{S S}=G_{n d} \cdot$ b) Typ. Square wave response at $V_{D D}$ $=V_{C}=+5 V, V_{S S}=G_{n d}$.

The gate control voltage required ( $\pm 5 \mathrm{~V}$ in this case) need only be equal to the absolute value of the peak input signal voltage. The maximum input signal voltage range is limited by VDD ( +5 V ) and $\mathrm{V}_{\mathrm{SS}}(-5 \mathrm{~V})$. The gate control voltages would then be +5 V and -5 V respectively. There is a minimum threshold voltage ( $\mathrm{V}_{\mathrm{TH}}$ ) required to turn "ON" the switch. This condition must always be met for proper operation - see published data, Ref. 1.


Fig. 7- Single p-channel MOS/FET switch characteristics

(a)

$v_{G n}=5 v$
$V_{S S}=-5 V$
(c)


$$
\begin{aligned}
& v_{G D}=-5 v \\
& v_{D D}=5 v
\end{aligned}
$$

(b)

(d)

Fig. 8- a) COS/MOS FET switch (transmission gate); b) p-channel characteristics; c) n-channel characteristics; d) composite characteristics.

## SWITCH AND LOGIC APPLICATIONS

## Switch Functions

The CD4016A Quad Bilateral Switch can be used to perform the four common switch functions shown in Fig. 9 (i.e., SPST, SPDT, DPST, and DPDT).

b) SPDT

d) DPDT


Fig. 9- Basic switch functions using the CD4016A.

## Logic Functions

Fig. 10a illustrates the use of the CD4016A to gate digital (or analog) signals. When the CD4016A is used as a digital "OR" gate, a logic " 1 " should be present at points a and b . Two control voltages A and B are required as shown. When a logic " 1 " is not being transmitted ( $A=B=$ " $O$ "), a logic " O " appears at the output. There are two methods to achieve this result: (1) a resistor tied from the output terminal to a logic " $O$ ", or (2) the remaining two transmission gates of the CD4016A can be connected (as shown in Fig. 10a) to a logic " $O$ " and be gated by the complement of the control functions A and B (i.e., $\overline{\mathrm{A}}$ and $\overline{\mathrm{B}}$ ). Use of the resistor tied to a logic " $O$ " will provide the designer with two "OR" gates from a single CD4016A. Use of the two transmission gates (in place of the resistor) provides lower power dissipation.

Analog signals may be used in place of the logic " 1 " signals at the signal input terminals (VIS) to the transmission gates and these analog signals may be passed to the output if a particular logic function is satisfied. A general logic function may be implemented by the use of transmission gates as shown in Fig. 10d. The function illustrated is $F=\overline{\mathrm{AB}}$ + CD. The implementation of some logic functions may be simpler and the propagation delay time may be shorter when transmission gates are used. The input signals $(a, b$ and $c$ in Fig. 10d) may be analog signals or digital signals. The transmission gates may be used in a wired "OR" configuration, which simplifies many logic designs.

Transmission gates may also be used in flip-flop or memory cell circuits. Fig. 11 shows transmission gates being used in conjunction with NOR gates and inverters to


Fig. 10- Logic functions using the CD4016A: a) "OR" gate; b) "AND" gate; c) "NOT" (inverter) gate; d) implementation of $F=\overline{A B}+C D$ using the CD4016A.
implement a master-slave type D flip-flop. These flip-flops are available commercially. (See Ref. 2.) All COS/MOS logic elements (gates, flip-flops, complex MSI and LSI functions) are comprised of the basic COS/MOS Transmission gate (parallel connection of $p$ - and $n$ - channel units) plus the basic COS/MOS inverter (series connection of p - and n - channel units). (See Ref. 2.)

## Multiplexing/Demultiplexing

A four channel PAM (Pulse Amplitude Modulation) Multiplex/Demultiplex system utilizing the CD4016A is shown in Fig. 12a. Commutator, MUX, and DMUX are the building blocks used to implement the system. Each input signal is sampled sequentially and applied to a single transmission line, but in a different time slot. The signals are detected and reconstructed at the outputs. These outputs will be proportional to the inputs, with no loss of information, as long as the conditions of Nyquist's sampling theorem are met: Sampling rate must be greater than twice the maximum frequency component of the input signal.

An RCA type CD4018A - "Divide-by-N" counter and associated decoding circuitry are used to provide the sequential signals to the control inputs of the CD4016A switches. The analog information is present at the outputs of the CD4016A only during the "ON" time of each switch. The clock frequency required for the counter is as follows:

$$
\mathrm{f}_{\mathrm{cl}}>2 \mathrm{f}_{\mathrm{m}} \mathrm{~N}_{\mathrm{c}}
$$

where $f_{m}$ is the bandwidth of the input signal and $N_{c}$ is the number of channels being sampled. For example, the circuit shown in Fig. 12a has a maximum input signal bandwidth of 10 kHz . Therefore,

$$
\mathrm{f}_{\mathrm{cl}}>2(10 \mathrm{kHz})(4)=80 \mathrm{kHz}
$$

The clock pulse is also applied to the transmission line to provide synchronization pulses for output decoding. A narrow clock pulse is used to prevent significant interaction between the clock and the sampled information. These clock pulses are removed from the output waveforms by taking advantage of the threshold voltage of a second counter (CD4018A). The magnitude of the analog signals is kept at a lower level than the switching voltage [ $\mathrm{V}_{\text {IL }}$ (max)] of the CD4018A or the CD4009A (Inverter A). $\left[\mathrm{V}_{\text {IL }}(\max )=30 \%\right.$ of VDD.] Therefore, only the clock pulses trigger the second counter. Inverter A opens the transmission line during the clock interval. Signals can be transmitted at all other times. In this example, the clock is transmitted on the same line as the analog information, although this procedure need not be followed. Separate transmission of the clock signal removes any restrictions on the signal amplitude provided the signal swing is maintained within the range of the $\mathrm{V}_{\mathrm{DD}}$ and $\mathrm{V}_{\mathrm{SS}}$ supply levels.

The output decoding is identical to the input decoding. The low-pass filters have a bandwidth equal to the bandwidth of the system and are used to filter the high frequency components generated by the sampling process, and to reconstruct the signals. Figs. 12b, c, and d show the waveforms of the signals at various points in the circuit.

Measurements and observations of a laboratory prototype of the PAM system discussed above, are presented below. Note: In the "all COS/MOS system", the switch


* = invalid condition
TRUTH TABLE

| CL* | D | R | S | $\mathbf{0}$ | $\overline{\mathrm{a}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\sim$ | 0 | 0 | 0 | 0 | 1 |
| $\sim$ | 1 | 0 | 0 | 1 | 0 |
|  | $\times$ | 0 | 0 | 0 | $\overline{0}$ |
| $\times$ | $\times$ | 1 | 0 | 0 | 1 |
| $\times$ | $\times$ | 0 | 1 | 1 | 0 |
| $\times$ | $\times$ | 1 | 1 | $*$ | $*$ |


$4=$ LEVEL CHANGE
$x=\operatorname{DON}$ 'T CARE CASE

Fig. 11- Type "D" flip-flop logic diagram and truth table.
control signals are compatible with commonly used control system logic levels. Analog input signals whose magnitude is equal in amplitude to these control signals, can be used. The analog signals may be of either polarity, positive or negative.

## Conditions:

Signal Input voltage frequency: 100 Hz to 10 kHz
Peak to Peak input: 400 mV
Peak to Peak input: 400 mV
RC Low pass filter cut-off frequency: $\frac{1}{2 \pi \mathrm{R}} \overline{\mathrm{C}}=1.33 \mathrm{kHz}$

$$
(\mathrm{R}=12 \mathrm{k} \Omega, \mathrm{C}=0.01 \mu \mathrm{~F})
$$

Results:
"ON" channel attenuation: 13 dB
Adjacent "OFF" channel signal: -50dB below input
Adjacent "ON" channel signal: -50dB below input
Distortion: $3 \%$ ( 1 kHz signal at LPF output, input signal 200 mV peak-to-peak; clock frequency 400 kHz )

In the example of Figs. 12a, 12b, 12c, and 12d, only one supply is used. The negative signal swing is limited to less than one diode drop $\left(\mathrm{V}_{\mathrm{BE}} \simeq 0.5 \mathrm{~V}\right)$ below ground potential. This one-supply system can be modified to permit higher input signal amplitudes: the ac input voltage is offset by the addition of a resistor tied from VDD to VIS terminals of the input CD4016A. The positive signal swing should not exceed the switching voltage of the CD4018A. (See Ref. 3 for detailed applications of the CD4018A.) Fig. 12e shows an oscilloscope trace of the input and output voltage waveforms for this modification using a $2-\mathrm{k} \Omega$ offset resistor with a $600-\Omega$ source impedance. The input signal amplitude is approximately 3 V and is offset from ground by $1-1 / 2 \mathrm{~V}$.

A method that permits the transmission of the clock signal on the same line as the multiplexed information is the use of a level detector to separate the clock signal from the information. The circuit modification is shown in Fig. 13. Such a level detector is described in the section that discusses the squelch control circuit. Two supplies are utilized in this application. The level detector permits the use of an input signal amplitude that approaches $\mathrm{VDD}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{SS}}$.

In general, PAM provides a simple method to transmit and receive data through a common transmission medium. The above system can be extended to more complex transmission systems such as PDM, PPM, and PCM. In telemetry applications, where transmission of multi-channel analog or digital data from airborne instrumentation is necessary, COS/MOS devices offer the advantage of low power dissipation. Intercom and public address systems can also benefit from the advantages of multi-channel-single transmission line communications.

## DIGITAL CONTROL OF SIGNAL GAIN, FREQUENCY AND IMPEDANCE

## Resistor Network

Fig. 14 shows a digitally controlled resistor network. Each resistor is shunted by $1 / 4$ CD4016A COS/MOS switch. When the switch is "ON" the resistor is shorted; when the switch is "OFF" the resistor is in the circuit. The "ON" impedance of the CD4016A is approximately $300 \Omega(10 \mathrm{~V}$

[^31]bias); the "OFF" impedance is approximately $1012 \Omega(10 \mathrm{~V}$ bias). Sixteen ( $2^{4}$ ) resistor value combinations can be obtained from this 4 -stage network. Such a network can be controlled from any logic system to select any value at the proper time. The control inputs could, for example, be connected to a binary counter (RCA type CD4004A)*, to generate a staircase of binary resistor values.

## Variable Gain Control

Fig. 15a shows the resistor network inserted into the feedback loop of an operational amplifier. This network provides the circuit with a 16 to 1 variation in gain. The gain of an op-amp in the configuration is given by

$$
\mathrm{A}=\frac{-\mathrm{Z}_{\mathrm{E}}}{\mathrm{Z}_{\mathrm{I}}}
$$

$\mathrm{Z}_{\mathrm{F}}$ is the digitally controlled resistor network. The control inputs to the CD4016A are connected to a binary counter as shown. The signal inputs can be either ac or dc. Waveforms for the voltage at various points in the circuit are shown in Figs. 15b and 15 c .

## Capacitor Network

A digitally controlled capacitance is shown in Fig. 16. This network has the capability of 128 capacitance values. There will be some resistance in series with each capacitor (i.e., RON of the CD4016A). This resistance can be neglected if $1 / \omega C \gg \mathrm{R}_{\mathrm{ON}}$. $\mathrm{R}_{\mathrm{ON}}$ is negligible in most frequency control applications discussed in this Note.

## Variable Frequency Control

Fig. 17a shows an astable multivibrator that uses a digitally controlled capacitance as the frequency-adjustment element. (See Ref. 4.) The control inputs to the CD4016A are obtained from a binary counter (CD4004A). The multivibrator is thus "swept" through a frequency range that depends upon the value of the capacitor network. For the values of resistance and capacitance shown in Figs. 17a and 16 , a frequency range of 1 kHz to 70 kHz can be obtained in 128 discrete steps. The sweep-rate is determined by the clock-rate to the binary counter. Fig. 17b shows the waveforms for the circuit.

Combinations of $\mathrm{R}, \mathrm{L}$, and C networks can be digitally controlled to provide a variable impedance, gain, frequency, phase-shift or bandpass.

## Digital-To-Analog (D/A) Conversion

A $\mathrm{D} / \mathrm{A}$ converter is a decoding device that has two inputs and one output. The inputs are a digital signal (D) and an analog reference $\left(\mathrm{V}_{\mathrm{R}}\right)$; the output $\left(\mathrm{V}_{\mathrm{O}}\right)$ is an analog signal related to the inputs as follows:

$$
\mathrm{V}_{\mathrm{O}}=(\mathrm{D})\left(\mathrm{V}_{\mathrm{R}}\right)
$$

where: $D=\left[a_{1} 2^{-1}+a_{2} 2^{-2}+\ldots+a_{n} 2-n\right]<1$.
Hence $V_{O}=V_{R}\left[a_{1} 2-1+a_{2} 2-2+\ldots+a_{n} 2-n\right]$.

## Weighted Resistor Network for D/A Converter

Fig. 18a shows a 4-bit D/A converter that uses a binary weighted resistor network and two CD4016A's. The value of each resistor is inversely proportional to the weighted value
$\qquad$

separate signals (U) and 4 demultiplexed reconstructed output signals ( $V_{O}, W_{O}, X_{O}$, and YOl;d) waveforms showing separation of clock signal from the information (1 channel only); e) waveforms for single supply circuit for input signal dc offset.
of the particular digit being decoded. There are sixteen possible steps and each step is equal to $1 / 15 \mathrm{VR}$.

When the control inputs of the CD4016A are connected to a binary counter (CD4004A) a staircase output voltage is generated (shown in Fig. 18b). The reference voltage $\mathrm{V}_{\mathrm{R}}$, can be an analog signal as shown in Fig. 18c.

Although simpler circuitry is an advantage of the weighted resistor network this approach demands widely varying values of resistance and stringent switching requirements. The accuracy of the output voltage depends upon the accuracy of the resistance values and how well the resistance values track with temperature variations. As the number of bits increases, the values of the resistances become physically impractical.

## R-2R Resistor Ladder D/A Converter

Two types of R-2R ladder networks are used for D/A conversion: (1) voltage-fed and (2) current-fed.

Fig. 19a shows a circuit diagram of a voltage-fed D/A converter that uses 2 CD4016A's and an R-2R network. The circuit provides 2 n equal voltage steps, where n is the number


Fig. 13-Modification of the circuit of Fig. 12 to permit increased input signal amplititude.


Fig. 14- Digitally controlled resistor network. (See RCA Data Bulletin No. 479 for details of terminal connections).


Fig. 15- a) Variable gain control circuit; b) waveform of output voltage for dc input voltage; c) waveform of output voltage for ac input voltage.


Fig. 16- Capacitor network. (See Data Bulletin File No. 479 for details of terminal connections).
$\qquad$
of "legs" used. $V_{R}$ is the dc reference input. The R-2R ladder network functions as a successive voltage divider. Each CD4016A connects or disconnects its "leg" to the reference voltage or to ground, and the output voltage is proportional to the input reference as discussed in the provious section. Thus, for the 4 -bit system shown the least significant bit (LSB) contributes $\mathrm{V}_{\mathrm{R} / 24}$ or $\mathrm{V}_{\mathrm{R} / 16}$ to the total output

voltage. A CD4004A binary counter is used to provide a staircase output from the D/A converter. (Fig. 19b). An analog reference voltage may be used as the input: Fig. 19c shows the output voltage waveforms. Laboratory data indicate less than a $1 \%$ error in accuracy. The overall accuracy is dependent upon the switch "ON" resistance ( $\mathrm{R}_{\mathrm{ON}}$ ), leakage current and the discrete component accuracy.

(b)
(a)

Fig. 17-a) Sweep generator (astable multivibrator) circuit;
b) output voltage waveforms.


(b)

(c)

(c)

Fig. 18-a) Weighted resistor network $D / A$ converter; b) output voltage waveforms for dc input voltage; c)
output voltage waveforms for ac input voltage. (See Data Bulletin File No. 479 for details of terminal connections).

The current-fed D/A converter is shown in Fig. 20a. This circuit is similar in performance to the voltage-fed $R-2 R$, except that the current-fed circuit has a higher accuracy. Higher accuracy is obtained because the same current is supplied from a constant current source over a wide variety of load values (including RON of the CD4016A's). The accuracy of the circuit is limited only by the accuracy of the resistors used. In this circuit a constant-current source feeds the R-2R network through the CD4016A. The current is divided by each branch in the same manner as voltage is divided in the voltage-fed circuit:

$$
\begin{aligned}
& \mathrm{V}_{\text {out }}=\left[\left(\mathrm{I}_{\text {total }}\right)\left(\mathrm{R}_{\mathrm{L}}\right)\right] \\
& \text { and, } \\
& \quad \mathrm{V}_{\text {out }}(\max )=\left(\mathrm{I}_{\mathrm{C}}\right)\left(\mathrm{R}_{\mathrm{L}}\right)\left[1-\left(1 / 2^{\mathrm{n}}\right)\right]
\end{aligned}
$$

where $I_{C}$, is the value of the constant-current. For the example shown in Fig. 20a, $\mathrm{I}_{\mathrm{C}}=500 \mu \mathrm{~A}, \mathrm{n}=4, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ and

$$
\mathrm{V}_{\text {out }}(\max )=(500 \mu \mathrm{~A})(2 \mathrm{k} \Omega)\left[1-\left(1 / 2^{4}\right)\right]=0.938 \mathrm{~V}
$$

for both dc and analog inputs. The measured error, including discrete component tolerance, is much less than $1 \%$.

## SAMPLE-AND-HOLD APPLICATIONS

A basic sample-and-hold circuit consists of a switch and an R-C network as shown in Fig. 21a. The capacitor charges to the peak value of the input signal when the switch is closed. When the switch is opened, the capacitor "holds" the full charge. The ROFF of the CD4016A is typically $1012 \Omega$, $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}$, and the leakage is 10 pA , which is excellent for sample-and-hold circuits.

Fig. 21b shows a complete sample-and-hold circuit. The operational amplifiers are used to buffer and to assure stability of operation. When the clock is a logic " 1 ", the CD4016A is "ON" and the input is being sampled. When the clock is a logic " $O$ ", the CD4016A is "OFF" and the capacitor holds the value of the sample. The effective sampling-time constant for this circuit is

$$
\mathrm{t}=\frac{10 \mathrm{RC}}{1+\mathrm{A}}
$$

Fig. 20b shows the output voltage waveforms for the circuit


Fig. 19-a) $R-2 R$ resistive ladder network $D / A$ converter (voltage-fed); b) output voltage waveforms for $d c$
input voltage; c) output voltage waveforms for ac input voltage. (See Data Bulletin File No. 479 for details of terminal connections).


Fig. 20- a) $R$-2R resistive ladder network D/A converter (current-fed); b) output voltage waveforms for dc

input voltage; c) output voltage waveforms for ac input voltage.


Fig. 21- a) Basic sample-and-hold circuit; b) sample-and-hold circuit using the CD4016A; c) input and output voltage waveforms.
where A is the open-loop voltage gain of the first CA3030A op-amp (typically 60 dB ). The second CA3030A op-amp (unity-gain-non-inverting) provides isolation of the output. This output voltage is fed back and compared with VIN in the first op-amp. Any voltage offsets or variations within the loop do not affect the output. Fig. 21c shows input and output voltage waveforms of the circuit ( $\mathrm{R}=500 \mathrm{k} \Omega$, $\mathrm{C}=530 \mathrm{pF}$ ).

Sample-and-hold circuits (without feedback) can be used to implement analog delay lines. A block diagram of an analog delay is shown in Fig. 22. Charge is transferred from one capacitor to the next at each clock pulse. Alternate switches in the delay line open and close simultaneously.


Fig. 22- Analog delay line.
The total delay of the system is given by

$$
\mathrm{t}_{\mathrm{d}}=\frac{\mathrm{M}}{\mathrm{f}_{\mathrm{s}}}
$$

where $M$ is the number of stages,
$f_{S}$ is the sampling frequency ( $\mathrm{f}_{\mathrm{S}}>2 \mathrm{f}_{\mathrm{m}}$ ), and
$f_{m}$ is the maximum frequency of the input signal.

## SQUELCH CONTROL (LEVEL DETECTOR)

Fig. 23a shows a squelch circuit. When the input signal reaches a voltage level (determined by the $1 \mathrm{M} \Omega$ resistor), the CD4016A will be gated "ON" and the output signal will be the same as the input. When the input signal is below this value, the CD4016A will be gated "OFF" and there will be no output from the CD4016A.

The control circuitry (CA3030A and CD4007A) functions as follows: The input signal is passed through a diode-capacitor peak detector, whose output will be the envelope of the input waveform. This output is amplified by the CA3030A (whose gain is made variable by adjustment of $\mathrm{R}_{1}$ ), and applied to the gate input of the CD4007A. The CD4007A is used as a NAND gate and has a very sharp switching voltage characteristic in this configuration. When the input to the CD4007A is equal to or greater than the switching voltage, the CD4007A is "ON" and a logic "O" will appear at the control gate of the CD4016A and turn off the switch. When the input voltage to the CD4007A is less than the switching voltage the CD4007A is off and a logic " 1 " appears at the control gate of the CD4016A and the desired signal reaches the output. Fig. 23b shows the output voltage waveforms.

The variable resistance which is a front-panel control permits the adjustment of the squelch threshold. This type of circuit is used in communication systems and in systems in which the signal must have a specific voltage level to be transmitted.


Fig. 23-a) Squelch control (level detector) circuit; b) input and output voltage waveforms:

## SUMMARY

The CD4016A switch offers the design engineer an electronic switch that can be used in a wide variety of applications, including transmission and multiplexing of analog or digital signals over a large range of voltage levels and signal frequencies. The CD4016A can also perform switching and logic function implementation with low power dissipation. The low "ON" resistance, high "OFF" resistance, wide input signal range, no offset from input to output, and control inputs that are compatible with standard logic voltage levels make the use of the CD4016A highly advantageous to the designer.

## REFERENCES

1. RCA data bulletin File No. 479, pp. 39-43.
2. RCA data bulletin File No. 479, pp. 30-32.
3. "Design of fixed and programmable counters using the RCA CD4018 COS/MOS presettable divide-by- ${ }^{\prime}$ ' counter", by J. Litus, Jr., ICAN-6498.
4. "Astable and monostable oscillators using RCA COS/ MOS digital integrated circuits", by J. A. Dean and J. P. Rupley, ICAN-6267.

# Interfacing COS/MOS With Other Logic Families 

By A. Havasy and M. Kutzin

The interface of different logic families requires that the circuits operate at a common supply voltage and have logic level compatibility. In addition the devices must maintain safe power dissipation levels and good noise immunity over the required operating temperature range.

The RCA CD4000A COS/MOS series circuits operate from power-supplies of 3 to 15 V . Thus they can drive and be driven by a number of logic families (within certain conditions and limitations), including all DTL and TTL families. COS/MOS devices have high noise immunity, low quiescent power dissipation and high packing densities. This Note describes the conditions governing the interface of COS/MOS logic circuits with other logic families.

## COS/MOS-TTL/DTL Interface

Fig. 1 shows the voltage characteristics required at the output and input terminals of saturated logic devices. Fig. 2 shows the COS/MOS input and output characteristics at $\mathrm{V}_{\mathrm{DD}}=5 \mathrm{~V}$. The COS/MOS devices are designed to switch at a voltage level of $30 \%$ of the power supply voltage. However, TTL/DTL devices are designed to switch at 0.8 V for inputs going high and 2 V for inputs going low.


Fig. 1- Interface voltage characteristics required at the output and input terminals of saturated logic devices.


Fig. 2- COS/MOS input and output characteristics at a power-supply voltage of 5 volts.

When interfacing one type of digital integrated circuit with another, attention must be given to the logic swing, output drive capability, dc input current, noise immunity, and speed of each type. Table I shows a comparison of these parameters for COS/MOS, medium power TTL and medium power DTL. The supply voltage column of Table I shows that both saturated bipolar and COS/MOS devices may be operated at a supply voltage of 5 V . Both logic forms are directly compatible at this supply voltage (with certain restrictions).

## Bipolar Driving COS/MOS

When a bipolar device is used to drive a COS/MOS device, the output drive capability of the driving device, the switching levels and input currents of the driven device are important considerations. Table I shows that only 10 picoamperes of dc input current are required by a COS/MOS device in either the " 1 " or " 0 " state. The input thresholds, (for the driven COS/MOS device) are 1.5 and 3.5 V , hence the output of the TTL/DTL driver must be no more than 1.5 V (" 0 " logic voltage) and no less than 3.5 V (" 1 " logic voltage) in order to obtain some noise immunity.

Table I-Comparison of COS/MOS, TTL, DTL Interfacing Parameters

| FAMILY | SUPPLY <br> VOLTAGE <br> (VOLTS) | LOGIC SWING/OUTPUT DRIVE CAPABILITY | DC INPUT CURRENT | NOISE IMMUNITY | PROPAGATION DELAYS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| cos/mos | 3.0 to 15 | $V_{S S}$ to $V_{D D}$ (driving COS/MOS) <br> Output drive is type dependent (see text). | 10 pA (typical) <br> 1 and 0 State | 1.5 at $V_{D D}=5 \mathrm{~V}$ <br> The switching point occurs from 30\% to 70\% of $V_{D D}$ which is 1.5 V to 3.5 V at $V_{D D}=5 \mathrm{~V}$ | 35ns (typical) for inverter $C_{L}=15 \mathrm{pF}$ |
| DTL and TTL | 4.5 to 5.5 | 0 State: <br> 0.4 V max. at $I_{\text {sink }}=16 \mathrm{~mA}$ <br> 1 State: <br> 2.4 V min. at $l_{\text {load }}=-400 \mu \mathrm{~A}$ | 0 State: <br> -1.6 mA max. <br> 1 State: <br> $40 \mu \mathrm{~A}$ max. | $\text { at } \mathrm{V}_{\mathrm{cc}}=5 \mathrm{~V}$ <br> 0.4 V guaranteed. The switching point occurs from 0.8 V to 2 V | 20 ns (typical) for inverter $C_{L}=15 \mathrm{pF}$ |

## Current Sinking

Fig. 3a shows the low state operation of a loaded bipolar driver stage. When the output drive circuit of the bipolar stage is in the low state, (as shown in Fig. 3b) the collector is essentially at ground potential. The "ON" transistor must go into saturation in order to assure a reliable logic " 0 " level ( 0 to 0.4 V ). To attain this voltage level there should be a high impedance path from the output to the power supply. Current sinking capability is not a problem in this configuration because the COS/MOS devices have extremely high input impedances (typically $10^{11} \Omega$ ). The voltage level is not a problem either; the COS/MOS devices have high noise immunity ( 1.5 V ).

## Current Sourcing

Current flows from the $\mathrm{V}_{\mathrm{CC}}$ terminal of a saturated logic output device into the input stages of the load, (i.e., the


Fig. 3- (a) Low-state operation of a loaded bipolar driver stage. (b) typical bipolar output-drive circuit in the low state.
output device acts as the current source for the load). Fig. 4 a shows high-state operation of a loaded bipolar driver stage. Whenever a typical bipolar driver circuit is in the high state, a pull up configuration (resistor or transistor) ties $\mathrm{V}_{\mathrm{CC}}$ to the output pin. The total load configuration should not draw sufficient current to reduce the output voltage level below the $\mathrm{V}_{\mathrm{IH}}$ required by the $\mathrm{COS} / \mathrm{MOS}$ devices.

There are three bipolar output configurations to consider:
a) Resistor pull-up
b) Open Collector
c) Active pull-up

## Resistor Pull-Up

Devices with resistor pull-ups, (shown in Fig. 4b) present no problem in the interface with COS/MOS devices.

${ }^{\prime} \mathrm{OH}=$ Maximum Permissible output driver current in high state ("1") (Driver Leakage).
IOL = Maximum output driver sinking current in low state (" 0 "').
IIL $=$ Low state input current drawn from the load stage (to the
$I_{1 H}=$ High state input current flowing into the load stage from driver.
Fig. 4- (a) High-state operation of a loaded bipolar driver stage. (b) typical bipolar output-drive circuit in the high state.

## Open Collector

Devices with open collectors require an external pull-up resistor as shown in Fig. 5. The selection of the external pull-up resistor is discussed below. It is recommended that when driving a COS/MOS device from an arrangement such as the one shown in Fig. 5, (with both VDD and VCC supply voltages at 5 V ) the driver should not fan out to any TTL/DTL gate, but can be fanned out to other COS/MOS devices.


Fig. 5- Example of DTL/TTL circuit with open collectors that require a resistor between the output and $V_{C C}$.

## Active Pull-Ups

When an active pull-up is used such as the transistor plus diode arrangement (shown in Fig. 6), there can be a problem in the " 1 " state because the minimum output level, (2.4V) cannot assure an acceptable " 1 " state input for the COS/MOS device. The 2.4 -volt minimum TTL/DTL output level is often specified at a load current of $400 \mu \mathrm{~A}$. However, negligible current is being drawn by the COS/MOS device, hence the minimum TTL/DTL high-output level would typically be 3.4 to 3.6 V under these conditions. There is no noise immunity in such a configuration. Therefore, it is recommended that a pull-up resistor be added from the output terminal of the bipolar device to $\mathrm{V}_{\mathrm{CC}}$. The selection of the external pull-up resistor is discussed below. N in the formulae [(2) and (4)] is equal to 1 , because it is not recommended that the outputs of devices that use active pull-ups be tied together.

When driving a COS/MOS device from such an output arrangement (as shown in Fig. 7), the driver should not fan out to TTL/DTL circuits; only to other COS/MOS devices.

## PULL-UP RESISTOR SELECTION

Selection of a pull-up resistor for a circuit requires consideration of fan-out, maximum allowable collector current in the low state (IOL max.), collector-mitter leakage current in the high state (ICEX), power consumption, power-supply voltage and propagation delay times. The minimum value of the external pull-up resistor in Fig. 8a is given by:

$$
\begin{equation*}
\mathrm{R}_{\mathrm{X}(\min )}=\frac{\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{OL}(\max )}}{\mathrm{I}_{\mathrm{OL}}-(\mathrm{M}) \mathrm{I}_{\mathrm{IL}}} \tag{1}
\end{equation*}
$$



Fig. 6- Transistor-diode pull-up.


Fig. 7- Modification of the circuit in Fig. 6 to drive COS/MOS devices.
where M is the number of COS/MOS load stages. The maximum value of the external pull-up resistor shown in Fig. 8 b is given by:

$$
\begin{equation*}
\mathrm{R}_{\mathrm{X}(\max )}=\frac{\mathrm{v}_{\mathrm{CC}}-\mathrm{V}_{\mathrm{IH}}}{(\mathrm{~N}) \mathrm{I}_{\mathrm{CEX}}+(\mathrm{M}) \mathrm{I}_{\mathrm{IH}}} \tag{2}
\end{equation*}
$$

where N is the number of TTL/DTL driver stages.
As previously discussed, the values of $\mathrm{I}_{\text {IH }}$ and IIL for the COS/MOS input currents in both high- and low-level states are approximately 10 pA and are neglected because their value is insignificant when compared with the value of the bipolar currents. Therefore, the equations for bipolar-toCOS/MOS interface using a pull-up resistor can be reduced to:

$$
\begin{align*}
& \mathrm{R}_{\mathrm{X}(\min )}=\frac{\mathrm{V}_{\mathrm{DD}}-\mathrm{V}_{\mathrm{OL}(\max )}}{\mathrm{I}_{\mathrm{OL}}}  \tag{3}\\
& \mathrm{R}_{\mathrm{X}(\max )}=\frac{\mathrm{V}_{\mathrm{CC}(\min )}-\mathrm{V}_{\mathrm{IH}(\min )}^{*}}{(\mathrm{~N}) \mathrm{I}_{\mathrm{CEX}(\max )}} \tag{4}
\end{align*}
$$

${ }^{*} V_{\text {IH }}$ in eq. 4 is the value for the COS/MOS Device.


Fig. 8a-Bipolar output (with pull-up resistor) driving COS/MOS in low-state operation.


CONDITIONS: ALL DRIVER STAGES IN HIGH STATE ("I")
Fig. 8b-Bipolar output (with pull-up resistor) driving COS/MOS in high state operation.

An example in which a typical 9000 -series TTL gate is used to drive a CD4000A COS/MOS gate the operating voltage and current specifications might be as follows:

Operating Voltage Current Specifications
$\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V} \pm 0.5 \mathrm{~V}$

$$
\mathrm{v}_{\mathrm{DD}}=5 \mathrm{~V}
$$

$$
\begin{aligned}
& \mathrm{I}_{\mathrm{OL}}=16 \mathrm{~mA}(\mathrm{TTL} \text { Gate }) \\
& \mathrm{I}_{\mathrm{IL}}=10 \mathrm{pA}(\operatorname{COS} / \mathrm{MOS} \text { Gate }) \\
& \mathrm{I}_{\mathrm{IH}}=10 \mathrm{pA}(\operatorname{COS} / \mathrm{MOS} \text { Gate }) \\
& \mathrm{I}_{\mathrm{CEX}}=10 \mu \mathrm{~A} \max \text { (TTL Gate) }
\end{aligned}
$$

$\mathrm{V}_{\mathrm{OL}}$ is obtained from Fig. 1 and is 0.40 V ;
$\mathrm{V}_{\mathrm{IH}}$ is obtained from Fig. 2 and is 3.5 V .
If $\mathrm{N} \& \mathrm{M}$ are both 1 , then:

$$
\begin{aligned}
& \mathrm{R}_{\mathrm{X}(\min )}=\frac{(5.5-0.4) \mathrm{V}}{16 \mathrm{~mA}} \approx 330 \Omega \\
& \mathrm{R}_{\mathrm{X}(\max )}=\frac{(5-3.5) \cdot \mathrm{V}}{100 \mu \mathrm{~A}}=15 \mathrm{k} \Omega
\end{aligned}
$$

For short propagation delay times, it is best to keep $\mathrm{RX}_{\mathbf{X}}$ small. However, power consumption increases rapidly at values below 1000 ohms. Some compromise is necessary. The typical power consumption is 14 mW (with the output of the TTL/DTL gate low) if a $2 k \Omega$ resistor is used. Final selection of the pull-up resistor, however, will depend on what is most important for the intended application: high speed or low power.

Figs. 8c and 8d show typical speed/power relationships as a function of RX for two popular bipolar open collector drivers. These figures illustrate the trade-off between speed and power; the power figure shown is the power dissipated in both the bipolar driver and the pull-up resistor.


Fig. 8c- Typical speed-power trade-off of open collector TTL buffer and pull-up resistor.


Fig. 8d-Typical speed-power trade-off of open collector TTL gate and pull-up resistor.

## COS/MOS DRIVING BIPOLAR

Figs. 9a and 10a show COS/MOS devices driving bipolar devices. The current sinking capability of the COS/MOS device must be considered when the device is driving a medium power DTL and TTL circuit. Table I shows that the TTL/DTL device requires no more than -1.6 mA in the " 0 " input state and a maximum of $40 \mu \mathrm{~A}$ in the " 1 " input state.

The COS/MOS device must be capable of sinking and sourcing these currents, while maintaining voltage output levels required by the TTL/DTL gate. Any given TTL/DTL gate will switch state at a voltage that ranges from 0.8 to 2 V . Hence the output drive capability of the COS/MOS driver must be at least $-40 \mu \mathrm{~A}$ for a given " 1 "-state output voltage of 2 V , and at least 1.6 mA for a given " 0 "-state output voltage of 0.8 V . In order to provide a noise margin of 400 mV , for the driven bipolar device, the COS/MOS device must sink 1.6 mA at a " 0 " logic state voltage of 0.4 V and $-40 \mu \mathrm{~A}$ at a logic " 1 " level at 2.4 V . For low-power TTL devices the required sink current is $180 \mu \mathrm{~A}$ at 0.4 V output.

## Current Sourcing

In the high-state operation, (Fig. 9b) VDD is normally connected to the driver output through one or more "ON" p-channel devices which must be able to source the total leakage current of the bipolar load stages. The published data for the particular COS/MOS and bipolar devices, must be consulted in order to determine the leakage currents (for the logic " 1 " state) and drive fan out to be used in the equation shown in Fig. 9a. Saturated-logic devices will not achieve their required switching levels unless this equation has been satisfied. All of the presently available COS/MOS devices are able to source $40 \mu \mathrm{~A}$ at 2.4 V , (supply voltage, $\mathrm{VDD}=5 \mathrm{~V}$ ), hence current sourcing is not a problem.

## Current Sinking

When the output of a COS/MOS driver is in the low-state an n-channel device is "ON" and the output is approximately at ground potential. The COS/MOS device sinks the current flowing from the bipolar input-load stage. The published data for the COS/MOS device must be consulted to determine the maximum output low-level sinking current, and the published data for the bipolar device must be consulted to determine its input low-level current.


Fig. 9- (a) Logic diagram for a COS/MOS device driving a bipolar device, high-state operation; (b) schematic diagram showing current flow.


Fig. 10- (a) Logic diagram for a COS/MOS device driving a bipolar device, low-state operation; (b) schematic diagram showing current flow.

Not all COS/MOS devices can sink 1.6 mA required by normal-power TTL devices at only a 0.8 V or 0.4 V " 0 "-state output level. Table II shows eleven types of COS/MOS circuits and their n -channel current-sinking capabilities at output voltages of both 0.8 and 0.4 V . The hex buffers can each sink 6 mA at 0.8 V and thus can drive $6 /(1.6)$ or, for recommended good noise immunity, three TTL/DTL gates (worst case).

Table II - Current Sinking Limits of COS/MOS Devices

| COS/MOS <br> TYPE | DESCRIPTION | SINK CURRENT-mA at $+25^{\circ} \mathrm{C}$ |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{\mathrm{OL}}=0 .$ <br> CERAMIC | VOLTS PLASTIC | $\mathrm{v}_{\mathrm{OL}}=0 .$ <br> CERAMIC | VOLTS <br> PLASTIC |
| CD4000A | Dual 3-input NOR Gate Plus Inverter | 0.4 | 0.3 | 0.8 | 0.6 |
| CD4001A | Quad 2-input NOR Gate | 0.4 | 0.3 | 0.8 | 0.6 |
| CD4002A | Dual 4-input NOR Gate | 0.4 | 0.3 | 0.8 | 0.6 |
| CD4007A | Dual Complementary Pair plus Inverter | 0.6 | 0.3 | 1.2 | 0.6 |
| $\begin{gathered} \text { CD4009A/ } \\ \text { CD4049A } \end{gathered}$ | Inverting Hex Buffer | 3.0 | 3.0 | 6.0 | 6.0 |
| $\begin{array}{r} \text { CD4010A/ } \\ \text { CD4050A } \end{array}$ | Noninverting Hex Buffer | 3.0 | 3.0 | 6.0 | 6.0 |
| CD4011A | Quad 2-Input NAND Gate | 0.2 | 0.1 | 0.4 | 0.2 |
| CD4012A | Dual 4-Input NAND Gate | 0.1 | 0.05 | 0.2 | 0.1 |
| CD4041A | Quad True/Complement Buffer | 0.4 | 0.2 | 0.8 | 0.4 |
| CD4031A (Q Output) | 64-Stage Static Shift Register | 1.3 | 1.3 | 2.6 | 2.6 |
| CD4048A | Expandable 8-Input Gate | 1.6 | 1.6 | 3.2 | 3.2 |

By paralleling inputs of the CD4000A, CD4001A, or CD4002A gates, " $N$ " times the sink current capability listed for each type may be obtained. Thus, all four inputs of one 4 -input NOR gate (CD4002A) could be tied together as shown in Fig. 11 for a maximum sink-current capability of 3.2 mA , which allows a fan out of two TTL/DTL gates at 0.8 V , or 1 TTL gate at 0.4 V .

Most COS/MOS MSI devices (such as counters and shift registers) have limited drive capability, hence their outputs may require buffering if they are to drive TTL/DTL gates. This buffering (use of added driver stages) can be provided by the hex buffers or any device with the same current sinking capability. The logic and circuit diagrams for the CD4009A and the CD4010A are shown in Figs. 12 and 13 , respectively.

The CD4009A and CD4010 have the added advantage of shifting voltage levels and may be used to interface TTL with COS/MOS devices operating at supply voltages up to 15 V as shown in Fig. 14. With this driving arrangement, designers who use higher voltages for COS/MOS circuits can achieve the maximum COS/MOS speed capability, as well as to be able to fan out to the bipolar devices. Fan out capability versus supply voltage for a bipolar supply level of 5 V and COS/MOS levels of 5 and 10 V is given in Table III. The drive capability of most COS/MOS devices enables them to drive some low power bipolar circuits (such as the 54 L and 74L series) directly, as shown in Fig. 15. Table IV gives dc fan out capability of COS/MOS devices driving low-power TTL devices in unit loads (as defined by the manufacturer) of 0.18 mA .

## COS/MOS-BIPOLAR HTL INTERFACE

Bipolar HTL (high-threshold-logic) circuits operate at voltage levels between 14 and 16 V . COS/MOS logic circuits

-Fig. 11- Method of interconnection of inputs of CD4002A to obtain maximum sink-current capability of 3.2 mA .

$v_{C C O} O^{-1}$

GND O-8
$v_{D D}{ }^{-16}$

$9255-4140$

Fig. 12- Logic and circuit diagram for the CD4009A.
can operate at these voltages as well, but generally are limited to voltages no higher than 15 V . HTL circuits are, in general, identical in construction to the DTL circuits with some resistance value changes necessary, as a result of the higher voltage levels used and the extremely important distinction of an added base/emitter junction in the reverse direction on the emitter side of the input transistor. This added junction is a zener diode which gives a higher threshold switching voltage. Conduction does not occur until the junction breaks down at a voltage of approximately 6.7 V . This provides the HTL with its high noise immunity.

Bipolar high-threshold-logic circuits have a more limited temperature range and dissipate much more power than do COS/MOS circuits. Therefore, care should be exercised when using the combination in extreme temperature environments, as the HTL resistance values vary by about 20 percent from


9755-414?
Fig. 13- Logic and circuit diagram for the CD4010A.
one end of their temperature range to the other. In addition, the bipolar transistor's sensitivity to temperature, increases the thermal runaway problems. The VOL level, propagation delay, and noise immunity of HTL circuits vary widely across the temperature range. COS/MOS circuits, however, show almost negligible variation for these same parameters over a temperature range that is approximately 75 -percent wider than that of HTL.


Fig.14-COS/MOS devices operating at 15 volts interfacing with TTL devices.


Fig. 15-COS/MOS devices driving low-power bipolar circuits.

The same general rules of interfacing described in the section that discusses COS/MOS-TTL/DTL interface also apply to the interface of HTL with COS/MOS circuits. Fig. 16 shows the voltage characteristics required at the output and input of an HTL device for a VCC $=15 \mathrm{~V}$. Fig. 17 shows the same characteristics for COS/MOS devices at $\mathrm{V}_{\mathrm{DD}}=$ 15 V . The HTL types either have a built in pull-up resistor (typically $15 \mathrm{k} \Omega$ ) or an active pull-up. An external pull-up resistor is unnecessary when COS/MOS devices are being driven by these HTL circuits. There is a difference in the noise immunity for these circuits. The dc noise immunity in the high state (logic " 1 ") will be 3.5 V for an active pull-up circuit and 5V (typically) for a resistor pull-up circuit.

Table III - Fanout Capability and Supply Voltage for the CD4009A/CD4049A and CD4010A/CD4050A

| $\mathrm{V}_{\mathrm{OL}}=0.4 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OL}}=0.8 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{DD}}{ }^{*}$ |
| :---: | :---: | :---: |
| All Package Types | All Package Types |  |
| 2 | 4 | 5 V |
| 4 | 7 | 10 V |
| ${ }^{*} \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$. |  |  |

Table IV - DC Fanout Capability of COS/MOS Devices Into Low Power TTL Devices

| TYPE | DESCRIPTION | FANOUT (UNIT LOAD $=0.18 \mathrm{~mA}$ ) |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & --- \text { PLASTIC----- } \\ & V_{\mathrm{OL}}=0.4 \mathrm{~V} \quad \mathrm{~V}_{\mathrm{OL}}=0.8 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & -- \text { CERAMIC---- } \\ & \mathrm{V}_{\mathrm{OL}}=0.4 \mathrm{~V} \quad \mathrm{~V}_{\mathrm{OL}}=0.8 \mathrm{~V} \end{aligned}$ |  |
|  |  |  |  |  |  |
| CD4000A | Dual 3-Input NOR gates plus Inverter | 1 | 3 | 2 | 4 |
| CD4001A | Quad 2-Input NOR gates | 1 | 3 | 2 | 4 |
| CD4002A | Dual 4-Input NOR gates | 1 | 3 | 2 | 4 |
| CD4006A | 18-Stage Static Shift register | 0 | 0 | 0 | 0 |
| CD4007A | Dual Complementary Pair-plus Inverter | 1 | 3 | 3 | 6 |
| CD4008A | 4-Bit full adder | 0 | 0 | 0 | 0 |
| CD4009A | Hex Buffer Inverter | 16 | 33 | 16 | 33 |
| CD4010A | Hex Buffer Non-Inverting | 16 | 33 | 16 | 33 |
| CD4011A | Quad 2-Input NAND gates | 0 | 1 | 1 | 2 |
| CD4012A | Dual 4-Input NAND gates | 0 | 0 | 0 | 1 |
| CD4013A | Dual type D Flip-Flops | 1 | 2 | 2 | 4 |
| CD4014A | 8-Stage static shift register Synchronous parallel-in/serial-out | 0 | 0 | 0 | 1 |
| CD4015A | Dual 4-stage static shift register Serial-in/parallel-out | 0 | 0 | 0 | 1 |
| CD4017A | Decade counter/divider plus 10 decoded decimal outputs | 0 | 0 | 0 | 0 |
| CD4018A | Presettable divide-by-N Counter | 0 | 0 | 0 | 0 |
| CD4019A | Quad AND-OR select gate | 1 | 3 | 2 | 4 |
| CD4020A | 14-Stage binary counter | 0 | 0 | 0 | 1 |
| CD4021A | 8-Stage static shift register Asynnchronous parallel-in/ serial-out | 0 | 0 | 0 | 1 |

The published data should be consulted to be sure that the rise, fall times and pulse widths of the HTL output are compatible with the required pulse width and input rise and fall time of the COS/MOS circuits. The procedure for the selection of a pull-up resistor for open-collector-output HTL circuits is the same as that of the open collector DTL/TTL. (See section that discusses pull-up resistors.) The procedure and equation for COS/MOS devices driving HTL are the same as those for COS/MOS devices driving DTL/TTL. The input current requirements for the HTL devices are obtained from the published data and substituted in the formulae. (See the section that discusses COS/MOS driving bipolar.) For example, the values, taken from the published data for a COS/MOS CD4009A driving a particular HTL circuit are as
follows:
Particular HTL Input Data: $\mathrm{V}_{\mathrm{CC}}=15 \mathrm{~V}$

$$
\mathrm{V}_{\mathrm{IH}}=8.5 \mathrm{~V} \min . \quad \mathrm{I}_{\mathrm{IH}} \max .=2.0 \mu \mathrm{~A} \text { (leakage) }
$$

$$
\mathrm{V}_{\mathrm{IL}}=6.5 \mathrm{~V} \max . \quad \mathrm{I}_{\mathrm{IL}}(\max .)=1.2 \mathrm{~mA}
$$

CD4009A COS/MOS output Data: $\mathrm{VDD}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=$ gnd

$$
\begin{array}{ll}
\mathrm{V}_{\mathrm{OH}}=14.99 \mathrm{~V} & \mathrm{~V}_{\mathrm{DD}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{SS}}=\mathrm{gnd} \\
\mathrm{~V}_{\mathrm{OL}}=0.01 \mathrm{~V} & \mathrm{I}_{\mathrm{OH}}=10 \mathrm{pA} \text { (leakage) } \\
& \mathrm{IOL} \max .=6 \mathrm{~mA} \text { (sinking) }
\end{array}
$$

The COS/MOS CD4009A easily provides the necessary voltage levels and sinking currents required to satisfactorily drive 5 of the HTL types in question.



Fig. 16-HTL output and input voltage charaçteristics at a $V_{C C}$ of 15 volts.

(a)


(c)



Fig. 17-COS/MOS output and input voltage characteristics at a VCC of 15 volts.
(b)

(d)



Fig. 18- Interface circuits used with high-speed ECL circuit.

## COS/MOS - ECL/ECCSL INTERFACE

Fig. 18 shows the interface of COS/MOS devices with ECL devices. High-speed ECL (emitter-coupled logic) and ECCSL (emitter-coupled current-steering logic) are nonsaturating bipolar logic families. The VCC to VEE voltage range is fixed from a ground level to -5 or -5.2 V ; logic " 1 " to logic " 0 " values are separated by only 300 . to 500 mV depending upon the particular type of ECL family used. Because each manufacturer shows different logic levels for a number of ECL families, care should be taken to use only the applicable values taken directly from the published data which describe the units chosen.

A logic " 1 " is the most positive frame of reference and a logic " 0 " the most negative. For example, for positive logic an RCA type CD2150 OR/NOR gate is at a logic " 1 " level when its voltage is -0.8 V and at a logic " 0 " when its voltage is -1.6 V (more negative value).

The COS/MOS device requires a greater voltage swing than that of the ECL, hence an amplifier circuit must be connected between the two when ECL drives COS/MOS. Several RCA linear amplifier circuits have been successfully used to provide higher switching level outputs from the high-speed ECL circuits. Among these are the differential amplifier arrays, (CA3026, CA3028, CA3049, CA3050, CA3051, CA3054) and wideband amplifiers. Use of a separate transistor circuit such as the one shown in Fig. 18e is suggested. Here the transistor must provide a voltage swing at the output of between VDD and VSS in order to drive the COS/MOS device from an input swing of only 0.8 V . Proper biasing of the transistor is essential. It is suggested that the VSS level for the COS/MOS circuit be the same as the VEE level of the ECL circuit, in order to minimize the number of power supplies as well as to provide better interface conditions.

The interfacing of COS/MOS devices that are driving ECL devices is a simpler matter. A number of methods are available to reduce the output voltage swing to 0.3 to 0.9 V . A precise resistor-divider network arrangement, an emitter follower, or numerous combinations of resistor, diode, and transistor configurations can successfully reduce the COS/MOS output swing (VDD to VSS) to the ECL logic " 1 ". and logic " 0 " levels. However, care must be taken to meet the necessary current sinking requirements of the ECL device in its logic " 0 " state. External circuitry is required when the COS/MOS circuit selected does not have the capacity to sink the current from the ECL load. Rise times, fall times, and pulse widths must be restricted to those specified in the published data.

## LEVEL SHIFTERS

The speed consideration is most important when a separate interfacing circuit is used. It is desirable, (unless high ac noise immunity is a prime design consideration) for the speed of the interfacing circuit to be maximized or at least made no slower than either type of logic. No interfacing device other than a pull-up resistor is required, however, between the COS/MOS and TTL logic at a supply voltage of 5 V. Speeds from the COS/MOS to TTL logic (which can be
found in the published data for COS/MOS devices) are comparable to the COS/MOS propagation delays. Speeds from TTL to COS/MOS, even with a large external resistor, are no slower than delay times for COS/MOS logic circuits. Speed, therefore, is not a problem in COS/MOS-TTL logic interfacing, if the clock rates are within the COS/MOS range.

When interfacing DTL or TTL devices with COS/MOS devices which are operated at a higher voltage supply, the same resistor-interface shown in Fig. 5 can be used. The resistor is tied to the higher level ( $\mathrm{V}_{\mathrm{DD}}$ ). The maximum supply voltage for the DTL and TTL gates, however, is specified at 8 V . Thus, not all units of this type may be used for interface applications that require higher supply voltages (VDD). Guaranteed operation at these higher supply voltages can be accomplished by selection of DTL and TTL units that have breakdown voltages [ $\mathrm{V}(\mathrm{BR}) \mathrm{CER}$ ] which exceed the COS/MOS operating voltage, or by using a level shifting circuit such as the level translator shown in Fig. 19. This circuit converts DTL, TTL, and RTL input logic levels to voltages compatible with COS/MOS circuitry. In interface applications, the supply voltage for the translator should be equal to the supply voltage required for the COS/MOS circuitry. The entire COS/MOS supply-voltage range, that exceeds that of the bipolar device, (up to 15 V ) may be used.

The COS/MOS CD4009A and CD4010A Inverting Hex Buffer and Non-Inverting Hex Buffer types, respectively, were designed to shift voltage levels from a driven high-voltage supply (VDD) level. This feature enables designers to operate COS/MOS circuits at 15 -volt (VDD) levels so that these circuits can achieve their maximum-speed capability, as well as fan out to lower voltage DTL or TTL circuits; or to any other logic forms which operate below the 15 -volt level. Further use of these circuits (CD4009A and CD4010A) is described in the COS/MOS-TTL/DTL interface and the COS/MOS-ECL interface sections. The statements in the former section concerning fan out and current sinking are applicable to all other compatible current-sinking logic families as well.


Fig. 19- Level translator used to convert DTL, TTL, and RTL input logic levels and voltages compatible with COS/MOS circuitry.

## COS/MOS TO P-MOS INTERFACE

A large number of p-MOS devices operate at supply voltages of $\mathrm{V}_{\mathrm{DD}}=0$ and $\mathrm{V}_{\text {SS }}=-6$ to -15 volts; voltages compatible to those required by COS/MOS devices. However, if the p-MOS system is using a negative logic convention, a conversion of COS/MOS positive logic functions must be made so that the two systems maintain a single logic criterion. Care must be taken when interfacing COS/MOS with p-MOS to assure that the same logic criterion is being used to describe each device type. An explanation of the
simple transposition from positive-logic NAND to negativelogic NOR and similar transpositions of other functions is given in the RCA COS/MOS Manual section "Logic Design" considerations.

## COS/MOS TO N-MOS INTERFACE

A number of $n$-MOS devices are available which function at the same VDD and $V_{S S}$ ranges of (COS/MOS devices) and with the same positive voltage logic levels. There is relatively no problem in directly interfacing these devices, when operated at the same VDD and VSS.

Appendix Table I - Common Logic Voltages, Supply Voltage and Temperature Range for COS/MOS Devices

| LOGIC <br> VOLTAGE |
| :--- | :--- |
| SYMBOL |$\quad$ DESCRIPTION



| Appendix Table II - Common Logic Voltages, Supply Voltage, and Operating Temperature Range Required to Interface with DTL/TTL Circuits |  |  |
| :---: | :---: | :---: |
| LOGIC VOLTAGE | DESCRIPTION | VOLTAGE (VOLTS) |
| $V_{\mathrm{OL}}$ <br> $\mathrm{VOH}_{\mathrm{OH}}$ <br> VIL <br> $\mathrm{V}_{\text {IH }}$ <br> $V_{C C}$ | Maximum output level in low-level output state Minimum output level in high-level output state Maximum input level in low-level input state Minimum input level in high-level input state Positive supply voltage | $\begin{gathered} 0.4 \\ 2.4 \\ 0.8 \\ 2.0 \\ 5.0 \pm 0.5 \end{gathered}$ |
| Operating Temperature Range: $-55^{\circ}$ to $+125^{\circ} \mathrm{C}-$ Full temperature range product. $0^{\circ}$ to $+85^{\circ} \mathrm{C}$-Limited temperature range product. |  |  |

Appendix Table III - HTL Common Logic Voltages, Supply Voltage and Operating Temperature Ranges

| LOGIC <br> VOLTAGE SYMBOL | DESCRIPTION | VOLTAGE |
| :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{OL}}$ <br> V OH <br> $V_{I L}$ <br> $\mathrm{V}_{\mathrm{IH}}$ <br> $\mathrm{V}_{\mathrm{NL}}$ <br> $\mathrm{V}_{\mathrm{NH}}$ <br> $V_{C C}$ | Maximum output level in low-level output state Minimum output level in high-level output state Maximum input level in low-level input state Minimum input level in high-level input state Worst case positive noise level tolerated at low level state <br> Worst case negative noise level tolerated at high Positive supply voltage | $\begin{gathered} 1.5 \mathrm{~V} \\ 13.5 \mathrm{~V} \\ 6.5 \mathrm{~V} \\ 8.5 \mathrm{~V} \\ 5.0 \mathrm{~V} \\ \\ 5.0 \mathrm{~V} \\ 15.0 \pm 1 \mathrm{~V} \end{gathered}$ |
| Operating Temperature Range $-30^{\circ} \mathrm{C}$ to $+75^{\circ} \mathrm{C}$ |  |  |

Appendix Table IV - ECL Common Logic Voltages, Supply Voltages and Operating Temperature Range

| LOGIC | DESCRIPTION | VOLTAGE RANGE** |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{OL}}$ | Maximum output level low-level state | -1.6 | -1.45* |
| VOH | Minimum output level high-level state | -. 8 | -.795* |
| $V_{\text {IL }}$ | Minimum input level low-level state | -1.4 | -1.7* |
| $\mathrm{V}_{\text {IH }}$ | Maximum input level high-level state | -. 75 | -1.1 |
| $\mathrm{V}_{\mathrm{NL}}$ | Worst case positive noise level tolerated at low-level state | .20* | .35* |
| $\mathrm{V}_{\mathrm{NH}}$ | Worst case negative noise level tolerated at high-level state | $-.235$ | -.305* |
| $V_{C C}$ | Positive supply voltage | 0 | 0 |
| $V_{\text {EE }}$ | Negative supply voltage | -5.5 | -5.0 |
| Temperature Range +10 to $+60^{\circ} \mathrm{C}$ |  |  |  |
| *At $T=+25^{\circ} \mathrm{C}$ <br> **These values are representative of the range for several ECL families. |  |  |  |

Digital Integrated Circuits
Solid State
Division

# Low-Power Digital Frequency Synthesizers Utilizing COS/MOS IC's 

by R. E. Funk -_.

Low-power low-cost digital frequency synthesizers are now achievable with Complementary Symmetry Metal-OxideSemiconductor (COS/MOS) integrated circuits. These devices dissipate nanowatt standby power and milliwatt operational power. The cost effectiveness of MOS/LSI now permits the designer to use digital frequency synthesis.

Digital Frequency synthesizers using integrated circuits offer the communications equipment designer several advantages as compared to the use of tuned circuits and banks of quartz crystals. These are:

1. Employment of digital MSI functions, which reduces the cost and increases reliability;
2. Only one crystal reference is used for all synthesized frequencies;
3. Spurious signals and unwanted harmonics are reduced (yielding a cleaner waveform) by the elimination of tuned circuits (resulting in lower manufac-turing-test costs and lower maintenance on equipment);
4. A simplified manual control by replacement of complex, and often unreliable, mechanical turning mechanisms with simple digitally coded switches.

Battery-powered digital frequency synthesizers have not been feasible because bipolar circuits require too much power. Additionally, the cost of this type of equipment could not be justified using bipolar IC's.

This Note describes digital phase-locked loops and the use of COS/MOS integrated circuits in the design and implementation of digital frequency synthesizers.

## REVIEW OF DIGITAL PHASE-LOCKED LOOP FUNDAMENTALS

The digital frequency synthesizer uses a phase-locked loop to produce desired output frequencies dependent upon the setting of a programmable counter. The counter is controlled by dialing up frequencies with front-panel control switches. The frequency setting of the switches is always proportional to a given programmable divider ratio.

Fig. 1 shows the phase-lock loop arrangement commonly employed. The output frequency of the programmable divide-by-" $N$ " counter locks onto and tracks the phase of the reference frequency. A phase difference between the divide-by-"N" counter output and the reference frequency produces a correction voltage at the output of the phase comparator. The polarity of this correction voltage is such that it will pull the voltage-controlled oscillator (VCO) frequency in such a direction that the divide-by-" N " output frequency will phase-track the reference frequency. Thus, for each setting of the frequency control switches, a digital code presets the divide-by-" $N$ " count to an integral number representing a desired output frequency. For each desired


Fig. 1. Basic digital phase-locked loop
output frequency, there is a corresponding unique phase difference and tuning voltage. At each "tuned condition", it is to be noted that the divide-by-" $N$ "-counter output frequency is phase-locked to the reference frequency and that the two frequencies are equal.

A low-pass filter is employed in phase-locked loops to remove time-variant components from the VCO control voltage. Otherwise, for example, the reference frequency and its harmonic output from the phase detector may be of sufficient magnitude to cause an audio-rate phase jitter at the VCO output, which can result in a most unpleasant distortion of the audio output.

## PRACTICAL DIGITAL PHASE-LOCKED LOOPS

In practical digital phase-locked loops for communications systems, VCO-output frequencies are often in the VHF and UHF bands, that is, from 30 to 400 MHz , and it is usually impractical or impossible to design IC divide-by-"N" counters that will operate within this range. For example, even high-power ECL circuits will not permit use of the complex divide-by-"N" function above 100 MHz . Required are low-cost techniques of lowering the VCO output frequency so that cost-effective low power MSI and LSI arrays can be employed as the logical divide-by-" N " counter. For low-power portable communications sets, efficient

COS/MOS arrays are employed using either of two basic techniques for lowering VCO output frequencies. These two techniques are prescaling and heterodyne down-conversion; they are described below.

## Prescaling

In the phase-locked loop diagram of Fig. 2 a fixed counter prescales the VCO output frequency down by a division factor of " $K$ " to the greatest value ( $f_{k}$ max) that can be handled by the I-C divide-by-"N" counter. The reference frequency ( $f_{r}$ ) is nominally equal to the channel spacing frequency ( $f_{c}$ ). However, where a prescaling counter is employed, the value of $f_{r}$ must be reduced by a division by " $K$ ". Hence:

$$
\begin{equation*}
\mathrm{f}_{\mathrm{r}}=\frac{\mathrm{f}_{\mathrm{c}}}{\mathrm{~K}} \tag{1}
\end{equation*}
$$

Phase-comparator reference frequencies are normally in the $1-$ to $-10-\mathrm{kHz}$ range, while the highly stable crystalcontrolled oscillators usually operate ( $f_{x}$ ) in the $2-$ to $-5-\mathrm{MHz}$ range. For this reason, divide-by-" $R$ " counters are employed where $f_{r}=\frac{f_{x}}{R}$

At phase-lock, the divide-by-" $N$ " output frequency ( $f_{n}$ ) tracks the reference frequency $f_{r}$, and so $f_{n}=f_{r}$. Furthermore, the modulo of the divide-by-" $N$ " counter ( N ) uniquely determines the output frequency ( $f_{0}$ ) that will satisfy the equation:

$$
\begin{equation*}
\mathrm{f}_{\mathrm{O}}=\mathrm{f}_{\mathrm{n}} \mathrm{KN} \tag{2}
\end{equation*}
$$

K operates in a fixed-integer counter, and N operates in a programmable modulo- N counter where the modulo is programmed by an external frequency-control code. The range of N is given by:

$$
\begin{equation*}
N \max =\frac{f_{o} \max }{f_{c}} \tag{3}
\end{equation*}
$$



Fig. 2. Digital phase-locked loop with prescaler
and

$$
\begin{equation*}
\mathrm{N} \min =\frac{\mathrm{f}_{\mathrm{o}} \min }{\mathrm{f}_{\mathrm{c}}} \tag{4}
\end{equation*}
$$

Having specified values of $K, N, R, f_{x}, f_{0}$, and $f_{c}$, it is simple arithmetic to completely specify all digital functions including the phase comparator, which, in most cases, also functions digitally. Further, the divide-by-"N" counter can be broken into decade or binary segments. This leads directly to specification of programmable-switch design. The low-pass filter can now be specified for optimum rejection of reference-frequency components.

However, since the frequencies of signals within the loop of Fig. 2 vary over a range of N , optimum stabilization of the negative part of the loop is compromised by the variation of gain with frequency. In addition to loop stabilization, the designer must also consider several other aspects of phase-locked loops. These matters are well covered in literature on the subject and include:

1. Loop settling time, loop switching time,
2. Resolution: related to reference-oscillator accuracy,
3. Spectral purity:
A. spurious outputs,
B. Signal-to-phase-noise ratio,
4. Loop modulation: Practical mode for transceivers,
5. Sweep mode: Applicable to test equipment usage,
6. System interface: A. Remote code programming,
B. Preset channel memory.

## Heterodyne Down-Conversion

Fig. 3 illustrates a digital phase-locked loop employing heterodyne down-conversion. Here the input frequency to the divide-by-" $N$ " counter ( $f_{k}$ ) is described as follows:

$$
\begin{equation*}
\mathrm{f}_{\mathrm{k}}=\mathrm{f}_{\mathrm{o}}-\mathrm{f}_{\mathrm{h}} . \tag{5}
\end{equation*}
$$

An offset crystal oscillator is employed to "mix down" the VCO output frequency ( $\mathrm{f}_{\mathrm{o}}$ ), and the desired output frequency range of $f_{k}$ is enclosed by suitable band-pass filtering. In the scheme shown in Fig. 3, the output frequency is expressed as:

$$
\begin{equation*}
\mathrm{f}_{\mathrm{o}}=\mathrm{f}_{\mathrm{n}} \mathrm{~N} . \tag{6}
\end{equation*}
$$

The input frequency to the " N " counter is given by:

$$
\begin{equation*}
\mathrm{f}_{\mathrm{k}}=\mathrm{f}_{\mathrm{o}}-\mathrm{f}_{\mathrm{h}} . \tag{7}
\end{equation*}
$$

The range of the " $N$ " counter is defined by these two equations:

$$
\begin{align*}
& \mathrm{N} \max =\frac{\mathrm{f}_{\mathrm{k}} \max }{\mathrm{f}_{\mathrm{c}}}  \tag{8}\\
& \mathrm{~N} \min =\frac{\mathrm{f}_{\mathrm{k}} \min }{\mathrm{f}_{\mathrm{c}}} \tag{9}
\end{align*}
$$

In many synthesizer systems employing heterodyne down-conversion, more than one value of offset frequency $\left(f_{h}\right)$ is switched in. For example, if the desired VCO output frequency band is broken into two equal ranges, and if values of $f_{h}$ are switched in for the two respective bands, the range of N will be exactly half that used in a prescaling system. The range of N will be traversed twice in tuning across the entire band. Practical application of this method is illustrated two paragraphs below in the description of an FM-broadcast-band synthesizer.

Advantages of heterodyne down-conversion are:

1. The reference frequency $\left(f_{r}\right)$ equals the channel spacing ( $\mathrm{f}_{\mathrm{c}}$ ); hence, the loop band-pass is wider,
2. Lowest power consumption; therefore, the offset oscillator and mixer can be extremely efficient.


Fig. 3. Digital phase-locked loop with heterodyne down-converter

The disadvantage of the heterodyne technique is that, because a second reference crystal and a mixer are needed, the designer may be afforded an unsought opportunity to demonstrate his prowess in eliminating spurious beat and sum frequencies.

## COS/MOS IN FM RECEIVER SYNTHESIZERS

## SYSTEM REQUIREMENTS

FM-broadcast-receiver synthesizers can be designed to use efficient COS/MOS IC's as principal counter elements. Both heterodyne and prescaling system techniques will be examined.

One-hundred FM channels are spaced 200 kHz apart in the $88-$ to $-108-\mathrm{MHz}$ band. The channel-1 carrier frequency is 88.1 MHz ; channel 100 is 107.9 MHz . Since the standard FM if frequency is centered at 10.7 MHz , the synthesizer must provide high-side LO-injection output frequencies of 98.8 to 118.6 MHz .

## PRESCALER SYSTEM DESIGN

FM synthesizer design parameters can be calculated and plugged into the block diagram of Fig. 2. The resulting synthesizer block diagram and parameter calculations are illustrated in Fig. 4. Each block is described below.

## Divide-by-"N" Counter

The divide-by-" N " counter is parallel loaded to have a unique count (modulus) for each required synthesizer output-channel frequency. It has been demonstrated that each counter step represents a $200-\mathrm{kHz}$ channel. For example, to tune the system to 118.6 MHz , a count of 593 . (See Fig. 4) is loaded into the counter and, hence, "divide-by-593" results. The " N " counter should be considered as counting down repeatedly from 593 to zero. Fig. 5 illustrates this counter's organization. Note that for each frequency integer, there is a one-to-one relation between each switch (one frequency integer) and the corresponding counter block.

For example, a divide-by-5 counter programs the $200-\mathrm{kHz}$ integer. Five counts of this counter step the $1-\mathrm{MHz}$ counter by a " 1 " count, etc.

While the span of the " N " counter must be 494 to 593 , as illustrated in Fig. 4, the actual range of a practical " N "-counter for an FM-band digital synthesizer can be offset as indicated in Table I. Here 6 counts (equivalent to a $1.2-\mathrm{MHz}$ offset) are added to both the top and bottom of the counter range to make the actual count span from 500 to 599; two simplifications in the synthesizer design result from this refinement: (1) the $100-\mathrm{MHz}$ binary count shown in Fig. 5 always starts in the $100-\mathrm{MHz}$ state, and, therefore, it does


Fig. 4. FM-band synthesizer using prescaler

Table I. Divide-by."N'"-Count/Frequency Relationships

| CHANNEL NO. | FM RECEIVER FREQUENCY ( fm ) MHz | $\begin{gathered} \text { LO } \\ \text { INJECTION } \\ \text { FREQUENCY }\left(f_{0}\right) \\ \left(f_{0}=f m+10.7\right) \\ M H z \end{gathered}$ |  | OFFSET FREQUENCY $\left(f_{0}+1.2 M H z\right)$ <br> MHz | $\begin{aligned} & \text { OFFSET } \\ & \text { N-COUNT } \\ & \text { (N + 6) } \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | 88.1 | 98.8 | 494 | 100.0 | 500 |
| 2 | 88.3 | 99.0 | 495 | 100.2 | 501 |
| 3 | 88.5 | 99.2 | 496 | 100.4 | 502 |
| 4 | 88.7 | 99.4 | 497 | 100.6 | 503 |
| 5 | 88.9 | 99.6 | 498 | 100.8 | 504 |
| 6 | 89.1 | 99.8 | 499 | 101.0 | 505 |
| ! | ; . | , | ! | : | : |
| : | $\cdots$ |  | : | ; | : |
|  |  |  | : | ; | ! |
|  |  |  | : | ; | : |
| : |  | ! | ; | : | : |
| : |  | : | ; | ; | ; |
| : |  | : | - | : | : |
| 98 | 107.5 | 118.2 | 591 | 119.4 | 597 |
| 99 | 107.7 | 118.4 | 592 | 119.6 | 598 |
| 100 | 107.9 | 118.6 | 593 | 119.8 | 599 |



Fig. 5. Divide-by-"N" counter organization
not have to be under switch control, and (2) the necessary one-to-one correspondence between switch position and " N "-count preset state is achievable. The latter statement means that when switching from channel 5 to channel 6 , as shown in Table I, the system is in fact switching from the $88.9-\mathrm{MHz}$ channel to the $89.1-\mathrm{MHz}$ channel. Note that the two least significant integers switch over. Note further that as the actual LO-injection frequency goes from 99.6 MHz to 99.8 MHz only one integer switches over. However, the $1.2-\mathrm{MHz}$-offset frequencies of 100.8 and 101.0 MHz do switch
over in the two least significant integers. Therefore, the $1.2-\mathrm{MHz}$ offset makes it possible to use the needed switch-compatible " N " counter.

Fig. 6 is a logic diagram showing the four counting elements of the " $N$ " counter illustrated in Fig. 4. Table II contains the counter truth tables, and Fig. 7 is a detailed logic diagram of the divide-by- 5 counter. Table III illustrates that the 9 -bit frequency-select code permits presetting the " N " counter to counts ranging from 500 to 599 . The counter


Fig. 6. Divide-by-"N" counter logic
"down-counts" to the " 8 " state, at which time a preset strobe count-recognition signal goes "high" (Output of G2 of Fig. 6). Fig. 8 shows the critical preset strobe-generation timing sequence. Following the "high" that appears on D of STFF (Fig. 6), the strobe goes "high" on the next positive clock transition as shown in Fig. 8. The strobe presets the entire " $N$ " counter to the dialed frequency. Note that the immediately succeeding positive clock transition is lost due to its being overlapped by the preset strobe. The second following clock transition, however, trips the counter to state $\mathrm{N}-1$. Table IV is a wiring truth table for two frequency-select switches, $S_{1}$ and $S_{2}$. The nine wires, $A^{\prime}$ through $N^{\prime}$, follow the patterns indicated and interface directly with the divide-by-"N" counter of Fig. 6.

## Divide-by-" N "-Counter Implementation

The divide-by-" $N$ " counter is the frequency-control element of the digital phase-lock loop. It is logically complex and must operate at the highest possible frequency consistent with minimum power for battery operation. The COS/MOS lowvoltage technology exhibits several characteristics that allow outstanding divide-by-" N "-counter performance. The

COS/MOS implementation and performance will be examined in depth.

Figs. 6 and 7 show COS/MOS counter logic containing the following complement of eight low-voltage devices.

1 CD4023A Triple 3-Input NAND Gate
1 CD4001A Quad 2-input NOR Gate
1/2 CD4002A Dual 4-iput NOR Gate
3 CD4013A Dual "D" Flip-Flop
2 CD4018A Presettable Decade Counter
Characteristics of the above devices are contained in data sheets in RCA bulletin 479. This family of low-voltage devices ( 3 volts to 15 volts) exhibits a typical flip-flop toggle rate of 10 MHz at 10 volts and a typical gate delay of 25 nanoseconds at 10 volts. In both cases a fan-out of 3 ( 15 picofarads) is used.

Before examining the performance of the " N " counter, some additional operating details are of interest. The four counter sections shown in Fig. 6 are rippled; that is, they are not synchronously clocked. Because of that, speed and, hence, COS/MOS power, is substantially less in each succeeding counter section from left to right; the divide-by-2

Table II. Divide-By-"N" Counter Truth Tables
(a) Divide-by-5 Counter

(b) Divide-by- 10 Counter

| $X 1 \mathrm{MHz}$ | $D$ | $E$ | $F$ | $G$ | $H$ |
| :---: | :--- | :--- | :--- | :--- | :--- |
| $X 10 M H z$ | 1 | $J$ | $K$ | $L$ | $M$ |
| 9 | 0 | 0 | 1 | 1 | 1 |
| 8 | 0 | 0 | 0 | 1 | 1 |
| 7 | 0 | 0 | 0 | 0 | 1 |
| 6 | 0 | 0 | 0 | 0 | 0 |
| 5 | 1 | 0 | 0 | 0 | 0 |
| 4 | 1 | 1 | 0 | 0 | 0 |
| 3 | 1 | 1 | 1 | 0 | 0 |
| 2 | 1 | 1 | 1 | 1 | 0 |
| 1 | 1 | 1 | 1 | 1 | 1 |
| 0 | 0 | 1 | 1 | 1 | 1 |

(c) Divide-by-2 Counter

| $\times 100 \mathrm{MHz}$ | N |
| :---: | :---: |
| 1 | 1 |
| 0 | 0 | input-clock rate.

Briefly, counter operation is as follows:
(1) The synchronous divide-by-5 counter (Fig. 7) advances the $1-\mathrm{MHz}$ decade counter once every five counts; that is, when $\mathbf{A}$ goes from 1 to 0 as shown in Table Il(a).
(2) The synchronous $1-\mathrm{MHz}$ decade counter advances the $10-\mathrm{MHz}$ decade once every 50 counts; that is, when $E$ goes from 1 to 0 as shown in Table II (b).
(3) The $10-\mathrm{MHz}$ decade advances the $100-\mathrm{MHz}$ binary counter once every 500 counts, that is, when $J$ goes from 1 to 0 .
(4) Preset count-logic state-recognition occurs at count 8 as shown in Table III.
(5) Preset strobe generation occurs at count 7 as shown in Fig. 8.

The CD4018A decade counter, which is a 5 -stage Johnson-counter configuration, has two outstanding characteristics.

1. Each flip-flop changes state at one-tenth of the input rate; hence, the power/speed ratio is minimized.
2. Frequency-control switching is accomplished using a single-wafer Johnson-code switch. A simple miniaturized 2-pole 10 -position switch is available from Grayhill (See Fig. 9).

## Divide-by-"N"-Counter Performance

Fig. 10 shows the divide-by-" $N$ " counter's power consumption as a function of operating frequency with a $V_{D D}$


Fig. 7. Divide-by-5 counter logic
of 15 volts. The curves show that a frequency of 8.7 MHz is possible. Maximum operating frequencies for 10 volts and 5 volts are 6.2 MHz and 2.7 MHz respectively. The maximum operating frequency required by the circuit in Fig. 4 is 5.93 MHz , which can be obtained with a supply potential of 9.6 volts and with a power consumption of 47 milliwatts.

Operation of the divide-by-" $N$ " counter using only a 3 -volt power supply is possible; in such a case, the maximum operating speed is 55 kHz and the power consumption is only 40 microwatts.

Fig. 11 illustrates the decrease in maximum operating frequency as the temperature is increased. This curve shows that up to $50^{\circ} \mathrm{C}$ the $5.93-\mathrm{MHz}$ operation can be achieved at a supply potential of 10 volts. The dynamic signal power remains fairly constant from $-25^{\circ} \mathrm{C}$ to more than $+100^{\circ} \mathrm{C}$, variations being well within 10 percent of the power dissipated at $50^{\circ} \mathrm{C}$. as shown in Fig. 12.

For $6-\mathrm{MHz}$ operation at 10 volts, the critical timing waveforms for generation of the preset strobe are shown in Fig. 13. Delay from the positive edge of the clock pulse of count 9 (Fig. 8) to the output of gate 2 (Fig. 6) is 250 nanoseconds. Maximum allowable delay is 320 nanoseconds or nearly two clock periods at 6 MHz . Thus, 60 nanoseconds of margin exist for safe operation.

The complementary nature of the COS/MOS devices permits a wide range of operating voltages to be used and yields high noise immunity. For example, the $p$ and $n$ thresholds are typically 1.5 volts for RCA CD4000A-series devices, permitting operation from 3 to 15 volts. Fig. 14 illustrates that $6-\mathrm{MHz}$ operation can be achieved using a 12 -volt supply having 2.3 volts peak-to-peak ripple.

Table III. Divide-By."N" Counter Recognition-State Truth Table


Fig. 8. Divide-by-"N" preset state timing

Quiescent power dissipated by any COS/MOS logic system is extremely low, and the quiescent power dissipated at $+25^{\circ} \mathrm{C}$ by the " N " counter of Fig. 6 is 2 microwatts at a $\mathrm{V}_{\text {DD }}$ of 10 volts. Fig. 15 shows the increase in quiescent power with increasing temperature. For the system described, however, the " N " counter runs continuously, so the quiescent power figure is academic, although some ultra-
low-power digital frequency-synthesizer systems do place the " N " counter and other loop elements on standby power periodically.

The complete divide-by-" $N$ " logic system shown in Fig. 6 can be integrated on one practical-sized LSI COS/MOS chip. For example, the logic of Fig. 6 uses approximately

Table IV. Frequency-Select Switch Table

| S1 (kHz) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| RECEIVER <br> FREQUENCY <br> kHz | POS. | $A^{\prime}$ | $B^{\prime}$ | $C^{\prime}$ |
| 900 | 5 | 0 | 0 | 0 |
| 700 | 4 | 0 | 1 | 1 |
| 500 | 3 | 1 | 1 | 1 |
| 300 | 2 | 1 | 0 | 1 |
| 100 | 1 | 1 | 1 | 0 |

## NOTE <br> $$
" O " \equiv \text { GROUND }
$$ <br> $$
" 1 " \equiv \mathrm{~V}_{\mathrm{DD}}
$$

1000 active transistors. definitely a state-of-the-art number of devices. Also, less than 16 I/O leads are necessary, making it feasible to package such a customized counter in a low-cost 16-lead plastic package. A more universal COS/MOS 4-decade counter, the CD4059A (Preliminary) can be adapted for use as the $\div \mathrm{N}$ counter.*

It is fair to compare the COS/MOS power consumption to the power consumption of a bipolar " N " counter performing the identical function. The popular 54 N TTL logic, or the equivalent, is used for high-speed counting, as shown in Fig. 16, and 54L logic, or the equivalent, is used for lower-speed functions.

Approximately 265 milliwatts at +5 volts is required by the bipolar design of Fig. 16, compared with only 50 milliwatts for the $\mathrm{COS} / \mathrm{MOS}$ design at a $\mathrm{V}_{\mathrm{DD}}$ of 10 volts.

## Divide-by-"R" Counter

The FM receiver synthesizer system shown in Fig. 4 requires a fixed reference counter to divide by 256 . To accomplish this, a $2.56-\mathrm{MHz}$ reference crystal oscillator is counted down to the $10-\mathrm{kHz}$ phase-comparison frequency.

[^32]|  | S2 (MHz) |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RECEIVER <br> FREQUENCY <br> MHz | POS. | $D^{\prime}$ | $E^{\prime}$ | $F^{\prime}$ | $G^{\prime}$ | $H^{\prime}$ | $\mathbf{I}^{\prime}$ |
| 107 | 20 | 0 | 0 | 1 | 1 | 1 | 1 |
| 106 | 19 | 0 | 0 | 0 | 1 | 1 | 1 |
| 105 | 18 | 0 | 0 | 0 | 0 | 1 | 1 |
| 104 | 17 | 0 | 0 | 0 | 0 | 0 | 1 |
| 103 | 16 | 1 | 0 | 0 | 0 | 0 | 1 |
| 102 | 15 | 1 | 1 | 0 | 0 | 0 | 1 |
| 101 | 14 | 1 | 1 | 1 | 0 | 0 | 1 |
| 100 | 13 | 1 | 1 | 1 | 1 | 0 | 1 |
| 99 | 12 | 1 | 1 | 1 | 1 | 1 | 1 |
| 98 | 11 | 0 | 1 | 1 | 1 | 1 | 1 |
| 97 | 10 | 0 | 0 | 1 | 1 | 1 | 0 |
| 96 | 9 | 0 | 0 | 0 | 1 | 1 | 0 |
| 95 | 8 | 0 | 0 | 0 | 0 | 1 | 0 |
| 94 | 7 | 0 | 0 | 0 | 0 | 0 | 0 |
| 93 | 6 | 1 | 0 | 0 | 0 | 0 | 0 |
| 92 | 5 | 1 | 1 | 0 | 0 | 0 | 0 |
| 91 | 4 | 1 | 1 | 1 | 0 | 0 | 0 |
| 90 | 3 | 1 | 1 | 1 | 1 | 0 | 0 |
| 89 | 2 | 1 | 1 | 1 | 1 | 1 | 0 |
| 88 | 1 | 0 | 1 | 1 | 1 | 1 | 0 |

Here. one CD4020A 14-stage ripple-carry counter may be used. Fig. 17 shows power consumption as a function of supply voltage for this counter. For a $\mathrm{V}_{\mathrm{DD}}$ of 5 volts, power is below 3 milliwatts for the $2.56-\mathrm{MHz}$ input. If an even lower-threshold-voltage COS/MOS device is used for the reference counter, such as the RCA TA5938, operating voltage and, hence, power consumption can be even lower. The TA5938 is a 14 -stage counter (CD4020A) manufactured with an ultra-low-threshold process, but still using the basic COS/MOS metal-gate technology. The thresholds of the TA5938 are less than 1 volt. Fig. 17 shows that only 0.4 milliwatts are consumed for $2.56-\mathrm{MHz}$ operation using the TA5938 at a supply potential of 2.3 volts.

## Phase Comparator

A simple type "D" flip-flop (COS/MOS CD4013A) will suffice for a phase comparator in the digital phase-lock loop system of Fig. 4. Fig. 18 shows the simple flip-flop phase comparator and low-pass filter; Fig. 19 demonstrates the operation of this phase comparator. Note that a positive charge is impressed on the low-pass filter when $f_{n}>f_{r}$ in the case shown. Also, phase-lock can occur only during $180^{\circ}$ of


## SWITCH POSITION 8

Fig. 9. Frequency control switch S?(Ref. Table IV)


Fig. 10. Divide-by-"N"-counter power consumption
the period. In the case shown in Fig. 19, negative feedback in the loop exists during the $180^{\circ}$ when $f_{r}$ is positive. When $f_{n}$ coincides with the negative-half phase of $f_{r}$, positive feedback exists in the loop and lock-up cannot occur. The waveforms of Fig. 19 show that when:

$$
\mathbf{f}_{\mathbf{n}}=\mathrm{f}_{\mathrm{r}},
$$

lock-up exists, and that when $f_{n}>f_{r}$, or $f_{n}<f_{r}$ either an out-of-lock condition exists or an error-correction voltage is being produced during lock-up.


Fig. 11. Divide-by-"N"-counter temperature-frequency characteristics


Fig. 12. Divide-by-"N"-counter dynamic power dissipation

The simple COS/MOS flip-flop phase comparator of Fig. 18 consumes only 0.1 milliwatts at a $V_{D D}$ of 10 volts. Although only one I-C flip-flop is required, a bulky LC filter must be provided to smooth and store the output error voltage. Also, such a phase comparator is non-centering; when loss of an input signal occurs, a maximum error voltage is created.

Another example of a COS/MOS low-power phase comparator is the familiar Exclusive-OR gate (CD4030A).
$\qquad$


Fig. 13. Strobe generation timing


Fig. 14. Divide-by-"N"-counter ripple-frequency characteristics


Fig. 15. Divide-by-"N"-counter quiescent power dissipation


Fig. 17. Divide-by-"R"-counter power consumption


Fig. 16. Bipolar-logic divide-by-"N" counter

The primary advantage in the use of this unit is that it will produce an error voltage for frequency centering when one of the inputs is lost. Either the Type I or Type II phase comparator of the CD4046A (low-frequency phase-locked-loop device) may also be used.

Another high-performance phase comparator is a sample-and-hold circuit amploying COS/MOS as shown in Fig. 20. The sample-and-hold phase comparator will substantially reduce the $10-\mathrm{kHz}$ carrier frequencies, thus reducing filter requirements for the loop and increasing the loop's gain-bandwidth product. COS/MOS IC's are used as the ramp generator and the sampling switch as illustrated in Fig. 21. Total power consumption at $10-\mathrm{kHz}$ operation is less than 15 milliwatts.

## Crystal Oscillator

The required $2.56-\mathrm{MHz}$ crystal oscillator can be implemented with a COS/MOS inverter-amplifier and feedback network as shown in Fig. 21.

The inverter is one-third of a CD4007A IC. Power consumption is approximately 2 milliwatts at a $\mathrm{V}_{\mathrm{DD}}$ of 5 volts.


Fig. 18. Flip-flop phase comparator

## SUMMARY OF DIVIDE-BY-"N" COS/MOS SUBSYSTEM

It has been demonstrated that COS/MOS can be effectively utilized in the synthesizer's divide-by-" $N$ " and divide-by-" $R$ " functions, in phase comparators, and in crystal oscillators.

Ten currently available CD4000A low-voltage COS/MOS parts can be utilized in the design of the COS/MOS portion of the FM synthesizer phase-locked loop. Soon, with the availability of a universal divide-by-" $N$ " subsystem, only three IC's will be needed to do the job. On a custom basis, the entire divide-by-" $N$ ", divide-by-" $R$ ", and phasecomparator functions can be integrated on one COS/MOS chip; this will be exceptionally cost effective and will also result in lower over-all power consumption.

For the complete synthesizer employing digital prescaling as shown in Fig. 4, the power consumption of the VCO and prescaler must be added to obtain the total synthesizer power of 204.4 milliwatts as shown in Table V. It is estimated that if the prescaler were designed to use high performance discrete devices it would consume less than 125 milliwatts and the VCO's could be designed to consume less than 25 milliwatts.


Fig. 19. Flip-flop phase comparator operation


Fig. 20. Sample-and-hold phase comparator

## FM SYNTHESIZER SYSTEM USING HETERODYNE DOWN-CONVERSION

From the previous discussion of the prescaling FM receiver synthesizer, it is apparent that system consumes relatively large amounts of power. The system described in Fig. 3, however, illustrates a heterodyne down-conversion technique that avoids high-frequency digital prescaling. Fig. 22 shows a detailed block diagram of a down-conversion system where a divide-by-2 prescaler is also employed to simplify the design.

Table VI shows how the heterodyne down-conversion operates. For frequencies selected between 88.1 MHz and 97.9 MHz , the respective LO-injection frequencies of 98.8 $\mathbf{M H z}$ and 108.6 MHz are down-converted by 98 MHz to 0.8 MHz and 10.8 MHz respectively. The range between those two frequencies then is prescaled by 2 down to 0.4 MHz and 5.4 MHz , which is the range of operating frequencies for the divide-by-" $N$ " counter. For the divide-by-" $N$ " counter of Fig. 22 the range is given by:


Fig. 21 Crystal oscillator

$$
\begin{align*}
& \mathrm{N} \max .=\frac{10.8 \mathrm{MHz}}{0.2 \mathrm{MHz}}=54,  \tag{10}\\
& \mathrm{~N} \min .=\frac{0.8 \mathrm{MHz}}{0.2 \mathrm{MHz}}=4 . \tag{11}
\end{align*}
$$

In order to simplify the correspondence between switch settings and counter-preset states, a $1.2-\mathrm{MHz}$, or " 6 -count", positive offset is introduced into the divide-by-" $N$ " counter design so that the range of $N$ is actually 10 to 60 , as shown in Table VI. For receiver frequencies between 98.1 MHz and $107.9 \mathrm{MHz}, 108 \mathrm{MHz}$ is mixed with the VCO output frequencies to down-convert to the 0.8 -to- 10.8 MHz range. Thus, the divide-by-" N " counter is "folded" and actually runs through the same count sequence for both of the two ranges of the band as illustrated in Table VI.

Table V. COS/MOS Divide-by-"N" Synthesizer Power Consumption

| FUNCTION | OPERATING <br> FREQUENCY | POWER <br> CONSUMPTION <br> (MILLIWATTS) |
| :--- | :--- | :---: |
| $\div$ N COUNTER | 5.93 MHz | 49 |
| $\div$ R COUNTER |  |  |
| $\phi$ COMPARATOR |  |  |
| CRYSTAL OSCILLATOR |  |  |
| VCO'S AND BUFFER |  |  |
| (ESTIMATED) | 1.28 MHz | 3 |
| PRESCALER | 1.28 MHz | 28 to 108 MHz |
| (ESTIMATED) | 98 to 108 MHz | 125 |



Fig. 22. Heterodyne down-conversion synthesizer

Table VI. Heterodyne Down-Conversion Operation


As Fig. 22 shows, the heterodyne system requires a " 2 " prescaler. Thus, the phase comparison reference frequency is now given by:

$$
\begin{equation*}
\mathrm{f}_{\mathrm{k}}=\frac{200 \mathrm{kHz}}{2}=100 \mathrm{kHz} \tag{12}
\end{equation*}
$$

and, compared to the presealing synthesizer, a 10 -to-1 improvement in loop bandwidth becomes apparent.

Since the divide-by-" N " counter now is required to span a count range of 10 to 60 , one less decade is required in the logic of the divide-by-"N" counter. Such a divide-by-"N" counter will operate in a fashion similar to the one described earlier in Fig. 6. Power consumption for this counter will be approximately 40 milliwatts at the $5.4-\mathrm{MHz}$ input rate for a $V_{D D}$ of 10 volts.

Even though the divide-by-" $R$ " counter consists of only five stages, instead of eight stages as needed for the prescaling system, power consumption again, as in that prescaling system, is concentrated in the first few flip-flops. The divide-by-" $R$ "-counter power dissipation is approximately 9 milliwatts at 3.2 MHz with a $\mathrm{V}_{\mathrm{DD}}$ of 10 volts.

The phase comparator required by the heterodyne system of Fig. 22 operates at 100 kHz as distinguished from the 10 kHz used in the prescaling system. Power consumption is now approximately 30 milliwatts for a sample-and-hold circuit design.

As has been noted, the heterodyne system (Fig. 22) requires a prescaler of " 2 " operating at up to 10.8 MHz . While a COS/MOS flip-flop can be used at this frequency, lowest power may be achieved by using a discrete flip-flop. Power could be less than 5 milliwatts.

Power consumption for the heterodyne type of FM synthesizer is summarized in Table VII, where total power
consumption is shown to be approximately 146 milliwatts. This is 58 milliwatts less than the 204 milliwatts consumed by the prescaling system.

## PRESET CHANNEL MEMORY

One of the many advantages of digitally tuning communications sets is the added versatility of control that emerges. For example, the digital channel-select word can be used to drive a digital display showing channel number and frequency. Another scheme often employed is to control the set remotely through a hard-wired serial bit-stream of data or through transmission and reception of a digital word.

An outstanding advantage of using low-voltage COS/ MOS to implement digital tuning is the cost effectiveness that permits adding a small preset channel memory to the system using the COS/MOS ultra-low-power memory capability. For example, a 4-word-by-9-bit memory will enable an individual to set up, by push button or rotary switch, four favorite FM stations within a given reception area.

A suitable preset memory scheme is depicted in Fig. 23. When $S_{1}$ is closed, the memory is powered from the primary system power source. However, when $S_{1}$ is opened and the set turned off, the small 3-volt battery supplies the few microamperes required to hold the memory in a non-volatile condition. Preset channels are written into the memory by setting up the selected channel on the frequency-select switches and switching the R/W switch to Write. The channel-select word is written into one of four words selected by the preset-select switch. By setting the R/W switch to Read and the $\mathrm{P} / \mathrm{M}$ switch to Preset, the " N " counter is thereby preset to retrieve any one of four selected words. When the $\mathrm{P} / \mathrm{M}$ switch is in Manual, the frequency-select switches control the divide-by-" N " counter directly.

Table VII. Power Consumption of Heterodyne Synthesizer

| FUNCTION | FREQUENCY RANGE MHz | POWER CONSUMPTION (MILLIWATTS) |
| :---: | :---: | :---: |
| $\div$ "N" COUNTER | 0.4 to 5.4 | 40 |
| $\div$ "R" COUNTER | 1.6 | 9 |
| CRYSTAL OSCILLATOR | 1.6 | 2 |
| $\phi$ COMPARATOR | 0.1 | 30 |
| $\div$ "K" COUNTER | 0.8 to 10.8 | 5 |
| VCO |  |  |
| (ESTIMATED) | 98.8 to 118.6 | 25 |
| MIXER AND OFFSET OSCILLATOR |  |  |
| (ESTIMATED) | 98 to 118.6 | 35 |
|  |  | 146 Total |

Fig. 24 illustrates mechanization of a 4-word-by-9-bit preset channel memory using two COS/MOS CD4039A scratch-pad memories. This memory chip is a 4 -word-by-8-bit unit with all of the requisite control inputs as shown in Fig. 23 and described in the paragraph above. The circuit is easily expandable in both word-length and bit-length by direct connections, needing no additional interfacing gates.

In system cost, size and performance, the preset channel memory using the CD4039A is unparalleled. For example, the preset channel memory shown in Fig. 24 will cost under $\$ 10$ per chip and will dissipate approximately 0.5 microwatts at a 3 -volt holding potential.

Either ordinary flash-light batteries or trickle-charge batteries can be used to provide long periods of maintenance-free operation.


Fig. 23. Digital preset channel-memory concept


Fig. 24. Preset channel-memory circuit

# Battery-Powered Digital-Display Clock/Timer and Metering Applications Utilizing the RCA CD4026A and CD4033A Decade Counters-7 Segment Output Types 

by R. Heuner, R. Knapp, J. Litus, Jr. and S. Niemiec

RCA CD4026A and CD4033A consist of a 5-stage Johnson decade counter and an output decoder which converts the Johnson code to a 7 -segment decoded output to drive each stage of a numerical display. The CD4033A has Ripple Blanking Input and Output (RBI and RBO) and lamp-test capability. The CD4026A has Display Enable capability. Both types are derived from the same basic layout but use different metallization patterns. Both types are particularly advantageous for display applications in which low power dissipation and/or low package count are important.

This Note describes the CD4033A and CD4026A and their use with various 7 -segment display units presently available. Interface packages and methods are discussed to help the designer select the best system to meet his needs. Also included are battery-operated systems for digital clocks and watches.

## CIRCUIT OPERATION AND PERFORMANCE CHARACTERISTICS

The inputs to the CD4033A IC are "Clock", "Reset", "Clock Enable", "Ripple Blanking Input" (RBI), and "Lamp Test" as shown in Fig. 1. The outputs are "Carry Out", "Ripple Blanking Output" (RBO), and the seven decoded outputs (a,b,c,d,e,f,g). A "high" reset signal clears the decade counter to its zero count. The counter is advanced one count at the positive clock signal transistion if the Clock Enable signal is "low". Counter advancement by way of the clock line is inhibited when the Clock Enable signal is "high". A timing diagram for the CD4033A is shown in Fig. 2. Antilock gating is provided on the Johnson counter to assure proper counting sequence.

The Carry-Out (Cout) signal completes one cycle every ten clock input cycles and is used to clock the succeeding decade directly in a multi-decade counting chain. The seven


Fig. 1- Logic diagram of CD4033A - decade counter/divider with decoded 7-segment display outputs.
decoded outputs ( $a, b, c, d, e, f, g$ ) illuminate the proper segments in a 7 -segment display device used to present the decimal number 0 to 9 . The 7 -segment outputs go "high" on selection.

The CD4033A has provisions for automatic blanking of the non-significant zeros in a multi-digit decimal number. This feature results in an easily readable display consistent with normal writing practice. For example, the number 0050.0700 in an eight-digit display would be displayed as 50.07. Zero suppression on the integer side is obtained by the connection of the RBI terminal of the CD4033A associated with the most significant digit in the display to a "low-level" voltage and the connection of the RBO terminal of the same stage to the RBI terminal of the CD4033A in the next-lower-significant position in the display. This procedure is continued for each succeeding CD4033A on the integer side of the display.

On the fraction side of the display, the RBİ of the CD4033A associated with the least significant bit is connected to a "low-level" voltage and the RBO of the same CD4033A is connected to the RBI terminal of the CD4033A in the next more significant-bit position. This procedure is continued for all CD4033A on the fraction side of the display.

In a purely fractional number (e.g. 0.7346 ) the zero immediately preceding the decimal point can be displayed by the connection of the RBI of that stage to a "high-level" voltage (instead of to the RBO of the next more significant stage). Similarly, the zero in a number such as 763.0 can be displayed by the connection of the RBI of the CD4033A associated with it to a "high-level" voltage. Ripple blanking of non-significant zeros provides an appreciable savings of display power.

The CD4033A has a "Lamp Test" input which, when connected to a "high-level" voltage, overrides normal



Fig. 2- CD4033A - timing diagram.
decoder operation and enables a check to be made of possible display malfunctions by putting the 7 outputs in the "high" state.

Figs. 3a, 3b, and 3c define the current capability of the 7 -segment outputs when selected for supply voltages of 3.5 V , $5 \mathrm{~V}, 10 \mathrm{~V}$ and 15 V . Table I shows the maximum ratings and some features of the CD4033A. (Additional information is given in the RCA data bulletin for the CD4033A, File No. 503).


Fig. 3- a) Output current capability of CD4033A, $V_{D D}=$ 3.5 and 5 V ; b) Output current capability of CD4033A, $V_{D D}=10,15 \mathrm{~V}$; c) Output current capability, $V_{D D}=5,10 \mathrm{~V}, T=-55^{\circ} \mathrm{C},+25^{\circ} \mathrm{C}$, $+125^{\circ} \mathrm{C}$.


Fig. 4- Logic diagram of CD4026A

Fig. 4 shows the logic diagram of the RCA CD4026A. The CD4026A is identical to the CD4033A except that the Ripple Blanking Input (RBI) and the Ripple Blanking Output (RBO) and lamp test capabilities have been replaced by a "Display Enable" control. An extra "C" segment output (not gated with the Display Enable) is available to retain the ability to implement the divide-by- 12 function. The power dissipation and output characteristics of the CD4026A and CD4033A are identical.

## DISPLAY-DRIVER CIRCUIT TYPES FOR USE WITH THE CD4033A AND CD4026A

## CD4009A/CD4010A - COS/MOS Hex Buffer/Logic

## Level Converters Inverting/Non-inverting

Figs. 5 and 6 show the circuit diagrams for the CD4009A (Inverting Hex Buffer) and CD4010A (Non-Inverting Hex Buffer), respectively. Six buffers are provided per package. Figs. 7 and 8 show $\mathrm{V}_{0}$ " O " output characteristics (n-channel) and $\mathrm{V}_{0}$ " 1 " output characteristics (combined p-and-nchannel devices) for both types.


Fig. 5- a) Schematic diagram (1 of 6 identical stages) of CD4009A.

Table I - Maximum Ratings and Features

## MAXIMUM RATINGS, ABSOLUTE-MAXIMUM VALUES

DC Supply Voltage (VDD - VSS)
Operating Temperature Range
(Ceramic \& TO-5)
(Plastic)
Storage Temperature Range
All Inputs

3 to 15 V
$-55^{\circ} \mathrm{C}$ to $+125{ }^{\circ} \mathrm{C}$
$-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
$-65^{\circ} \mathrm{C}$ to +1500 C
$\mathrm{V}_{\mathrm{SS}} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$

Features:
Noise Immunity $\quad 45 \%$ of VDD (Typical Value)
Clock Pulse Frequency $5 \mathrm{MHz} @ V_{D D}=10 \mathrm{~V}$
(Typical Value)


Fig. 6- a) Schematic diagram (1 of 6 identical stages) of CD4010A.


Fig. 7- a) CD4009A and CD4010A $V_{O}$ " $O^{\prime \prime}$ output drive capability, $V_{D D}=V_{C C}=3.5,5 \mathrm{~V}$; b) CD4009A and


Fig. 8- a) CD4009A \& CD4010A $V_{C C}-V_{0} " 1 "$ output drive capability, $V_{D D}=V_{C C}=10,5$, and $\left.3.5 \mathrm{~V} ; b\right)$

COMMON-EMITTER CONFIGURATION


92cs-179s8


CD4010A $V_{O}$ " $O$ " output drive capability, $V_{D D}=$ $V_{C C}=10,15 \mathrm{~V}$.


CD4009A \& CD4010A $V_{C C}-V_{O}$ "1" output drive capability, $V_{D D}=10 \mathrm{~V}$ and $V_{C C}=5 \mathrm{~V}$.

Fig. 9- a) Functional diagram of $C A 3081 ;$ b) $V_{C E(\text { sat })}$ as a function of $I^{\prime}$ at $T_{A}=25^{\circ} C$.

CA3081 and CA3082 - General-Purpose High-Current n-p-n Transistor Arrays.

Fig. 9a shows the schematic diagram of the CA3081 (common emitter array). Fig. 9b shows $\mathrm{V}_{\mathrm{CE}}$ (sat) as a function of $\mathrm{I}_{\mathrm{C}}$ for one of 7 identical transistors (See Ref. 1 for additional information.)

Fig. 10a shows the schematic diagram of CA3082 (common collector array). Fig. 10b shows $h_{F E}$ as a function of $I_{C}$ at $V_{C E}=3 \mathrm{~V}$.

## INTERFACING THE CD4033A AND CD4026A WITH POPULAR 7-SEGMENT DISPLAY TYPES

## Light Emitting Diodes

The MAN 3 (Monsanto or equivalent) is a low power monolithic, 7 -segment diffused planar GaAsP "Light Emitting Diode" display. Figs. 11a and 11b show the equivalent schematic and physical dimensions of the MAN 3 Fig. 11c shows brightness as a function of forward current. A fairly bright display ( 200 foot lamberts) is achieved at a


COMMON-COLLECTOR CONFIGURATION


Fig. 10-b) Functional diagram of CA3082; b) $h_{F E}$ as a function of $I^{\prime}$.
typical power dissipation of 8.5 milliwatts ( $1.7 \mathrm{~V} \times 5 \mathrm{~mA}$ ) per segment for a $100 \%$-duty-cycle drive mode. Greater display intensities can be realized by the utilization of
$V_{F}=1.7 \mathrm{~V}(T Y P$.$) TO 2.0 \mathrm{~V}(\mathrm{MAX}.) ; \mathrm{T}_{A}=25^{\circ} \mathrm{C} ; \mathrm{I}_{F}=5 \mathrm{~mA}$ $\Delta V_{F}=2 \mathrm{mV} /{ }^{\circ} \mathrm{C} \mathrm{I}_{\mathrm{F}}$ MAX /SEGMENT $=10 \mathrm{~mA}$ CONTINUOUS; TEMPERATURE RANGE: $-55^{\circ} \mathrm{C}<\mathrm{T}<+85^{\circ} \mathrm{C}$


CHARACTER SIZE:
. $115 \times 0.064$
WITH $10^{\circ}$ SLANT


NOTE: FOR ADOITIONAL INFORMATION SEE MONSANTO'S PUBLISHED DATA ESP 35 DATED $2 / 70$
(b)


Fig. 11-c) MAN-3 schematic diagram; b) Package physical dimensions; c) brightness as a function of forward current.

(o) 14-LEAD DUAL-IN-LINE PACKAGE

(b) 22-LEAD FLAT PACK


NOTE:FOR DETAL ED WFORMATION SEE HEWLETT PACKARD PUQLISHED DATA ON HPSOB2 SERIES SOLID STATE
NUMERIC INOICATOR DATED 6/70.

Fig. 12- Package physical dimensions for HP5082.

higher-forward-current drives for less than $100 \%$ duty cycle (i.e., Light Enhancement Factor equals dc current divided by pulsed current $I_{F}(A V)$ and is greater than unity, where both dc and pulsed current result in similar light intensity as seen by the human eye).

The requirement of lowest power at greatest light intensity makes it desirable to multiplex the display current between characters of a display, as well as between segments of a character. Display wiring may also be simplified by such multiplexing methods. Displays similar to MAN 3 characteristics, but containing multiple 7-segment display elements are available from Hewlett Packard and others. For example, Fig. 12 shows the approximate physical dimensions for the HP 5082 . Series of LED's. The characteristics are similar to those of the MAN 3.

Fig. 13 shows techniques for the interface of the CD4033A or CD4026A to the MAN 3 display at various supply voltage conditions. Fig. 13a shows a direct drive condition at $100 \%$ duty cycle for $\mathrm{V}_{\mathrm{DD}}$ between 9 and 15 V . A typical CD4033A can supply a forward current of 5 mA per segment with a supply voltage as low as 9 V and yields a fairly bright display. The power supply dissipation is approximately 45 mW per segment ( 9 V x 5 mA ).

(b)

(d)

Fig. 13- CD4033A (or CD4026A) being interfaced with MAN-3 at various supply voltages as shown.

For lower system power dissipation and separate logic and display supply sources, the RCA CD4010A COS/MOS Hex Buffer package can be utilized, as shown in Fig. 13b. In this case, the power supply dissipation per segment is less than $25 \mathrm{~mW}(5 \mathrm{~V} \mathrm{x} 5 \mathrm{~mA})$.

For supply voltages as low as 3.5 V , an n-p-n transistor array interface circuit is required as shown in Fig. 13c. External base or emitter resistors may be used to obtain finer control of forward current, depending on the $\mathrm{n}-\mathrm{p}-\mathrm{n}$ array selected. For supply voltages less than 3.5 V , both the CD4009A and a p-n-p transistor array interface-circuit are required as shown in Fig. 13d.

Fig. 14a illustrates a method for character-drivemultiplexing using the CD4033A. Character multiplexing and the use of higher forward-segment currents at less than $100 \%$. duty cycle permit light enhancement factors greater than 1 to be realized. This mode of operation (compared with the $100 \%$ duty cycle mode, for the same display brightness) permits savings in display power dissipation. Fig. 14b shows a similar character multiplexing arrangement using the CD4026A. The multiplexing is accomplished at the logic level, as opposed to switching the Display character ground currents. A Character Display Driver Multiplexing circuit to interface the CD4026A with the EPSOO2 series Multiple Character Display is shown in Fig. 14c. A remetallization (not shown), of the CD4033A could be used to eliminate the


象 $N$ IS THE NUMBER OF CHARACTERS IN THE DISPLAY.
$M$ IS THE NUMBER OF CHARACTER DISPLAY CONTROL COUNTER DECODED OUTPUTS. THE DISPLAY, CONTROL COUNTER CLOCK AND THE VALUE OF M DETERMINES THE DISPLAY DUTY CYCLE OF THE CHARACTERGY
(a)
" N " channel device of all segment outputs. This permits direct connection of respective segments of all characters to the base of one common set of CA3082 segment drivers. A common set of segment ground return resistors would be required at the base of each CA3082.

The MAN 1 is a 7 -segment diffused planar GaAsP "Light Emitting Diode" display. Figs. 15 a and 15 b show the equivalent schematic and physical dimension-diagrams of the MAN 1. Fig. 15 c shows the brightness as a function of forward current characteristics. Good brightness ( 275 foot Lamberts) is obtained at a forward current of 16 mA , for a $100 \%$ duty cycle drive mode.

Figs. 16a and 16b show the CD4033A or CD4026A being interfaced with the MAN 1 display at various supply voltages. The CD4009A (shown in Fig. 16a) is able to sink 16 mA or more at "0" output voltage up to 2 V , with a supply voltage ( $\mathrm{V}_{\mathrm{DD}}$ ) as low as 7 V . This feature permits a drop of 4 V or more across the MAN 1 diodes. When the CD4009A is used in this application care should be taken not to exceed its maximum power ratings ( $100 \mathrm{~mW} /$ per buffer stage; 200 mW per package).

The CD4033A (shown in Fig. 16b) provides a minimum base current of 0.4 mA into the CA3081 at a supply voltage of $V_{D D}=500 \mathrm{~V}$, for a forward current in excess of 12 mA . The forward voltage of the MAN 1 ( 4.0 V ) limits the minimum $\mathrm{V}_{\mathrm{DD}}$ to approximately 5.0 V .


Fig. 14-a) Character display drive multiplexing using the CD4033A and the MAN-3; b) character display drive multiplexing using the CD4026A and the'MANK3.


Fig. 14-c) Character display drive multiplexing using the CD4026A and the HP5082 Series.


Fig. 15-a) MAN-1 schematic diagram; b) package dimensions; c) brightness as a function of forward current.

## INCANDESCENT READOUTS

The Pinlite* Series " 0 " and " $R$ " devices are low-power, miniaturized, incandescent readouts. Fig. 17 summarizes the voltage-current requirements, brightness (foot-lamberts), and physical dimensions of these display devices. Figs. $18 \mathrm{a} \& 18 \mathrm{~b}$ show the CD4033A being interfaced with Pinlite devices.

Fig. 19a shows the physical dimensions of the RCA's NUMITRON Devices, DR2000 and DR2100 series. Brightness and segment current as a function of segment voltage are plotted in Figs. 19b and 19c. Typical brightness is 7000 ft . lamberts, at a segment voltage of 4.5 V and a current of 24 mA .

Fig. 20a and 20b show the CD4033A or CD4026A being interfaced with RCA NUMITRON Devices DR2000 Series
*Trademark of Pinlite, Inc.
displays. In Fig. 20a, if $\mathrm{V}_{\mathrm{DD}}$ is less than 8.0 v , a CD4010A buffer must be used between the CD4033A or CD4026A segments and the CA3081. For Fig. 20b, care should be taken not to exceed the maximum power dissipation of the CD4009A ( 100 mW per buffer unit, 200 mW per package).

## Low Voltage Vacuum Fluorescent Readouts

The TungSol Digivac S/G** Type DT1704B or DT1705D, Nippon Electric (NEC)-Type DG12E/LD915 and Sylvania Type 8894 are low voltage and low power Vacuum Fluorescent 7-Segment Readouts. Figs. 21a and 21b show the physical dimensions and brightness characteristics of the
**Trademark of Tung-Sol Division Wagner Electric Corp.


Fig. 16- a) CD4033A (or CD4026A) driving the MAN-1 at $7 V \leqslant V_{D D} \leqslant 15 V, V_{D D}=V_{C C} ;$ b) CD4033A (or CD4026A) driving MAN-1 at $V_{D D} \geqslant 5 \mathrm{~V}$.


Fig. 17- Pinlite, Inc. series " $O$ " and " $R$ " 7-segment display


Fig. 18- Interfacing CD4033A (or CD4026A) with Pinlite series " $O$ " and " $R$ " 7 -segment displays.


TungSol Digivac DT1704B \& DT1705D. A brightness level of 150 foot lamberts (typical) is indicated at a plate voltage of 25 V:. Fig. 22 illustrates a method of driving these devices with the CD4033A. The requirements are 100 to $300 \mu \mathrm{~A}$ per segment at tube voltages of 12 to 25 V depending on the required brightness level. The filaments require 45 mA at 1.6 V , (ac or dc). With a $\mathrm{V}_{\mathrm{ON}}=18 \mathrm{~V}$, medium brightness in low ambient light background, will result. The point of no noticeable glow is $\mathrm{V}_{\text {OFF }}=4.5 \mathrm{~V}$.

## DIGITAL TIMER/CLOCK/WATCH APPLICATIONS

The decoded 7 -segment outputs of the CD4033A can be utilized to control its counting function. Table II shows the truth table for the CD4033A segment and carry out signals. Figs. 23a to 23 h show the logic configurations for counting from 2 through 9 using the CD4033A signal for count control. The CD4026A can be utilized in a similar manner.


Fig. 22- Interfacing CD4033A (or CD4026A) with Tung-Sol S/G type DT1704B or DT1705D.


Fig. 23- Logic configurations to control counting functions of CD4033A.

## Digital Display Clock/Watch Configuration

## (Divide-by-60, Divide-by-60, Divide-by-12.)

Fig. 24 shows the logic diagram of a divide-by-60, divide-by-60, divide-by-12 digital-display counting circuit. The input clock-signal rate is 1 Hz . The two 60 counters cycle synchronously from 0 to 59 , while the 12 counter cycles from 1 to 12.

Figs. 25 a and 25 b show pertinent waveforms of the divide-by- 60 and divide-by- 12 sections, respectively. Minutes and hours updating switches (second rate) as well as the seconds, minutes and hours reset switches are provided. A 24-hour counter can be easily substituted for the 12 hour counter.

With reference to Figs. 24 and 25a, the CD4033A-II "b" segment goes low at the 59th clock pulse input. At the 60th clock pulse input, the CD4033A-I goes from a " 9 " to a " 0 " and the CD4013A-I is clocked to " 0 " state, which in turn resets CD4033A-II from a " 5 " to a " 0 ". A reset condition has been realized after 60 clock input pulses. The CD4013A-I is then set at the 5th clock input pulse in preparation for the next cycle.

With reference to Figs. 24 and 25b, the "c" segment goes low at the 12th clock input pulse. The CD4013A-III's Q output is low from the 10th clock input pulse. At the 13th clock input pulse CD4013A-IV is clocked to the " 1 " state

Table II - Truth Table - 7 Segment and Carry Out Signals

| COUNTER OF: | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| COUNT | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 |

DECODED OUTPUT

| $a$ | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $b$ | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 1 | 1 | 1 |
| c | 1 | 1 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 |
| $d$ | 1 | 0 | 1 | 1 | 0 | 1 | 1 | 0 | 1 | 1 |
| e | 1 | 0 | 1 | 0 | 0 | 0 | 1 | 0 | 1 | 0 |
| f | 1 | 0 | 1 | 0 | 1 | 1 | 1 | 0 | 1 | 1 |
| $C_{\text {out }}$ | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1 | 1 |
|  | 1 | 1 | 1 | 1 | 1 | 0 | 0 | 0 | 0 | 0 |

which in turn resets CD4013A-V and VI. The CD4013A-V and VI combination then generates a one second wide reset pulse to the CD4033A-V and CD4013A-III reset inputs, as well as a two second wide pulse to the clock enable input of the CD4033A-V to advance it to the " 1 " count. The reset and advance to one operation may be clocked at a rate much faster than the seconds clock.


Fig. 24-Divide-by-60, divide-by-60, divide-by-12 digital display counting circuit.


Fig. 25-a) Divide-by-60 voltage waveforms; b) divide-by-12 voltage waveforms.

The CD4026A may be utilized in place of the CD4033A, if "Display Blanking" is desirable to effect power savings. For this case the divide-by-12 function utilizes the ungated "C" output for counter gating.

## Battery Powered Digital Clock Prototype

## Using the MAN 3-LED Displays

Fig. 26 shows the photographs and logic diagram of a complete battery powered digital: clock prototype, utilizing MAN 3-LED display devices. A 9-V battery is utilized to drive all of the logic circuitry. Power drain on the $9-\mathrm{V}$ battery is approximately 7 mA continuous, (over $90 \%$ of which is consumed in the 262 kHz crystal oscillator configuration). Other oscillator configurations and lower crystal frequencies enable very significant reductions of this current drain. To conserve power, the MAN 3 display devices are powered by two series 1.5 volt batteries. The CD4010A's permit translation from the 9-V logic level to the lower voltage, higher current $3-\mathrm{V}$ display drive levels. While the display is activated, a maximum of approximately 120 mA of display current is required.

Although not utilized in the prototype shown, the character display multiplexing methods of Figs. 14a, b or c may be utilized for greater light enhancement and/or lower power dissipation.

## Battery Powered Digital Clock Prototype Utilizing TungSol Digivac S/G DT1704B's Displays

Fig. 27 shows the logic diagram and a photograph of a complete battery powered digital clock prototype utilizing TungSol Digivac display devices. As noted in the discussion of low-voltage vacuum fluorescent readouts, medium brightness levels are obtained under low to medium ambient light conditions. A larger display is achieved by use of the Digivac units than with the MAN 3 units. The logic is powered by two series $9-\mathrm{V}$ cells at $\mathrm{V}_{\mathrm{DD}}$ with a $4.5-\mathrm{V}$ zener offset of $\mathrm{V}_{\mathrm{SS}}$ (the logic sees $18 \mathrm{~V}-4.5 \mathrm{~V}=13.5 \mathrm{~V}$.) The logic circuit drives the $150-\mu \mathrm{A}$ segment plate currents of the Digivacs directly. The filament power for the Digivacs is supplied by two parallel $1.5-\mathrm{V}$ batteries. Filament power is off until a display is required.


Fig. 26- a) Photograph of battery-powered L.E.D. digital clock.


Fig. 26-b) Logic/Wiring Diagram


Fig. 27- a) Logic/Wiring Diagram.


Fig. 27- b) Photograph of Clock.

## OTHER DIGITAL CLOCK APPLICATIONS

Plug In Industrial Digital Wall Clocks - 100 V Powered Clock. If primary $110-\mathrm{V}$ power fails a rechargeable battery maintains current to the counters and the clock continues to operate. The displays go off until the $110-\mathrm{V}$ power is restored. When the $110-\mathrm{V}$ power is restored the display comes on; the clock continues to keep correct time; and no resetting is required. A "display on demand" feature with loss of the $110-\mathrm{V}$ power can also be included.

Commercial Digital Clock (110-V Powered Clock). The regulation requirements are from 3.5 V to 15 V .


Fig. 28-Block diagram dc metering using CD4033A or CD4026A.

Portable Elapsed Time Meter a digital watch, and a down-time clock are other applications which can be achieved through the use of the CD4033A or CD4026A.

## DIGITAL METER APPLICATIONS

The CD4033A and CD4026A are unique in that they have both counting and decoding on a single chip. The block diagram of Fig. 28 demonstrates the use of the CD4033A and CD4026A in digital meter applications where time multiplexing or sampling-and-display functions are utilized (to eliminate the need for holding circuits). An analog input is converted to a sequence of pulses where the pulse count is proportional to the analog input level. Sampling rates may be fast enough to result in an apparent fixed display, or they may be slower and cause noticeable changes in display during sampling. Longer display times or display blanking during sampling may be used to prevent flicker.

## Timers/Frequency-Delay-Phase Meters

Fig. 29 shows a general block diagram using the CD4033A or CD4026A in Digital Counter/Timers. As in the dc meter applications, time multiplexing of sampling and display functions is utilized.


Fig. 29- Block diagram using CD4033A or CD4026A in Digital-Counter/Timers.

## REFERENCES

1. RCA data bulletin for CA3081, CA3082 File No. 480
2. RCA data bulletin for CD4033A and CD4026A File No. 503

# COS／MOS Rate Multipliers－Versatile Circuits for Synthesizing Digital Functions 

by G．J．Summers

The RCA COS／MOS rate multipliers，CD4527B and CD4089B，are versatile MSI circuits that can be used as building blocks to generate a range of digital functions in low－power systems where minimum package count is desir－ able．Rate multipliers can be used in various applications， such as numerical control，instrumentation，digital filtering， and frequency synthesis．When used with an up／down counter and control logic，they can be used to perform such operations as multiplication，addition，subtraction，gener－ ation of algebraic equations and differential equations， integration，and to raise numbers to various powers． This Note discusses each of these applications and symmetric rate multiplication，the problem of eliminating round－off error in a direct frequency－synthesis application in a common－carrier multiplex system．

## Rate－Multiplier Description

The rate multiplier is a circuit that produces an output pulse train whose frequency is proportional to the product of two inputs．One of the inputs is a clock frequency， $\mathrm{f}_{\mathrm{c}}$ ，and the other a pre－programmed multiplier number（binary or BCD）whose value is fixed at a given instant．The output of the rate multiplier is a frequency whose average rate is equal to $f_{c} \mathrm{x}$ ，where $0<\mathrm{x} \leqslant 1$ ．Thus the output rate is always less than or equal to $f_{c}$ ，and，in general，is composed of pulses which are unevenly spaced．It should be noted that even though the output rate is time averaged to the correct fractional rate of the input，there is always a round－off error associated with the output．This error can be reduced by increasing the bit capacity of the multiplier．

The principle of rate multiplication may be illustrated with the aid of the simplified circuit of a binary rate multiplier shown in Fig．1（a）．Four bits of binary informa－ tion are used to perform multiplication by any factor from $1 / 16$ to $15 / 16$ by programming the $S_{8}, S_{4}, S_{2}$ ，or $S_{1}$ gates for the proper factor．The final output frequency， $\mathrm{f}_{\mathrm{x}}$ ，is obtained by ORing the outputs of each AND gate as shown in the figure．The timing diagram in Fig．1（b）shows how a value for $f_{x}=\left(\frac{6}{16}\right) f_{c}$ can be obtained by gating the $S_{4}$ and $S_{2}$ outputs．


Fig．1－（a）Simplified circuit of binary rate multiplier；（b）timing diagram for（a）．

The functional diagram of the CD4527B (BCD rate multiplier) is shown in Fig. 2. The BCD inputs can be


Fig. 2-Functional diagram of the CD4527B, BCD rate multiplier.
programmed from 1 to 9 to form an output multiplier constant of $1 / 10$ to $9 / 10$. For example, if the $B C D$ input were set to seven ( 0111 ), the output rate would be $f_{c}(7 / 10)$. This multiplication factor can be expanded to a greater number of bits by using the cascade/enable feature of the CD4527B as demonstrated in Fig. 3. The strobe feature


Fig. 3-BCD rate multiplier cascaded for multiplier A/1000, $1 \leqslant$ $A \leqslant 999$.
allows outputs to be enabled or inhibited. ${ }^{1}$

## RATE-MULTIPLIER APPLICATIONS

## Cascading

The rate multiplier can be connected in parallel or series as shown in Figs. 3 and 4. When devices are connected in parallel, as in Fig. 3, an n-bit rate multiplier is formed which obeys the input/output relation:

$$
f_{\text {out }}=\frac{A}{K^{n}} f_{\text {clk }}
$$

where $0<\frac{A}{K^{n}} \leqslant 1$

In the case of the CD4527B (BCD), the $\mathrm{K}^{\mathrm{n}}$ factor is $(10)^{n}$, where $n$ denotes the number of stages; for the CD4089B (binary), $\mathrm{K}^{\mathrm{n}}$ becomes (2) ${ }^{\mathrm{n}}$, where n denotes the number of bits.


Fig. 4-Multiplication of three variables, A, B, and C.

In the circuit of Fig. 3, three BCD rate multipliers are connected in parallel; they produce an output rate which is proportional to the input clock by any multiple of $\mathrm{A} / 1000$. The A variable can be made to assume any value from 1 to 999 by programming the BCD inputs with a logical 1 or a logical 0 . By using the CD4089B, the same circuit could be used to build a binary multiplier. The variable A would then range from 1 to 4095 , and $K^{n}$ would be (2) ${ }^{12}$ or 4096.

When rate multipliers are arranged serially, as shown in Fig. 4, two or more variables can be multiplied. The input/output relationship for the circuit shown in Fig. 4 is:

$$
f_{\text {out }}=\frac{\mathrm{A} \cdot \mathrm{~B} \cdot \mathrm{C}}{4096} \mathrm{f}_{\mathrm{clk}}
$$

where $1 \leqslant A, B$, or $C \leqslant 15$.

## Multiplication

Two or more variables can be multiplied by using three or more rate multipliers and one up/down counter. The output is then a fixed number, either BCD or binary, not a pulse rate or frequency as before. Thus, in this discussion, as well as in the following arithmetic applications, the output is referred to as $\mathrm{N}(\mathrm{N}=1,2, \ldots \ldots)$ and not $\mathrm{f}_{\text {out }}$ -

As an example, consider the circuit shown in Fig. 5. The input variables, $A$ and $B$, are programmed to a $B C D$ or binary number: the resultant output from the counter $\left(Q_{1}, Q_{2}, Q_{3}\right.$, $\left.\mathrm{Q}_{4}\right)$ is $\mathrm{N}=(\mathrm{A} \cdot \mathrm{B}) / \mathrm{K}$. For the CD4527B, $\mathrm{K}=10$, and for the CD4089B, $K=16$. Since the output of the up/down counter must be an integer from 1 to $9, \mathrm{~A} \cdot \mathrm{~B} / \mathrm{K}$ must also be an integer. For example, if $K=10, A=0101$, and $B=0100$, then $N=5(4 / 10)=2=0010$ as read on the $Q_{4}, Q_{3}, Q_{2}$, and $Q_{1}$ lines, respectively. Analysis of the circuit of Fig. 5 shows that:

$$
\begin{aligned}
& R_{1}=f_{\text {clk }}\left(\frac{A}{10}\right) \\
& R_{2}=f_{\text {clk }}\left(\frac{A}{10}\right)\left(\frac{B}{10}\right)=f_{\text {clk }}\left(\frac{A \cdot B}{100}\right) \\
& R_{3}=f_{\text {clk }}\left(\frac{N}{10}\right)
\end{aligned}
$$


$92 \mathrm{CM}-24873$
Fig. 5-Multiplication of two variables, $A$ and $B$.

The interface circuit (CD4001A) shown preceding the up/down counter in Fig. 5 is used to convert the counter from a single clock to a dual-clock input device. Since the counter must count both up and down at random intervals it is desirable to have separate inputs for the up and down commands. The counter cannot accept simultaneous inputs to the command terminal, therefore, a multi-phase clock frequency is used at the input.

In Fig. 5 the output rate, $\mathrm{R}_{2}$, addresses the "up count", and command, $R_{3}$, addresses the "down count" of the CD4510B or CD4516B. As $R_{2}$ and $\mathrm{R}_{3}$ change, the counter steps up or down until the loop stabilizes. The counter acts as a null detector, equalizing the input rates so that $\mathbf{R}_{\mathbf{2}}=\mathbf{R}_{\mathbf{3}}$ when stability is reached. Thus, at equilibrium:

$$
\mathbf{R}_{\mathbf{2}}=\mathbf{R}_{\mathbf{3}}
$$

or

$$
\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A} \cdot \mathrm{~B}}{100}\right)=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}}{10}\right)
$$

therefore

$$
\mathrm{N}=\left(\frac{\mathrm{A} \cdot \mathrm{~B}}{10}\right)
$$

If the true product $\mathrm{A} \cdot \mathrm{B}$ is desired, then another rate multiplier can be used in the feedback loop to eliminate the $1 / 10$ scaler multiplier. When the rate multiplier is programmed for a multiplier of $1, R_{3}=f_{c l k}\left(\frac{N}{100}\right)$; thus, $R_{2}=R_{3}$ yields $\mathrm{N}=\mathrm{A} \cdot \mathrm{B}$.

## Addition and Subtraction

Two or more variables can be added or subtracted by using three or more rate multipliers, one up/down counter, and one summing circuit. These circuits are constructed in a loop arrangement, as in Figs. 6 and 7, similar to the one shown for multiplication in Fig. 5.

It should be noted that a simple OR gate cannot be used to sum $R_{1}$ and $R_{2}$ because, if pulses occur simultaneously on $R_{1}$ and $R_{2}$ during the same clock period, information can be lost. The circuits shown in Figs. 6, 7, and 8 eliminate the problem provided the synchronization rate is higher than that of $R_{1}$ and $R_{2}$.

Fig. 6 is the diagram of a circuit used to sum two variables, $\mathbf{A}$ and $\mathbf{B}$. The figure shows that $\mathbf{R}_{1}$ and $\mathbf{R}_{\mathbf{2}}$ are summed and routed to the "up count" terminal of the counter. In subtraction, the summing circuit is placed in the signal path to the "down count" terminal of the counter, as illustrated in the circuit of Fig. 7. Both addition and subtraction can be performed.

In Fig. 6:

$$
\begin{aligned}
& \mathrm{R}_{3}=\mathrm{R}_{1}+\mathrm{R}_{2}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A}}{10}\right)+\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~B}}{10}\right) \\
& \mathrm{R}_{4}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}}{10}\right)
\end{aligned}
$$

Then, at equilibrium:

$$
\mathrm{R}_{3}=\mathrm{R}_{4}
$$

$\qquad$


Fig. 6-Addition of two variables, $A$ and $B$.


92CM-24874

Fig. 7-Combined addition and subtraction .
therefore

$$
\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A}}{10}\right)+\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~B}}{10}\right)=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}}{10}\right)
$$

or

$$
\mathrm{N}=\mathrm{A}+\mathrm{B}
$$

As discussed above, the circuit shown in Fig. 7 is used to add and subtract simultaneously. From Fig. 7:

$$
\begin{aligned}
& \mathrm{R}_{3}=\mathrm{R}_{1}+\mathrm{R}_{2}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A}}{10}\right)+\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~B}}{10}\right) \\
& \mathrm{R}_{6}=\mathrm{R}_{4}+\mathrm{R}_{5}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{C}}{10}\right)+\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}}{10}\right)
\end{aligned}
$$

Then, at equilibrium:

$$
R_{3}=R_{6}
$$

and

$$
N=A+B-C
$$

Finally, the average-rate output of the rate multiplier can be modified by the sum of two variables by using the less complex circuit shown in Fig. 8. It should be noted that the output is a time-averaged rate, not a fixed number, N , as before.


## Division

Fig. 8 - The sum of two variables, $A$ and $B$, with a constant multiplier.

## Square Roots/Higher-Order Roots/Algebraic Equations

The RCA COS/MOS rate multiplier can be used in circuits such as those shown in Figs. 10 and 11 to generate roots of the form $\mathrm{A}^{\mathrm{x} / \mathrm{y}}$, where x and y are integers. The up/down counter is also used in a feedback loop configuration, as in Figs. 5 through 8, above, to perform this operation. The circuit shown in Fig. 11 can also be used to generate $\mathrm{A}^{1 / 3}$ by programming one of the three rate multipliers with the variable A and the other two with unity.

From Fig. 10:

$$
\begin{aligned}
& \mathrm{R}_{1}=\mathrm{f}_{\mathrm{clk}}\left(\frac{1}{10}\right)\left(\frac{\mathrm{A}}{10}\right)=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A}}{100}\right) \\
& \mathrm{R}_{2}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}}{10}\right)\left(\frac{\mathrm{N}}{10}\right)=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}^{2}}{100}\right)
\end{aligned}
$$

Then, at equilibrium:

$$
R_{1}=R_{2}
$$

therefore

$$
N=\sqrt{A}
$$

Two variables, $A$ and $B$, can be divided by use of the circuit shown in Fig. 9. Two rate multipliers are connected in parallel to form the A variable. The parallel connection ensures that the multiplier constant, $1 / 10$, does not appear in the final result, A/B. From Fig. 9:

$$
\begin{aligned}
& \mathrm{R}_{1}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A}}{100}\right) \\
& \mathrm{R}_{2}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~B}}{10}\right) \\
& \mathrm{R}_{3}=\mathrm{R}_{2}\left(\frac{\mathrm{~N}}{10}\right)=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}}{10}\right)\left(\frac{\mathrm{B}}{10}\right)
\end{aligned}
$$

At equilibrium, $\mathrm{R}_{\mathbf{1}}=\mathrm{R}_{\mathbf{3}}$; therefore:

$$
\frac{\mathrm{A}}{100}=\left(\frac{\mathrm{N}}{10}\right)\left(\frac{\mathrm{B}}{10}\right)
$$

or

$$
N=\frac{A}{B}
$$

From Fig. 11:

$$
\begin{aligned}
& \mathrm{R}_{1}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A}^{2}}{100}\right)\left(\frac{1}{10}\right)=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~A}^{2}}{1000}\right) \\
& \mathrm{R}_{2}=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}}{10}\right)\left(\frac{\mathrm{N}}{10}\right)\left(\frac{\mathrm{N}}{10}\right)=\mathrm{f}_{\mathrm{clk}}\left(\frac{\mathrm{~N}^{3}}{1000}\right)
\end{aligned}
$$

At equilibrium, $\mathrm{R}_{1}=\mathrm{R}_{\mathbf{2}}$; therefore:

$$
N^{3}=A^{2}
$$

or

$$
N=A^{2 / 3}
$$

In addition to generating roots of the form $A^{x / y}$ various algebraic equations can be generated and solved by combining the root-determining techniques with those used in multiplication, division, addition, and subtraction. Only block diagrams with input/output relationships are shown for these circuits owing to the complexity of the wiring interconnects.


92CM-24872
Fig. 9-Divison of the variable $\mathbf{A}$ by the variable $\boldsymbol{B}$.


Fig. 10 -Generation of $A^{1 / 2}$


Fig. 11-Generation of $A^{2 / 3}$

From Fig. 12:
$R_{1}=A^{2} / K^{2 n}$
$R_{2}=B^{2} / K^{2 n}$
$R_{3}=N^{2} / K^{2 n}$

Then, at equilibrium:

$$
R_{1}+R_{2}=R_{3}
$$

therefore,

$$
N^{2}=A^{2}+B^{2}
$$



Fig. 12-Generation of the equation $N^{2}=A^{2}+B^{2}$.

The COS/MOS CD4527B and CD4089B rate multipliers can also be used to solve a known equation. For example, Fig. 13 can be used to solve the well-known quadratic equation,


Fig. 13-Solutions of the quadratic equation, $a x^{2}+b x+c$.
92CM-24875
$a x^{2}+b x+c=0$. The solutions, $x_{1}$ and $x_{2}$, are assumed to be real, and can be found by monitoring the output of counter $\mathrm{N}_{3}$. As discussed above, the $\mathrm{K}^{\mathrm{n}}, \mathrm{K}^{2 \mathrm{n}}$ factors are the multiplication factors inherent with the type of rate multiplier (BCD or binary) used.

## Frequency Ratios

The circuit shown in Fig. 14 can be used to compute the ratio of two frequencies, $f_{1}$ and $f_{2}$. Since the frequencies are usually random, care should be taken to condition these inputs to ensure that coincidence does not occur at the counter command input. Fig. 15 shows a circuit that can be used to condition the input frequencies. ${ }^{4}$ The input clock frequency should be at least 4 times faster than the highest input frequency ( $f_{1}$ or $f_{2}$ ).

## From Fig. 14:

$$
\mathrm{R}_{1}=\mathrm{f}_{1} / \mathrm{K}^{\mathrm{n}}
$$

and

$$
\mathrm{R}_{2}=\mathrm{f}_{2} \mathrm{~N} / \mathrm{K}^{\mathrm{n}}
$$

Then, at equilibrium, $\mathrm{R}_{1}=\mathrm{R}_{2}$; therefore:


92CS-24866
Fig. 14-Frequency ratios.


Fig. 15 -Retiming circuit for $f_{1}$ and $f_{2}$

## Integration

The CD4527B and CD4089B rate multipliers can be used as digital integrators by feeding the output of the rate multiplier to the input of an up/down counter in the up-count mode only. The system will operate as an integrator if the input to the counter is in pulse form. Each pulse input to the counter acts as an increment with respect to time, so that the counter accumulates the pulse increments. If the counter is large enough, so that the delta increment represents only a small portion of the total counter contents, then the delta increment approaches a differential and the counter accumulates the integral of this differential over time. For example, assume that the counter output is $N(\mu)$ where $\mu$ represents the incremental pulse and is monotonically increasing. If each pulse at the input to the rate multiplier increases $\mu$ by one unit, and the frequency f is defined as $\mathrm{f}=\mathrm{d} \mu / \mathrm{dt}$, then the output of the rate multiplier is:

$$
\mathrm{K} \frac{\mathrm{~d} \mu}{\mathrm{dt}}=\mathrm{Kf}_{\mathrm{clk}}
$$

This relation is the same as that described above under the heading "Rate Multiplier Description".

If the output of the rate multiplier is supplied to the up-count input of the counter, then, at a given instant:

$$
K-\frac{\mathrm{d} \mu}{\mathrm{dt}}=\mathrm{N}(\mu)
$$

But the counter output $\mathrm{N}(\mu)$ is changing with time owing to its input $K-\frac{d \mu}{d t}$, thus:

$$
\mathrm{K} \frac{\mathrm{~d} \mu}{\mathrm{dt}}=\frac{\mathrm{dn}}{\mathrm{dt}}
$$

or

$$
\mathrm{Kd} \mu=\mathrm{dn}
$$

## Therefore

$$
\mathrm{N}(\mu)=\int_{0}^{\mu} \mathrm{K} \mathrm{~d} \mu
$$

Fig. 16 illustrates the principle of integration as described above. If the feedback loop scheme is used in Fig. 16 i.e., if $\mathrm{N}(\mu)$ is the program input A to the multiplier:



Fig. 16-Integration.
Therefore

$$
\frac{\mathrm{dA}}{\mathrm{~d} \mu}=\dot{\mathrm{A}}=\frac{1}{\mathrm{~K}^{\mathrm{n}}} \mu
$$

or

$$
\mathrm{A}=\mathrm{e}^{\mu / \mathrm{K}^{\mathrm{n}}}
$$

Thus, the rate multiplier can also be used to solve differential equations.

## Symmetric Rate Multiplication

In the previous discussion, the classic rate multiplier was used to produce an output pulse train whose period is not generally symmetrical. In many cases, the multiplication factor $1 / \mathrm{K}$ is not of the form $1 / 2^{\mathrm{n}}$ ( n integer); thus, a "round off" error is associated with the output signal. In fact, if the output waveform is observed on a spectrum analyzer, a Bessel distribution similar to that caused by an FM modulated signal will appear. In many applications where spectral purity is important, such harmonic and spurious outputs are intolerable.

There is a technique, the symmetric rate multiplication technique (SRM), that can be used to eliminate rate outputs with the above mentioned spectral characteristics. The SRM approach yields output rates with symmetrical duty cycles ( 50 percent) and no "round off" errors. The only limitation to the SRM technique is the clock frequency. However, in applications where limited numbers of frequencies are to be synthesized, the SRM approach works very well, and the clock or master osillator is not a controlling factor.

Consider the circuit shown in Fig. 17, where the input clock frequency $f_{c}$ is derived from an oscillator whose period is symmetrical ( 50 -percent duty cycle) and whose frequency is fixed. For simplicity, the multiplication factors programmed in are of the form $1 / \mathrm{K}$, where $1 \leqslant K \leqslant 9$. The final output frequency is:

$$
f_{\text {out }}=f_{c}\left(\frac{1}{K}\right)
$$

where $f_{\text {out }}$ is a frequency whose period is symmetrical. The multiplication factors $1 / \mathrm{K}$ are assumed to be available and stored for use at any given time as they are in the CD4527B.

When the K factor is selected, the corresponding AND gate is implemented, and the clock signal propagates through each divider stage except the $\div 6(\div 3$, and $\div 2)$ stages. These stages are bypassed, and the remainder, $R$, yields the numerator for the final result. Furthermore, the output waveform, $\mathrm{f}_{\text {out }}$, is symmetrical provided the $\div 3, \div 5$, and $\div 7$ stages are symmetrical dividers. Examples of $\div 3, \div 5$, and $\div 7$ symmetrical stages are shown in Figs. 18, 19, and 20, respectively.

A frequency synthesizer designed to generate the channel frequencies shown in Table I for use in a voice multiplex


Fig. 17-Symmetric rate multiplier for $1<K \leqslant 9$.
92CM-24877

In addition, two numbers, N and R , are defined: N is the lowest common multiple of the $K$ factors and $R$ is the product of the remaining K factors when one is chosen for rate multiplication. The output frequency then becomes:

$$
f_{\text {out }}=f_{c}\left(\frac{R}{N}\right)
$$

In Fig. 17, the number N is:

$$
\mathrm{N}=5 \cdot 7 \cdot 8 \cdot 9=2520
$$

Note that the $\div 2$ and $\div 3$ stages are included in $\div 8$ and $\div 9$. As an example, to multiply the clock $f_{c}$ by $1 / 6$ :

$$
\begin{aligned}
& \mathrm{N}=2520 \\
& \mathrm{R}=2 \cdot 2 \cdot 3 \cdot 5 \cdot 7
\end{aligned}
$$

and

$$
f_{\text {out }}=f_{c}\left(\frac{2 \cdot 2 \cdot 3 \cdot 5 \cdot 7}{2520}\right)=f_{c}\left(\frac{1}{6}\right)
$$


(a)

Fig. 18-(a) Symmetrical $\div 3$ and (b) timing diagram.


Fig. 18-(a) Symmetrical $\div 3$ and (b) timing diagram.


Fig. 19-(a) Symmetrical $\div 5$ and (b) timing diagram.


Fig. 20-(a) Symmetrical $\div 7$ and (b) timing diagram.
system up through the first (CCITT) group will demonstrate the SRM techniques. The numbers listed next to each channel frequency are the lowest common factors of that frequency.

In an application of this type, channel carriers must be spectrally pure (spurious emission $>70 \cdot \mathrm{~dB}$ down) and the phase jitter must be low (typically $\leqslant 1^{\circ}$ ). From a systems point of view, if these carriers do not meet requirements such as these, then other system (crosstalk) specifications cannot be met. If carriers are synthesized using the classic rate multiplier, then requirements such as those mentioned above will not be met unless measures are taken to remove spurious emission from the waveform after generation has taken place. For example, the voice carrier has a channel separation of 4 kHz , so that the unwanted sideband separation is 8 kHz . To eliminate spurious emission with this type of distribution requires a critical filter with a high Q (usually 4 coils, 9 poles). Suppression of FM jitter or noise is another problem altogether. The SRM approach minimizes that problem because:

1. Output frequencies synthesized by the SRM technique have 50 -percent duty cycles; thus, only odd harmonics exist, and these are easy to filter out.
2. The output has been derived from divider chains; thus, FM suppression by factors of $20 \log \mathrm{~N}$ will exist. For example, a $\div 2$ yields $20 \log 2$ or approximately 6 dB of suppression.

Table I indicates that dividers ranging from 2 to 31 are needed to synthesize the 28 carriers listed. To synthesize these frequencies, a clock whose LCM (lowest common multiple) is that of the desired frequencies is chosen; as described above,

Table I-Channel Frequencies

| Channel Freq. <br> (kHz) | Lowest Common Factors <br> (Divider Stages) |
| :---: | :--- |
| 28 | $2,2,7$ |
| 32 | $2,2,2,2,2$ |
| 36 | $2,2,3,3$ |
| 40 | $2,2,2,5$ |
| 44 | $2,2,11$ |
| 48 | $2,2,2,2,3$ |
| 52 | $2,2,13$ |
| 56 | $2,2,2,7$ |
| 60 | $2,2,3,5$ |
| 64 | $2,2,2,2,2,2$ |
| 68 | $2,2,17$ |
| 72 | $2,2,2,3,3$ |
| 76 | $2,2,19$ |
| 80 | $2,2,2,2,5$ |
| 84 | $2,2,3,7$ |
| 88 | $2,2,2,11$ |
| 92 | $2,2,23$ |
| 96 | $2,2,2,2,2,3$ |
| 100 | $2,2,5,5$ |
| 104 | $2,2,2,13$ |
| 108 | $2,2,3,3,3$ |
| 112 | $2,2,2,2,7$ |
| 116 | $2,2,29$ |
| 120 | $2,2,2,3,5$ |
| 124 | $2,2,31$ |
| 128 | $2,2,2,2,2,2,2$ |
| 132 | $2,2,3,11$ |
| 136 | $2,2,2,17$ |
|  | 2 |

the limiting factor of the SRM approach is the clock frequency. The table shows that the clock frequency increases as the number of frequencies to be synthesized increases. COS/MOS circuitry is used in this example, and since a COS/MOS device normally operates at $10 \mathrm{MHz}, \mathrm{f}_{\mathrm{clk}}$ will not exceed this frequency. Table II lists some of the many combinations that can be used to obtain channel carriers that can be synthesized with clock frequencies not exceeding 10 MHz ; those not listed can be obtained by a number of clock frequency choices. Using Table II, circuits similar to those shown in Fig. 17 can be constructed to implement this application.

Many possible LCM combinations can be used to implement the SRM technique, as illustrated; however, the common factors (dividers) must be bypassed in the synthesized frequency, and remainder ( R dividers) used to obtain the final result. For example, when 72 kHz is to be synthesized, the $\div 2, \div 2, \div 2, \div 3$, and $\div 3$ factors are bypassed and the $\div 2, \div 2, \div 2, \div 2, \div 3$, and $\div 5$ remainder used.

Table II - Channel Carriers Synthesizable with Clock Frequencies Not Exceeding 10 MHz

|  | Channel <br> Frequency <br> $(\mathrm{kHz})$ | Lowest Common <br> Factors <br> (Divider Stages) |
| :--- | :---: | :--- |
|  | 32 | $2,2,2,2,2$ |
|  | 36 | $2,2,3,3$ |
|  | 40 | $2,2,2,5$ |
| Clock $=5,760 \mathrm{kHz}$ | 48 | $2,2,2,2,3$ |
| LCM $=128 \cdot 9 \cdot 5=5,760$ | 60 | $2,2,3,5$ |
|  | 64 | $2,2,2,2,2,2$ |
|  | 72 | $2,2,2,3,3$ |
|  | 80 | $2,2,2,2,5$ |
|  | 96 | $2,2,2,2,2,3$ |
|  | 120 | $2,2,2,3,5$ |
|  | 128 | $2,2,2,2,2,2,2$ |
|  | 28 | $2,2,7$ |
| Clock $=3,696 \mathrm{kHz}$ | 44 | $2,2,11$ |
| LCM $=7 \cdot 11 \cdot 16 \cdot 3=3,696$ | 56 | $2,2,7$ |
|  | 84 | $2,2,3,7$ |
|  | 88 | $2,2,2,11$ |
|  | 112 | $2,2,2,2,7$ |
|  | 132 | $2,2,3,11$ |
|  | 52 | $2,2,13$ |
| Clock $=1,768 \mathrm{kHz}$ | 68 | $2,2,17$ |
| LCM $=8 \cdot 13 \cdot 17=1,768$ | 104 | $2,2,2,13$ |
|  | 136 | $2,2,2,17$ |

## SUMMARY

The COS / MOS rate multipliers CD4527B and CD4089B can be used to generate many digital functions. These MSI circuits are very useful as basic building blocks in low-power systems where minimum package count is desirable. Several of these applications, such as frequency synthesis and instrumentation, require low power and low package count to be competitive. Many arithmetic functions can also be performed by the COS/MOS rate multipliers with the aid of an up/down counter and some control logic. This feature is very useful in several areas of numeric control and digital processing systems. All of these features, and the fact that the CD4527B and CD4089B are part of the standard COS/MOS family of digital IC's, make these devices very useful to the design engineer.

## REFERENCES AND BIBLIOGRAPHY

1. A more detailed analysis of the cascade, strobe, $\mathrm{E}_{\mathrm{O}}, \mathrm{E}_{\mathrm{IN}}$, and " 9 " or " 15 " features can be found in the CD4527 or CD4089 data sheets.
2. RCA DATABOOK Series SSD-203B, "COS/MOS Digital Integrated Circuits," 1975.
3. A. R. Elliott, "A High-Speed Binary Rate Multiplier," Proceedings of the IEEE, August 1971, pp. 1256-1257.
4. Texas Instruments Application Note CA-160, "SN7497 Binary Rate Multiplier."
5. R. Phillips, "Many Digital Functions Can Be Generated," Electronic Design, 3, February 1968, pp. 82-85.
6. K. P. Rajappan, V.C.V. Pratapa Reddy, 'Decade Rate Multiplier," Proceedings Letters, February 1972, pp. 759.
7. J. B. Peatman, "The Design of Digital Systems," McGraw Hill, N. Y., 1972, pp. 359.

## Subject Index

## A

## Adders:

Full, 4-bit with parallel carry out
(technical data, File No. 503)
Triple, serial positive and negative logic types
(technical data, File No. 503)
AND-OR bi-phase pairs, COS/MOS triple
(technical data, File No. 576)
Analog or digital signals, transmission and multiplexing of (ICAN-6601)
AND-OR gates, COS/MOS, triple bi-phase pairs
(technical data, File No. 576)
AND-OR select gate COS/MOS quad (ICAN-6600)
AND-OR select gate, COS/MOS quad
(technical data, File No. 479)
Arithmetic unit, COS/MOS (ICAN-6600)
Circuit description (ICAN-6600)
Operation (ICAN-6600)
Performance data (ICAN-6600)
Arithmetic arrays, COS/MOS (ICAN-6600)
Arithmetic unit (ICAN-6210)
Arithmetic logic unit (ALU), 4-bit
(technical data, File No. 635)
Astable multivibrator, COS/MOS (ICAN-6267)

B
Bilateral switch, COS/MOS quad (ICAN-6601)
Digital control of signal gain, frequency, and impedance (ICAN-6601)
Features (ICAN-6601)
Logic functions (ICAN-6601)
Multiplexing/demultiplexing (ICAN-6601)
Operation (ICAN-6601)
Sample-hold applications (ICAN-6601)
Switch and logic applications (ICAN-6601)
Technical data (File No. 479)
Binary counter (ICAN-6166)
Bi-phase pairs, AND-OR, COS/MOS (technical data, File No. 576)
Buffer, COS/MOS quad, true/complement
(technical data, File No. 572)
Buffers/converters, COS/MOS hex
(technical data, file No. 479)
(technical data, File No. 599)
(technical data, File No. 804)
Buffer/converter, hex strobed
(Preliminary technical data)
Buffer, output (ICAN-6210)
Bus register, COS/MOS MSI, 8-stage
(technical data, File No. 575)

394
Page
Nos.
Page
Nos.

## C

Clocked D latch, COS/MOS quad
(technical data, File No. 589)
Clock/timer, battery-operated,
Digital-display, COS/MOS; Applications (ICAN-6733) 623
Circuit operation (ICAN-6733) 613
Display-driver circuits (ICAN-6733) 615
Performance characteristics (ICAN-6733) . 613
Clock Timer, 21-stage
(technical data, File No. 614) 222
Comparator:
Magnitude, 4-bit
(technical data, File No. 805) 313
Phase (ICAN-6716) 598
Conversion, digital-to-analog (ICAN-6000) 447
COS/MOS digital integrated circuits (Title page) 1
Applications information 441
Design and operating considerations 21-24
Family characteristics 31-424
Functional diagrams 8-18
Technical data 31-424
COS/MOS IC's for low-voltage Applications $\quad \mathbf{2 5 - 2 9}$
(technical data, File Nos. 479, 503) 32, 124
COS/MOS integrated circuits, general features
(File No. 479)
32
COS/MOS logic gates noise immunity of (ICAN-6176) 495
COS/MOS MIL-M-38510 CD4000A series types
COS/MOS power-supply considerations (ICAN-6576) 562
COS/MOS switch (ICAN-6080) 458
Counter, COS/MOS binary/ripple, 12-stage
(technical data, File No. 624)
200
Counter, COS/MOS, 21-stage (File No. 572) 205
Counters, COS/MOS, applications of:
Decade, 7-segment-output (ICAN-6733) 613
Divide-by-N (ICAN-6716) 601
Divide-by-R (ICAN-6716) 605
Divide-by-12 (ICAN-6733) 624
Divide-by-60 (ICAN-6733) 624
Fixed, single-stage, divide-by-N Programmable,
Multidecade, Divide-by-N (ICAN-6498)
Counter, COS/MOS, fixed and programmable,
Design of (ICAN-6498)
Counters, COS/MOS MSI, design and applications of (ICAN-6166)

479
$\begin{array}{ll}\text { Counters, COS/MOS (technical data): } \\ \text { Binary 7-stage (File No. 503) } & 124\end{array}$
Binary, 14-stage (File No. 479) 109
Binary, 14-stage with oscillator (File No. 813) 291
Decade (File No. 503) 130
Divide-by-N (File No. 479) 99
Divide-by- $N$, programmable (preliminary data)285

## Subject Index

| Counters, COS/MOS (technical data): (Cont'd) | Page Nos. | Down-converter, heterodyne, COS/MOS (ICAN-6716) | Page <br> Nos. <br> 599 |
| :---: | :---: | :---: | :---: |
| Up/down, presettable (File No. 503) | 150 | Driver, liquid crystal |  |
| Up-counter, Dual BCD (File No. 808) | 407 | (technical data, File No. 634) | 267 |
| Up-counter, Dual Binary (File No. 808) | 407 | Driver circuits for digital displays, types of |  |
| Counters/dividers, COS/MOS, applications of: |  | (ICAN-6733) | 615 |
| Decade (ICAN-6166) | 485 | D-type latch, clocked, COS/MOS quad |  |
| Divide-by-8 (ICAN-6166) | 486 | (technical data, File No. 589) | 212 |
| Crosstalk (ICAN-6176) | 495 |  |  |
|  |  | E |  |
| D |  |  |  |
|  |  | Encoder, 8-input priority |  |
| Data-gathering and processing system (ICAN-6210) | 503 | (preliminary Technical data) | 417 |
| Arithmetic unit (ICAN-6210) | 508 |  |  |
| Control unit (ICAN-6210) | 512 | F |  |
| Description (ICAN-6210) | 503 |  |  |
| Digital processor (ICAN-6210) | 505 | Flip-flop, COS/MOS dual D-type: |  |
| Input signal conditioning and |  | Technical data (File No. 479) | 70 |
| transmission (ICAN-6210) | 504 | Use of in arithmetic unit (ICAN-6600) | 568 |
| Memory (ICAN-6210) | 507 | Flip-flop, COS/MOS dual J-K master-slave |  |
| Output buffer (ICAN-6210) | 510 | (technical data, File No. 503) | 139 |
| Output transmitter (ICAN-6210) <br> Receiver (ICAN-6210) | 510 506,511 | Flip-flop, gated J-K M-S type |  |
| Decoder, COS/MOS, BCD-to-decimal, Binary to octal (technical data, File No. 503) | 506,511 | (Preliminary technical data) <br> Fluorescent readouts, low-voltage vacuum (ICAN-6733) | 386 622 |
| Decoder, 4-bit latch/ 4 to 16 line (technical data, File No. 814) | 401 | FM receiver synthesizers, COS/MOS (ICAN-6716) | 598 |
| Decoder/Driver, 7 -segment display (technical data, File No. 503) |  | Prescaler system design (ICAN-6716) | 598 |
|  | 130 | System requirements (ICAN-6716) <br> FM synthesizer system, COS/MOS (ICAN-6716) | 598 |
| Decoder/Driver, BCD to 7-Segment latch (Preliminay data) | 398 | Frequency multipliers, COS/MOS (ICAN-6267) | 538 |
| Decoder/Demultiplexer, dual 1-of-4 |  | Full adder, COS/MOS four-bit: |  |
| (technical data, File No. 858) | 419 | Technical data (File No. 479) | 50 |
| Digital-clock prototypes, COS/MOS (ICAN-6733) | 625 | Use in arithmetic unit (ICAN-660) |  |
| Digital-display clock, COS/MOS (ICAN-6733) | 613 |  |  |
|  | 674 | G |  |
| Digital-display devices (ICAN-6733) | 617 |  |  |
| Digital-display metering application, |  | Gates: |  |
| COS/MOS (ICAN-6733) | 613 | AND, dual 4-input |  |
| Digital-display timer, COS/MOS (ICAN-6733) | 613 | AND, quad 2-input |  |
| Digital frequency synthesizer, COS/MOS (ICAN-6716) | 598 | AND, triple 3-input |  |
| Digital meter applications, COS/MOS (ICAN-6733) | 630 | (technical data, File No. 806) | 348 |
| Digital signals, transmission and multiplexing of (ICAN-6601) | 579 | AND-OR bi-phase pairs, triple (technical data, File No. 576) | 195 |
| Digital timer/clock/watch applications, |  | AND-OR-Invert (AOI) dual 2 wide, 2-input (technical data, File No. 811) | 362 |
| Digital-to-analog conversion, general |  | AND-OR-Invert (AOI) expandable 4-wide, 2-input (technical data, File No. 812) | 368 |
| Digital-to-analog converter, COS/MOS (ICAN-6080) 457 |  | AND-OR-Select, quad (technical data, File No. 479) | 104 |
| Digital-to-analog switch, COS/MOS (ICAN-6080) 453 |  | Dual complementary pair plus inverter |  |
| Down-conversion, heterodyne (ICAN-6716) | 598,608 | (technical data, File No. 479) | 44 |


| Gates: (Cont'd). |  |
| :---: | :---: |
| Multifunctional, 8 input, expandable (technical data, File No. 636) | 245 |
| Exclusive-NOR, quad 2-input (preliminary technical data) | 340 |
| Exclusive-OR, quad 2-input (technical data, File No. 503) | 157 |
| Exclusive-OR, quad 2-input (preliminary technical data) | 340 |
| NAND, 8-input (technical data, File No. 809) | 329 |
| NAND, quad 2-input (technical data, File No. 479) | 63 |
| NAND, quad 2-input (ICAN-6600) | 568 |
| NOR, 8-input (technical data, File No. 810) | 357 |
| NOR, quad 2-input (technical data, File No. 479) | 32 |
| NOR, quad 2 -input (ICAN-6600) OR, dual 4-input | 568 |
| OR, triple 3-input (technical data, File No. 807) | 342 |
| Gate-oxide protection circuit (ICAN-6218) | 514 |
| Ground-line noise (ICAN-6716) | 598 |
| H |  |
| Heterodyne down-conversion (ICAN-6716) | 600,610 |
| I |  |
| Incandescents readouts (ICAN-6733) | 621 |
| Interfacing of COS/MOS devices (ICAN-6602) | 586 |
| Active pull-ups (ICAN-6602) | 588 |
| Bipolar driving COS/MOS (ICAN-6602) | 588 |
| COS/MOS-bipolar HTL interface (ICAN-6602) | 591 |
| COS/MOS driving bipolar (ICAN-6602) | 589 |
| COS/MOS-ECL/ECCSL interface (ICAN-6602) | 595 |
| COS/MOS-to-N-MOS interface (ICAN-6602) | 597 |
| COS/MOS-to-P-MOS interface (ICAN-6602) | 596 |
| COS/MOS-TTL/DTL interface (ICAN-6602) | 586 |
| Current sinking (ICAN-6602) | 587, 590 |
| Current sourcing (ICAN-6602) | 587, 590 |
| Level shifters (ICAN-6602) | 595 |
| Resistor, pull-up (ICAN-6602) | 587 |
| Ladder networks, resistance (ICAN-6080) | 453 |
| Latch, addressable 8-input (preliminary technical data) | 392 |
| Latch, COS/MOS quad, clocked D (technical data, File No. 589 | 212 |

## Subject Index

|  | Page Nos. |  | Page Nos. |
| :---: | :---: | :---: | :---: |
| NAND R/S latch, 3 -state COS/MOS |  | Preset-channel memory, COS/MOS (ICAN-6716) | 611 |
| quad (technical data, File No. 590) | 216 | Processor, digital (ICAN-6210) | 505 |
| Noise immunity (of COS/MOS logic gates): |  | Program-switch (" N "-select) options (ICAN-6498) | 561 |
| (ICAN-6176) | 495 | Protection circuit COS/MOS gate-oxide (ICAN-6218) | 514 |
| Crosstalk noise immunity (ICAN-6176) | 499 | Pull-up resistor (ICAN-6602) | 587 |
| External noise immunity, signal-line (ICAN-6167) | 496 | Pulse-width circuit, COS/MOS voltage- |  |
| Ground-line noise immunity (ICAN-6176) | 499 | controlled (ICAN-6267) | 537 |
| Power-supply noise immunity (ICAN-6176) | 497 |  |  |
| Types of noise (ICAN-6176) | 495 |  |  |
| NOR gates, COS/MOS quad 2-input (ICAN-6600) | 569 | Q |  |
| NOR gates (positive logic), COS/MOS (technical data, File No. 479) | 32 | Quiescent dissipation (of COS/MOS devices) (ICAN-6576) | 562 |
| NOR R/S latch, COS/MOS quad, 3 state (technical data, File No. 590) | 216 |  |  |
| Numitron devices (ICAN-6733) | 621 | R |  |
| 0 |  | RAM, COS/MOS, binary, 4-word, 8-bit (techanical data), (File No. 613) | 188 |
| Oscillators, COS/MOS astable and monostable: |  | Read-only-memory, COS/MOS (technical data), (File No. 613) | 188 |
| Astable multivibrator circuits (ICAN-6267) | 531 | Readouts, incandescent (ICAN-6733) | 621 |
| Applications (ICAN-6267) | 537 | Receiver synthesizer, COS/MOS FM (ICAN-6716) | 601 |
| Compensation for 50 -per-cent duty cycle (ICAN-6267) | 535 | Register, 4-bit D-type storage, 3 state outputs (preliminary technical data) | 354 |
| Monostable multivibrator circuits (ICAN-6267) | 534 | Registers, COS/MOS MSI, design and |  |
| Oscillator, COS/MOS crystal-controlled (ICAN-6716) | 608 | application (ICAN-6166) | 479 |
| Oscillator, COS/MOS phase-locked, |  | Resistance ladder networks (ICAN-6080) | 453 |
| voltage-controlled (ICAN-6267) | 537 | Resistance networks for DAC's (ICAN-6080) | 453 |
| Oscillator, COS/MOS voltage-controlled |  | Resistor, pull-up (ICAN-6602) | 587 |
| (ICAN-6267) | 537 | R/S latches, COS/MOS quad 3-state |  |
|  | '. | (technical data), (File No. 590) | 216 |
| P |  |  |  |
|  |  | S |  |
| Phase comparator, COS/MOS (ICAN-6166) | 479 |  |  |
| Phase-locked loop, fundamentals of (ICAN-6101) | 471 | Schmitt Trigger, Quad 2-input NAND type |  |
| Phase-locked loops, practical digital types |  | (technical data, File No. 836) | 378 |
| (ICAN-6101) | 472 | Serial adder, COS/MOS triple |  |
| Phase-locked loop (technical data, File No. 637) | 227 | (technical data), (File No. 503) | 168 |
| Power-line noise (ICAN-6176) | 495 | Shift register, Dynamic 200-stage |  |
| Power supply considerations for COS/MOS devices: |  | (technical data, File No. 816) | 305 |
| AC dissipation characteristics (ICAN-6576) | 562 | Shift register, static, COS/MOS |  |
| AC performance characteristics (ICAN-6576) | 564 | MSI (technical data), (File No. 575) | 173 |
| Filtering requirements (ICAN-6576) | 566 | Shift register, COS/MOS, parallel-in, |  |
| High dc source (ICAN-6576) | 567 | parallel-out, 4-stage (technical data) |  |
| Quiescent dissipation (ICAN-6576) | 562 | (File No. 568) | 181 |
| Regulation requirements (ICAN-6576) | 566 | Shift register, COS/MOS dual 4-stage serial- |  |
| System power, calculation of (ICAN-6576) | 565 | input/parallel-output, static (ICAN-6166) | 490 |
| Switching characteristics (ICAN-6576) | 565 | (technical data, File No. 479) | 81 |
| Power Supplies for COS/MOS (ICAN-6304) | 551 | Shift register, COS/MOS 8-stage, |  |
| Prescaler, COS/MOS (ICAN-6716) | 599 | asynchronous, parallel-input/serial |  |
| Prescaling (ICAN-6716) | 599 | output static (ICAN-6166) | 492 |

Shift register, COS/MOS 8-stage static (technical data), (File No. 479)
Shift register, COS/MOS, 18 -stage static (ICAN-6166)
Shift register, COS/MOS 18-stage (technical data), (File No. 479)
Shift register, static COS/MOS 64-stage (technical data), File No. 569)
Shift register, 8 -stage shift-and-store 3-state outputs (Preliminary technical data).
Squelch control, COS/MOS (ICAN-6602)
Static shift register, COS/MOS MSI, 8-stage (technical data), (File No. 575)
Static shift register, COS/MOS, 64-stage (technical data), (File No. 569)
Switch, COS/MOS (ICAN-6080)
Synthesizer system, FM (ICAN-6716)

| Page <br> Nos. | T | Page |
| ---: | :--- | ---: |
| 76 | Nos. |  |
| 490 | Timer, COS/MOS, battery-operated, <br> digital-display (ICAN-6733) <br> Transistor array, integrated-circuit high-current, <br> n-p-n, display-driver applications of (ICAN-6733) <br> Transmission of analog and digital signals <br> (ICAN-6101) | 617 |
| 162 | Transmission-line reflections (ICAN-6176) <br> Transmitter, output (ICAN-6210) | 471 |
| 384 | True/complement buffer, COS/MOS quad <br> (technical data, File No. 572) | 495 |
| 586 | 510 |  |
| 173 | V | 205 |
| 162 | VCO, phase-locked (ICAN-6267) <br> Voltage-controlled oscillators (ICAN-6267) <br> Voltage-follower amplifier, COS/MOS (ICAN-6080) | 455 |


[^0]:    ${ }^{4}$ Maximum noise-free low-level Bipolar output voltage.
    $\neq$ Minimum noise-free high-level Bipolar output voltage.

    - See Appendix.

[^1]:    * Limit determined by minimum feasible leakage measurement for automatic testing.

[^2]:    When the Parallel/Serial Control input is "high", data is jammed into the 8 -stage register via the parallel input lines asynchronously with the clock line.
    Register expansion is possible using additional CD4021A packages.

[^3]:    * Formerly developmental type TA5385C.

[^4]:    - Formerly developmental type TA5677.

[^5]:    A Formerly developmental type TA5873.

[^6]:    If more than one unit is cascaded, $\mathrm{t}_{\mathrm{r}} \mathrm{CL}$ should be made less than or equal to the sum of the fixed propagation delay at 15 pF (see chart above) and the transition time of the output driving stage for the estimated capacitive load.

[^7]:    * Outputs change at positive transition of clock in the serial mode and when the $A / S$ control input is "low" in the parallel mode.

[^8]:    *Formerly developmental type TA5876

[^9]:    ${ }^{+}$Bit inputs driven from low-impedance driver.

[^10]:    * Input Pulse to Reset of External Counting Chip External Counting Chip Output to Terminal 4
    A See Text.

[^11]:    * When the devices are used as demultiplexers, the "CHANNEL IN/ OUT" terminals are the outputs and the "COMMON OUT/IN" terminal(s) is (are) the input(s).

[^12]:    * See operating precautions, above.

[^13]:    - Square wave
    $\triangle$ Symmetrical about 0 volts.

[^14]:    ＊The pin designations are compatible with other static 256 －Bit memories and are，therefore，not compatible with standard COS／MOS CD4000A－series devices；i．e．$V_{D D}$ is pin 5 and $V_{S S}$ is pin 4.

[^15]:    *See "Symbol Definitions"

[^16]:    ${ }^{4}$ Symmetrical about 0 volts.

[^17]:    ＊An output bit may be filled in in this counter state by a less significant CD4089B cascaded in the Add mode．

[^18]:    MAXIMUM RATINGS，Absolute－Maximum Values：
    STORAGE－TEMPERATURE RANGE．．．．．．．．．．．-65 to $+150^{\circ} \mathrm{C}$ OPERATING－TEMPERATURE RANGE．．．．．．．．-40 to $+85{ }^{\circ} \mathrm{C}$ DC SUPPLY－VOLTAGE RANGE：
    （VDD＊）．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．-0.5 to +18 V
    DEVICE DISSIPATION（PER PACKAGE）．．．．．．． 200 mW
    ALL INPUTS ．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．．$v_{S S} \leqslant v_{1} \leqslant v_{D D}$ LEAD TEMPERATURE（DURING SOLDERING）

    At distance $1 / 16 \pm 1 / 32 \mathrm{in}$ ．$(1.59 \pm 0.79 \mathrm{~mm})$ from case for 10 s max．
    $+265^{\circ} \mathrm{C}$
    ＊All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal．

[^19]:    * All voltage values are referenced to $\mathrm{V}_{\mathrm{SS}}$ terminal.

[^20]:    *Circled numbers refer to times indicated on master timing diagram.

[^21]:    * Formerly CD4091A \& CD4092A, respectively.

[^22]:    When these devices are supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed 0.013".

[^23]:    *Trade Mark: Emerson and Cumming, Inc.

[^24]:    －1－megohm series resistor．

[^25]:    ${ }^{1}$ See Table II for sources of anti－static materials．

[^26]:    * This voltage may be difficult to measure depending on accuracy, resolution, and offset voltage of test equipment used. Although device output " 1 " or " 0 " limits to which RCA tests in manufacture are 10 millivolts, a value of 50 millivolts may be used for customer measurements without compromise of device quality or system performance.

[^27]:    *For data, see bulletin File No. 479.

[^28]:    - COS/MOS Quad True/Complement Buffer
    ${ }^{\Delta}$ For data, see bulletin File No. 619.
    ${ }^{-}$For data, see bulletin File No. 341.

[^29]:    * See Ref. 5

[^30]:    $\mathrm{R}_{\mathrm{tc}}=0.4 \mathrm{megohm}, \mathrm{C}_{\mathrm{tc}}=1000 \mathrm{pF}, \mathrm{R}_{\mathrm{s}}=0.8 \mathrm{megohm}$

[^31]:    * CD4004A has been superseded by CD4024A.

[^32]:    * If the CD4059A (Preliminary) is employed, $K$ must be increased from 20 to 40 and other loop parameters adjusted accordingly. Also, the CD4059A (Preliminary) is controlled using BCD-coded switches.

